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Volume 1

4705

AUTOCAL MULTIFUNCTION CALIBRATOR

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CALIBRATION AND SERVICING HANDBOOK

for

THE DATRON 4705

AUTOCAL MULTIFUNCTION CALIBRATOR

Volume 1

Part 1 Calibration and Servicing Information

Part 2 Technical Descriptions

850063

Issue 1 (December 1987)

For any assistance contact your nearest Datron Sales and Service Center. Addresses can be found at the back of this handbook.

Due to our policy of continuously updating our products, this handbook may contain minor differences in specification, components and circuit design to the instrument actually supplied. Amendment sheets precisely matched to your instrument serial number are available on request.

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THIS INSTRUMENT IS CAPABLE OF DELIVERING A LETHAL ELECTRIC SHOCK !



FRONT or REAR terminals carry the Full Output Voltage. THIS CAN KILL!



Guard terminal is sensitive to over-voltage

It can damage your instrument!

Unless **you** are **sure** that it is **safe** to do so, **DO NOT TOUCH** the **I+ I- Hi** or **Lo leads** and **terminals**

DANGER

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Servicing Diagrams and Component Lists	Refer to Volume 2
General Description, Installation, Controls, Connections and Operation;	Refer to
Applications, Specification and Specification Verification	User's Handbook

PART 1 CALIBRATION AND SERVICING INFORMATION

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PART 1

CALIBRATION AND SERVICING INFORMATION

SECTION 1	Calibration.
SECTION 2	Fault Diagnosis
SECTION 3	Dismantling and Reassembly.
SECTION 4	Servicing and Internal Adjustments.

SECTION 1 CALIBRATION

(User's are recommended to have first completed the Verification procedures in Section 7 of the User's Handbook.)

1.1 GUIDE TO ROUTINE CALIBRATION

Circumstances Calling For Subsequent Recalibration

SCHEDULED RECALIBRATION

Routine calibration is carried out from the front panel, avoiding thermal disturbance and allowing immediate return to use. The 4705 is fully calibrated before leaving the factory. The specifications for the 4705 are based on standard intervals of up to 24 hours, 90 days or 1 year from calibration. Some users will wish to maintain the highest accuracy by recalibrating at short intervals (e.g. every 24 hours). In these cases, recalibration becomes a routine task. For this reason, Routine Autocalibration procedures are also explained in Section 8 of the User's Handbook.

Users may wish to choose alternative schemes, accounting for:

- · The accuracy required when in use,
- The instrument specifications (User's Handbook Section 6)
- The scheduled calibration intervals normally adopted by the user's organization

The Routine Calibration procedures are sufficient for all normal recalibration purposes, except when Pre-cal is called for (*Refer to Table 1.1*).

RESTANDARDIZATION

Occasions may arise when it is necessary to trim the instrument's internal Master Reference. For example, when the 4705 is to be made traceable to a different National Standard, after transportation from one country to another (*Refer to AUTOCAL FACILITIES page 1-3*).

CALIBRATION MEMORY CORRUPTION

Battery Change

Calibration corrections are stored in an internal memory which remains energized by a battery. The Lithium battery which powers the non-volatile calibration memory should be replaced after 5 years (*Refer to Section 4.3*). After replacement, a full Pre-calibration is required followed by a complete Routine Autocalibration.

Memory Check failure

When cal is pressed the constant is checked to be within prescribed limits before being stored. Values outside prescribed limits flag a *Fail 6*. The same check is performed:

- · When the instrument is powered-up
- Each time the output is switched ON
- During each self-test routine

CRITICAL PART CHANGES

Recalibration (or Verification) is necessary after replacement of a critical PCB assembly or a critical component. These are listed in Table 1.1 (*see flap of page 1-1*), indicating the extent of the recalibration necessary.

Ohms Internal Adjustments

- If the Power Supply/Current Heatsink has been changed it may be necessary to adjust the quiescent bias current (IQ) by internal adjustment. Refer to *Section 4.7* for further information.
- If a standard resistor value has been changed by subjecting to undue stress, it may be possible to recalibrate by internal adjustment. Refer to *Section 4.4* for further information.

Recalibration Procedures in this Section

ROUTINE AUTOCALIBRATION

The Routine Calibration procedures are sufficient for all normal recalibration purposes, except when Pre-cal is called for (*refer to Table 1.1 on flap of page 1-1*).

REMOTE CALIBRATION OVER THE IEEE 488 BUS

The device-dependent commands necessary for routine calibration of the instrument over the IEEE 488 bus are described as a supplement to Section 5 of the User's Handbook. A guide line example is given, but this needs to be adapted for the bus controller in use.

PRE-CALIBRATION PROCEDURES

In an initial internal calibration process at manufacture, certain 'Precal' parameters are established in a special calibration memory.

Under certain conditions (detailed in Table 1.1) these parameters need to be re-established by completing the 'Pre-Cal' procedure <u>before</u> a Full Routine Autocalibration.

Assembly	Components Replaced	Calibration Required
Digital	Complete Assembly	Pre- & Routine Calibration
		Pre- & Routine Calibration
(11.2)	Lithium Battery (Sect. 4.3)	
	Non-volatile RAM (M10/M23)	Pre- & Routine Calibration
	Non-volatile RAM Supply	Pre- & Routine Calibration
	commutator components	
Reference	Complete Assembly	Pre- & Routine Calibration
Divider	Defense a Area while (dd 4 7)	Due & Deutine Onlikestier
(11.4)	Reference Assembly (11.4-7)	Pre- & Routine Calibration
	Any set of main, guard or	Pre- & Routine Calibration
	LSD switch FET's	
	Reference Buffer	Pre- & Routine Calibration
	Switch Driver Flip Flops or	Pre- & Routine Calibration
	their preselected resistors	
	R79	Pre- & Routine Calibration
DC	Complete Assembly	DC (All Ranges) only.
Assembly	1V attenuator R73/R74	DC (1V, 100mV, 10mV,
(11.5)	1 v allonualUI 11/ U/11/4	1mV, 100µV Ranges) only.
	100mV attenuator R69/70/71	DC (100mV, 10mV, 1mV,
	72/75/76	100μV Ranges) only.
	100V/1000V attenuator	
	R8/9/25/26/46/47/64/65	DC (100V, 1000V Ranges)
	88/95/98	only.
Sine	Complete Assembly	Specification Verification at
Source		User's Discretion
(11.6)		
AC	Complete Assembly	Routine Calibration
(11.7)		
	Sense Amplifier	Routine Calibration
	Reference Inverter	Routine Calibration
	AC/DC Transfer & Integrators	Routine Calibration
[/Ω	Complete Assembly	I/Ω
(11.8)	(N.B. Internal Adjustment	
	required, refer to Section 4.5)	
		Dat
	+10 attenuator (R43/44) (DCI function)	DCI
	. ,	
1	Current shunts	DCI
	R8/9/10/79/80	
	(DCI function)	
	M8 and associated components	ACI
	Current Shunts	
	Feedback resistor R45	
	Standard Resistors, associated	I/Ω
	pre-selected/variable trimmer	internal adjustment (Section 1.5)
	resistors (Ω function)	Ω calibration (replaced values only)
All Other Assessed 1		
MUUTIER ASSembli	es Not Listed Above	Specification Verification

PREPARING THE 4705

Before any calibration is carried out, prepare the 4705 as follows:

- 1. Turn on and allow a minimum of 4 hours to warm up in the specified environment.
- 2. Cancel any MODE keys, ensure OUTPUT set to OFF.
- 3. IEEE 488 Address switch: Set to ADD 11111 (Address 31) unless the 4705 is to be calibrated vial the IEEE 488 interface.
- 4. CALIBRATION ENABLE key switch: Insert Calibration Key and turn to ENABLE.

These actions activate the four calibration modes (labelled in **red**), and present the **cal** legend on the MODE display.

Caution

Inadvertent use of the cal key will overwrite the calibration memory!

CAUTION:

Re-configuration of measurement circuitry should only be attempted when all voltage sources are OUTPUT OFF.

Before setting OUTPUT ON ensure the correct polarities have been selected and that any measurement device has been set to low sensitivity.

NOTE

The message Error 3 appears on the MODE display for any attempt to select an inappropriate mode.

RETURNING THE 4705 TO USE

When any calibration is completed, return the 4705 to use as follows:

- 1. Ensure that OUTPUT OFF LED is lit.
- 2. CALIBRATION ENABLE key switch: Turn to **RUN** and withdraw calibration key.
- 3. IEEE 488 Address switch: Restore to correct address if the 4705 is to be used in an IEEE 488 system.

The cal legend and calibration modes are deactivated.

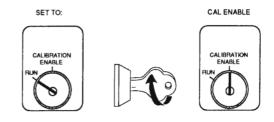


ADD 11111 (ADDRESS 31)

IEEE 488 ADDRESS

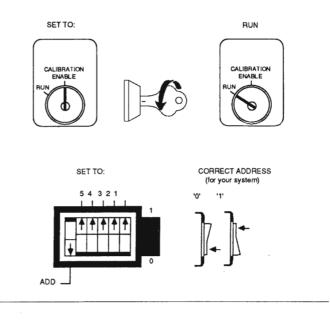
SET TO

54321



WARNING:

Terminals marked with the symbol carry the output of the 4705. These terminals and any other connections to the load under test could carry lethal voltages. Under no circumstances should users touch any of the front (or rear) panel terminals unless they are first satisfied that no dangerous voltage is present.



EQUIPMENT REQUIREMENTS

Before removing the 4705 from service check that the necessary calibration equipment is available. The equipment summary, listed by function, relates to the procedures recommended in this handbook:

Caution

When choosing a set of current shunts ensure that their power dissipation ratings are sufficient to avoid permanent degradation from the self-heating effects of the current being checked. This applies particularly to the 1 Amp shunt.

DC FUNCTION

Low Voltage (100mV to 10V) An adjustable Voltage source of suitable accuracy Example: Datron 4000A

A battery-operated null detector with variable sensitivity, able to withstand 1200V across its input terminals: Example: Keithley Instruments Model 155

High voltage (100V and 1000V) A Precision Divider Example: Datron 4902/s High Voltage Divider.

A battery-operated null detector with variable sensitivity, able to withstand 1200V across its input terminals: Example: Keithley Instruments Model 155

Current (100µA to 1A) A DC Voltmeter, of suitable accuracy standardized at 1V and 100mV. Example: Datron 1081 (or 1071 using 'compute' mode).

A set of calibrated current shunts of suitable accuracy.

AC FUNCTION

Voltage (1V to 1000V) An Adjustable DC Voltage Source of suitable accuracy. Example: Datron 4000 or 4000A Autocal Standard.

An AC/DC Thermal Transfer Standard capable of operating over the range 1V to 1100V RMS.

2-wire HF compensation (1V to 10V) An AC DVM of suitable accuracy Example: Datron 1081

Millivolts at LF(1mV to 100mV) A commercially-available Inductive Voltage Divider of suitable accuracy and frequency response; with ratios of 10:1, 100:1 and 1000:1.

An AC DVM of suitable accuracy and frequency response. Example: Datron 1081 or similar.

Millivolts at HF (1mV to 100mV) An AC DVM of suitable accuracy and frequency response. Example: Datron 1081 or similar. Current (1mA to 1A) A DC Current Source of suitable accuracy. Example: Datron 4000 or 4000A

AC/DC Thermal Transfer and a set of Calibrated Thermal-Transfer Current Shunts of suitable accuracy. Example: Tinsley 5685 or Holt HCS-1 AC/DC Standard resistors.

An AC/DC transfer switching unit Example: Holt HCS-1

Current (1µA to 1A) A set of calibrated AC Shunts of suitable value and accuracy. Example: Tinsley 5685 or Holt HCS-1 AC/DC Standard resistors.

An AC DVM of suitable accuracy and frequency response. Example: Datron 1081 or alternatively Datron 1071 using 'compute' mode.

A Buffer capable of operating with negligible errors from DC to 5kHz at a 1Volt level

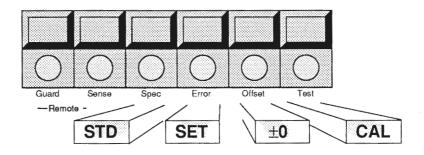
RESISTANCE

2-Wire & 4-Wire (10Ω to $100M\Omega$) A set of standard resistors covering 10Ω to $100M\Omega$. The 10Ω to $10k\Omega$ should be 4-wire type.

An accurate resistance bridge, or other ratiometric device for measuring resistance to the required accuracy.

A Datron 1071 used as a transfer-measurement device.

AUTOCAL FACILITIES



These keys are activated by two rear panel switches (*refer to flap of page 1-2 'Preparing the 4705'*). When these modes are active, the legend 'cal' is presented on the MODE display.

The following is a general description of the facilities available. For specific information see the introduction proceeding each of the function's calibration routines.

CAL

The 4705 assumes that the selected range is to be calibrated at the exact Full Range value or at Zero. The instrument decides on 'Zero Offset' or 'Full Range Gain' from the OUTPUT display value (defined by the same limits as for 'SET'), and executes the calibration. If the value initially set on the OUTPUT display is below 2% of Full Range value, the instrument assumes that an offset calibration is requested, and if at 2% or above, a gain calibation is assumed.

CAL (with pre-selection)

If the CAL key is pressed after first pressing STD SET or ± 0 . The CAL key executes, then cancels, the preselected AUTOCAL mode.

Caution

The following keys preselect an AUTOCAL mode, modifying the action of the 'CAL' key.

SET

The SET key allows gain or offset calibration to a Calibration Standard value which cannot be adjusted to a nominal Full Range value or to absolute zero.

Before selecting SET, the $\hat{\parallel}$ keys are operated to place the Calibration Standard value on the OUTPUT display and set the 4705 output level.

Pressing SET then informs the 4705 that calibration is to be carried out at this value. The instrument acknowledges by duplicating the value on the MODE display.

Next, the \iint keys are manipulated to null the 4705 output against the Calibration Standard (the OUTPUT display changes during this adjustment).

Pressing the CAL key executes the calibration. The 4705 memorizes the difference between the two display values, and exits from SET mode. This is shown by transfer of the Standard value from the MODE display to the OUTPUT display. The instrument uses the difference to modify stored constants, which in 'RUN' mode correct both positive and negative outputs on the calibrated range only.

 ± 0

The ± 0 key is used to align the ON+ and ON- zeros of all DC voltage and current ranges, by a two part calibration on the 10V range. It is only necessary when the ON+ and ON- zeros of the 10V range do <u>not</u> coincide at the same null. Available in DC function only.

STD

The STD key allows a user to re-standardize by trimming the value of the internal Master Reference voltage effectively changing the gain of all DC voltage and current ranges in the same ratio. The facility can be used to avoid a full recalibration of the 4705 when Laboratory References have been re-standardized (for instance when the instrument has been moved from one country to another).

First check ± 0 Alignment. The STD calibration is carried out on either the 1V or 10V range, using the DC Low Voltage procedure. Select STD after placing the Calibration standard value on the OUTPUT display. Continue the routine from step (l.). Procedurally STD differs from SET only in the use of the STD key instead of the SET key.

Caution

Using the 'STD' key changes the gain of all voltage and current ranges

INTERCONNECTIONS

It is recognised that interconnection instructions may need to be adapted to meet an individual user's requirements. It is assumed that users will possess some knowledge of the operation and use of standards equipment.

SENSE AVAILABILITY AS FOLLOWS

1V 10V 100V 1000V	-	Local/Remote Sense
1mV 10mV 100mV	-	Local Sense only
All current ranges	-	not applicable
(Local: 2-wire sense,	Remote:	4-wire sense)

Output must be OFF to change sense connection (except that Remote changes automatically to Local when switching to Millivolt Ranges).

OUTPUT OFF DEFAULT WHEN UPRANGING

The 4705 cannot enter High-Voltage state with OUTPUT ON. Consequently, when ranging-up, the operating system allows the upranging to occur, but defaults to OUTPUT OFF for two specific cases:

- When upranging to the 1000V Range
- When upranging to the 100V Range; To a voltage of 90V or more on DC To a voltage of 75V or more on AC

Otherwise, OUTPUT remains ON when changing OUTPUT RANGE (refer to User's Handbook Section 4, pages 4-7 to 4-9).

GENERAL PROCEDURE

Prepare the instrument for calibration (refer to 'Preparing the 4705' procedure on flap of page 1-2). The message Error 3 appears on the MODE display for any attempt to select an inappropriate mode. Select the equipment and procedures to be used. Set all sources to zero and all measurment devices to low sensitivity and configure using the interconnection diagram provided. If calibrating DC function, start with ± 0 Alignment check routine. When all calibration has been completed use the 'Return to Use' routine on the Throwclear page.

Calibration Routine

Set the 4705 to OUTPUT ON and Full Range value. Adjust the 4705 output to equal the calibration standard and press 'cal'. The OUTPUT display changes to nominal.

Calibration Routine (with preselection)

The OUTPUT display is set to the Calibration Standard value, the 4705 output is switched ON, and one of the calibration mode preselector keys (STD, SET or ± 0) is pressed. The 4705 output is adjusted to equal the Calibration Standard value, and the CAL key is pressed to execute the calibration.

1.2 DC CALIBRATION

1.2.1 Zero Calibrations

The following procedures are available;

±0 ALIGNMENT CHECK ±0 CALIBRATION RANGE ZERO CALIBRATION

±0 ALIGNMENT CHECK

 ± 0 alignment can be checked without affecting the stored constants. If necessary recalibrate before proceeding with DC Range Zero, DC Voltage, DC Current or DC Current Range Zero calibration (*refer to Appendix 2 - Calibration Source Zero Offsets*).

NOTE

For alignment checks only, set the security keyswitch to RUN.

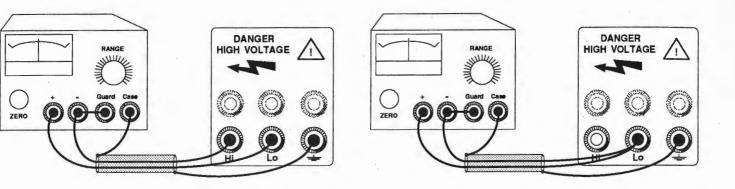
±0 CALIBRATION

The ± 0 key is used to align the ON+ and ON- zeros of all DC voltage and current ranges, by a two part calibration on the 10V range. It is only necessary when the ON+ and ON- zeros of the 10V range do not coincide at the same null. Available in DC function only.

RANGE ZERO CALIBRATION

All the procedures for DC Gain calibration take into account the zero offsets. However a Range Zero calibration will allow the 4705 ON+ zero output to be set as close as possible to absolute zero. The procedure adjusts each range to a null detected across the sense 'Hi' and 'Lo' terminals.

±0 ALIGNMENT CHECK



4705 ON+ & ON- ALIGNMENT MEASUREMENT

NULL DETECTOR SELF-ZERO

The following checks the ON+ and ON- zero turnover. The alignment should be checked and if necessary calibrated before proceeding with DC or DCI calibration (refer to Appendix 2 - Calibration Source Zero Offsets). It is not necessary to be in 'CAL' mode to perform the alignment check.

ROUTINE:

1. Null Detector

Set to Low sensitivity

2. 4705

-6

With OUTPUT OFF, Select DC, OUTPUT Zero. Select 10V RANGE and ON+.

3. Null Detector

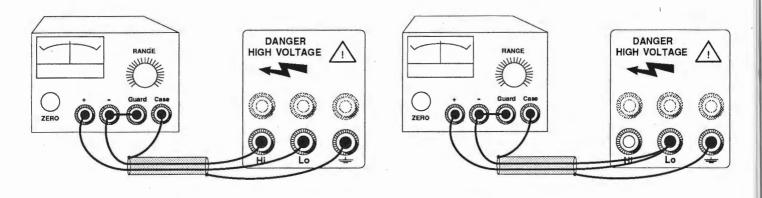
- Successively increase sensitivity range, using 'self-zero' control to give near-zero readings; until a range is reached which clearly resolves a single increment of the leastsignificant digit on the 4705 OUTPUT display.
- Disconnect Hi lead from the 4705 Hi terminal, and connect to Lo as illustrated for Null Detector self-zero.
- Adjust Null Detector to zero using self-zero control.
- Disconnect Hi lead from the 4705 Lo terminal, and reconnect to Hi.
- Note Null detector reading.

4. 4705 Select 'ON-".

5. Null Detector Note Null detector reading.

If the turnover is considered excessive the user can recalibrate as close as possible to absolute zero (*refer on to ±0 CALIBRATION*)

±0 CALIBRATION



4705 ON+ & ON- ALIGNMENT

NULL DETECTOR SELF-ZERO

EXPLANATORY NOTE: After ' ± 0 ' is selected; the calibration firmware stores the OUTPUT display value every time the CAL key is pressed, until it has received one reading from each polarity (as defined by the ON state). If it receives only one polarity it will continue to update the stored value until it stores the other polarity. It then carries out the necessary calculations to align the two zeros. Thus the ± 0 calibration can be performed in either direction: ON+ first, then ON-; or ON- first, then ON+; and it is possible to correct the nulling for the first polarity, but not for the second (opposite). This procedure will allow, at time of calibration, the turnover error to be reduced to $\leq 5\mu V$ taking polarity into account. Use of the ± 0 key should be followed by a complete Range Zero Calibration.

ROUTINE:

- 1. Null Detector Set to low sensitivity.
- 2. 4705
- a. With OUTPUT OFF, Select DC, OUTPUT Zero.
- b. Select 10V RANGE and ON+.
- 3. Null Detector
- a. Successively increase sensitivity range, using 'self-zero' control to give near-zero readings; until a range is reached which clearly resolves a single increment of the least-significant digit on the 4705 OUTPUT display.
- **b.** Disconnect from the 4705 Hi terminal, and connect to Lo as illustrated for Null Detector self-zero.
- c. Adjust to zero using self-zero control.
- d. Disconnect from the 4705 Lo terminal, and reconnect to Hi.
- 4. 4705

Press ±0 Key: ±0 LED lights, Adjust the OUTPUT] keys to null the detector. Press CAL key: CAL LED lights

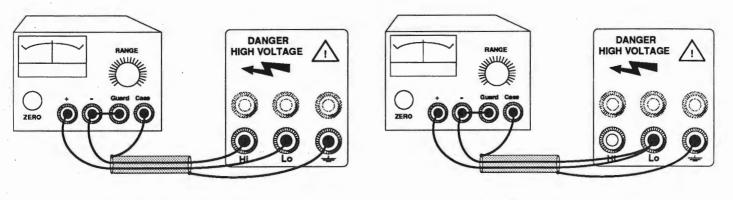
- 5. Null Detector Reduce Null Detector sensitivity
- 6. 4705 Select 'ON-'
- 7. Null Detector

Successively increase sensitivity range, using the 4705 OUTPUT []] keys to give near-zero readings; until the zeroed range is reached.

8. 4705

Press CAL key: CAL LED goes off. ±0 LED goes OFF, OUTPUT display falls to zero.

RANGE ZERO CALIBRATION



4705 ON+ RANGE ZERO

NULL DETECTOR SELF-ZERO

Calibration of DC Voltage Range Zeros.

The routine below includes a sequence for zeroing the Null Detector on the correct sensitivity range. This is necessary, because for most Null Detectors the zero is range-dependent. The self-zero input should include the Hi and Lo leads as shown in the connection illustration. Commencing with the lowest range calibrate the DC Zeros in the sequence of the table using the Zero Calibration Routine for each range selected.

ROUTINE:

1. Null Detector Set to Low sensitivity

2. 4705

With OUTPUT OFF, Select DC, OUTPUT Zero. Select RANGE from table and ON+.

3. Null Detector

Successively increase sensitivity range, using 'self-zero' control to give near-zero readings; until a range is reached which clearly resolves a single increment of the least-significant digit on the 4705 OUTPUT display.

a. Disconnect from the 4705 Hi terminal, and connect to Lo as illustrated for Null Detector self-zero.

- b. Adjust to zero using self-zero control.
- c. Disconnect Hi lead from the 4705 Lo terminal, and reconnect to Hi.
- 4. 4705

Use OUTPUT \iint keys to zero the Null Detector reading. Continue until a single increment of the least-significant digit on the OUTPUT display gives the closest approach to zero.

Press CAL key. CAL LED flashes once. OUTPUT display reverts to zero. The Range is now calibrated at zero to the Null Detector zero value.

Nominal Calibration Points for Range Zeros

4705 Range	Calibration Operation	4705 Ou	tput Setting	AUTOCAL Key Used
100mV	ON+ zero	(ON+)	0.00000mV	OUTPUT Î↓ then 'CAL'
1V	ON+ zero	(ON+)	.0000000V	OUTPUT Î↓ then 'CAL'
10V	ON+ zero	(ON+)	0.000000V	OUTPUT Î↓ then 'CAL'
100V	ON+ zero	(ON+)	0.00000V	OUTPUT Î↓ then 'CAL'
1000V	ON+ zero	(ON+)	0.0000V	OUTPUT Î↓ then 'CAL'

1.2.2 Voltage

INTRODUCTION

The following routines:

DC Low voltage (100mV to 10V) and **DC High Voltage** (100V to 1kV)

adjust all DC Voltage Range gains against a Calibration Source, after correcting for the Source's zero offset.

The procedures assume that the 4705 'ON+' and 'ON-' output zero levels are coincident, and that all DC Voltage Range zeros have been adjusted to a null detected across the Sense 'Hi' and 'Lo' terminals (Refer to ' \pm 0 Alignment Routine').

Caution

First read 'Notes on the use of the Null Detector' (Appendix 1), and 'Calibration Source Zero Offsets' (Appendix 2).

1. CONNECTIONS

Ensure that all source outputs are OFF and Null Detector is set to Low Sensitivity. Use short leads and connect the Null Detector between the 4705 and Calibration Source as shown.

2. CALIBRATION ROUTINES

Start with the <u>lowest</u> Nominal Calibration Point from the table. Use the accompanying routine and repeat for each 4705 Range to be calibrated. Ensure that the interconnecting circuit has thermally stabilised before carrying out each 'Autocal' operation.

Notes:

- The Null Detector should be approximately self-zeroed before use to avoid excessive deflections. It is not necessary to do this on the sensitivity range used for final gain calibration, as the reference zero is set in operation (e.).
- The routine assumes calibration at nominal Full Range values. To trim the internal Master Reference Voltage on the 1V or 10V Range, or to calibrate at a non-nominal value, refer to following description of SET and STD keys.

DC AUTOCAL FACILITIES

CAL

If the CAL key is pressed the 4705 assumes that a calibration at either Zero or Full Range is required. It uses the value on the OUTPUT display to distinguish between Zero (Offset calibration) and Full Range (Gain calibration).

Caution

Below 2% of Range, the 4705 corrects for an assumed offset error; at 2% of Range and above the correction is for an assumed gain error.

If SET or STD has been pressed the CAL key executes the preselected AUTOCAL mode.

SET

The SET key allows calibration to any value in the selected Range (e.g. at a standard cell voltage). Press SET after operation (k.) and before operation (l.). The SET LED lights green and the OUTPUT display reading also appears on the MODE display. Continue the routine but note that on pressing CAL (step (n.)) the MODE display clears as its value is transferred to the OUTPUT display. The SET LED goes off.

Caution

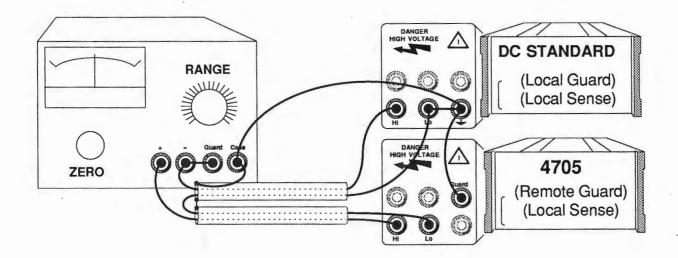
If the value initially set on the OUTPUT display is below 2% of Full Range value, the instrument assumes that an offset calibration is requested, and if at 2% or above, a gain calibration is assumed.

STD

The STD key allows a user to trim the value of the internal Master Reference voltage. STD calibration in DC mode effectively changes the gain of all voltage and current ranges in the same ratio. It does not affect values of AC or Ohms functions. STD calibration can be carried out on either 1V or 10V Ranges and differs from the SET procedure only in the use of the STD key instead of the SET key.

±0

DO NOT USE - refer to earlier ±0 Alignment routine.



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WARNING:

Terminals marked with the symbol carry the output of the 4705. These terminals and any other connections to the load under test could carry lethal voltages. Under no circumstances should users touch any of the front (or rear) panel terminals unless they are first satisfied that no dangerous voltage is present.

CAUTION:

Connection or disconnection of measurement circuitry should only be attempted when all voltage sources are OUTPUT OFF.

Before setting OUTPUT ON ensure that the correct polarities have been selected and any measurement device has been set to low sensitivity.

Routine:

a. Null Detector Set to Low sensitivity.

b. 4705

Ensure OUTPUT OFF. Select OUTPUT Zero DC and required RANGE.

c. Calibration Source Set to 'ON+' Zero.

Select correct Range.

d. 4705

Press the ON+ key.

e. Null Detector

Successively increase sensitivity range, using self-zero to give near-zero readings; until a range is reached which clearly resolves a single increment of the least-significant digit on the 4705 OUTPUT display.

f. 4705

Reselect OUTPUT Zero.

g. Null Detector

Use the 'Self-zero' control to give an accurate zero.

h. 4705

Press the OFF key.

j. Calibration Source

Set to the required voltage for Range gain calibration.

Nominal Calibration Points for Low Voltage

	4705 lange	Calibration Operation	Calibration Source & 4705 Output (ON+ Nominal) [1]	Control to be Adjusted to Obtain Null	Press 'CAL' Key to Calibrate
	00mV	Zero offset	0.00000mV	Null Det. 'Zero'	Not used
	00mV	Range gain	100.00000mV	4705 OUTPUT Î↓	[2] 'CAL'
[3]	1V	Zero offset	.0000000V	Null Det. 'Zero'	Not used
	1V	Range gain	1.0000000V	4705 OUTPUT	[2] 'CAL'
[3]	10V	Zero offset	0.000000V	Null Det. 'Zero'	Not used
	10V	Range gain	10.000000V	4705 OUTPUT Î↓	[2] 'CAL'

[1] It is expected that many users will wish to calibrate Range gains at values other than the nominals shown. In these cases set the Calibration Source voltage and 4705 OUTPUT display to in-house standard values near nominal.

[2] For non-nominal gain calibration; use 'SET' key after entering value on the OUTPUT display before adjusting for null.

[3] To trim the internal Master Reference voltage on 1V or 10V Range: use 'STD' key after entering value on 4705 OUTPUT Display before adjusting for null (Refer to Calibration Routine and description of 'STD').

k. 4705

Use Full Range or OUTPUT \iint keys to set the required positive value on the OUTPUT display. Press the ON+ key and select Full Range.

N.B. At this stage do not readjust the Null-Detector self-zero.

1. 4705

Use OUTPUT []] keys to zero the Null Detector reading. Continue until a single increment of the least-significant digit on the OUTPUT display gives the closest approach to zero.

m. Null Detector

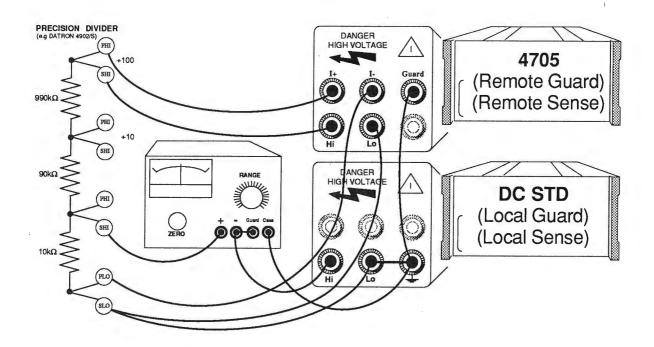
Set to LOW sensitivity.

n. 4705

Press CAL key: CAL LED flashes once.

The 4705 is now gain-calibrated at this voltage.

DC HIGH VOLTAGE (100V to 1000V)



WARNING:

Terminals marked with the symbol carry the output of the 4705. These terminals and any other connections to the load under test could carry lethal voltages. Under no circumstances should users touch any of the front (or rear) panel terminals unless they are first satisfied that no dangerous voltage is present.

CAUTION

Connection or disconnection of measurement circuitry should only be attempted when all voltage sources are OUTPUT OFF.

Before setting OUTPUT ON ensure that the correct polarities have been selected and any measurement device has been set to low sensitivity. Note: On the diagram, the terminals of the Precision Divider are marked 'PHI', 'PLO', 'SHI' and 'SLO'. These are terms which apply to the Datron 4902 and 4902S, referring to their Power Hi & Lo inputs and Hi & Lo Sense points, for true 4-wire connections (described in their User's Handbook).

> For other dividers, it is important that true 4-wire connections are made directly to the elements of the divider, and that the divider has been calibrated at the connection points.

Routine:

a. Null Detector Set to Low sensitivity.

b. 4705

Ensure OUTPUT OFF. Select OUTPUT Zero DC and required RANGE.

c. Calibration Source Set to 'ON+' Zero.

Select correct Range.

d. 4705

Press the ON+ key.

e. Null Detector

Successively increase sensitivity range, using self-zero to give near-zero readings; until a range is reached which clearly resolves a single increment of the least-significant digit on the 4705 OUTPUT display.

f. 4705

Reselect OUTPUT Zero.

g. Null Detector

Use the 'Self-zero' control to give an accurate zero.

h. 4705

Press the OFF key.

j. Calibration Source

Set to the required voltage for Range gain calibration.

k. 4705

Use Full Range or OUTPUT keys to set the required positive value on the OUTPUT display. Press the ON+ key and select Full Range.

N.B. At this stage do not readjust the Null-Detector self-zero.

1. 4705

Use OUTPUT []] keys to zero the Null Detector reading. Continue until a single increment of the least-significant digit on the OUTPUT display gives the closest approach to zero.

m. Null Detector

Set to LOW sensitivity.

n. 4705

Press CAL key: CAL LED flashes once.

The 4705 is now gain-calibrated at this voltage.

Nominal Calibration Points for Low Voltage

4705 Range	Calibration Operation	Precision Divider Select	Calibration Source (ON+ Nominal) [1]	4705 Output (ON+ Nominal) [1]	Control to be Adjusted to Obtain Null	Press 'CAL' Key to Calibrate
100V	Zero offset	+10	0.00000V	0.00000V	Null Det. 'Zero'	Not used
100V	Range gain	+10	10.00000V	100.00000V	4705 OUTPUT Î↓	[2] 'CAL'
1000V	Zero offset	+100	.0000000V	0.0000V	Null Det. 'Zero'	Not used
1000V	Range gain	+100	10.000000V	1000.0000V	4705 OUTPUT Î↓	[2] 'CAL'

[1] It is expected that many users will wish to calibrate Range gains at values other than the nominals shown. In these cases set the Calibration Source voltage and 4705 OUTPUT display to in-house standard values near nominal.

[2] For non-nominal gain calibration; use 'SET' key after entering value on the OUTPUT display before adjusting for null.

1.2.3 Current

The following routine:

DC Current Calibration (100µA to 1A)

adjusts all DC Current Range Zeros and Range Gains against a Standardized DVM, using a set of calibrated current shunts. The routine sets an independent output zero level using the standard calibration load for the Range. The Range Zero calibration has not been separated from the Range Gain calibration, because of the need to change shunts between ranges.

The procedure assumes the following:

- The 4705 'ON+' and 'ON-' output zero levels are coincident, having been adjusted to a null detected across the Sense 'Hi' and 'Lo' terminals on the 10V Range (refer 'Zero Alignment Check') and
- that the 4705 DC 1V and 100mV Full Range values have already been calibrated or verified.
- the DVM used has been correctly Standardized (sic)

GENERAL PROCEDURE

1. STANDARDIZATION

First read 'Calibration Source Zero Offsets'. Note that any offset in the source's output must be nullified before gain calibration is carried out.

The Zero and Full Range routines assume that the preferred shunt values (*refer to table*) are used and therefore the DVM has been standardized against the 1V and 100mV Ranges of the 4705.

Preferred Shunt Values

4705 Range	Nominal Shunt value	Minimum Wattage	Nominal DVM Reading
100µA	10kΩ	1mW	1V
1mA	1kΩ	10mW	1V
10mA	100Ω	100mW	1V
100mA	10Ω	1W	1V
1A	0.1Ω	1W	100mV

2. CONNECTIONS

Ensure that the 4705 OUTPUT OFF LED is lit and select DCI function. Connect the calibrated current shunt and DVM across the 4705 Hi and Lo terminals as shown. Use short leads and ensure that the DVM is set to the 1V Range.

3. CALIBRATION ROUTINE

Caution

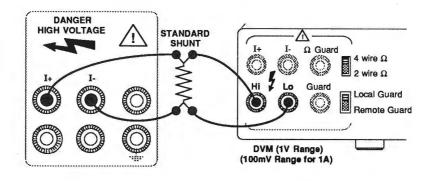
The combined Zero and Full Range procedure assumes that the DVM used has been standardized on the required voltage ranges.

EXPLANITORY NOTE

The offset voltage developed across the shunt is measured by the DVM. However as the shunt is unlikley to be exactly a nominal value, the voltage measured across the shunt for a Nominal Full Range current must be calculated from the product of the shunts Actual Value and the Nominal Full Range Current The 4705 OUTPUT 11 keys are adjusted to give this reading and the 'CAL' key is pressed.

Use the routine and accompanying table, start with the 100μ A Range and repeat the procedure for each 4705 Range. Ensure that the interconnecting circuit has thermally stabilised before carrying out each 'Autocal' operation.

DC CURRENT (100µA to 1A)



Zero Calibration:

1. 4705

Ensure OUTPUT OFF Select RANGE as detailed in the table below.

2. DVM

Press 'Input Zero' key.

3. 4705

Ensure 'Zero' OUTPUT is selected. Select OUTPUT 'ON+'.

Increment the OUTPUT value until the DVM reads zero. Continue until a single increment of the least-significant digit on the OUTPUT display gives the closest approach to zero.

Press CAL. CAL LED flashes once. OUTPUT display reverts to zero.

Range Gain Calibration:

4. 4705

Select Full Range.

Increment the OUTPUT value until the DVM reads the product of the Shunt value and the Nominal Full range output.

Press CAL. The Range has now been gain-calibrated at this current.

Select Zero and OUTPUT OFF. Select next range and shunt value. Repeat the routine from Step 1.

4705	Calibration	4705	To correct	4705
Range	Operation	OUTPUT	DVM reading:	Autocal
100μΑ	DVM Zero	OFF	DVM 'Input Zero'	-Not Used
	Range Zero	ON+	4705 OUTPUT îI keys	'CAL'
	Range Gain	FULL RANGE	4705 OUTPUT îI keys	'CAL'
1mA	DVM Zero Range Zero Range Gain	OFF ON+ FULL RANGE	DVM 'Input Zero' 4705 OUTPUT	-Not Used 'CAL' 'CAL'
10mA	DVM Zero	OFF	DVM 'Input Zero'	-Not Used
	Range Zero	ON+	4705 OUTPUT û↓ keys	'CAL'
	Range Gain	FULL RANGE	4705 OUTPUT û↓ keys	'CAL'
100mA	DVM Zero	OFF	DVM 'Input Zero'	-Not Used
	Range Zero	ON+	4705 OUTPUT û↓ keys	'CAL'
	Range Gain	FULL RANGE	4705 OUTPUT û↓ keys	'CAL'
*1A	DVM Zero	OFF	DVM 'Input Zero'	-Not Used
	Range Zero	ON+	4705 OUTPUT î↓ keys	'CAL'
	Range Gain	FULL RANGE	4705 OUTPUT î↓ keys	'CAL'

*DVM on 100mV Range for 1A.

1.3 AC CALIBRATION

The following routines:

AC Voltage Calibration (1Volt to 1000Volts) Millivolts LF (1mVolt to 100mVolts) Millivolts HF (1mVolt to 100mVolts) AC Current Calibration (1mA to 1A) AC Current Calibration (100µA to 1A)

adjust the Gain of all AC Voltage and Current Ranges.

1.3.1 Introduction

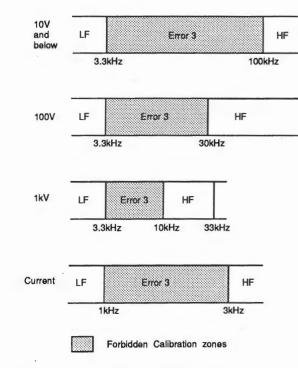
'Wideband' Calibration

When CAL is pressed without preselecting SET, or STD; the instrument makes the assumption that each OUTPUT Range is to be calibrated at the exact Full Range value, at either LF or HF, or both.

This allows two correction values to be stored for each output range. From their difference, the microprocessor calculates a compensation factor, which affects the corrections applied at all subsequentlyselected frequencies on that output range. In this way, the instrument can be calibrated to meet its 'Wideband' specification.

To ensure that the selected Low and High frequencies have sufficient seperation for the compensation to be effective over the full frequency range, calibration is automatically prohibited in an 'excluded' band of frequencies for each output range. Because of the extended frequency range of lower Voltage ranges, and the Voltage/Frequency constraints on higher Voltage ranges, the exclusion band can differ from one output range to another. If an excluded frequency is selected, the calibration is cancelled and *Error 3* is displayed. The following diagram illustrated the mid-frequency exclusions:

AC AUTOCAL FACILITIES



SET

The SET key allows calibration to any value between 20% and 200% of nominal Full Range value (20% to 110% on 1000V range). If, for instance, an adjustable DC voltage standard is not available, the SET key permits the 4705 to be calibrated against a Thermal Transfer standard whose reference is a buffered bank of Standard Cells. SET can also be used as a means of compensating for known errors in the Measurement System.

Press SET after selecting the Full Range OUTPUT value. The SET LED lights green and the OUTPUT display reading also appears on the MODE display. Continue the routine but note that on pressing CAL the MODE display clears as its value is transferred to the OUTPUT display. The SET LED goes off.

STD

CAUTION

This calibration affects all Voltage and Current Ranges and is <u>NOT</u> recommended - Use DC standardization procedure for highest accuracy.

The STD facility is restricted to the 1V and 10V Ranges, on the 100Hz and 1kHz Frequency Ranges only. STD calibration differs from SET procedure only in the use of the STD key instead of the SET key.

 ± 0 . Not applicable for AC operation.

AC CALIBRATION SEQUENCE

INTRODUCTION

Because most users will calibrate the 4705 AC ranges via thermal transfer standards, the calibration procedures assume that this method will be employed. However, details of setting up a thermal transfer standard are not included, as several different models are in use, each with its own methods of connection and procedures.

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Instead it is assumed that users will be able to operate their own equipment correctly, according to the manufacturer's instructions. The procedures which follow therefore concentrate on the operation of the 4705 during calibration, accepting that the required thermal transfer will be set up to a DC source of suitable accuracy.

AC PROCEDURES

AC Voltage Calibration (1Volt to 1000V)

Select AC and the desired frequency, set the 4705 OUTPUT display to the Calibration Standard value, and switch the 4705 OUTPUT ON. If calibrating a non-nominal voltage value, SET needs to be selected. Adjust the 4705 output to obtain a null at the Calibration Standard value, and press the CAL key to execute the calibration.

LF Millivolts Calibration

Because 'Flatness' data is passed on to the millivolt ranges from the 1V Range calibration, the 1V range must be calibrated first. A DVM is then standardized at the required millivolt value and frequency, using the calibrated 1V Range and an Inductive Voltage Divider (IVD). The desired frequency is selected, the OUTPUT display set to Full Range, and incremented or decremented to give the required value on the DVM. If calibrating at a non-nominal value SET must be selected. The CAL key is pressed to execute the calibration.

HF Millivolt Calibration

From the 10V Range a 10% Range correction is calculated. This is applied at 100mV on the 1V Range to standardize a DVM, which is subsequently used to calibrate the 100mV Full Range. The process is extended to calibrate the 10mV Range from 10% of the 100mV Range, and 1mV Range from 10% of the 10mV Range.

Current calibration

(Using Thermal Transfer, Current Shunts and DC Current Standard)

The method employs a DC Current Standard, so that the shunt remains connected for both AC and DC nulling of the Thermal Transfer Standard.

Alternative Current Calibration

(Using verified 4705 1V Range, Calibrated Standard AC Shunts and AC DVM)

This method requires Standard Current Shunts which have been designed to give a flat frequency response. Each current range requires its own specific value of shunt, calibrated to develop either 1V or 100mV Full Range at LF and HF. An AC DVM is standardized to the appropriate voltage, and the Current range is calibrated when the voltage across its shunt is correct.

High Frequency Calibrations

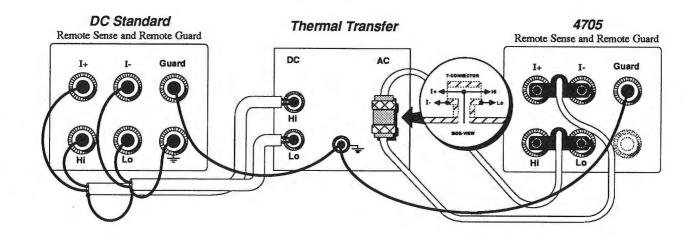
Several iterations may be required to acheive satisfactory calibration; particularly if the initial errors are large, or if the Transfer System being used imposes a long calibration time.

CAUTION:

Connection or disconnection of measurement circuitry should only be attempted when all voltage sources are OUTPUT OFF.

1.3.2 Voltage

AC VOLTAGE CALIBRATION (1V to 1000V)



WARNING:

Terminals marked with the symbol carry the output of the 4705. These terminals and any other connections to the load under test could carry lethal voltages. Under no circumstances should users touch any of the front (or rear) panel terminals unless they are first satisfied that no dangerous voltage is present.

CAUTION:

Connection or disconnection of measurement circuitry should only be attempted when all voltage sources are OUTPUT OFF. Before setting OUTPUT ON ensure the correct polarities have been selected and that any measurement device has been set to low sensitivity. Note: For the arrangement shown in the diagram, the coaxial Tconnector provides true 4-wire connection to the AC coaxial input of the Thermal Transfer.

> For Thermal Transfers with other AC terminations, it is important that true 4-wire connections are made directly to the AC input terminals, and that the device has been calibrated at the connection points.

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Ensure case of Thermal Transfer Standard is adequately grounded.

Commencing with the 1V Range, calibrate the 4705 at the calibration points in the table as part of the following procedure:

- 1. 4705 & DC Voltage Standard With OUTPUT OFF, connect to the Thermal Transfer AC and DC inputs, respectively.
- 2. 4705
- a. On AC FUNCTION, select the required OUTPUT RANGE.
- b. Select the required FREQUENCY RANGE.
- c. Use FREQUENCY L keys to display the required Calibration Frequency.
- d. Press the Full Range key to display the required Calibration Voltage.
- e. Set 4705 OUTPUT ON.
- 3. DC Voltage Calibration Standard Set to the Calibration Voltage, OUTPUT ON.

4. Thermal Transfer Standard

- a. Configure for DC measurement at the required Calibration Voltage.
- b. Adjust for Null at the Calibration Voltage.
- c. Configure for AC measurement at the Calibration Voltage.
- 5. 4705
- a. Use the OUTPUT []] keys to adjust the OUTPUT Display reading to obtain a null on the Thermal Transfer.
- Execute the calibration by pressing the CAL key. Repeat
 (a.) to (b.) until satisfactory null is achieved.

Calibration Points for 1V to 1000V Ranges.

DC Standard OUTPUT Voltage	470 OUTF RAN FREQU	PUT GE/	4705 Nominal OUTPUT Voltage	Freq. Band set by 4705
1.00000V	1V	1kHz	1.00000V	LF
1.00000V	1V	100kHz	1.00000V	HF
10.0000V	10V	1kHz	10.0000V	LF
10.0000V	10V	100kHz	10.0000V	HF
100.000V	100V	1kHz	100.000V	LF
100.000V	100V	100kHz	100.000V	HF
1000.00V	1000V	1kHz	1000.00V	LF
1000.00V	1000V	30kHz	1000.00V	HF

MILLIVOLTS (LF) FULL RANGE CALIBRATION (1mV - 100mV) (Using calibrated 4705 1V Range, Inductive Voltage Divider (IVD) and AC DVM)

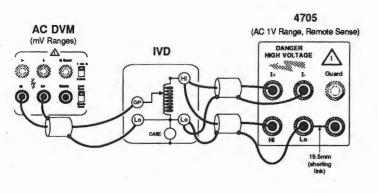


Fig. 1 Standardization of DVM

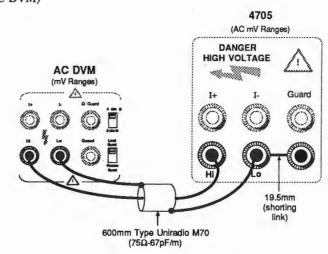


Fig. 2 Calibration of 4705

CALIBRATION PROCEDURE

Standardize and calibrate at the calibration points in the table using the following procedures:

Stage 1

Connect as Fig. 1, to standardize the DVM.

4705, IVD and AC DVM 1

With OUTPUT OFF, connect the circuit for Standardization.

- IVD 2 Set ratio as required for the Millivolt Range to be calibrated.
- AC DVM 3

Configure for measurement at the required Calibration Point.

- 4705
- On AC FUNCTION, select 1V RANGE. 8.
- Select the required Frequency Range. b.
- Use FREQUENCY **II** keys to display the required c. Calibration Frequency.
- Use OUTPUT II keys to display the required IVD input d. voltage (if at Nominal Full Range, merely press the Full Range key).
- Set OUTPUT ON and note DVM reading as V1. e.
- f. Set OUTPUT OFF, and reconnect the circuit for Calibration.

4705

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Stage 2

Selecting SET as required in the following procedure:

Connect as Fig. 2, to calibrate the 4705.

- Select the required Millivolt OUTPUT RANGE. 8.
- Use OUTPUT **U** keys to display the Calibration Voltage b. on the OUTPUT Display (if at Nominal Full Range, merely press the Full Range key).
- Set 4705 OUTPUT ON (and if NOT at Nominal Full c. Range, Select SET).
- Use the *I* keys to adjust the OUTPUT Display reading to d. obtain V1 on the DVM.
- Execute the calibration by pressing the CAL key. Repeat e. (d.) to (e.) as required. Set OUTPUT OFF.

Nominal Cal. Points for Millivolt Ranges.

IVD Ratio (1V Range to mV Range)	OUT	705 TPUT NGE/ UENCY	4705 Nominal OUTPUT Voltage	Freq. Band set by 4705
10:1	100mV	1kHz	100.000mV	LF
100 : 1	10mV	1kHz	10.000mV	LF
1000 : 1	1mV	1kHz	1.000mV	LF

MILLIVOLTS (HF) CALIBRATION PROCEDURE (1mV to 100mV)

(Using verified 4705 1V and 10V Ranges, 10% Range Correction factor and AC DVM)

SUMMARY

The verified output values of 1V on the 1V Range; and 10V on the 10V Range are used to measure the 4705 linearity error at 1V on the 10V range. From the linearity measurement, a 10% of range Linearity and Scaling Factor 'C' is derived.

This factor is subsequently used to correct the 4705 output setting at 10% of range, to standardize a DVM for calibration of the next range down.

N.B. These calibrations are not fully traceable. Calibrate the 4705 at or close to the calibration points in the table, selecting SET as required as part of the following procedure.

Note:

It is assumed that the 1V and 10V ranges have been Wideband calibrated at the required HF calibration points. It is also assumed that the Millivolts (LF) Calibration has been completed.



4705 OUTPUT RANGE/ FREQUENCY		4705 Nominal OUTPUT Voltage	Freq. Band set by 4705
100mV	100kHz	100.000mV	HF
10mV	100kHz	10.000mV	HF
1mV	100kHz	1.000mV	HF

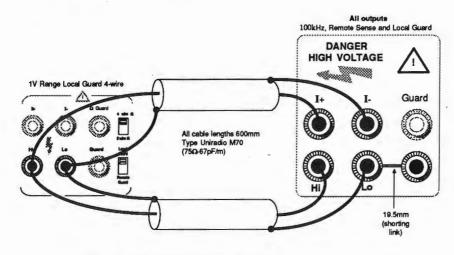


Fig. 1 10V and 1V Range Interconnections

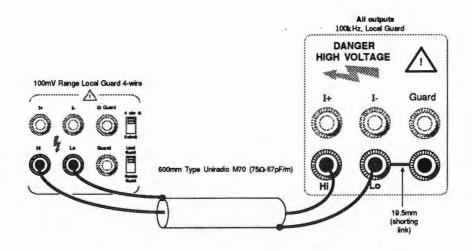


Fig. 2 100mV and 1mV Range Interconnections

Stage 1

Derive the Linearity and Scaling Factor 'C' as follows (C is a number of value close to 0.1):

a. Ensure that the Millivolts (LF) Calibration has been completed.

Ensure that the 4705 has been calibrated and verified at 10V and 1V HF (100kHz) Full Range. Record the measured values as follows:

4705 10V FR setting - 10.0000V Actual output voltage - 'V1'

4705 1V FR setting - 1.00000V Actual output voltage - 'V2'

- b. Calculate 1V correction 'V3' = $\frac{1}{V2}$
- c. With OUTPUT OFF connect a DVM to the 4705 terminals using the exact 4-wire connections as in Fig. 1. Set the DVM to measure AC on its 1V range.
- d. On 4705, select the 1V range and Remote Sense.
 Set FREQUENCY to 100kHz.
 Set OUTPUT display reading to V3.
 Set OUTPUT ON, and note the DVM reading as 'Vt'.
 Set OUTPUT OFF.
- e. On 4705, select the 10V range (Remote Sense).
 Set 4705 OUTPUT display reading to 1V.
 Set OUTPUT ON.
 Adjust the OUTPUT display for a DVM reading of Vt.
- f. Note the 4705 OUTPUT display reading as 'V4'. Set OUTPUT OFF.
- g. From the values V1 and V4 calculate the 10V range linearity correction and scaling factor 'C' as follows:
 - $C = \frac{V1 \times V4}{100}$

Record in 51/2 digits resolution



Vt is a transfer value

Vt =V

Record in 51/2 digits resolution

V4 =V

C =

Calculate in 51/2 digits resolution

N.B. The following calibration from the front panel can only be carried out if the IEEE Address switch on the rear panel is set to Address 31 (11111).

Stage 2

To Calibrate the 100mV Range Full Range Output

- a. Insert the Calibration security key into the 'CALIBRATION ENABLE' switch on the rear panel, and turn to 'ENABLE'.
- b. Ensure that the DVM is still connected to the 4705 terminals as shown in Fig. 1.
- c. Set the 4705 to the 1V range. Calculate the value 'V3 x C'. Set OUTPUT display to this value.
- d. Set the DVM to measure 100mV.
- e. Set 4705 OUTPUT ON, allow the output to settle. Note the DVM reading as 'V(100t)'.
- f. Set 4705 OUTPUT OFF and reconnect the DVM to the 4705 terminals in 2-wire as shown in Fig. 2.
- g. Set 4705 to its 100mV range. (Remote Sense is automatically deselected.)
 Set OUTPUT ON and adjust the 4705 Output for a DVM reading of V(100t).
 Press the 'CAL' pushbutton and observe the DVM reading.
- h. Repeat operation (g.) until the post-CAL DVM reading is within $1\mu V$ of V(100t).

Stage 3

To Calibrate the 10mV Range Full Range Output

- a. Ensure that the DVM is still connected to the 4705 terminals as shown in Fig. 2.
- Ensure that the 4705 is set to the 100mV range.
 Calculate the value '100mV x C '.
 Set OUTPUT display to this value.
- c. Set the DVM to measure 10mV.
- d. Allow the output to settle. Note the DVM reading as 'V(10t)'.

.

- e. Set 4705 to its 10mV range.
- Adjust the 4705 Output for a DVM reading of V(10t).
 Press the 'Cal' pushbutton and observe the DVM reading.
- g. Repeat operation (f.) until the post-CAL DVM reading is within $1\mu V$ of V(10t).

Calculate in $5^{1}/_{2}$ digits resolution

 $V3 \ge C$

V(100t) is a transfer value

V(100t) =mV

Calculate in 51/2 digits resolution

100mV x C =mV

V(10)t is a transfer value

V(10t) =mV

Stage 4

To calibrate the 1mV Range Full Range Output

- a. Ensure that the DVM is still connected to the 4705 terminals as shown in Fig. 2.
- Ensure that the 4705 is set to the 10mV range.
 Calculate the value '10mV x C'.
 Set OUTPUT display to this value.
- c. Set the DVM to measure 1mV.
- Allow the output to settle.
 Note the DVM reading as 'V(lt)'.
- e. Set 4705 to its 1mV range.
- f. Adjust the 4705 Output to give a settled DVM reading of V(lt).
 Press the 'CAL' pushbutton and observe the DVM reading.
- g. Repeat operation (f.) until the post-CAL DVM reading is within $1\mu V$ of V(lt).

Stage 5

Calibration Disable

a. Turn the Calibration security key, inserted in the 'CALIBRATION ENABLE' switch on the rear panel, to 'RUN'. Remove the key.

Calculate in 41/2 digits resolution

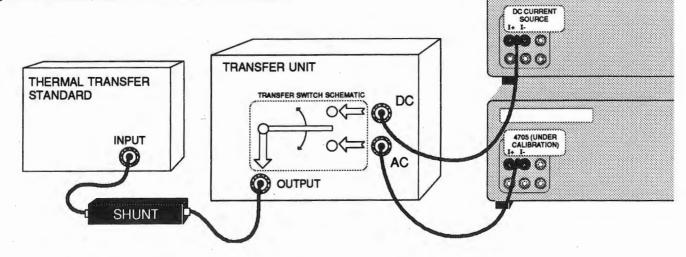
 $10 \text{mV} \ge 0.00 \text{mV}$

V(lt) is a transfer value

V(lt) =mV

1.3.3 AC Current

AC CURRENT CALIBRATION (1mA - 1A) (Using Thermal Transfer, Current Shunts and DC Current Standard)



For all connections use low loss co-axial cable and keep leads as short as possible. Some types of shunt can be directly fitted to the Thermal Transfer.

Note

Calibrate 1mA Range only if the Thermal Transfer is adequately calibrated at these levels.

Routine

Commencing with the lowest Range, calibrate the 4705 at the calibration points in the table as part of the following routine:

1. Thermal Transfer Standard

Configure for DC measurement at the required developed voltage and connect with the appropriate shunt to the Transfer Unit.

2. DC Current Standard

- a. With OUTPUT OFF, connect to the Transfer Unit and set to the required calibration current.
- b. Set OUTPUT ON.

3. 4705

- a. With QUTPUT OFF, set to the required calibration Current and Frequency and connect to the Transfer Unit.
- b. Set OUTPUT ON.
- 4. Transfer Unit Switch for DC output.
- Thermal Transfer Standard Adjust for null at the Calibration Current. Configure for AC measurement at reduced sensitivity.

6. Transfer Unit

Switch for AC output.

7. Thermal Transfer & 4705

Use the OUTPUT \iint keys to adjust the OUTPUT Display reading to obtain a null on the Thermal Transfer increasing the Transfer sensitivity as required.

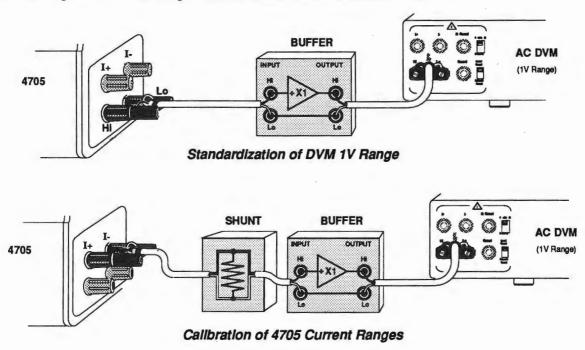
Execute the calibration by pressing the CAL key.

Nominal Cal. Points for 1mA to 1ARanges.

DC Standard OUTPUT Current	4705 OUTPUT RANGE/ FREQUENCY		4705 Nominal OUTPUT Current	Freq. Band set by 4705	
1.00000mA	1mA	300Hz	1.00000mA	LF	
1.00000mA	1mA	5kHz	1.00000mA	HF	
10.0000mA	10mA	300Hz	10.000mA	LF	
10.0000mA	10mA	5kHz	10.000mA	HF	
100.000mA	100mA	300Hz	100.000mA	LF	
100.000mA	100mA	5kHz	100.000mA	HF	
1.00000A	1A	300Hz	1.00000A	LF	
1.00000A	1A	5kHz	1.00000A	HF	

CURRENT FULL RANGE CALIBRATION (100µA - 1A)

(Alternative Method using verified 4705 1V Range, Calibrated Standard AC Shunts and AC DVM).



100µA to 1A procedure

Commencing with the $100\mu A$ Range, calibrate the 4705 at the calibration points in the table as part of the following procedure:

- 1. 4705 and AC DVM
 - With OUTPUT OFF, connect the 4705 and DVM for Standardization. Select the 1V Range on the AC DVM.

OUT	05 PUT NGE/ JENCY	4705 Nominal OUTPUT Current	Freq. Band set by 4705
100µA	300Hz	100.000µА	LF
100µA	5kHz	100.000µА	HF
1mA	300Hz	1.00000mA	LF
1mA	5kHz	1.00000mA	HF
10mA	300Hz	10.0000mA	LF
10mA	5kHz	10.0000mA	HF
100mA .	300Hz	100.000mA	LF
100mA	5kHz	100.000mA	HF
1A	300Hz	1.00000A	LF
1A	5kHz	1.00000A	HF

Calibration points for 100µA to1A Ranges.

2. 4705

- a. Set to the 1V Range at the Calibration Frequency and adjust for calibrated 1.000000V output.
- b. Set OUTPUT ON and note the DVM reading as 'V1'.
- c. Set OUTPUT OFF, and reconnect the test circuit for Calibration, using the correct shunt for the range to be calibrated.
- d. On I FUNCTION, select the required OUTPUT RANGE.
- e. Select the required FREQUENCY RANGE .
- f. Use FREQUENCY 1 keys to display the required Calibration Frequency.
- g. Press the Full Range key.
- h. Set 4705 OUTPUT ON.
- j. Use the OUTPUT \iint keys to adjust the OUTPUT Display reading to obtain a DVM reading of 'V1'.
- **k.** Execute the calibration by pressing the CAL key. Set OUTPUT OFF.

1.4 RESISTANCE CALIBRATION

(Measurement and Storage of the values of an internal resistor.)

Calibration Memory

In Ω function, each RANGE key selects a nominal-value standard resistor. Adjustment of the resistor value is not routinely necessary unless *Error 6* occurs during calibration (*refer to Section 4.4*). During calibration the actual value is measured and stored in the calibration memory to be displayed whenever that range is selected. Separate memory stores exist for Remote Sense (4-wire), Local Sense (2-wire) and Local Sense zero. Zero calibration is not available in Remote Sense.

4-wire Calibration Limits

The value measured in 4-wire Remote Sense does not include the resistance of internal or external wiring because of the measurement techniques used.

The instrument accepts any value within ± 200 ppm of nominal as a valid calibration.

2-wire Calibration Limits

The value measured in 2-wire Local Sense is greater than for 4-wire Remote Sense, as it includes the resistance of internal wiring and relay contacts. The instrument will not accept any 2-wire value less than the stored value for 4-wire, so the 4-wire Remote Sense calibration must be carried out before attempting 2-wire Local Sense. The extra internal resistance depends on range, so the instrument accepts the following values x as valid 2-wire calibrations:

Zero calibration.

 10Ω to $1M\Omega$ Ranges: $0 \le x < 0.900\Omega$

Value calibrations.

10 Ω to 1M Ω Ranges: 4-wire value $\leq x < (4$ -wire value +1.999 Ω)

Error 6 appears on the MODE display for any attempt to enter a value outside the 4-wire or 2-wire limits.

Note:

When resistance is calibrated in Remote Sense, the instrument overwrites the Local Sense calibration memory with the new 4-wire value. For this reason 2-wire calibration should always be performed after 4-wire calibration.

General Procedure.

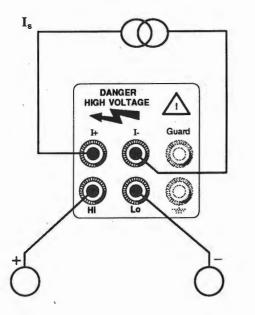
Prepare the 4705 for calibration. Connect as required and use the following calibration routines to calibrate the resistors in sequence, commencing with the 100M Ω Range.

Note

All measurements use 4-wire connections to exclude the effect of external lead resistance from the measured value.

4-WIRE RESISTANCE CALIBRATION

(Remote Sense selected)



CALIBRATION SEQUENCE

1. 4705

Select OUTPUT OFF and Ω . Select **Remote Sense**.

2. 4705

Press required (RANGE) key; The previously-calibrated value appears on the OUTPUT display.

3. 4705 and resistance-measuring equipment Press OUTPUT ON+ and measure the value of the internal resistor.

1

4. 4705

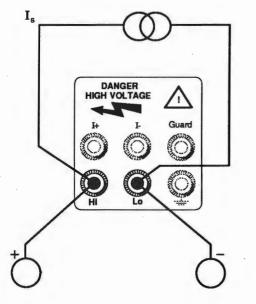
Using the OUTPUT [] keys, set the measured value on the OUTPUT display. Press CAL Key to store OUTPUT display value. Set OUTPUT OFF.

5. Repeat operations (2) to (4) for each RANGE.

Nominal Calibration Points and Limits for 4-wire calibration.

Range	Measured R Minimum	esistance Maximum
100Μ Ω	99 · 9800 MG	100 · 0 199 Ma
10M Ω	Ma	am 221 00·01
1M Ω	·999800 MG	
100k Ω	99·9800 **	···· 221 0· 001
10k Ω	9·99800 **	eej 00, 01
1k Ω	·999800 **	°* ₽₽1
100Ω	99 ·9800 *	۵ <u>۱۹۹</u> ۵۰ ۵۵۱
10 Ω	° .99800	° (10,01

(Remote Sense OFF. Note: 2-wire calibration should always be performed after 4-wire calibration.)



CALIBRATION SEQUENCE

1. 4705

Select OUTPUT OFF and Ω . Deselect Remote Sense.

2. 4705

Press required resistor (RANGE) key; The previouslycalibrated value appears on the OUTPUT display.

3. 4705 and resistance-measuring equipment Press OUTPUT ON+ and measure the value of the internal resistance.

4. 4705 Using the OUTPUT ¹U keys set the measured value on the OUTPUT display. Press CAL Key to store OUTPUT display value

5. 4705

Press Zero Key and repeat operations (3) to (4) for this RANGE selection. Set OUTPUT OFF.

6. Repeat operations (2) to (5) for each RANGE value of the Table.

Nominal Calibration Points and Zero Limits for 2-wire calibration. * The Local Limit Span: Lower Limit = Remote Value; Upper Limit = Remote Value + 'U' (digits).

Range	*Local Full Range Limit Span 'U' (digits)	Measured Zero Limit
1 Μ Ω	+1	
1 00k Ω	+19	
10k Ω	+19	0 · 00000 🌇 🗅 · 00090
1k Ω	+199	
100Ω	+199	
10Ω	+199	

1.5 REMOTE CALIBRATION GUIDELINES

The operation of the instrument in systems applications via the IEEE 488 interface, is described in Section 5 of the User's Handbook. In addition to its capability as a programmable calibrator, the 4705 can itself be calibrated under remote control. Full autocalibration of the instrument over the bus implies availability of a suitably programmed controller, programmable standards, programmable Null Detector, and a programmable Thermal Transfer.

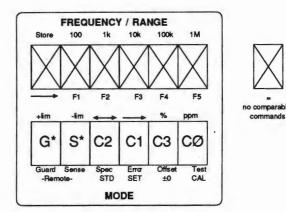
Calibration Commands

The table below lists the device-dependant commands used for Routine Calibration. The relevant calibration codes are also listed.

These commands can only be activated when two conditions have been fulfilled:

- the CALIBRATION ENABLE Keyswitch on the instrument Rear Panel must be set to ENABLE, and
- the IEEE Interface command-code W1 must have been received and activated.

Additional commands can be activated when 'PRE-CAL ENABLE' switch is enabled. Refer to 1.6.3 Remote Pre-Calibration Guidlines.



Transfer of calibration facilities

When the 4705 is under remote control over the bus, the commandcode WØ overrides the settings of the CALIBRATION ENABLE and internal PRE-CALIBRATION ENABLE switches, disabling the 'C' codes. 111

General Procedure

The Main Register is set to the Calibration Standard value (M***...), the 4705 Output is switched ON (01), and one or a specified sequence of the calibration mode command codes (C1, C2, C3, I) may be transmitted.

The 'M' Code is adjusted to obtain a null at the Calibration Standard value, and CO is transmitted to execute the calibration.

Command Codes (Key caps)	Description	Functions and Facilities					
		DC Voltage	DC Current	AC Voltage	AC Current	2-Wire Ω	4-Wire Ω
CØ	Range Zero	100mV-1000V Ranges	All Ranges			10Ω-1MΩ Ranges	
	Gain calibration to Nominal Full Range	100mV-1000V Ranges	All Ranges	All Ranges	All Ranges	10Ω-1MΩ Ranges	All Ranges
* C1 (SET)	Zero offset for range at User's selected value	All Ranges	Ali Ranges				
	Gain for range at User's selected value	All Ranges	All Ranges	All Ranges	All Ranges		
*C2 (STD)	Internal Reference gain at user's Standard value	1V &10V Ranges		1V &10V Ranges			
* C3 (±0)	Alignment of internal ON+ and ON- zeros	10V Range					
I	User's Message	Refer to	User's Handbo	ook Section 5 'Pro	ogramming of Bus	Transmissions	

Availability of Command Codes

*Preselector - must be activated later by command code CØ (CAL)

Command Code Facilities (Routine Calibration)

For a General description see 'Autocal Facilities' page 1-3.

C1 (SET)

C1 gives calibration at any point in the selected range by allowing the user to input the value of the calibration standard used (initial M code used). Before executing the calibration CØ uses the final 'M' Code value to distinguish between Zero (Offset calibration) and Full Range (gain calibration). The limits of Offset or Full Range depend on function selected (refer Sect 1.2 DC Calibration and Sect 1.3 AC Calibration).

C2 (STD)

C2 allows a user to compensate for changes of the internal Master Reference voltage. For best accuracy it is recommended this procedure is carried out in DC function. Note that the gain of all voltage and current ranges change in the same ratio. Execute with $C\emptyset$

CØ (execute pre-selection)

CØ executes one of the above preselected AUTO-CAL modes.

CØ (CAL ONLY)

If Command CØ is sent without pre-selection code C1/C2 the instrument assumes that the selected range is to be calibrated at either Zero or Full Range. It uses the value input by the 'M' Code to distinguish between Zero (Offset calibration) and Full Range (gain calibration) according to the function selected (*refer Sect 1.2 DC Calibration and Sect 1.3 AC Calibration*).

Guidelines - An Example

The following sequence suggests a method of calibrating the instrument 1V Range Gain against a buffered standard cell value of +1.018057V. It is assumed that the instrument is correctly addressed with its Calibration Keyswitch set to ENABLE and the instrument Output is OFF. Connect the Null Detector, set to low sensitivity, between the Standard Cell buffer and the 4705. The nulling operation is seperated into its own string, as it is likely to be iterative.

SET Calibration of 1V DC Gain FØR5GØSØW1M+1.018057C101=M(for null)CØ

The example suggests only the broad outline of one of many sequences which could be used to perform instrument calibrations.

Calibration Command Strings

The following AC command strings are given for the sole purpose of illustrating the methodology designed into the 4705 for remote calibration modes. Some reference to external operations is inferred. The nulling operation is separated into its own string, as it is likely to be iterative.

It is assumed that the 4705 has previously been programmed in function and range (not autorange $R\emptyset$) and that the external circuit is set up correctly. The 4705 is already programmed into its calibration mode by W1, with the calibration keyswitch set to ENABLE, and output OFF.

- a. Nominal Full Range LF Gain Calibration: H(LF)A101=M (for null)=CØ=OØ=
- b. Nominal Full Range HF Gain Calibration: H(HF)A101=M(for null)=CØ=OØ=
- c. Combined Nominal LF and HF Gain Cal: H(LF)A101=M(for null)=CO= H(HF)=M(for null)=CO=O0=
- d. Non-nominal LF Gain Calibration: H(LF) M(20%-200%FR)C1= O1=M(for null)=CØ=OØ=
- e. Non-nominal HF Gain Calibration: H(HF) M(20%-200%FR)C1= O1=M(for null)=CO=O0=
- f. Combined Non-nominal LF and HF Gain Cal: H(LF)M(20%-200%FR)C1= O1=M(for null)=CØ= H(HF)M(20%-200%FR)C1= M(for null)=CØ=OØ=
- g. Standardization at Nominal Full Range 1V or 10V Range only): H(LF)A1C2O1=M(for null)=CØ=OØ=
- h. Standardization at a Non-nominal value (1V or 10V range only): H(LF)M(20%-200%FR)C2= O1=M(for null)=CØ=OØ=

1.6 PRE-CALIBRATION

1.6.1 Introduction

In an initial calibration process at manufacture, certain 'PRE-CAL' parameters are established in a special calibration memory to define the overall linearity of the instrument, and to allow maximum routine calibration memory span for adjustments. For normal purposes, all subsequent Routine Calibration procedures are sufficient to maintain calibration.

Preparation for the pre-calibration operation includes removal of the Top Cover, to facilitate selection of pre-calibration mode and operation of the calibration memory clear push-button. DC and AC pre-calibration must then be completed followed by a Full Routine Recalibration. Thereafter all routine calibrations may be performed from the front panel or over the IEEE Interface without removing the covers.

Circumstances Calling for Pre-Calibration

The stored parameters are invalidated by replacement of certain critical parts of the instrument.

- The Lithium battery which powers the whole calibration memory when the instrument supply is switched off. This should be replaced at five-year intervals (*Refer to Section 4.3*).
 The Digital Assembly
- The Reference Divider Assembly
- Critical components in the Digital or Reference Divider, AC and Sine Source assemblies

A full list appears on flap of page 1-1. After replacement of any of these parts, new parameters must be stored in the pre-calibration memory, by procedures (in manual or remote control) detailed in this section.

EQUIPMENT REQUIREMENTS

DC

- A precision divider capable of dividing 20.000,000V to 10.000,000V to a ratio error of better than 0.1ppm between tappings. For example a Datron 4902/S precision divider or alternatively a Datron 4903 DC Calibration Unit.
- A DC 10V reference with an accuracy of better than 2ppm. Example: Datron Instruments 4000A or a bank of standard cells.

AC

- A precision voltmeter capable of 1V AC measurement with a stability between readings of better than ±5ppm.
 Example: Datron Instruments 1081
- An inductive voltage divider with ratios of x1.0 and x0.1 capable of dividing 10.000,00V to 1.000,000V to an accuracy better than 2ppm.

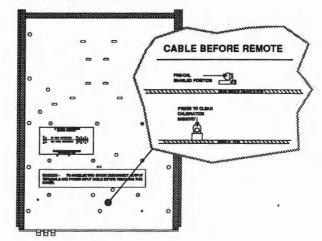
PREPARING THE 4705

Before clearing the pre-calibration store, prepare the 4705 as described on flap of page 1-2. The adjustments detailed in the following sequences include intentionally clearing the instrument's pre-calibration memory, which loses all previous calibration information. Therefore before proceeding make certain that the reasons for carrying out a complete recalibration are valid. (If in any doubt, consult your Datron Service Centre)

Identification of Access Holes

These give access to the 'PRE-CAL ENABLE' switch and the 'CLEAR CALIBRATION MEMORY' switch.

- a. Release 6 screws retaining the top cover.
- b. Lift the top cover at the front of the instrument and locate the two holes which give access to the two-position 'PRE-CAL ENABLE' switch and the press-button 'CLEAR CALIBRATION MEMORY' switch.



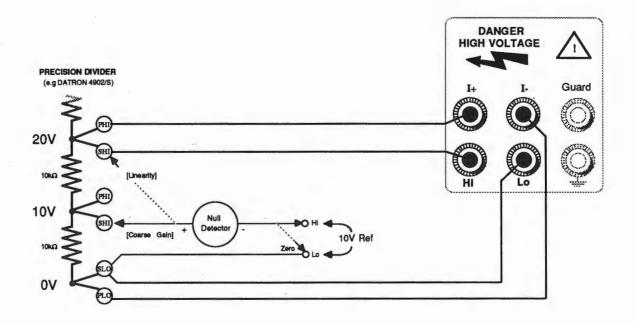
c. Locate the hole which gives access to the PRE-CAL ENABLE switch. Insert an insulated tool in the hole and move the pre-cal switch to the right (Enable). The legend 'cal', as presented on the MODE display, also appears on the OUTPUT display.

Caution

The following operation (d.) clears all the calibration memory stores as part of pre-calibration. Proceed only if this is required.

- d. Locate the hole which gives access to the Calibration Memory CLEAR push-button. Insert an insulated tool in the hole and press the button to clear the calibration memory.
- c. Refit the top cover but do not secure.

Complete the following pre-calibration procedure.



First complete the ± 0 calibration procedure on page 1-7, but with precalibration mode selected.

Ensure the 4705 OUTPUT OFF LED is lit, cancel any MODE keys, select Remote Sense and deselect Remote Guard. Select DCV FUNCTION and 10V RANGE. Connect the Precision Divider to the instrument terminals as shown. Use short leads.

a. 4705

Ensure OUTPUT OFF and select the 10V RANGE.

b. Precision Divider/Null Detector

Set the Null Dectector to Low sensitivity and connect to the Precision Divider at 10V tapping.

c. 4705

Connect to the precision divider as shown. Select +ON with zero OUTPUT

d. Reference/Null Detector

If the reference is a buffered bank of standard cells, switch the Buffer output to zero. However if an electronic reference is used connect Null Detector -ve lead to Reference Low. Set Null Detector to high sensitivity. Zero Null Detector.

Reduce Null Detector sensitivity.

Switch on or reconnect the 10V reference Hi to Null detector.

e. 4705

Select SET, its LED lights. Adjust the OUTPUT keys for Full Scale OUTPUT (+19.99999V). Use instrument OUTPUT () keys to adjust the Null Detector reading to zero.

Press CAL: the SET LED goes out.

f. Precision Divider/Null Detector

Increase Null Detector sensitivity. Reconfigure Null Detector Hi to divider 20V tapping.

g. Reference/Null Detector

If the reference is a buffered bank of standard cells, switch the Buffer output to zero. However if an electronic reference is used connect Null Detector -ve lead to Reference Low. Set Null Detector to high sensitivity. Zero Null Detector. Reduce Null Detector sensitivity. Switch on or reconnect the 10V reference Hi to Null detector.

h. 4705

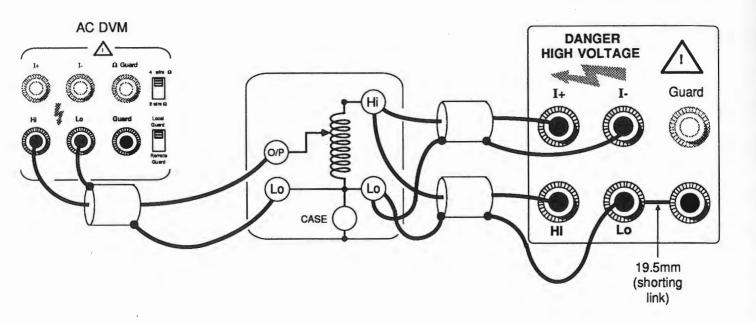
Select STD, its LED lights. Press +ON and Full Range OUTPUT (10.00000V).

j. Null Detector

Increase Null Detector sensitivity and use 4705 OUTPUT 1 keys to adjust the reading to zero.

k. 4705

Press the CAL key: the STD LED goes OFF. Pre-cal is now completed. Select OUTPUT OFF and disconnect.



Ensure the 4705 OUTPUT OFF LED is lit, cancel any MODE keys, select Remote Sense and deselect Remote Guard. Select ACV FUNCTION and connect the IVD to the instrument terminals as shown. Use short leads. Select the 1kHz Frequency Range.

a. IVD

Select x1.0 ratio.

b. 4705

Select 10V range, at 1kHz on the 1kHz Frequency range. Select 1.0000V. Press the ± 0 key, its LED lights. Use instrument OUTPUT []] keys to adjust the DVM reading to 1V. Press CAL: the ± 0 LED remains lit and 1.000,00V (nominal 10% Full Range) appears on the OUTPUT display.

c. IVD

Select the x0.1 ratio to divide the 4705 output by 10.

d. 4705

Select Full Range. Use instrument OUTPUT [1] keys to adjust the DVM reading to 1V. Press the CAL key: the ± 0 LED goes OFF. Recheck, without pre-selection, at 1V and 10V. If required repeat the procedure. Select OUTPUT OFF and disconnect. Pre-cal is now completed. Disable pre-cal and complete a Full Routine Calibration.

PRE-CAL DISABLE

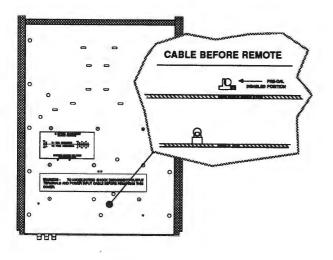
When pre-calibration is complete the pre-cal enable switch must be set to RUN.

Caution

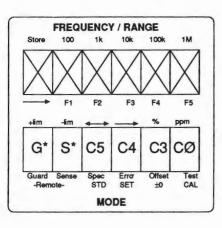
DO NOT press the internal push-button which clears the calibration memory. If this is done, any parameters stored in the calibration memory are cleared; so pre-calibration is cancelled, and must be repeated.

- a. Lift the top cover at the front.
- **b.** Locate the hole which gives access to the PRE-CAL ENABLE switch.
- c. Insert an insulated tool in the hole Pre-cal and move the switch to the left (RUN). The legend 'cal' remains on the MODE display, but disappears from the OUTPUT display.
- d. Refit and secure the top cover.

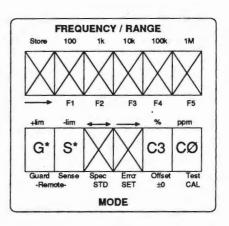
A Full Routine Calibration is necessary before completion of the Return to Use procedure on flap of page 1-2.



1.6.3 REMOTE PRE-CALIBRATION GUIDELINES



Transfer of DC precalibration facilities



Transfer of AC precalibration facilities

General Procedure

The transfer of Pre-calibration facilities to remote control is illustrated above. The general procedure follows that for remote Routine Calibration; the external circuit is connected as for manual pre-calibration.

These commands can only be activated when the following conditions have been fulfilled:

- The CALIBRATION ENABLE Keyswitch on the instrument Rear Panel must be set to ENABLE
- Ensure that the IEEE address switch is set correctly
- The IEEE Interface command-code W1 must have been received and activated.
- The internal 'PRE-CAL ENABLE' switch is set to ENABLE.

When the 4705 is under remote control over the bus, the command code WØ overrides the setting of the CALIBRATION ENABLE and internal PRE-CAL ENABLE switches, disabling the 'C' codes.

Pre-Calibration Command Strings

The following command strings are given for the sole purpose of illustrating the methodology for the remote pre-calibration mode. Some reference to external operations is inferred. The nulling operation is separated into its own string, as it is likely to be iterative.

It is assumed that the external circuit is set up correctly.

The 4705 has already been programmed into its calibration mode by W1, with the calibration keyswitch and the internal PRE-CAL ENABLE switch set to ENABLE.

The calibration memory stores have been cleared, and the 4705 Output is OFF.

8

The string sequence for DC pre-calibration is as follows:

1) ±Zero

FØR6M+ØO1C3= M***= CØ=M-Ø= M***= CØ=OØ= (Set-up and ±0 preselection) (Iterative nulling operation) ('CAL' and -ON) (Iterative nulling operation) ('CAL' then OUTPUT OFF)

2) Coarse Gain and Linearity

FØR6C4M+19.9999901= M***= CØ=OØ= C5=M+10.0000001= M***= CØ=OØ= (Set-up and linearity preselection) (Iterative nulling operation) ('CAL' then OUTPUT OFF) (Set-up and linearity preselection) (Iterative nulling operation) ('CAL' then OUTPUT OFF.)

1

The string sequence for AC pre-calibration is as follows:

Full Range and 1/10th Range Linearity

F1R6H***C3O1=M10= M***= CØ=M1= M***= CØ=OØ (Program to frequency in LF band) (Iterative nulling operation) (First 'CAL' of two-part process) (Iterative nulling operation) (Second 'CAL' cancels preselected mode)

1.7 Ω OPTION INTERNAL ADJUSTMENT

The Autocal procedure for routine calibration of the 4705 resistance Function is described in Section 1.4.

The method of calibration is to measure the value of each standard resistor, and store the measured value in non-volatile calibration memory. Subsequently, each time a resistance RANGE is selected, the previously calibrated value is displayed.

If a standard resistor has been subjected to undue stress, its value may have moved outside its tolerance (signalled by an *Error 6* message during Routine Autocalibration). If the value is less than approx. 50ppm outside tolerance, it can be adjusted internally using a variable trimmer. For values out of tolerance in excess of 50ppm it is likely that the resistor has been over-stressed - consult your Datron Service Centre.

Manual Trimming Procedure

The following procedure is a supplement to Routine Autocalibration. It is necessary only when the 4-wire calibration of Section 1.4 has resulted in an *'Error 6'* message.

It can also be used when, for operational reasons, it is necessary to adjust a resistor to its nominal value. For this purpose a continuously-reading method of measurement is convenient.

- a. Release eight screws retaining the top cover.
- b. Lift the top cover at the front of the instrument and locate the 8 holes giving access for ' Ω OPTION ADJUSTMENT'.
- c. Insert an insulated screw driver tool in the hole for the range selected, and adjust the preset resistor (rotating clockwise increases the resistance value).
- d. Re-measure the 4-wire value and repeat operation (c.) until the desired value is obtained.
- e. Re-calibrate the range for 4-wire and 2-wire connections as detailed in Section 1.4.
- f. Repeat the manual trimming procedure above for all ranges as required.
- g. Finally refit and secure the top cover using the eight screws removed in (a.), above.

Appendix 1 - Notes on the Use of the Null Detector

The Null Detector is normally connected in series with the 4705 Hi lead. A high-impedance-input device should be chosen to reduce off-null currents due to differences in the outputs of the DC voltage source and the 4705. A battery-operated instrument is preferred to ensure adequate isolation. Some Null Detectors possess high input impedance only when their readings are on-scale, so care should be taken to ensure that drain currents from the DC Voltage source do not become excessive. This applies particularly if the DC source is a standard cell or a bank of cells. Six points are important:

- 1. The null detector should be connected to the 4705 (or 4705 load resistor) only when the 4705 OUTPUT OFF LED is lit. (with output OFF, the I+, I-, Hi and Lo terminals are at high impedance).
- Always set the null detector to its lowest sensitivity before connecting up, and increase sensitivity only when the voltages output by the DC Voltage source and the 4705 are close in value.
- 3. Do not change polarity of the 4705 or DC Voltage source without first switching the 4705 OUTPUT OFF. Care must be taken to ensure that the correct polarity ON key is pressed, to avoid excessive voltages being connected across the null detector, particularly when checking the 4705 directly against a standard cell.
- 4. Most Null Detectors are equipped with a 'Self-zero' or 'Zero-check' facility. For maximum accuracy, the Null Detector range zero should be checked before each calibration nulling operation is performed. However, when gain-calibrating the 4705 Voltage and Current Ranges, the zero offset of the calibration voltage source is nullified by adjustment of the Null Detector zero control. This setting should not be altered until the corresponding Range gain has been calibrated.

5. WARNING

During performance checks and calibration a common mode voltage equal to the full range voltage is present at the Null Detector input terminals. On 1000V checks this voltage is potentially lethal, so EXTREME CAUTION must be observed when making adjustments to the null detector sensitivity.

6. CAUTION

The Null Detector used must be able to withstand voltages up to 1200V between its input terminals. Such voltages will be present during the time that the 4705 is ramping from zero to 1000V Full range after setting OUTPUT ON. Inadvertent disconnection of the Precision Divider terminals can transfer full output across the Null detector.

Appendix 2 - Calibration Source Zero Offsets

It is common practice to accept a small offset in the output of a voltage calibration standard, providing that the same offset is present at all output values, including zero.

A more difficult situation arises if there is a 'DC turnover offset' between the source's positive and negative output values. In this case, a difference in DC value will be observed when switching the source between its positive and negative outputs with zero volts selected. This type of error is normally adjusted out on the 4705 by a preliminary '±0' calibration on the 10V Range, to a null detected across its output terminals. This sets both ON+ and ON- zeros to the same DC level; and as the same linear analog circuitry is used to generate both output polarities, range calibration of zero and gain in positive polarity is then all that is required.

The 4705 analog circuitry is fully floating, so its output may be referred to any common mode voltage within the range specified on page 6.1 of the User's Handbook. In particular, each Range zero may be aligned to absolute zero in Local Sense by calibration to a null across its Hi and Lo (Sense) terminals. But if it is then gain-calibrated against an offset source without re-zeroing to that source's offset zero, normal mode gain errors will result. It is therefore essential that any offset in the source's output be nullified before gain calibration is carried out. This can be done at Range zero, simply by trimming the Null Detector null.

Thus the notional sequence of calibration for the 4705 should be as follows:

a. ±0

Check that the 10V Range 'ON+' and 'ON-' zeros coincide at absolute zero (Adjust if necessary).

b. Range Zeros

Carry out 'ON+' zero calibration on all Ranges against the same absolute zero.

c. Range Gain

- Each Range Gain in turn, (Null Detector connections as shown for Voltage or Current)
- i. At 'ON+' zero output from both source and 4705, trim the Null Detector for null.
- ii. At the required positive DC level, calibrate the 4705 Range gain.

This sequence ensures that the 4705 'ON+' and 'ON-' zeros are both set to absolute zero, and that both positive and negative polarities are accurately gain-calibrated to a unipolar source. If it is required to check the 4705 'ON-' gain calibrations against a bipolar source, the source's 'ON-' zero offset must first be nullified, as described in c. i. above.

SECTION 2 FAULT DIAGNOSIS

WARNING

HAZARDOUS ELECTRICAL POTENTIALS ARE EXPOSED WHEN THE INSTRUMENT COVERS ARE REMOVED. ELECTRIC SHOCK CAN KILL

2.1 INTRODUCTION

2.1.1 Use of Diagnostic Guides

The diagnostic guides given in Section 2.2 are intended to aid the user in locating a failed printed circuit board or other assembly. The self-diagnostic capabilities of the instrument provide the first step in fault analysis by displaying a FAIL message on the mode display. Initial actions to be taken after the occurrence of a FAIL message are given, where applicable, in the diagnostic guides of Section 2.2. The FAIL message localizes the failure into a distinct functional area and the "Fault Condition" summary in each guide relates the function failure to a probable hardware boundary.

The identities of the assemblies involved in the failure are given beneath the fault condition summary, but it is unlikley that all assemblies listed will prove to be faulty. For successful failure analysis, it is advisable to be familiar with the electronic functioning of the instrument and with the physical location of the assemblies. To assist in these aspects, the diagnostic guides include references to relevant parts of this publication.

2.1.2 Effects of Protective Measures on Diagnosis

2.1.2.1 Protective Suppression of Fault Conditions

The 4705 incorporates built-in protection in hardware and software. To minimize damage, protective circuitry acts immediately, backed up by a pre-programed CPU response to detected failure symptoms. If possible the CPU informs the user by presenting a failure message on the MODE display.

When investigating a failure, it should therefore be anticipated that protective measures will have suppressed the original fault conditions. A useful starting-point is to identify the origin of the failure message to localize the area of search.

2.1.2.2 FAIL 5 as Default State

Faults which result in display messages FAIL 2, 3 or 4 can pose a safety hazard to the operator, and apply excessive voltage to external circuitry. To protect against this, the instrument is programmed to default to FAIL 5 state as rapidly as possible after its initial response to the failure symptoms. The CPU switches Output OFF and trips the safety monitor (Watchdog). If the conditions of the original failure message have been removed the display changes to FAIL 5.

CAUTION

The instrument warranty can be invalidated if damage is caused by unauthorised repairs or modifications. Check the warranty detailed in the "Terms and Conditions of Sale". It appears on the invoice for your instrument.

In normal use, an operator will probably notice only FAIL 5, and miss the original failure message. In FAIL 5 state, front panel control is inhibited until Safety Reset is pressed. This returns the instrument to the state for which the original fault conditions and failure message were produced, but with Output OFF.

2.1.2.3 To Observe the Original Failure Message

Two procedures can be used:

- a. Carry out the self-test routine of Section 2.3. The failure message may recur during this test.
- Reset the instrument to reproduce the fault, carefully watching the MODE display.
 The original failure message could reappear momentarily, prior to defaulting into FAIL 5.
- Then select the appropriate diagnostic guide in Section 2.2.

2.1.3 FAIL 6

FAIL 6 reports two types of NV RAM failure.

a. Overall sumcheck failure.

The values are calculated at Power on, Self-Test and recovery from FAIL). If the instruments stored calibration constants are outside maximum or minimum permissible values a Fail 6 message is displayed.

b. Limits check of the calibration constants. Values are checked when read from the NV RAM at every OUTPUT change. When a Fail 6 occurs the output remains on and the stored gain or zero correction value is defaulted to x1 or x0 respectively.

2.2 DIAGNOSTIC GUIDES

2.2.1 FAIL 1 (Excessive Internal Temperature)

INITIAL ACTION

- 1. Wait approximately 1 minute until the CPU has defaulted the instrument to OUTPUT OFF. The CPU clears the FAIL 1 message and enables the keyboard.
- 2. Switch OUTPUT ON.
- No failure display no further action. FAIL 1 recurs fault persists.

FAULT CONDITION

High temperature sensed in:

- Positive Heatsink Assembly, or
- Negative Heatsink Assembly.

Fault indication signal OVERTEMP active.

POSSIBLE FAULT LOCATIONS

- Positive Heatsink Assembly (page 11.13-1).
- Negative Heatsink Assembly (page 11.13-2).
- Power Amplifier Assembly (page 11.9-1).

FURTHER INFORMATION IN THIS HANDBOOK

Technical Descriptions: Section 7.12.9.

2.2.2 FAIL 2 (Over-Voltage)

INITIAL ACTION

- 1. Ensure that OUTPUT is OFF
- (4700 should have tripped to FAIL 5).
- 2. Power OFF any external voltage source.

N.B.

- This failure can be caused by injection of an <u>external</u> voltage across the terminals OR the output of high voltage when not requested by the user.
- DC voltages in excess of 130V.
- AC voltages between the limits of 75V to 110V RMS.
- 2. Disconnect external leads from the terminals.
- 3. Press Safety Reset.
- 4. Carry out self-test sequence.
- 5. FAIL 2 recurs fault persists.
- No failure display Reproduce original conditions in Local Sense with no external connections.
- 7. No failure display check external circuit and proceed with careful use.
- 8. FAIL 2 recurs fault persists.

FAULT CONDITION

- 1. Over voltage circuit on the DC Assembly has detected the excess voltage between PHi and PLo lines and has activated HV ST signal to the CPU, and
- 2. The CPU has recognized that the instrument is not in High Voltage State, so has generated FAIL 2 display, then
- 3. The CPU has switched Output OFF, tripped the watchdog and generated FAIL 5 display.

POSSIBLE FAULT LOCATIONS

- Injection of external voltage.
- D.C Assembly (page 11.5-1).
- Power Amplifier Assembly (page 11.9-1).

FURTHER INFORMATION IN THIS HANDBOOK

Self-test procedure: Section 2.3. Technical descriptions: Section 7.3.7.

INITIAL ACTION

No immediate action required.

FAULT CONDITION

- 1. Control data corrupted.
- 2. CPU has detected errors in serial transfer of data between outguard and in-guard circuits, and generated FAIL 3 display, then
- The CPU has switched Output OFF, tripped the watchdog and generated FAIL 5 display.

POSSIBLE FAULT LOCATIONS

- Reference Divider Assembly (page 11.4-1).
- Analog Interface Assembly (page 11.3-1).

FURTHER INFORMATION IN THIS HANDBOOK

Technical descriptions: Section 6.4.

2.2.4 **FAIL 4** (Precision Divider Fault)

INITIAL ACTION

No immediate action required.

FAULT CONDITION

- 1. Precision divider fault.
- 2. CPU has detected errors in the most-significant data bits set in the precision divider input data latches, and generated FAIL 4 display, then
- 3. The CPU has switched Output OFF, tripped the watchdog and generated FAIL 5 display.

POSSIBLE FAULT LOCATION

• Analog Interface Assembly (page 11.3-1).

FURTHER INFORMATION IN THIS HANDBOOK

Technical description: Section 6.5.2.3.

INITIAL ACTION

Use the checking sequence below, watching the MODE display carefully at each stage to detect any FAIL number appearing immediately before FAIL 5. If no failure message occurs, carry on to the next stage.

- Stage 1: Press Safety Reset.
- Stage 2: Carry out self-test sequence (Section 2.3).
- Stage 3: Set Output ON.
- Stage 4: Proceed with careful use.

If FAIL 2 occurs at stage 3, ensure that it is not due to injection of an exessive external voltage by disconnecting the instrument terminals and repeating the checks. If FAIL 5 alone occurs, proceed to "Fault Condition" below. For any FAIL other than FAIL 5, transfer to the diagnostic guide for that message.

FAULT CONDITION

18mS monostable (M10 in reference divider) has been deprived of at least two trigger pulses and has timed out, activating "BARK" and "BARK DELAYED" (BARK +47mS) signals from M13 in the reference divider assembly.

Summary of "BARK" effects:

- 1. Removes the drive from the High Voltage (1kV) transformer.
- 2. Disables the 400V Power Supply.
- 3. BARK status message sent to CPU signalling a failure.
- 4. CPU starts controlled shut-down.

Summary of "BARK DELAYED" effects:

- 1. Disconnects the voltage Power and Sense circuits from the instrument output terminals.
- 2. BARK DELAYED disables the registers of the serial/parallel data converters.
- 3. Outputs from control latches in the reference divider pcb are disabled by setting into "Tristate". Each output line has a pull-up or pull-down resistor which sets the analog circuitry into a safe condition.

POSSIBLE FAULT LOCATIONS

- Digital Assembly (No gated WRT STRB pulses at J2/J3-29) (page 11.2-1).
- Analog Interface Assembly (No SSDA strobe pulses; or Watchdog disabled) (page 11.3-1).
- Reference Divider Assembly (Incorrect functioning of Watchdog setup circuitry) (page 11.4-1).

NB.

The Watchdog is designed primarily to ensure that CPU malfunctions do not set up dangerous conditions in the analog circuitry.

FURTHER INFORMATION IN THIS HANDBOOK

Technical description: Section 6.4.

2.2.6 FAIL 6 (Calibration Memory Fault)

INITIAL ACTION

- 1. Select Output OFF, Spec OFF, Error OFF.
- 2. Perform self-test sequence (Section 2.3) or select Output ON at the requested value.
- 3. No failure display no further action.
- 4. FAIL 6 recurs recalibration required.
- 5. Select Cal (refer to Section 1).
- 6. Recalibrate (refer to Section 1).
- 7. Calibration failure fault persists.

FAULT CONDITION

Calibration memory fault on Digital pcb assembly.

POSSIBLE FAULT LOCATION

• Digital Assembly (page 11.2-1)

FURTHER INFORMATION IN THIS HANDBOOK

Self-test procedures: Section 2.3. Calibration procedures: Section 1. Technical descriptions: Section 6.1.

2.2.7 FAIL 7 (P.A. 400V Power Failure)

INITIAL ACTION

- 1. Switch power OFF.
- 2. Check line supply is correct for input voltage setting.
- 3. Switch power ON no failure display no further action.
- 4. FAIL 7 recurs fault persists.

FAULT CONDITION

- Positive or Negative 100V power supply failure
- Fault indication signal 400V(2) FAIL active
- Check line input voltage

POSSIBLE FAULT LOCATIONS

- Power Amplifier Assembly (page 11.9-1).
- Reference Divider Assembly (page 11.4-1).
- Positive Heatsink Assembly (page 11.13-1).
- Negative Heatsink Assembly (page 11.13-2).
- Power Supply/I Heatsink Assembly (page 11.13-3).
- Mother Board (page 11.16-1).

FURTHER INFORMATION IN THIS HANDBOOK

Technical descriptions: Sections 6.7.

2.2.8 FAIL 8 (P.A.38V Power Failure)

INITIAL ACTION

- 1. Switch power OFF.
- 2. Check line supply is correct for input voltage setting.
- 3. Switch power on no failure display no further action.
- 4. FAIL 8 recurs fault persists.

FAULT CONDITION

- Positive or Negative 38V power supply failure.
- Fault indication signal 38V(2) FAIL active.
- Check line input voltage.
- It is possible for a misleading FAIL 8 message to occur, caused by a logic supply failure, in particular -15 Volts. The FAIL 9 message will have been displayed momentarily. Refer for fault location and further information to FAIL 9.

POSSIBLE FAULT LOCATIONS

- Power Amplifier Assembly (page 11.9-1).
- Reference Divider Assembly (page 11.4-1).
- Power Supplies (page 11.12-1).
- Mother Board (page 11.16-1).

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FURTHER INFORMATION IN THIS HANDBOOK

Technical descriptions: Section 6.7.

2.2.9 FAIL 9 (P.A. 15V Power Failure)

INITIAL ACTION

- 1. Switch power OFF.
- 2. Check line supply is correct for input voltage setting.
- 3. Switch power on no failure display no further action.

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4. FAIL 9 recurs - fault persists.

FAULT CONDITION

- Positive or Negative 15V power supply failure. This is indicated by a transitory Fail 9 followed by Fail 8.
- Fault indication signal 15V(2) FAIL active.
- Also 400V power supply is disabled.
- Check line input voltage.

POSSIBLE FAULT LOCATIONS

- Power Amplifier Assembly (page 11.9-1).
- Reference Divider Assembly (page 11.4-1).
- Power Supplies (page 11.11-1).

FURTHER INFORMATION IN THIS HANDBOOK

Technical descriptions: Section 6.7.

2.2.10 Error EF (External Frequency selected but not detected)

INITIAL ACTION

- If External Frequency Lock is not required: Ensure external frequency selection switch (\$53) is set to OFF.
- If External Frequency Lock reference is required:
- 1. Ensure reference frequency is available at Rear Panel connector J53.
- 2. Ensure Rear Panel switch S53 is set to ON.

FAULT CONDITION

• The external reference signal detector has set 'EXT REF ST' to Logic Ø.

POSSIBLE FAULT LOCATIONS

- External circuit.
- Interconnection Assembly (page 11.17-2).
- Mother Assembly (page 11.16-4).
- Analog Interface Assembly (page 11.3-4).

FURTHER INFORMATION IN THIS HANDBOOK

Technical descriptions: External Frequency Lock: Section 8.3. 2.2.11 Error OL (Voltage: Output current limit exceeded) (Current: Output compliance voltage limit exceeded)

INITIAL ACTION

- If Voltage range selected:
- 1. Set Output OFF (Automatic if 100 or 1000V range selected).
- 2. Disconnect external circuit.
- 3. Set Output ON:

- If no Error OL or FAIL message, check external circuit for low resistance, drawing output current in excess of specification (refer to User's Handbook *Section 6*). Ensure Capacitive Load constraints are not exceeded, *page 6.7*.

- If Error OL recurs, internal fault persists.

- If I range selected:
- 1. Set Output OFF.
- 2. Short Output terminals I+ to I-.
- 3. Set Output ON:

- If no Error OL or FAIL message, check external circuit for high resistance, developing output voltage in excess of compliance limit.

- If Error OL recurs, internal fault persists.

FAULT CONDITION (IN DC RANGES)

- If Low DC Voltage range (100µV -10V): DC Overcurrent Detector circuit (Vol 2 page 11.5-2) has detected a current in the PLO(DCV) line of approx 28mA or more, and has activated LIM ST signal to the CPU.
- If High Voltage range (100V or 1000V): Either
- a. DC Overcurrent Detector circuit (Vol 2 page 11.5-2) has detected excessive current in the PLO(DCV) line and has activated LIM DET signal to the CPU, or
- b. DC 1000V Over-Voltage detector (Vol 2 page 11.14-2) has detected an output voltage in excess of 1440V and has activated LIM DET signal to the CPU.

In either condition **a**. or **b**., M10 in the power amplifier removes the 16kHz drive from the input to the PA, and generates HI I ST signal to the CPU; which responds by setting Output OFF, and DC Reference voltage to zero.

If I range selected:

Overvoltage detector circuit (M15 in I/ohms Assembly) has detected a terminal voltage of 4.4V or more and has activated LIM ST signal to the CPU. If 100mA or 1A range selected, the CPU switched Output OFF and reduces DC Reference voltage to zero.

FAULT CONDITION IN AC RANGES

If 1mV, 10mV, 100mV or 1V Range:

Sine Source Assembly overcurrent sense circuit (M49a/M49b) has detected a current in the AC 1V line of approximatly 25mA RMS or more, and has activated LIM ST signal to the CPU.

If 10V range:

10V overload detector in the Power Amplifier Assembly has detected a current in the I+ line of approximately 60mA RMS or more. In this condition a hardware limit comes into effect.

- If High Voltage ranges (100V or 1kV): Either
- a. 100V Overload detector in the Power Amplifier Assembly has detected a load in excess of 120mA RMS on the 400V power supply,
- b. 1kV Current Overload detector (M8) in the Output Control assembly has detected an excessive output current, or
- c. 1k Overvoltage Detector in the Output Control Assembly has detected a voltage on the PHI(V) line in excess of 1440V RMS.

In these ranges the output is switched off automatically by the CPU.

If I range selected:

Overvoltage detector circuit has detected a terminal voltage of 3V RMS or more and has activated LIM ST signal to the CPU. If 100mA or 1A range selected, the CPU switched Output OFF.

POSSIBLE FAULT LOCATIONS

- External circuit.
- Sine Source Assembly (page 11.6-1).
- AC Assembly (page 11.7-1).
- DC Assembly (page 11.5-1).
- Power Amplifier Assembly (page 11.9-1).
- I/Ohms Assembly (page 11.8-1).

FURTHER INFORMATION IN THIS HANDBOOK

Technical descriptions:

Low DC Voltage ranges: Section 7.3 and 7.6. Low AC Voltage ranges: Section 9.4. 100 or 1000V ranges: Section 9.5. I ranges: Section 10.

2.3 SELF-TEST SEQUENCE

2.3.1 General

The self-test sequence is performed in two stages:

Stage 1 is a fully automated test of safety monitoring and high-voltage safety interlocks;

Stage 2 is a semi-automatic test of keyboard and display functions, which also responds to operator's key selections.

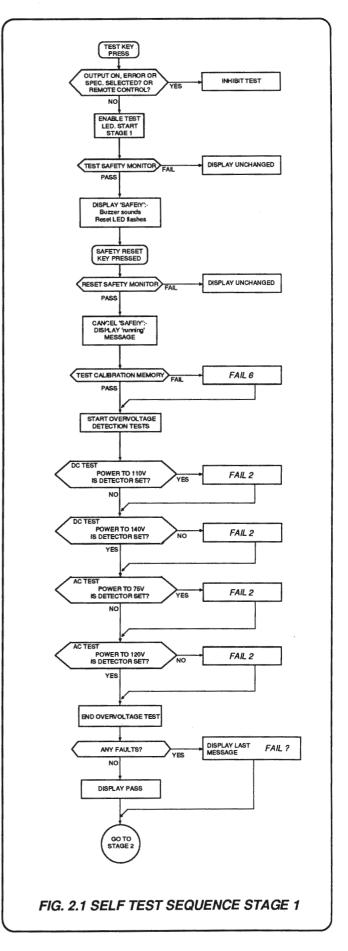
2.3.2 Stage 1 (Fig. 2.1)

Entry into Stage 1 is selected automatically whenever the TEST key is pressed for the first time (the test is not allowed if OUTPUT ON, ERROR or SPEC are selected or when in remote control). Indication of test mode is given by the LED in the TEST key being lit. The full sequence of Stage 1 must be completed before exit from the test mode can be made. The tests performed in Stage 1 are as follows:

- 1. Safety Monitor Watchdog Test. In this, the safety monitor is tripped causing the word SAFEtY to appear in the Mode display, the Safety Reset LED flashes and the buzzer sounds continuously. It is necessary for the operator to reset the safety monitor by pressing the Safety Reset key, after which the SAFEtY display is replaced by the 'running' message, and the test sequence continues.
- Calibration Memory Test. The contents of the non-volatile calibration RAM are checked for validity. Failure results in the message FAIL 6 appearing on the Mode display.
- 3. High-voltage Protection. This test ensures that a voltage demand made to the power amplifier does not trip the software voltage detector when immediately below the detector threshold level, but when raised to a level above the detector threshold the detector is tripped.

Incorrect detect action is shown by the message FAIL 2 on the Mode display. No voltages appear at the output terminals during this test.

Fail messages are updated as the test sequence progresses through the calibration memory and high-voltage tests. After completion of the high-voltage test, the test mode ends and the Test LED is cancelled. If faults were encountered the last FAIL message will remain on the display replacing the running message. Fault diagnosis can now be performed. If no faults are encountered during Stage 1, the message PASS is displayed. The calibrator can now be returned to normal operation, or Stage 2 of the self-test sequence can be selected.



.3.3 Stage 2 (Fig. 2.2)

intry into Stage 2 of the self-test sequence is made when the Test ey is pressed AFTER the completion of Stage 1. and BEFORE any ther key.

The test proceeds by sequentially displaying all segments and egends.

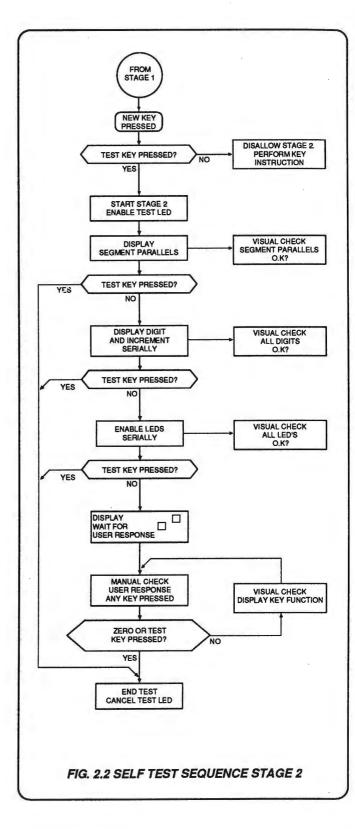
The test continues, showing segment-by-segment, all seven-segment ligits, legends and commas.

After all digits have been displayed, the keyboard LED indicators are it in a sequence which proceeds from left to right. (Test LED emains lit).

The next test in the sequence requires operator participation in order o check key functions. Two half-digit symbols are shown on the node display to indicate that the keys are ready to be checked.

Departion of Up, Down and Output Selection keys are shown by a ymbol on the display immediately above the key; operation of 'requency Range, Mode, Range, Function and Output keys are hown by the key's LED. In these tests the display or LED remains it until another key is pressed.

At any part of Stage 2, pressing Test or Zero key will end the test ind cancel the Test LED.



2.4 FUSE PROTECTION

In addition to the electronic protection devices used in the instrument, fuses are provided to protect against catastrophic component failure.

2.4.1 Fuse Replacement

A blown fuse is merely a symptom of failure, in the large majority of cases the cause lies elsewhere.

CAUTION

Every occurrence of a blown fuse should be investigated to find the cause. Only when satisfied that the cause is known, and has been removed, should a user replace a fused link by a serviceable item.

2.4.2 Reasons For Fusing

The fuses in the calibrator fall into two groups:

- a. Clip-in anti-surge fuses in the Power Supplies and Mother Board protect the power source from damage.
- b. Soldered-in fuses are used in some locations to ensure that the printed circuit tracks are protected in the unlikely event of extreme failure conditions.

2.4.3 Locating a Blown Fuse

The ultimate causes of blown fuses are so extensive that it is impractical to list them. In many cases the underlying cause, or the blown fuse itself, will activate an electronic protective process which can conceal some of the symptoms.

Fault location in the Calibrator should proceed from the primary indications of fault condition (e.g. failure messages described in Section 2.2). These will lead to particular areas of investigation, and at this point the relevant circuit fuses should be checked first. Whether fuses are blown or not, the checks will add to the information available for further diagnosis. Table 2.1 is indexed in Circuit Diagram page order, giving fuse values. The types of fuses to be used can be found in the component lists of Section 12.

Table 2.1 (overleaf) lists their locations.

LOCATION AND DESIGNATOR	VALUE/FITTING	PROTECTED CIRCUITS	Page
DC Assembly			
F1	1A/Solder-in	DC 10V, 100V & 1kV Error	11.5-1
F2	250mA/Solder-in	SHI(DCV)	11.5-2
F3	1A/Solder-in	Power Lo/Guard	11.5-2
F4	1A/Solder-in	Power Lo	11.5-2
F5 F6	1A/Solder-in 1A/Solder-in	DC 1kv PHI(V)	11.5-1 11.5-2
AC Assembly			
F1	1A/Solder-in	1V range only & Current ranges up to 10mA	11.7-1
F2	1A/Solder-in	All AC Voltage ranges (PHI(ACV))	11.7-1
I/Ω Assembly			
F1 Not used			44.0.0
F2	375mA/Solder-in	PLO(Ohms)	11.8-3
F3	1A/Solder-in	SLO(Ohms)	11.8-3 11.8-3
F4 F5	375mA/Solder-in 2.5A/Solder-in	PHI(Ohms) All Current/Ohms Outputs	11.8-1
Power Supply (OG)			
F1	4A/Clip-in	Digital and Display supplies	11.10-1
Power Supply (IG)			
F1	4A/Clip-in	Supplies -22V(2)	11.11-1
F2	4A/Clip-in	Supplies +22V(2)	11.11-1
F3	3.15A/Clip-in	Supplies +15V(2)	11.11-1 11.11-1
F4 F5	3.15A/Clip-in	Supplies -10V(2), -15V(2) Supplies -8V(2)	11.11-2
F6	1A/Clip-in 1A/Clip-in	Supplies -8V(2) Supplies +8V(2)	11.11-2
Power Supply (38V)			
F1	1A/Solder-in	-38V Supply Line	11.12-1
F2	1A/Solder-in	+38V Supply Line	11.12-1
Mother Board		T (
F1	1A/Clip-in	Transformer secondary to 400V PSU	11.16-5
F2	1A/Clip-in	Transformer secondary to 400V PSU	11.16-5
F3 F4	2.5A/Solder-in 2.5A/Solder-in	Transformer secondary to 38V PSU Transformer secondary to 38V PSU	11.16-5 11.16-5
Power Input Module			
220/240V	3A/Clip-in	All circuits	11.18-6
100/120V	6.25A/Clip-in	All circuits	11.18-6

TABLE 2.1 FUSE LOCATION AND PURPOSE

SECTION 3 DISMANTLING AND REASSEMBLY

3.1. GENERAL PRECAUTIONS

3.1.1 WARNINGS

- 1. ISOLATE THE INSTRUMENT FROM LINE SUPPLY BEFORE ANY DISMANTLING OR REASSEMBLING.
- THE COMBINED REMOVAL TOP 2. OF AND BOTTOM COVERS, GROUND/GUARD AND ASSEMBLIES REAR PANEL ASSEMBLY LEAVES THE MOULDED INTERNAL CHASSIS THIS CAN CONSTITUTE A UNSUPPORTED. SAFETY HAZARD TO BOTH PERSONNEL AND EQUIPMENT.

3.1.2 CAUTIONS

- 1. REMOVAL OF THE TOP GROUND/GUARD ASSEMBLY INVALIDATES MANUFACTURER'S CALIBRATION CERTIFICATION.
- 2. HANDLE THE INSTRUMENT CAREFULLY WHEN INVERTED, TO AVOID SHAKING PRINTED CIRCUIT BOARDS LOOSE.
- 3. DO NOT TOUCH THE PCB EDGE CONNECTORS.
- 4. ENSURE THAT NO WIRES ARE TRAPPED WHEN FITTING GROUND/GUARD ASSEMBLIES.
- 5. DO NOT ALLOW WASHERS, NUTS ETC. TO FALL INTO THE INSTRUMENT.

3.2 General Mechanical Layout (Volume 2, pages 11.0-1 and 11.18-1 to 11.18-7).

All circuits are housed within a single unit on printed circuit board assemblies, the eight major PCBs being plugged into a "Mother" PCB assembly. The 4705 MULTIFUNCTION CALIBRATOR can be used as a bench-top instrument, or it may be rack mounted in a standard 19" rack.

3.2.1 Front Panel

Six output terminals with captive, insulated caps are provided. Alternatively, the terminals can be fitted to the rear panel (Option 42) at manufacture (*page 11.19-2*).

A printed overlay on the front panel labels all the controls, and retains polarizing filters for the displays.

3.2.2 Rear Panel

The recessed Power Input plug, Power Fuses and Line Voltage Selector are contained in an integral filter module at the centre of the rear panel.

The Calibration Enable switch (with removable key), and the External Frequency Input BNC socket (J53) are mounted directly on the panel between the Power Input module and the cooling-air intake filter.

The intake filter is retained by a grille but is removable for cleaning. At the extreme left of the panel, an extractor fan draws cooling air through the filter and internal heat exchangers, discharging to atmosphere.

The IEEE 488 standard connector socket (J27) with instrument address switch, the Calibration Interval Switch and the external frequency switch (S53) are all mounted on the Interconnection PCB assembly. This is fitted on spacers to the inside face of the panel with external components protruding to the rear. Socket J54 is provided to facilitate future expansion.

3.3.1 External Construction

Rigid side extrusions, together with the front and rear panel assemblies, form the basic chassis of the instrument. The side extrusions have handles and rear spacers fitted for bench-top use, or are fitted with 'ears' and slides for rack mounting (see User's Handbook, *Section 2*).

The top cover locates into the side extrusions and is secured by screws. The bottom cover is attached in the same way, and includes six domed feet. An operator's instruction card pulls forward from below.

3.3.2 Internal Construction

The chassis is enclosed top and bottom by ground and guard screens. The upper ground and guard screens allow most internal adjustments to be performed without removal. Locations of adjustable components, instructions and warnings are printed on its upper surface.

The interior of the chassis is divided into two compartments. A thermally-enclosed compartment occupies the forward half of the chassis, and is used to house the low power, precision printed circuit board assemblies.

The rear compartment contains high power components, is air-cooled and further subdivided. One section is positioned across the intake airflow, housing the In-guard and Out-guard Power Supply assemblies and providing anchorage for the Mains (Line) Transformer assembly. The other section houses three Heatsink assemblies, provides anchorage for the LF Transformer assembly, High Voltage assembly and 38V Power Supply assembly.

Filtered air passes over the power supplies, mixes with air in the rear compartment, is drawn through the heatsink assemblies, and is finally expelled from the instrument by the extractor fan.

Guard screens are provided against the outer walls of the power supply sub-compartment and the heatsink compartment.

Interconnections between the Power Amplifier assembly, all forwardcompartment assemblies, and the Front assembly are made via a Mother PCB. The latter fits across the bottom of the forward compartment, extending at the front to the Front assembly and at the rear to the 38V Power Supply. Four moulded stiffeners keep the mother pcb rigid, also providing lateral locating slots for printed circuit boards and guard screens.

The main printed circuit boards in the forward compartment fit across the full width of the instrument chassis. They slide into vertical slots cut into the moulded chassis, their PCB edge-connection fingers making electrical contacts with sockets mounted on the Mother Assembly. Interleaved between the assemblies are screening shields. These are also guided by slots, and make similar electrical contact.

The Power Amplifier assembly PCB slots in behind the forward compartment across the full width. It connects to the Mother PCB in the same way, but has additional discrete electrical connections for the high power lines.

Each PCB is identified by the color of its ejector lever. The color name is coded at its correct location on the top of the internal moulded chassis (refer to *Table 3.1*). Also, each assembly's edge connector is uniquely configured to prevent incorrect fitting.

The Front PCB assembly, carrying the display components, connects into the front end of the mother PCB outside the thermally-insulated compartment.

3.4 GENERAL ACCESS

- ENSURE THAT POWER IS OFF.
- Heed the General Precautions 3.1.1 & 3.1.2.

If, during a procedure, sufficient access has been obtained then no further dismantling is required.

3.4.1 TOP COVER (11.18-2 Detail 10)

- Removal
- a. Remove the eight M4 x 12mm socket head countersunk screws from cover.
- **b.** Remove cover by lifting at the front.

3.4.2 BOTTOM COVER (11.18-2 Detail 10)

- Removal
- a. Invert the instrument.
- **b.** Remove the eight M4 x 12mm socket head countersunk screws from cover.
- c. Remove cover by lifting at the front.

Fitting

Locate cover at rear first, then reverse removal procedure.

Fitting

Locate cover at rear first, then reverse removal procedure.

- 3.4.3 FRONT PANEL (11.18-4 Detail 6)
- Remove covers 3.4.1 & 3.4.2
- Removal
- a. Remove the four M4 x 8mm taptite screws from the front panel.
- **b.** Remove Earth Connector.
- c. Remove the Front Panel.

Fitting

Reverse the removal procedure, referring to Page 11.18-4.

3.4.4 TOP GROUND/GUARD SHEET (11.18-2 Detail 9)

- Removal of the Top ground/guard shield involves breaking Datron's calibration seal and renders manufacturer's calibration invalid.
 - Instrument cooling air-flow adversly affected. Internal temperature rise triggers Fail 1. Power OFF and allow to cool as required. Remove the top cover (*para. 3.4.1*).
- Removal

Fitting

a. Refer to Page 11.18-2 Detail 9 and remove:

- i. ten M4 x 8mm pozi-countersunk screws
- ii. six M3 x 6mm pozi-pan screws and M3 shakeproof washers
- iii. one M3 x 12mm pozi-pan screw and M3 shakeproof washer
- b. Remove the top ground/guard assembly.

3.4.5 BOTTOM GROUND SHEET (Page 11.18-1 Detail 8)

- Invert the instrument
- Remove the bottom cover (para. 3.4.2).
- Removal
- a. Refer to Page 11.18-1 Detail 8 and remove:
 - i. ten M4 x 8mm pozi-countersunk screws
 - ii. six M3 x 6mm pozi-pan screws and M3 shakeproof washers
- b. Remove the bottom ground sheet assembly.

3.4.6 BOTTOM GUARD PLATE (Page 11.18-1 Detail 7)

- Invert the instrument. Remove the bottom cover (para. 3.4.2). Remove the bottom ground sheet assembly (para. 3.4.5).
- Removal

Fitting

- Refer to Fig. 11.18-1 Detail 7 and remove ten M3 x 6mm pozicountersunk screws.
- b. Remove the bottom guard plate.

Reverse the removal procedure, ensuring that no wiring is strained or trapped.

al

3-4

Fitting

Reverse the removal procedure.

Refer to Page 11.18-2 Detail 9 and reverse the removal procedure.

Note:

Do not remove the Top Ground/Guard sheet (*para 3.4.4*) if only selecting pre-cal, erasing cal memory, removing Instruction Card or Rear Panel.

In addition to the following Location instructions, refer to Volume 2 page 11.0-1.

Assembly	Access Required (Heed Caution 3.1)	Location (Page Detail in bracket)	Ejector Color	Section	Page (Vol 2)
Instruction Card	-	11.18-2 (11)		3.5.1	-
Front Assembly	3.4.5	11.18-3 (4)	-	3.5.2	11.1-1
Digital Analog Interface Reference Divider Output Control Sine Source AC Current	3.4.4	Chassis Identifier Code BLK BRN RED ORG YEL GRN BLU	BLACK BROWN RED ORANGE YELLOW GREEN BLUE	3.5.4	11.2-1 11.3-1 11.4-1 11.5-1 11.6-1 11.7-1 11.8-1
Common Guard and Ground Screens	3.4.4	11.18-5 (13)	-	3.5.6	•
Power Amplifier	3.4.4	11.18-1 (4) VLT	VIOLET	3.5.8	11.9-1
Power Supplies Out-Guard In-Guard ±38V	3.4.4	11.18-1 (1) 11.18-1 (2) 11.18-1 (5)	-	3.5.10 3.5.12 3.5.14	11.10-1 11.11-1 11.12-1
Heatsinks	3.4.4	11.18-1 (4)	-	3.5.16	11.13-1
High Voltage	3.4.4	11.18-1 (5)	-	3.5.18	11.14-1
Transformers Mains HF LF	3.4.4	11.18-5 (9) 11.18-4 (6) 11.18-5 (10)	-	3.5.20 3.5.22 3.5.24	11.15-1 11.15-2 11.15-2
Mother Board	-	11.18-3 (3)	-	-	11.16-1
Interconnections	3.5.28	11.18-6 (15)	-	-	11.17-1
Terminal Board	3.4.3	11.18-4 (8)	-	3.5.26	11.17-3
Rear Panel	-	11.18-4 (6)	-	3.5.28	11.18-6
Instrument Assembly	-	-	-	-	11.20-1

TABLE 3.1 INTERNAL LOCATION AND ACCESS

5.1 INSTRUCTION CARD

Pull the instruction card forward to its fullest extent. Bow the card and release the rear lugs from the slots. c. Refit in reverse procedure.

5.2 FRONT ASSEMBLY (Page 11.18-3 Detail 4)

Remove Front Panel (para. 3.4.3)

Removal

Remove two screws retaining the power switch, together with their two shakeproof washers and four plain washers.

Fold the power switch and its cable clear of the pcb.

Remove the M3 x 6mm pozi-pan screws and wavey washers from 11 positions on the circuit board.

Ease the lower edge of the PCB away from the Mother PCB, to disengage the mating connectors.

Remove the assembly.

Fitting

Reverse the removal procedure. Ensure all mating connectors are full engaged and that the surfaces of displays are clean.

.3 MAJOR PCB ASSEMBLIES

ENSURE THAT THE INSTRUMENT POWER IS OFF.

Removal

Identify the PCB assembly to be removed (see Table 3.1)

Place the thumb of each hand under the lip of the two ejectors on the PCB assembly to be removed.

Gently lever the ejectors upwards and outwards to release the edge connectors.

Remove the assembly.

Fitting

- a. Identify the chassis location of the PCB assembly to be fitted (See *Table 3.1 and page 11.0-1*).
- b. Ensure the ejectors are in the 'down' position.
- c. Insert the PCB edges into the identified slots in the side walls of the chassis.
- **d.** Allow the PCB to slide down to the Mother PCB, then press home by gently pushing down on the ejectors.

3.5.4 COMMON, GUARD AND GROUND SCREENS (Page 11.18-5 Detail 12)

- The first screen (counting from front to back) is the Ground Screen and has two securing screws. Of the six remaining screens the first five are aluminium, single screw and interchangable. The rearmost screen is steel and not interchangable Each plate mates with a miniature connector on the mother PCB adjacent to the side wall of the chassis.
- Removal
- a. Remove any adjacent assemblies to obtain access.
- b. Undo securing screw/s.
- c. Grip the plate and lift out from the chassis.

- Fitting
- a. Insert the plate into the correct slots in the side walls of the chassis (ensure correct orientation).
- **b.** Allow the plate to slide down to the Mother PCB, then gently press home.
- c. Secure with a 3 x 6mm Pozi-screw and shakeproof washer (two for the ground screen).
- d. Replace assemblies removed for access.

3.5.5 POWER AMPLIFIER ASSEMBLY (Page 11.18-1 Detail 4)

- Do not pull on the connector wires. Some resistance to movement will be felt from the locking clips of the connector bases.
- Removal
- a. Disconnect the five connectors from the assembly as shown on *Page 11.18-1* Detail 4.
- b. Fold back the connectors and wires clear of the assembly.
- c. Place the thumb of each hand under the lip of the two ejectors.
- **d.** Gently lever the ejectors upwards and outwards to release the edge connectors.
- e. Remove the assembly.

Fitting

- a. Ensure that all wires and connectors are clear of the PCB area.
- **b.** Insert the PCB edges into their respective slots in the side walls of the chassis; component side facing the rear of the instrument.
- c. Allow the assembly to slide down to the Mother PCB taking care not to trap any wires.
- d. Ensure the ejectors are in the 'down' position then press the assembly home by gently pushing down on the ejectors.
- e. Identify and fit the five connectors J1 to J5, as shown on Page 11.18-1 Detail 4.

3.5.6 OUT-GUARD POWER SUPPLY (Page 11.18-1 Detail 1)

- Do not pull on the connector wires. Some resistance to movement will be felt from the locking clips of the connector bases.
- Removal
- a. Disconnect J1, J2, and J3 from the In-Guard Power Supply Assembly.
- b. Disconnect the connector J3 from the PCB.
- c. Fold back the connectors and wires clear of the assembly.
- d. Grip the top edge of the PCB and lift gently from the chassis.
- e. Remove the assembly.

Fitting

- a. Ensure that all wires and connectors are clear of the PCB area.
- **b.** Insert the PCB edges into their respective slots in the chassis sub-compartment.
- c. Allow the assembly to slide down to the miniature connectors on the chassis, taking care not to trap any wires.

- d. Fit the J3 connector to the assembly.
- e. Press the assembly home by gently pushing down on the top edge of the PCB.
- f. Fit J1, J2 and J3 to the In-Guard Power Supply Assembly.

3.5.7 IN-GUARD POWER SUPPLY (Page 11.18-1 Detail 2)

- Do not pull on the connector wires. Some resistance to movement will be felt from the locking clips of the connector bases.
- The Out-Guard Power Supplies components can obstruct the removal of the In-Guard Power Supply. Remove Out-Guard Power Supply Assembly (para 3.5.6)
- Removal
- a. Disconnect the three connectors J1, J2 and J3 from the PCB.
- b. Fold back the connectors and wires clear of the assembly.
- c. Grip the top edge of the PCB and lift gently from the chassis.
- d. Remove the assembly.

Fitting

- a. Ensure all wires and connectors are clear of the PCB area.
- **b.** Insert the PCB edges into the respective slots in the chassis subcompartment.
- c. Allow the assembly to slide down to the miniature connectors on the chassis, taking care not to trap any wires.
- **d.** Press the assembly home by gently pushing the top edge of the PCB.
- e. Fit the Out-Guard Power Supply (para. 3.5.6)
- f. Identify and fit the three connectors J1, J2 and J3 as shown on Page 11.18-1 Detail 2.

3.5.8 38V POWER SUPPLY (Page 11.18-1 Detail 5)

- Heed the General Precautions 3.1.
- Removal
- a. Grip the edges of the pcb and pull the assembly vertically upwards. Some resistance will be felt from the edge connector.
- Fitting
- a. Locate the assembly into the guides
- **b.** Apply downward pressure until the connector is felt to have engaged.

3.5.9 HEATSINK ASSEMBLIES (Page 11.18-1 Detail 3)

- Heed the Warnings and Cautions 3.1.1 & 3.1.2. Allow heatsinks to cool before handling. Do not pull on the connector wires. When disconnecting connectors, some resistance to movement will be felt from the locking clips of the connector bases.
- Although the heatsink assemblies are discrete items, removal is simplified when performed in the following order: 1. Negative Heatsink assembly 2. Positive Heatsink assembly 3. Power Supply/Current Heatsink assembly.

Removal

- a. Remove the six M3 x 12mm pozi-countersunk screws from the heatsink retaining plate.
 I1
- b. Remove the heatsink retaining plate.
- c. Disconnect connectors:

J1 at the Negative Heatsink Assembly J2 at the Power Amplifier Assembly

- d. Remove Negative Heatsink assembly.
- e. Disconnect J3 at the Power Amplifier assembly
- f. Remove the Positive Heatsink assembly

. Disconnect at the following points:

J1	Power Amplifier Assembly
J31, J19	Mother Assembly
J1	In-Guard PSU Assembly

h. Remove the Power Supply/Current Heatsink assembly.

Fitting

Reverse the removal procedure. To ensure correct location, orient the PCB side of each heatsink to face inwards

3.5.10 HIGH VOLTAGE ASSEMBLY (Page 11.18-1 Detail 5)

- Removal
- a. Lift the assembly upwards as shown on Page 11.18-1 Detail 5.
- Remove the connections J2, J3, and J4 as shown in the diagram.
- c. Lift the assembly clear of the instrument.

3.5.11 MAINS TRANSFORMER ASSEMBLY (Page 11.18-5 Detail 9)

Remove the Out-Guard and In-Guard Power Supply Assemblies (see paras 3.5.10 and 3.5.12).

Removal

- Disconnect the connectors from the transformer at the following assemblies:
 - J32 Mother Assembly (Page 11.18-1 Detail 3)
 - J6 Interconnection Assembly
 - (fixed on the rear panel see page 11.184 Detail 8)
 - J4 H.V Assembly (Page 11.18-1 Detail 5)
 - J33 Mother Assembly (Page 11.18-1 Detail 3)
- b. Turn the instrument to stand on its left side (on Left Hand extrusion)

- c. Release the four M8 x 110mm bolts, washers and nylock nuts.
- d. Remove the M3 x 8mm pozi-countersunk screw, M3 steel nut and shakeproof washer which secures the solder tag terminals of four ground wires. Fold back the wire which is fitted to the rear panel assembly.
- e. Remove the Mains (Line) Transformer assembly.
- Fitting Reverse the removal procedure, referring to Page 11.18-5 Detail 9.

Fitting

Reverse the removal procedure, referring to Page 11.18-1 Detail 5.

Removal

Fitting

Reverse removal procedure, referring to Fig. 3.1.

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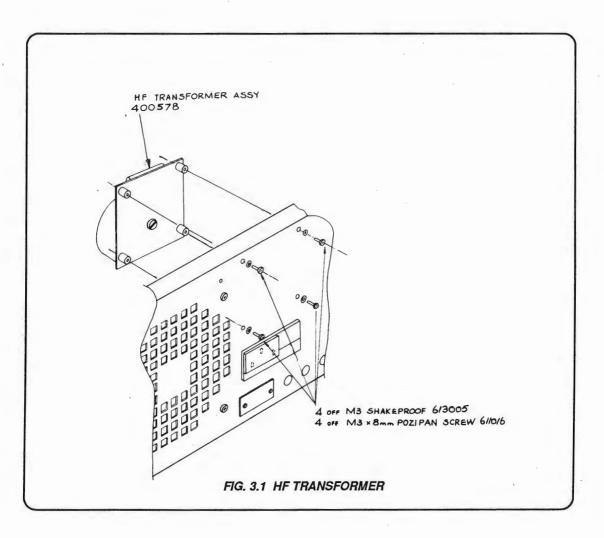
a. Remove four M3 x 8mm pozi-pan screws (see Fig. 3.1).

b. Disconnect connectors at the following points:

J2 - High Voltage Assembly;

J5 - Power Amplifier Assembly.

c. Remove the HF transformer assembly.



LF TRANSFORMER ASSEMBLY (Page 11.15-2 Detail 1 to 4) 3.5.13

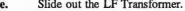
- Remove High Voltage Assembly (3.5.18) and the Heatsinks (3.5.16.)
- Removal •
- Disconnect connector J4 from the Power Amplifier and J3 from я. the High Voltage Assembly (see Fig. 3.2).
- Turn the instrument to stand on its right hand side (on R.H. b. extrusion).
- Desolder J34 from the mother board and connections A, B, M, c. H, K, & L. Unscrew supporting clips.
- From the LF Transformer; remove the four M5 nylock nuts and d. flat steel washers, Remove the pair of transformer assembly M5 x 65mm screws closest to the rear panel and the transformer bolt plate.

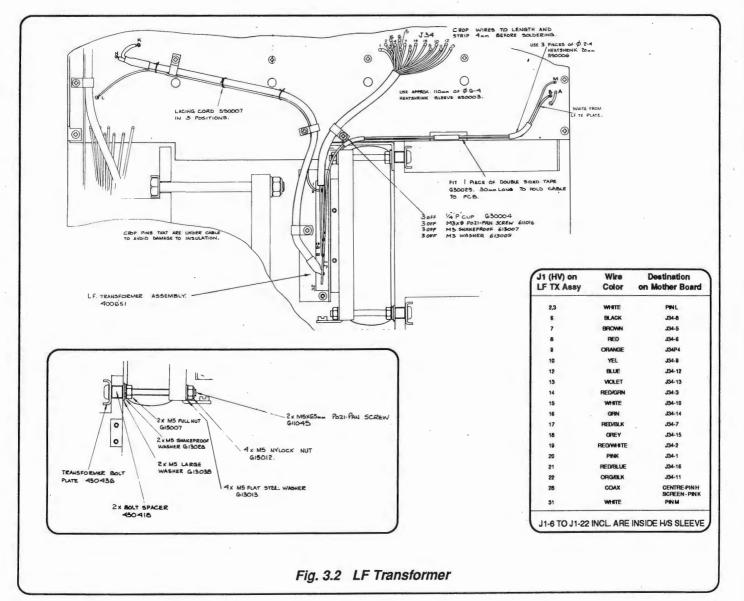
Fitting

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Reverse the removal procedure, referring to Fig. 3.2 and Page 11.15-2 Detail 1 to 4.

Slide out the LF Transformer. e.





4 TERMINAL PCB ASSEMBLY (Page 11.17-3)

Remove Front panel (para 3.4.3).

Removal

Remove the four M3 x 6mm pozi-pan screws (11.18-4 Detail 8)

The terminal board can be tipped down to facilitate component access. If leads are short remove Bottom Guard Plate (*para.* 3.4.6) and desolder as required.

15 REAR PANEL ASSEMBLY (Page 11.18-6)

Do not remove the rear panel assembly when Top and Bottom covers and Ground/Guard assemblies are removed. Perform the following operations with Top and Bottom Covers and Ground/Guard assemblies fitted, or with AT LEAST the Top OR Bottom Ground Sheet assembly fitted.

This procedure provides access to rear panel-mounted components by releasing the Rear Panel assembly and moving it away from the chassis to the extent allowed by internal wiring connections.

Removal

Remove the six screws of the two rear spacers 11.18-4 Detail 7.

Remove the two rear spacers.

Remove the four screws of the filter grill.

Remove the filter grille and filter.

Remove the Pozi-pan screw revealed by the removal of the filter and grill.

Remove the four rear panel screws (Page 11.18-4 Detail 6)

Looking at the rear, locate the upper right hand screw securing the extractor fan. Above this screw, locate an M3 x 6mm Pozipan screw (screw fixing hole only shown on cut-away sketch above Rear Panel in Detail 6 of *page 11.18-4*). Removal of the screw allows the rear panel to be detached.

h. Gently pull the Rear Panel assembly away from the chassis to the extent allowed by the wiring. Do not stress the wires.

Fitting

- a. Press the Rear Panel assembly to the chassis while ensuring that:
 - i. The wires lay in the cut-out in the moulded internal chassis
 - ii. The ribbon cables fit in the recess in the moulded internal chassis
 - iii. All other wires are free and not trapped by the rear panel assembly.
- **b.** Fit screws, filter, filter grille and rear spacers, reversing the removal procedure.

Fitting

Reverse the removal procedure.

SECTION 4 SERVICING & INTERNAL ADJUSTMENTS

4.1 INTRODUCTION

This section provides procedures for any maintenance or calibration operations which require removal of covers or partial dismantling. The operations fall into three Categories:

- A: Routine Servicing (TABLE 4.1a),
- B: Internal Calibration Adjustments (TABLE 4.1b)
- C: Adjustment Following Replacement of PCBs (TABLE 4.1c overleaf).

Category A	Routine Servicing				
Servicing Required	Time Interval	Procedure (Section 4)	Calibration Required	Calibration Procedure	
Clean the Air Intake Filter	1 year (or less in adverse conditions)	4.2	-	-	
Change Lithium Battery (non-volatile calibration memory)	5 years	4.3	(a)Full pre-cal then (b)Full routine recalibration	Sect. 1.4 Sect. 1.2	

TABLE 4.1a.

Indication	Adjustment Required	Procedure (Section 4)	Calibration Required	Calibration Procedure
"ERROR 6" (during Routine Recalibration)	Re-set internal trimmers	4.4	Routine 4-wire & 2-wire Ω	Sect.1.2

Category C	Adjustment Following Replacement of PCBs				
PCB Assembly	Adjustments	Procedure (Section 4)	Pre-cal (Sect. 1.4)	Routine ca (Sect. 1.2)	
Terminal	Capacitive Load Test	4.6	-	Full	
Digital	-	-	Full	Full	
Reference Divider	-	-	Full	Full	
DC	Capacitive Load Test	4.6	-	Full	
Sine Source	-	-	-	Full	
AC	Capacitive Load Test Sense Amp zeros	4.6 4.10	-	Full	
Current/Ohms Assembly	Quiescent Current Compliance Resistance	4.7 4.8 4.4	-	All I range All I range Ohms	
Power Amp	100V PA bias	4.5	-	-	
Mother	Common-mode null	4.9	Full	Full Full	
Out-guard PSU	Common-mode null	4.9	-	Full	
Heatsinks +ve & -ve	100V PA bias	4.5	-	-	
Power supply Current Heatsinks	Quiescent Current	4.7	-	All I range	
HF or LF Transformer	-	-	-	1kV Rang	
Mains (line) Transformer	Common-mode null	4.9	-	-	

TABLE 4.1c.

4.1.1 General Procedure Notes

- a. Set Power OFF before attempting to dismantle the instrument (for dismantling and reassembly instructions consult *Section 3*).
- **b.** If Top ground/guard assembly is removed subsequent testing with Power On should be completed in less than 5 minutes to avoid overheating.
- c. After servicing ensure that all connections have been made (*Section 3, Fig. 3.6*) and that Top and Bottom shields and covers have been replaced. Leave assembled instrument powered-up for at least 1 hour before carrying out any adjustment.
- **d.** Although replacement assemblies are set up by the manufacturer, the internal adjustments recommended in *Table 4.1* must be carried out to ensure correct operation. These adjustments need to be carried out when the assembly is in the user's instrument, in order to account for interaction between assemblies.

WARNING

HAZARDOUS ELECTRICAL POTENTIALS ARE EXPOSED WHEN THE INSTRUMENT COVERS ARE REMOVED.

ELECTRIC SHOCK CAN KILL!

CAUTION

AFTER ANY MAINTENANCE OPERATIONS WHICH INCLUDE REMOVAL OF TOP OR BOTTOM GROUND ASSEMBLY, CARRY OUT THE FULL SELF-TEST SEQUENCE (Section 2.3) BEFORE RETURNING TO NORMAL USE.

DAMAGE CAUSED BY UNAUTHORISED REPAIRS OR MODIFICATIONS CAN INVALIDATE INSTRUMENT WARRANTY. CHECK THE WARRANTY DETAILED IN THE "TERMS AND CONDITIONS OF SALE". IT APPEARS ON THE INVOICE FOR YOUR INSTRUMENT.

4.2 CLEANING THE AIR INTAKE FILTER

(Datron Part No. 450277-1) (Refer to Section 3.14, Fig. 3.8)

4.2.1 Servicing Frequency

The filter should be cleaned at intervals no greater than one year. In dusty conditions the frequency should be increased.

4.2.2 Removal (Fig. 3.8)

- a. Remove the four M3 x 10mm pozi-countersunk screws (11) which retain the filter grille (12).
- b. Remove the filter grille and reticulated foam filter.

4.2.3 Cleaning

- **a.** Wash the foam filter in a dilute solution of household detergent (hand hot). Rinse thoroughly in clean hand-hot water and dry completely, without using excessive heat.
- **b.** Clean the grille, and the grille holes in the rear panel (use a vacuum cleaner and soft brush on the rear panel).

4.2.4 Inspection

Examine the foam filter for wear, replacing if links are broken.

4.2.5 Reassembly

Place the filter in the grille housing and secure the grille to the rear panel using the screws removed in 4.2.2 above.

LITHIUM BATTERY - REPLACEMENT 4.3 (Datron Part No. 920101)

FIRST READ THESE NOTES!

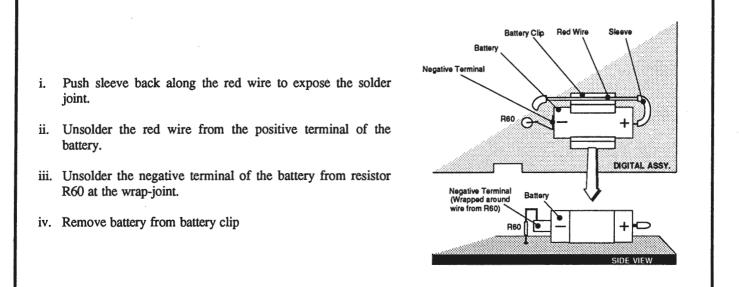
- This procedure is to be performed at intervals of 5 years from new.
- Procedure 4.3.1 allows calibration memory to be retained during battery replacement. This requires the use of an Extender Card (Datron Part No. 400625) to give access to the battery and during its removal provide a supply to the non-volatile RAMs. To ensure memory integrity the soldering iron used must be isolated from mains earth by at least $50k\Omega$.
- Procedure 4.3.3 resets the calibration memory to its nominal state (but does not require the use of an extender card) during replacement of the battery. If this method is used a Precalibration and full Routine Recalibration (Section 1.4 and 1.2) must follow before the instrument specification can be realized, as calibration data will be corrupted. In this case it is therefore recommended that the battery be replaced immediately prior to a scheduled full recalibration.

4.3.1 **Procedure (Calibration Maintained)**

- Ensure that power OFF is selected. a.
- Remove the top cover and top ground/guard assembly (Section 3 paras. 3.2.1 and 3.4.1). b.
- Remove the Digital Assembly from the chassis (Section 3 para. 3.6.4). C. Do not place the assembly on any conducting surface or touch the gold edge connector.
- d. Place extender card in digital assembly slot. Push Digital Assembly onto extender card

Caution

- If the calibrator has been in use; allow to cool for 2 hours. From power ON (step f.) the internal temperature of the instrument will begin to rise. Ensure the procedure is completed within approximately 15 minutes; any Fail 1 message which occurs during this time period can be safely ignored.
- Precautions must be taken to prevent solder or other material falling into the calibrator.
- Ensure continuity of mains supply while battery is disconnected.
 - e. Select power ON. To reduce power dissipation ensure output remains OFF.
 - Remove battery (refer to Fig. 4.1). f.





- g. Fit and solder in a new battery, reversing the procedure of step (f.) Select power OFF (calibration matained).
- h. Refit the Digital Assembly into the chassis (Section 3 para. 3.5.5).

4.3.2 Return to Use

Refit the top ground/guard assembly into the chassis (Section 3 para. 3.4.8). Refit the top cover (Section 3 para. 3.4.2).

 Users having followed procedure 4.3.3 must now carry out Pre-calibration and full Routine Calibration in accordance with Section 1.4 and 1.2 respectively.

4.3.3 Procedure (Calibration lost)

Follow the procedure 4.3.1 (ignore steps (d.) and (e.)) and 4.3.2.

4.4 OHMS FUNCTION-STANDARD RESISTOR ADJUSTMENT

4.4.1 Introduction

Routine adjustment of the standard resistors used in Ω function is not required. A resistor is calibrated by the user entering its measured value into a non-voltaile calibration memory. This value is subsequently recalled and displayed to the user each time the resistor is selected.

4.4.2 'Error 6' Message

'Error 6' is dispalyed if the value entered by the user during calibration is outside the resistor's tolerance (Section 1.2) i.e outside the calibration memory span. Under normal use the resistor drift is well within the tolerance, so 'Error 6' appears only if the user enters an erroneous value.

4.4.3 Undue Resistor Stress

If the resistor has been subjected to undue stress, it is possible that its value may have changed slightly, and be outside its tolerance. If it is less than approximately 50ppm outside tolerance an internal trimmer can be adjusted, and the value can be calibrated.

4.4.4 Possible Damage

A stressed resistor may have been damaged if its value is greater than 50ppm outside its tolerance. It is advisable to have such a resistor tested or replaced by Datron Service Center.

4.4.5 To Reset Internal Trimmers

Follow the procedure detailed in Section 1.7 to adjust the resistor value. If this is unsuccessful contact your Datron Service Center.

4.5 Bias Current Adjustment - 100V PA

(Refer to Layout Drawing 480618 and 480637)

Adjustment of the 100V/1kV amplifier bias voltages must be carried out after fitting a replacement Power amplifier assembly or Heatsink assembly. The following procedure ensures the drain voltages of Q4 and Q2 are +120V and -120V respectively.

USE EXTREME CARE THROUGHOUT THE FOLLOWING PROCEDURES.

4.5.1 Test Equipment Required

Digital voltmeter (any Datron Autocal voltmeter)

4.5.2 Initial Conditions

Remove Top cover. Remove Top ground/Guard assembly. Ensure 38V/400V selector is set to 400V.

4.5.3 Procedure

- a. Set 4705 Power OFF to connect DVM as follows;
- b. Power Amplifier Assembly Connect DVM in DC function, Lo to 2C (near Q20) and Hi to Tab of Q4.
- WARNING. At Power ON (even with Output OFF) the heatsinks are maintained at LETHAL VOLTAGES! Use insulated adjustment tool.
 - c. Select Power ON .
 - d. Positive Heatsink Assembly Adjust R10 for a reading of +120V (5V).
 - e. Power OFF, disconnect DVM.

4.5.4 Return to Use

Refit Top ground/guard shield and Top cover.

CAPACITIVE LOAD TEST

(Refer to Layout Drawing 480536)

AC 1kv current overload detector, on the DC Assembly monitors output current. ERROR OL is displayed when output ent limit is exceeded.

r replacing the DC Assembly, the Terminal assembly, AC assembly, PA assembly, Positive or Negative Heatsinks, or the transformers it is necessary to ensure the limit level is re-set to account for any capacitance changes. The value of R84 will lie /een $2k43\Omega$ and $3k65\Omega$. R84 will be selected from the E96 (1%) series.

1 Test Equipment Required

- a. Test Load ($1k\Omega$ non-inductive resistor, capable of dissipating 20 Watts).
- b. Digital Voltmeter fitted with AC Volts Ranges (any Datron Autocal multimeter)

2 Initial Conditions

Top cover removed. Remove Top ground/guard assembly. Ensure 38V/400V power supply selector set to 400V.

3 Procedure

RNING THE PROCEDURES INVOLVE THE MEASUREMENT OF LETHAL VOLTAGES. USE EXTREME CARE TO AVOID ELECTRIC SHOCK.

- a. Ensure 4705 Power OFF.
- b. On DC board remove Link J, and make Link L. DC assembly must be fitted in chassis (not on extender card)
- c. Monitor Link L with respect to $\sqrt{2B}$ with scope set to 5V per division.
- d. Connect Load resistor across the 4705 output terminals.
- e. Connect the DVM across the Load resistor and select AC 1kV range on DVM.
- f. Set 4705 Power ON.
- g. On 4705 select AC 1kV Range and adjust OUTPUT [↑]↓ keys for 90V on the OUTPUT display. Select 10kHz range and set frequency to 4kHz. Set OUTPUT ON.
- h. Increment demanded voltage and check that 'Scope goes to zero volts when the DVM indicated between 108V and 112V. Select output OFF.

RNING Calibrator Power must be OFF when changing R84. Lethal voltages are present!

- j. If outside limits set in (h.) reselect R84 and repeat from step (f.).
- k. When correct operation occurs solder in R84 break Link L and replace Link J.

4 Return to Use

Refit Top ground/guard shield and Top cover.

4.7 QUIESCENT CURRENT ADJUSTMENT - CURRENT/OHMS ASSEMBLY

(Refer to Layout Drawing No. 480614 and Page 11.8)

To allow a measurement of quiescent current in the power amplifier stage, its power supply lines are broken and a 0.1Ω resistor inserted in series with each 22V supply line. The voltage developed across either of these resistors gives a current measurement. The quiescent current is set by adjustment of R23 on the Current/Ohms Assembly.

4.7.1 Test Equipment Required

- a. Digital Voltmeter (any Datron Autocal voltmeter)
- b. Two 2.5-watt resistors, 0.1Ω , 10%, wire wound (Welwyn W21 or equivalent)

4.7.2 Initial Conditions

Top cover removed. Top ground/guard assembly removed.

4.7.3 Procedure

- a. Switch the 4705 Power OFF.
- **b.** Break the 22V supply connections to the Voltage-to-Current converter power stage by removing connector J1 from the Inguard power supply pcb.
- c. Re-make each 22V supply connection from its female pin on the freed J1 connector to its corresponding male pin on the In-guard P.S pcb, using one 0.1Ω resistor in series with each supply line (Red and Brown wires).
- **d.** Connect the digital voltmeter across one of the 0.1Ω resistors fitted in step (c.).
- e. Switch 4705 Power ON. Select AC Current, 1Amp Range, ensure OUTPUT OFF.

CAUTION In the following (step f.), use a thin insulated screwdriver.

- f. Carefully adjust R23 on I/ Ω assembly for a digital voltmeter reading of 10mV ±1mV (equivalent to 100mA through a 0.1 Ω resistor).
- g. Switch 4705 Power OFF.
- **h.** Disconnect and remove both 0.1Ω resistors and the digital voltmeter from J1. Reconnect J1 to the In-guard Power Supply pcb pins.

4.7.4 Return to Use

Refit top ground/guard assembly and Top cover.

4.8 COMPLIANCE ADJUSTMENT

(Refer to Layout Drawing 480614 Page 11.8)

Ensure that the Quiescent Current Adjustment Procedure has been completed (Section 4.7).

In the following procedure a DVM is used to measure output current as a voltage developed across a load resistor. Series resistance is then added to one of the power leads to establish a compliance voltage. The change in current output due to compliance is measured and an adjustment made to bring the instrument within manufacturer's specification.

4.8.1 Test Equipment Required

- a. Digital Multimeter fitted with AC Volts Ranges. (Datron Instruments model 1081).
- b. Test leads, (each containing a 22.1Ω resistor).
- c. One 2.5-watt load resistor of 0.10Ω , 10%, Wire Wound. (Welwyn W21 or equivalent).
- d. A 1.4Ω resistor to introduce compliance voltage.

4.8.2 Initial Conditions

Remove Top cover. Remove Top ground/guard assembly.

4.8.3 Procedure

- a. Connect the 0.1 Ω load resistor between the 4705 current output terminals (I+/I-).
- b. HF adjustment. Select ACI, 1A full range output at 5kHz. Select OUTPUT ON.
- c. With the DVM, measure the AC voltage across the load and note the reading. Set OUTPUT OFF.
- d. Introduce the 1.4 Ω compliance resistor in series with the I+ lead. Set OUTPUT ON (Test should be done in less than 5 minutes to avoid overheating). Use the DVM to measure the AC voltage across the 0.1 Ω load and note the reading.
- e. Remove compliance resistor. If there is a change of reading >10 μ V between (c.) and (d.) adjust R10 to reduce the change of reading to <10 μ V. After each adjustment of R10 repeat (c.) to (e.).
- f. <u>LF Adjustment</u>. Complete above procedure, leaving the 4705 as selected (ACI, 1A Full Range), but change frequency to 500Hz and limit to 5μV.
- g. If change of reading in (d.) is $>5\mu$ V adjust R31.
- h. If an adjustment was made to R31 repeat complete procedure from (b.) until no further adjustments are required.
- j. Output OFF, disconnect load resistor.

4.8.4 Return to Use

Replace Top ground/guard assembly and Top cover.

4.9 COMMON MODE NULL ADJUSTMENTS

(Refer to Diagram 480561 Page 11.10-1 & Diagram 480604 Page 11.18-4)

The procedure ensures that after replacement of Outguard Power Supply, Mains transformer or Mother Assembly, any power supply noise breakthrough on the Lo or Guard terminals is adjusted to a minimum. Resistor R12 on the Outguard Power Supply Assembly (accessible through a hole in the Top earth shield) is adjusted to minimize the voltage between Lo and Ground. On the Mother Assembly (accessible through a hole in the Bottom ground shield) R25 is adjusted to minimize noise between Guard and Ground.

4.9.1 Test Equipment Required

Oscilloscope (with AC input and sensitivity to 100mV/div).

4.9.2 Initial Conditions

Remove Top and Bottom covers. Ensure all guard/earth screws are correctly tightened.

4.9.3 Procedure

- a. Set 4705 to AC 10V range with Output OFF.
- b. Ensure that the OUTPUT display is 0.000,00 V with local guard selected.
- c. Connect the oscilloscope AC input to the 4705 Guard terminal and the oscilloscope Ground to the 4705 Ground terminal.
- d. Locate R12 on the Outguard Power Supply assembly (accessible through the hole in the Top ground/guard assembly)
- e. Select OUTPUT ON and adjust the oscilloscope controls to obtain the line related noise waveform.
- f. Without touching the Top ground/guard assembly, adjust R12 for minimum waveform amplitude.
- g. Select Remote Guard and obtain a noise waveform.
- h. Locate R25 on the Mother pcb assembly through the hole in the Bottom ground/guard assembly
- j. Without touching the Bottom Ground Assembly, adjust R25 for minimum waveform amplitude.
- k. Repeat procedure from step (b.) to step (j.) until minimum waveform amplitude is obtained.
- I. Select OUTPUT OFF. Disconnect the oscilloscope.

4.9.4 Return to Use

- a. Refit Top cover.
- b. Refit Bottom cover.

4.10 SENSE AMPLIFIER ZEROS

(Refer to Layout Drawing 480663)

The sense amplifier, situated on the AC Assembly, is provided with access holes located in the Top ground/guard shield. In the following procedure the reading and adjustment steps are always taken with the 4705 OUTPUT ON and at one-tenth of the selected Full Range value.

4.10.1 Test Equipment Required

Digital voltmeter (Datron Instruments model 1081 or 1071).

4.10.2 Initial Conditions

Remove Top cover only.

4.10.3 Procedure

- a. Connect the DVM Hi to TP5 on the AC Assembly (accessible via the hole in the upper guard shield). Connect its Lo to the 4705 Lo terminal. On the DVM select the DC 10V range with filter in.
- b. On the 4705 select the AC 100V range, set 10V and 1kHz output. Select OUTPUT ON and adjust R122 for a DVM reading of less than 200μV.
- c. On the 4705 select the AC 10V range, 1V output. Select OUTPUT ON.
- d. Note the DVM reading.
- e. On the 4705 select the 1V range, 100mV output. Select OUTPUT ON.
- f. Note the DVM reading.
- g. Adjust R107 on the AC assembly to set both (d.) and (f.) readings to less than 200µV.
- h. Repeat procedure from (b.) to (g.) until readings are correct and the difference between all ranges is less than 400µV taking polarity into account.
- j. Disconnect the DVM.

4.10.4 Return to Use

Refit Top cover.

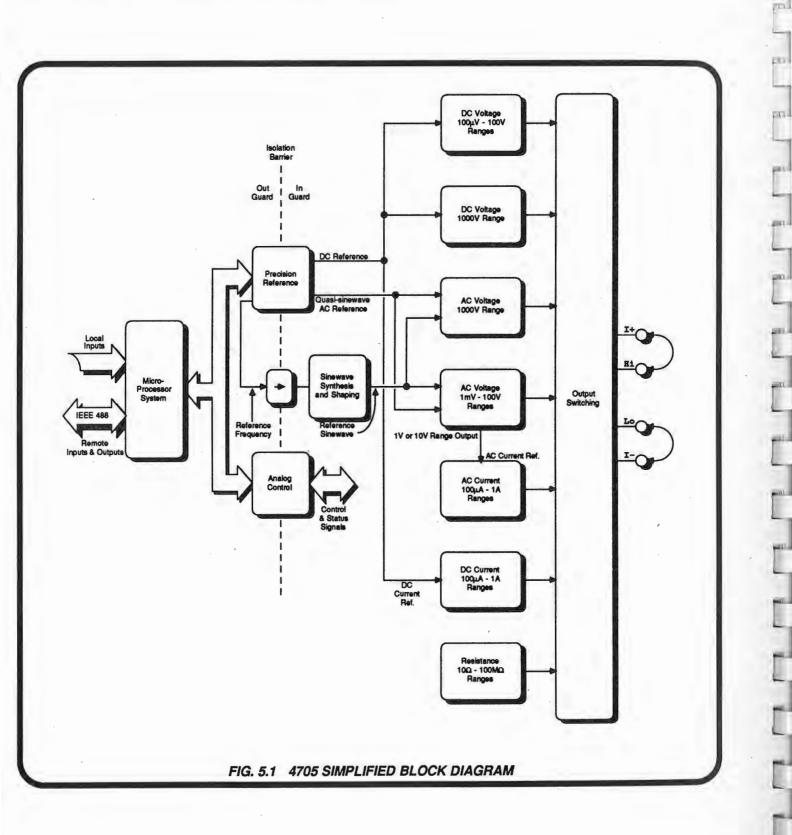
PART 2

TECHNICAL DESCRIPTIONS

SECTION 5	Principles of Operation.
SECTION 6	Digital, Control and References; Power Supplies
SECTION 7	DC Voltage Outputs - Amplitude Control System.
SECTION 8	AC Outputs - Frequency Control System.
SECTION 9	AC Voltage Outputs - Amplitude Control System
SECTION 10	Current Outputs; Resistance.

PART 2 TECHNICAL DESCRIPTIONS

SECTION 5 PRINCIPLES OF OPERATION



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5.1 BLOCK DIAGRAMS

5.1.1 SIMPLIFIED BLOCK DIAGRAM

Figure 5.1 illustrates the general functions and signal flow within the 4705.

5.1.2 GENERAL DESCRIPTION

The Datron 4705 Autocal Multifunction Calibrator is an accurate DC or Sinewave AC voltage source, whose output amplitude (and frequency for AC) are determined by user inputs (within the specifications detailed in the User's Handbook).

DC Voltage The maximum DC or RMS AC output voltage available from the 4705 is 1100V.

Current and Resistance The 4705 provides outputs of DC and AC current; and has eight accurately defined resistance values, in decades.

For DC and AC amplitude control, an adjustable precision reference is derived from pre-conditioned zener diodes.

For AC outputs, the calibrator frequency is synthesized using a crystal-controlled oscillator as a frequency reference.

5.1.3 FUNCTIONAL BLOCK DIAGRAMS

Figures 5.2 (Digital, Control and References), 5.3 (DC/ Ω) and 5.4 (AC) break the main functional divisions into smaller blocks.

They can be thrown clear of the handbook to provide a functional overview; they also form an index to other sections of Part 2.

5.2 INPUTS

The microprocessor accepts inputs from two main sources:

- · The front panel keyboard provides local control inputs.
- The IEEE 488 bus system provides remote control inputs.

5.3 DIGITAL OUTPUTS

The microprocessor system outputs digital information to five main areas:

- The front panel displays provide local outputs for monitoring and control.
- The IEEE 488 bus system provides remote outputs.
- The precision reference generator produces an accurate DC reference for output-amplitude control. Sensed DC outputs are scaled and compared against the DC reference directly. Sensed AC outputs are scaled and compared against a 'quasi-sinewave' reference, whose peak value is set by the DC reference.
- The frequency synthesizer and sinewave oscillator together determine the frequency and purity of the AC output sinewave signal.
- Various decoders control function and range selection, internal processes and status monitoring.

5.4 PRECISION REFERENCE

(Fig. 5.2)

5.4.1 AMPLITUDE REFERENCE

The circuits produce a DC reference voltage which can be set between 0V and $\pm 20V$ for DC outputs, and between $\pm 0.126V$ and $\pm 2.794V$ for AC outputs. The value of the reference is set by the value on the OUTPUT display, modified in software by range scaling and calibration corrections.

For DC, the range-scaled sense voltage is compared directly with the reference - the resulting error controls the DC output value directly. For AC outputs it determines the amplitude of the 'quasi-sinewave', a stepped waveform which is used as the AC amplitude reference. This operates in the error sensing loop, having a shape whose crest factor closely approaches that of a true sinewave.

The circuitry is divided into four main areas:

a. The period division comparator, outside guard, consists of a binary counter and comparator, both effectively of 25 bits. The counter is driven by a crystal-controlled clock; the comparator being set by latched data from the microprocessor system.

When the binary count matches the data set in the latches, the comparator produces a switching pulse (reset). The counter fills to overflow point, at which the comparator produces a second pulse (set). Thus accurate mark-period timing is generated.

- b. The switching integrator receives the pulses across guard. They are used to drive solid-state divider switches, chopping the output from a very stable 20V DC Master Reference. The resulting square wave is very accurately defined, both in mark-period ratio and amplitude. Integration of the square wave, by an active low-pass filter with high rejection at the chopping frequency, generates the DC Reference voltage.
- c. For DC outputs, the selected output polarity controls a switch which inverts the DC Reference for negative outputs.
- d. For AC outputs, a negative version of the DC reference is generated by inversion. Both positive and negative versions are passed to the quasi-sinewave generator, which sets the positive and negative inputs to a potential divider, whose centre-tap is tied to reference common.

The outputs from the divider are selected in ten equal time-steps by digital logic, the ratios being selected so as to produce a periodic signal of quasi-sinusoidal form. The Crest Factor of this signal (Peak value divided by RMS value) is 1.397, close to that for a pure sinewave. The RMS ratio of sinewave to quasisinewave is stored during calibration, and reapplied as correction during normal use. and l

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Because the amplitude of the quasi-sinewave depends on the value of the DC Reference voltage, its settling time to a stable value is determined by the 7-pole DC reference filter.

For accurate sine/quasi-sine RMS comparison, it is important that both the quasi-sinewave steps and the comparator sequence are synchronized to zero-crossing points in the sensed output sinewave. This is ensured by first:

including the divide-by-ten logic of the quasi-sinewave generator as part of the range-divider chain for the frequency synthesizer,

and then:

feeding the quasi-sinewave frequency to the comparator to synchronize the ten-step sequence which controls the RMS comparison process.

5.4.2 FREQUENCY REFERENCE

When the 4705 is operating in AC function, its internal frequency reference is derived from the 13-bit counter in the Precision Reference out-guard circuitry. The counter is tapped at 16kHz, which is fed directly to the synthesizer to establish the frequency of the VCO oscillation.

For users who wish to lock the output frequency of the 4705 to an external frequency source, a phase-locked loop ensures that the 16kHz reference frequency phase is tied to that of the external Reference Frequency. With correct frequency selection on the front panel, this ensures that the 4705 output frequency locks to the external reference frequency.

This function is performed in the External Reference Frequency Buffer.

5.5 ANALOG CONTROL

(Fig. 5.2)

The analog circuitry is controlled by data held in a 48-bit in-guard latch. The microprocessor regularly updates the latch contents, using the serial link to pass the data (through opto-isolators) across the isolation barrier. Certain analog status signals are returned to the microprocessor, also using the serial link.

5.6 DC VOLTAGE OUTPUTS (Fig. 5.3)

5.6.1 LOW VOLTAGE -100μV TO 10V RANGES

5.6.1.1 Power Delivery

The basic DC range of the 4705 is 10V (19.999,999V FS). The 10V range output is derived from a buffered 'Error' amplifier, which compares the sensed output directly with the DC Reference.

For the 1V range, the DC reference is attenuated by 10:1 before being applied to the error amplifier. The error amplifier output is buffered before being applied to the I+ and I- terminals.

For the 100mV range, the 1V DC buffer output signal is reduced by a passive 10:1 attenuator before passing to the Hi and Lo terminals. The I+ and I- terminals are not used.

The 100mV attenuator also serves the 100μ V, 1mV and 10mV ranges. Output values on these ranges are set purely by scaling the DC reference in software, and the consequent reduction in output resolution available is matched by the resolution of the OUTPUT display.

5.6.1.2 Sensing

On the 1V and 10V ranges, the input from the Hi and Lo (sense) terminals is applied to the error amplifier.

For the millivolt ranges and the $100\mu V$ range, there is no remote sensing. To complete the sense feedback, the 1V DC buffer output is applied directly to the error amplifier, which is a configured as for the 1V range.

5.6.2 HIGH VOLTAGE - 100V RANGE

The 10V range signal is applied to the 100V power amplifier, which drives the output terminals directly from the VMOS output stage. The sensed signal is attenuated before being applied to the error amplifier.

5.7 AC VOLTAGE OUTPUTS (Fig. 5.4)

5.7.1 SINEWAVE SYNTHESIS AND SHAPING

To control AC outputs, the frequency synthesizer and quadrature oscillator together generate a reference sinewave of stable amplitude and high purity.

5.7.1.1 Frequency Synthesis

The user-demanded frequency is related to frequency range selection, and is expressed as a binary number 'n' by the microprocessor. It is passed into guard together with binary-coded frequency-range data, to control the frequency of the synthesizer.

The binary counter in the reference divider is synchronized to the 4.096MHz master crystal-controlled clock. This counter outputs a 16kHz frequency reference signal to the synthesizer, where it is divided by two to 8kHz.

In the synthesizer, binary subdivisions of 'n' switch the capacitors of a voltage-controlled oscillator, adjusting its relaxation time-constant so as to cover five possible frequency bands within each frequency range. The VCO output frequency is divided by 'n', then phasecompared with the 8kHz reference. The integrated output from the phase comparator controls the charge and discharge current of the capacitors in the VCO.

Thus the VCO frequency is adjusted to: n x 8kHz.

The frequency range data is decoded and used to define division ratios in a series of frequency dividers, which act on the output from the VCO. The result is the user-selected frequency, to an accuracy of 100ppm.

5.7.1.2 Sinewave Shaping

The quadrature oscillator is approximately tuned to the user-selected frequency by the binary word 'n', together with the decoded frequency range data, which combine to switch its circuit constants. The oscillator output is applied to a second phase comparator, and referred to the synthesizer frequency. The comparator output adjusts the oscillator frequency to that of the synthesizer.

The quadrature oscillator feedback is conditioned to ensure that its unity loop gain and its 360° loop phaseshift occur together; only at a specific amplitude, and at the synthesized frequency.

The oscillator output passes as reference sinewave to the VCA.

5.7.2 VOLTAGE-CONTROLLED AMPLIFIERS

The output from the quadrature oscillator is applied to two cascaded voltage-controlled amplifiers. The gain of the second of these (the 1V buffer) is adjusted in coarse steps; the gain of the first being adjusted in response to the error between the scaled output amplitude, and that of the quasi-sinewave reference.

The settling curve of the 7-pole filter in the precision reference divider is imposed on the 1V buffer slew rate, by using the filter's DC reference output to control the coarse gain. This signal is changed into a 10-bit word by an analog-to-digital converter, whose digital output adjusts the input resistance of the 1V buffer in steps of 1000ppm of Full Scale. As the 1V buffer is part of the error loop, this adjustment injects an undesirable scaling into the loop. Therefore, to correct the loop gain, the same 10-bit word is used to apply inverse scaling to the error signal from the comparator, before it reaches the first VCA.

5.7.3 LOW VOLTAGE -1mV TO 10V RANGES

5.7.3.1 Power Delivery

On the 1V range, the output from the 1V buffer is passed to the I+ and I- terminals directly.

For the 10V range, the 10V amplifier (a X10 amplifier on the Power Amplifier assembly) is inserted between the 1V buffer and the I+ and I- terminals.

For the millivolt ranges, the 1V buffer output signal is reduced by switched, passive attenuators before being output via the Hi and Lo terminals.

5.7.3.2 Sensing

On the 1V range, the input from the Hi and Lo (sense) terminals is applied to the non-inverting input to the 1V/10V sense amplifier, which acts as a voltage follower.

For the 10V range, the sense amplifier is configured as a divide-byten inverter.

For the millivolt ranges, there is no remote sensing. To complete the sense feedback, the 1V buffer output is input directly into the sense amplifier, which is a configured as for the 1V range.

5.7.3.3 Sine/Quasi-Sine RMS Comparator

The output sinewave is sensed and scaled to 1V levels before being applied to the comparator, which compares it with the reference quasisinewave to generate a DC signal whose value represents the output RMS error.

In a strict sense, this circuit does not compare RMS values directly. Instead, it compares the magnitudes of the mean-squares of its two inputs, but if these are equal, then the RMS values are equal. The error loop gain is virtually linear, due to the scaling applied to the error amplifier.

A cycling sequence is continuously imposed, each cycle having a duration of ten quasi-sinewave periods. During the first cycle:

- a. the reference quasi-sinewave is first squared and integrated as an analog DC signal (REF), which is memorized in a sample-andhold circuit;
- b. the sensed sinewave input is squared, the (REF) value is subtracted, and the result is integrated and memorized as the DC (SIG) signal in a second sample-and-hold circuit;
- c. the DC (SIG) value is output as the mean-square AC error signal.

On subsequent cycles, the (REF) value is also subtracted from the squared quasi-sinewave, so that both (REF) and (SIG) signals converge to steady states as the 4705 output reaches the demanded voltage.

The mean-square AC error signal is passed through the scaled error amplifier to control the VCA.

5.7.4 HIGH VOLTAGE - 100V RANGE

The high voltage loop uses much of the low voltage circuitry; the only differences being in the power amplification to the range voltages, and the attenuation of the sensed output down to 1V range levels.

5.7.4.1 Power Delivery

On the 100V range, the 100V amplifier (on the Power Amplifier assembly) is included in the output path from the 1V buffer to the I+ and I- terminals.

5.7.4.2 Sensing

The 1V/10V sense amplifier is not used on the 100V range. Instead, a separate inverting sense amplifier reduces the sensed sinewave by a ratio of 100:1.

5.8 1000V RANGES

5.8.1 DC 1000V RANGE (Fig. 5.3)

5.8.1.1 Power Delivery

An AC voltage-amplifier/rectifier system is employed to transform the DC Reference levels up to the high voltages required for the DC 1000V range.

The error voltage, which results from comparison between the scaled sense voltage and the DC Reference, controls the amplitude of a 16kHz AC signal output from a DC modulator. The modulated signal drives the HF step-up transformer via the 100V AC Power Amplifier. A high voltage rectifier and elliptical filter convert the AC transformer output into the DC voltage output. Output polarity is determined by a changeover switch, inserted between the rectifier and the filter.

5.8.1.2 Sensing

The sensed signal is reduced to DC Reference levels by an extensively-guarded precision attenuator, before being applied to the error amplifier.

5.8.2 AC 1000V RANGE (Fig. 5.4)

5.8.2.1 Power Delivery

The output from the AC 1V Buffer is pre-amplified by the 1kV error amplifier, before being applied to the 100V power amplifier. The 100V amplifier output is transformed up by 1:6, then passed to the I+ and I- terminals. The error amplifier receives feedback from the transformer secondary.

To cover the full frequency range, two transformers with a frequency overlap are employed. The HF transformer is selected as frequency is increased above 3kHz, but the LF transformer is used as frequency is reduced below 3.3kHz. A second feedback loop from the LF transformer primary only, eliminates any saturation of its magnetic circuit.

5.8.2.2 Sensing

The amplifier used to sense the 100V range is also employed for the 1000V range. Although the basic amplifier is common to both, each range has its own input attenuator and feedback ratio. On the 1000V range this ratio is 550:1, and software scales the reference divider digital input to set the quasi-sinewave to values which at full scale are equivalent to 1100V RMS. The amplifier output is compared with the quasi-sinewave in the RMS comparator, the resulting error signal being used to control the output from the VCA.

5.9 DC/AC CURRENT Outputs; RESISTANCE Outputs

A separate PCB assembly deals with both DC and AC Current functions, together with the Resistance function.

5.9.1 DC CURRENT (Fig. 5.3)

The DC Reference is switched to drive a voltage-to-current converter (this converter is the current amplifier used for the AC Current function).

The various ranges are selected by digital control signals from the microprocessor system. The converter shunts are switched into the output circuit to scale the current.

5.9.2 AC CURRENT (Fig. 5.4)

The ACI Reference signal is obtained by activating either the AC 10V range (used for the 1mA, 10mA and 100mA ranges), or the AC 1V range (for the 100 μ A and 1A ranges). This is switched to drive a voltage-to-current converter, followed by a current amplifier.

Range selection is the same as for DC current output.

5.9.3 **RESISTANCE** (*Fig. 5.3*)

Eight fixed precision resistors, in a decade range (from 10Ω to $100M\Omega$) are switched to the output terminals. The resistors are fully floating, being selected by relays under the control of digital signals from the microprocessor system.

5.10 DATRON 'AUTOCAL'

Precision components are used in all critical locations. Individual analog corrections for frequency-response, gain and offset errors are not applied. Instead, the accumulated errors are measured during calibration, and stored digitally in non-volatile memories.

In subsequent use, characteristic equations are applied to the stored errors to generate software corrections, which are then used to modify the reference divider ratios and so compensate for the accumulated analog errors.

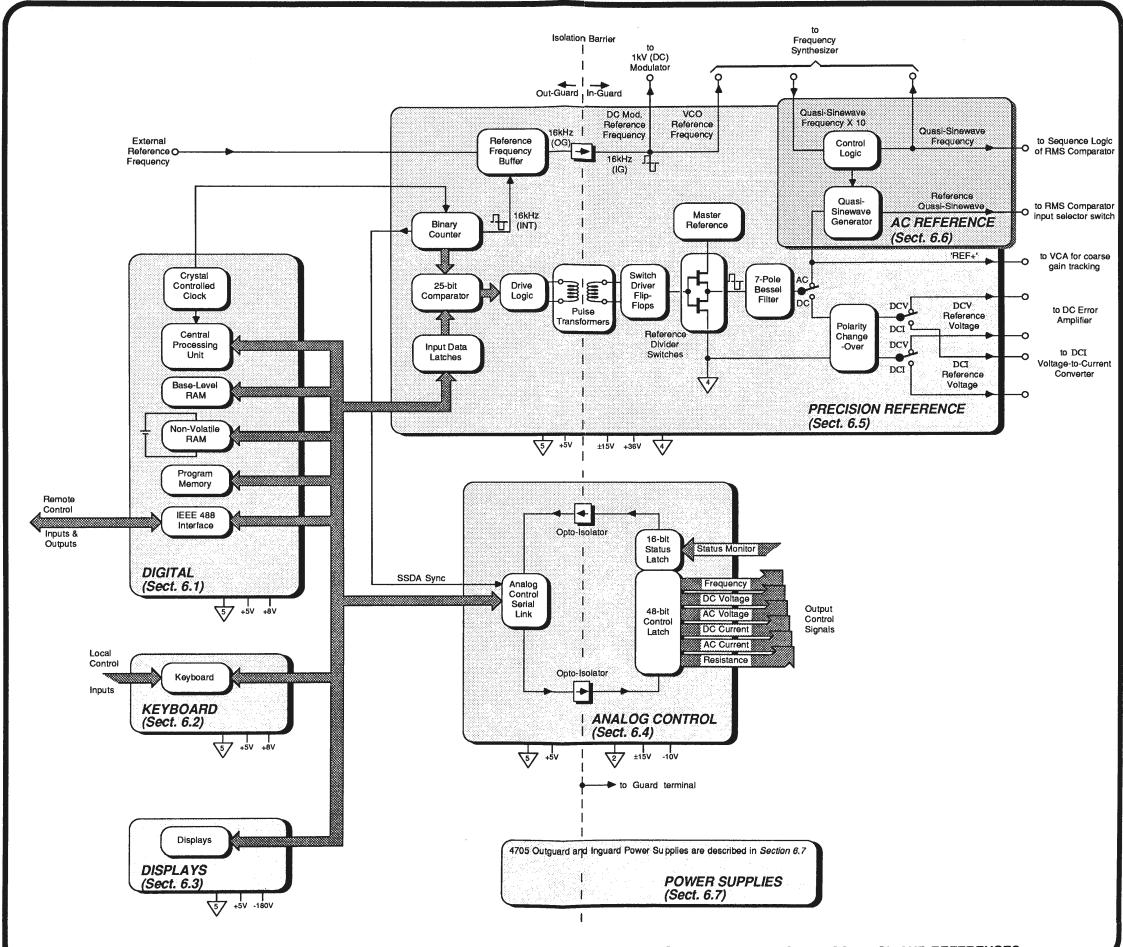
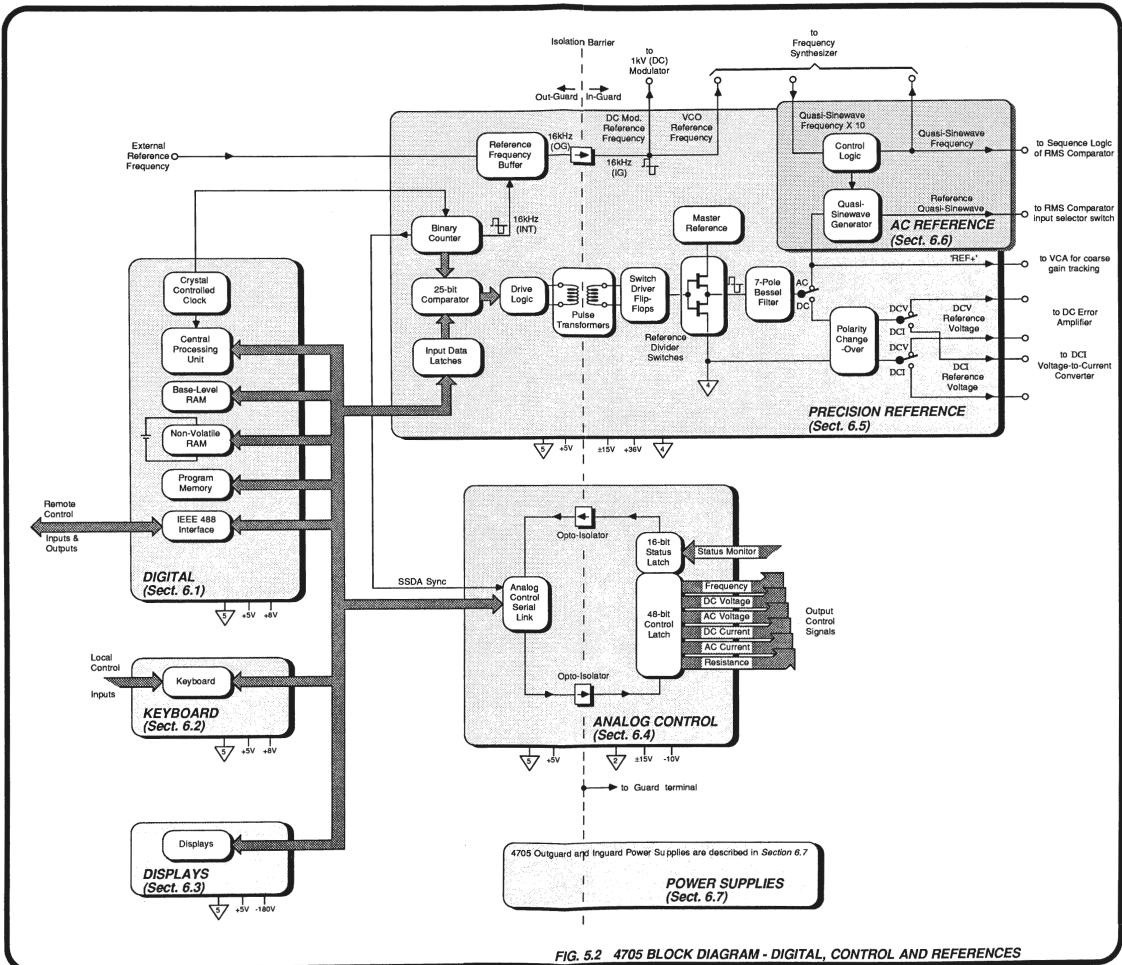
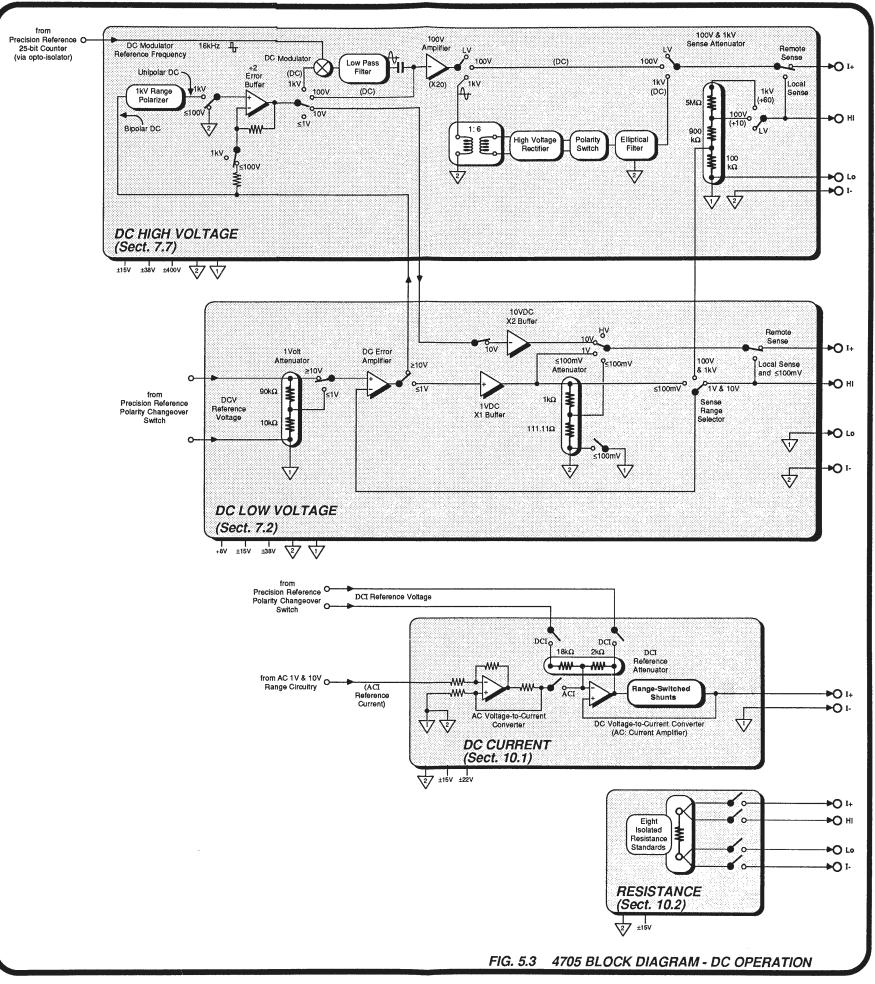
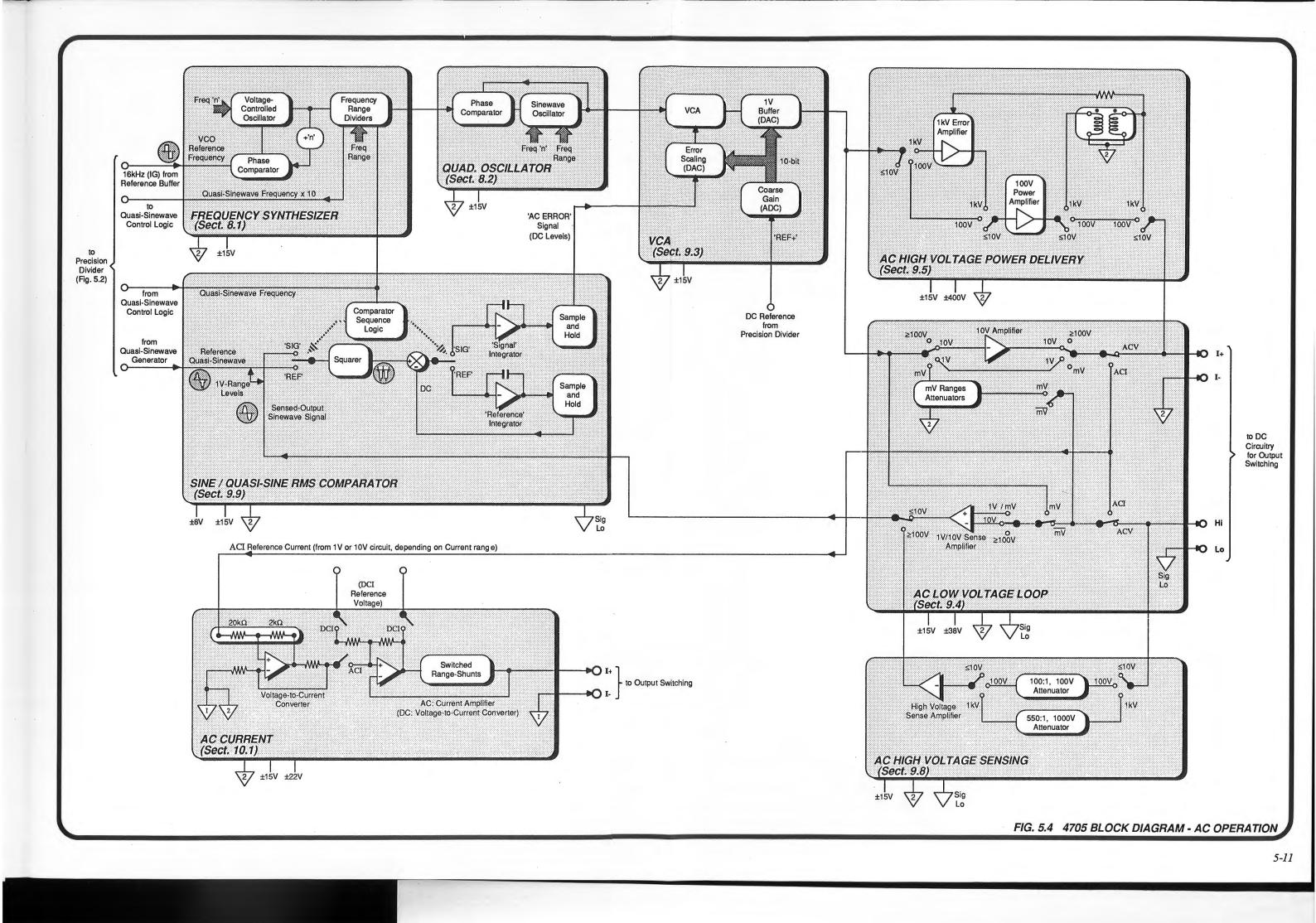


FIG. 5.2 4705 BLOCK DIAGRAM - DIGITAL, CONTROL AND REFERENCES







SECTION 6 DIGITAL CIRCUITS; REFERENCE CIRCUITS; POWER SUPPLIES

6.1 DIGITAL

The circuits described in this sub-section perform the following functions:

- Central processing, with supporting memory, for management of instrument operation.
- Storage of calibration constants in non-volatile memory.
- · Generation of Master clocks, with clock-waveform shaping.
- Address decoding to generate control signals.
- Controlled power-up and power-down of digital circuits.
- Servicing IRQs from asynchronous sources.
- Interfacing the instrument to the IEEE 488 bus.

The functions are performed by circuits located mainly on the Digital Assembly (400559). Master Clock generation, synchronization and division is carried out by circuits on the Analog Interface Assembly (400648).

Fig. 6.1 shows the arrangement and main interconnections of the central digital circuits.

6.1.1 GENERAL

The instrument is managed by a 6802-series micro-processor system, under the control of an operating program held in 26k bytes of EPROM. All front and rear panel controls provide direct inputs to the system, except for the Power ON/OFF switch and Safety Reset Key. The system ensures that the processor reverts to a safe state on power-up and power down.

Work space and stack is provided by 2k bytes of random-access memory (RAM). A further 2k bytes of CMOS RAM act as a nonvolatile memory to hold calibration constants, powered by a back-up Lithium battery when the instrument is turned off.

6.1.1.1 Synchronous Operation

The operating program manipulates the internal circuitry by activating control signals. These result from providing peripheral decoders with specific address combinations. The program is run at 680kHz cycling frequency, originally derived from a 4.096MHz master crystal oscillator.

6.1.1.2 Asynchronous Operation

Any Key operation (other than Safety Reset), or one of two internal conditions, will initiate an asynchronous interrupt (IRQ) which suspends the CPU's current task. The CPU absorbs the new instructions, rearranges its schedule to conform to the demanded new configuration, then continues with the interrupted task until it is completed. Finally it returns to the initial operation of the amended schedule and proceeds synchronously.

Three main sources of interrupt are used:

- · Remote Command via the Digital Interface
- Keyboard Command
- Real-time Clock Pulses (8ms intervals)

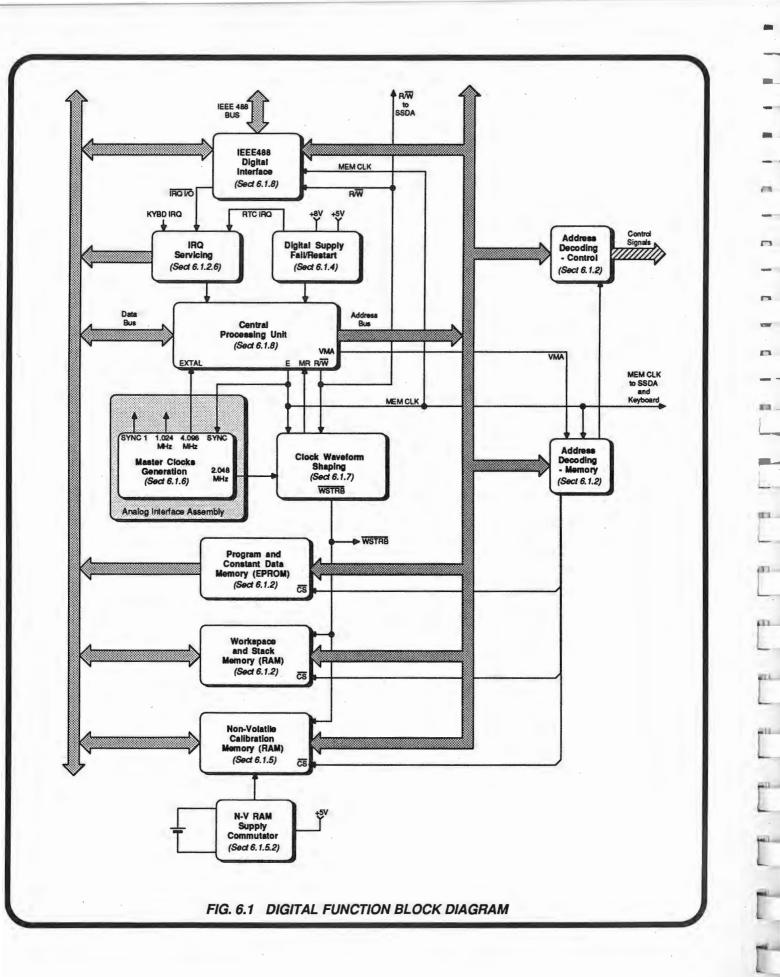
The CPU identifies the source by polling the data bus each time it receives an IRQ interrupt.

6.1.1.3 Output Generation

From user inputs of output value, frequency, error and calibration constants, the CPU computes a binary value to a resolution of 25 bits. This is used to adjust the mark/period ratio of the Reference Divider switch which ultimately controls the Working Reference Voltage for the output analogue circuitry.

6.1.1.4 Display Refresh

The gas discharge display is continuously refreshed by cycling through character data stored in a separate display-image RAM. To alter the display the processor merely alters the contents of the RAM.



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6.1.2 CENTRAL PROCESSOR and PROCESSOR MEMORY

(Circuit Diagram 430559 Pages 11.2-2 and 11.2-3)

A 6802 microprocessor (M34), together with its memory, controls communication throughout the whole instrument.

6.1.2.1 Memory

The memory can be split into four main areas, the microprocessor RAM not being used:

- Program Memory (M18, M19, M20 and M21) defines and controls the operational functions of the whole instrument system.
- Constant Data Memory (held in EPROM with the Program Memory) - stores fixed factors used in processing; such as the key mapping tables, and the instrument specification tables that are used in'Spec' Mode.
- Non-Volatile Calibration Memory (M23) stores all the calibration constants used to correct each output value, which are determined during the 'Auto-cal' cycle.
- Volatile Operating Memory (M22) used for volatile data storage such as display images, computation results and present output value. This memory is also used for scratch pad operations.

Separate memory is used for special purposes, such as the Display Image RAM M16 (which is synchronously loaded but asynchronously read); the storage areas in the IEEE 488 GPIA (M29) and the Keyboard Interface (M6 on Front Assembly); and the Memory Address decoder PROM (M3). These are described in later sub-sections.

6.1.2.2 Central Processing Unit (Circuit Diagram 430559 Page 11.2-2)

The MC6802 (M34) is a monolithic 8-bit micro-processor, with interrupt and clock-stretching facilities. It is driven by a single phase 4.096MHz square wave generated by the Master Clock X1 in the Analogue Interface Assembly. (This clock synchronizes the reference divider switch with the processor cycle).

6.1.2.3 Address and Data Lines

Address lines A_{15-11} are decoded as chip-select signals for the RAM/ROM circuit, lines $A_{13-\emptyset}$ are connected to the instrument address bus. Data lines $D_{7-\emptyset}$ are linked via programming plug JL1 to the instrument data bus.

6.1.2.4 E, MR and MEMCLK

The 4.096MHz clock input at M34-39 (EXTAL) is divided by four and used as output at M34-37 (E). Although the natural frequency of E is 1.024MHz, the action of the waveform shaping input to MR reduces it to approx. 680kHz as MEMCLK for the IEEE 488 interface; and for the Analogue-Interface and Front assemblies.

6.1.2.5 NMI

The internal switch S1 provides a non-maskable hardware interrupt which has two functions.

- With the external CALIBRATION switch set to RUN, MI initializes the processor system.
- With the CALIBRATION switch set to ENABLE, NMI clears the non-volatile calibration memory (M23) before initializing the processor system.

6.1.2.6 **IRQ**

Any one of three asynchronous Interrupt Request signals are able to activate the maskable \overline{IRQ} input at M34-4:

- RTC IRQ is a real-time clock occuring every 8ms to provide timing information for the processor's monitoring facility.
- **KYBD IRQ** occurs each time a front panel key is pressed. (Not Safety Reset).
- **IRQ IO** occurs when the IEEE 488 Interface has a transaction to communicate to the processor.

D1, D2 and Q1 constitute a DTL OR-gate to isolate the IRQ inputs. On receipt of Logic-Ø on pin 4, M34 stores its register contents in stack RAM, and vectors to IRQ service addresses FFF8 and FFF9, saving the current processor environment.

The IRQ Service Routine addresses M51 and M52, setting Logic- \emptyset at M52-9 which enables the tristate buffers M36 and M37 (at M36-1 and 15, M37-15). This sets IRQ data bits D₅, D₆ and D₇ on the data bus so that the processor can identify the source of the IRQ and select the appropriate sub-routine to service the interrupt request.

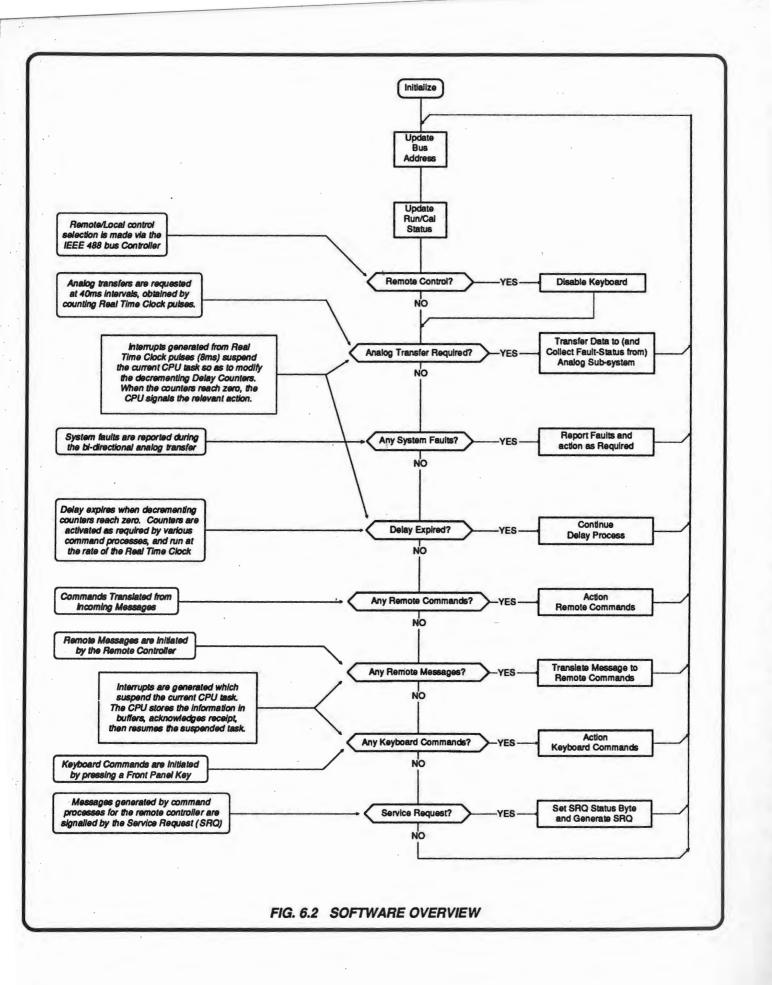
The IRQ inputs are released as part of the service sub-routine, and after its completion, the processor recovers its environment from stack RAM and proceeds with the interrupted operation.

6.1.2.7 Software Interrupt

The 6802 will also recognise Opcode 3F on the data bus as an interrupt request ('Implied' addressing mode). This code is hard-wired via R9, R10 and AN3 onto the data bus so that if the CPU tries to access a non-available address, the floating bus will be pulled to 3F, initiating the software interrupt. The CPU vectors to FFFA and FFFB, whose contents cause the 6802 to re-initialize the system.

6.1.2.8 Read-Write Line R/\overline{W}

The processor sets the R/\overline{W} line to Logic-1 when it is in Read state, and Logic-Ø when it has data to write into the addressed device. The R/\overline{W} signal is passed only to the SSDA on the Analogue Interface assembly, and to the IEEE 488 GPIA (M29). All other devices which require read-write control, operate from the \overline{RD} STRB and \overline{WRT} STRB signals generated from R/\overline{W} by M49/50.



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6.1.3 SOFTWARE OVERVIEW

The software management organization is shown in *Figure 6.2*. The machine cycle progresses through the task schedule as illustrated, being interrupted by the demands of activities dependent on real time, and those dedicated to local and remote commands. Real time and

6.1.4 DIGITAL SUPPLY: FAIL/RESTART CIRCUITRY

Power-up, restart and shut-down of the digital circuitry are performed in a controlled sequence to safeguard against both hardware and software failures. The Safety Monitor ('Watchdog' - Section 6.4.6) maintains a continuous surveillance of the software management, and shuts down the instrument in the event of a failure either in the digital control circuits or in software management.

6.1.4.1 Power-up Sequence (Circuit Diagram 430559 Page 11.2-2)

Power-on is first sensed by the Supply Fail Detector circuit. This draws its supplies from the +8V DC unregulated supply, which is the first of the power supplies to rise to a working level. The comparator circuit of M28 has a nominal threshold of +7.1V, above which a good working level of the +5V DC supply is assured.

As the +8V supply rises, but still below +7V, M28-2 follows until the Zener D6 avalanches, when it is held at +2.45V. At this level M28-3 voltage is less than 1V, so M28-1 remains at 0V holding the 'D' input of M8-5 at Logic- \emptyset and M7-3 at Logic-1. Thus M8 and M9 are held in reset, initiating and maintaining the following states:

- a. M8-2 (Q) at Logic-1, PWR ON RST active. This signal is fed to the Front Panel assembly, holding the keyboard encoder M6 in reset, and disabling the LED cathode driver decoder M4.
- b. M6-4 at Logic-Ø, PWR ON RST active. This signal holds the microprocessor M34 in reset state. The VMA output at M34-5 is held at Logic-Ø, disabling address decoder M3, setting all M3 address outputs to Logic-1. This combination sets M5-13 to Logic-1, but the Logic-Ø at M6-2 sets Logic-1 at M5-11, ultimately setting Logic-1 at M7-2.

The Logic- \emptyset of PWR ON RST also holds the IEEE 488 GPIA M29 (*page 11.2-4*) in reset. It is also fed to the Analog Interface assembly where it holds the SSDA M44 in reset.

When the +8V supply rises above about +7.1V, M28-3 voltage rises above the +2.45V on M28-2, so M28-1 rises to place a Logic-1 both on M8-5 (D input) and M7-1. M7-3 thus falls to Logic- \emptyset , removing the resets from 14-bit counter M9 and restart flip-flop M8. So M8 is enabled to receive its clock from M9, which itself starts to count its own 2.048MHz clocks.

At full count, 8ms after M9 is enabled, M9-3 clocks M8. As M8 'D' input is already at Logic-1, this is clocked to M8-1 (Q), with Logic- \emptyset to M8-2 (\overline{Q}). The PWR ON RST and \overline{PWR} ON RST signals revert to their inactive states, and start-up proceeds: command interrupts suspend the current activity of the processor so that the immediate task can be serviced. The processor then resumes the suspended task and continues with the programmed routine, accounting for any alterations introduced by the interrupt.

a. PWR ON RST at Logic-Ø:

On the Front assembly, enables keyboard encoder M6 and LED cathode driver decoder M4.

b. PWR ON RST at Logic-1:

- i. Removes reset from CPU M34, allowing the software to initialize; and also removes the reset from the IEEE bus controller M29 (page 11.2-4).
- ii. Removes the reset from the SSDA M44 on the Analog Interface assembly.

c. M8-1 to Logic-1:

- Provides an enabling input to M10-1 (See Non-Volatile RAM Supplies - Section 6.1.5).
- ii. Triggers monostable M53-4. This monostable has a relaxation period of 470ms, during which time it holds the FP RST output at Logic-Ø. On the Reference Divider assembly this allows the Watchdog circuits to reset. (See Section 6.4.6)
- 111. Enables the 'Real-Time Clock' IRQ via M7-13 and flip-flop M8-10. The actions of M9, M8 and M51 interrupt the software routine every 8ms. 'RTC IRQ' sets five external states onto lines D_{4-0} of the Data bus (M36 and M37), and forces the CPU to observe them.

Address decoder M51-5 is normally held at Logic-1, so the Logic-1 at M7-11 and M8-10 allows M9-3 clock to affect the RTC IRQ output at M8-13. For so long as the +8V supply holds above +7.1V, M9 continues cycling through its full count, clocking M8-11 to initiate the RTC IRQ at 8ms intervals.

The CPU terminates each RTC IRQ service sub-routine by addressing M51, pulsing M51-5 (M7-12) to Logic-Ø (Realtime clock reset 'RTC RST). M7-11 and M8-10 are pulsed to Logic-1, resetting M8-13 (RTC IRQ) to Logic-Ø. At the next full count of M9; M8-13 is once again clocked to Logic-1, initiating another RTC IRQ.

Pulses from M9-3 regularly clock the binary state of M8-5 through to M8-1, monitoring the supply status. When running normally, M8-5 and M8-1 are both at Logic-1. If the supply fails, M8-5 reverts to Logic-Ø, but M7-1 at Logic-Ø provides a fast reset setting M8-4 to Logic-1 without waiting for the next clock pulse. M7-3 also resets the 8ms counter to zero count at M9-11.

6.1.4.2 CPU Re-start

(Circuit Diagram 430559 page 11.2-2)

Memory addressing by the CPU is monitored by the NAND logic of M4, M5 (four elements) and M7-3. In the correct addressing sequence there are two basic conditions:

- Invalid memory address: CPU VMA = Logic-Ø, and M3 outputs (D_{Ø-7}) = Logic-1.
- Valid memory address:

CPU VMA = Logic-1 CPU E = Logic-1 M3 outputs $(D_{\emptyset,7})$ = One address line set to Logic-Ø

Both these conditions disable M5-11, setting a Logic- \emptyset at M7-3 which allows the clock M9 and flip-flop M8 to function normally. The possibility of a glitch occurring at the change-over between the two conditions is gated from the control line by switching at M5-5.

Incorrect addressing sequence in the CPU would be shown by:

- CPU VMA = Logic-1, and E = Logic-1, the CPU indicating that it has selected a valid external address;
- All M3 outputs = Logic-1, no address is selected.

This situation is most likely with a software failure. The logic control path via M4 and M5 now gives a Logic-Ø at M7-2 and thus a Logic-1 at M7-3 which:

- Resets counter M9 to zero;
- Forces M8-1 to Logic-Ø. This forces RTC RST at M7-11 and removes an enable from M10-1. (See Non-Volatile RAM Supplies Section 6.1.5)
- Forces M8-2 to Logic-1. This change:

Resets the CPU by M34-40 to Logic-Ø. VMA is forced to Logic-Ø which in its turn removes the reset from M9-11 and M8-4 via M6-2 (Logic-Ø), and the M4/M5/M7 control path.

Makes PWR ON RST and PWR ON RST signals active, thus resetting the other software-controlled areas.

After 8ms from CPU reset, flip-flop M8-3 is triggered from clock M9. M8-1 and M8-2 change state and the start-up sequence proceeds again.

6.1.5 NON-VOLATILE RAM

6.1.5.1 'NV INHIBIT' Signals

(Circuit Diagram 430559 pages 11.2-2 and 11.2-3)

Chip-select to the non-volatile memory M23 is inhibited during power-up, re-start and power-down operations, by the logic signal 'NV INHIBIT being set to Logic-1. During normal running this signal reverts to Logic-Ø. With the <u>NV INHIBIT</u> signal at Logic-1 (M10-4) during normal running; write access to the NV RAM is available, but only enabled if the calibration security keyswitch on the rear panel is set to ENABLE. The NAND logic gates M10, used to control the inhibit, remain powered from the RAM standby supply after power-down.

Conditions for normal running are as follows:

- Supply fail detector circuit provides a Logic-1 (supplies valid) output to opto-coupler M11. This action causes its opticallycoupled transistor to conduct and hold M10-2 at Logic-1.
- M10-8 is held at Logic-1 (to +5V via R6).
- M10-1 is held at Logic-1 by flip flop M8-1.

The above conditions ensure a Logic-1 output from M10-10 (by holding NV INHIBIT inactive).

During power-up, NV INHIBIT is held active until the power supplies have settled and the CPU has gained control of memory:

The input to M10-8 is delayed on the +5V supply by the timeconstant C8, R6. Also, the input to M10-1 is held at Logic- \emptyset by flip-flop M8-1 until the CPU reset is removed.

At power-down, or in the event of a supply failure, NV INHIBIT becomes active before +5V supply fails:

The first indication of supply failure is made by supply fail detector M28 output going to Logic-Ø. This cuts off the optocoupler M11 which takes M10-2 to Logic-Ø. M10-8/12/13 are held at Logic-1 by the +5V supply, thus M10-9 is taken to Logic-1 and M10-10 to Logic-Ø (NV INHIBIT active).

In the event of a CPU reset, the $\overline{\text{NV INHIBIT}}$ is made active for the period of reset by the switching action of M8-1 and M10-9.

6.1.5.2 Supply Commutator (Circuit Diagram 430559 page 11.2-3)

This circuit provides the non-volatile RAM M23 with a batterydriven standby supply when the instrument is in the power-down condition. It also ensures continuity of supply during the changeover period between normal (line) operation and standby, minimizing battery current leakage.

In the power-down condition, the battery powers M10 and M23, returning from battery common (TP13) via D7 and R60. The battery common is isolated from the general common 5A by transistor Q2, which is cut-off.

During power-up, M28 is powered from the +8V supply before the +5V supply voltage becomes established. As long as the +5V supply voltage is less than the battery voltage, Q3-4 is biased negatively, and Q3 is unbalanced in favour of heavy conduction through Q3-6. M28-5 is held low, and M28-6 high as the +5V supply voltage increases, so M28-7 remains at Common-5A potential, and opto-coupler M39 is not energized. Q2 stays off, maintaining isolation of the battery supply from Common-5B. M10 and M23 remain powered from the battery.

As the +5V supply voltage increases, D7 cathode potential rises, reducing Q3-4 bias, reaching zero when the supply voltage is equal to the battery voltage (less than 10mV is developed across R60).

When the +5V supply voltage exceeds the battery voltage, Q3 becomes biased in favour of heavy conduction through Q3-2, pulling M28-6 low and reversing the differential input to M28. M28-7 rises to the +8V rail and energizes the opto-coupler M39, which switches Q2 on, connecting common-5A to the battery common. M10 and M23 are now powered from the +5V supply and the standby battery is isolated by reverse-biased diode D7.

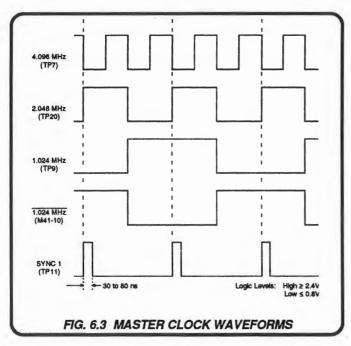
During power down, Q3 compares the +5V supply against the battery, switching Q2 off via M28 and M39 when the +5V supply voltage falls below the battery voltage, and the non-volatile RAM supply commutates to standby battery. Alternatively, Q2 is switched off by failure of the +8V supply to M28 if this occurs before the +5V supply voltage falls below the battery voltage.

Eventually the +5V and +8V supplies both fall to zero, the battery provides the supply to the non-volatile RAM, and battery common is isolated from Common-5A by Q2.

6.1.6

MASTER CLOCK GENERATION (Circuit Diagram 430648 page 11.3-3)

(Refer to Fig. 6.3 for waveforms)



The master clock generator is based on crystal oscillator X1 which provides a precision 4.096MHz squarewave reference frequency output.

The primary frequency of 4.096MHz is divided by JK flip flop stages M41, both of which are connected to toggle when clocked. The first division stage is synchronized at its reset input, M41-3, to the memory clock via flip-flop M42. This ensures correct phasing of the 2.048MHz squarewave output from M41-14.

M41-11 and M41-10 outputs provide complementary 1.024MHz and $\overline{1.024MHz}$ squarewaves respectively. Monostable M40, which is triggered at 2.048MHz from M41-15, provides the positive-going 2.048MHz synchronizing pulses, SYNC1.

6.1.7 CLOCK WAVEFORM GENERATION (Circuit Diagrams 430559 page 11.2-2 and 430648 page 11.3-3)

- NB As the circuit locations in *Fig 6.4* are clearly marked, and as there are no duplicate designators in the circuits, this description does not refer to a component's location except where necessary.
- NOTE To avoid confusion, the terms 'high' and 'low' are used to replace 'Logic-1' and 'Logic-Ø' respectively in the following description.

The crystal oscillator on the Analog Interface Assembly provides a 4.096MHz Master Clock signal (X1-8) for the whole instrument. This drives the 6802 CPU at M34-39 (EXTAL) so M34-38 is not connected. M41 divides 4.096MHz to generate a 2.048MHz clock for the Memory Clock Stretching Circuit (M35/M49).

The CPU (M34) divides the EXTAL input internally by 4 and outputs the result as E (Enable) at M34-37, to act as a 'Phase 2' Memory Clock for the SSDA on the Analog Interface and the keyboard controller on the Front assembly.

If M34-3 (MR-Memory Ready) were permanently held at +5V, the E signal would be 1.024MHz. But in the 4700, a 'stretching' circuit (M35/M49) doubles the Logic High (+5V) time of E by switching MR to Logic Low (0V) for part of the cycle. This is shown on Fig.6.4.

The frequency of E is thus reduced to approximately 680kHz, with 1µs available for data access to the SSDA, Keyboard Controller, IEEE GPIA and memory.

6.1.7.1 Memory Clock Stretching Circuit (Fig. 6.4)

The action of M35 and M49 is dependent upon the finite propagation time between clocks at M35-1/M35-6 and Q output at M35-15. When M34-3 (MR) is +5V; M34-37 (E) is toggled by alternate positive-going edges of the 4.096MHz clock, with a propagation delay of approximately 80ns. Also, the 4.096MHz signal is divided by 2 in M41, resulting in 2.048MHz signal whose negative-going edges clock M35. M35 cascade action is controlled by the condition of the Memory Clock (E) and affected by its own propagation times.

6.1.7.2 Shaping Action (Figs. 6.4 and 6.5)

At T1 and T2: The 4.096MHz clock edge at T1 causes E to rise from low to high at T2. As M35-10 is also high, MR changes from high to low at T2, holding E high. M35 pin state is 4 and 10 high, 9, 12 and 16 low.

At T3: The 2.048MHz falling edge clocks M35, and M35-9 rises to high awaiting the next clock edge (not until T5). M35-10 also remains high, so MR is held low and E stays high.

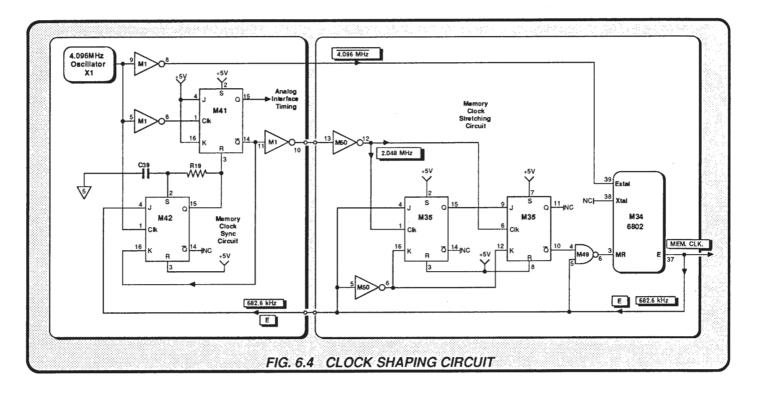
At T4: MR is still low, so the 4.096MHz clock has no effect on E, and E is stretched.

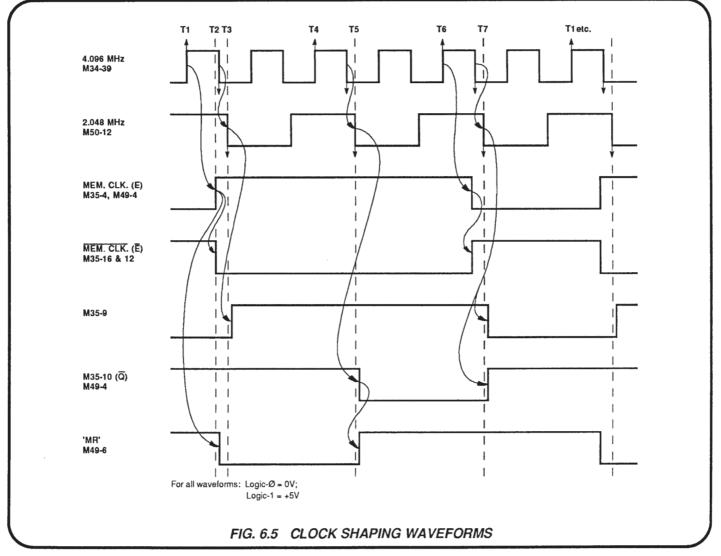
At T5: MR returns to high when the Logic-1 on M35-9 is clocked as a Logic-Ø to M49-4. This allows the 6802 to toggle E at the next effective clock edge.

At T6: The rising edge of the 4.096MHz clock causes E to fall to low, setting up M35-4 to low, M35-12 and 16 to high. (M35-9 is already high.)

At T7: M35-10 is toggled to high, but as M49-5 is now low, MR remains high to allow E to be toggled at the next effective processor clock edge (not until the next T1). Also at T7, M35-15 is clocked to low to set M35-9 ready for the next (T3) clock edge. The circuit is now set up to its initial (pre-T1) condition so the action repeats. Note:

A remote possibility exists, that a severe disturbance could upset the synchronization of the 'E' signal with the 2.048MHz clock. To guard against this, M42 acts as a monostable to provide negative reset pulses into M41-3. Under all normal conditions, these will occur when M41 is already toggled in its reset state.





6.1.8 IEEE 488 DIGITAL INTERFACE (Circuit Diagram 430559 Page 11.2-4)

The IEEE Interface circuitry is located on the bottom right-hand corner of the Digital PCB (viewed from the front of the instrument). M29, M40, M47 and M48 execute and decode interface functions, and transfer data (input/output).

The General Purpose Interface Adaptor (GPIA) M29, is softwaredriven by the 6802 CPU, as part of its normal function. M29 is addressed at CS by $\overline{\text{XIOBBD}}$ from M51, and its internal registers are accessed by A_Q, A₁ and A₂ from the address bus.

The GPIA is clocked by Memory Clock E, with read or write control direct from the processor R/W signal at M29-5; and at instrument power-on, the signal PWR ON RST from the Restart Generator circuit (M6-4) initializes M29 at M29-19.

Information is passed between M29 and the CPU (M34), via the data bus D_{0} - D_{7} . The address switch data is linked to D_{0} - D_{6} by tristate buffers M47. During initialization and at subsequent intervals, the state of M29-4 (ASE) changes from +5V to 0V, enabling M47. The status of the address switches on the 4700 rear panel is transferred into M29 via M47 and the data bus for comparison with the received address.

M40 and M48 are bidirectional bus-driver arrays. The drivers for bus management lines: IFC, ATN and REN are permanently held in Receive state, and the SRQ driver in Transmit state. The EOI line driver is switched from Receive to Transmit by M29-28 $(T/\overline{R}1)$ changing from 0V to +5V as required by M29. M29-27 $(T/\overline{R}2)$ is normally held at 0V for reception of system data via DIO₁₋₈ bus lines, and set to +5V for instrument data to be sent over the bus.

Some system controllers output excessive noise along the REN line. To avoid spurious switching of M29 between Local and Remote control states, the noise is filtered by R58 and C31.

Difficulty has been experienced with certain controllers in that NDAC can transfer data on to the bus too early. Resistor R62 and capacitor C7 slow down the transitions of NDAC to overcome this problem.

M29-40 (\overline{IRQ}) is used to inform the CPU when certain states occur. In particular, the \overline{IRQIO} signal is generated at each byte-transfer over the bus, whether the byte is sent or received. Additionally, \overline{IRQIO} is activated whenever certain specific commands are received, e.g: 'DAC', 'SPA', and changes between Remote and Local Status.

When the CPU receives $\overline{IRQ IO}$, it addresses M29's 'Interrupt' Status Register, then M29 identifies the reason via the instrument data bus.

For further information refer to 'Getting Aboard the 488 Bus' published by Motorola, or the appropriate device data sheets.

1

1

6.2 KEYBOARD

(Circuit Diagram 430558 Page 11.1-1)

The circuitry described in this section performs the following functions:

- Provides front-panel operator control of instrument Output, Function, Range and Mode circuitry, by push-button keys. Key operation is detected internally and transferred to the CPU via the instrument data bus.
- Indicates the present instrument state by means of LEDs fitted in the keys.

 Generates audible warning of errors, failures, and high voltage at the Output Terminals. (Also see Circuit Diagram 430648 Page 11.3-3)

In addition a rocker switch sets instrument Power ON and OFF (*refer to Section 6.7*) and a 'Reset' key provides a hardware reset for the safety monitor (Watchdog) circuits (*refer to Section 6.4*). The circuitry is located on the Front PCB Assembly (400558), linked to the CPU by control signals and the data bus.

6.2.1 KEY and LED MATRICES

The keys are electrically arranged in an 8 x 7 matrix as shown in the circuit diagram. The seven columns are scanned by M5; any key contact is detected on one of the eight return lines $RL_{0.7}$, memorized by M6, and signal KYBD IRQ is passed to the CPU. The CPU responds by interrogating M6 Keyboard memory and acting on the specific key command.

The LEDs in the keys are electrically arranged in an 8 x 4 matrix. The four rows are scanned by M4, and the eight columns receive the appropriate bit patterns from M6 display memory. This memory is up-dated as required from the CPU data bus D_0 - D_7 .

6.2.2 PROGRAMMABLE INTERFACE M6 (Fig. 6.6)

M6 interfaces the keyboard and LEDs to the instrument data bus. It is addressed by \overline{KYBD} CS from the Digital assembly, to chipselect \overline{CS} which enables commands or data to flow via the data bus at DB_{0.7}. The CPU sets address A₀ to Logic-Ø for data flow; but for programming the interface for mode change or during initialization, A₀ is set to Logic-1.

6.2.2.1 Read/Write Control

The \overline{WRT} STRB signal from the Digital assembly is applied to M6 \overline{WR} . Data or Command is input to M6 from the CPU data bus during \overline{WR} low and \overline{CS} low, and is latched on the \overline{WR} positive-going edge.

The \overline{RD} STRB signal from the Digital assembly is applied to M6 \overline{RD} . Data is output from M6 on to the data bus during \overline{RD} low and \overline{CS} low.

6.2.2.2 M6 Initialization

Switching power on to the instrument causes M6 to be cleared by the PWR ON RESET pulse from the Digital assembly. The interface is then programmed during initialization as follows:

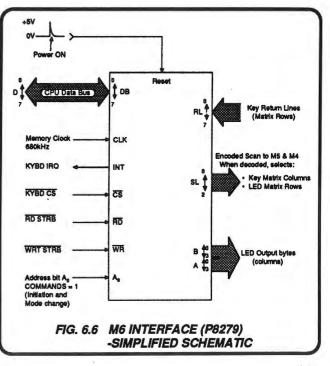
- a. Clock divider set to 'divide by eight': The memory clock (E) at approximately 680kHz is divided by 8 to give an internal clock frequency of 85kHz.
- b. An inherent division by 16 reduces the scan clock to 5kHz giving a scan cycling frequency of 333Hz.
- c. Encoded Keyboard Scan: The scan output from SL₃₋₀ is a 4-bit count. SL₃ is not used; SL₂₋₁ scans M4, SL₂₋₀ scans M5.
- d. Keyboard Mode:

The internal keyboard RAM is programmed as FIFO, input being routed via $RL_{7.0}$ return lines. Two-key lockout is employed with debounce.

- e. Display Mode:
 - · Eight character left entry for the LED display.
 - Inter-digit blanking:
 - all 1's on B₀₋₃ and A₀₋₃ between digits.

6.2.2.3 M6 Reprogramming

The Frequency Store key and the 13 dual **1** keys have a reprogrammable function. When one of these keys is pressed, the P8279 is reprogrammed into Scanned Sensor Mode. When released, the P8279 reverts to Encoded Keyboard Scan Mode.



6.2.3 SCAN DECODING

The encoded scan output from M6 (approximately 333Hz cycle frequency at $SL_{2.0}$) is decoded by M5 to energize each key-matrix column line once every scan cycle. $SL_{2.1}$ scan outputs are also decoded by M4A to energize each LED-matrix cathode driver once in every scan cycle for a period of two digits.

6.2.4 KEY SELECTION

The keys are electrically grouped within a matrix of 8 rows of 7 (one position vacant - the Reset key is not part of the matrix). This does not conform to their physical grouping on the front panel. Each of the eight return lines $RL_{0.7}$ defines a matrix row, whose seven elements are scanned by M5 (Low active).

The keyboard memory RAM in the P8279 (M6) is an image of the key matrix, internally synchronized to the SL_{2-0} column scan, and receiving row inputs from $RL_{0.7}$. It thus stores the state of each of the 55 keys. The use of 2-key lockout rejects two or more simultaneous contacts. Any single key depression is debounced, initiating the interrupt KYBD IRQ to the CPU which then interrogates the keyboard image RAM in the P8279.

The next action depends upon the key's function:

a. 14 key pressed:

- M6 is reprogrammed into Scanned Sensor mode for as long as the key is pressed, the CPU acting on the key information.
- If a single for key is held down for longer than half a second, the display enters 'auto ft' mode, running at about 3 digits per second.
- iii. When the key is released, M6 is returned to Encoded Keyboard Scan mode.

- b. 'Store' key pressed:
 - M6 is reprogrammed into Scanned Sensor mode for as long as the key is pressed, the CPU acting on the key information.
 - ii. If an F1 to F5 key is pressed while 'Store' is held down, the appropriate frequency memory location is accessed, and the output frequency is reset to the value in the memory.
 - III. When the 'Store' key is released, M6 is returned to Encoded Keyboard Scan mode.
- c. Any other key pressed (not 'Reset'):
 - M6 remains in Encoded Scan mode; the scan continues as the CPU is acting on the key information.
 - KYBD IRQ interrupts are generated only by the low-going edges of the key contact pulses, so M6 remains sensitive to subsequent key depressions.

6.2.5 KEY LED OPERATION

After performing the change requested by the key depression, the CPU changes the bit-patterns stored in M6 internal display RAM. As this is scanned internally in synchronism with the decoded outputs of M4A, each output byte of $B_{0.3}$ / $A_{0.3}$ drives the row of LEDs accessed by M4A output lines.

The bit-pattern of the byte selects the LEDs to be lit in that matrix row:

B ₀₋₃ / A ₀₋₃ bits at:	Logic-1 = LEDs unlit;
	Logic-Ø = LEDs lit.

During changes of output between successive bytes, all the lines from $B_{0.3} / A_{0.3}$ are set to Logic-1 to avoid spurious LED flashes.

Transistors Q25-Q32 drive the LED anodes, from a +5V supply regulated by M2. Darlington amplifiers Q21-Q24 drive the LED cathodes.

6.2.6 AUDIBLE WARNING BUZZER

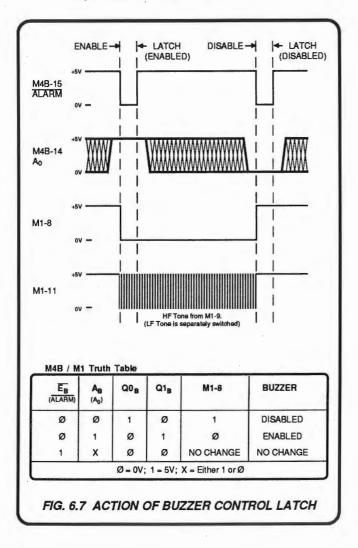
There are two reasons for an audible warning from the calibrator:

- When the instrument enters High Voltage State (>110VDC or >75VRMS). A 4kHz tone is used, pulsed as described in the User's Handbook.
- When an inappropriate selection is attempted, or if any FAIL or Error message is displayed. For this purpose a single 500Hz 'Beeper' pulse is generated.

6.2.6.1 High Voltage State Alarm Control (Circuit Diagram 430558 page 11.1-1)

M4B and M1 act as a control latch for the quartz warning buzzer. With $\overline{\text{ALARM}}$ at Logic-1 (+5V) M1 remains unchanged; but with $\overline{\text{ALARM}}$ at Logic-Ø (0V) the state of M1 depends on the condition of the A₀ line:

> A_0 at Logic-1: the buzzer sounds a tone. A_0 at Logic-Ø: the buzzer is silent.



The latch is operated at CPU speed. Two ALARM pulses are used for each burst of sound. The first, with A_0 at Logic-1, starts the burst; the second, with A_0 at Logic- \emptyset , ends it.

The waveforms and truth table in Fig.6.7 illustrate the action of the latch, with M1-13 at Logic- \emptyset .

During POWER ON initialization, the combination of \overline{ALARM} at Logic-Ø and A₀ at Logic-Ø; is applied to M4B to force power-up in the disabled condition.

The 4kHz HF TONE signal at M1-9 originates in the Precision Divider counter which is situated on the Analog Interface Assembly. (*Refer to Circuit Diagram 430648 page 11.3-2*).

The 500Hz LF TONE signal at M1-13 remains at Logic- \emptyset unless the 'Beeper' in the Analog Interface assembly is switched. (See section 6.2.6.2).

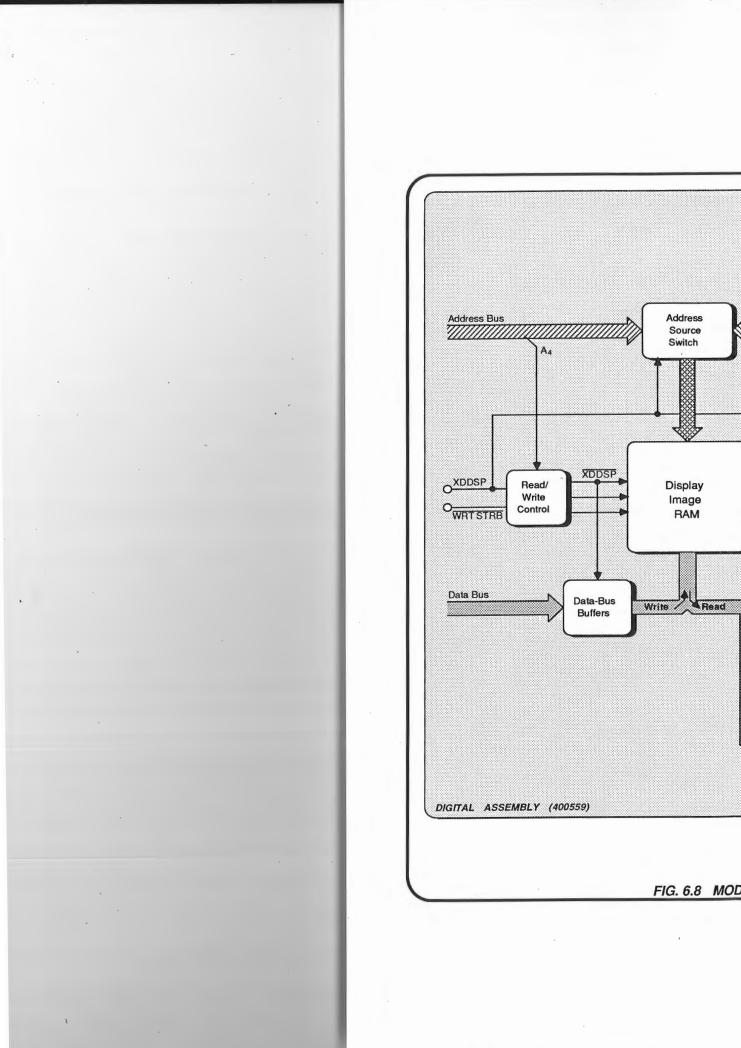
Note that A_0 may be used for other purposes when ALARM is at Logic-1, but this will not affect the buzzer state.

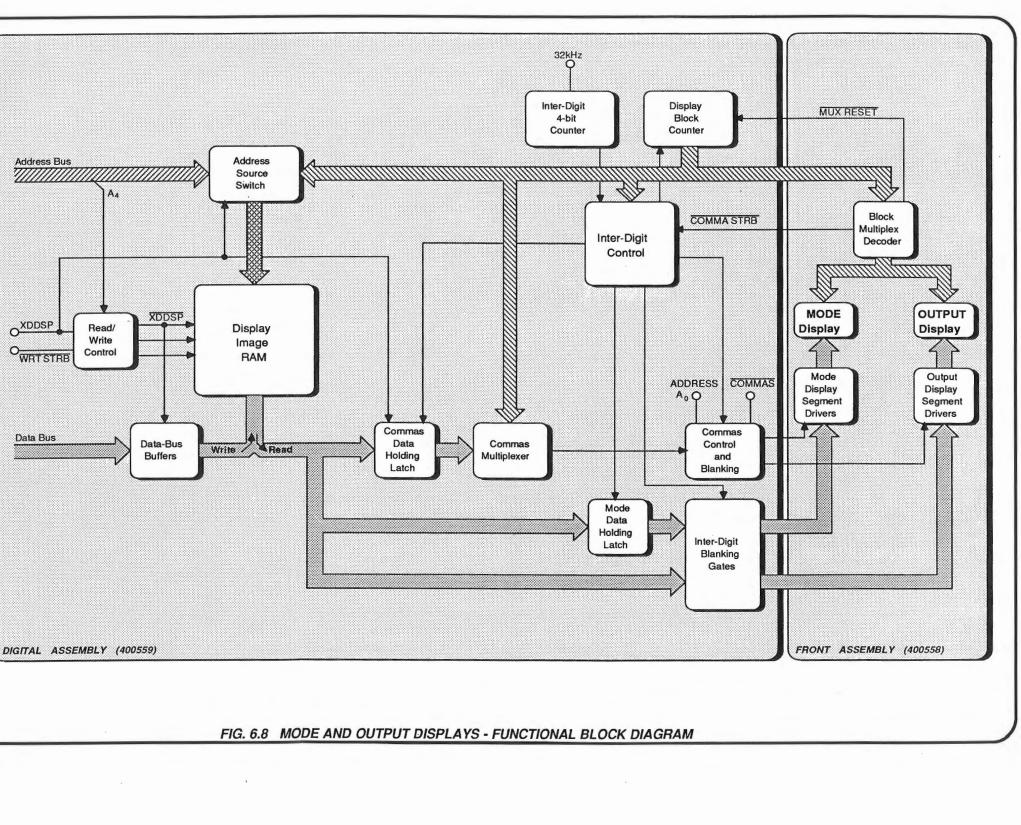
6.2.6.2 'Beeper' Control (Circuit Diagrams: 430558 page 11.1-1, 430648 page 11.3-3)

The Alarm Control circuitry on the Front assembly is overridden for Beeper control. During a 'Beep', the HF TONE signal is inhibited, and the LF TONE signal at M1-13 is enabled to control the buzzer output.

On the Analog Interface assembly (page 11.3-3) the Beeper consists of a monostable timer and NAND logic. Unless a requirement arises for a 500Hz warning, the BEEP signal is at Logic-1. Thus M55-3 is at Logic- \emptyset , so M54-5 at Logic-1 inhibits the LF TONE signal, M54-4 remaining at Logic- \emptyset . M54-8 is at Logic- \emptyset enabling the 4kHz HF TONE, which is passed to the Front assembly at M1-9 (page 11.1-1).

When required, a single 'Beep' is originated by the CPU pulsing M34-3 (page 11.3-1) to Logic-Ø. This is the BEEP signal applied to the monostable M55-2. M55-3 rises to Logic-1 for approx. 150ms until the monostable times out, then reverts to Logic-Ø. M54-8 is at Logic-1 during this period, inhibiting the HF tone and setting M54-11 to Logic-1. This is passed to M1-9 on the Front assembly, where it ensures that M1-12 is at Logic-Ø to override any High Voltage alarm. M54-5 at Logic-Ø enables the 500Hz LF TONE signal to pass via M54-4 to M1-13 on the Front assembly (see page 11.1-1). As M1-12 is held at Logic-Ø during the beep, the buzzer produces 150ms of audible 500Hz output.







6.3 DIGITAL DISPLAYS

The circuits described in this section perform the following functions:

• Storage of display data in a Display Image RAM, updated under CPU control.

• Generation of multiplex count which selects segment data from the RAM, and energizes the appropriate digital blocks in synchronism.

• Distribution of high voltage supplies to energize the plasma displays.

6.3.1 GENERAL (Fig.6.8)

The purpose of the Display Image RAM is to accept and store current display data, which is read out to drive the display segments. The Display Block Counter generates a 4-bit count at 2kHz which scans the 11 digit-blocks of both displays in parallel. The same count scans the RAM, selecting segment information for each block in turn. As there are two displays, and therefore two RAM bytes to read for each block, the 'MODE' display data is first entered into a holding latch during the inter-digit blanking period at the start of the time-slot for its block.

To update the displayed characters, the CPU writes into the RAM at high speed (680 kHz), using signal XDDSP to connect the Address bus through the Address Source Switch to the RAM. XDDSP also connects the Data Bus to the RAM through the Data Bus Buffers, writing the new segment data into the selected RAM Address. The high speed of the transfer, compared with the much slower scanning speed in Read mode, avoids spurious effects appearing on the displays.

Each RAM address contains only 8 bits, but there are nine segments in each display block. Comma-segment information is therefore not written into its normal block address in the RAM, but stored as a bit in a separate 'Commas' byte, which holds the data for all eight blocks having a comma. The byte is read out into a Commas Data Holding Latch, once every block-scan cycle, and then selected for display by a Commas Multiplexer 8-into-1 switch.

Part of the Digital assembly (400559) houses the display multiplexer, which includes the display image RAM, the interdigit and multiplex counters, and control circuitry.

The two plasma displays, the block multiplex decoder, segment drivers and high voltage circuits are located on the Front assembly (400558). The block diagram of Fig.6.8 shows the arrangement and main interconnections of the display circuitry.

6.3.2 STATIC CONDITIONS (Circuit Diagram 430558 Page 11.1-2)

All plasma display block anodes are driven from the +5V supply and all segment cathodes from the -175V supply. The supplies are connected by conduction of anode and cathode driver transistors:

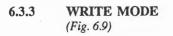
Anodes:	
Both Displays -	Q10 to Q20,
Cathodes:	
MODE display -	Q2 to Q9, and Q41,
OUTPUT display -	Q33 to Q40, and Q42.

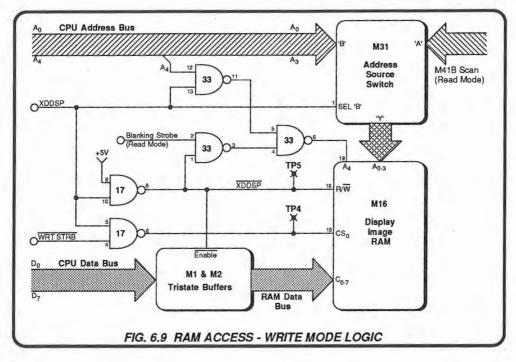
When not energized, all anodes and cathodes are held at -70V by the action of 75V zener D17.

To energize a particular block (simultaneously on both displays), the multiplex decoder causes the relevant anode driver transistor to conduct, lifting its two anodes to +5V.

At the same time, the two sets of data (for the characters to be displayed in the two blocks) are extracted from the Display Image RAM, and applied to the segment cathode drivers. Those segments selected for illumination are pulled to -175V, striking the discharge.

Four keep-alive electrodes in each digit block (two anodes and two cathodes) are maintained at +5V and -175V respectively. This ensures a rapid strike when a digit is energized, helping to prevent inter-block 'streaming'.





Whenever the CPU is programmed to update a display (eg. for Range, Function, Mode or Value change) it sets address decode XDDSP to Logic-1 with each byte of data to be transferred. This causes M31 and M33 to select the CPU address lines A_{4-0} which are mapped directly to the RAM address input lines A_{4-0} . The RAM is placed into its write mode by signal \overline{XDDSP} at Logic- \emptyset (M17-8, TP5, M16-16).

The RAM M16 is divided into two sections, using the address bit A_4 to differentiate between OUTPUT and MODE display images. When the CPU is loading the RAM with OUTPUT display data, it sets A_4 to Logic-1, passing to set M16-19 (A_4) input to Logic-1. MODE display and COMMAS images are written into M16

6.3.4 READ MODE

(Fig. 6.10)

Unless the CPU has data to update, the signal XDDSP remains at Logic-Ø, to hold the display multiplexer circuitry in Read mode. The RAM data bus is isolated from the CPU data bus by tri-state buffers M1/M2, and M16 is chip-selected in read mode by M17-6 and M17-8 at Logic-1.

6.3.4.1 Display Scan Address Interlacing (Circuit Diagram 430559 Page 11.2-1)

M31-1 (SEL) at Logic-Ø causes the RAM to be addressed from the display block scan, mapping M41B outputs: Q4B, Q3B, Q2B, Q1B to RAM address input lines: A_0 , A_3 , A_2 , A_1 respectively. This bit-rotation interlaces the extraction of display data, in synchronism with the interlaced block selection by the Front Assembly Scan decoder.

with A_4 at Logic-Ø (M33-4 and 13 at Logic-1 in write mode). (In Read mode M16-19 is again used to differentiate between the two image sections).

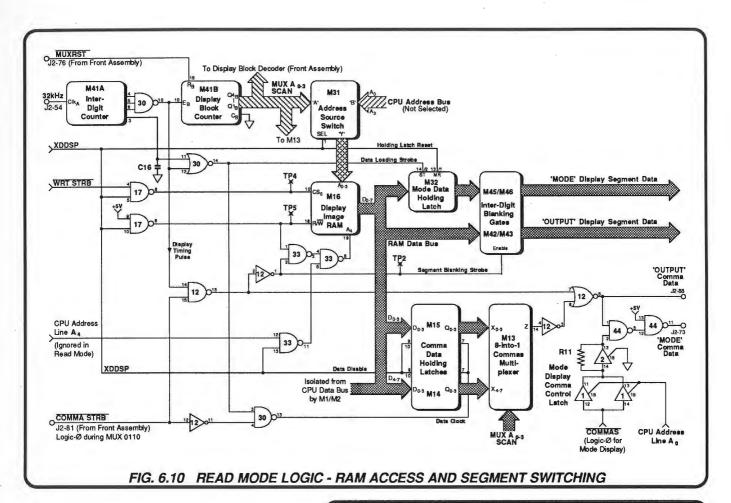
The signal $\overline{\text{XDDSP}}$ (M17-8) enables the tri-state buffers M1 and M2, connecting the CPU data bus to M16 data input/output lines D₀₋₇. With each byte of display data, the CPU also generates the write strobe signal $\overline{\text{WRT STRB}}$. This is combined with XDDSP (M17-6, M16-10, TP4) to enable M16 internal Input/Output tristate buffers to accept the data byte (chip select CS₀). Once the display data has been loaded into the RAM, the CPU returns XDDSP to Logic-Ø and the RAM reverts to Read mode.

6.3.4.2 Block Multiplex Decoding (Circuit Diagram 430558 Page 11.1-2) (Figs. 6.10 and 6.11)

The 4-bit Block scan output MUX A_{3-0} from the multiplex scan counter M41B (dig) is used at DATA₄₋₁ input to M3 (on the Front assembly), which decodes it into a low-active 16-line scan S_{15-0} .

To strobe the commas, M3 output S_6 generates the signal COMMA STRB, and its S_{13} terminates each scan by resetting M41B in the Digital assembly (MUX RESET). Outputs S_7 , S_{14} and S_{15} are not used.

The other eleven M3 outputs switch transistors Q10 - Q20 on sequentially, driving the anodes of both plasma displays in synchronism. As can be seen from *Fig. 6.11*, the interlace is maintained to avoid consecutive activation of adjacent blocks, thus preventing inter-block 'streaming'.



6.3.4.3 Display Data Selection (Circuit Diagram 430559 Page 11.2-1)

When the processor writes display data into the Display Image RAM, the A_4 input is used to select the MODE or OUTPUT display data storage area (see para 6.3.3 and Fig. 6.11). In Read mode also, A_4 is set to Logic-1 to read OUTPUT display data, and to Logic- \emptyset for MODE or COMMA data.

For an alpha-numeric display block, 18 bits of data could be required:

One byte - OUTPUT display block segments; One byte - MODE display block segments; Two bits - COMMAS (one for each display).

The problem of transferring two bytes of data along the single-byte RAM data bus is overcome by strobing each MODE display segment byte into a holding latch (M32), during the first 30μ s of its block selection time-slot. The MODE display section of the RAM is selected by setting its A₄ input to Logic-Ø for this Inter-digit' period, during which the inter-digit blanking gates, (M42/43, M45/46), set all the segment lines going to the Front Assembly to Logic-Ø (segments OFF).

COMMAS data are stored in the Display Image RAM as a separate byte (*refer to Section 6.3.4.6*).

$\begin{array}{c c c c c c c c c c c c c c c c c c c $			A0 Dut D1 t AM Iy)	M3 Output 'S' Low Active (Front Assembly)	Display Block Anode Energized, or Signal Selected (for both displays simultaneously)		
.0	0	0	0	s ₀	A ₁		
0	0	0	1	s ₁	Ag		
0	0	1	0	S ₂	A5		
0	0	1	1	S ₃	A7		
0	1	0	0	S ₄	Ag		
0	1	0	1	S ₅	A ₁₁		
0	1	1	0	S ₆	COMMA STRB		
0	1	1	1	S7	Not Used		
1	0	0	0	S ₈	A2		
1	0	0	1	Sg	A4		
1	0	1	0	S ₁₀	A ₆		
1	0	1	1	s ₁₁	A ₈		
1	1	0	0	S ₁₂	A10		
1	1	0	1	S ₁₃	MUX RESET		
1	1	1	0	S ₁₄	Not included in cycle		
1	1	1	1	S ₁₅) (MUX RESET at S ₁₃)		
	FIG	5. B.1	1 DISF	LAY SCAN	SEQUENCES		

6.3.4.4 Display Timing

(Fig. 6.12)

Read mode is driven by a 32kHz square wave (Waveform 'A', generated from the 13-bit counter in the Analog Interface Assembly M15-11), used as clock for a 4-bit counter (M41A). The three most significant bits are combined at M30-10 to produce Waveform B, the display master-timing pulse, used also for interdigit blanking.

The following example explains how the display data is set up for the next display block in sequence, during the $62.5\mu s$ of the display timing pulse.

Example

Initial State:

M41B count has already reached 1001, and the block-4 anodes of both displays are energized (*Fig.6.11*).

The OUTPUT display data for block 4 is selected in the Display Image RAM (M16) to drive the segment cathodes for a figure '6', which appears on the OUTPUT display.

Block 4 of the MODE display is showing a figure '3', and the data for this is being output from the MODE display Holding Latch (M32). The data held in M16 for the next byte (Block 6 of both displays) is:

OUTPUT display -	Figure '8
MODE display -	Figure '7

Block Changeover: The next block is selected during the display master timing pulse (*Fig. 6.12, Waveform B*).

- a. The negative-going leading edge triggers the scan counter (M41B) whose output advances to 1010 (block 6). On the Front Assembly, M3 de-energizes A_4 anodes and energizes A_6 anodes.
- b. For the duration of the Display Master Timing Pulse (Logic-Ø at M12-14), the A₄ input to M16 is set to Logic-Ø as A₃₋₀ inputs are advanced to 0101. MODE display data for figure '7' is loaded onto the RAM data bus as follows:

- i. M17-6 at Logic-1 selects M16 at M16-10,
- ii. M17-8 at Logic-1 holds M16 in Read mode,
- iii. RAM address $A_{4-0} = 00101$ reads MODE display block 6 data onto the RAM data bus (M1/M2 isolates from the CPU data bus),
- iv. M30-14 at Logic-1 strobes the byte into M32 during the 30µs of Waveform D, then returns to Logic-Ø leaving figure '7' data latched at M32 output.
- v. M12-1 at Logic-Ø blanks the two displays by setting M45/M46/M42/M43 outputs to Logic-Ø, regardless of their inputs from M32 and the RAM data bus.
- c. The positive-going edge of Waveform B lifts the RAM A_4 input (M16-19) to Logic-1, addressing the OUTPUT display section of memory. A_{3-0} is still at 0101, selecting block 6 display data (in our example a figure '8') which it loads on to the RAM data bus.

B1

R

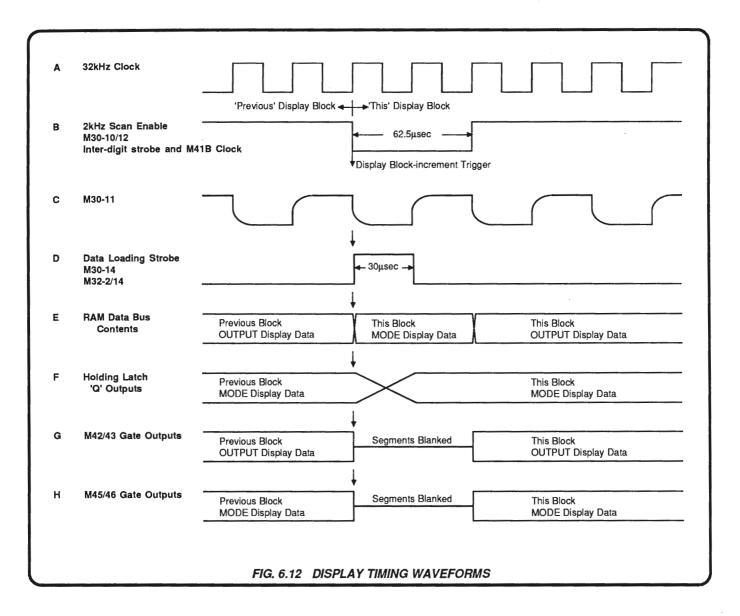
10

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The end of the master timing pulse also releases the blanking by enabling gates M42/M43/M45/M46, so the data for both MODE and OUTPUT displays are now delivered to the cathode drivers on the Front assembly, to strike the gas discharge in the two energized A_6 blocks.

This condition persists for 437.5μ s until the next master timing pulse, when Waveforms B and C repeat the process for the next block of stored display data.

At any time during the cycle, the CPU may force Write mode. This will not disturb the scan from M41B, but XDDSP will reset M32 outputs to Logic- \emptyset (M32-1/13). However, the speed of byte transfer from the CPU ensures that the data being transferred is not visible on the displays. Subsequently, each block will be driven by its new stored data.



6.3.4.5 Display Segment Drive

(Circuit Diagram 430558 Page 11.1-2)

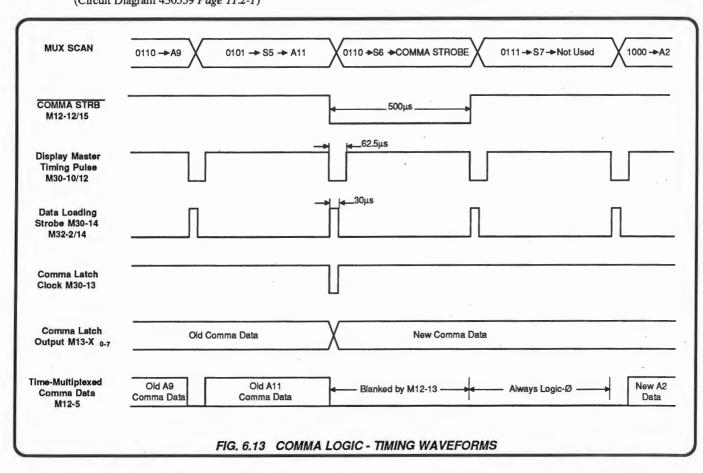
The strobed segment signals from the Digital Assembly are input to the Front Assembly on J1 pins 67-75 (MODE display) and J1 pins 82-90 (OUTPUT display). These are already synchronized to their blocks by the 4-bit block scan MUX A_{3-0} within the Digital assembly.

For each block in sequence, the appropriate segment bit-pattern is set at the input to the segment drivers. For bits at Logic-1, the rise is passed through line capacitors to reverse-bias the DC restoration diodes and forward bias their driver-transistor bases. The segment cathodes are pulled down to -170V by the resultant collector currents, from their quiescent -70V. The correct block anode is simultaneously lifted from -70V to +5V by its anode driver transistor, striking the gas discharge and displaying its digit. For bits at Logic-Ø the cathode drivers remain cut off. The above action proceeds for both displays simultaneously. The anode driver transistor energizes its corresponding block anode on both displays, at the same time as the cathode drivers are loaded with the correct block bit-pattern for their own display.

The cathode driver emitter resistors control the segment cathode currents for uniform brilliance of all segments.

During change-over between blocks, all segment inputs at Logic-1 are returned to Logic- \emptyset by the inter-digit blanking strobes M42/43/45/46 on the Digital assembly. This turns off the drive transistors and blanks the display. The high scan frequency and persistence of the operator's vision prevents the blanking being observed on the display.

6.3.4.6 Comma Logic (Figs. 6-10 and 6.13) (Circuit Diagram 430559 Page 11.2-1)



The comma is the ninth segment (i) in each of the numerical display blocks. It cannot fit into a block's byte in memory, as there are only eight bits per byte. But all the comma information can be stored in a single byte of memory in the RAM (RAM address 01100). This is possible although there are nine numerical blocks, because the ninth block never requires a comma. Legend blocks A_{10} and A_{11} do not have a segment (i).

The RAM COMMA data is updated by the CPU in Write mode, and is read out (as though it were another display block) by M41B scan 0110 during the master display pulse (Waveform B sets RAM A_4 input to Logic-Ø). The same MUX combination 0110 selects S_6 output from M3 decoder on the Front Assembly, which sets the signal COMMA STRB to Logic-Ø.

Thus for the duration of $S_6 = 0$, (500µs); the COMMA data is on the RAM data bus, but the blanking gates prevent it reaching segments (a)-(h).

6.3.4.7 Comma Drive Multiplexing

The COMMA STRB signal is inverted and combined with the Data Loading Strobe at M30-13 as a Logic-Ø pulse, whose positive-going edge clocks the comma data into latches M14/15, approximately 30µsec after it has been loaded on to the RAM data bus. The permanently-enabled ouputs from these latches are input as $X_{0.7}$ into the 8-into-1 multiplexer M13 during a complete MUX scan until the next COMMA STRB signal.

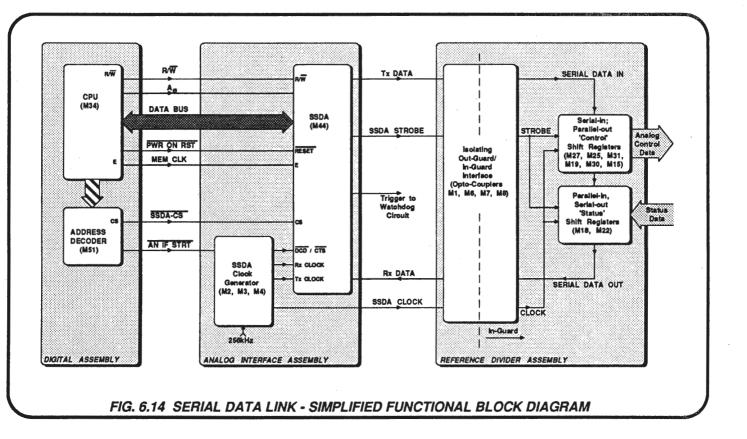
The block-multiplex scan from M41B selects the correct X input to synchronize with activation of its display block anode. This is output from M13-14 (Z), into blanking gates M12.

Comma information is blanked during COMMA STRB, and by inter-digit blanking during display-block change-over (M12-7).

The Comma drive line from M12-5 to the front panel, via J2-88, controls segment (i) cathode driver for the OUTPUT display.

If commas are required on the MODE display (e.g. in 'Spec' operating mode +Lim or -Lim) they will always be in the same display blocks as the OUTPUT display. When this mode is selected, the CPU pulses the $\overline{\text{COMMAS}}$ line to Logic-Ø at the same time as Address line A₀ goes to Logic-1. Tristate buffer outputs M1-11 and 13 go to +5V, setting M2-13 output to +5V (Logic-1). Outputs M1-13 and M1-11 go tristate when the $\overline{\text{COMMAS}}$ line returns to Logic-1, leaving M2-13 latched to +5V by the positive feedback action of R11. So M44-2 enables the comma data to the MODE display segment driver, via J2-73, to copy the OUTPUT display commas on to the MODE display.

When MODE display commas are not required, Logic- \emptyset (0V) is set on A₀ with \overrightarrow{COMMAS} signal at Logic- \emptyset . Thus M2-13 latches to Logic- \emptyset and M44-2 disables the flow of comma data to the MODE display.



6.4 ANALOG CONTROL INTERFACE

The circuitry described in this section performs the following functions:

- Provides a two-way interface via a serial data link between outguard digital processing and in-guard analog control circuitry on the reference divider assembly (see Fig. 6.14).
- Monitors the CPU operation, serial transfer, digital supply failure and restart operations (watchdog), imposing a controlled safety default condition if there is a danger of losing digital control of the analog functions.

A manual reset of the safety monitor is provided on the front panel (see Fig. 6.17).

6.4.1 GENERAL

Safety and Control information is input from Digital (400559) and Front (400558) Assemblies to out-guard circuits located on the Analog Interface Assembly (400648), processed and transferred across the 'Guard' isolation barrier to in-guard circuits in the Reference Divider Assembly (400652). After further processing in the Reference Divider Assembly, safety and control information is output to the following assemblies:

- Sine Source Assembly (400446),
- AC Assembly (400663),
- PA Assembly (400618),
- DC Assembly (400536),
- · Current/Ohms Assembly (400614), and
- High Voltage Assembly (400537).

Certain selected 'Status' signals, originating in the analog assemblies, are returned to the CPU during the data transfer. Thus, the data link forms a continuous loop, as shown in Fig.6.14.

6.4.2 SERIAL DATA TRANSFER (Fig. 6.14) (Circuit Diagrams: 430559 Page 11.2-2, 430648 Page 11.3-3, 430652 Pages 11.4-4 and 11.4-5)

A bi-directional serial data link passes information across the guard isolation screen; passing CPU commands to control the in-guard analog circuitry, and returning critical status signals from the guarded circuits back to the CPU.

The link is managed by a synchronous serial data adaptor (SSDA) which, having first been loaded with three bytes of control instructions by the microprocessor; transmits the resultant 24-bit word across guard one bit at a time, via its Tx DATA channel.

The 48 bits necessary to control the analog circuitry thus require two successive 24-bit transmissions.

Simultaneously with each 24-bit transmission, the SSDA receives a 24-bit word via its Rx DATA channel, enabling the CPU to parity-check its returned data, and obtain the status of the analog functions.

6.4.2.1 The Transfer Cycle (Fig. 6.14)

The CPU uses an address-code signal AN I/F STRT (Analog Interface Start) to initiate each 24-bit shift, by triggering a separate clock generator (M2, M3, M4) which produces a burst of 24 clocks per shift. Data is clocked in a serial string through a continuous loop comprising:

- the 48-bit, serial in/parallel out, analog control shift register;
- the 16-bit, parallel in/serial out, status shift register;
- back to the SSDA receiver (Rx DATA).

The serial data string is correctly located after two 24-bit shifts, so then the SSDA generates a strobe pulse which:

a. Transfers the data present in the serial data string of the six 8-bit analog-control shift registers (M27, M25, M31, M19, M30, M15) into their enabled parallel output registers and onto the analog control bus.

When the strobe ends, further transfer is disabled and the registers' output data is latched.

b. Injects the status data at each of the 8-bit parallel inputs of the two status shift registers (M18, M22) into corresponding locations in the serial data string.

When the strobe ends, the parallel inputs to the status registers are disabled.

After the strobe pulse, the CPU initiates a further circulation of serial data (including the status data), in order to obtain the status data and return the analog control bits to the SSDA Rx DATA register for parity checking by the CPU.

This extra (confimatory) circulation requires three more 24-bit shifts, so a complete data transfer consists of five shifts. If no error is detected, the SSDA provides a trigger-enable to allow updates to prevent activation (BARK) of the watchdog circuits.

If an error is detected on the first transfer, the CPU activates a second complete transfer, and then a third if an error is detected on the second. If the error persists after the third transfer, the trigger-enable is withheld, and the instrument will shut down under the control of the 'Watchdog' safety monitor.

All interfacing between out-guard and in-guard circuits is achieved using electrically-isolating opto-couplers.

6.4.2.2 Data Transfer Organization (Fig. 6.15)

Data is transferred serially via the SSDA, control registers and status registers as directed by the CPU.

The exchange of data between the CPU and SSDA is made in bytes of 8 bits on the instrument data bus, each exchange comprising three bytes (24 bits) of parallel data. The shifts of serial data through the in-guard circuit are synchronized by clocks which are controlled from the CPU, and the SSDA Rx return registers are cleared when read by the CPU.

Once the in-guard serial data is correctly positioned at the inputs to the control registers, the SSDA generates a strobe which enables its transfer to the parallel outputs of the control registers. The same strobe enables injection of the data on the parallel inputs of the status registers into the serial data string.

The transfer operation requires five serial data shifts, each of three bytes, through the registers. During this operation: the control registers are loaded with bytes of new data (ND); the status registers are loaded with new status data (NS); and the whole of the ND and NS data is returned to the CPU, which:

a. verifies that the analog control bits of the serial data string return to the SSDA Rx DATA register without error. This indicates that at least, the correct bit pattern was applied to the analog control register inputs at the time the strobe was generated.

b. acts upon the status data received.

6.4.2.3 Transfer Sequence

The sequence of events in the transfer operation is as follows, referring to Fig. 6.15:

- a. Three bytes of new data, ND1, ND2 and ND3 are loaded into the SSDA transmitter registers; this data is destined for control registers D1, D2 and D3. The SSDA receiver registers were cleared when last read by the CPU.
- b. A burst of 24 clock pulses, initiated by the CPU, shifts all data three bytes to the right. After the shift is completed, the transmitter registers are loaded with new data bytes ND4, ND5 and ND6 (destined for control registers D4, D5 and D6). During this period, no transfers are made between the serial data string and the parallel control or status registers.
- c. A second burst of 24 clock pulses again shifts all data three bytes to the right. New data bytes ND1 to ND6 are now correctly positioned in control registers D1 D6. After completion of the shift, three dummy bytes are loaded into the transmitter registers. Old data in the receiver register is ignored.
- **d.** With new data bytes ND1 to ND6 correctly located, the SSDA generates a strobe pulse. This pulse:
 - i. latches the 48 bits of bytes ND1 to ND6 at the parallel outputs of control registers D1 to D6;
 - ii. enables the parallel inputs of status registers S1 and S2, loading two new status bytes NS1 and NS2 and clearing old data OD5 and OD6 from the registers.
- e. A third burst of 24 clocks again shifts all data three bytes to the right. The CPU reads bytes NS1, NS2 and ND1 from the SSDA receiver registers (the CPU may take immediate action on NS returns). After the shift is complete, new data bytes ND1, ND2 and ND3 are re-loaded into the transmitter registers.

- f. A fourth burst of 24 clocks again shifts all data three bytes to the right. The CPU reads bytes ND2, ND3 and ND4 from the receiver registers. After the shift is complete, new data bytes ND4, ND5 and ND6 are re-loaded into the transmitter registers.
- g. A fifth burst of 24 clocks again shifts all data three bytes to the right. Bytes ND5 and ND6 are read from the receiver registers. The CPU has now read all new data and status bytes and the transfer sequence ends. If an error is detected between new data transmitted and new data received, the transfer process is repeated; three attempts are allowed before a fault condition is declared.

6.4.3 SYNCHRONOUS SERIAL-DATA ADAPTOR (Circuit Diagram 430648 Page 11.3-3)

6.4.3.1 SSDA Initialization

When power supplies are first switched on or an external reset signal EXT RST is applied, the signal $\overline{PWR ON RST}$ (Power On Reset) is held at Logic- \emptyset for approximately 8ms.

During this period, the SSDA is latched in a reset condition to prevent erroneous output transitions at its Tx and Rx interfaces; the internal transmit registers are inhibited to prevent the loading of data from the data bus and the SSDA strobe output is held at Logic-1.

After **PWR ON RST** returns to Logic-1; the instrument state is initialized by the firmware program. This routine clears the latches, registers and SSDA strobe.

6.4.3.2 Parallel Data Input From CPU

The conditions for parallel data on the data bus to be accepted by the SSDA are as follows:

- a. Chip-select SSDA CS at Logic-Ø.
- b. Read/Write command R/\overline{W} at Logic-Ø. This controls the direction of data flow via the Data Bus through the SSDA input/output port. When R/\overline{W} is at Logic-Ø, data on the Data Bus is written into a selected register within the SSDA.
- c. The memory clock 'MEM CLK' 682.6kHz square wave synchronizes the SSDA operating cycle to that of the CPU.

With register address bit Ao at Logic-1 and input conditions present as above, the SSDA accepts data from the data bus into a 3-byte internal FIFO register. The data is entered over several MEM CLK cycles and stored in the FIFO register in readiness for serial transmission from the SSDA.

When the address bit A_0 is at Logic-Ø, data transferred into the SSDA are recognised as programming instructions. The SSDA is programmed as part of the initialization routine. For details of 'Control Byte' operation, refer to Motorola 6852 data sheet.

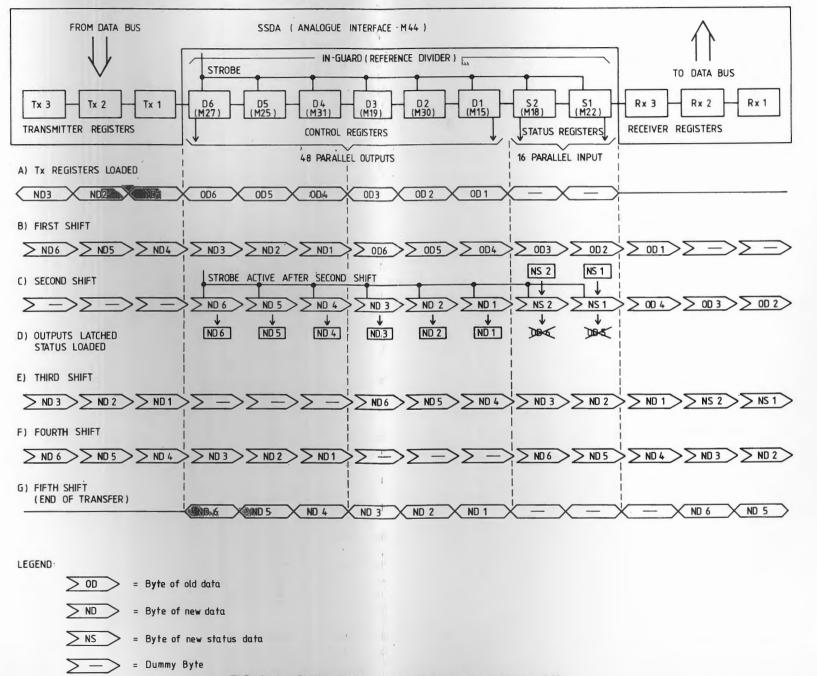


FIG. 6.15 SERIAL DATA TRANSFER ORGANIZATION

6.4.3.3 Parallel Data Output to CPU

The conditions for data to be read back from the SSDA on to the data bus are as follows:

- Chip-select SSDA CS at Logic-Ø.
- Read/Write command R/\overline{W} at Logic-1.
- Memory clock, MEM CLK, present.

The data read from the SSDA may be from one of two sources, selection being made by address bit Ao:

- With A₀ at Logic-1, received data from the serial data input FIFO is transferred to the data bus.
- With A₀ at Logic-Ø, the CPU reads an internal SSDA status register.

Serial Data Transmission 6.4.3.4

Serial data transmission is controlled by the CTS (clear to send) input to the SSDA. Transmission is inhibited by CTS at Logic-1, and enabled when CTS is set to Logic-Ø by the CPU address-code signal AN I/F STRT. The first serial bit is transmitted by the negative transition of the first full positive Tx clock pulse (256 kHz) after CTS has been set to Logic-Ø. CTS is held at Logic-Ø by the AN I/F STRT latch for the duration of 24 full Tx clock pulses, thus enabling the serial shift transmission of the 24 data bits from the Tx Data FIFO in the SSDA.

6.4.3.5 Serial Data Reception

Serial data is received by the SSDA, controlled by the DCD (data carrier detect) level and clocked by Rx CLOCK. DCD is common to the transmit control CTS so that transmission to, and reception from the serial/parallel shift registers is synchronous. Both Rx CLOCK and Tx CLOCK have the same frequency but Rx CLOCK is inverted with respect to the latter. The first bit arriving at its Rx DATA input is clocked into the SSDA Receive FIFO register on the positive transition of the first full Rx clock after DCD is set to Logic-Ø.

SSDA CLOCK GENERATION 6.4.4

Serial data is transmitted and received in bursts of 24 data bits. Three clocks are used to time the flow of bits, ensuring that:

- Data has time to settle before being clocked along the shift registers.
- The first Rx data sample is taken before it is lost by the first bitshift
- Subsequent Rx data has time to settle before being sampled by the SSDA.
- Exactly 24 bits are shifted in each burst.

6.4.4.1 SSDA, Tx and Rx Clock Action (Fig. 6.16)

The three clocks are derived from the 256 kHz square wave output from the 13-bit counter. The 256 kHz squarewave is used directly as the signal 'Tx CLOCK' into the SSDA.

(Refer to Circuit Diagram 430648 Page 11.3-2 - M15-14).

After CTS is set to Logic-Ø, the negative transition of the first full positive pulse triggers the first serial Tx data bit setup. (Refer to Fig. 6.16 Waveforms G and H).

'Rx CLOCK' is an inverted version of the 256kHz squarewave. After DCD is set to Logic-Ø, the positive transition of the first full Rx clock cycle triggers the SSDA. The SSDA thus samples the first Rx data bit before the SSDA clock triggers the shift registers. (Fig. 6.16 Waveforms K and J).

'SSDA CLOCK' is also an inverted version of the 256kHz squarewave. The inversion allows approximately 2ms of data setup time for all serial data bits prior to clocking the data along the shift registers. SSDA CLOCK is gated at M2-3 by the action of M3-12 to ensure that the first Rx data is sampled before it is lost by the first bit-shift. 24 clock pulses are counted by M4, allowing 24 bits to be shifted before resetting the Analog Interface Start latch M2-11 (TP3) to Logic-1.

(Refer to Fig. 6.16 Waveform I).

6.4.4.2 SSDA Clock Circuitry (Circuit Diagram 430648 Page 11.3-3)

The following paragraphs describe the action of the SSDA clock generator circuitry.

The action of the SSDA clock generator is initiated by the command AN I/F STRT from the CPU. This occurs after the parallel data has been loaded into the SSDA transmit registers from the data bus. The Logic-Ø pulse of AN IF STRT sets flip-flop M2-10/11 to give a Logic-Ø at TP3 which then:

- Sets the D input level of flip-flop M3-5;
- Removes 'SET' to enable shift register M3 at M3-6 and M3-8;
- Removes 'RESET' to enable counters M4 at M4-7 and M4-15. (Refer to Fig. 6.16 Waveforms A and C).

At the next rising edge of the inverted 256 kHz (Rx CLOCK) from M43-8 after AN I/F STRT, the shift register M3 is clocked but only M3-1 'Q' output changes state to Logic-Ø. This is applied to the SSDA CTS and DCD inputs, thus releasing the inhibits on the SSDA transmit and receive registers.

(Refer to Fig. 6.16 Waveforms D and E).

At the next (second) rising edge of the clock to M3, M3-12 changes to Logic-1. This allows NAND M2-3 to pass 256 kHz clock pulses via buffer M5-12 to the Reference Divider Assembly to shift the serial data string along the analog-control and status registers. (Refer to Fig. 6.16 Waveforms D, F and I).

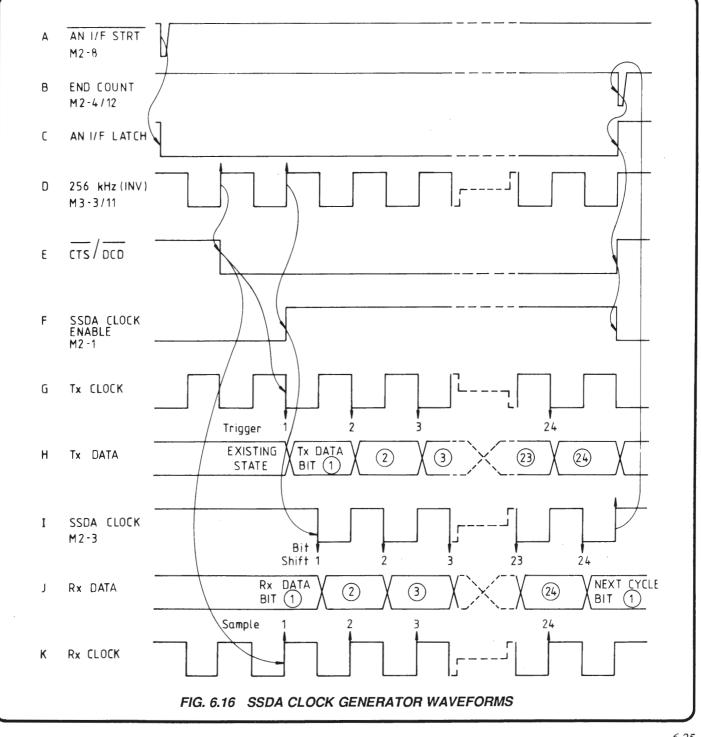
The 256 kHz clock at NAND M2-3 is applied to the 4-bit up-counter clock input at M4-1, each rising edge causing the counter to increment by 1.

The divide-by-16 output M4-6 is applied to enable M4 at its M4-10 input; the falling edge occurring at count-16 and incrementing the second counter to produce, at M4-11, a Logic-1 output. Later, at count-24, M4-6 changes again to Logic-1, and together with M4-11 output, gives a Logic- \emptyset from NAND M2-4, causing the following actions:

- a. Flip-flop M2-12 is reset to give Logic-1 at TP3.
- b. The Logic-1 at TP3 sets shift register M3 to give:
 - i. Logic-1 at M3-1, thus inhibiting \overline{DCD} and \overline{CTS} ;

- ii. Logic-Ø at M3-12, disabling NAND M2-3 and thus stopping any further SSDA clocks.
- c. The Logic-1 at TP3 resets the up-counters M4 causing:
 - i. the counter outputs to fall to Logic-Ø, inhibiting further counting;
 - ii. NAND M2-5 to rise to Logic-1, re-setting flip-flop M2-12 to prepare for the next AN I/F STRT input.

(Refer to Fig. 6.16 Waveforms I, B, C, E and F).



6.4.5 SERIAL/PARALLEL CONVERTER (Circuit Diagram 430652 Pages 11.4-4 and 11.4-5)

Serial control data transmitted from the SSDA (Analog Interface Assembly), together with their control signals (SSDA strobe and SSDA clock), enter the Reference Divider Assembly via the Mother Assembly.

The data and signals cross the isolation barrier through opto-isolators M6, M7 and M8 into guard.

Serial control and status data is returned out of guard to the SSDA receiver via opto-isolator M1.

6.4.5.1 Logic Levels

The nominal logic levels (Logic-1 = +5V, Logic- \emptyset = 0V) used in the out-guard SSDA circuits, are offset at the opto-isolator outputs to:

Logic-1 = 10V, Logic-Ø = 15V;

and level-shifted for the in-guard circuitry to:

Logic-1=0V, Logic-Ø = 15V

6.4.5.2 Serial-In/Parallel-Out Control-Data Convertors

Six 8-bit serial shift registers M27, M25, M31, M19, M30 and M15 each have latchable parallel outputs. Their serial "D" inputs and "Q's" outputs are cascaded to form a single 48-bit serial shift register. M27 receives 'serial data in' from M8 via the level-shifting buffer M36-4, and M15 passes serial data on to the Parallel-in/Serial-out Status-Data converters.

6.4.5.3 Parallel-In/Serial-Out Status-Data Converters

Two 8-bit serial shift registers M18 and M22 each have parallel inputs. M18 serial "Ds" input accepts serial data from M15; M18 "Q8" output is cascaded to M22 "Ds" input; and M22 "Q8" output delivers SERIAL DATA OUT to buffer M11-11 and back to the SSDA via M1 opto-isolator.

M18 and M22 thus form a 16-bit serial shift register whose 16 parallel inputs' states can be inserted into the serial data string.

6.4.5.4 Serial Data Cycling

The serial data, organized into five blocks of three bytes (*Refer to Section 6.4.2.2*), is accompanied by synchronized bursts of 24 clocks. The output from opto-coupler M7 is buffered via level-shifter M36-2 and then inverted at M14-6. The timing of the positive clock edges allows all bits of serial data (distributed throughout the shift registers) to stabilize before being clocked on.

After the CPU has generated two bursts of data and clock pulses, the serial control data has shifted into the correct positions in control registers M27, M25, M31, M19, M30 and M15. So before the third

burst of three bytes, the SSDA produces a strobe which writes the control data into their parallel outputs. Simultaneously, the strobe also fills the 16-bit serial register of M18 and M22 with the status data present on their parallel inputs.

When the strobe ends, further transfers between serial and parallel registers are disabled. The new control data remains latched in the parallel control registers, and the new status data is in the serial status register ready for shifting to the SSDA Rx DATA register through guard.

The control and status bits in the registers are then circulated by three further bursts of clock pulses, until the CPU has read both the new status data and all the control data that were written by the strobe. Verification that the returned control data is identical to the transmitted data, ends the transfer.

If after three attempts, the returned data does not match the transmitted data; the CPU omits to re-trigger monostable M10 in the Reference Divider Assembly. M10 times out and allows the signal BARK DEL to go to Logic-Ø, disabling the 48 control data outputs by 'tri-stating' the registers M27, M25, M31, M19, M30 and M15.

6.4.5.5 Parallel Control-Data Outputs and Status-Data Inputs

The data latched in M27, M25, M31, M19, M30 and M15 outputs control the operation of the Analog circuitry. The effects are therefore described in the sub-sections relevant to their destinations.

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As this is a multi-purpose converter, designed for use in more than one model of instrument, some of the control and status lines are not used.

6.4.6 SAFETY MONITOR (WATCHDOG) (Fig.6.17)

6.4.6.1 Watchdog Signals

The watchdog circuits continuously monitor the CPU/SSDA functional process. Detection of a processor malfunction by the watchdog results in the following actions:

a. BARK. This signal:

- i. removes the drive from the primary of the High Voltage (1kV) transformer,
- ii. disables the 400V Power Supply, and
- iii. disconnects the Current Assembly output from the instrument output terminals.
- b. BARK. This is returned as a status bit to the CPU via the SSDA to signal a failure.
- c. BARK DELAYED. This occurs 47ms after BARK and disconnects the AC Voltage Power and Sense circuits from the instrument output terminals.
- d. BARK DELAYED. This signal disables the registers of the serial/parallel data converters.

6.4.6.2 Effects at Power-on

The watchdog outputs are manipulated by the power-on reset circuits as follows:

- BARK DELAYED and BARK DELAYED are held active for 80ms from power-on and then are allowed revert to the inactive state only after two SSDA strobes have been detected.
- BARK is forced active until CPU/SSDA functioning has been verified; the latter must occur within 470ms of power-on.
- BARK is held inactive for 470ms from power-on, after which it provides a FAIL message to the CPU.

6.4.6.3 Effects after 'Reset'

Operation of the Reset control on the front panel provides a further 100ms period for the CPU/SSDA functional process to settle, during which time the watchdog circuits must verify correct functioning before their outputs are reset.

6.4.6.4 Watchdog Trip Action

The watchdog is tripped if the system fails to transmit analog-control updates to the analog circuitry. The updates are of two types:

- Transfer of 'Output value' data via the Analog Interface comparators,
- Transfer of analog switching data via the SSDA every 40ms.

The CPU generates pulses at 8ms intervals to verify that the correct output value has been latched into the Analog Interface comparators. These pulses are allowed to pass into guard only if the SSDA verifies that the analog switching data is being transferred normally at 40ms intervals. Once in guard, the pulses prevent the watchdog flip-flops from generating their four BARK output signals, by retriggering a monostable (M10-4: 18ms) to hold it in its unstable state.

If two or more pulses are missing, M10 releases the hold, and the watchdog flip-flops 'Bark', activating the safety circuitry. They will be missing if the output value comparators are incorrectly updated; if the SSDA fails to generate 'Transmit' pulses for a period exceeding 470ms; or if the CPU crashes.

6.4.7 WATCHDOG CIRCUITRY

6.4.7.1 Out-Guard Watchdog (Circuit Diagrams 430648 Section 11.3 and 430652 Section 11.4)

The CPU verifies the validity of each serial-interface transfer by giving the SSDA an instruction to generate a 'Watchdog Enable' trigger. This 'W.DOG ENBL SET' pulse (M44-7 on page 11.3-3), triggers watchdog-enabling monostable M29-11 (page 11.3-1).

W.DOG ENBL SET triggering and retriggering extends the natural (470ms) unstable state of M29 indefinitely. Unless the retriggers fail, the M29-9 output (W. DOG ENABLE) remains at Logic-Ø. Absence of W.DOG ENBL SET retriggers, for longer than 470ms, allows M29-9 to restabilize to Logic-1.

W.DOG ENABLE is inverted at M43-3 and applied to NAND gate M46-12 (page 11.3-4).

During each successful processor cycle, the CPU addresses M51-9 (Digital Assembly *page 11.2-2*). The resulting low active pulses at 8ms intervals are inverted, and gated with WRT STRB to generate the active-low signal $\overline{W.DOG}$ at M49-11.

W.DOG travels via the Mother Assembly to the Analog Interface Assembly to be gated with the W.DOG ENABLE signal at NAND M46 (*page 11.3-4*). The resulting signal at M46-13, W.DOG, consists of positive-going pulses at 8ms intervals when the CPU/SSDA system is working normally, or a Logic-1 level if the SSDA fails.

The W.DOG signal travels via the Mother Assembly to be passed into guard on the Reference Divider Assembly (Opto-coupler M9 on *page 11.4-5*).

6.4.7.2 In-Guard Watchdog

(Circuit Diagram 430652 Page 11.4-5)

NOTE:

The operating levels of the in-guard CMOS circuits are negatively displaced as follows (nominal voltages):

Opto-coupler output circuits

Logic-1: -19VDC Logic-Ø: -15VDC

Digital CMOS circuits

Logic-1: 0V Logic-Ø: -15VDC

Level-shifter M36 carries out the interfacing between these two levels.

The 'W.DOG' signal is opto-coupled into guard by M9. During normal operation: the W.DOG in-guard positive-going pulses, at 8ms intervals, keep re-triggering the monostable M10-4 to give a continuous Logic-Ø at M10-7. The 18ms unstable state of M10 allows for one pulse to be absent, but if two or more pulses are missing, M10 resets, taking M10-7 to Logic-1.

The logic level from M10-7 is connected directly to the set input of flip-flop M13-6. With the reset input to M13-4 held at Logic- \emptyset during normal operation, the output conditions of M13-1 and M13-2 are as follows:

- Set input M13-6 = Logic-Ø (no fault); M13-1 (Q) = Logic-Ø - BARK not active M13-2 (Q) = Logic-1 - BARK not active
- Set input M13-6 = Logic-1 (malfunction); M13-1 (Q) = Logic-1 - BARK active M13-2 (Q) = Logic-Ø - BARK active

The action of M13-2 changing to Logic-Ø triggers the monostable M10-11 which has a relaxation time of 47ms. After 47ms, M10-9 output clocks flip-flop M13-11 to give the command BARK DEL from M13-13 and BARK DEL from inverter M14-12.

6.4.7.3 Power-On Reset

(Circuit Diagram 430652 Page 11.4-5)

When power is first applied, the build-up of the 15V supply forces shift register M37 Set inputs to Logic-Ø, but its Reset inputs are held at Logic-1 by the charging action of R122/C7.

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So M37 is forced into reset state for about 80ms:

- M37-2 imposes Logic-1 at M13-8 Set input.
- M37-1 at Logic-Ø holds M10 inactive at M10-3, thus preventing random triggering at M10-4 from erratic W.DOG inputs, as the SSDA/CPU functions start up. 'Q' output M10-7 holds M13-6 Set input at Logic-1.

Also, the Reset inputs M13-4 and M13-10 are held at Logic-1 for a period of 470ms from power-on by the signal $\overline{FP RST}$, generated by the power-on reset action of M53 on the Digital Assembly. (*page 11.2-2*).

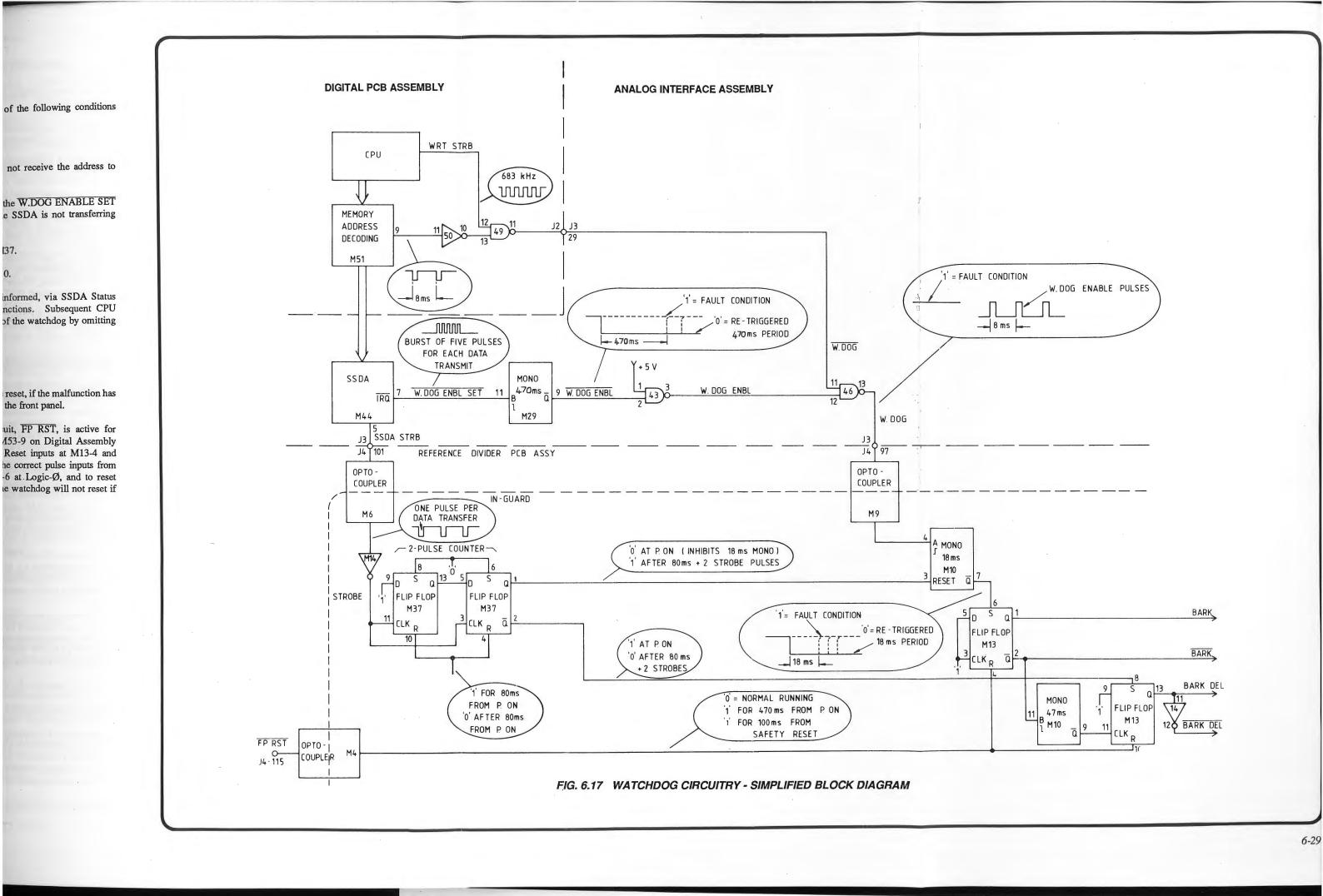
Therefore, the Set/Reset inputs M13-8/M13-10, initially both at Logic-1, force M13-13 output to Logic-1 to give active BARK DELAYED and BARK DELAYED outputs.

The Set/Reset inputs M13-6 and M13-4, also initially at Logic-1, force:

- · M13-1 to Logic-1 (Active BARK), and
- M13-2 to Logic-1 (Non-active BARK).

The output states of M37 (M37-1 = Logic- \emptyset , M37-2 = Logic-1) remain unchanged after the 80ms time constant at M37 Reset inputs, but then M37-11 is free to be triggered from the SSDA strobe input. Two strobe inputs must occur before M37-1 clocks to Logic-1 and M37-2 to Logic- \emptyset . M13-13 now changes to Logic- \emptyset , making BARK DELAYED and BARK DELAYED inactive, and the inhibit is removed from M10-3.

The outputs M13-1 and M13-2 remain unchanged until M10-7 falls to Logic- \emptyset by the clocking action of pulses on the W.DOG input. This must occur before M13-4 returns to Logic- \emptyset (at 470ms from power-on) for BARK to be made inactive, otherwise BARK remains active and BARK is set to Logic- \emptyset , producing a fail status bit which is passed to the CPU.



6.4.7.4 Malfunction (Fig 6.17)

Any malfunction which introduces one of the following conditions will cause the watchdog to bark:

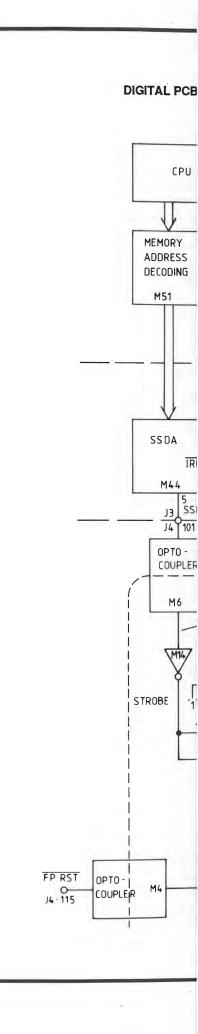
- a. CPU WRT STRB fails at Logic-Ø.
- b. M51 on the Digital Assembly does not receive the address to activate M51-9.
- c. Failure of transmission of bursts of the W.DOG ENABLE SET pulses from the SSDA to M29 (The SSDA is not transferring serial data).
- d. The SSDA Strobe is not triggering M37.
- e. W.DOG pulses are not triggering M10.

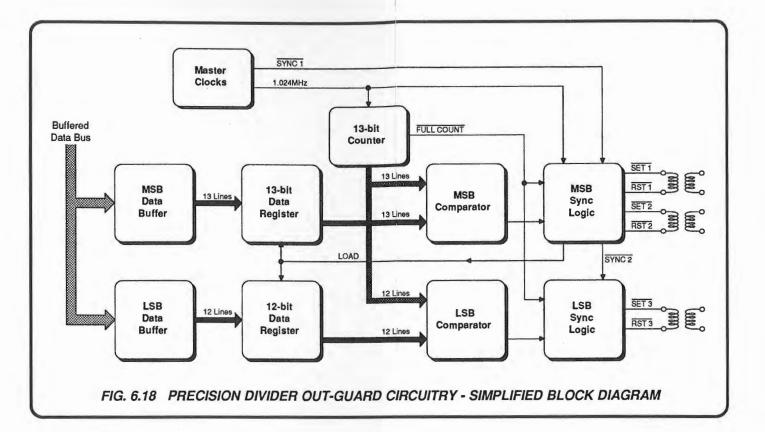
As well as these failures the CPU is informed, via SSDA Status byte transfer, of certain analog malfunctions. Subsequent CPU action can include deliberate activation of the watchdog by omitting to address M51 as in (b) above.

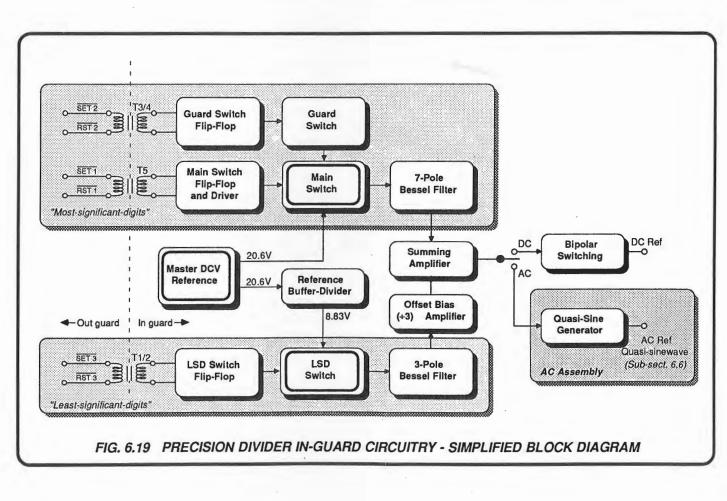
6.4.7.5 Reset

Once the watchdog has 'Barked' it can be reset, if the malfunction has cleared, by pressing the Reset control on the front panel.

The Reset input to the watchdog circuit, $\overline{\text{FP}}$ RST, is active for 100ms after pressing the Reset key. (M53-9 on Digital Assembly *page 11.2-2*). During this period, the Reset inputs at M13-4 and M13-10 are held at Logic-1, allowing the correct pulse inputs from the processor and SSDA to hold M13-6 at Logic-Ø, and to reset BARK DEL at M13-13 to Logic-Ø. The watchdog will not reset if the malfunction persists.







6.5

· Receives and latches the demanded output value from the CPU in the form of a 25-bit word.

· Generates a continuous 13-bit up-count from the 1.024MHz Master Clock (8ms count cycle). · Compares the 13-bit count with the 13 most-significant bits of

The in-guard circuitry performs the following functions:

• Provides a Master Reference Voltage (20.6V) which is chopped by the 'Most Significant' JFET switch to generate a square-wave, whose Mark/Period ratio is controlled by the 13 most-significant bits of the 25-bit word. A 7-pole Bessel filter smooths the square-wave to provide a DC voltage, whose value varies directly as the Mark/Period ratio of the MSB square-wave.

• Provides a Buffered Reference Voltage (8.83V) which is chopped by the 'Least-Significant' JFET switch to generate a square-wave, whose Mark/Period ratio is controlled by the 12 least-significant bits of the 25-bit word. A 3-pole Bessel filter smooths the square-wave to provide a DC voltage, whose value varies directly as the Mark/Period ratio of the LSB square-wave.

The value of this reference voltage is accurately proportional to the value demanded by the CPU's 25-bit word. For DC outputs, with polarity changeover switching, it can have values between +20V and -20V (including zero); but as a reference for AC outputs, its value lies between +0.126V and +2.79V.

stepped AC reference voltage whose peak value is equal to the DC Working Reference Voltage. This gives the Sense/Reference Comparator (described in sub-section 9.5) the considerable advantage of comparing AC Sense against AC Reference. (If AC were compared with DC, small DC off-sets would magnify and lead to 'DC turnover' errors). The AC waveform is constructed in ten steps by a digitally controlled switching network. It has been given the name 'Quasi-Sinewave".

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· For AC outputs only, the in-guard circuitry digitally generates a

The in-guard circuitry is located on the Reference Divider Assembly.

6-30

PRECISION DIVIDER

The out-guard circuitry described in this section performs the following functions:

the 25-bit word, generating 'Set' and 'Reset' pulses. These are transferred into guard to trigger the 'Most Significant' JFET switch in the Reference Divider.

· Compares the 12 most-significant bits of the count with the 12 least-significant bits of the 25-bit word, generating 'Set' and 'Reset' pulses. These are transferred into guard to trigger the 'Least-Significant' JFET switch in the Reference Divider.

The out-guard circuitry is located on the Analogue Interface Assembly.

· Conditions the two DC voltages produced by the Bessel filters, delivering them via full 4-wire connections to be summed on either the DC assembly (for DC output selections) or on the AC assembly (for AC outputs) as a DC 'Working Reference'.

6.5.1 PRECISION DIVIDER COMPARATORS

(Circuit Diagram No. 430648 Section 11.3)

6.5.1.1 General (Figs. 6.18 and 6.19)

The comparators are designed as a means of translating a binary word into the accurately defined Mark/Period ratio of a square-wave. The ratio of the square-wave's average value to its peak value subsequently defines the division ratio applied to the Master Reference, and must be adjustable at high resolution.

The required decimal resolution translates into a 25-bit binary word, each bit needing to exert control of the division ratio. A single comparator of this length would require more than 30 million clocks to scan, which at sensible clock frequencies would occupy several seconds. To filter out the resultant chopping frequency would require large and expensive components, and force unrealistic operational time constraints.

In the Datron Precision Divider, the 25-bit word is split into two parts (13 most-significant bits - MSB; 12 least-significant bits - LSB), a scan-cycling frequency as high as 125Hz is obtained.

Both MSB and LSB comparators are scanned concurrently by the same 13-bit counter, forming two separate square-waves. These act on two separate reference divider switches and filters to generate two separate DC voltages which are subsequently recombined, giving the required resolution.

In summary, the two comparators translate information from the CPU into time-related pulses which control mark/period switching in the reference divider. One comparator operates on the thirteen most-significant bits of CPU data; the other deals with the twelve least-significant bits. The comparators perform concurrently, cycling continuously at 125Hz, taking 8ms per full count.

At the start of each 8ms counting period, each comparator generates a SET pulse to start its reference divider 'Mark' element. Then after precisely-measured delay times, each generates a RESET pulse to terminate the 'Mark', and start the 'Space'.

At each 8ms full-count, the clock resets and continues up-counting from zero.

6.5.1.2 Comparator Operation (Fig. 6.18)

The MSB and LSB Data Buffers are periodically loaded and latched with binary 'Demanded Output Value' data under the control of the CPU.

At the end of each comparator counting cycle, the 13-bit counter $\overline{FULL \ COUNT}$ output enables the generation of set pulses $\overline{SET \ 1}$, $\overline{SET \ 2}$ and $\overline{SET \ 3}$ by the MSB and LSB 'Sync Logic' circuits.

FULL COUNT also generates the LOAD command. This writes the data, currently latched in the buffers, into working data latches which form the 13-bit and 12-bit Data Registers, updating the earlier 'Demanded Output Value' which is resident in the comparator.

The MSB and LSB comparators translate this binary data into 'RESET' pulses, whose time relationships to the 'SET' pulses are established by the value of their binary words.

6.5.1.3 13-Bit (MSB) Comparator (Circuit Diagram No. 430648 Page 11.3-2)

The 13 binary outputs of the up-counter scan the 13 Exclusive-OR elements of the MSB Comparator. With the least-significant bit at 512kHz, and the most-significant at 125Hz, the 8ms scan time thus divides into 8192 time elements, each of 977ns.

Each time element has a unique binary code, incrementing by one bit on its predecessor. When this coincides with the bit-pattern set in the data register, the comparator provides an output pulse to the MSB sync logic. The latter generates reset pulses $\overline{RST 1}$ and $\overline{RST 2}$ in synchronism with the signal SYNC1 (2.048MHz).

6.5.1.4 12-Bit (LSB) Comparator (Circuit Diagram No. 430648 Page 11.3-1)

This functions in the same manner as the MSB comparator, but scanning only twelve bits over the same 8ms counting period, thus accommodating 4096 time elements of 1954ns for each binary increment.

SYNC2 pulses, generated in the MSB Sync Logic circuitry at half the rate of SYNC1, synchronize the $\overline{RST3}$ output from the LSB Sync Logic.

6.5.2 COMPARATOR CIRCUIT ACTION

6.5.2.1 Input Data Latches (Circuit Diagram 430648 Pages 11.3-1 and 11.3-2)

The input buffered data latches M31 to M34 and M37 to M39 receive 27 data bits in four bytes from the buffered data bus. Latches are selected by signals REF DIV 1, 2, 3 or 4 from the memory address decoding on the digital pcb. Data is clocked to the 'Q' outputs of the latches on the positive-going edge of WRT STRB.

Data from the input latches is used as follows:

25 bits form a data word to the comparator registers M47, M48, M49 (part), M51 and M52. The remaining 3 bits from the data latches are used for separate functions:

- a. M34-5 triggers monostable M29 (part), whose Q output is inverted and buffered to provide the control UPD (OG) used in the relay drive logic for analog switching.
- **b.** M34-4 (EXT FREQ SEL) selects between the internal 16kHz synchronizing frequency and the 16kHz output from the External Frequency Input Buffer.
- c. M34-3 (BEEP) triggers the Beeper monostable M55, which is activated to draw attention to display messages.

6.5.2.2 13-Bit Counter

(Circuit Diagram 430648 Page 11.3-2) (Refer to Fig 6-20 for Waveforms)

The counter consists of three 4-bit binary counters M15, M16, M17 and J-K flip flop M42 (half dual package). The squarewave outputs from the counter are on 13 binary-coded lines, the first (leastsignificant) being a 512kHz squarewave, the others successively divided in frequency to the most significant output of 125Hz.

Bit 1 is provided by J-K flip flop M42, which toggles on each falling edge of the 1.024MHz clock to give 512kHz Q and \bar{Q} outputs. These outputs are used as follows:

- a. The two complementary 'Q' outputs together provide the leastsignificant input to the 13-bit comparator;
- b. The Q output controls the counting rate of M15, synchronizes M16 and M17, and is used in the gating of FULL COUNT.

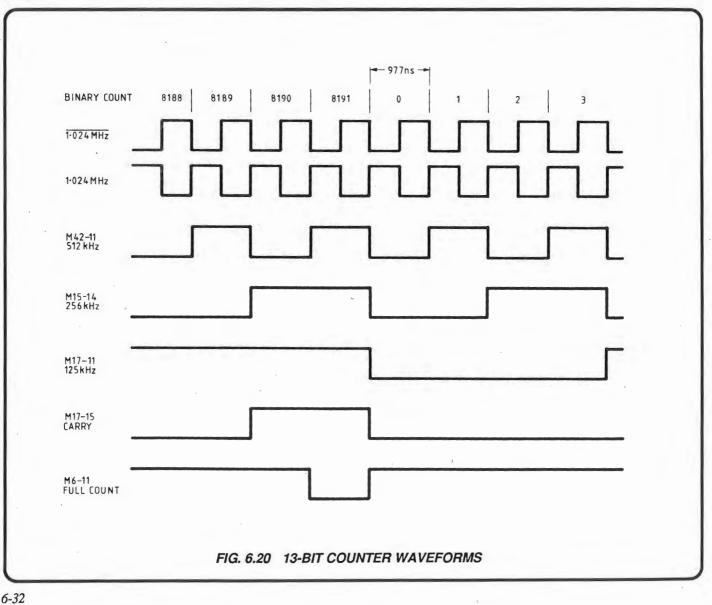
Counters M15, M16 and M17 are cascaded as a 12-bit counter and are synchronously clocked by the 1.024MHz. M15 can count only when its count-enable input M15-7 is set to Logic-1 by the Q output of M42.

As M42 output is at 512kHz, clocking of M15 occurs on the rising edge of alternate 1.024MHz clocks, thus giving outputs of 256, 128, 64 and 32kHz squarewaves from M15.

Counter M16 is enabled by the carry output from M15 together with 512kHz from M42 at the count-enable pins M16-10 and M16-7 respectively, thus giving outputs of 16, 8, 4 and 2kHz squarewaves from M16.

Counter M17 functions in a similar manner to give outputs of 1kHz, 500, 250 and 125Hz squarewaves.

The 2µs-long 'Carry' output from M17 occurs at the end of the 125Hz output when all counter outputs are at Logic-1. The carry output is NANDed with M42Q output to give the 1µs-long logic command FULL COUNT. The counting cycle resets and continues, starting from bit 1.



6.5.2.3 13-Bit Comparator Action (Circuit Diagram 430648 Page 11.3-2)

The 13-bit comparator provides a Logic-1 output at TP12 whenever a coincidence occurs between the following two sets of data:

a. Data set in registers M47, M48 and M49-1;

b. Data from 13-bit counter M42, M15, M16 and M17.

Twelve exclusive-OR elements M25, M26, M27 and three NOR gates of M12 are used to detect a coincidence. The data in the registers is preset by the CPU, while that presented by the 13-bit counter cycles through every binary combination possible on 13 lines.

Two coincident inputs to an exclusive-OR gate provide a Logic- \emptyset to the 12-input NOR gates M24/M23; full coincidence in bits 2 to 13 is shown by a Logic- \emptyset at NAND M13-6. Coincidence at bit 1 is shown by Logic- \emptyset at M12-13 and M12-4 (M12 acting as an exclusive-OR gate) as follows:

M12	PINS	OUTPUT PINS			
6	11	9/12	4	13	
0 0 1 1	1 1 0 0	0 1 0 1	0 1 0 0	0 0 1 0	Only 4 input combinations available

A $\overline{\text{BUSY}}$ signal is generated by the comparator at NAND M50-13 (TP2) when the 13-bit counter approaches full count. Bits 8 to 13 are at Logic-1 for the period of 125µs preceding the end of the counter cycle (see Fig. 6-21). The $\overline{\text{BUSY}}$ level is applied to the M49 D-input at pin 9 and is synchronously clocked through as the signal $\overline{\text{REF BUSY}}$ to buffer M45-2 by 1.024MHz.

As described earlier, the demanded output value is defined by the CPU to a resolution of 25 bits, contained in four data bytes. The time needed for the 4-byte transfer could allow the latches to contain

spurious data until they were fully loaded, and an inaccurate parity could be registered with the counter still running. The counter must not be interrupted, as its full count defines the 'period' of the mark-toperiod ratio used to control the division of the reference voltage. It is therefore necessary to reduce the loading time, and this is achieved by double-latching the data.

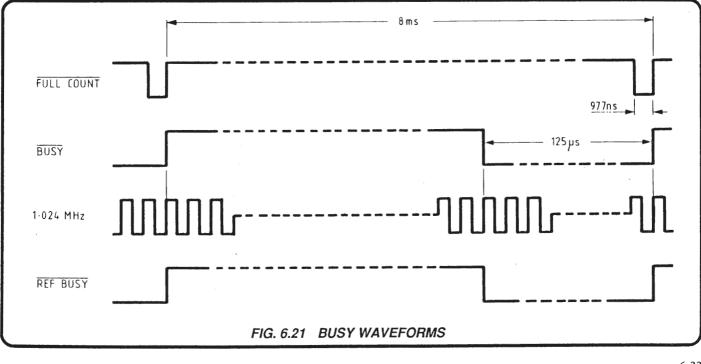
When the CPU has data to load into the input data latches, it first interrogates the comparator by enabling buffers M45 using the signal $\overline{\text{REV DIV RD}}$. The $\overline{\text{REF BUSY}}$ signal at Logic-1 (M45-3) indicates to the CPU that enough time is available to load the latches (at least 125µs remain before the LOAD pulse occurs).

If the REF BUSY signal is at Logic-Ø, the CPU waits until it returns to Logic-1 again.

When the REF BUSY signal is at Logic-1, the CPU loads the data by first carrying out four transfers of one byte each into the seven quad buffer latches M31 to M34, and M37 to M39. Each byte's destination is addressed by one of the chip-select signals REF.DIV.1 to REF.DIV.4, which enables the selected buffer latches. The data is latched by the WRT STRB signal.

Once the full 25-bit word has been latched into the buffers, it is available as a single word at the data inputs of the comparator latches M47, M48, M49, M51 and M52. The CPU again interrogates the comparator by $\overrightarrow{\text{REF DIV RD}}$, and five of the elements of M45 buffer the five most-significant data bits back to the CPU. If parity with the transmitted data is confirmed, the CPU takes no action. When the counter times out, the FULL COUNT signal is clocked through to M14-6 by $\overrightarrow{\text{SYNC 2}}$ as the LOAD signal, and the new data is transferred into the comparator latches.

If the data latched in the buffers is not as transmitted, the CPU initiates the FAIL 4 message procedure to the operator.



6.5.2.4 'Most Significant Bits' SYNC Logic (Circuit Diagram 430648 Page 11.3-2) (Refer to Fig. 6.22 for Waveforms)

This circuit, M14, M6, M7 and M8, provides the following signals: $\overline{SYNC 2}$, LOAD, $\overline{SET 1}$, $\overline{SET 2}$, $\overline{RST 1}$ and $\overline{RST 2}$.

SYNC 2 is obtained by NAND gating 1.024MHz and SYNC1 to give a synchronizing pulse at half the rate of SYNC1.

The LOAD pulse enables the 13-bit comparator registers, and is generated at M14-6 at the end of the counter's full-count output. FULL COUNT sets the D input M14-2 and the level is clocked, inverted, from M14-6 by the next two $\overline{SYNC2}$ pulses that occur.

The inverse of LOAD is used to time the pulse $\overline{SET 1}$ by NORgating at M7-4 with 1.024MHz. The M7-4 pulse is NAND-gated with SYNC1 to provide $\overline{SET 1}$ from M8-1. The pulse $\overline{SET 2}$, which occurs 977ns before $\overline{SET 1}$, is obtained by gating the signal FULL COUNT with 1.024MHz at NOR M7-10 and then NAND-gating at M8-10 with SYNC1.

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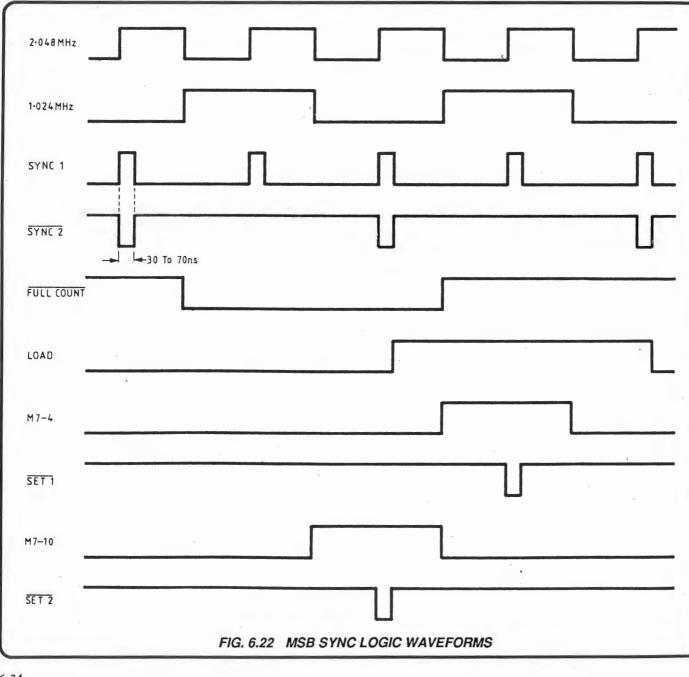
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Reset pulse generation (see Fig. 6.23) is initiated by a Logic-1 level at TP12. This can occur at any one of the 8192 binary counts of the 13-bit counter, its actual time slot depending on the binary count at which the coincidence occurs.

The coincidence level at TP12 is NAND gated at M6-8; M6-10 being at Logic-1 for all binary counts except 8191. The Logic- \emptyset at M6-8 is NOR-gated at M7-1 with 1.024 MHz, this is then used to select the next SYNC1 pulse via NAND M8-4 to provide the pulse $\overline{\text{RST 1}}$.



The coincidence level at TP12 is used to set the D input at flip-flop M14-12. This level is clocked to NAND M6-5 by the next $\overline{SYNC2}$ pulse. NAND input M6-4 is at Logic-1 except when LOAD is active, thus M14-9 output is inverted at M6-6 to be NOR-gated with 1.024MHz at M7-13. This is then used to select the next SYNC1 pulse via NAND M8-10 to provide the pulse $\overline{RST2}$.

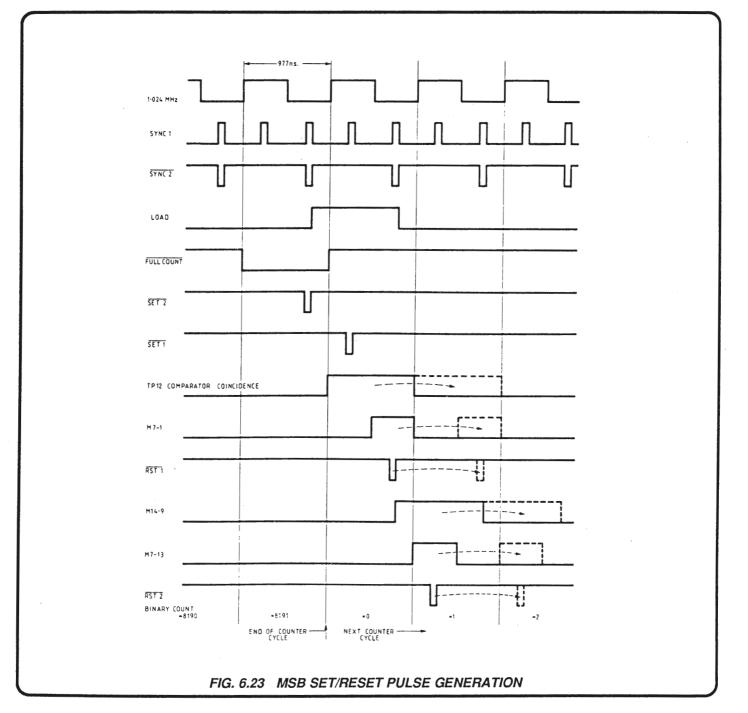
The pulse-timing example given in *Fig.6.23* shows the generation of $\overrightarrow{\text{RST 1}}$ and $\overrightarrow{\text{RST 2}}$ when coincidence occurs in the comparator at binary count = 0 (waveforms in continuous lines).

Coincidence occuring at binary count 1 causes $\overline{RST1}$ and $\overline{RST2}$ to increment in time by 977ns with respect to the $\overline{SET1}$ and $\overline{SET2}$ pulses (waveforms in broken lines).

RST 1 and RST 2 are generated with the same relationship in time to the comparator coincidence when the latter occurs in any binary count time slot from 0 to 8190 (inclusive).

Note that as the comparator word increments in value, $\overline{\text{RST 1}}$ and $\overline{\text{RST 2}}$ increment in time after $\overline{\text{SET 1}}$ and $\overline{\text{SET 2}}$, which remain stationary with respect to $\overline{\text{FULL COUNT}}$ and LOAD.

RST 1 and RST 2 are inhibited when coincidence occurs at binary count 8191 to allow for the re-loading of the input registers at the end of the counter cycle. The inhibit is performed by the level of FULL COUNT going to Logic-Ø and NAND M6-10, preventing RST 1 being generated; and by flip-flop M14-5 output going to Logic-Ø for the period of the load pulse, inhibiting $\overline{RST 2}$.



6.5.2.5 12-Bit Comparator Action (Circuit Diagram 430648 Page 11.3-1)

This functions in an identical manner to the 13-bit comparator previously described. Twelve exclusive-OR gates, M19, M20 and M21, receive the 12-bit binary output from the common counter and compare these bits with the data in the data registers.

The least-significant bit changes at a rate of 256kHz, and the mostsignificant bit at 125Hz. Coincidence occurring in any of the 4096 binary-count time slots available in the comparator cycle is shown as a Logic-Ø at TP5 for a period of 1954ns.

6.5.2.6 'Least Significant Bits' SYNC Logic (Refer to Fig. 6.24 for Waveforms)

The timing of $\overline{SET 3}$ is controlled by the $\overline{FULL COUNT}$ pulse from the 13-bit counter. The inverted $\overline{FULL COUNT}$ at M43-6 is gated with the inverted $\overline{SYNC 2}$ from M43-11 to give, at M46-1, $\overline{SET 3}$.

The comparator coincidence logic level is inverted to Logic- \emptyset at M12-1; M12-2 being at Logic- \emptyset except when FULL COUNT is low. The waveform at M12-1 lasts for 1954ns and therefore allows two consecutive SYNC 2 pulses to be gated to M46-4 (RST 3).

This condition exists for all $\overrightarrow{\text{RST 3}}$ timings except at the binary count of 4095; in this instance, the FULL COUNT pulse occurs after the gating of the first $\overrightarrow{\text{SYNC 2}}$ pulse, sets M12-2 to Logic-1 and so prevents the second pulse appearing at $\overrightarrow{\text{RST 3}}$. In practice, the second pulse of $\overrightarrow{\text{RST 3}}$ has no operational significance.

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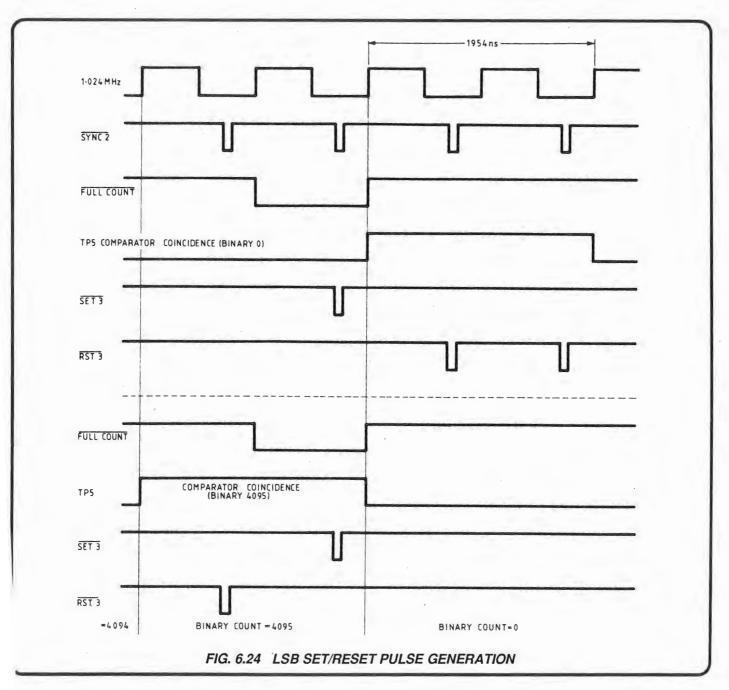
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6.5.3 REFERENCES and REFERENCE DIVIDER (Circuit Diagrams 430652 Section 11.4) (Refer also to Fig. 6.19)

The set and reset pulses from the precision divider comparators control the timing of JFET switches, which in turn chop the Master Reference voltages.

The chopped references are filtered to generate two voltages whose levels are proportional to the MSB and LSB squarewaves' mark:period ratio (duty cycle). These MSB and LSB voltages are conditioned, and transferred to the AC Assembly by full 4-wire sensed connection where they are summed at a star-point to generate a Working Reference: 'REF+Ve'. The output voltage increments at high resolution (0.03ppm: approx. 0.6μ V), with a maximum possible range of adjustment of 0-20V.

6.5.4 MASTER REFERENCE (Circuit Diagram 430452 page 11.4-7) (Refer also to Fig. 6.25)

The Master Reference determines the fundamental long and shortterm stability of the whole calibrator. It is a separate pcb mounted on the Reference Divider assembly. (Refer to the Layout Drawing facing *Page 11.4-7*)

The basic ciruit shown in Fig. 6.25 acts as a constant-current generator for a zener reference.

The random character of zener drift in the short-to-medium term may in the long term be regarded as averaging to zero. The averaging action of the eight zener diodes (shown on *Page 11.4-7*) reduces the short and medium term variations (due to drift and noise) by a factor of $\sqrt{8}$, which is effectively three times as stable as a single zener diode.

The diodes and resistors are selected and matched for near-zero temperature coefficient; the overall instrument values are shown together with the stability and accuracy specifications in Section 6 of the User's Handbook.

At manufacture, the zener operating current is adjusted for zero temperature coefficient, by selectively removing links TLA1-5 and TLB1-5.

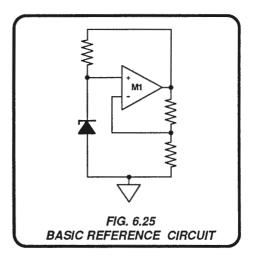
The zener voltage of +24.5V at TP3 and TP4, with respect to Common-R1, is reduced by R24/R25/R26 to +20.6V. This is an approximate value, but it has high temperature and time stability. Correction constants for the Absolute Reference voltage values are stored in non-volatile memory, and applied to affect the Mark/Period ratio of the JFET Reference Divider switching squarewave. During instrument recalibration, these constants are updated.

6.5.5 REFERENCE BUFFER-DIVIDER (Circuit Diagram 430652 Page 11.4-2)

R80 and R81 drop the 20.6V Master Reference voltage (V Ref) to +8.83V. M23/Q40 is a voltage-follower providing +8.83V with respect to Common-4 at the star-point TP11 to supply the Least-Significant Digit switch.

The high resolution associated with the full 13-bit count and a 20V reference is advantageous for DC outputs. Such resolution, however, is not strictly necessary for the accuracies associated with AC outputs; and also the 1V Range is the basic AC range, all other ranges employing either attenuation or amplification.

For AC outputs, therefore, the working reference is reduced to a range from 0.126V to 2.79V by software. This results in a reduction of the maximum mark:period ratio of the chopping waveform to about 0.14.



M2 buffers the +20.6V for transmission, at the same value, to the 'Most Significant' Switch in the Reference Divider. Delivery is by sensed connection, the Reference Common-R1 being connected to the Reference Divider Common-4 by a low- resistance wire link from pin A.

6.5.4.1 Buffer M2 - Temperature Compensation (Circuit Diagram 430452 Page 11.4-7)

At manufacture, the temperature compensation applied to M2 is adjusted by R29 (SET TC SLOPE). This adjustment requires specialized test equipment and should not be attempted by users. If a fault is suspected on the Reference PCB Assembly (400452), contact your Datron Service Center.

6.5.6.1 Switch Driver

 $\overline{\text{SET 3}}$ and $\overline{\text{RST 3}}$ pulses from the LSB Comparator in the Analog Interface Assembly are transferred into guard via pulse transformers T1 and T2, whose centre-tapped secondaries are balanced about Common-4 0V (T1) and +9V (T2).

Q5-Q8 form a fast bistable using emitter-coupled logic, to switch TP1 between +9V (mark) and +20V (space). During the "Mark" time after SET 3 pulse, Q29 and Q30 are switched ON, connecting LKA to +9V Ref. Q1-Q4 have the same bistable action as Q5-Q8, switching Q31 off during the "Mark" period by -11V at TP2, thus disconnecting LKA from Common-4 (0V). During the "Space" time after RST 3 pulse, Q29 and Q30 disconnect LKA from +9V Ref, and Q1-Q4 switch Q31 on, connecting LKA to Common-4 (0V). Fig.6.26 demonstrates this action.

6.5.6.2 JFET Switch and 3-Pole Filter

The combined action of the switch FETs alternately provides charging current for the 3-pole filter (during "mark") and discharging current (during 'space').

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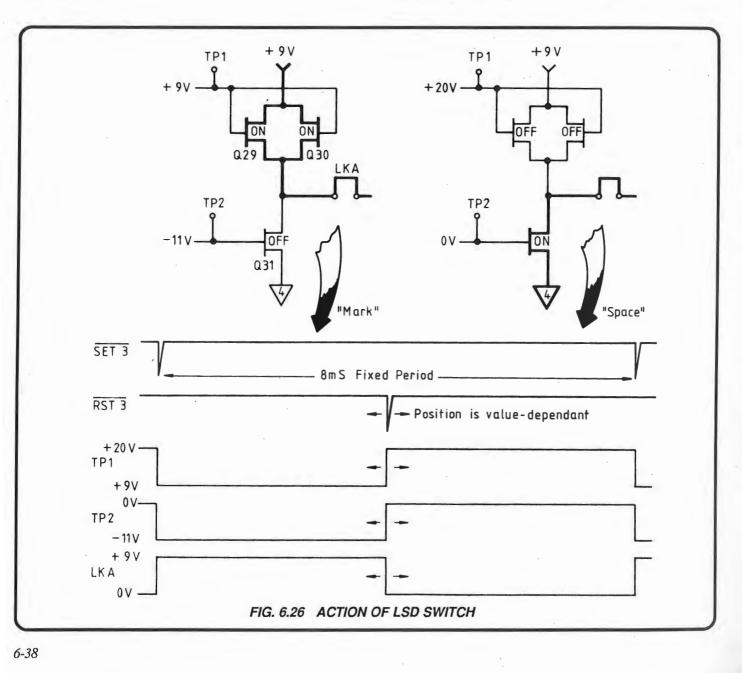
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Two JFETs in parallel (Q29 and Q30) are necessary to equalize the charging and discharging time-constants by matching the "ON" resistances. This preserves linearity of the filter output voltage over the full range of mark/period ratios applied via the set and reset pulses.

The 3-pole filter has the advantage of not being in series with the DC output signal. The 125Hz ripple content is reduced to a level which is acceptable within the overall instrument specification. The filter output is buffered by voltage-follower M16.



6.5.6.3 Offset Bias Amplifier

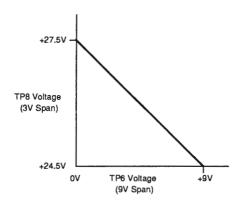
M20 performs a dual role:

- a. Its gain is set to 1/3 by R65/R64
- **b.** Its output is level-shifted to provide an offset bias for summing (this allows the summed output to have a negative zero offset).

Also a small thermal coefficient zero correction is factory-preset (D10/R85).

M20 transfer function is approximately as shown.

The actual values are as set digitally in software, affecting the mark:period ratio of the J-FET switches, using stored calibration constants.



6.5.7 MOST-SIGNIFICANT-DIGITS SWITCHING (Circuit Diagram No. 430652 Page 11.4-1)

The large reference voltage (20.6V) and the need for higher resolution makes the MSB Switching circuitry more complex than for LSB; but the principle is the same: the set and reset pulse-timing adjusts the mark:period ratio of the square wave fed to the filter.

The arrangement used for the MSB switching satisfies two essential requirements:

- a. The charge and discharge path resistances for the 7-pole filter must be closely matched.
- b. The leakage current of the path switched off must be minimal.

Requirement (a) demands that the matched devices used in both paths are of the same type (P-channel JFETs have approximately 10 times the "on" resistance of N-channel types). But without the voltage standoff and leakage current shunt created by the guard switch, the pinch-off gate voltage for one of the paths would be high enough to generate gate-leakage current in excess of requirement (b).

A description of the Main and Guard Switch action is given overleaf.

5.8 MAIN and GUARD SWITCHES (Fig. 6.27) (Circuit Diagram 430652 Page 11.4-1)

he Mark to Space (RESET) transfer is symmetrical c-b-a.

efer to Fig. 6.27, in which only the Space to Mark (SET) state ansfer a-b-c is shown.

The switch driver flip-flops establish the voltage shown at TP3, 4 and 5 as controlled by the set and reset pulses. The drivers are ECL fast bistables, but note that Q19 and Q20 are included in the main switch driver as a level-shifter for Q32/Q35.

+20 6V +20.6V +31 6V Vref -11V +20.6V -11V +20.6V +20 6V 9TP5 20.6V TP39 (b) (c) (a) R/25 5 036 OF D20 103 0V .6V 033 10V 10V 10V 03 OV To 7-pole 4 14 filter 20.6V 20 6V DIG 03 32 R126 3 6 TP4 -11V 0٧ -11V SET 2 SET 1 0 V TP4 -11V + 31 6V TP5 +206V + 20 6V TP 3 -11V LK8 Switch Output 0.5*µ* s 0 V (b) Filter charging through (c) Filter charging through (a) Filter discharging through Q 34 and Q 37 Q33 and Q36 only Q 33, Q 36, Q 32 and Q 35

FIG. 6.27 ACTION OF MAIN AND GUARD SWITCHES (MSD)

5.8.1 Switch Timing (Fig. 6:27)

T 1 pulse is delayed by 0.5 μ s after SET 2 pulse, and RST 2 is ayed by 0.5 μ s after RST 1.

 $\overline{T 2}$ and $\overline{RST 2}$ pulses control the timing of Q36, Q33, Q34 and 7 in the main switch (TP4 and TP5).

SET 1 and RST 1 pulses turn Q35 and Q32 on and off (TP3). Because of the 0.5μ s delays, Q35 and Q32 conduct only during the time that Q36 and Q33 are also conducting.

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6.5.8.2 Filter Discharge Path

In Fig. 6.27(a) the switches are in "space" state:

- Q37 and Q34 are turned on by TP4 at 0V, to provide the filter discharge path.
- Q33 and Q36 are turned off by TP5 at +31.6V,

Q32 and Q35 are turned off by TP3 at -11V.

The filter discharges via resistor R79 and FETs Q34 and Q37. During both Mark and Space periods, R79 (78.7kOhms) is a major determinant of the 7-pole filter charge and discharge currents. Because in 'space' state the 'On' resistances of Q34 and Q37 (3Ω - 5Ω each) are very small in comparison, the potential at link B can be regarded as zero when considering the effects of the other switching voltages.

Reverse leakage currents in JFET junctions are normally of the order of a few picoamps unless the junction voltages are much in excess of 20V. To control leakage effects from the four JFETs which are turned off, the cathode of diode D20 is connected to the common junction of the four devices. Its anode is returned to the junction of R125 and R126, close to $\pm 10V$.

The reverse leakage characteristics for a J108 FET (Q35 and Q32) are generally several times heavier than for a J174 (Q36 and Q33). This means that in this switch, the leakage currents via Q35 and Q32 out of the common junction are 4-5 times greater than those entering via Q36 and Q33.

The net leakage out of the junction holds D20 slightly in forward bias, so that its cathode cannot rise above about +10.3V, when the four FETs are turned off in 'space' state. Thus D20 guards the 'buffer' FETs Q33 and Q32 from the effects of the relatively high voltage on Q36 gate. The effects of the buffer FETs' own leakages on the voltage at the filter input can be regarded as negligible, because Q33 leakage currents towards LKB are virtually balanced by those away via Q32.

6.5.8.3 Filter Charge Path

To preserve linearity over the full range of Mark:Period ratios, the filter charging path time constant must closely match that of the discharge path. Q35 and Q32 are factory-selected to form a matched set with Q34 and Q37, all J108 N-channel FETs (the 'on' resistance of P-channel FETs in a true complementary switch would be much higher, of the order of 30Ω - 40Ω). Nevertheless, to avoid high voltages being developed across Q35/Q32 when changing between states (causing excessive leakage), P-channel FETs are employed. Q36/Q33 are switched on before (and switched off after) Q35/Q32.

Fig. 6.27(b) shows this intermediate state after $\overline{\text{SET } 2}$ and before $\overline{\text{SET } 1}$, and *Fig. 6.27(c)* illustrates the fully-conducting state after $\overline{\text{SET } 1}$. Note that for descriptive purposes, the second step on LKB waveform is heavily exaggerated, and is not readily viewed on an oscilloscope. The slightly longer charging time-constant during this half micro-second, due to the higher resistance of Q36/Q33, is not sufficient to disturb the linearity of the filter in excess of specification.

The voltage between TP4 and LKB during 'mark' state is some 31 volts. In the absence of D19, an adverse voltage distribution could cause excessive reverse leakage in Q37. D19 controls the distribution by limiting the voltage at its cathode to about +10V, constraining Q37 source-gate voltage to a tolerable 20.5V.

6.5.9 7-POLE FILTER (Circuit Diagram 430652 Page 11.4-1)

M26, M28, M32, Q41 and Q42, together with associated capacitors and resistors, form a 7-pole Bessel filter in three active elements; providing approximately 135dB of attenuation at the 125Hz switching frequency and increasing at a rate of 140dB/decade. This allows sufficient bandwidth to avoid excessive settling time while reducing the output ripple to within instrument specification. Q41 and Q42 source-followers provide input bias currents for M26 and M28 from the 15V supplies, and buffer the line from bias-current effects. M32 bias-current effects are insignificant.

The '+Ve SUMMING AMP' filter output DC voltage (TP13), is fed to a buffer amplifier for subsequent summing with the output from the Least-Significant Switch offset-bias amplifier. R101 and C51 prevent any spike remnants from the chopper-stabilized buffer amplifier being fed back into the filter.

6.5.10 SUMMING AMPLIFIER

(Circuit Diagram 430652 Page 11.4-3)

6.5.10.1 '+VE SUMMING AMP' Buffer

M33, M34 and Q44 buffer the '+Ve SUMMING AMP' voltage output from the 7-pole filter (this is proportional to the Mark/Period ratio of the 13 most-significant bits of the binary word which defines the instrument output value demand).

M33 is a high-gain, chopper-stabilized integrator with a bandwidth of approximately 10Hz, and Q44 provides additional bandwidth for rejection of HF common-mode noise.

M35, D14, D15, Q48 and Q49 generate boot-strapped supplies to preserve full dynamic-range linearity. Q46 and Q47 establish 3mA constant-current drives for D14 and D15.

The whole amplifier acts as a voltage-follower, M34/Q45 providing the output drive, buffering the output of M33 and Q44. The output 'Hi O/P' is delivered to the DC assembly via RL2 for positive DC outputs, or via RL1 if the output is to be negative. For AC outputs, it is always delivered to the AC assembly via RL2 (RL1 being permanently de-energized for AC ranges). The output is sensed either in the DC or AC assembly to account for the volts-drops in the connecting circuit. The sense feedback voltage 'Hi SENSE' is applied to the inverting input of the whole buffer via R98.

For a zero count in the MSB comparator, the filter output voltage is approximately +3.2 mV, and a full count of 8191 would produce +20.6V. These are the voltages which are developed at the buffer output.

6.5.10.2 '-VE SUMMING AMP' Buffer

M38, M39 and Q51 buffer the '-Ve SUMMING AMP' voltage output from the Offset Bias Amplifier derived from the 3-pole filter (this is proportional to the Mark/Period ratio of the 12 leastsignificant bits of the binary word which defines the instrument output value demand).

The dynamic range of the filter output voltage was originally defined by the Reference Buffer (8.83V) for efficient operation of the FET switching circuitry.

It was scaled in the Offset Bias Amplifier to give +27.5V for an LSB comparator count of zero (from approx. +1.1mV at TP6), and +24.5V for a full count of 4095 (from +8.83V at TP6). It now needs to be scaled down so that it has correct proportionality to the '+Ve SUMMING AMP' dynamic range.

R99 and R100 attenuate the '-Ve SUMMING AMP' input voltage by a factor of 0.8545 x 10^{-3} . At zero count, +27.5V is reduced to +23.5mV, and at full count +24.5V reduces to +20.9mV. These are the extremes of voltage developed at the buffer output.

The whole amplifier acts as a voltage-follower, but without bootstrapped supplies (the small input voltage dynamic range of approx. 2.5mV does not warrant it). Otherwise the circuit is identical to the '+Ve SUMMING AMP'. M39/Q52 provide the output drive, buffering the output of M38 and Q51.

The output 'Lo O/P' is delivered to the DC assembly via RL2 for positive DC outputs, or via RL1 if the output is to be negative. For AC outputs, it is always delivered to the AC assembly via RL2 (RL1 being permanently de-energized for AC ranges).

The feedback voltage, sensed in the DC or AC assembly, is returned via the appropriate relay, and applied to the inverting input of the whole buffer via R127.

6.5.10.3 Summing

On the DC or AC assembly, the outputs from the two buffers are summed by defining the 'Lo O/P' level as 'Reference Common' (Common-1 for DC, Common-2C for AC), and the 'Hi O/P' level as 'REF+Ve'. Thus at any instant, the voltage developed as 'REF+Ve' with respect to 'Reference Common' will always be 'Hi O/P' minus 'Lo O/P', at their current values.

The reference voltages and reference division ciruitry are chosen to allow for software calibration adjustments, so the summing span overlaps the possible required span of 0V to 19.999999V at both extremes:

With an overall 25-bit count of zero in the comparators, REF+Ve is +3.2mV minus +23.5mV, a negative overlap of 20.3mV.

At overall full count, REF+Ve is +20.6V minus +20.9mV, approximately +20.58V.

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6.5.10.4 Bipolar Reference Switching

Relays RL1 and RL2 are used in DC ranges for polarity reversal. However, this is not necessary for AC operation, for which RL1 is un-energized, and RL2 is energized, outputs from the summing buffers being fed to the AC assembly via RL2.

6.5.10.5 DC and AC References

For DC operation, the summed DC reference is applied to the Error Amplifier directly (*refer to page 11.5-1*), but for AC operation, the DC reference is applied to a voltage divider which is used to provide a 'Quasi-sinewave' AC reference signal.

The generation of this signal is described in Section 6.6.

6.6 AC REFERENCE - THE QUASI-SINEWAVE

6.6.1 AC-to-AC SENSE/REF COMPARISON

In the Sense/Reference comparator, a considerable advantage is gained by comparing AC with AC. (If AC sense were compared with DC reference, small DC offsets would be magnified, leading to 'DC turnover' errors). The AC waveform used as reference is constructed in ten steps by a digitally controlled switching network, based on the DC reference as its peak value. It has been given the name 'Quasi-Sinewave''.

To drive the VCA, the comparator produces a DC error signal which is proportional to the difference in 'Mean Square' values, and is driven to zero by the action of the Output-Sense loop. At zero error the RMS value of the comparator's sense input has thus been adjusted by the loop to be equal to the RMS value of its reference input.

On the 1V Range there is neither amplification nor attenuation in the Output-Sense loop. The quasi-sinewave is designed so that with the 1V Range selected, its RMS value is equal to the voltage demanded on the front panel OUTPUT display, (with small, controlled adjustments for calibration).

On higher ranges, decades of amplification are switched in to set the output to the demanded voltage. Switched decades of attenuation reduce the sensed sinewave back to the 1V-Range level for comparison with the quasi-sinewave.

For millivolt ranges, the instrument output terminals are not within the output/sense loop. Instead, the AC 1V output from the 1V buffer is sensed internally and applied to the comparator to complete the loop. The AC 1V signal is reduced to the selected millivolt range levels at the terminals by precise, passive, decade attenuators.

On current ranges, the current reference is derived from either the closed 1V or 10V Range Output/Sense loop.

Therefore on all ranges the Output/Sense loop gain is driven to a magnitude of 1, so that the VCA and the comparator both operate at 1V Range levels.

6.6.2 DC REFERENCE - SCALING for AC

The Reference Divider hardware is common to both DC and AC outputs. On DC ranges, the basic voltage range is the 10V Range, with 100% overrange at Full Scale. In these cases the full span of reference values is employed, generating the resolution necessary to accommodate the DC accuracy available.

The same analog accuracy is not available for AC, so the high resolution is not necessary. Moreover, the linearity of the analog circuitry is improved by using a smaller dynamic range in the reference circuits. So for AC outputs the 1V Range is the basic range, and the software scales its demanded value accordingly.

The sensed output is compared against the quasi-sinewave, whose characteristics match those of the sensed sinewave. To construct the quasi-sinewave, the DC reference voltage needs to be set as its peak value.

The software imposes the scaling factors which establish the reference voltage at the peak value of the quasi-sinewave. Thus the full span of the 25-bit comparator, and hence the possible dynamic range of the DC reference, are realized only on DC ranges and at times when the Reference Divider itself is being calibrated.

Before initial calibration, the maximum obtainable reference voltage for AC is slightly greater than 2.8V, and the minimum is slightly less than 125mV. This overlaps the peak voltages of the quasisinewaves corresponding to the maximum and minimum values of sensed output; giving a margin for accurate calibration from digital gain factors held in the non-volatile calibration memory.

6.6.3 DC REFERENCE -VOLTAGE VALUES for AC

As mentioned earlier, the DC Reference is used to establish the amplitude of the quasi-sinewave. When the 1V AC Range is selected, the reference is set to the peak value of the quasi-sinewave, which is 1.397 times the demanded RMS (sinewave) voltage output of the instrument. In normal use, therefore, the reference voltage is adjusted by front panel OUTPUT display selections; between 125.7mV (for 0.9V selection) and 2.79V (for 1.999999V selection), plus or minus any user-calibration corrections.

On higher and lower AC ranges, analog range switching in the sense amplifiers scales the sense voltages for comparison with the same RMS voltage span of quasi-sinewaves.

6.6.4 REFERENCE INVERTER (Circuit Diagram 430663 page 11.7-2)

The quasi-sinewave is derived by a specific form of D-A converter, selecting voltages from a divider network. Because negative values are required, the divider is strung between positive and negative reference voltages. The unity-gain Reference Inverter generates the negative reference 'REF-Ve' by inverting 'REF+Ve'.

M1, M2 and Q1 perform the inversion. M2 generates the bandwidth necessary for amplitude switching operations, while chopperstabilized integrator M1 removes DC offsets, always referring the inverter output to Common-2C. To compensate for RMS value changes in the quasi-sinewave (due to switching errors arising from frequency changes), feedback from the quasi-sinewave is applied via R1, C4, R4 and C5. Q1 provides the output drive to the quasi-sinewave generator.

6.6.5 QUASI-SINEWAVE GENERATOR (Circuit Diagram 430663 page 11.7-3)

The SYNC \emptyset input to M11-15 RESET, if set to Logic-1, would disable the Quasi-sinewave sequence counter M11. The facility is not required in this application so J7-49 is unconnected on the Mother assembly (*page 11.16-2*). M11-15 is thus pulled down to logic- \emptyset by R40 to enable the quasi-sinewave for both AC Voltage and AC Current functions.

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The quasi-sinewave is generated at a frequency determined by the Frequency Synthesizer 100Hz-4kHz output (*para 8.1.3.3* describes the synthesis), clocking the decade counter M11 via J7-50. This continuously recycles M11 in ascending count through Q_{\emptyset} to Q_9 , ten clocks constituting one cycle of the quasi-sinewave, so the quasi-sinewave runs at a frequency of between 10Hz and 400Hz. The carry C_{out} of M11 returns to the Synthesizer via J7-51 to be selected as the reference frequency for the 100Hz (10-330Hz) frequency range.

With increase of frequency range, the difference between the frequencies of output and quasi-sinewave increases in decade steps. As the comparison of sense and quasi-sinewave signals is performed at mean-square DC levels, this difference theoretically does not matter, so long as the signal is at an exact multiple of the quasi-sinewave frequency. However, to achieve optimum operation of the Sense/Reference comparator, each zero crossing of the quasi-sinewave is synchronized to coincide with a sense-signal zero crossing.

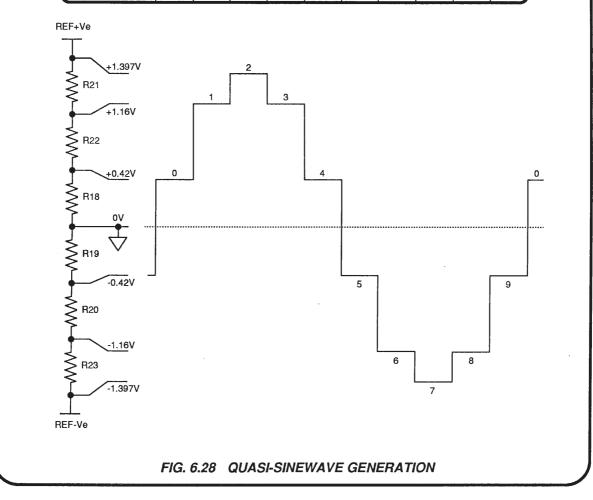
Synchronization is achieved by the clock input to M9, which controls the timing of the quasi-sinewave switches M8 and M14. Using the same clocks, M11 and M10 transit times prevent the data from arriving at M9 'D' inputs until the data already established there by the previous clock pulse has been latched at its outputs. Thus data ripples through M11 and M9 at successive clock pulses.

The ripple delays the data by one clock period and would, if left uncorrected, put the switching out of sequence. The arrangement of the connections between M11 outputs and M9 data inputs, combines appropriate outputs so as to correct the switching pattern. The table in *Fig. 6.28* demonstrates the rotation of 1 clock period; the quasi-sinewave steps being labelled at M9 inputs and outputs.

The quasi-sinewave is output to the transfer switching input to the Sig/Ref comparator at M16-1. The action of the transfer switch is described in Section 9.5.

A second output is filtered and fed back as compensation to the Reference Invertor as described earlier (*para 6.6.4*).

Step	0	1	2	3	4	5	6	7	8	9
M11 Output at Logic-1:	Q9	Qø	Q1	Q ₂	Q ₃	Q4	Q ₅	Q ₆	Q7	Q8
M10 Output pin at Logic-1:	4	11	-	11	4	10	3	-	3	10
M9 Output pin at Logic-1:	O ₁	O4	0 ₅	O4	O1	O ₂	Oø	O ₃	Oø	0 ₂
Switch Energized M8 pin: M14 pin:	5	6	13 -	6	5	- 5	- 6	- 13	- 6	- 5
Step Voltage fed to M16-1:	+0.42	+1.16	+1.397	+1.16	+0.42	-0.42	-1.16	-1.397	-1.16	-0.42



6.7 POWER SUPPLIES

The circuits described in this section perform the following functions:

- Line power switching, fusing, filtering, voltage selection and transformation.
- Main digital supply generation and distribution (Outquard).
- Display high voltage supply generation.
- In-guard stabilized supply generation for Common-2 and Common-4 circuitry.
- A simplified power-distribution block diagram appears at Fig. 6.29.

The power input module is mounted on the rear panel. The mains (line) transformer is located in the rear section of the instrument, close to the In-guard and Out-guard Power Supply assemblies.

(For details of location and attachment, refer to Section 3; and Section 11, page 11.0-1).

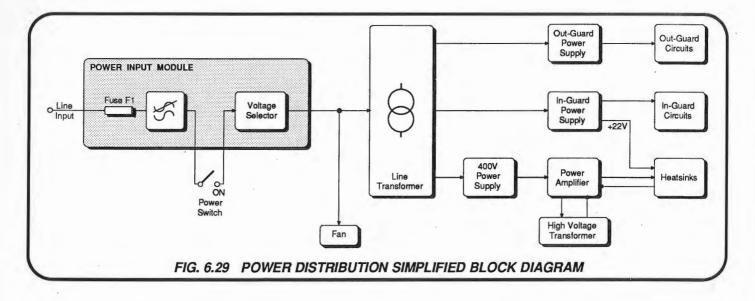
6.7.1 LINE POWER DISTRIBUTION (Fig.6.29) (Circuit Diagram 430439 Page 11.17-2)

The single phase line supply enters via a 3-pole input cable at the rear of the instrument. The cable connector plugs into a power input module which contains a fuse, filter and line voltage selector pcb. (For details of fuse values and operating voltage selection refer to the *User's handbook, Section 2*).

Both 'line' and 'neutral' rails are filtered by a low-pass LC network before being fed through the instrument to the two-pole 'Power' switch on the front panel.

The switched supply is fed back into the power input module, to the voltage selector pcb, which configures the line transformer primary circuit as determined by the user. Power for the air circulation fan is provided directly from the power input module.

All line transformer secondaries are electrostatically decoupled from the primaries by a ground screen between the windings. The secondaries which supply the Common-2 and Common-4 in-guard circuits are decoupled by an additional screen which is connected to the instrument guard.



6.7.2 OUT-GUARD POWER SUPPLIES (Circuit Diagram 430561 Page 11.10-1)

6.7.2.1 Digital Main Supply

This circuit provides:

- +8V unregulated supply for the Front and Digital assemblies.
- +5V regulated supply for out-guard digital circuits.

6.7.2.2 +8V Unregulated Supply

This is taken directly from full-wave rectifier D1, D2 via fuse F1 (rated at 4A).

6.7.2.3 +5V Regulated Supply

The output voltage is controlled by series regulator Q5, Q6. Load current is sensed by R1 in the base-emitter circuit of Q1, which increases the conduction of Q5 and Q6 parallel combination for increases of load current. The 2.45V zener D4 provides the reference voltage for comparator M1 at M1-3. The output voltage is sensed between the +5V and DIG COMMON rails on the Mother assembly, and divided down to reference potential at M1-2. R8 and R9 ensure that regulation persists even if the sense links are disconnected.

M1 output drives Q2 whose collector voltage controls Q5 and Q6 conduction. If the +5V rail voltage falls due to loading, Q2 collector voltage rises, increasing Q5 and Q6 conduction to restore the rail voltage. Zener D5 prevents the positive excursion of the +5V rail in the event of regulation breakdown. Zener D3 restricts positive excursions of Q2 base voltage, and hence the drive to Q5 and Q6, to provide current limiting. C9 and C10 give a controlled fast response to reduce the effects of transients on the +5V rail.

PTC thermistor R7 protects the power supply from high groundleakage currents, notably in the external circuits of the IEEE 488 bus system. R7 presents a minimum of 80Ω between the digital common line and ground; this resistance increasing with increasing ground-leakage current.

A supplementary +5V supply is fed out to the Front assembly from J4-21. This is available to power the LEDs in the front panel keys, but is not used in this instrument, as a regulator on the Front assembly produces the required +5V supply from the unregulated +8V supply (para 6.7.2.2).

6.7.2.4 180V Display Supply

180 Volts are required to operate the digital plasma displays on the Front assembly. Because the display anode drivers are powered from the Digital Main Supply +5V rail, the 180V positive pole is referred to this rail in the power supply. The negative pole is therefore at a potential of -175V. Refer to Section 6.3 for further details.

Series regulation is provided by D6, R16 and Q3; and shunt regulation by D7 and Q4.

6.7.2.5 Common Mode Null

This circuit provides a line-hum cancelling (bucking) output to the instrument guard network. For adjustments refer to Section 4.9.

6.7.3 IN-GUARD POWER SUPPLIES (Circuit Diagram 430554 Pages 11.11-1/2)

6.7.3.1 In-Guard Common-2 Supplies

The general 15V supply for the analog circuitry is provided by three integrated-circuit regulators (*page 11.11-1*) as follows:

+15V from M2.

Because of the high current taken from this supply, the regulator power dissipation is shared. The rectifier output is first regulated to +18.5V by Q1, Q3 and D9; and then to +15V by M2.

- -15V from M1. This is a mirror image of the positive supply.
- -10V from M6, derived from the -15V supply.

The supply is protected by 3.15A fuses F3 and F4 at the bridge rectifier output. Chokes L4 and L5 attenuate HF transients on the AC input.

The 8V supply for the Sine-Source assembly is provided by two integrated-circuit regulators M8 and M9 (*page 11.11-2*). The supply is protected by 1A fuses F5 and F6 at the bridge rectifier output. Chokes L7 and L9 attenuate HF transients on the AC input.

6.7.3.2 ±22V PS/I Heatsink Supply

This provides +22V and -22V unregulated power outputs to the PS/I Heatsink assembly. Both supplies are protected at 4A by fuses F1 and F2, the AC input being HF-filtered by chokes L2 and L3. The 22V common return is maintained close to the common-2 return potential by resistor R1.

6.7.3.3 Reference Divider Common-4 Supplies (Circuit Diagram 430554 Pages 11.11-2)

This circuit provides +36V, +15V and -15V regulated outputs to the Reference Divider in-guard circuits. The +36V supply is also used to power the +20V Master DC Reference.

Two secondary windings of the line transformer are used, and intersupply transients are reduced by the special coupling arrangements of common-mode choke L10. The rectified output from bridge W4 is series-regulated by M3 to produce the +36V supply. R2/R3 sense the output voltage.

D11 and M4 reduce the +36V to generate the +15V regulated supply.

The -15V supply is provided by bridge W3 and regulator M7.

6.7.3.4 38V Common-2 Supply (Circuit Diagrams 430544 Page 11.12-1 and 430604 Page 11.16-5)

The 38V regulated supply is used for two purposes:

- to power the 10V Amplifier in the Power Amplifier assembly;
- to provide a lower positive source voltage to reduce dissipation on the Power Amplifier assembly, when negative voltages are being output on the 100V DC Range (refer to sub-section 7.8.3.4).

It is plugged into the Mother assembly in the rear compartment next to the Heatsinks.

The mains (line) transformer 40VRMS secondary centre tap is referred to Common-2 on the Mother assembly. It provides a variable AC output by R25 on the Mother assembly to balance line-induced voltages on the guard screens. The 40V is rectified, filtered and smoothed on the Mother assembly before being passed to the regulator at approx. 50VDC.

On the 38V Power Supply assembly the output voltage is controlled by series regulators Q2 and Q1. As the regulator is symmetrical, only the positive side is described.

The output voltage is divided by R26 and R25 to provide a sense signal for comparator M1, which is powered by a local shunt regulator D8/R16/C8. The 2.45V reference for the comparator is derived by D6/R23 from the comparator supply.

M1 output drives Q8 whose collector voltage controls Q6 and hence Q2 conduction. If the +38V rail voltage falls due to loading, Q8 collector voltage rises, increasing Q5 and Q6 conduction to restore the rail voltage.

Load current is sensed by R24 in the base-emitter circuit of Q5, which is normally cut off unless the load current exceeds 170mA. At this point Q5 conducts and pulls down the base of Q6, setting a hard current limit.

Zener diode D2 turns Q5 hard on in the event of an output short circuit, providing a rapid reponse to catastrophic failure in the power amplifier circuitry. As the output voltage falls below +22V, D2 arrests the fall on Q5 base, switching Q5 hard on and turning Q6 and Q2 off. This leaves D2, R8 and R9 controlling the output current, which falls to less than $500\mu A$.

When the load is removed, the conduction of Q5 via R26/R25 is insufficient to hold Q6 cut off, especially as Q8 is also cut off by the comparator. So Q2 is allowed to conduct, the output voltage rises until first D2, and then Q5, cut off and the output voltage is restored to comparator control.

The 38V output is taken through wired-in fuses F1 and F2. These merely protect the PCB tracking in the event of an output shortcircuit. The output voltages are protected from reverse polarity by D1 and D2 on the Mother assembly.

6.7.3.5 38V Supply Failure

(Circuit Diagram 430618 Page 11.9-4)

The 38V output voltage is monitored in the Power Amplifier assembly. The monitor is described in *Section 7*, para 7.8.6.3.

6.7.3.6 400V Common-2 Supply

This is described in Section 7, paras 7.8.5 and 7.8.6.4.

SECTION 7 DC VOLTAGE OUTPUTS - AMPLITUDE CONTROL SYSTEM

7.1 INTRODUCTION

7.1.1 GENERAL PROCESS

When DC Voltage Function is selected, a relay (RL2) on the Reference Divider assembly feeds the output of the summing amplifier into the DC assembly as DC Ref (Hi and Lo), the value of which represents the demanded output voltage and polarity.

7.1.2 DC VOLTAGE SYSTEM BLOCK DIAGRAM

The DC Voltage Amplitude Control System is briefly described in Section 5, and illustrated in the Block diagram of Fig. 5.3.

7.1.3 CIRCUIT OPERATION

The circuits described in this section perform the following functions:

- Buffer the DC Ref voltage (-20V to +20V) and provide output voltages to the instrument terminals, on the 10V DC Range.
- Amplify the DC Ref voltage providing output voltages:

-200V to +200V on 100V Range -1100V to +1100V on 1000V Range

- Attenuate the DC Ref voltage and provide output voltages between -2V and +2V on the 1V DC Range.
- Further attenuate the 1V Range voltages and provide output voltages:

-200mV	to	+200mV	on	100mV Range
-20mV	to	+20mV	on	10mV Range
-2mV	to	+2mV	on	1mV Range
-200µV	to	+200µV	on	100µV Range.

- On the 10V Range, sense the output voltage (at the load in Remote Sense), making continuous, direct comparisons in a closed negative-feedback loop with the DC Ref voltage input from the Precision Divider. The comparison generates an 'error' voltage which corrects the output voltage.
- On the 1V Range, sense the output voltage at 1V Range levels, comparing the sensed voltage with the attenuated DC Ref input, and correcting the output as on the 10V Range.
- On the sub-volt ranges; sense the 1V Buffer output at 1V Range levels, correcting its output as on the 1V Range.
- On the 100V Range, sense the output voltage at 100V levels, and reduce the sensed voltage to 10V levels. Compare the attenuated voltage with the DC Ref input from the Reference Divider and correct the output voltage as on the 10V Range.

The DC Voltage circuitry selects the required range, from switching data transmitted into guard via the Serial Data Link. The appropriate range circuit generates the demanded voltage at the output terminals. Output switching and protection are provided.

DC Voltage Ranges up to 100V are described in Section 5.6, and the DC 1000V Range in Section 5.8.1; at block diagram level.

- On the 1000V Range, provide a VCA drive from the Error Amplifier, to a DC Modulator for the high voltage amplification circuits. Attenuate the sensed output voltage, comparing the attenuated voltage with the DC Ref input at 10V Range levels, and correcting the output as on the 10V Range.
- Provide switching of DC Voltage Output, Range, Guard and Sense, under the control of signals from the Analog Control Interface.
- Sense excess currents in the output circuit, providing a LIM ST status signal to the CPU via the Analog Control Interface.
- Sense High Voltage State (at approx. >130V) on the PHI (I+) output line, providing a HV ST signal to the CPU via the Analog Control Interface.

Many of the circuits described in this section are located on the DC PCB assembly. The major exceptions are as follows:

10V Range Buffer stage	-	Power Amplifier assembly,
100V Amplifier	-	Power Amplifier assembly and
		Heatsink assemblies,
1000V Range output circuits	-	LF and HF transformer
		assemblies and the High Voltage
		assembly,
Function Switching	-	Current/Ohms assembly,
Output Filtering	-	Terminal Board assembly.

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7.2 LOW VOLTAGE LOOPS (Fig. 7.1)

Although the 10V range is regarded as the basic DC range of the instrument, this is because the full 20V Reference is used, and suffers no overall voltage attenuation nor amplification in its output loop. However, it does require power amplification at dissipations which preclude its positioning within the thermal shield, so its output buffer is located on the Power Amplifier assembly. This factor complicates the routing of its signals.

The 1V range loop is more direct; its buffer is located on the DC assembly, and there are fewer circuit elements to describe in its path. For reasons of simplicity, therefore, the 1V range is chosen for this description of the basic DC output loop.

The descriptions in Section 7.2.1 and Section 7.3 concentrate on the signal path of the 1V Range loop; from the polarity switch in the Precision Divider, out to the 'Power' terminals, and back to the 'Sense' input of the Error Amplifier.

For descriptions of the alterations to the 1V loop to accommodate the other DC voltage ranges, refer to the following sub-sections:

100mV Range	7.4
100µV to 10mV Ranges	75
10V Range	7.6
100V Range	7.8
1kV Range	7.9

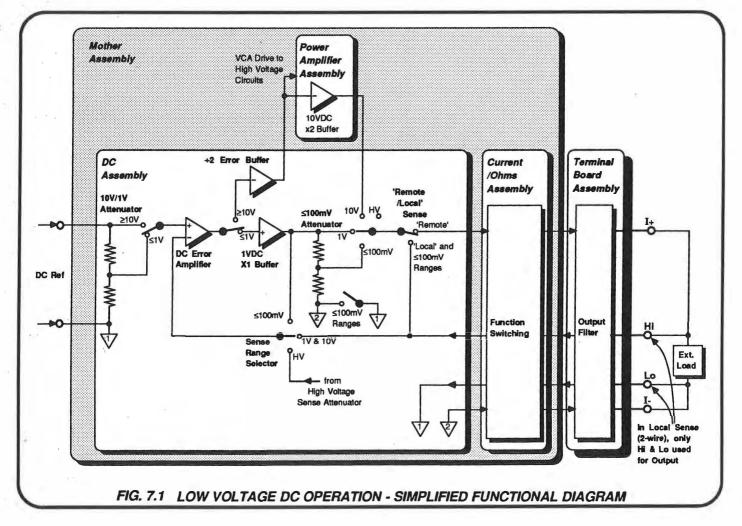
On the circuit diagrams in Section 11, all relay contacts are shown with their relays in the unactivated condition.

7.2.1 1V RANGE SUMMARY

The low voltage loop and routing are illustrated in the simplified diagram of Fig. 7.1. Switching contacts are shown in positions set for the 1V Range.

DC Ref is variable between -20V and +20V referred to common-1, and the 1V attenuator provides voltages between -2V and +2V. The Error Amplifier and 1V Buffer are connected to form a voltagefollower when I+ is connected to Hi (in either local or remote sense).

The output from the 1V Buffer is connected directly to the I+ terminal via power switching, the sense feedback returning from the Hi terminal, via sense switching, to the Error Amplifier inverting input. The sensed output voltage is adjusted by the feedback until it equals the attenuated DC Ref Value, i.e. for zero differential input to the Error Amplifier.



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7.3 DC 1V LOOP

7.3.1 **REFERENCE DIVIDER ASSEMBLY** (Circuit diagram 430652 *Page 11.4-3*)

For positive outputs, the positive DC Reference PHI(REF), PLO(REF), SHI(REF) and SLO(REF) pass via energized relay RL2, to be output as a 4-wire sensed connection into the DC assembly. The four lines are routed out at J4 pins 9, 10, 11 and 12 into the Mother assembly. For negative outputs, energized relay RL1 configures the lines to give a negative DC reference.

7.3.2 DC ASSEMBLY (Circuit diagram 430536 Page 11.5-1)

The DC Reference enters at J5 pins 1, 2, 3 and 4. On DC Voltage ranges, RL18 connects the power and sense lines to the two starpoints TP2 and TP3. TP3 is the signal Common-1 point, to which all instrument DC voltage sense inputs are referred.

For the 1V and lower ranges, RL16-5/4 connects the output of the 1V attenuator to the non-inverting input of the Error Amplifier. (On the 10V and higher ranges, RL16-8/9 connects the full DC Reference to the Error Amplifier.)

7.3.3 ERROR AMPLIFIER

The DC Ref Voltage from the Reference Divider is applied to two amplifiers: M21 is a high-gain chopper-stabilized integrator of approximately 10Hz bandwidth, Q5 provides additional bandwidth for rejection of HF common-mode noise. M20 provides additional gain and output drive, through a transient-suppressing diode clamp circuit.

The whole amplifier is bootstrapped by M22, D48, D49, Q6, Q7 and Q10. Q8/Q9 provide 1.4mA constant-current drives for D48/D49 over the range of BS-Common variation (-20V to +20V on the 10V and higher ranges). Power for the bootstrapped amplifier is obtained originally from the $\pm 38V$ supply; used also to power the 10V Buffer in the PA assembly, referred to Common-2.

Extensive screening and filtering is used to eliminate the effects of the chopping spikes at inputs and output of M21.

7.3.4 **IV BUFFER**

On the 1V and lower ranges the error amplifier output is applied to the 1V Buffer, via the closed contacts 10/11 of energized relay RL16. A current amplifier M23 is chosen, as the buffer has to drive the external load directly via the output switching, output lines and external leads.

It also drives the 100mV Attenuator on the 100μ V - 100mV ranges.

M23 is powered by a separate individually-filtered 8V supply (*refer* to pages 11.5-4 and 11.11-2). Its input and output are protected by back-to-back zener diodes.

The output from the 1V buffer is connected, via contacts 12/7 of energized relay RL3, to the '1V+10V+100V' PHI(DCV) star point.

7.3.5 RANGE SWITCHING

On the 1V and 10V ranges the 1V+10V+100V star point is decoupled to Common-2A by C28 via contacts 2/3 of energized relay RL4.

Relay RL5 is energized on the 1V and 10V ranges; and after passing through the back-to-back contacts RL5-8/9, which cancel their own thermal EMFs, the DC1V+10V+100V signal is renamed 'PHI(DCV)'.

7.3.6 OUTPUT SWITCHING (Circuit Diagram 430536 Page 11 5-2)

The PHI(DCV) output and other connections from the Range relays (*Page 11.5-1*) are passed to the instrument output terminals via several relay contacts which provide switching for Remote or Local Sense, Remote or Local Guard, and Output On/Off.

The output does not travel directly to the terminals from the DC assembly, as further switching is required. Function changes switch the terminal lines on the Current/Ohms assembly (para 7.3.8.1).

7.3.6.1 DCV/ACV Switching

For DC voltage ranges, relays RL10 and RL11 are energized. The PHI(DCV) line from the range relays passes via RL10 contacts, TP8, 1A fuse F6, and RL15 contacts (if output is set ON); to the PHI(V) line at J5-19. For DC voltage outputs, the four ACV lines at J5-25/26/29/30 are disconnected by relays in the AC assembly.

In Remote Sense, the power return line PLO(DCV) is linked via RL11 contacts, 1A fuses F4 and F3, relay RL14 and RL15 contacts to J5-23 as PLO(V). PLO(DCV) is held close to Common-2A by R56/C30 (page 11.5-1), being protected against excessive departure from Common-2A potential by the back-to-back 3V zeners D13 and D25. The voltage developed across R56 by the output current is monitored by comparator M13 (page11.5-2).

7.3.6.2 Output On/Off.

Because the DCV and ACV lines are separately switched, a single independent 4-pole relay RL15 can be used to set output on and off. Thus the lines at J5-19/20/23/24 carry either DCV or ACV signals to and from the output terminals. Where ACV and DCV join, the power lines change their names to PHI(V) and PLO(V).

7.3.6.3 Remote Sense Switching.

When Remote Sense is not selected, two-wire outputs to external loads can only be connected from the Hi and Lo terminals (a relay on the Mother assembly disconnects the I+ terminal). Relay contacts RL14-9/8 connect PHI(DCV) to SHI(DCV), and RL14-3/2 connect PLO(DCV) to SLO(DCV). Relay contact RL14-5/4 is open, severing the connection to the I- terminal.

In Remote Sense relay RL14 is energized, removing the connections between the power and sense lines, and RL14-5/4 reinstates the link from PLO(DCV) to the I- terminal. This gives full 4-wire sensing at the external load.

7.3.6.4 Remote Guard Switching

The front panel 'Guard' terminals are permanently connected to the internal guard shields via J5-15/16 and J5-11/12. With 'Remote Guard' selected, the direct connection between Guard and Lo is severed by the open contact of energized relay RL17. R121 damps any high frequency resonance in the combined internal and external guard circuits; C62 reducing HF noise on the millivolt ranges. With Remote Guard off, RL17 connects the guards to PLO(V) via PTC thermistor R97, which also assists in reducing millivolt noise.

7.3.7 OUTPUT PROTECTION

Two circuits are described in the following paragraphs:

 The DC Overcurrent Detector, which senses the current flowing in the PLO(DCV) return line, sending a signal to the statusreporting logic if the DC current exceeds approx. 28.5mA.

On the 100V and 1kV DC ranges the 'LIM DET' signal is sent, but on the 10V DC and lower ranges the 'LIM ST' signal is made active.

• The Overvoltage Detector provides an indication to the CPU that the output voltage is in 'High Voltage State', ie. the 'HV ST' signal is activated if the output DC or peak AC voltage is greater than 110V. If the instrument has not been programmed into High Voltage State, then an anomaly exists, and remedial action is taken by the CPU.

The results of activating the overcurrent detector are described later in *sub-section 7.12.7*.

7.3.7.1 DC Overcurrent Detection

On DC voltage ranges of 1V and higher, the current taken by the instrument load develops a voltage across resistor R56 (page 115-1), which is applied to the resistor chain R31/R30/R36 (page 115-2). On 100mV and lower ranges R56 is shorted out by relays RL2-5/4 (page 115-1), RL11-2/5 & 11/8 and RL14-2/3 (page 115-2).

M13 is an open-collector comparator wired to detect excessive voltages across R30/R36 (R31 is the common bias resistor). Diodes D17 and D18 set the reference potential at M13-3 (for positive outputs) to approx. +285mV; and at M13-6 (negative outputs) to approx. -285mV. Under normal operation, when the output current

is less than 25mA, both halves of M13 are held in open-collector. When the output current through R56 exceeds approximately 28.5mA, the voltage across it exceeds 285mV and one of the halves of M13 switches its output to the negative rail (analog logic-Ø). Diode D52 conducts, pulling M10-6 and M10-9 to logic-Ø:

LIM DET Activation:

On the 10V and lower DC ranges, M10-5 is permanently held at logic-1 disabling M10-6, so the overcurrent signal has no effect on M10-4, which is held at logic-1 and D3 remains in reverse bias. The LIM DET signal is not activated.

On the 100VDC or 1kVDC range, M10-6 is enabled by M10-5 at logic- \emptyset , so the overcurrent signal sets M10-4 to logic- \emptyset and LIM DET is activated at logic-1.

LIM ST Activation:

In this case the effect of the 100VDC and 1kVDC signals is reversed, and M10-9 is sensitized to the DC overcurrent signal only on the 10V and 1V ranges, when M10-8 is at logic- \emptyset . For excessive DC output currents, M10-10 sets D9 cathode to logic- \emptyset pulling the <u>LIM ST</u> line to its logic- \emptyset active state.

The AC 1kV Overcurrent Detector receives no input on DC ranges, as no current passes through the sensing resistors R107 and R108.

7.3.7.2 High Voltage Status Detector ('Overvoltage')

In order to provide information to the CPU, so that it can decide whether the High/Low voltage state is as demanded, the voltage level on the PHI(V) line (TP8) is monitored and compared against a reference. The detector senses DC levels for DC voltage outputs, or peak levels for AC voltage outputs.

M17 is a dual comparator whose hysteresis is set to $\pm 1.22V$. For as long as the voltage on the PHI(V) line remains within approx. $\pm 125V$, the division ratio of M16 keeps the input to M17-5/9 within the $\pm 1.22V$ hysteresis, and M17-12/7 remains at logic-1 (0V).

The PHI(V) voltage at TP8 is applied via R83 and R62 to M16-2, which is referred to Common-2B, M16-3 being connected directly to this common. Resistors R61 and R68 apply feedback to M16, setting its gain to -0.0098. C29, C31 and R63 ensure that any transient switching spikes do not activate the comparator. The output from M16-6 is compared with $\pm 1.22V$ in comparator M17.

The open-collector comparator M17 is wired to detect excessive voltages at M16 output (R69 is the common bias resistor). Diodes D26 and D27 set the reference potential at M17-10 (for positive outputs) to +1.22V, and at M17-4 (negative outputs) to -1.22V. Under normal operation in low voltage state, the output voltage lies between -110V and +110V, and M16 output is between -1.07V and +1.07V. Both halves of M17 are thus held in open-collector,

If the DC PHI(V) voltage exceeds 125V (or for an AC peak corresponding to a sinewave RMS exceeding 90V), either M17-7 or M17-12 pulls towards logic-Ø. Current source Q2 permits only 3mA to flow in M17 output circuit, so the voltage input to D6 cathode and M12-11 (B trigger) suffers a negative-going trigger edge.

a. Effect of Overvoltage on DC Voltage Ranges

For DC outputs the 'Q' output of M12 is permanently held at logic-1 by $\overline{\text{DC FNCT}}$ at M12-13 set to logic- \emptyset , so the effect of the negative-going transition at M12-11 is suppressed. However, diode D6 conducts, pulling the $\overline{\text{HV ST}}$ line at J5-105 to logic- \emptyset (-15V). This is passed to the CPU, via the status register in the reference divider and the serial data interface.

The CPU is now aware that the DC output voltage exceeds 110V. The CPU has to make a decision, as to whether the programmed output voltage and the detected state are compatible. If High Voltage state has not been commanded, a fault is assumed and FAIL 2 message is presented on the MODE display.

b. Effect of Overvoltage on AC Voltage Ranges

For AC outputs the DC FNCT signal is inactive at logic-1, so M12-13 at logic-1 removes the reset. Monostable M12 is set to produce a logic-1 at its Q output (M12-9) unless its B input at M12-11 is edge-triggered negatively. In 'Low Voltage State' conditions no trigger is given, so M12-9 remains at logic-1, D7 and D6 are reverse-biassed and the \overline{HV} ST line remains at the logic-1 level of 0V.

When the comparator output switches to logic- \emptyset , D6 conducts instantaneously to obtain the earliest possible reaction to the overvoltage. But as this is a peak value, the HV ST signal would revert to logic-1 without monostable M12. M12 produces a logic- \emptyset (-15V) pulse of 140ms duration, which forward-biasses D7, and the HV ST line transmits a logic- \emptyset pulse of 140ms duration. Successive positive or negative peaks of overvoltage retrigger the monostable, maintaining its Q output (and thus the HV ST signal) at logic- \emptyset .

7.3.8 ROUTING to the TERMINALS

The two power lines are routed from J5-19/23 through the Mother assembly to the Current/Ohms assembly.

7.3.8.1 Current/Ohms Assembly (Circuit Diagram 430614 page 11.8-1)

With any Voltage Range selected, relays RL8 and 9 are un-energized as shown. Also, relays RL24 and RL25 (Ohms function switching refer to page 11.8-3) are un-energized. Voltage Output relay RL23 is energized; connecting PHI(V) to J8-8/9 as 'PHI', and PLO(V) to J8-16/17 as 'PLO'.

PHI and PLO pass into the Mother assembly via at J8-25 and J8-29 respectively.

7.3.8.2 Mother Assembly (Circuit Diagram 430604 page 11.16-1)

PHI and PLO enter at J8-8/9 and J8-16/17 respectively.

PLO passes through the common mode choke L1 via J23-3 and then J26-4 as T-' to the Terminal Board assembly.

PHI is switched by relay RL1. If Remote Sense is not selected, RL1 is un-energized as shown; disconnecting PHI from the I+ terminal circuit, and shorting it to the sense SHI input line. When in Remote Sense, RL1 is energized and PHI passes through the common mode choke L1 via J23-1 and J26-1, and as T+' to the Terminal Board assembly.

7.3.8.3 Terminal Board Assembly (Circuit Diagram 430640 page 11.17-3)

I+ and I- are filtered and passed to the front panel terminals. Ferrite bead FB1 and C2 protect the internal circuitry from the effects of HF pickup in the external circuit.

7.3.8.4 Option 42 - Rear Terminal Output (Circuit Diagram 430557 page 11.17-1 Layout Drawing 480603 page 11.19-2)

Option 42 is incorporated at manufacture. With rear output terminals, the Terminal Board assembly is not fitted. The connections to the rear are taken from J26 on the Mother assembly. A capacitor C1 connects Guard to Earth (Ground), and ferrite beads are fitted on the Hi, I+ and Guard leads at the terminals. The terminal filter relay is not fitted.

7.3.9 1V LOOP - OUTPUT SENSING

For users with Option 42 - Rear Output, the circuitry at the terminals is changed. Refer to Sect. 7.3.8.4.

7.3.9.1 Terminal Board Assembly (Circuit Diagram 430640 page 11.17-3)

If Remote Sense is selected, the front panel sense terminals Hi and Lo are connected externally to I+ and I- respectively at the load.

The sensed voltage is filtered by FB2 and C3 to reject external HF pickup. Except on the 1000V Range, a signal ('R-', 'R+') originates as TERM FILTER' in the Reference Divider to energize relay RL1, which introduces capacitor C1 to augment this HF rejection.

The filtered sense voltage is fed into the Mother assembly between J26-2 (Hi) and J26-5 (Lo). (No external sensing is provided for the millivolt ranges. See *paras* 7.3.6.3, 7.3.8.2, 7.3.9.2 and Fig. 7.1 for the simplified local sensing arrangement.)

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7.3.9.2 Mother Assembly

(Circuit Diagram 430604 page 11.16-1)

Lo passes through the common mode choke and directly to the Current assembly at J8-18 as SLO.

Hi also passes through the choke and enters the Current assembly as SHI at J8-10. However, if Remote Sense is not selected, it is shorted to PHI by relay RL1 for two-wire connection. RL1 is energized from the REM SENSE +ve and -ve lines from the DC assembly.

7.3.9.3 Current/Ohms Assembly (Circuit Diagram 430614 page 11.8-1)

With any Voltage Range selected, relays RL8 and 9 are unenergized as shown. Ohms function relays RL24 and RL25 are also unenergized (refer to *page 11.8-3*). RL23 is energized; connecting SHI into the Mother assembly as 'SHI(V)' via J8-26, and connecting SLO via J8-30 as 'SLO(V)'.

7.3.9.4 DC Assembly

(Circuit diagram 430536 Page 11.5-2)

In normal 4-wire operation (Remote Sense selected) with OUTPUT 'ON' on the 1V and 10V Ranges, relays RL10, 11, 14 and 15 are energized.

SHI(V) enters from the Mother assembly at J5-20 and is passed directly through RL15 and RL10 contacts, 1A fuse F2, and to the range relays as SHI(DCV).

SLO(V) travels via RL15 and RL11 contacts to the range relays as SLO(DCV).

With Remote Sense not selected, relay RL14 is unenergized. RL14-9/8 short SHI(V) to the power Hi output PHI(V). RL14-2/3 short SLO(V) to the power Lo output PLO(V).

Refer to Page 11.5-1.

SLO(DCV) is referred to Reference Common-1. SHI(DCV) passes to the contacts 8/9/10/11 of energized 1V+10V range relay RL4, and via R77 to the inverting input of the Error Amplifier.

N.B. Although the relays are referred to above as 'energized' and 'un-energized', this is not strictly true as polarized relays are used to dispense with the power needed to hold the relays in.

This distinction is not significant to the present text, but is discussed later in *sect 7.11* where the relay logic is detailed.

7.4 100mV RANGE

The 1V Attenuator and 1V Buffer are connected into the circuit as for the 1V range. Relays RL1 and RL2 are energized. The output from the 1V buffer is connected to the star point at TP5 by RL1-7/12, and RL2-5/4 connects the Common-2 star point, at the base of the 100mV Attenuator, to Reference Common-1. Thus the 100mV Attenuator is connected across the 1V Buffer output.

The TP5 starpoint is connected directly to the Error Amplifier inverting input via RL2-9/8 and R77, completing the sense feedback. The Error Amplifier adjusts the voltage at TP5 until the error is reduced to zero; the TP5 voltage thus converges to that of the attenuated DC Ref at RL16-4.

The output of the 100mV Attenuator, at the TP6 star point, is therefore one hundredth of the DC Ref voltage, and can be varied between -200mV and +200mV. Note that the full DC Reference voltage resolution is available, so that the 100mV range resolution remains at 71/2 digits. This is reflected in the resolution of the OUTPUT display on the instrument front panel.

The 100mV Attenuator output passes through RL2-2/3/10/11 to join the PHI(DCV) line. On ranges below 1V the Remote Sense

relay RL14 (page 11.5-2) cannot be energized; so with DC Voltage and Output ON selected, the 100mV range output is routed via contacts RL14-9/8 and the SHI(V) line, on towards the Hi terminal on the front panel for 2-wire connection.

The other connection to the load returns via the Lo terminal, arriving at the DC assembly as SLO(V), referred to Common-1 (page 11.5-1). Contacts 2 and 3 of unenergized Remote Sense relay RL14 connect the SLO(V) line to the PLO(DCV) line, and through the overcurrent sense resistor R56 to Common-2A. However, no overcurrent sensing is available on ranges below 1V, as R56 is shorted by the RL2-5/4 connection between Common-1 and Common-2A at the base of the 100mV Attenuator, and the contacts of the energized RL11 and un-energized RL14 (page 11.5-2).

N.B. Although the relays are referred to above as 'energized' and 'un-energized', this is not strictly true as polarized relays are used to dispense with the power needed to hold the relays in.

This distinction is not significant to the present text, but is discussed later in sect 7.11 where the relay logic is detailed.

7.5 **100**μ**V** - **10mV RANGES**

These ranges use the same relay settings as 100mV Range, so the output voltages remain at 1/100 of the DC Ref voltages. The differences lie in the spans of DC Ref voltages used.

To achieve the correct DC Ref span, the appropriate scaling is computed digitally and the 4-byte binary words set in the 13-bit and 12-bit comparator latches of the Analog Interface. The DC Ref spans are scaled as follows:

 10mV Range
 -2V to +2V

 1mV Range
 -200mV to +200mV

 100μV Range
 -20mV to +20mV

7.6 DC 10V LOOP

7.6.1 DC REF. and ERROR AMPLIFIER (Circuit diagram 430536 Page 11.5-1)

The DC Ref signal is derived as for the 1V range, entering the DC assembly at the same pins: J5 pins 1, 2, 3 and 4. Relay RL18 again connects the power and sense lines to the two star-points TP2 and TP3, TP3 being the signal Common-1 point.

On this range, RL16-8/9 connects full DC Ref to the non-inverting input of the Error Amplifier, which operates as for the 1V range, except that the span of voltages is now the full -20V to +20V.

7.6.3 **10V BUFFER (Power Ampl. Assembly)** (Circuit Diagram No. 430618 pages 11.9-1/2).

The discrete, complementary, 10V Range buffer-amplifier is a dualpurpose circuit, generating power to the output terminals for both DC and AC functions.

As it provides the full output current, it is located on the Power Amplifier assembly so that the heat from its power stage can be developed outside the thermally-shielding Chassis assembly, and dissipated by forced-air cooling from the fan. Its output is fed back to the DC or AC assembly for range and output switching, as the 'DC10V+100V' signal.

7.6.3.1 DC Path

The DC path is blocked by C56; M17 is the DC input buffer, connected as an integrator with diode clamping. M19 operates as an inverter in open loop, so applies high DC gain to the output from M17 on M19-2, referred to Common-2C by R112.

The output from M19 drives both halves of the symmetrical, inverting, discrete power amplifier through current-limiters Q21 and Q24, and is buffered by emitter-followers Q22 and Q23. Commonemitter devices Q27 and Q29 form a voltage amplifier, driving the complementary output stage Q32 and Q33. Resistors R119 and R120 set the gain of the discrete stages to approximately 4.5.

The forward amplification contains three inversions, negative DC feedback being applied to M17 inverting input by R122, defining an overall gain of 10 in conjunction with input resistor R123.

Because of this scaling, the resolution available on these ranges is reduced in proportion to the scaling ratio. The displayed output resolution is automatically adjusted according to range selection:

10V, 1V and 100mV Ranges	-	71/2 digits
10mV Range	-	61/2 digits
1mV Range	-	$5^{1/2}$ digits
100µV Range	-	$4^{1}/_{2}$ digits

7.6.2 DC ÷2 ERROR BUFFER M14 (Circuit diagram 430536 Page 11.5-1)

The Error Amplifier output is blocked from the 1V Buffer by the open contacts 10/11 of RL16. Instead, it is connected by RL6-6/4 as input to M14.

For the 10V and 100V ranges, M14 is connected as an inverting +2 line buffer by the un-energized relay RL6-6/4 and 11/13. For the 10V range, M14 output passes to the Power Amplifier assembly via J5-73 and the Mother assembly.

The output from the line buffer M14 on the DC assembly (the signal 'DC 10V+100V+1kV ERROR') enters the PA assembly at J9-40, passing to the input of the 10V Power Amplifier via DC/AC selector relay RL4-11/13 and 10V selector RL3-9/13. The signal is attenuated by R171 and R124 in a ratio of 4.17:1. So a positive full range DC Ref signal of +10V from the Reference Divider appears at J9-40 as -5V, and is further attenuated by R171/R124 to approximately -1.2V across R124, which refers it to Common-2B.

The amplifier is best regarded as having separate DC and AC paths.

For DC range selections, the DC error signal is applied at M17-2, is amplified by 10 and output at TP11 via the low DC resistance of L8. The forward voltage gain, from the output of the Error Amplifier to the output of the 10V Buffer, is thus of the order of 1.2. This is more than sufficient to support the specified output current, when corrected to the demanded output voltage by the sense feedback to the Error Amplifier.

In AC operation, the effect of the DC path is to sense and correct the DC offsets throughout the whole AC amplifier, referring the output to Common-2A at M17-3.

7.6.3.2 AC Path

The AC path is blocked by the integrator M17, but is applied to the non-inverting input of M19 through the coupling capacitor C56. M19 operates in open loop, applying its output to the discrete power amplifier (see *para 7.6.3.1* above).

The amplifier AC gain is also set to 10 by R122 and R123, the circuit time constants being selected to allow overall instrument output operation over the full frequency range of 10Hz to 1MHz.

7.6.3.3 Overload Detection

The 10V FLAG line, connected to D71 cathode, is pulled up to 0V (in-guard logic-1) by 7.2k Ω (See *page 11.9-5* - R154 in parallel with R38). An Error OL message results from this line being driven to logic-Ø by Q34. During DC operation, relay RL8 is un-energized, configuring the collector loads of emitter-followers Q32 and Q33 as low-pass filters. This de-sensitizes the overload detector and the overload limiters Q28 and Q30 from the effects of transient currents.

Overload detector Q31 reaches Vbe threshold when the DC current value in R139 and R141 exceeds approximately 35mA. Similarly, Q34 detects currents in R147 and R149. In either case, Q34 conducts, pulling diode D71 cathode down to -15.7V. This drives the 10V FLAG line to logic-Ø, so the status message is returned to the CPU via the SSDA serial interface, and the 'Error OL' message is displayed.

This does not preclude further increase in output current, but under these conditions the instrument accuracy specification is not guaranteed.

During AC operation, relay RL8 is energized, the filter is removed, and the Overload Detector is adjusted to operate as a peak current detector. R172/R141 and R173/R147 cause the 10V FLAG to activate for RMS values of output sinewave current in excess of approximately 80mA.

RANGE SWITCHING (DC Assembly)

(Circuit Diagram 430536 Page 11.5-1)

The DC 10V+100V signal enters the DC assembly from the Mother assembly at J5-37/38 and R73/L6 filter out any spikes picked up in transit. Relay RL4 is energized, shorting the high voltage resistor R67, so the signal goes directly through the 1Amp fuse F1 to the 1V+10V+100V star-point.

7.6.3.4 Overload Limiting

If the DC output current increases to approximately 39mA, the current in either R139 or R149 causes the Vbe threshold of Q28 or Q30 to be exceeded, shunting the base current of the corresponding voltage amplifier. Thus the output drive to the final stage is limited.

In AC operation, if the RMS output current increases to approximately 100mA, the peaks of current cause the Vbe threshold of Q28 or Q30 to be exceeded. The output drive to the final stage is limited at this level.

-

12.2

17.7

100

ET.F

7.6.3.5 Output Protection

The output current passes through the combination of R144 and L8. At DC and low frequency AC, the inductor provides a low output impedance, whereas at high frequencies the resistor stabilizes the amplifier when driving capacitive loads.

7.6.3.6 10V Buffer Output

For DC and AC 10V ranges, relay RL3 is energized.

For DC, RL4 is un-energized, so the 10V Buffer output passes via RL3-8/4 and RL4-4/6 as the 'DC 10V+100V' signal, J19-19/20 to the Mother assembly, and thence to the DC assembly.

For AC, RL4 is energized, diverting the 10V Buffer output via RL4-4/8 as the 'AC 10V+100V' signal, and out at J19-15/16 via the Mother assembly to the AC assembly.

7.6.3.7 10V Amplifier Power Supplies

M17 and M19 are supplied from 15V Common-2A rails, but the discrete amplifier receives power from the 38V supply, which is also used for the Error Amplifier on the DC assembly.

7.6.5 REMAINDER OF THE 10V LOOP

From this point, the 10V range loop follows the same path as the 1V loop, both outwards to the I+ and I- terminals and back to the Error Amplifier inverting (sense) input. Of course, on the 10V range, the returning sense signal is compared with the full DC Ref voltage, rather than the attenuated DC Ref for the 1V range. Refer to sub-section 7.3; from para. 7.3.6 onwards.

7.6.4

7.7 DC HIGH VOLTAGE LOOPS

The basic instrument includes a high voltage DC range, nominally 100V full range, but extending from -200V to +200V full scale. The factory-fitted Option 10 introduces a nominal 1000V DC range, which covers the span from -1100V to +1100V.

7.7.1 HIGH VOLTAGE DELIVERY

Both ranges employ the same referencing arrangement used for the 10V DC Range, but the techniques necessary to generate high voltages differ from those in the low voltage loops:

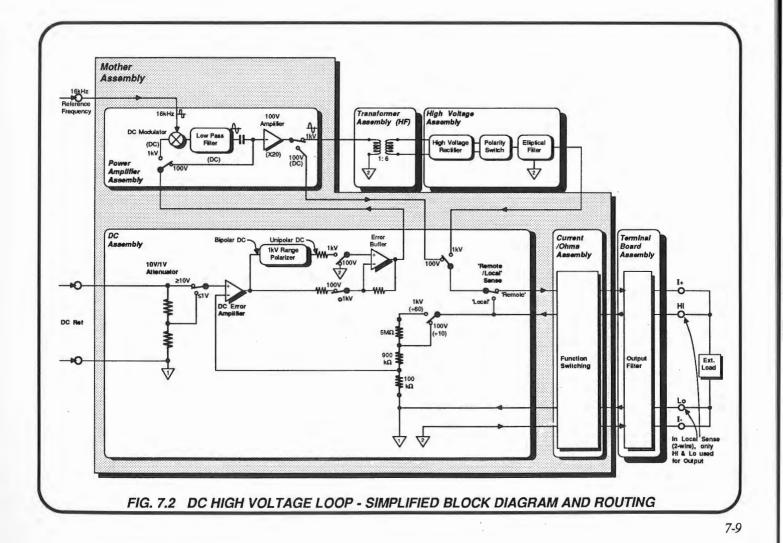
• For the 100V Range, a VMOS circuit amplifies the ±20V Reference directly, as a DC signal, powered from a separate ±400V supply. The 100V range voltages are passed back via the range switching circuitry in the DC assembly to be output from the instrument as for the low voltage ranges.

7.7.2 HIGH VOLTAGE SENSING

A guarded high-voltage switched precision attenuator reduces the DC sense voltage from the Hi and Lo terminals to Reference levels. The attenuated sense voltage is compared with the DC Ref voltage, their difference being used as an error signal to correct the range output level.

The simplified block diagram of *Fig.* 7.2 illustrates the high voltage DC circuit arrangement and signal flow. The details of the 100V and 1000V ranges are described in *Sub-sections* 7.8 and 7.9.

For the 1000V Range, the DC reference is first converted to a 16kHz AC signal, amplified in the same 100V amplifier, then stepped up to 1000V range voltages through a separate transformer. Subsequent high voltage rectification, filtering and polarity-switching converts the AC output from the transformer secondary into a DC voltage. A separate line conveys the 1kV range voltage back to the DC assembly for range switching and output from the instrument.



7.8 100V RANGE

7.8.1 INTRODUCTION

The '10V+100V+1000V DC ERROR' signal, generated by the +2 DC Error Buffer in the DC assembly, enters the Power Amplifier as for the 10VDC range; but the 10V Amplifier is bypassed for the high voltage ranges.

On the 100V range, the signal is switched directly into the 100V Amplifier, where it is scaled up by a factor of -20, the amplifier output being delivered via the 'DC 10V+100V' line to the PHI(DCV) line on the DC assembly. Thereafter the output is transferred to the instrument terminals as for the 10V range.

7.8.2 100V RANGE POWER ROUTING

7.8.2.1 DC Reference and Error Amplifier (Circuit diagram 430536 Page 11.5-1)

The DC Ref signal is derived as for the 1V range, entering the DC assembly at the same pins: J5 pins 1, 2, 3 and 4. Relay RL18 again connects the power and sense lines to the two star-points TP2 and TP3, the latter being the signal Common-1 point.

On the 100V range, RL16-8/9 connects the full DC Reference to the non-inverting input of the Error Amplifier, which operates as for the 1V range, except that the span of voltages is now the full -20V to +20V.

7.8.2.2 DC ÷2 Error Buffer M14

The Error Amplifier output is blocked from the 1V Buffer by the open contacts 10/11 of RL16. Instead, it is connected by RL6-6/4 as input to M14.

For the 10V and 100V ranges, M14 is connected as an inverting +2 line buffer by the un-energized relay RL6-6/4 and 11/13. For the 100V range, M14 output passes to the Power Amplifier assembly via J5-73 and the Mother assembly.

7.8.2.3 Power Amplifier and Output Routing (Circuit Diagrams: 430618 pages 11.9-2 and 11.9-3; 430536 page 11.5-1)

'DC Error' enters the Power Amplifier assembly at J9-40 (refer to page 11.9-2). Relay RL3 is un-energized, shorting the 10V Amplifier input; and RL4 is un-energized, routing the DC Error signal to the 100V Amplifier as signal '100V I/P' (page 11.9-3).

Energized relay contacts RL2-8/4 apply the signal to the Gain Stage, which provides drive to the power amplifiers in the positive and negative heat sinks, via J3-12 and J3-11. The single-ended output from the heatsinks at J3-9 passes via R89, L7 and relay RL2-13/9 (RL2 energized), to RL3-6 (*page 119-2*), and onto the 'DC 10V+100V' line via RL4-4/6, R174 and J9-19/20.

On the DC assembly (*page 11.5-1*), the signal is routed to the PHI(DCV) line as for the 10V range.

7.8.3 100V AMPLIFIER (Circuit Diagram 430618 page 11.9-3)

The 100V amplifier is in three stages:

- Gain Stage: this is similar to the first stage of the 10V amplifier, but with a different distribution of gain.
- Driver Stage: providing most of the gain, this stage runs from a regulated 400V supply.
- Buffer Output Stage: complementary MOSFET circuits, located on the positive and negative heatsinks, provide a singleended output with the required voltage swing, at low impedance.

The voltage gain for the whole 100V amplifier is set at 100 by the input resistors R74/R71 and the feedback resistor R88.

The 100V amplifier is also used for 100V AC outputs, and on the DC and AC 1000V ranges to drive the step-up transformer. For this reason the following description is applicable to both DC and AC signal processing, and will be referred to in the sub-sections dealing with those functions and ranges.

7.8.3.1 Input to Gain and Driver Stages (Circuit Diagram 430618 pages 11.9-2 and 11.9-3)

The DC ERROR signal enters the PA assembly at J9-40, passing to the input of the 100V Power Amplifier via relays RL4-11/13 and RL2-8/4. It is referred to common 2B by developing a voltage across R72.

7.8.3.2 DC Offset Correction

M10 is the DC offset integrator, with diode clamping. It provides a DC input to the non-inverting input of the voltage gain amplifier M8, controlling its DC offset. This is similar to the arrangement in the 10V Amplifier.

7.8.3.3 Signal Processing

M8 is a high speed hybrid amplifier operating as an inverter. With link LKD normally made, its stage gain is approximately 2.5, frequency compensated by C18 and C72. It operates from the 15V Common-2B supplies, but its signal output is converted into a current by Q10 and Q8; allowing its mean DC voltage for AC signals to reach the -400V levels required to operate the driver MOSFET output circuit. Diodes D44, D43 and D36 prevent negative latch-up.

Voltage Regulator M21 sets its pin 1 to +12V. Common-emitter buffer Q10 drives the capacitance of Q8 source-gate from the output of M8, forming a cascode current generator. The drain of p-channel MOSFET Q8 passes the signal current to the mirror Q12/Q11 at voltages close to the negative 400V rail.

The current-mirror output transistor Q11 is also in cascode with its associated MOSFET Q9. Emitter resistor R53 defines the current in Q9, the ratio R52/R53 setting the mirror's current gain.

7-10

MOSFETs are inherently capacitive, so measures are taken to nullify the effects, on slew rate, of the capacitive currents between Q9 electrodes. The cascode arrangement ensures that any source-gate and source-drain capacitive currents join the main flow of source current and have little effect on slew rate.

The Miller feedback of the drain-gate capacitance has the greatest effect on slew rate, generating AC currents between anti-phase electrodes which normally pass into the input circuit. In this arrangement, Q13 diverts these currents back into the cascode current, while maintaining a standing bias of about 4 volts between gate and source. These measures minimize the reduction of Q9 operating bandwidth.

R51 and D42 provide Q13 operating bias, and D51 protects the bias circuit. The high-power resistor R49 refers the bias circuit to Common-2, and C26 stabilizes the base-emitter bias of Q13. Zener diode D39 protects the MOSFET from source-gate voltage breakdown.

7.8.3.4 Driver Regulator

At Full Scale on the 100V AC range, the output from the driver is 200V RMS. This requires Q9 drain to provide a peak-to-peak voltage swing approaching 600 Volts, as there is no voltage gain in the heatsink power amplifiers. The positive supply which provides Q9 current therefore needs special regulation.

The 400 volt supply is at this point unregulated, so can contain line ripple and level variations, this noise level being critical to the output performance. To define a stable supply voltage, a DC restoration circuit is employed as a trough detector, maintaining a level about 5V below the most negative excursions of the ripple.

At power-up, 75V zener D57 allows a rapid charge of reservoir capacitors C49 and C59, until the charge reduces D57 voltage below the avalanche level. When D57 cuts-off, R100 provides a charge path of $1M\Omega$, giving a time constant of approximately 10 seconds. The smoothed voltage across C49/C59 is divided by R101, R86 and R87; so a small voltage is dropped across R101, and Q20 gate is held about 5V below the +400V(2)B line voltage. The N-channel source-follower Q20 thus provides a quiet, low-impedance DC supply voltage.

Zener diodes D60 and D61 divide the voltage across C49 and C59, so that their breakdown voltages are not exceeded. The 10V zener D54 protects the TMOS gate/source from excessive voltages.

The opto-coupler M16 permits the 400v supply to be switched off, allowing D56 to assume forward bias, thus connecting the rail to the +38V supply. This facility is made available to reduce the voltage across R65, and hence its continuous power loading, when the instrument is delivering a DC output of negative polarity. M16 is turned off for AC and positive DC outputs, by the 'POSITIVE' signal from the processor being set to logic-1 (0V). Thus M16-6 is isolated from M16-5, and the +400V rail out of the regulator remains energized. For negative DC outputs, the cathode of the LED in M16 is pulled to logic- \emptyset (the POSITIVE signal being set to -15V on M16-3 - see *page 11.9-5*); the LED emits, and M16-6/5 shorts out D54 turning Q20 off. The total supply voltage for negative outputs is then limited to 438V.

At HF, inductor L6 appears as a current source, increasing the impedance of Q9 drain load with frequency to compensate for capacitive loading. It has the advantage of not increasing the net power dissipated in the stage; any active current source would have significant output capacitance. The 12-watt resistor R65 is the main resistive drain load for Q9.

7.8.3.5 Driver Output

The driver develops its output voltage, which can involve peak-topeak AC swings of up to 600V, across the load resistor R65. Zener diode D41 is included to clamp the output in the event of the heatsinks being disconnected. This is normally held below avalanche by the current passing through a series bias buffer (Q8) in the Positive Heatsink assembly, via J3-11 and J3-12.

The main frequency compensation is performed by capacitor C12. This could have been connected to the drain of Q9, but the output line slew rate is sensitive to capacitive loading. Instead it is connected via J2-7, to a low impedance point in the Negative Heatsink assembly, which follows the driver output voltage swing.

7.8.4 100V POWER AMPLIFIER (Circuit Diagrams 430637 page 11.13-1 and 430539 page 11.13-2)

The 100V power amplifier stage is split between the Positive and Negative Heatsink assemblies. The driver output voltage is connected into the Positive assembly, and the frequency compensation feedback is derived in the Negative assembly.

The whole circuit is a complementary, single-ended push-pull amplifier with unity voltage gain. To achieve the full 300V peak voltage output, two MOSFET source-followers are connected in cascode, for each polarity, in a totempole arrangement.

To obtain the required peak current levels, each source-follower consists of two MOSFETs in parallel. In all, therefore, eight MOSFET devices are used.

On 100V ranges, the output currents are such as to bias the amplifier in class A, but on 1000V ranges the output currents impose class AB conditons. Crossover distortion is minimized by a regulated bias, generated by a Vgs multiplier (M1 in the Positive Heatsink assembly).

Power for the amplifier is provided by the same 400V supply that serves the driver circuit. To minimize internal temperature by improving efficiency, overall power loss is reduced by regulation only where required. Thus only the driver stage is regulated, allowing the power amplifier to take power directly from the unregulated supply. Being source-followers, the ripple on their 400V rail is not transmitted.

7.8.4.1 Positive Heatsink Assembly (Circuit Diagram 430637 Page 11.13-1)

N-channel MOSFETs Q1 and Q2 are connected in parallel, as are Q3 and Q4. All devices are matched for power dissipation and threshold voltage for an even dissipation of approximately 400W between the two heatsinks. All gate-source potentials are limited by 10V zeners.

The input voltage from the driver is present at J3-11 and J3-12. Most of the driver load current passes through the bias buffer Q8, and the voltage developed across Q8/R21 is applied to the bias control R10. The Vgs multiplier M1/Q8 acts as a high gain shunt regulator, generating a bias of between 5V and 9V, set by R10. The regulator's own bias chain of Q9, D8, and Q5 (which is connected as a diode) responds to the temperature of the heatsink to compensate for the temperature coefficients of the MOSFETs.

The 'DRIVE-' voltage at J3-11 is transferred directly to the negative heatsink input via J1-7 (Circuit Diagram 430539 page 11.13-2).

The 'DRIVE+' voltage at J3-12 is buffered by Q7 and applied to the gates of Q3 and Q4. In the event of an output short-circuit, Q6 detects the output current as a voltage across R14, imposing a hard limit of 1.5A by reducing the signal voltage at the input to the MOSFET gates.

The series gate resistors R5 and R6, together with their associated drain-gate capacitances, form the dominant pole of the amplifier. Damping resistor R19 with ferrite bead FB1, prevent local oscillations in emitter-follower Q7.

Q1 and Q2 act as buffers to provide a bootstrapped supply for the output devices Q3 and Q4, splitting the overall power dissipation to four points of application to the heatsink. The gates of Q1 and Q2 receive their drive from the output line, obtained via the divider R16/R22/R23/R15. Capacitors C10 and C13 decouple any noise on the 400V rail; C11 and C12 correct any lag which may be generated by C10 and C13. C5 and C6 control the division ratio at HF, swamping any stray capacitance.

The drains of Q3 and Q4 are shorted together, and connected via J1-5 by a 10nF capacitor to the corresponding point in the Negative Heatsink, completing an AC bootstrap (BS). The gates of Q3/Q4 (J1-1) and Q1/Q2 (J1-4) are similarly linked to their corresponding points in the negative heatsink. This ensures that AC swings in both polarities are identical.

The combined output from the Positive and Negative Heatsinks is transmitted back to the Power Amplifier assembly via along the screen of the input connection.

7.8.4.2 Negative Heatsink Assembly (Circuit Diagram 430538 Page 11.13-2)

This is virtually a mirror image of the Positive Heatsink circuit. However, because the P-channel MOSFETs are operating closer to their maximum voltage rating, they are further protected by Zener diodes which limit their drain-gate potentials.

The HF swamp capacitors are not required, as the whole circuit is AC-bootstrapped to corresponding points in the Positive Heatsink assembly, via C1, C2 and C4.

HF compensation for the driver and output stages is derived at low impedance from the junction of R2 and D12. It feeds back via J2-7 to the driver output circuit, through C12 in the Power Amplifier assembly, to avoid capacitively loading the driver output line.

7.8.4.3 Over-Temperature Detection

The two NTC thermistors in each heatsink circuit are part of a bridge network which detects excessive temperatures on the heatsinks. The action of the bridge is described in *section* 7.12.9.

7.8.4.4 100V Output Connection

DANGER!

For guarding purposes, the output from the heatsinks is transmitted back to J3-9 of the Power Amplifier assembly along the screen of the input cable. The voltages on this screen are POTENTIALLY LETHAL. Utmost caution should be exercised when working in its vicinity.

7.8.4.5 Heatsink Removal

The 100V Amplifier can work with the heatsinks removed, because of the clamp diode (D41 on *page 11.9-3*) in series with the driver load. If they are removed, however, J3-9 and J3-11 in the disconnected socket of J3 must be connected together, to maintain the feedback. In this condition, the gain falls due to loading of the driver by resistors in the DC or AC assembly.

7.8.5 POWER SUPPLIES AND PROTECTION

Three main power supplies are employed in the Power Amplifier:

• 15V Common-2 in-guard supply.

This is used for all low voltage applications, including the switching and functional logic. For the most part the logic conforms to the standard: logic-Ø = -15V; logic-1 = 0V.

• 38V Common-2 supply.

Required mainly for the 10V Power Amplifier, but also for negative DC outputs in the 100V Amplifier driver, this supply is generated on the separate 38V Power Supply assembly (*Refer to page 11.12-1*). Part of the supply circuit is situated on the Mother Assembly.

• 400V Power Supply.

The 100V Power Amplifier used for the 100V and 1000V ranges, for both DC and AC outputs. The line transformer secondary output is rectified and smoothed on the Mother assembly, and the main regulator circuitry for the driver stage is contained on the Power Supply / Current Heatsink. The power output stage of the 100V Amplifier receives unregulated 400V supply. Extensive protection is incorporated.

7.8.5.1 38V Supply

(Circuit Diagram 430544 Page 11.12-1)

The mains (line) transformer secondary centre tap is referred to Common-2 on the Mother assembly after passing through the 38V Power Supply assembly. This secondary also provides an adjustable AC output for the 'Common Mode Null' balancing circuit.

A single bridge rectifier on the Mother assembly provides both positive and negative raw supplies for the foldback regulator in the 38V Power Supply assembly.

The 38V supply circuit is described in Section 6.7, para 6.7.3.4.

7.8.5.2 400V Transformation and Rectification (Circuit Diagram 430604 Page 11.16-5)

The mains (line) transformer secondary centre tap is referred to Common-2 on the Mother assembly. The secondary is switched with the secondary for the 38V supply, to allow a lower voltage to drive the 100V power amplifier for servicing purposes. Under operational conditions in the 4200, this switch, which is situated prominently on the Mains Transformer assembly, is set to the 400V position.

A single bridge rectifier on the Mother assembly uses series diodes to achieve the high peak inverse voltage performance required for the 400V supply.

After smoothing, and part-loading by a bleeder resistor chain (the bleeder resistors also balance the voltages across the capacitors); the rectifier output is passed via J31, to provide both positive and negative raw supplies for the foldback regulator in the PS/I Heatsink assembly.

7.8.5.3 400V Current Control (Circuit Diagram 430540 Page 11.13-3)

When the 400V supply is enabled, the LEDs in opto-isolators M1 and M2 are conducting, allowing their opto-transistors to be energized. As the circuits for both polarities are otherwise symmetrical, only the positive circuit is described.

Zener Diode D8 protects the source-gate circuit of level-shifter Q3. This N-channel MOSFET supplies a current of 1.4mA, as defined by Q8, to the current-monitor reference zener diode D7. This current is available only if the 400V supply is enabled by M1, otherwise Q4 base is pulled down by D1/R9, Q4 conducting via D7 so Q9 is pinched off.

Under normal operating conditions the Power Amplifier supply current is drawn through the P-channel MOSFET Q9, which is held in conduction by R8, R12 and D2. The current is sensed by the parallel combination of resistors R17 and R32. Although the peaks of the current taken by the power amplifier can reach 1.4A, the mean value is less than 0.5A. Ripple currents making up the difference are smoothed by the main reservoir capacitors C31 and C22 on the Power Amplifier assembly (*page 11.9-3*). For mean currents more than approximately 0.5A (in particular for output short-circuits); the voltage sensed across R17/R32, subsequently divided by the attenuator R10/R9, exceeds the threshold of Q4/D7. Q4 conducts to pass current into R8, reducing the drive to Q9 gate, so the $\pm 400V(2)B$ voltage at D5 anode falls. When the voltage dropped by Q9 rises to 56V, zener D5 conducts and pulls Q4 base down, further reducing the drive to Q9 gate. This cumulative action is slowed only by the time constant of the combination R34/C15, so that both voltage and current on the $\pm 400V(2)B$ line are simultaneously closed down.

With a persistent 400V overload, the circuit cannot recover naturally from this 'foldback' mode. However, the 400V voltage is monitored. If the 400V monitor senses a failure, a status bit is passed back to the CPU via the SSDA serial link. The CPU makes three attempts to reinstate correct operation by removing the PA bias while restarting the supply via the 400V enable line. If after the third attempt the voltage does not recover, the CPU assumes that a hardware fault is present, so displays the 'FAIL 7' message.

7.8.5.4 100V Current Sense and 1kV Overvolts Detector (Circuit Diagram 430618 Page 11.9-6)

This detector circuitry is used only for AC High Voltage ranges, and is described with the AC Voltage Amplitude Control system in *Section 9.* However, as the 400V supplies pass through the circuit for DC high voltage ranges, it is worth a mention at this point.

The 400V(2)B lines enter the Power Amplifier assembly from the PS/I Heatsink at J1-8/6 and are filtered by L1 and L2 before being applied across two neon lamps LP1 and LP3. These lamps are visible from the top and rear of the instrument when the PA board is exposed, indicating that a dangerous voltage is present.

The 400V(2)B lines pass on to power the driver stage of the 100V amplifier, where the voltage is regulated as described in sect. 7.8.3.4.

The 400V(2)C lines supply the power amplifier in the Positive and Negative Heatsinks.

On the AC 100V range, the current in each of these lines is used as an analog of the load placed on the amplifier. (On the 1000V ranges, any overload is sensed by an AC or DC overcurrent detector in the DC assembly.) On the AC 1000V Range, the voltage applied to the primary of the step-up transformer is fed via a resistor to the detector at M2-5/9. The '100V AC' line is set to logic- \emptyset (-15V) only when the 100V AC range is selected.

7.8.6 PA POWER SUPPLY MONITORS (Circuit Diagram 430618 Page 11.9-4)

All three power supply voltages: 15V, 38V, and 400V; are monitored using similar comparators to initiate individual 'FAIL' messages. In addition, if either the 400V or the 15V circuit detects a low power supply voltage, the 400V supply is disabled.

7.8.6.1 Comparator Supply Protection

To ensure that failure of either the 15V or the 38V supply does not remove the power from the three comparators, these two sources are 'OR'ed by D5, D6, D15 and D16 (the 38V supply being ballasted by R1 and R15) to provide the V+ and V- supply to the Quad op-amp M3. In nine of the possible sixteen states of failure of these two supplies, power will still be applied to the comparators. The maximum values of V+ and V- are limited to +16V and -16V by zener diodes D7 and D14.

7.8.6.2 15V Monitor

Zener diode D29 is the 2.45V reference for the 15V comparator. It is ballasted by R27 to V+, and its +2.45V above the -15V rail is applied to the non-inverting input of M3c. The +15V to -15V supply is divided by R29/R30/R33, generating a voltage +2.50V above the -15V rail at the inverting input to M3c under normal operating conditions. Thus the output at M3c-7 remains at the negative (V-) rail, holding D28 in forward bias, and the 15V(2) FAIL line at J9-108 is held at Logic-Ø (-15V).

If the voltage between the $\pm 15V$ supply rails falls to less than 29.4V, the voltage across R30/R33 falls to less than the reference 2.45V. The output at M3c-7 changes state to the V+ rail, reversebiassing D28, so the 15V(2) FAIL line is pulled to logic-1 (0V) by R28.

The logic levels on the 15V(2) FAIL line pass via the Mother assembly to the Parallel/Serial status registers in the Reference Divider assembly (M18-5 on *page 11.4-4*). During each control data transfer, the SSDA also passes the condition of the status registers back across guard to be read by the CPU. When the 15V(2) FAIL line switches to logic-1 due to a 15V failure, this is detected by the CPU which produces the FAIL 9 message on the MODE display.

The 15V monitor output line also gives an input to the 400V enable logic (sect 7.12.5). The effect of a 15V failure is to disable the 400V(2)B regulated supply via D26 conduction and J1-3 at logic-1.

7.8.6.3 38V Monitor

The action is similar to the 15V monitor, but because of the higher voltage, the divider between the +38V and -38V lines is balanced by two 10k Ω droppers in each line. Without Q5, the 2.45V zener bias current would affect the sensing level. By employing Q5 as a voltage follower, D25 bias current can pass directly to the V-rail and still be referred to the R25/R26 junction. The V_{be} drops in Q5 cancel one another out, so the zener and the sensor R25/R32 are referred to the same potential.

In normal operation the voltage across the 715Ω of R25/R32 is approximately 2.62V, in excess of the 2.45V of D25.

If the 76V between the +38V and -38V rails fails by falling to 71V, the voltage at M3b-2 falls below that at M3b-3, and the output at M3b-1 changes state from -V to +V. The action of D22 and the 38V(2) FAIL line are the same as for the 15V monitor.

7.8.6.4 400V Monitor

The 400V Monitor is in two mirrored halves, each dealing with its own polarity of the supply, so only the positive half is described.

Zener D9 provides the +2.45V reference on the non-inverting input at M3d-12. The divided +400V is sensed across R16 at a normal operating voltage of +3.27V (referred to common-2C) and applied to the inverting input at M3d-13, thus setting the output at M3d-14 to the V- rail voltage. D20 is reverse-biassed so the 400V(2) FAIL voltage is pulled to logic- \emptyset (-15V) by R7.

If the +400V supply fails by falling below +300V, the voltage across R16 falls below the +2.45V reference and the M3d-14 output switches to the V+ rail voltage. D20 conducts, pulling the 400V(2) FAIL line at J9-106 to logic-1.

In normal 400V operation R31 is shorted by the 400V/50V switch on the Mains (line) transformer, via the 'Lo SUPPLY A' and 'Lo SUPPLY B' lines. When the switch is set to 50V, the Lo SUPPLY A line is connected to -15V, effectively disabling the monitor output by holding the 400V(2) FAIL line at logic-Ø.

The output line gives an input via D3 to the 400V enable logic (described in *sub-section 7.12.5*). Its effect is as for a 15V failure.

7.9 1000V RANGE

7.9.1 INTRODUCTION

7.9.1.1 Power Signal Processing

Method

The 1000V DC Range obtains its high voltages by using the 100V power amplifier to drive an AC signal into the primary of a step-up transformer. The AC signal is derived by modulating a 16kHz reference with the DC ERROR signal.

Error Signal Conditioning

The '10V+100V+1000V DC ERROR' signal is pre-conditioned by the VCA Drive circuitry in the DC assembly, before it enters the Power Amplifier. The 10V Amplifier is bypassed.

High AC Voltage Generation

The modulated 16kHz signal is passed from the DC modulator into the 100V Amplifier, where it is scaled up by a factor of -100, the amplifier output being delivered via the 'OUTPUT' line to the HF Transformer assembly.

Rectification and Output

The stepped-up secondary voltage is rectified and filtered in the High Voltage assembly:

- A constant-current source acts as a shunt to sustain the current drawn from the high-voltage secondary winding through the bridge rectifier. Polarity is switched with respect to common-2 via the LC-filtered 38V common-2 supplies. Positive polarity output is referred to -38V at zero output, to overlap with negative polarity output referred to +38V. The overlap allows digital calibration constants to be used to align zero voltage output in both polarities to the same calibrated zero.
- The main output filter is placed in the output line. This is a low-pass filter with a high rejection at 16kHz, reducing the ripple voltage to within specification limits.
- The output voltage is fed out through the Range switch on the DC assembly, where it is subject to Remote Sense and Output On/Off switching, before being passed to the I+ terminal by the same route as for low voltage ranges. High voltage status is detected on the DC assembly as described in *para* 7.3.8.2 for the 1V Range.
- The external current is sunk into common-2 via the overcurrent detector, which warns the control processor when the output current exceeds approximately 28.5mA (see para 7.3.8.1). On the 1000V range the processor will switch the output off on receipt of the overcurrent signal from the overcurrent detector.

7.9.1.2 Sense Loop

Sense Attenuation

The sensed output voltage from the Hi and Lo terminals is reduced down to 'DC Ref' levels by a guarded precision attenuator on the DC assembly, and then applied to the inverting input of the Error Amplifier:

- The Lo terminal and Sense Attenuator Lo are both referred to Common-1 (DC Ref Lo). The attenuator is dual-purpose, being used for both 100V and 1000V ranges. The Hi sense voltage is divided in the Sense Attenuators by 10 (100V Range) or 60 (1000V Range).
- The attenuated output is compared against DC Ref Hi in the Error Amplifier, modifying its output to the VCA Drive.
- The 10V Bootstrap, in addition to supplying the Error Amplifier, also buffers DC Ref Hi as reference for the VCA Drive circuit.

Error Conditioning

The bipolar DC error voltage between the buffered DC Ref Hi and the Error Amplifier output is converted by a switched precision rectifier in the 'VCA Drive', to provide a suitable unipolar control signal for the DC modulator. The buffered output from the rectifier becomes the '10V+100V+1000V DC ERROR' signal which adjusts the amplitude of the 1000V Range outputs.

Loop Action and Reference Scaling

The Sense loop thus stabilizes the 1000V Range DC output to a value which is 60 times the DC Ref voltage, this value being determined by the division ratio of the precision sense attenuator. The DC Ref voltage is scaled digitally so that Full Scale of 20V corresponds to 1100V on the OUTPUT display and at the output terminals.

7.9.2 1000V RANGE POWER ROUTING

7.9.2.1 DC Reference and Error Amplifier (Circuit diagram 430536 Page 115-1)

The DC Ref signal is derived as for the 1V range, entering the DC assembly at the same pins: J5 pins 1, 2, 3 and 4. Relay RL18 again connects the power and sense lines to the two star-points TP2 and TP3, the latter being the signal Common-1 point.

On the 1000V range, RL16-8/9 connects the full DC Reference to the non-inverting input of the Error Amplifier, which operates as for the 1V range, except that the span of voltages is now the full -20V to +20V.

The Error Amplifier output is blocked from the 1V Buffer by the open contacts 10/11 of RL16. Instead, it passes as input to M15-5. The error signal is conditioned by the VCA Drive circuit M15/M14 and passed to the line buffer at M14-5. For the 1000V range, M14 is connected as a non-inverting line buffer by contacts 8/4 and 9/13 of energized relay RL6. M14-7 output passes to the Power Amplifier assembly via J5-73 and the Mother assembly.

7.9.2.2 Power Amplifier Routing

(Circuit Diagrams: 430618 pages 11.9-2 and 11.9-3)

DC Error' enters the Power Amplifier assembly at J9-40 (Refer to *page 11.9-2*). Relay RL3 remains un-energized, shorting across the 10V Amplifier input. The DC Error signal is routed via link LK.W and TP14 to the 1kV DC Modulator at R78. The route to the 100V Amplifier input as signal '100V I/P' via RL4-11/13 is blocked by the open contacts 8/4 of unenergized relay RL2 (*page 11.9-3*).

The output from the modulator is a 16kHz AC signal at TP15 whose amplitude is determined by the value of the DC Error signal. With RL1 unenergized on the 1kV DC Range, this AC signal passes via RL1-11/13 contacts to the '1kV ERROR O/P' line.

RL2-6/4 contacts (page 11.9-3) apply the signal to the Gain Stage, which provides drive to the power amplifiers in the positive and negative heat sinks, via J3-12 and J3-11. The single-ended output from the heatsinks at J3-9 passes via the OUTPUT line to the 1kV ENABLE relay contacts RL6-8/9 (page 11.9-2). RL6 is energized, and RL7 is unenergized on the DC 1kV Range, so the OUTPUT line is connected to J5-3 (PA assembly) and out as a direct link to the High Frequency Transformer assembly.

7.9.2.3 High Voltage Assembly Routing (Circuit Diagram 430537 page 11.14-1)

The high voltage output from the secondary of the HF transformer is input to the High Voltage assembly between its J2-1/2 and J2-8/9. After rectification, polarity switching and filtering, the DC 1kV signal is output via J1-2/3 to pin L on the Mother assembly, where it is again filtered before passing to the DC assembly on J5-33/34.

7.9.2.4 DC Assembly Power and Sense Routing (Circuit Diagram 430536 page 11.5-1)

On the DC assembly, the DC 1kV signal line is fused at 1A by F5, and the signal is routed through RL7-5/4. At this point the voltage is also used to energize the attenuator guard network R15 etc. It is routed to the PHI(DCV) line through RL7-10/11, then out to the I+terminal and back from the Hi terminal on the SHI(DCV) line as for the 1V range. The current returning from the I- terminal is sunk into common-2 via the overcurrent detector R56 (see para 7.3.8.1).

SHI(DCV) is range switched on to the HV attenuator R17 etc. by RL7-8/9, the reduced voltage being taken off through RL9-10/11 and applied to the inverting input of the Error Amplifier.

7.9.3 VCA DRIVE CIRCUITRY (Circuit Diagram 430536 page 11.5-1)

The attenuated sense signal is applied to the inverting input of the Error Amplifier via RL9-10/11. This bootstrapped, high gain circuit compares the sense signal with DC Ref. When both are equal; the output at M20-6, the bootstrap common BS at TP1, DC Ref Hi and the sense signal are all at the same level. Therefore the differential input to the error buffer-comparator M15 is zero at M15-6/5.

The second M15 stage acts as a bipolar-unipolar switch which adapts the bi-polar action of the Error Amplifier to the unipolar sensitivity of the DC modulator:

- With the front panel OUTPUT ON+ LED lit, the POSITIVE control signal is at logic-1 (0V). FET Q1 conducts, setting the M15-3 non-inverting input to zero volts, so the amplifier inverts the input at M15-2.
- Alternatively, if the OUTPUT ON- LED is lit the POSITIVE signal is at logic-Ø (-15V), cutting off Q2. M15-3 follows the M15-7 voltage, so the amplifier acts as a voltage follower.

The gain from M15-7 to the I+ terminal is approx. x2000. R87 and C40 at the Error Amplifier input; and R40, C21 on the first stage of M14; provide frequency compensation for the overall loop.

For the 1000V range, the second M14 stage is connected as a noninverting line buffer by contacts 8/4 and 9/13 of activated relay RL6. The output from M14-7 passes to the Power Amplifier assembly via J5-73 and the Mother assembly.

7.9.3.1 Action of VCA Drive Circuitry

If a user increases a positive OUTPUT display value, the positive DC Ref Hi voltage will increase (this is a demand to increase a positive output voltage). The polarity switch inverts the positive input from M15-7, so M15-1 feeds a negative output to M14. This is inverted at M14-1 and then buffered by voltage follower action at M14-7. It is passed via the Mother assembly to the DC modulator on the Power Amplifier assembly as an increasing positive DC signal.

In the case of an increasing negative OUTPUT display value, the negative DC Ref Hi value will increase negatively. But now the POSITIVE signal is at logic- \emptyset (-15V), so the output from M15-7 is not inverted and remains negative as for positive outputs. The action of M14 is not altered, so an increasing positive signal is sent to the DC modulator as before.

In both of the above cases the signal sent to the DC modulator is increasing positively, and this will result in an increasing 16kHz amplitude input to the 100V Amplifier. All polarity information is lost, so has to be re-inserted after rectification of the step-up transformer output, by the polarity switch in the High Voltage assembly.

7.9.4 DC MODULATOR

7.9.4.1 16kHz Derivation (Circuit Diagrams: 430648 page 11.3-2; 430652 page 11.4-5; 430618 pages 11.9-5 /11.9-2)

The 13-bit counter in the Analogue Interface generates 16kHz at pin 14 of M16 (*page 11.3-2*). This is transferred into guard through optoisolator M3 on the Reference Divider (*page 11.4-5*). The 16kHz square wave, switching between logic-1 = 0V and logic- \emptyset = -15V, enters the Power Amplifier assembly on J9-61 (*page 11.9-5*).

Providing the 1kV range is selected, and the 'PA CLAMP' signal is at logic- \emptyset (-15V), the full 15V p-p squarewave passes via M6-4 and M9-10 to inverter Q41 (*page 11.9-2*).

7.9.4.2 DC Error Signal Processing (Circuit Diagram 430618 page 11.9-2)

The modulator operates by alternately charging the low-pass filter formed by R83, C83 and C84 via the series switch Q39, and discharging it through Q40.

The 16kHz MOD DRIVE squarewave alternates between logic-1 (0V) and logic- \emptyset (-15V). After inversion in Q41, the signal at its collector switches between the +15V and -15V rails. Positive half-cycles of the MOD DRIVE signal make Q41 conduct, switching Q40 off and Q39 on, so the DC Error voltage charges the filter. For negative half-cycles the conditions are reversed and the filter is discharged to Common-2.

The DC Error signal is always positive, due to the polarity switch on the DC assembly. Its amplitude depends on the difference between the conditioned output voltage and the DC Ref Value, but is limited to +12V by D75.

The filter reduces the 32kHz and higher harmonic content of the squarewave, while passing 16kHz with little distortion. Its output is buffered by source-follower Q42, before being AC-coupled to the 100V Amplifier by a high pass filter (formed mainly by C86 with the approx. 400Ω input resistance of the amplifier).

The near-sinusoidal 16kHz signal input to the 100V Amplifier has amplitude which is proportional to the value of the DC Error signal, so acts as an AC analog of the difference between the normalized instrument DC output voltage and the value of the DC Ref voltage. It is based on a mean of 0V, and is passed as the '1kV ERROR O/P' signal via RL1-11/13 and RL2-6/4 into the Gain Stage of the 100V Amplifier (*page 11.9-3*).

7.9.5 100V AMPLIFIER

(Circuit Diagram 430618 page 11.9-3) (For description refer to Subsections 7.8.3 and 7.8.4)

This operates as for the 100V range, but in this case the DC path simply maintains the zero offset of the AC signal, which is amplified along the AC path. The output signal 'OUTPUT' is fed from J3-9 to relay RL6 contacts (*page 11.9-2*) for application to the step-up transformer.

7.9.6 '1kV ENABLE' RELAY RL6 (Circuit Diagram 430618 page 11.9-2)

Relay RL6 allows the OUTPUT signal from the 100V Amplifier to energize the HF step-up transformer, providing the following conditions are met:

The 1kV Signal is at Logic- \emptyset :

This is a processor-controlled signal, set to logic-Ø when the instrument output is switched on, in the 1000V range.

The Watchdog has NOT 'Barked'.

The '1kV ENABLE' Switch S1 on the Power Amplifier assembly is set to 'ENABLE'.

S1 is situated below the left-hand ejector lever (viewed from the front of the instrument), facing the rear. It allows the high voltage to be switched off for servicing purposes. A red LED glows when all other conditions are met.

When RL6 is closed, the OUTPUT signal from the 100V Amplifier is switched through to the contacts of RL7.

7.9.9 CONSTANT-CURRENT ASSEMBLY (Circuit Diagram 430563 page 11.14-2).

7.9.7 LF/HF TRANSFORMER SELECTION

The two transformers are separately located, their secondaries being connected into the High Voltage assembly. The HF transformer is selected when RL7 is unenergized, its primary being returned to Common-2C. RL7 is energized to select the LF transformer.

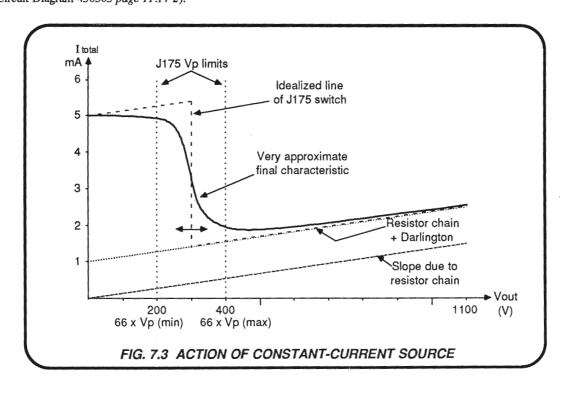
For the 16kHz signal used with the 1000V DC Range, the HF transformer is selected by RL7 being unenergized.

7.9.8 HIGH VOLTAGE TRANSFORMER AND RECTIFIER (Circuit Diagram No. 430537 page 11.14-1).

For the 1000V DC Range, the HF transformer gives a step up ratio of 1:6.17. This ratio generates secondary voltage outputs large enough to provide DC outputs from the instrument of 1100V. The AC relays RL2 and RL3 in the High Voltage assembly remain unenergized for the 1000V DC range, but the DC relay RL4 is energized, applying the HF transformer secondary voltage to the rectifier bridge via RL4-5/4 and RL4-2/3.

The rectifier bridge uses two series diodes in each arm. Each diode is current-rated at 1A, with a p.i.v. of 1.5kV.

N.B. The transformer secondary, and bridge rectifier are not directly referred to any common. This allows the rectifier output to float so that it may be used for either polarity.



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7.9.9.1 Constant-Current Source.

Q1-12 form a series Darlington chain, connected across the bridge rectifier output as a constant-current source, having two functions:

- It maintains conduction in diode bridge D56-D63 under no-load conditions.
- At higher voltages, D15-D17 limit Q11 base voltage to +2.4V, limiting the series current in R11, with Q13 pinched off. At lower voltages Q13 conducts, shunting R11 with 170-180Ω (R10 plus Q13 'On' resistance which falls to approx 125Ω), and increasing the discharge current. The approximate shape of the overall characteristic is shown in Fig. 7.3.
- NB Note that the minimum voltage applied across the constantcurrent source is 38V. Even at zero output voltage and current, the diode bridge generates 38V to back off the positive or negative 38V connected to RL3.

7.9.9.2 Overvoltage Detection

Zener diodes D1 - D13 form a series chain across the High Voltage supply. When the voltage exceeds 1440V this chain conducts, lifting D13 cathode and driving opto-isolator M1. M1 collector falls, turning on Q14, whose collector voltage rises to provide a 'LIM DET' logic-1 (0V) output at pin 5. This signal travels from the High Voltage assembly at J1-14, via the Mother assembly, to the Power Amplifier assembly at J9-69.

The operation of the LIM DET circuitry and subsequent action is described in *Section 7.12*.

7.9.10 POLARITY SWITCHING

(Circuit Diagram 430537 page 11.14-1)

Double-pole relay RL5 performs the polarity-reversal. With RL5 unenergized as shown the output filter is connected to rectifier positive, and the -38V Common-2 supply is connected to rectifier negative. During zero calibration, the -38V is backed off to give a true zero output by an output from the rectifier.

Relay RL5 is controlled by the Exclusive-NOR gate M4-2, under the influence of the CPU's 'POSITIVE' and 'PA CLAMP ON' signals from the serial data-link parallel output registers. When negative outputs are selected, providing the PA is not clamped; RL5 is energized, the output filter is connected to rectifier negative, and the +38V Common-2 supply is connected to rectifier positive. Again, the +38V is backed off by an output from the rectifier for all negative outputs, including zero.

The requirements which decide the use of the Exclusive-NOR function are discussed in *sub-section* 7.12.4.

7.9.11 OUTPUT FILTERING

The high voltage output is filtered in three stages:

- a. L3, R1, C1 and C2 together form a 2-pole low-pass filter, which attenuates 16kHz by approx. 30dB and 32kHz by approx. 42dB.
- **b.** L4, L5 and their associated capacitors form a 5-pole filter with elliptical characteristics, attenuating by at least 60dB above 16kHz.
- c. The final stage is formed by R10, with C1, R84 and R85 on the Mother assembly (Circuit Diagram 430604 *page 11.16-1*). This provides further attenuation of approximately 30dB at 16kHz and 36dB at 32kHz.

7.9.12 1kV DC OVERCURRENT

The overcurrent detector on the DC assembly operates on the 1000V Range identically as on the 1V Range. Refer to *para* 7.3.8.1.

7.9.13 1kV and 100V SENSE ATTENUATION (Circuit Diagram 430536 page 11.5-1)

Both ranges' output voltages are sensed on the SHI(DCV) line and reduced to 10V Range levels in the same guarded attenuator.

The 1000V Range output is developed across the full attenuator via relay RL7-8/9 contacts, and the guard chain is driven from the DC 1kV line via RL7-5/4.

The 100V output enters the attenuator at the tapping between R85 and R101 via RL8-9/8 contacts, the corresponding guard voltage being applied to the Guard chain via RL8-4/5.

The output tapping is common to both ranges, taken at the $900k\Omega/100k\Omega$ junction of R101. Thus the 1000V DC Range voltages are attenuated by 60:1, the 100V DC Range voltages by 10:1. The reduced output from the Sense attenuator is applied to the inverting input of the Error Amplifier.

Each junction between adjacent elements of the attenuator has its own guard screen. To eliminate leakage while providing an effective guard, a separate attenuator steps the power output voltage on the PHI(DCV) down to the correct voltage for each junction's guard screen.

The Sense attenuator sinks into Common-1, the 'reference' common to which the Error Amplifier and the 10V/1V attenuator are also referred. The guard attenuator sinks into Common-2, the general analog power common.

7.10 LOGIC CONTROL OF DC OUTPUTS

Two main aspects of analog control functions can be considered:

- The effects of the controls on the analog circuitry, which are discussed elsewhere in the descriptions of the relevant circuits;
- b. The methods of implementing the control logic, which have been developed to use the minimum number of control signals. It is also required to dissipate as little energy as possible inside the heat-shielding chassis assembly, to avoid temperature effects on the accuracy of the analog circuits themselves.

7.10.1 LOGIC LEVELS

In general, the analog control logic operates between 0V and -15V, with Logic-1 = 0V, and Logic- \emptyset = -15V. These levels are set originally at the serial/parallel control data latches in the Reference Divider assembly as outputs from the serial data link, and are accepted by the parallel/serial status data latches as inputs to the link back to the CPU. Some special control signals are passed into guard via opto-isolators, also in the Reference Divider, operating between - 10V and -15V. These are subsequently adjusted to the normal control logic levels.

7.10.2 HEAT REDUCTION

Two methods are used to ensure that the energy dissipated by the relays is minimized:

Use of bistable latching relays.

Use of an 'Update' signal;

7.10.2.1 Update Considerations

For some heat-sensitive environments within the chassis assembly, polarized bistable latching relays are used which only require actuation, and hold on without a solenoid supply. Where relays need hold-on energization, they are usually tied to 0V or +15V on one side, and controlled on the other by the uncommitted collector of an inverting Darlington driver. Thus when the input to the driver is logic-1, the relay is held energized by its -15V output; and when the driver input is logic- \emptyset , its output is high impedance, releasing the relay.

For some relays it is necessary to hold the full actuating voltage across the solenoid for the whole time that it is energized. But where periodic updating will not cause difficulties, a relay is held on between 0V and -15V, raising the 0V side to +15V to actuate it during an update. Such relays have a secure hold-on voltage of approximately 12V, but require 20V or more to pull them in.

At intervals of 40ms (typically - depending on the priorities of the CPU's program), the CPU generates a data transfer across the serial interface, and an 'Update' signal is passed into guard by the CPU via an opto-isolator (M4 in the Reference Divider - *page 11.4-5*). This serves two purposes:

- It is mainly provided to ensure no delay in transferring important status data back to the CPU;
- It is available when it is required to update the analog state of the instrument functions, as demanded by reversionary modes or user inputs.

After passing into guard, the update signal is named 'UPD(IG)'

7.11 DC ASSEMBLY RELAY DRIVES AND LOGIC

7.11.1 INTRODUCTION

(Circuit Diagrams 430536 page 11.5-3 and 430668 page 7-23).

The analog circuitry is mainly controlled by low-thermal relays, many contacts being fitted back-to-back to further reduce temperature effects. For the fastest response, the output relay RL15 is not latched, but can trip out quickly if the power supply fails, removing any output voltage from the terminals.

The rest of the relays are latched, allowing hold-on without power, to reduce the internal temperature at their contacts. As they are polarized they require a bipolar actuating drive, which is provided by Tristate' relay drivers and a bias amplifier.

7.11.1.1 Latched Bistable Relays (Circuit Diagram 430536 page 11.5-3).

As can be seen from the circuit diagram on *page 11.5-3*, the relays are strung out between the output of their bias amplifier (-7.5V approx. at M1-2) and the drive outputs from the Clamp assembly.

The bias amplifier M1 is a frequency-compensated voltage follower, buffering the tapping of attenuator R4/R5, to hold one side of each relay permanently at -7.5V. The relay drivers on the Clamp assembly can provide outputs at 0V or -15V when enabled by the $\overline{UPD(IG)}$ pulse, but return to tristate when disabled. A relay is therefore driven to one or the other of its bistable states during update, then latched in the chosen state when the driver output returns to open-circuit.

All the latched relays operate in the same polarity sense: when its driver output updates at logic-1 (0V), the relay latches to select its nominal function; for a logic- \emptyset (-15V) update, the function is deselected. In the analog circuit diagrams, the relay contacts are shown in their deselected state, equivalent to the un-energized state of a conventional non-latching relay. For consistency, in the analog descriptions relays are referred to as being 'energized' or 'unenergized'.

7.11.1.2 'Tristate' Relay Drivers (Circuit Diagram 430668 page 7-23).

The relay drivers (M1, M2, M3 on the Clamp assembly) are octal 'Tristate' buffers. Each chip is served by two inverted enable inputs on pins 1 and 19 (four buffers - half the chip - per enabling input).

Whenever a switching command has been received, the CPU performs a control data transfer and the $\overline{\text{UPD}(\text{IG})}$ line from J5-104 is pulsed to -15V for 50ms.

The switching logic places a logic-1 (0V) on the input of selected drivers, and logic- \emptyset (-15V) on those whose function is not selected. Because all the buffers are non-inverting, during the update pulse a driver selects its function by setting its output voltage to 0V, or deselects by pulling its output voltage to -15V.

7.11.2 CLAMP ASSEMBLY (Circuit Diagrams 430536 page 11.5-3

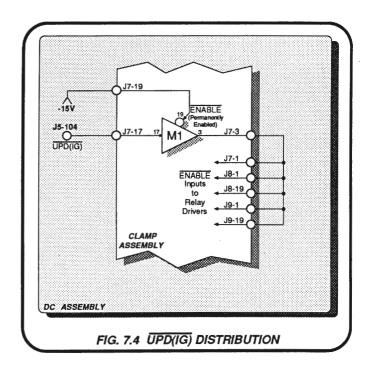
and 430668 page 7-23).

On the DC Relay Drive Logic circuit diagram (page 11.5-3) the Clamp assembly is shown in block form. Also, the pcb pin numbers correspond to the pin numbers of the buffer chips: J7, J8 and J9 being the connections to M1, M2 and M3 respectively. For signals crossing the block from left to right, the output of each non-inverting buffer is drawn opposite its input, so the function remains unchanged as it crosses the block. As a further aid to identification, the pins of any one buffer are numbered so that the input and output numbers add up to 20.

7.11.2.1 UPD(IG) Distribution

As the $\overline{UPD(IG)}$ signal is distributed as the enable to many buffers, it is itself buffered before being fanned out. So the four $\overline{UPD(IG)}$ connections at the top of the block are inputs to four buffers (M1) which are permanently enabled by J7-19 at -15V. The outputs of two of these buffers are brought out to J7-5 and J7-7 which are not connected (and not shown on the circuit diagram).

The input at J7-11 emerges from the Clamp assembly at J7-9 to operate the driver for the non-latching relay RL15 (at M2-6). The fourth input at J7-17 emerges at J7-3, and is reconnected as the fanned-out enable to the other buffers on the assembly (see Fig. 7.4).



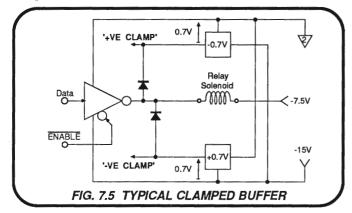
7.11.2.2 Buffer Clamping

(Circuit Diagram 430668 page 7-23).

The 40244 octal buffer can be sourced from several manufacturers. Some variants are protected against SCR avalanche if the output voltage were to exceed the rail voltage, but some are not. Each buffer drives its output into the solenoid of a relay, and is switched on and off by the update enable. The self-inductance of the solenoid can generate back EMF's well in excess of the rail voltage, so to guard against the possibility of catastrophic failure, it was decided to provide external protection in the form of a clamp circuit.

On the Clamp assembly Q1-Q4 form two power supplies, each delivering a regulated voltage of a diode-drop less than the rail voltage ('+VE CLAMP' and '-VE CLAMP'). A diode connected from the buffer output to each of the clamp lines permits the output voltage to rise to, but not exceed, the rail voltage (see Fig. 7.5).

Where two buffers are used in parallel to drive two relays, the clamp diodes can be omitted from one buffer output (eg. M2-9 and M2-7 are joined on the DC assembly between J8-9 and J8-7, so both are clamped).



7.11.3 DC ASSEMBLY SWITCHING LOGIC (Circuit Diagram 430536 page 11.5-3).

The analog-control signals are transferred into guard on the Reference Divider assembly, and latched as 'Q' outputs in the Serial/Parallel Data Converter. Offset positive logic is employed (Logic- \emptyset = -15V, Logic-1 = 0V) for the signals entering the DC assembly via J5 from the Mother assembly. For general analog control considerations refer to *Sect. 7.10*.

7.11.3.1 Range Switching Logic

Range control data is input as a 3-bit code on DCRØ, DCR1 and DCR2 lines. The bit-pattern is decoded by M4 to select the correct range relays. As the 100μ V, 1mV, 10mV and 100mV ranges all use the same analog circuitry, only one bit-combination (DCR2) is required for these four ranges. The resulting five combination variations are listed in Table 4.1 against the range selections, showing the states of M6 'Q' output pins and the relays energized for each range.

Note that deselection of DC function sets each DCR(2-Ø) to logic-1. The M6 'Q' outputs all fall to logic-Ø, deselecting all range relays except RL1, RL2, RL3 and RL16, which are selected by DCR2 being at logic-1.

7.11.3.2 Function and Output Switching Logic

Output voltages are passed through the DC assembly on all AC and DC ranges. RL15 connects the SHi, SLo, PHi and PLo to the Hi, Lo, I+ and I- terminals of the instrument. Four signals control this relay:

OFF at logic-Ø when Output is selected ON. BARK DEL at logic-Ø unless the watchdog has tripped. AC FUNCT at logic-Ø if AC Function is selected, or DC FUNCT at logic-1 if DC Function is selected.

Under these conditions M4 pins 1 and 2 are set to logic-1, M4-9 is at logic- \emptyset ; M4 pins 3, 4 and 5 are at logic- \emptyset , M4-6 is at logic-1. So M2-2 is driven positive, and as M2-3 is biassed at about -4.75V, then M2-1 goes to approx. -12V. During the update pulse J7-9 goes to -15V, so M2-7 goes to +15V. RL15 is thus actuated by some 27V, but after the UPD(IG) pulse is terminated, M2-7 returns to 0V and RL15 is held on. If AC and DC are both deselected, or if the output is set to OFF, or if the Watchdog barks; the -12V at M2-1 reverts to approx. +11.5V. If the UPD(IG) pulse is not present, the voltage across RL15 falls through zero and RL15 is de-energized. If it is present, only approx. 4.5V is connected across RL15, which is insufficient to hold the relay on. Under these conditions the instrument terminals are disconnected from the output.

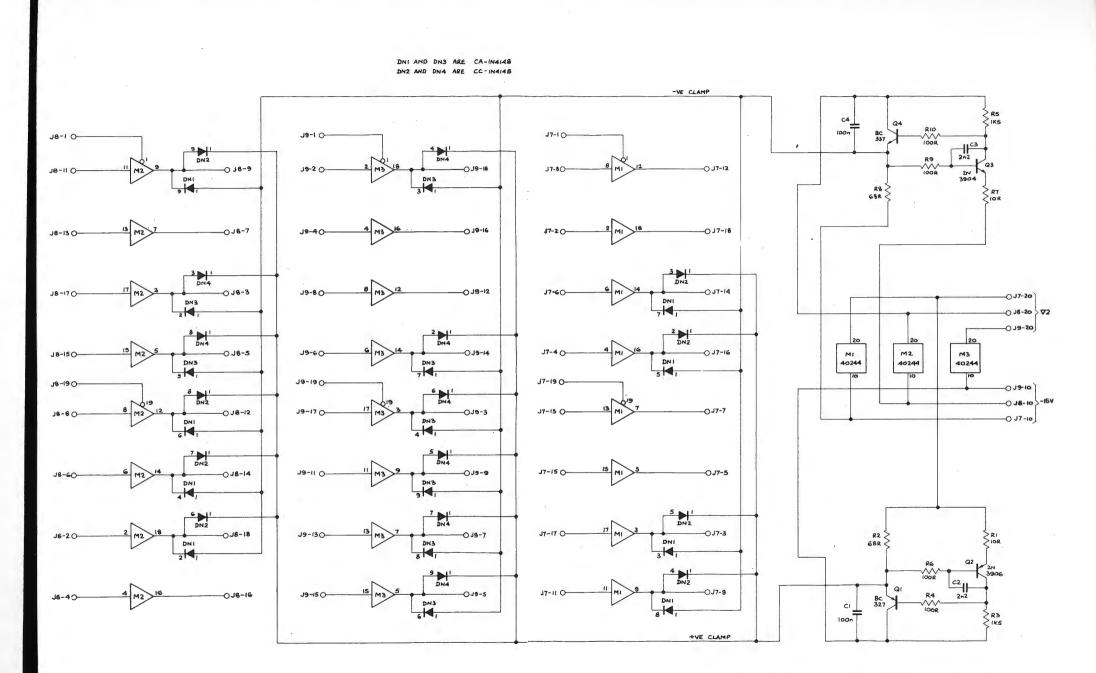
Relays RL10 and RL18 are selected when DC voltage has been commanded, providing that the Watchdog has not barked. With DC FNCT at logic-1, M4-11/13 are at logic-Ø. If the Watchdog has not barked then BARK DEL is logic-Ø at M14-12. As a result of both these conditions, M4-10 is at logic-1 and both relays RL10 and RL18 are selected. RL10 connects the PHI(DCV) and SHI(DCV) line to the PHI(V) and SHI(V) lines respectively, RL18 connects the DC Ref output from the Reference Divider to the DC Error Amplifier input.

Relay RL11 connects the power and sense Lo lines back to their respective commons. Thus when RL10 and RL18 are selected for DC voltage outputs, so is RL11. But in Current Function it is also required to the Local Guard to Common-2. This also is done by selecting RL11. With Current Function selected, the I FNCT signal is at logic-Ø so M3-13 is at logic-1 and RL11 is selected.

The Remote Sense Relay RL14 is also selected by the $\overline{I \text{ FNCT}}$ signal, as well as by the front panel selection of remote sense. These are combined at OR-gate M10-3, before selecting RL14 directly via its buffer. RL14 removes the local sense short between the power and sense lines at both Hi and Lo signal levels. For Current Function this has negligible effect on the DC assembly, but the REM SENSE '+' and '-' signals are also passed out to RL1 on the Mother assembly (*page 11.16-1*). Although remote sense is not selectable for DC or AC Current ranges, it is necessary to route the current output to the I+ and I- terminals on the front panel. RL1 on the Mother assembly is energized to do this. (For Local Sense on voltage ranges, RL1 routes the power Hi line to the Hi terminal instead of I+).

REM GU selects the Remote Guard relay RL17 via its buffer.

The HIGH I LIMIT and AC 1kV RANGE signals are concerned with the AC 1kV Overcurrent Detector circuit. The signals operate their relays RL12 and RL13 directly through their buffers. *Section 9* discusses their effects. The effects of control signals '1kVDC', '100VDC', 'DC FNCT' and 'POSITIVE' are discussed in the descriptions of the analog circuitry at their destinations.



DC CLAMP CIRCUIT Drawing 430668

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7.12 PA ASSEMBLY LOGIC AND RELAY DRIVES

(Circuit Diagrams 430618 Pages 11.9-4 and 11.9-5)

The CMOS logic operates between the levels 0V and -15V, with logic-1 = 0V, and logic- \emptyset = -15V. Relays are tied to +15V on one side, and controlled on the other by the uncommitted collector of an inverting Darlington driver. Thus when the input to the driver is logic-1, the relay is energized by 15V; and when the driver input is logic- \emptyset , its output is high impedance, releasing the relay.

7.12.1 DC RANGE SWITCHING (Page 11.9-5)

The three inputs DCRØ, DCR1 and DCR2 carry the DC range switching information, and are decoded by M7a as follows:

	M	M7a inputs E B A CR2 DCR1 DCRØ 0 0 0 0 0 1 0 1 0 0 1 1			M7a outputs			
		-		Q2	Q1	QØ		
Range								
Select	DCR2	DCR1	DCRØ					
1000V	0	0	0	0	0	1		
100V	0	0	1.	0	1	0		
10V	0	1	0	1	0	0		
1V	0	1	1	0	0	0		
100mV	1	0	0	0	0	0		
10mV	1	0	0	0	0	0		
1mV	1	0	0	0	0	0		
100µV	1	0	0	0	0	0		
Deselect DC	1	1	1	0	0	0		

7.12.2 AC RANGE SWITCHING (Page 11.9-5)

The three inputs ACRØ, ACR1 and ACR2 carry the AC range switching information, and are decoded by M7b as follows:

	M7	b inpu	ts	M	7b outp	outs
	E	B	Α	Q2	Q1	QØ
Range						
Select	ACR2	ACR1	ACRØ			
1000V	0	0	0	0	0	1
100V	0	0	1	0	1	0
10V	0	1	0	1	0	0
1V	0	1	1	0	0	0
100mV	1	0	0	0	0	0
10mV	1	0	1	0	0	0
1mV	1	1	0	0	0	0

7.12.3 FUNCTION AND RANGING LOGIC

DCV Logic

When un-energized, relay RL4 selects the DC ERROR signal in preference to the AC 1V signal, as input to the Power Amplifier when DC Voltage function is selected. When un-energized, Relay RL8 reduces the permissible overload on the output of the 10V Amplifier, also when DC Voltage is selected.

When 'DC' is selected on the front panel, both DC FNCT (J9-70) and \overline{I} FNCT (J9-72) signals are at logic-1. Under these conditions both inputs to NAND M6-12/13 are at logic-1, so M6-11 is at logic- \emptyset and both relays RL4 and RL8 are un-energized. For all other function selections DC FNCT is at logic- \emptyset , so M6-11 is at logic-1 to energize both relays.

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AC & DC 10V Range Logic

On the DC 10V Range only, the input to M6-1 is logic-Ø; and on the AC 10V Range only, the input to M6-2 is logic-Ø. Logic-1 occurs at M6-3 to operate relay RL3 only when either the AC or DC 10V range is commanded.

AC & DC 100V Range Logic

The input to Q12-8 is logic-1 only when the DC 100V range is selected, and the input to Q12-9 is logic-1 only on the AC 100V range. Either input gives logic-1 at M12-10, so relay RL2 operates only when either the AC or DC 100V range is commanded.

AC 100V Range Logic

A '100V AC' signal is also passed to activate the 100V Current Sense circuit (see page 11.9-6), only on the AC 100V Range.

DC 100V Range Logic

The decoded DC 100V Range signal at M7a-5 is also connected to the cathode of D31. On other ranges the diode conducts to pull the DC INPUT CLAMP signal to logic- \emptyset (Off), but on the DC 100V Range D31 releases the line so that the PA CLAMP ON signal can set it to logic-1 (On).

AC & DC 1000V Range Logic

The 1kV signal enters the Power Amplifier at J9-32. It is at logic- \emptyset only when AC or DC 1000V Range is commanded by the CPU, with the OUTPUT set ON. 'BARK' enters at J9-66, and is at logic- \emptyset only if the watchdog has not detected a failure (see Sect. 6). With both inputs to M4-8/9 at logic- \emptyset the output at M4-10 is logic-1 which lights the internal warning LED D70. Relay RL6 is energized if the internal 1kV ENABLE switch on the PA assembly is set to its normal operating position of ENABLE. This allows the AC drive to be passed to the step-up transformers (16kHz signal in the case of the DC 1kV Range, to the HF transformer).

For other ranges, or if the watchdog barks, RL6 is de-energized, removing the AC drive to the step-up transformers. LED D70 is also de-energized.

AC 1000V Range Logic

The input to M13-3 is logic-1 to energize relay RL1 only when the AC 1000V range is commanded. A 'AC 1kV RANGE' signal is also passed to the DC assembly to select the overload sense resistor.

DC 1000V Range Logic

Although the combination of the universal $\overline{1kV}$ Range signal and the AC 1kV signal is used to define the DC 1kV circuitry, two extra facilities are required for the DC 1kV Range. The 16kHz REF FREQ signal has to be switched to the DC modulator. For negative outputs on the 100V Range the 100V Amplifier positive rail is reduced to +38V instead of the +400V supply, so this has to be restored to +400V for the AC signals on the 1kV Range. For these applications the decoded DC 1kV Range signal at M7a-4 is used as input to M4-6 and M6-6.

The REF FREQ signal enters at J9-61 and is enabled at M6-5 by the 1kV Range decode on M6-6. Provided that the PA CLAMP ON signal is Off (ie. at logic-Ø), the 16kHz 'MOD DRIVE' signal is passed to the 1kV DC Modulator (see page 11.9-2).

The POSITIVE signal entering at J9-41 is input to M4-5 and the 1kV Range decode is input to M4-6. If a negative output on the 100V Range is commanded, then both inputs are at logic- \emptyset . The output at M4-4 is logic-1 and M15 causes the LED in M16 to conduct by pulling M16-3 to logic- \emptyset . The photo-transistor of M16 conducts (*see page 11.9-3*), placing a short circuit between the source and gate of Q20, which turns off the +400V supply to the 100V Amplifier driver stage. Q9 conduction causes D56 to conduct, so for negative outputs on the 100V Range the positive rail for the driver is sourced from the +38V supply.

On the DC 1kV Range the +400V supply is required to deal with the AC signal being amplified, so M4-6 at logic-1 inhibits the disabling photo-coupler; M13-15 being open-collector. The same inhibition results for positive outputs on the DC 100V Range (when the +400V is needed to power the driver stage) by M4-5 at logic-1.

7.12.4 'PA CLAMP ON' SIGNAL

PA CLAMP ON is applied before the 1kV DC control loop is broken by the 1kV line, and released when the loop is restored. It is also required on entry into and exit from the 100V DC Range. Other ranges are 'don't care' states.

7.12.4.1 DC 1000V Range Clamp

When the DC 1000V Range is selected, but Output is set Off, the drive is removed from the input to the step-up transformer. The High Voltage assembly polarity relay RL5, in the positive position, connects -38V to the base of the Constant Current chain at Pin 2. The other end of the chain is connected, via the instrument output lines, to the head of the 1kV sense attenuator on the DC assembly. The attenuator output is fed to the inverting input of the Error Amplifier.

Under these conditions, the Error Amplifier 'sees' a negative voltage at the Output terminals, and would drive heavily into saturation on its positive side to correct the output. This would occur regardless of the size of the positive DC Ref voltage being applied on its noninverting input. When the positive Output was reset to On, the power circuitry could generate a massive swing which would result in catastrophic failure. A similar (but polarity-reversed) effect could be present for negative DC Output selections.

This excess loop gain is removed by reversing the position of the polarity switch during the time that the output is turned off, so that the Error Amplifier sees a positive voltage and backs off toward zero. The logic to reverse the polarity is driven by the PA CLAMP ON and POSITIVE signals, employing an exclusive-NOR gate.

In the High Voltage assembly, M2-4 feeds the driver for the polarity changeover relay RL5. The inputs at M4-5 and M4-6 are POSITIVE and PA CLAMP ON respectively.

The required reversal conditions are satisfied as shown:

Selected 'P Commands	OSITIVE'	PA CLAMP ON	M2-4 State	RL5 State	Nominal Output Polarity
-VE•O/P ON	ø	ø	1	Energized	-ve
-VE•O/P OFF	Ø	1	Ø	Un-energized	+ve
+VE•O/P ON	1	ø	Ø	Un-energized	+ve
+VE•O/P OFF	1	1	1	Energized	-ve

The PA CLAMP ON signal at logic-1 also disables the 16kHz MOD DRIVE signal to the DC Modulator.

7.12.5 '400V ENABLE' LOGIC

The '400V(2) OFF' signal from the CPU is normally at logic- \emptyset for voltage ranges; but after a 'FAIL 7' message indicates a 400V supply failure, it is toggled three times, attempting to restore the supply.

Thus in normal operation, BARK is logic- \emptyset and the PSI OFF signal from M11-4, also logic- \emptyset , is input to M1-1/6 (*page 11.9-4*). M1 consists of six inverting drivers, each with uncommitted-collector output (as used for the relay drivers). M1-1 at logic- \emptyset allows M1-2 to be pulled to logic-1 by AN1-1/2, or to logic- \emptyset by M1-14. In the lower chain with four inversions, M1-14 is also open-collector, if a 400V or 15V failure has not been detected by the monitors.

Thus for normal operation M1-2 is pulled to logic-1 and the 'ENABLE 400V-' line from M1-15 is held at logic- \emptyset (-15V). With the 'ENABLE 400V+' line it energizes the opto-isolator LEDs in the 400V power supply (PS/I heatsink *page 11.13-3*).

A failure of either the 400V or 15V supply pulls M1-3 to logic-1, disabling the 400V supply by setting the ENABLE 400V- line to logic-1. If the +15V or -15V rail collapses, the opto-isolator current is cut off in any case, due to zener D24.

7.12.6 'BIAS OFF' LOGIC

On the 100V or 1000V ranges, after receiving a 400V FAIL signal from the monitor, the CPU attempts three times to restore the 400V supply. The foldback current limiting for the supply (in the PS/I heatsink) prevents reinstatement if an overload persists. Thus it is necessary to remove the overload if the supply is to be restored. This is done by setting the BIAS OFF line to logic- \emptyset (-15V), cutting off Q10 (*page 11.9-3*) and removing the output drive.

The three attempts are made by toggling the 400V(2) OFF line (described in *sub-section 7.12.5*). Each time the supply is enabled, R6 and C1 hold the BIAS OFF signal at logic-Ø for about 1ms to allow the supply to build up before the load is reapplied.

After three unsuccessful attempts, the CPU assumes a permanent hardware fault and holds the 400V(2) OFF signal at logic-1.

7.12.7 '<u>LIM ST</u>' LOGIC

This status signal is passed back to the CPU via the SSDA serial link to indicate that certain limits have been exceeded. The LIM ST signal entering the Reference Divider at J4-76 (page 11.4-4) can be activated to logic- \emptyset by any one of nine detectors, as illustrated in the simplified diagram of Fig. 7.6.

7.12.7.1 'LIM DET'

The $\overline{\text{LIM DET}}$ signal output from the Power Amplifier at J9-67 (*page 11.9-5*) can result from the LIM DET signal setting the latch M5a. LIM DET is associated with the high voltage ranges, and can be activated by:

- DC Assembly (page 11.5-1/2) AC 1kV Overcurrent Detector, DC Overcurrent Detector (100V & 1000V DC ranges);
- High Voltage Assembly (Constant Current Source) DC 1kV Overvoltage Detector;
- Power Amplifier Assembly AC 100V Overcurrent Detector, AC 1000V Overvoltage Detector. (These two combine to generate the 100V FLAG, which is NORed with 'DC FNCT' before becoming LIM DET.)

NOT100V FLAG is initiated by the AC 100V Overload Detector or AC 1000V Overvoltage Detector (*page 11.9-6*), whenever the 400V supply current peaks are excessive, or the AC 1kV Range drive voltage to the primary of the step-up transformer is excessive.

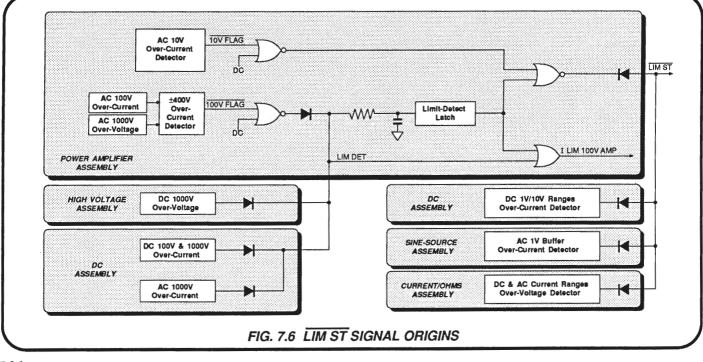
The LIM DET logic-1 is immediately transferred via M12-3 as the signal T LIM 100V AMP' to the gate of Q14 (*page 11.9-3*). Q14 conduction reduces the 100V amplifier input to zero, so if the overload is external the LIM DET signal should revert to logic-Ø.

7.12.7.2 'LIM ST' Generation

The latch M5a is set by logic-1 on pin 6, for as long as LIM DET remains at logic-1. Its 'Q' output activates the 'LIM ST' signal via M4-3, informing the CPU. It also reinforces and latches the 'I LIM 100V AMP' signal. LIM ST is also activated if the overload signal 10V FLAG from the 10V Amplifier is at logic- \emptyset when in AC 10V Range.

Other detectors which can provide the LIM ST signal are:

- DC Assembly (page 115-1/2) DC Overcurrent Detector (1V & 10V DC ranges);
- Sine-Source Assembly (Constant Current Source) AC 1V Buffer Overcurrent Detector;
- Current/Ohms Assembly
 DC and AC Current ranges Overvoltage Detector



7.12.7.3 CPU Response

On receipt of the $\overline{\text{LIM ST}}$ signal, the CPU initiates a series of clock pulses on the T LIM RST' line via the SSDA and Reference Divider, so that M5a can be reset as soon as the LIM DET signal clears to logic- \emptyset , M5a 'D' input being strapped to logic- \emptyset (-15V). The CPU also displays the 'Error OL' message.

If the LIM DET line has cleared to logic-Ø, the 100V Amplifier input is reinstated by M5a being reset. Furthermore, if the overload was temporary, the LIM DET line remains at logic-Ø, and normal operation resumes. The CPU is informed by LIM ST at logic-1, so the I LIM RST pulses are discontinued, and the Error message is removed.

For a persistent overload, the detectors operate once again. The cycle repeats until user action is taken to remove the overload. The Error message continues to be displayed.

If the overload is an internal fault, it is likely that another protection circuit will have detected it and taken its own action.

7.12.8 'LF', 'LF' and '1kV GAIN'

These are signals used to control the gain and compensation of the AC 1kV amplifiers, (*Refer to section 9.*?).

The 'LF' signal is set to logic-1 by the CPU via the SSDA serial link and Reference Divider latches, when the AC 1000V range and the 100Hz or 1kHz frequency ranges are selected. It is inverted as $\overline{\text{LF}}$ at M11-12, and then inverted as buffered 'LF' at M11-10.

'FREQ RØ' is also CPU-controlled. It is set to logic-1 when either the 1kHz or 100kHz frequency range is selected.

' \overline{LF} ' and 'FREQ RØ' are combined at M6-10 to give the '1kV GAIN' signal, which is at logic-Ø only when the 100kHz range is selected. (The software prevents the 1MHz range being selected on the 1000V range).

7.12.9 THERMISTOR COMPARATOR

Two NTC thermistors situated in different positions on each PA heatsink are part of a bridge network which detects excessive temperatures on the heatsinks.

(Para 7.8.4.3 and pages 11.13-1/2 refer.)

The reference arm of the bridge is formed by R165 and AN9-7/10 in parallel, both in series with AN9-6/11.

The sense arm has four parallel sections, each consisting of one section of AN9 in series with one of the NTC thermistors. Four null detectors are used (M22 and M23), each comparing the voltage at the reference arm junction with that at the junction of one of the sections (TEMP +R/-R/+F/-F).

At 25°C each thermistor resistance is $10k\Omega$. The bridge is unbalanced in favour of open-collector outputs from the four comparators, pulled up to Common-2 by AN2-3/4 and AN2-5/6. Q36 is therefore cut off, and the 'OVERTEMP' signal at J9-31 is at logic- \emptyset (-15V).

If one of the chip temperatures exceeds 100°C, its thermistor resistance falls to the extent that the bias on its null detector is reversed. The null detector output is taken low to -15V, Q36 conducts and the OVERTEMP signal goes to logic-1.

The OVERTEMP status signal is passed to one of the Reference Divider status registers, (*page 11.4-4*), where for safety reasons it is pulled-up by a 1M Ω section of AN2. The CPU reacts to the logic- \emptyset signal by displaying the 'FAIL 1' message, and forcing a recovery sequence:

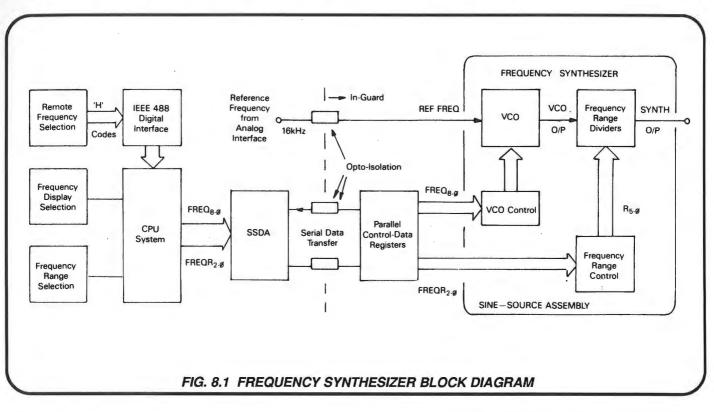
OUTPUT OFF;

Reference Divider ramp to zero; Remote Sense OFF; Analog Control 'OFF' bit set; Analog Control '1kV' line disabled; Display and Keyboard locked;

After approximately 1 minute, the CPU defaults the instrument to the normal 'OUTPUT OFF' state in the selected ranges with output set to zero. The FAIL 1 message is removed, and the user is at liberty to try another attempt.

Under normal power-up conditions, with the Power Amplifier assembly plugged in and Q36 cut off, AN2-7/8 holds the line more negative than -14V (logic-Ø). If the Power Amplifier is removed, no over-temperature information is available from the heatsinks. In this event, the OVERTEMP signal rises to logic-1, indicating failure.

SECTION 8 AC VOLTAGE OUTPUTS - FREQUENCY CONTROL SYSTEM



8.1 DIGITAL FREQUENCY SYNTHESIZER (Fig. 8.1)

8.1.1 GENERAL

Users normally set the operating frequency by a combination of 'FREQUENCY RANGE' and 'FREQUENCY' display selections. These are memorized by the CPU and translated into two binary control words:

'FREQ R2-Ø'

A three-bit word, five of whose codes represent the five frequency ranges.

'FREQ8-Ø'

A nine-bit word whose value 'n' defines the chosen frequency with respect to the selected frequency range.

Users can select a frequency by means other than pressing a FREQUENCY RANGE key and setting a frequency on the display; for example by using 'Store' or the IEEE 488 digital interface. But regardless of the selection method, the CPU will always compute the two binary words, which then synthesize the selected frequency in the Sine-Source Assembly.

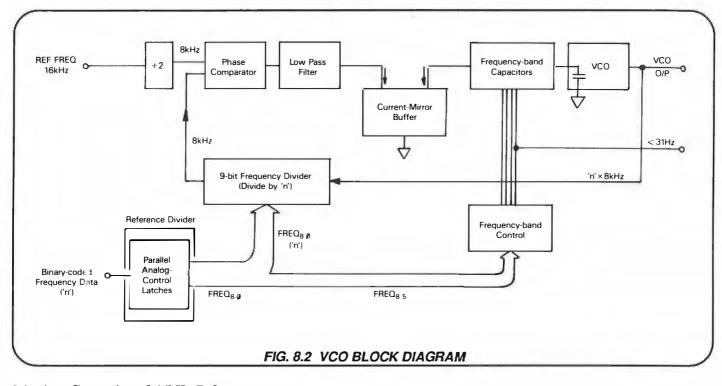
Both words are passed into guard via the SSDA, and latched at the outputs of the Reference Divider Parallel Control registers. A 16kHz reference frequency is also taken into guard, to be divided by two to 8kHz in the Sine-Source assembly.

After entering the Sine-Source assembly, $FREQ_{8-\emptyset}$ effectively multiplies the 8kHz reference by a factor 'n' to determine the frequency of a Voltage Controlled Oscillator (VCO). The VCO frequency (signal 'VCO O/P') is input into a series of frequency dividers, whose ratios are set by FREQ R_{2- \emptyset}. The division ratios are chosen so as to make the dividers generate the Frequency Synthesizer output signal ('SYNTH O/P') at the user-selected frequency.

The purpose of the synthesizer is to provide an accurate frequency reference for the quadrature sinewave oscillator. The oscillator is approximately tuned by selection of circuit constants using the combination of 'FREQ $R_{2,\Theta}$ ' and 'FREQ_{8-\Omega}'.

'SYNTH O/P' acts as the reference in the phase comparator of a Phase-Locked Loop, controlling the frequency of the main Quadrature Sinewave Oscillator to an accuracy determined by the crystal oscillator.

8.1.2 VOLTAGE CONTROLLED OSCILLATOR



8.1.2.1 Generation of 16kHz Reference (Circuit Diagrams 430648 page 11.3-2, 430652 page 11.4-5 and 430446 page 11.6-4)

The 16kHz (INT) signal originates at M16-14 in the Analog Interface (*page 11.3-2*) and is buffered as '16kHz(OG)' (*page 11.3-1*). On the Reference Divider at J4-104, it passes into guard via opto-isolator M3 (*page 11.4-5*), gating with 'DISABLE REF FREQUENCY' and 'BARK' in M24, filtered by R86/C38 to reduce harmonics from the transmission path, and is sent via the Mother Assembly to J6-53 on the Sine-Source Assembly (*page 11.6-4*).

Schmitt-trigger M14 inverts the 16kHz into a symmetrical squarewave, which is then applied as clock to M13a, a bistable connected to divide by two. The resulting 8kHz squarewave is taken as the reference frequency for phase comparator M12. Note that in this configuration the SIG input of M12 is used for the reference, and the divided VCO output signal is applied to the REF input. This is necessary to provide the correct sense in the phase control element M50, because of the inversion of integrator M11.

8.1.2.2 Squarewave Generation by the VCO

The VCO is a discrete-component ECL relaxation oscillator generating an output of frequency 'n' x 8kHz. Its natural frequency is dependent on:

- the value of capacitor C2 (or C2 plus one of C3 C6),
- the value of its continuous discharge current through the phase control element (current mirror M50), and
- the value of its charging current through Q2 on alternate half cycles (4.7mA).

Consider C2 fully discharged. Q4 is off, so all the 4.7mA from Q6 passes through Q5. The collector voltage of Q4 is close to the positive rail, buffered by Q7 and R9 to hold Q5 on. Also, as Q3 is turned off by Q4 collector voltage, Q2 is turned on by its emitter, passing 4.7mA into C2 and the current mirror M50.

Capacitor C2 charges until Q4 turns on. Cumulative Schmitt action passes the fall at Q4 collector to the base of Q5, ensuring a rapid transition between states; so the 4.7mA is transferred from Q5 to Q4. Q3 turns on, its emitter falling quickly to cut Q2 off, so the charging path to C2 etc. is interrupted.

M50 continues to discharge C2, whose voltage falls slowly until Q4 starts to cut off again. The cumulative action is repeated to turn Q2 on, recharging C2. The cycle of charge and discharge continues, generating 'VCO O/P' squarewaves at buffer Q12 emitter.

8.1.2.3 Coarse Frequency Control (Circuit Diagram 430446 Page 11.6-4, and Fig. 8.2)

At any time, only one of the capacitors C3, C4, C5 and C6 can be connected in parallel with C2, by conduction of its associated transistor. This splits the frequency range of the VCO into five bands, governed by the four most-significant bits of the frequency control word FREQ_{8-Ø} acting on M8. The association is shown in *Table 8.1*; note that the VCO frequency bands quoted in the table are correct only because the VCO is under the fine control of comparator M12, within the phase-locked loop.

FREQ ₈₋₅ bits	Range of	M8 Outputs at	C2-C6	VCO - Frequency
8765	'n' Values	Logic-1	Selection	Band (kHz)
0000	10 to 31	×g	C2 and C6	80 to 248
0001	32 to 63	X 1	C2 and C5	256 to 504
0 0 1 X	64 to 127	X _{3·2}	C2 and C4	512 to 1016
0 1 X X	128 to 255	X ₇₋₄	C2 and C3	1024 to 2040
1 X X X	256 to 500	NONE	C2 only	2048 to 4000

TABLE 8.1 COARSE FREQUENCY CONTROL

8.1.2.4 Fine Frequency Control (Circuit Diagram 430446 Page 11.6-4, and Fig. 8.2)

In the following description, capacitors C3, C4, C5 and C6 are ignored, but references to C2 should be read as including the appropriate additional capacitor.

The VCO output is fed back to M12 phase comparator via M9 and M13b, which are connected to act as a 9-bit frequency divider. Because the divider is controlled by $FREQ_{8-\emptyset}$, the VCO output frequency is always divided by 'n' before being applied to the REF input of the comparator. The output from the comparator will only be zero if the frequency fed back to M12-6 is 8kHz (ie. the VCO frequency is n x 8kHz), and in phase with the 8kHz REF FREQ at M12-3 (TP14).

The output from M12 is integrated by M11 to drive a DC current into the current mirror M50, which has a gain of two, its output current being drawn from the charge on C2. During the half-cycles of the VCO oscillation when C2 is being charged, the mirror obtains its current from Q2 conduction.

The phase control loop seeks to phase-lock the two inputs to the comparator. If they are in phase, the comparator output is at high impedance ('TRISTATE'). In this condition the integrator capacitors C16 and C18 have no charge or discharge path, so M11's extremely high gain maintains their charge, and thus the voltage at TP6. M11 supplies the input current for M50, the mirror continues to draw the same discharge current from C2, so the frequency of VCO oscillation remains constant. Thus the loop stabilizes only when the frequency divided by 'n' from the VCO output is in phase with (and therefore at the same frequency as) the reference 8kHz.

In stable operation, therefore, the loop maintains VCO oscillations at n x 8kHz, and the feedback dividers reduce this frequency by a factor of 'n' to 8kHz.

Any disturbance in the loop will generate corrections to restore zero phase difference at the inputs of M12. Frequency deviations are therefore detected at an early stage as phase changes, giving a measure of 'phase advance' correction.

8.1.2.5 'INHIBIT' (VCO Off)

The VCO can be switched off by a logic-1 of 0V at the base of Q11 (INHIBIT signal). This originates in the CPU system, setting FREQ $R_{2,\emptyset}$ code to 111 (a non-existent 'R7' range) when AC functions are deselected. It also resets the +2 flip-flop M13a, so that no reference frequency is passed into the phase comparator.

8.1.2.6 VCO Supply Rail Protection

To prevent VCO oscillations appearing on the 15V power rails, which also supply the integrator M11 and current mirror M50, the positive rail is heavily decoupled, regulated by Q8, and all devices whose currents are likely to disturb the rails are supplied through constant current sources (Q1, Q6, Q9 and Q13).

8.1.2.7 VCO Output

The VCO, M11 and M50 operate from the 15V supplies. M12, M9 and the frequency dividers which follow the VCO, all operate from the in-guard logic supplies of +0V and -15V. The VCO output from Q12 emitter is therefore limited by D1 to logic supply levels. A re-conversion back to 15V levels is accomplished at the input to the integrator M11, as TP31 pulses are negative at M11 input.

D1 is a Schottky hot carrier diode of reverse capacitance approx. 2pF. This avoids distorting the high frequency output squarewaves (for 1MHz output, the VCO oscillates at 4MHz).

The output passes through R12 to avoid loading the VCO, and then fed as 'VCO O/P' to the frequency dividers at M5-9 (*page 11.6-5*).

8.1.3 FREQUENCY RANGE DIVIDERS (Fig 8.3)

As mentioned earlier in *para 8.1.1*, the purpose of the synthesizer is to provide an accurate frequency reference for the quadrature sinewave oscillator. The VCO frequency (signal 'VCO O/P') is input to a series of frequency dividers, whose ratios are set by 'FREQ R_{2-0} ', so as to make the dividers generate the selected frequency as 'SYNTH O/P'. FREQ R_{2-0} is a three-bit word, five of whose codes represent the five frequency ranges.

A second purpose is to clock the Quasi-Sinewave Generator in synchronism with the synthesizer output (and hence with the main quadrature sinewave oscillator output). The synthesizer frequency is a multiple of the Quasi-Sine frequency, except on the 100Hz frequency range, where they are both at the same frequency. Thus the divider ratios are also chosen to generate the correct frequencies for the quasi-sinewave clock, for each frequency range selected.

8.1.3.1 Divider Ratios

(Circuit Diagram 430446 Page 11.6-5)

Binary/BCD Divider M5 is set for binary division by fixing M5-2 and M5-10 at Logic-Ø. Conversely, M1 is set for decimal division by fixing M1-2 and M1-10 at Logic-1.

BCD counter M2 is set to count up, by fixing M2-10 at Logic-1. Its CARRY OUT signal at M2-7 is at 1/10 of its clock frequency, and its Q1 output on M2-6 is at half its clock frequency. Flip-flop M4a is connected to divide its clocks by two.

Multiplexer M6 selects the appropriate source frequency to clock the Quasi-Sinewave generator. In particular, on the 100Hz Range it selects the \overrightarrow{CARRY} OUT from M2, which is subsequently divided by 10 in the quasi-sinewave counter, and returned via J6-51 to be used as SYNTH O/P.

8.1.3.2 Ratio Selection by Frequency Range (Fig. 8.3 and Table 8.2)

The frequency range selection word FREQ $R_{2-\emptyset}$ is decoded by M29 into five range lines $R_{4-\emptyset}$. These lines perform the following functions:

- a. Switch ranges in the quadrature sinewave oscillator by relays RL1-RL8 selection of integrator capacitors (*page 11.6-1*);
- b. Switch ranges in the Cosine Squarer output filter (page 11.6-2);
- c. Adjust the division ratios of Frequency Range Dividers M5 and M1 (page 11.6-5) for range R₄ (1MHz Range),
- d. Select appropriate outputs from the Frequency Range Dividers (page 11.6-5); and
- e. The INHIBIT line turns off the VCO for non-AC functions.

Functions (a) and (b) are described later in Section 8.2. In this description we are concerned mainly with functions (c) and (d).

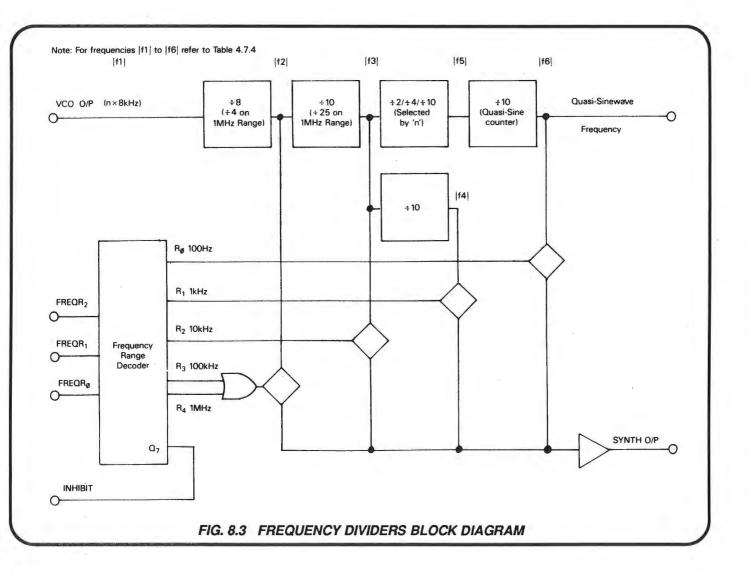
Table 8.2 shows how frequency range switching derives the synthesizer output frequencies by selecting the appropriate outputs from the dividers. Note that except for the 1MHz Range R_4 , the ratios of individual dividers are not altered.

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On the 100Hz Range R_{\emptyset} the overall division ratio of 8000 is achieved as for the 1kHz Range, but with a further division by 10 in the quasi-sinewave counter M11 on the AC Assembly.

On the 1MHz Range, R_4 , the division ratio of M5 is changed from 8 to 4. The DP_A inputs M5-5 and M5-6 are primed to Logic-1 and Logic-Ø respectively, whereas on all other ranges the priming is reversed. Range R_4 also alters the division ratio of M1 from 10 to 25, by changing its priming bit-pattern, to correct the quasi-sinewave frequency; but as the synthesizer output is taken through M10-4/3 from M5 output, the adjustment to M1 does not affect the SYNTH O/P frequency.



FREQ. RANGE	FREQUENCY DISPLAY				RELEVANT		R	QUASI-SINE CLOCK FREQUENCIES	SYNTHESIZER OUTPUT	
	Hz	kHz		M5	M1	M2	M11* (AC PCB)	(J6-50)*	(J6-52)	
100Hz (RO)	10-63 64-127 128-330	80-504 512-1016 1024-2640	8000	8 8 8	10 10 10	10 10 10	10 10 10	Hz 100-630 640-1270 1280-3300	Hz 10-63 64-127 128-330	
1kHz (R1)	0.30k-0.63k 0.64k-1.27k 1.28k-3.30k	240-504 512-1016 1024-2640	800	8 8 8	10 10 10	10 10 10		kHz 1.5-3.15 1.6-3.175 1.28-3.3	Hz 300-630 640-1270 1280-3300	
10kHz (R2)	3.0k-6.3k 6.4k-12.7k 12.8k-33.0k	240-504 512-1016 1024-2640	80	8 8 8	10 10 10			kHz 1.5-3.15 1.6-3.175 1.28-3.3	kHz 3.0-6.3 6.4-12.7 12.8-33.0	
100kHz (R3)	30k-63k 64k-127k 128k-330k	240-504 512-1016 1024-2640	8	8 8 8				kHz 1.5-3.15 1.6-3.175 1.28-3.3	kHz 30-63 64-127 128-330	
1MHz (R4)	0.30M-1.00M	1200-4000	4	4				kHz 1.2-4.0	kHz 300-1000	

 * Quasi-sine counter M11 on the AC Assembly divides VCO output at all frequencies, but contributes to SYNTH O/P only on the 100Hz Frequency Range.

TABLE 8.2 SYNTHESIZER OUTPUT - DIVISION RATIOS

8.1.3.3 Frequency Synthesis for the Quasi-Sinewave Generator (Fig. 8.3 and Table 8.3)

The 100Hz frequency range uses the quasi-sinewave counter as a divider in deriving its SYNTH O/P frequency. Although not a direct component of the frequency of the SYNTH O/P signal on other ranges, the quasi-sinewave frequency is deliberately derived in the synthesizer, so that the zero-crossings of its waveform can be synchronized at a time when the main sinewave is also crossing zero. (The main sinewave, of course, can be at a high multiple of the quasi-sinewave frequency.)

The quasi-sinewave frequency is held to a maximum of 330Hz (400Hz on the 1MHz range), to limit errors due to high harmonics. The 1MHz frequency range contains only one frequency band, but the other four ranges are each divided into three bands, corresponding to the three most significant bits of the frequency word FREQ_{8- $eacurredef{PREQ}$.}

Table 8.3 illustrates the way that the three bands affect the quasi-sine frequencies. Note that division ratios of 2, 4 or 10, by M2 and M4a, are selected by FREQ₆, FREQ₇ and FREQ₈ at M6 pins 11, 10 and 9 respectively. Frequency range R_{\emptyset} at M7-2 ensures that on the 100Hz range, the divide-by-10 output of M2 is always selected, regardless of the state of these three bits.

To ensure that the Divide-by-2 outputs of M2 and M4a are locked into the correct phase for quasi-sinewave generation, a synchronizing signal 'CHOP LOCK' is derived from the quasi-sinewave counter 'Q $_{\emptyset}$ ' output, entering at J6-75. Following DC-restoration from 8V supplies to the normal 0V/-15V logic supplies by C20/D3/R15/M7, the signal is applied to M4a SET input, and M2 RESET input.

(700)

For all frequency ranges, the '100-5kHz' quasi-sinewave generator clock is passed to the AC Assembly via J6-50 and the Mother Assembly. This output is level-shifted by Q42, to the 8V supplies which are used in the quasi-sinewave generator circuitry.

The quasi-sinewave generator reset signal 'SYNC $_{\emptyset}(IG)$ ' (which was transferred into Guard by M2 on the Reference Divider), is input to the Sine-Source Assembly on J6-48 to be similarly level-shifted by M43, before being passed to the AC Assembly via J6-49. This signal, however, is not used on this instrument.

For other details of the quasi-sinewave generator refer to Section 6.6.

		FRE	QUENCIES						
FREQ. RANGE	FREQUENCY DISPLAY Hz	VCO OUTPUT (n×8kHz) kHz	Dividef Quasi M5 M1	SINEW	AVE	OVERALL DIVISION RATIO	QUASI-SINE CLOCK FREQUENCY (J7-50)	QUASI-SINE FREQUENCY (& J7-51) Hz	OUTPUT FREQUENCY Hz
100Hz (RØ)	10-63 64-127 128-330	80-504 512-1016 1024-2640	8 10 8 10 8 10	10 10 10	1 1 1	800 800 800	Hz 100-630 640-1270 1280-3300	10-63 64-127 128-330	10-63 64-127 128-330
1kHz (R1)	0.30k-0.63k 0.64k-1.27k 1.28k-3.30k	240-504 512-1016 1024-2640	8 10 8 10 8 10	2 2 10	_ 2	160 320 800	kHz 1.5-3.15 1.6-3.175 1.28-3.3	150-315 160-317.5 128-330	0.30k-0.63k 0.64k-1.27k 1.28k-3.30k
10kHz (R2)	3.0k-6.3k 6.4k-12.7k 12.8k-33.0k	240-504 512-1016 1024-2640	8 10 8 10 8 10	2 2 10	2	160 320 800	kHz 1.5-3.15 1.6-3.175 1.28-3.3	150-315 160-317.5 128-330	3.0k-6.3⊾ 6.4k-12.7k 12.8k-33.0k
00kHz (R3)	30k-63k 64k-127k 128k-330k	240-504 512-1016 1024-2640	8 10 8 10 8 10	2 2 10	_ 2 _	160 320 800	kHz 1.5-3.15 1.6-3.175 1.28-3.3	150-315 160-317.5 128-330	30k-63k 64k-127k 128k-330k
1MHz (R4)	0.30M-1.00M	1200-4000	4 25	10	_	1000	kHz 1.2-4.0	120-400	0.30M-1.00M

TABLE 8.3 QUASI-SINEWAVE FREQUENCY DERIVATION IN FREQUENCY SYNTHESIZER

8.1.3.4 Synthesizer Frequency Analysis

Table 8.4 is provided to allow a complete analysis of the frequencies to be found in the divider circuitry. In part, it duplicates figures from tables 8.2 and 8.3.

FREQ. RANGE (NOM)	FREQUENCY DISPLAY Hz	VCO DIVISOR 'n'	f1 vCO OUTPUT (n×8kHz) kHz		M1 OUTPUT (f2+10)	T M1 OUTPUT (f2 ÷ 10)	M5 OUTPUT M1 OUTPUT (f1+8) (f2+10)	UT M1 OUTPUT (f2÷10)	f4 M2 OUTPUT (f3+10) Hz	15* M6 OUTPUT (M6-3) Hz M6 Input Channels and Division Ratios			f6 J6-51 INPUT (f5÷10) Hz
							Xø (f3+2)	X ₁ (f3+4)	X _{2·7} (f3÷10)				
100Hz (RØ)	10-63 64-127 128-330	10-63 64-127 128-330	80-504 512-1016 1024-2640	10-63 64-127 128-330	1.0-6.3 6.4-12.7 12.8-33.0	100-630 640-1270 1280-3300			100-630 640-1270 1280-3300	[_ 10-63] _ 64-127] _ 128-330]			
1kHz (R1)	0.30k-0.63k 0.64k-1.27k 1.28k-3.30k	30-63 64-127 128-330	240-504 512-1016 1024-2640	30-63 64-127 128-330	3.0-6.3 6.4-12.7 12.8-33.0	[100-630] [640-1270] [1280-3300]	1500-3150	1600-3175	1280-3300	150-315 160-317.5 128-330			
10kHz (R2)	3.0k-6.3k 6.4k-12.7k 12.8k-33.0k	30-63 64-127 128-330	240-504 512-1016 1024-2640	30-63 64-127 128-330	[3.0-6.3] [6.4-12.7] [12.8-33.0]	100-630 640-1270 1280-3300	1500-3150	1600-3175	1280-3300	150-315 160-317.5 128-330			
100kHz (R3)	30k-63k 64k-127k 128k-330k	30-63 64-127 128-330	240-504 512-1016 1024-2640	[30-63] [64-127] [128-330]	3.0-6.3 6.4-12.7 12.8-33.0	100-630 640-1270 1280-3300	1500-3150	1600-3175	1280-3300	150-315 160-317.5 128-330			
1MHz (R4)	Hz 0.30M-1.00M	ʻn' 150-500	kHz 1200-4000	(f1+4) kHz [300-1000]	(f2÷25) kHz 12-40	(f3 + 10) Hz 1200-4000			1200-4000	Hz 120-400			

Note:

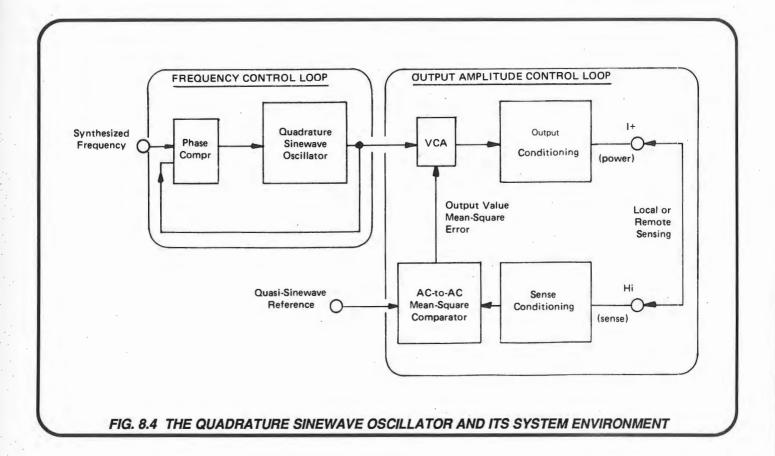
Frequency spans in square brackets [...] are the SYNTH O/P frequencies on those ranges. Other frequencies are present and may be tested.

*Quasi-sine counter M11 on the AC Assembly divides VCO output at all frequencies, but contributes to SYNTH O/P only on the 100Hz Frequency Range.

TABLE 8.4 SYNTHESIZER DIVIDERS - FREQUENCY ANALYSIS

8.2 QUADRATURE SINEWAVE OSCILLATOR

(Fig. 8.4)



8.2.1 PURPOSE AND ENVIRONMENT

The purpose of the oscillator is to define the amplitude-stability, purity and frequency of the sinusoidal output of the instrument on all ranges. Its output is of sufficient constant amplitude to drive the subsequent signal-conditioning circuitry.

After originating in the oscillator, the sinewave amplitude is accurately defined in two output-sense loops, using a low-distortion VCA as control element. The sinewave is set close to its demanded value by analog conditioning in the output circuits.

The output voltage is sensed, attenuated to its 1V Range equivalent, then its mean-square value is compared against that of the quasisinewave reference. The difference is converted into a DC error voltage which corrects the output by adjusting the VCA gain. As the purity and amplitude-stability of the output sinewave depend substantially upon its source, a high quality oscillator is necessary. A 'quadrature' (dual-integrator) circuit is chosen for two main reasons:

- This arrangement allows extensive phase and amplitude controls to be applied, to establish the required high specification.
- Its natural frequency can be easily programmed by electrical selection of its component values.

The oscillator is approximately tuned by selection of circuit constants using the two CPU-derived binary words 'FREQ $R_{2-\theta}$ ' and 'FREQ_{8-\theta}'. These also accurately define the crystal-sourced frequency of the Digital Frequency Synthesizer output, to which the oscillator is phase-locked. Thus the output sinewave frequency accuracy is held to 100ppm.

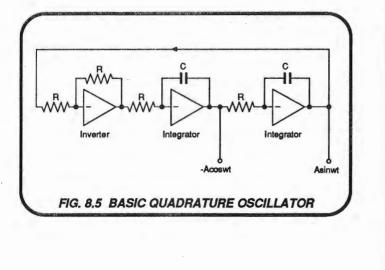
8.2.2 SIMPLE QUADRATURE OSCILLATOR

8.2.2.1 Basic Circuit (Fig. 8.5)

The circuit consists of two RC integrators and an inverter, connected in a positive feedback loop. The nominal phase-shift around the loop is 360° (actually 720°: 270° in each integrator, 180° in the inverter).

Assuming perfect integrators, matched components and an inverter gain of exactly -1, this circuit will undergo stable oscillation at a frequency given by:

w = 1/R.C



8.2.2.2 Inadequacies of the Basic Circuit (Figs. 8.5 and 8.6)

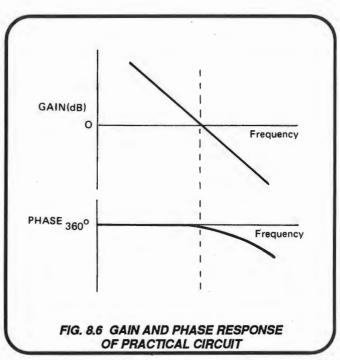
For an unrefined practical implementation of the basic circuit, the loop gain and phase response would be as shown in Fig. 8.6.

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The two main conditions for stable oscillation at constant amplitude are: exactly unity loop gain, and exactly 360° (or multiple of 360°) of loop phase-shift; so the circuit of *Fig. 8.5* clearly does not satisfy these conditions. Without some attempt to control gain and phase, the loop would be either over- or under-damped, so oscillations would either die away or increase in amplitude until limited by the supply rails.



8.2.3 PRACTICAL QUADRATURE OSCILLATOR (Fig. 8.7)

The method chosen to refine the simple circuit corrects the loop phase-shift to exactly 360° using a feedback signal. Furthermore, it is arranged that this signal is correct only at a given output

8.2.3.1 Phase Correction

The loop phase is corrected by introducing a small cosine term (B.coswt) to be summed with the sine feedback (A.sinwt) at the input to the inverter. The resultant output of the inverter is thus given by:

	V(t) = -(A.sinwt + B.coswt)	
	$=$ M.sin(wt + ϕ)	1
where	$M = \sqrt{(A^2 + B^2)}$	
and	$\sin \phi = B/M; \cos \phi = A/M.$	

amplitude, so the amplitude of stable oscillation is defined. In Fig. 8.7 the correction circuit is added.

Hence and for B«A:

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The ϕ term represents an additional phase shift in the inverter, which by suitable scaling can be made equal to the phase error in the basic oscillator loop. Scaling is achieved by multiplying A.coswt by the DC amplitude error (A²-I_{REF}), as described opposite.

8.2.3.2 Constant Amplitude Control

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The above method of phase correction plays its part in controlling the output amplitude. With both sine and cosine terms available, a DC analog of the sinusoidal output amplitude can be obtained utilizing the identity:

$$\sin^2 wt + \cos^2 wt = 1.$$

Equal-amplitude sine and cosine outputs are squared in 4-quadrant multipliers. Their squares are summed to generate amplitude feedback in the form:

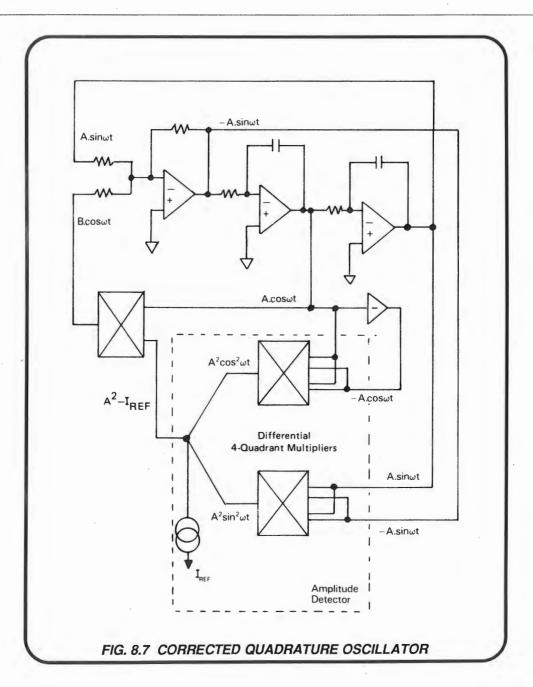
$$A^{2}.\sin^{2}wt + A^{2}.\cos^{2}wt$$
$$A^{2}(\sin^{2}wt + \cos^{2}wt)$$
$$A^{2}.$$

This method therefore expresses the square of the output amplitude as a DC current analog, from which is subtracted a constant DC reference current T_{REF} .

The difference current ' A^2 -I_{REF}' is taken as the amplitude error, which defines the fraction 'B' of the cosine term to be fed back to the inverter as 'B.coswt'.

In a perfect oscillator, this 'cos' feedback would be driven to zero. But in any practical circuit, some small remnant of B.coswt persists at the correct loop phase-shift, correcting the loop gain to within the stability specification.

Acting thus together, the combined feedbacks correct both loop gain and phase simultaneously. The method of amplitude correction prevents the appearance of AC components in the amplitude error signal, thus avoiding unacceptable levels of harmonic distortion due to the cosine multiplier.



8.2.4 FREQUENCY CONTROL

Section 8.1 describes frequency generation in the Frequency Synthesizer. Binary control words computed by the CPU represent user-selections of FREQUENCY RANGE and FREQUENCY. These adjust frequency division ratios in the feedback circuit of a

8.2.4.1 Coarse Adjustment

The Sinewave Oscillator is already approximately tuned to the selected frequency by the two binary control words, which select from weighted values of integration capacitance and resistance:

- Frequency ranges are selected by control word FREQ R_{2-Ø}, which controls relays to change the values of integrator capacitance.
- Frequencies within a range are selected by the control word FREQ_{8-Ø}, which controls FETs to change the values of integrator resistance.

8.2.4.2 Fine Adjustment (Fig. 8.8)

The oscillator's output is converted into a squarewave and applied as 'signal' to the phase comparator of a second phase-locked loop. The Synthesizer output signal 'SYNTH O/P' is input as reference frequency to the same comparator. The difference is integrated to produce a DC phase error signal, which is applied to control the gain of the inverter stage of the oscillator.

phase-locked loop, and division ratios in subsequent frequency dividers, to set the Synthesizer output signal 'SYNTH O/P' to the selected frequency. Stability and accuracy are assured by a crystalsourced reference of 16kHz.

It can be shown that the actual operating frequency is a function of the inverter gain. In the frequency domain, the oscillator loop transfer function is given by:

$$G \times (w_{ol}/s) \times (w_{ol}/s)$$

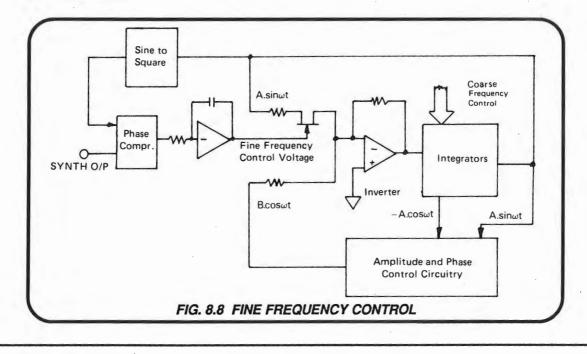
where G is the inverter gain, w_Ø is the unity-gain frequency s = j.w, where w is the actual frequency of operation.

For stable oscillation, the loop transfer function must equal 1/0.

Hence	$\mathbf{G}.\mathbf{w}_{\emptyset}^{2}/\mathbf{s}^{2} = 1/\underline{0}$
Therefore	$G.w_{0}^{2} = j^{2}.w^{2} = -1.w^{2}$
and	$w = -w_{0}G^{1/2}$

Thus by adjusting the gain of the inverter, the phase error signal from the comparator exerts fine control of the oscillator frequency. This phase-locks the oscillator to the Frequency Synthesizer.

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8.2.5 OSCILLATOR OUTPUT

The A.sinwt signal is inverted and buffered out to provide the drive to the output loop VCA. The buffer feedback resistors are positive TC thermistors which compensate for the TC of the VCA input FETs (*refer to section 9*).

QUADRATURE OSCILLATOR CIRCUIT DESCRIPTION

8.2.6 MAIN INTEGRATORS

(Circuit Diagram 430446 page 11.6-1)

The cascaded integrators consist of M19 and M30 together with their input resistors and feedback capacitors. Both circuits are identical in operation, although some slight differences in implementation exist.

8.2.6.1 Frequency Range Switching

The feedback capacitors are selected by the binary control word 'FREQ $R_{2,0}$ '. This is decoded into five lines $R_{4,0}$ (page 11.6-5), each representing a frequency range. The capacitors for R_4 (1MHz) are fixed, one other set being added in parallel when its range is selected. Relays RL1 to RL8 perform the switching.

8.2.6.2 Frequency Increments

The integrator input resistors are connected in a binarily-weighted ladder network, the total input resistance depending on the pattern of FET conduction. Each FET is turned on by its corresponding binary digit in the frequency control word FREQ_{8-Ø} (appearing as $A_{8-Ø}$ and $B_{8-Ø}$ at the FET gates).

The least-significant bits, representing low frequencies, control the highest-value resistors at the base of the ladder. The most-significant bits, which represent the highest frequencies, control the lowest-value resistors at the top.

Any user-selected frequency in a given frequency range is thus represented by a bit-pattern in the control word, which is repeated in the FET conduction pattern and resistance selection at the input of both integrators.

8.2.7 INVERTER STAGE

The inverter completes the positive feedback loop of the basic oscillator. The very high bandwidth device used for M15 is compensated by C27, and its TO8 case is grounded.

8.2.7.1 Gain Control

The inverter has three inputs:

- a. A.slnwt from the second integrator, the basic oscillator feedback loop.
- **b. B.coswt** from the Amplitude correction loop.
- c. 'FREQ ERROR', a DC current which alters the inverter's input resistance (and hence its gain) by controlling FET conduction, phase-locking the oscillator to the synthesizer output frequency (refer to para 8.2.4.2).

Inputs (a) and (b) [A.sinwt and B.coswt] are summed as currents at the inverting input. The amplitude of the B.coswt signal is determined by the action of the amplitude control loop, described in sections 8.2.8 and 8.2.9.

Input (c) controls the gain of the inverter. The A.sinwt is applied via two input resistors R28 and R41 in series. R28 is shunted by the two FETs of Q29, whose the source-drain resistance is altered by the 'FREQ ERROR' current via current-mirrors M16 and M18.

Adjustments to the natural oscillation frequency are made by switching the integrator time constants.

8.2.6.3 Slew Rate and Protection

Emitter-followers at the outputs of the integrator operational amplifiers allow the high slew-rates necessary to be achieved, by buffering any loading effects. The diode clamp networks between output and input prevent latch-up by imposing unity-gain feedback when output peaks exceed approx. 5V.

8.2.6.4 Output Offset Control

The amplitude detector circuit squares the outputs from both integrators. It is therefore important that their DC offset voltages are not included in the squaring computation.

The 'Cosine' offset is removed by adjustment of R50 at the noninverting input of M30, and the 'Sine' offset by R49 at the input of inverter M15. This latter adjustment removes the combined offsets of M15 and M19. (At manufacture, and after any replacement of major board components, the controls are iteratively adjusted for minimum AC fundamental component in the DC amplitude control signal 'V_G' at link 'B'.)

As mentioned earlier, its DC input offset is adjusted by R49 to null the sine DC offset.

Two FETs in series are required for the amplitude levels reached by A.sinwt. R41 is selected to account for differing 'on' resistances of different batches of FETs. This input circuit is a scaled-down version of that employed for the VCA in the main output loop, details of which appear in *Section 9*. A description of the action of the frequency tracking loop follows at *para 8.2.7.2*.

8.2.7.2 Frequency Tracking - General

As stated in *para* 8.2.4.2, the oscillator's output is applied to the comparator of a phase-locked loop. The Synthesizer output is input as reference frequency to the same comparator. The phase-difference pulse train from the comparator is integrated to produce a DC phase error signal, which is applied to control the gain of the inverter stage of the oscillator. This exerts fine control of the oscillator frequency, tracking the Synthesizer frequency.

8.2.7.3 Tracking Comparator

(Circuit Diagram 430663 Page 11.7-6)

After buffering and invertion by M47 on the Sine-source Assembly (*page 11.6-1*), the oscillator A.sinwt output is passed to the AC Assembly via J6-45 and J7-45.

On the AC Assembly, the sinewave is converted into a squarewave by Schmitt bistable Q32/Q33, and level-shifted to logic supply levels of 0V and -15V by D25/Q28. Q28 provides a current-limited load for maximum gain, while D24 and D25 prevent voltage saturation of Q32. Q23 buffers the resulting squarewave into the phase comparator input at M30-6.

The slower zero-crossings at the lowest frequencies could be susceptible to HF noise, so this is filtered, on the 100Hz frequency range only, by Q27 and C48.

The 'SYNTH O/P' squarewave, at the demanded frequency, is transmitted from the Sine-source Assembly at low (1V Full Range) level. This holds the maximum slew rate to a value which avoids inducing interference in other internal circuits. Q20 and Q21 amplify the signal to the CMOS logic levels of 0V and -15V required by the comparator input at M30-3.

Note that current steering is used between Q32 and Q33, and between Q20 and Q21. Also, a constant current source Q22 provides Q23 emitter current. These measures prevent the fast switching edges in the schmitt and amplifier circuits from injecting spikes into the supply rails.

Phase-comparator output M30-5 consists of positive pulses (0V) when the oscillator lags the synthesizer, or negative (-15V) when the oscillator leads. When both are in phase, M30-5 is at high impedance.

At integrator M31 input, zener diode D30 holds the non-inverting input at -6.4V; so for in-phase signals into the comparator, the inverting input seeks the same level. The integrator tends to hold its voltage level (with very slight drift due to capacitor leakage but limited to -9.8V by D32/D33). When the oscillator output lags the synthesizer output, the positive-going comparator pulses are integrated to drive M31-6 slowly more negative. When the phase of the oscillator leads, the integrator output becomes more positive.

The phase control loop seeks to phase-lock the two inputs to the comparator. If they are in phase, the comparator output is at high impedance ('TRISTATE'). In this condition the integrator capacitors C53 and C56 have no charge or discharge path, so M31's extremely high gain maintains a constant charge on the capacitors. The constant voltage on Q37 base maintains a constant 'FREQ ERROR' current,

Q37 appears to be an open-collector amplifier. However, its collector current passes via J7-44 and J6-44, into the two currentmirrors at the input to the oscillator inverter on the Sine-source Assembly (*page 11.6-1*), and thence to the -15V rail.

With constant input current, the mirrors continue to draw the same output current from the AN4 bias network for Q29, so the frequency of the dual-integrator oscillator remains constant. Thus the loop stabilizes only when the oscillator frequency is in phase with (and therefore at the same frequency as) the Frequency Synthesizer output. The overall action is for a lagging oscillator (frequency lower than the synthesizer) to increase the DC current flowing into the two current mirrors, and vice-versa if the oscillator leads. The two inputs to the comparator are in phase when the sinewave output from the oscillator is at the synthesizer frequency.

Any disturbance in the loop will generate corrections to restore zero phase difference at the inputs of M30. Frequency deviations are therefore detected at an early stage as phase changes, giving a measure of 'phase advance' correction.

8.2.8 SINEWAVE AMPLITUDE DETECTOR

The method of amplitude measurement relies on the identity $sin^2wt+cos^2wt = 1$ to convert AC output signals from the oscillator into a representative DC signal.

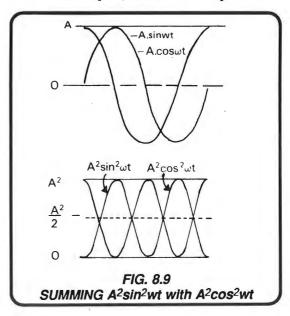
Squaring Asinwt and Acoswt: $\begin{array}{rcl}
A^2 sin^2 wt &=& (A^2 - A^2 cos 2 wt)/2, \\
A^2 cos^2 wt &=& (A^2 + A^2 cos 2 wt)/2, \end{array}$

The AC waveforms of A²cos²wt and A²sin²wt are inverted versions of each other, at twice the original frequency, and both are symmetrical about the DC mean value of A²/2.

By summing the two, the AC waveforms are eliminated, leaving a DC signal, A^2 , representing the square of the amplitude.

In the Amplitude Detector, the Vsin and Vcos outputs from the oscillator are squared electronically and summed as a differential current I^2 . This is compared with a constant DC reference current I_{REF} to generate the error current ($I^2 - I_{REF}$), which is used to derive an amplitude error voltage 'V_G'. This is filtered and passed to the Amplitude Control circuits (*page 11.6-1*).

 V_G is driven to zero by the action of the amplitude control loop, so that $I^2 - I_{REF} = 0$, and thus $I^2 = I_{REF}$. The loop therefore stabilizes only when the two are equal, and at a constant amplitude.



8.2.8.1 Squaring Circuit Inputs (Circuit Diagram 430446 Page 11.6-1)

Vcos and Vsin are squared independently in a pair of differential four-Quadrant multipliers, each with two identical differential inputs.

The Sine Squarer receives Vsinwt from the second integrator M30 (Q44 emitter), and -Vsinwt from the main inverter (M15-11).

As +Vcoswt is the only natural cosine output from the oscillator, the -Vcoswt signal is derived by inversion in M31. These are both fed as inputs to the Cosine Squarer.

8.2.8.2 Cosine Squarer (Circuit Diagram 430446 Page 11.6-2)

Isolating the Cosine circuit alone as an example, there are two differential inputs. One is applied across M34 pins 13 and 16, and the other across pins 6 and 10.

The multiplying action of the squaring circuitry relies on the exponential transconductance between a transistor's base voltage and its emitter-collector current:

$$I_c$$
 is proportional to $exp(V_{be})$
so V_{be} is proportional to $Ln(I_c)$

The difference between the currents in M34-1 and M34-14 collectors is linearly proportional to Vcoswt (due to M34 emitter resistors AN15). The currents are drawn from the supply through Q55 (which is connected as two matched diodes), but because of the exponential transconductance, Q55 base-emitter voltages increase logarithmically with increase of emitter current. Therefore the differential voltage at Q56 and Q57 bases due to Q55 emitter currents is logarithmic:

(V₀₅₅₋₄ - V₀₅₅₋₃) is proportional to Ln(V.coswt)

The difference between the currents in M34-9 and M34-7 collectors is also linearly proportional to Vcoswt (due to other M34 emitter resistors AN15). But each collector current is divided between the two halves of the dual transistor in its collector circuit, regulated both by the dual transistor's exponential transconductance, and by its logarithmic differential base voltage.

The combined effect of these two factors is similar to the mathematical operation of multiplying by adding logarithms: a term is produced in each Q56 and Q57 collector current, proportional to the linear product of the two input voltages.

By cross coupling the collectors of Q56 and Q57 as shown, other constant terms are suppressed, and the difference between the currents drawn from AN15-7/8 and AN16-9/10 is proportional to:

Vcoswt x Vcoswt

The inputs are equal, so the differential output current is proportional to $V^2 cos^2 wt$.

8.2.8.3 Sine Squarer

The Sine Squarer behaves in the same way, producing a differential current in its collector loads proportional to V^2sin^2wt .

8.2.8.4 Cos², Sin² and I_{REF} Summing

In this application, the currents from both Sine and Cosine Squarers are combined in common loads. The voltages developed across the loads will therefore also differ by an amount proportional to the expression $V^2 cos^2 wt + V^2 sin^2 wt$. Thus if a reference current was not superimposed, and utilizing the well-known identity 'sin² + cos² = 1', a DC voltage would exist between TP9 and TP10 (TP9 positive), equal to:

$$KV^2(\cos^2wt + \sin^2wt) = KV^2$$

where 'K' is a constant at constant temperature, dependent upon identical circuit values in both squarers, and 'V' is the amplitude of both sine and cosine outputs from the oscillator.

However, a reference current is superimposed. The DC current I_{REF} is drawn through the 1kohm load AN15 by M40 (pin 2), reducing the positive value of TP9 voltage to (KV² - KV_{REF}) with respect to TP10. (The reference current is established at a value which includes the scaling factor 'K', by D26 and R91. The value of R91 for correct oscillator amplitude is determined at manufacture). M34 is connected as a diode to compensate for M40 V_{be} temperature drift.

Voltage K(V² - V_{REF}) is applied to the input of M35a, the unity-gain Summing Amplifier. M35a is connected to remove any common mode present at its input, so at TP11, K(V² - V_{REF}) is referred to common 2A. At this point it can be recognized as the Amplitude Error Voltage. Moreover, the amplitude loop adjusts the oscillator outputs to drive the error voltage to zero, so the action of the loop also drives V² to equal V_{REF}.

8.2.8.5 Filtering

Because components cannot be matched exactly, some small differences can exist between the \sin^2 and \cos^2 terms. Such differences appear in V_G as the fundamental and second harmonics of the oscillator frequency. These are limited by filtering in the filter formed by M35b and its associated circuit.

It would be possible to set a single low-pass bandwidth for all ranges, but as this would need to filter down to 20Hz for the 100Hz range, it would also impose inconveniently long settling times for the higher frequency ranges. The low-pass bandwidth of the filter is therefore switched between frequency ranges by the $R_{4.0}$ signals decoded from FREQ $R_{2.0}$ in the synthesizer (page 11.6-5).

The frequency range signals select the appropriate feedback components, by conduction of only one FET from Q47-Q52 per range. (Q48 is not used).

The filter output is the oscillator amplitude DC error signal 'V_G', limited to a maximum of approximately 6V by the action of back-to-back clamp diodes D24 and D25. V_G passes via link B to the 'Amplitude Control' circuitry (*see page 11.6-1*). The value of V_G determines the fraction, and its polarity the phase, of the V.coswt signal which is to be added to V.sinwt at M15 input.

8.2.9 AMPLITUDE CONTROL IMPLEMENTATION (Circuit Diagram 430446 Page 11.6-1)

Before describing the control circuitry, it is useful to review the various controls imposed on the oscillator (see Figs. 8.4 and 8.7):

- a. Frequency control by phase-locked loop to the frequency of the synthesizer output (albeit with a constant phase lag). This is effected by controlling the gain of the inverter stage of the oscillator. (Input resistance of M15 is changed by adjusting the conduction of FETs Q29.)
- **b.** Phase control to establish exactly 360° loop phase-shift by injecting a small amount of Vcoswt into the oscillator inverter input (via R29).
- c. Amplitude control by adjusting the sense and amplitude of V.coswt added to V.sinwt, so that the loop gain is exactly unity at 360° loop phase-shift, at a constant output amplitude, and at the synthesizer frequency. (M23 gain is adjusted by varying the attenuation of its input signal, using FETs Q41_a and Q41_b.)

Amplitude error is corrected by adding a controlled fraction of either Vcoswt or -Vcoswt to the Vsinwt feedback being applied to the main inverter M15. A push-pull control circuit is employed in order to adjust both amplitude and sense. Vcoswt is input from Q31 emitter to R71, and its inverse is input to R70 from the output of M31, (which also provides the -Vcoswt input for the cosine squarer).

8.2.9.1 V.coswt Amplifier - M23

M23 is connected as a summing VCA, with a fixed feedback resistor R53. Vcoswt and -Vcoswt are applied to opposite ends of its balanced input resistor chain R71, R65, R64 and R70. The center of the chain is the virtual ground of M23, so if the 'on' resistances of $Q41_a$ and $Q41_b$ are equal, the balance is not disturbed and M23 output voltage is zero.

When the Loop-gain Error is zero ($V_G = 0V$), the static conditions set approx. -3V bias on both FETs (depletion mode) to reduce crossover distortion. The FET gates are also bootstrapped by M24 and M25 to half the AC voltage between source and drain.

The DC conditions are:

Q41,	Q46 emitter -	-0.75V
	M26 I _{in} -	150µA
	M26 Iout -	300µA
		-1.5V
Q41 _b	M32-6 -	0V
	Q45 emitter -	-0.75V
	M27 I _{in} -	150µA
	M27 Iout -	300µA
		-1.5V

Amplitude Error:

M23-6 - zero

The Amplitude Error adjusts the 'on' resistance of $Q41_a$ and $Q41_b$ differentially, due to the inverter M32 in the side feeding $Q41_b$. In the case of a positive V_G of about 0.5V:

Q41 _a	Q46 emitter	0.25V
	M26 I _{in}	- 50µA
2	M26 Iout	- 100µA
×	Q41 _a V _{gs}	0.5V (more conduction)
Q41 _b	M32-6	0.5V
	Q45 emitter	1.25V
	M27 I _{in}	- 250µA
	M27 Iout	- 500µA
	Q41 _b V _{gs}	 -2.5V (less conduction)

The output voltage at M23-6 is in the same phase as Vcoswt, increasing with larger amplitude error.

For a negative V_G , M23-6 output voltage assumes the same phase as the -Vcoswt signal, increasing with larger amplitude error.

Transistors Q45 and Q46 act as voltage-to-current converters to drive the 'x2' current mirrors M27 and M26. Voltage reference diodes D20 and D22 provide the crossover bias. D21 and D23 provide clamping when Q45 and Q46 bases are driven positive, preventing V_{be} breakdown.

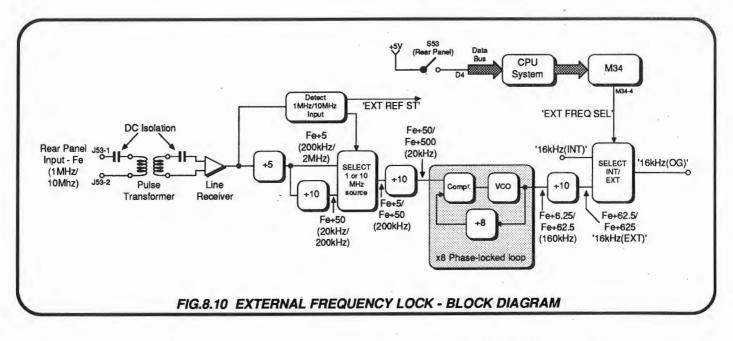
M23 output (now recognized as 'B.coswt') is summed with the basic oscillator feedback (Vsinwt) at the main inverter input (M15-5). When the amplitude is correct, and the loop phase is exactly 360°, M23 output is zero and does not inject any 'cos' component into the loop.

If the loop gain or phase is in error, then the squarers' output current is not equal to the reference current, V_G is not zero, and a small amount of cos component is fed into the loop. This adjusts the loop phase and gain to correct the oscillator amplitude.

8.3 EXTERNAL FREQUENCY LOCK

The External Frequency Lock allows the instrument output to be synchronized with an external reference frequency of either 1MHz or 10MHz (a tolerance of $\pm 1\%$ on these frequencies is specified).

The main use envisaged for this facility is for a user to improve on the ± 100 ppm frequency accuracy of the instrument, by locking the internal frequency synthesizer to a customer's own frequency standard.



8.3.1 INTRODUCTION

The output sinewave frequency is synthesized in the Sine-Source assembly, normally synchronized to an internally-generated reference frequency of 16kHz. To lock the output to an external reference, it is necessary only to divide the frequency of the reference down to 16kHz and use this instead of the internal reference. The circuitry described in this sub-section is shown in block form in *Fig. 8.10* and carries out the following functions:

- Isolates, limits and buffers the input reference signal to TTL levels.
- Divides the input frequency 'Fe' by 5 and then by 10 (Fig. 8.10).
- Detects whether the Fe is 1MHz or 10MHz; from this it sets the selector to choose either its +5 or +50 input, to give an output of 200kHz. The detector sets the status signal 'EXT REF ST' to Logic-1 whenever either of the two signals is present.
- Divides the selector output by 10, then multiplies by 8 in a phase-locked loop, finally dividing by 10 again to 16kHz to give the signal '16kHz(EXT)'.
- Selects either '16kHz(INT)' or '16kHz(EXT)' in response to the position of the Rear Panel switch S53, and to the presence of a 1MHz or 10MHz External Reference signal. The selected signal '16kHz(OG)' is transferred into guard by opto-isolator M3 on the Reference Divider assembly, and thence as 'REF FREQ' to the digital frequency synthesizer on the Sine Source assembly.

8.3.2 EXT REF SIGNAL INPUT (Circuit Diagrams: 430439 Page 11.17-2;

430604 Page 11.16-4; 430648 Page 11.3-4.)

The External Reference signal of 1MHz or 10MHz enters the instrument via pins 1 (Hi) and 2 (Lo) of Rear-Panel connector J53 on the Interconnection assembly (*page 11.17-2*). It is transferred via J18 and J3 on the Mother assembly (*page 11.16-4*) to the buffer input circuit on the Analog Interface assembly (*page 11.3-4*).

C59 and R1 remove any DC components of the signal; and R15, D1 and D2 limit its excursions to approximately $\pm 0.7V$ before it is applied to the pulse transformer T1.

The output from T1 drives line receiver M9, C62 setting the DC offset to zero, and R16 providing some noise-immunity.

8.3.3 DIVISION CHAIN

8.3.3.1 '+5' and '+10' Counters M11

The line receiver output at TP24 clocks the +5 section of M11 counter. Its frequency is reduced to either 200kHz (for 1MHz input) or 2MHz (10MHz input), and this signal is used to clock the second (+10) section of M11. This section (and the other two +10 counters M28) is connected as a 'bi-quinary' divider to establish a symmetrical mark/space ratio. The frequency at M11-13 is either 20kHz (for 1MHz input) or 200kHz (10MHz input). The outputs from both counters are fed to the dual 4 into 1 line selector M18, which always chooses the 200kHz signal.

8.3.3.2 'EXT FREQ SEL'

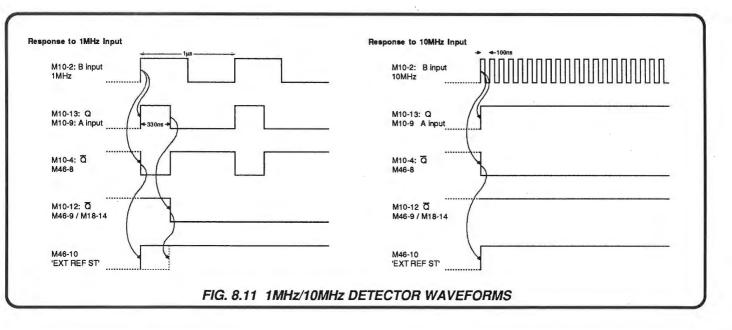
When S53 on the rear panel is closed to select External Reference, +5V from S53 enters the Digital assembly at J2-25 (*page 11.2-2*), setting line D2 on the Data bus to Logic-1 each time that M36 is enabled by any IRQ (ie. every 8ms in response to the internal signal RTC IRQ *para 6.1.2.6*). The CPU passes the information to the External Reference Buffer on the Analog Interface assembly via the Precision Divider Input Data Latches. The state of S53 is repeated at M34-4 (*page 11.3-1*) and input to M18-2 (B) to set M18 outputs.

8.3.3.3 1MHZ/10MHz Detector M10

The state of the other input to M18 at M18-14 'A' depends on the frequency of the external reference signal at TP24, which is used to clock M10-2 'B'. Each positive-going edge triggers the first (330ns) monostable, initially setting M10-13 to Logic-1 (*Fig. 8.11*).

If the frequency is 1MHz, M10-13 times out and returns to Logic- \emptyset before the next 1MHz trigger arrives, thus providing a train of negative-going triggers for the second (5.7 μ s) monostable at M10-9. The first negative-going edge sets M10-12 to Logic- \emptyset , but in this case each succeeding retrigger arrives before the monostable has timed out, and so M10-12 remains at Logic- \emptyset . The output from M10-12 drives M18 control input M18-14 (A).

If the frequency is 10MHz, M10-13 (330ns) cannot time out before the next retrigger arrives at M10-2, so it remains at Logic-1. No negative edges appear at M10-9 to trigger M10-12 to Logic- \emptyset , so the control input to M18-14 remains at Logic-1 as shown in *Fig 8.11*.



8.3.3.4 M18 Frequency Selections

The input sources to M18-10/11/12/13 are switched to M18-9 according to the following table. The *italicized* frequencies cannot

be obtained because it is **frequency** which controls the A input to M18:

Reference Frequency	'EXT FREQ SEL' M18-2 (B)	1/10MHz Detect. M18-14 (A)	Source Transferred	M18-12 Frequency	M18-13 Frequency
1MHz	1	Ø	M18-12 (2C2)	200kHz	20kHz
10MHz	1	1	M18-13 (2C3)	2MHz	200kHz
No Input, or 10MHz (and Not Selected)	Ø	1	M18-11 (2C1)	٥V	ov
1MHz (and Not Selected)	Ø	Ø	M18-11 (2C0)	0V -	ov

8.3.3.5 Further Division of M18 Output

The 200kHz output from M18-9 is divided by a further +12.5 before it becomes the signal '16kHz EXT'. This is achieved in three stages:

The x10 dividers are connected as bi-quinary counters to maintain the symmetrical squarewave.

8.3.3.6 PLL Frequency Multiplier

The Phase-Locked Loop is formed by M30 and M53. The VCO oscillates at a frequency which when divided by 8 (M53-11) phase-locks to the 20kHz present at TP25. At this frequency (160kHz) the error voltage across C30 is a very low amplitude ripple balanced about 0V DC.

The loop can be regarded as a simplified version of the synthesizer VCO, described in *para 8.1.2.4*. The VCO output is low-pass filtered, then buffered and inverted by Q1 which drives the final +10 counter.

8.3.4 INT/EXT Reference Selection

The 16kHz (EXT) signal output from M28-13 is a symmetrical squarewave phase-locked to the External Reference frequency at TP27. It is passed into the same selector (M18) which carries out the 1MHz/10MHz and INT/EXT selection of the divided signal input. The 16kHz (INT) signal is also applied to M18. In this case the other half of the dual selector is employed.

The 16kHz(EXT)REF signal from TP27 is input via M18-3 and M18-4, whereas the 16kHz(INT) signal goes to M18-5 and M18-6. Switching between 1MHz and 10MHz (M18-14) has no effect, as the output at M18-7 selects from shorted input lines. The INT/EXT switching by EXT FREQ SEL (M18-2) selects between the two pairs of shorted inputs to give the 16kHz (OG) output from M18-7. This is buffered out via M5-6, J3-104 (*page 11.3-1*) and the Mother assembly to the Sine Source assembly at J6-53 (*page 11.6-4*).

8.3.5 'EXT REF ST' (M46)

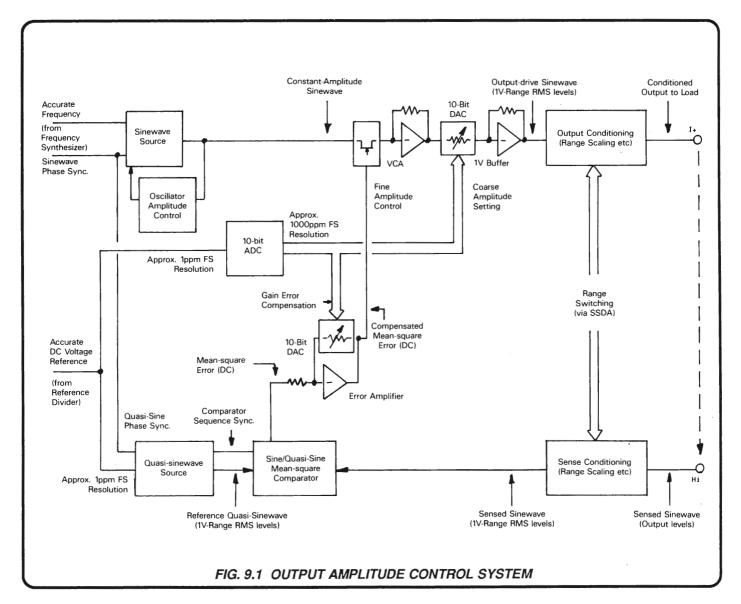
If no external reference signal is present, both M10 monostables remain permanently in their relaxed (timed-out) state. Thus M10-4 and M10-12 are at Logic-1, both inputs to NAND M46 are Logic-1, so its output (EXT REF ST) is at Logic-Ø. For signal frequencies of 1MHz or 10MHz one of the inputs to M46 is at Logic-Ø, so EXT REF ST goes to Logic-1.

M46 output is returned to the CPU, being sensed on the data bus line D4 at each RTC IRQ (M37-13 page 11.2-2), so the CPU knows whether an external reference signal is present or not. It also knows when S53 is selected, and issues the 'Error EF' message on the MODE Display if S53 is selected but no external reference signal is present. This warns the user that with the external reference facility selected, the VCO in the Reference Buffer is free-running in the absence of a locking signal, and is still the reference for synthesis of the instrument output frequency. The output is thus unlocked both from the user's sync source and from the internal crystal oscillator. This is normally because no external reference has been connected to J53 on the rear panel!

SECTION 9 AC VOLTAGE OUTPUTS - AMPLITUDE CONTROL SYSTEM

9.1 INTRODUCTION

This complex system generates the whole range of AC voltage outputs, as defined by its inputs. For the AC Current function, an AC voltage is derived from the internal voltage amplitude loop on the 1V or 10V range to act as an accurate reference. Thus the following description applies also to the generation of that reference.



Feature of Output Controlling Element

Sinewave Purity: Quadrature	via SSDA and Control Latches
-----------------------------	------------------------------

Fine Amplitude: Reference Divider and Quasi-sinewave Generator

Controlling Input to Loop

Constant-amplitude sinewave from Quadrature Oscillator Constant-amplitude sinewave Ranging Signals Accurate DC Reference Voltage (Resolution reduced to approx. 1000ppm FS by 10-bit DAC) Quasi-sinewave RMS value at a resolution of approx. 1ppm FS

9.2 AC VOLTAGE AMPLITUDE CONTROL SYSTEM - BLOCK DIAGRAM

(Fig. 9.1)

The system elements are described individually in the five subsections from 9.3 to 9.7. The system block diagram at Fig. 9.1

9.2.1 FREQUENCY and WAVESHAPE CONTROL

Sinewave sourcing is the subject of *sub-sections 8.1* (Frequency Synthesizer) and 8.2 (Quadrature Oscillator). The result is a high-purity sinewave of constant 1.9V amplitude, input to the VCA.

9.2.2 OUTPUT RANGING

The microprocessor passes Voltage and Current range selections into guard via the serial data link as described in *sub-section 6.4*.

This range information is held in the Analog Control latches in the Reference Divider Assembly, providing signals to the Output and Sense conditioning circuitry.

Their effects are described in sub-sections 9.4 to 9.6.

9.2.3 COARSE AMPLITUDE SETTING

The 1V Buffer also acts as a coarse amplitude control within each range. The value of its input resistance is adjusted to control its gain, which is incremented in steps of approximately 1000ppm of Full Scale by a 10-bit digital-to-analog converter.

The increments are defined by a 10-bit analog-to-digital converter, which responds to the accurate DC Reference voltages generated by the Reference Divider. The value of the 'DC Ref' voltage is proportional to the values set on the front panel OUTPUT display, as described in *sub-section* 6.5.

This coarse adjustment of output amplitude allows the fine control element (the VCA) to operate within a small dynamic range, minimizing introduced distortion and thus maintaining the high purity of the output sinewave. The operation of the coarse amplitude control is described in *sub-section 9.3*.

9.2.4 FINE AMPLITUDE CONTROL

9.2.4.1 Error Loop

The output amplitude is controlled within the coarse increments by an 'error' loop. The output is sensed at the load for 4-wire connections, or at an internal point in the forward path when 2-wire connection is selected (or imposed).

The sensed output is reduced to 1V Range RMS levels by the Sense Conditioning circuitry (as described in *sub-sections 9.4 and 9.6*), and its mean-square value is compared with that of the Reference Quasisinewave. The difference between the two values is expressed as a DC error, and fed to control the gain of the VCA. throws clear of the handbook, so that it can be used for reference when reading these descriptions.

Because the coarse amplitude control adjusts the error loop gain, and the error itself results from comparison with an amplitude analog, the gain of the error loop would not naturally be constant. Compensation is therefore applied to the error to reduce the loop gain in synchronism with increasing increments of coarse amplitude. (The Error Amplifier feedback resistance is reduced by a second DAC in step with the coarse amplitude ADC. The result is that the loop gain, and therefore the loop dynamics, are virtually linear.)

Details of VCA operation and error compensation are described in sub-section 9.3.

9.2.4.2 Mean-Square Comparator

When a value is set on the OUTPUT Display, it describes the RMS value of the output. From the displayed value the Reference Divider generates an accurate DC Reference voltage (stepping in increments of approximately 1ppm of Full Scale), which results in a quasi-sinewave whose peak voltage has the same value. (Thus at 1V Full Range output, the DC Reference voltage and the quasi-sinewave peak voltage are both 1.397V.)

The Crest Factor for any wave is defined as its Peak value divided by its RMS value. For a pure sinewave the figure is $\sqrt{2}$ (say 1.414), whereas the quasi-sinewave crest factor is 1.397. So for the same RMS value of 1V Full Range output, the quasi-sinewave input to the comparator has a peak value of 1.397V, against the sense feedback peak of 1.414V. The comparison is between mean-square rather than RMS values, but when the mean-square difference is zero, so is the RMS difference.

Generation of DC Reference voltage and Quasi-sinewave are described in Section 6.

9.2.4.3 Synchronization

The comparator is based on a sequence of squaring, integration, sampling and subtraction. Its operation and accuracy rely heavily on the synchronism of sinewave and quasi-sinewave, each state-change in the sequence occurring at zero-crossings of both waveforms. Thus both waveforms synchronize to clocks from the synthesizer, even when the sinewave is at a multiple of the quasi-sinewave frequency. The comparison sequence cycles once every ten quasi-sinewave periods. Comparator operation and synchronization details are described later in *sub-section 9.7*.

9.3 VOLTAGE CONTROLLED AMPLIFIERS

(Circuit Diagram 430446, page 11.6-3)

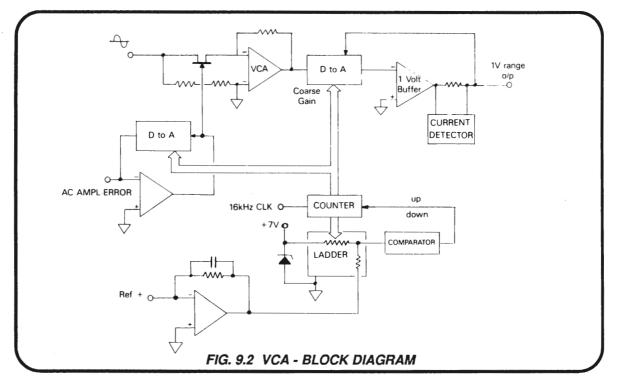
The circuits described in this section perform the following functions:

- Modify the output of the Sine Source by coarsely tracking the gain of the output amplitude to the requested output voltage, providing stepped coverage of the instrument's dynamic range.
- Provide smooth adjustment of gain, within the coarse steps, in response to error signals from the Sine/Quasi-Sine Comparator.
- Impose the settling rate of the true analog DC reference voltage on both the coarse gain adjustment and the mean-square error (AC AMPL ERROR) scaling.
- Sense excess currents in the output buffer, providing a LIM ST signal to the CPU via the analog control interface.

All the circuits described in this section are located on the Sine Source Assembly. On the circuit diagram, two voltage-controlled amplifiers are shown:

- The 1 Volt Buffer (M45, M46 and the discrete output amplifier). Its input resistance is controlled by the DAC M43.
- The main VCA M48/Q88, whose input resistance is determined by the FET chain Q76 and Q77.

For a general description of the Output Amplitude Control System refer to *sub-sections 9.1 and 9.2*.



9.3.1 GENERAL (Fig. 9.2)

The main VCA receives a constant amplitude sinewave input from the Quadrature Oscillator (*Sect. 8*). Its gain is controlled by an error voltage, which is obtained by comparing the sensed sinewave output of the instrument with the reference quasi-sinewave.

The 1 Volt Buffer is included in the output signal path on all voltage and current ranges. It also acts as a VCA, since its input resistance is controlled by its 10-bit Digital-to-Analog Converter. The DAC receives its binary input from an Analog-to-Digital Converter, whose numerical output tracks the user's output demand, in increments of size approximately 1000ppm of full scale.

It is also necessary to ensure that the rate of coarse gain adjustment tracks the settling-time characteristics of the DC Reference filter. To

achieve this, the ADC is controlled by the level of the DC Reference voltage. The filtered reference's settling time is thus imposed on the ADC digital output, and hence on the 1V Buffer gain adjustments.

For reasons given in *sub-section 9.1*, it is also necessary to compensate the output loop gain error synchronously with the coarse gain steps. The tracking ADC therefore drives a second DAC, which selects values of feedback resistor in the Error Amplifier. This increments the output-amplitude error loop gain, modifying the AC AMPL ERROR signal which originated in the mean-square comparator.

The tracking ADC and its DACs ensure that the loop has the fastest possible settling time for any selected frequency.

9.3.1 VCA AND 1V BUFFER

The VCA and 1V Buffer combine in cascade to modify the amplitude of the sinewave output from the sine oscillator, accurately covering the instrument's dynamic range (see Section 9.1 and 9.2). The eventual output from the 1V Buffer (AC 1V FR) forms the instrument's basic 1V AC range.

9.3.1.1 Main Voltage-controlled Amplifier (Circuit Diagram 430446 Pages 11.6-1 & 11.6-3).

The Sine Oscillator output from +2 buffer M47 (page 11.6-1) is emitter-followed by Q75 to the VCA FET input chain Q76/Q77 (page 11.6-3). These dual FETs are enclosed with M47 PTC feedback resistors R136 and R137, in a metal heatsink. The matched FETs Q76/Q77 (R_{DS} ON within 1%) form the variable gain element for the low input-offset amplifier M48, to provide distortion-free and linear control of gain.

Each FET gate is current-bootstrapped from the divider AN18, to maintain a linear relationship between gain and input voltage. C106 and C117 drive the chain at HF. The center of the FET chain is also bootstrapped, M44 ensuring precise AC tracking. Resistors R143 and R135 divide and limit the maximum input resistance, preventing the gain from falling to zero.

9.3.1.2 The 1V Buffer

The buffer consists of a voltage follower with hard current limiting. Amplifiers M45 and M46 buffer the Class A power stage from the capacitance of the input DAC. The first buffer M45 has extremely high DC gain, rolling off at HF due to the feedback of C108. It removes the input DC offsets of M46.

M46 controls the buffer's AC performance; C112 ensures that the non-inverting input appears as a virtual AC ground at HF, allowing source-follower Q74 to develop the AC input across R159.

The discrete output stage provides class A current amplification, avoiding any cross-over distortion particularly at HF. Power transistor Q93 is provided with load and quiescent currents, from constant-current source Q94 (70mA) and constant-current sink Q86 (140mA). *Refer to Fig. 9.3*.

With zero input conditions Q94 is saturated, limiting the quiescent current at 70mA. Only the small bias current for Q92 flows in R144, so the output voltage is just +Vb.

The input signal to Q92 controls Q93, allowing a small signal transistor with good HF performance to adjust the large output currents flowing in R144.

Voltage amplifier Q92 conduction falls during positive half-cycles of input, reducing Q93 conduction. The quiescent current still flows in Q94, but part is now diverted through the output circuit via R144, R112 and L7.

During negative half-cycles of input; Q92 conduction increases, so Q93 conducts more heavily, drawing its extra (load) current through R144, and its quiescent current from Q94. The emitter of Q92 also attempts to go negative, drawing current directly from the load. The combined currents flow into the current sink, so Q86 must be able to sink 70mA quiescent + 70mA load.

The VCA gain is adjusted by the 'AC AMPL ERROR' signal, scaled by M41 and M42. The coarse gain scaling of the 1V buffer derives from the DC Reference voltage 'Ref+'.

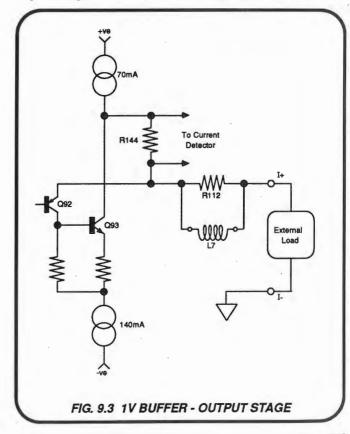
The thermal linking to M47 feedback resistors compensates for the FET chain temperature coefficient. The inertia of the heatsink's thermal time-constant also prevents gain modulation due to draughts.

The DC signal 'AC AMPL ERROR' is scaled and then fed to each gate by transistors Q78 to Q81, which have low collector capacitance. The voltage control element formed by these transistors adjusts the DC gate voltages of the FETs in the chain, and hence the input resistance of the VCA.

M48 output is emitter-followed and passed through DC-isolating (and AC-compensating) capacitors C121 and C122 into M43, the 1V buffer DAC.

In the output line, inductor L7 and resistor R112 provide phase compensation for capacitive loading at HF.

If any components in the discrete amplifier are changed, re-adjustment of gain (using M48 feedback resistor R149) may be necessary.



9.3.1.3 Current Detector

Except for a small bias current, all output current from the discrete buffer stage flows in R144, so the current level can be detected by sensing the differential voltage across it. This sense voltage rides on the output voltage; thus to capture it, the current detector is bootstrapped to the AC 1V output.

High-speed dual comparator M49 forms the basis of the Current Detector circuit. Its supplies are bootstrapped via TP29 to the junction of R144 and R112 in the 1V Buffer output. Q82 and Q84 provide constant current drive to 6.2V Zeners D40 and D41, with Q83 and Q85 providing the regulation for the bootstrapped rails at TP35 and TP36.

The comparator latching levels are set by dividers R151/R152 and R153/R154, their values allowing for bias current error in R144. The comparator's output is open-collector when the peak voltage across R144 is less than the positive or negative latch level. Line drivers Q90 and Q91 are cut off, so the LIM ST line at J6-70 is pulled to +15V by AN2 in the Reference Divider (page 11.4-4).

When the level is exceeded in either polarity, then either M49a or M49b output goes negative. This turns Q90 and Q91 on, pulling the $\overline{\text{LIM ST}}$ line to -15V (in-guard logic- \emptyset). The signal is passed to the CPU via the serial data link.

This limit is set much lower than the hard current limit of the buffer. If exceeded, the instrument displays 'Error OL', described in *Section 2* (Fault Diagnosis). In overload at 35-40mA, a built-in margin of safety allows the instrument to meet most of its specifications.

9.3.2 ADC - DAC TRACKING

As mentioned earlier, it is necessary to track the coarse gain stepping rate to the settling time imposed by the DC Reference filtering. A tracking Analog-to-Digital Converter (ADC) is used to synchronize stepping, ensuring the fastest possible settling time at the selected frequency.

To set circuit conditions for the required output within a range, the gain of the main VCA is set in response to fine amplitude information, in the form of an error signal from the Sine/Quasi-Sine comparator. For constant output amplitude loop gain, the error loop gain also needs to track the coarse amplitude stepping.

For an outline of the Output Amplitude Control System, refer to the descriptions in *sub-sections 9.1 and 9.2*.

9.3.2.1 Use of 'REF+' (Circuit Diagram 430446 page 11.6-3)

The ADC requires a voltage input which tracks the value of instrument AC output demanded by the user, with settling times imposed by the Reference filter. The DC 'REF+' voltage exhibits these characteristics, so is used in this circuit to determine the numerical value of the ADC binary output.

'REF+' originates in the Reference Divider and is used to set the peak value of the quasi-sinewave in the AC assembly. Its value ranges from +0.126V at 9% of Full Range, through +1.397V at Full Range, to +2.794V at Full Scale.

REF+ is input to the Sine-Source assembly at J6-57 and J6-56, then applied to amplifier M41b, which is connected to remove any common mode present at its input. Thus at TP47, M41b output is referred to Common-2A.

Capacitors C99, C130 and C131 filter any HF pickup from the reference voltage, and M41b scales up the DC voltage levels by a factor of 2.43, to:

9% of Full Range	: -0.306V,
Full Range	: -3.395V,
Full Scale	: -6.789V.

A fixed positive version of this Full Scale value is also generated (Q66/D30/D31) as a reference for the tracking ADC M38 at M38-27.

9.3.2.2 Tracking ADC M38 (Fig.9.4)

M38 is a 'System DAC' which can be employed either in 'READ' or 'WRITE' mode. WRITE mode is not used for this function.

In READ mode the binary count can be output continuously from the ten pins $DB_{9,0}$. An internal 10-bit counter is clocked at 16kHz into pin 9 via level shifters Q53 and Q54. The counter can be controlled by two level-sensitive inputs: CONT 1 and CONT 2 (logic-1 = +5V; logic- \emptyset = 0V) as follows:

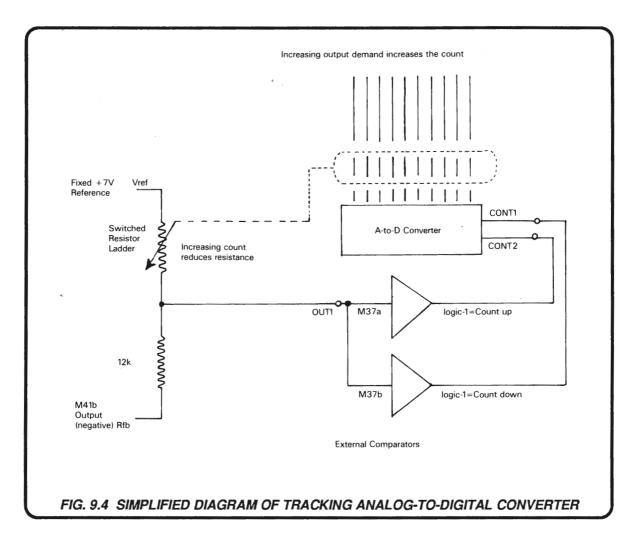
CONT 1	CONT 2	Effect on Count
ø	ø	not used
ø	1	Incremented
1	ø	Decremented
1	1	Frozen

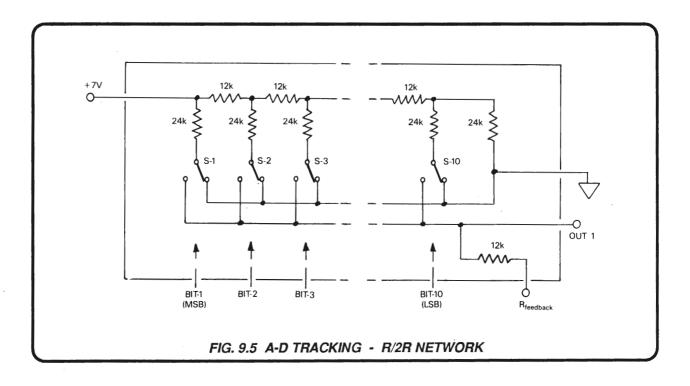
An internal $12k\Omega$ reference resistor and switched resistor ladder form a divider between pin 27 (V_{REF}) and pin 1 (R_{FB}). Their junction is brought out to pin 2 (OUT 1). (See Figs. 9.4 and 9.5.)

The ladder is switched by the 10-bit counter. At zero count it is open-circuit; as the count is increased the ladder resistance reduces in inverse proportion, until at full count of 2^{11} - 1 (corresponding to the instrument Full Scale output), it reaches its minimum of $12k\Omega$.

At Full Scale (FS) the M41b output voltage is -6.789V, into R_{FB} , and the fixed reference into V_{REF} is the positive version of this input, so at FS the OUT 1 voltage is balanced at zero.

For instrument output values below FS, the negative M41b output voltage is linearly reduced, so that the OUT 1 voltage tends to increase positively. By feeding an external comparator which drives the CONT 1 and CONT 2 counter controls, the OUT 1 voltage is used to provide automatic control of the count itself. In the case of a reduced output demand, a lower count is required to increase the resistance of the ladder, resetting OUT 1 to the zero balance.





9.3.2.3 Window Comparator

M37 is a high-speed dual comparator, which accepts OUT 1 as its input voltage, and controls the M38 counter via its CONT 1 and CONT 2 inputs. The 'Counter Freeze' condition of M38, resulting from both CONT inputs being at logic-1, allows hysteresis bias to be applied the comparator to create a 'Dead Band' window.

Each of the two outputs of M37 responds to its input in the same way: high impedance when its non-inverting input is more positive than its inverting input, and pulled low when the inverting input is more positive (uncommitted-collector).

M37a is connected as a non-inverting device, but M37b inverts its input. OUT 1 is input to both circuits. Both inputs are biassed by approximately 15mV to generate the dead-band hysteresis: M37a by R96/R98, R37b by R100/R101.

9.3.2.4 Action for OUT 1 = Zero

Because of the bias, both M37 outputs are pulled low when the voltage at OUT 1 is zero. The inverting level-shifters Q67 and Q68 are both cut off by -15V on their gates, so CONT 1 and CONT 2 are at logic-1. M38 is thus put in the 'Freeze' condition, so its 10-bit output value is held.

In this condition, M36-12 and M36-13 inputs are both at -15V, so M36-10 is also -15V. R99 is therefore placed in parallel with R100, increasing the bias on M37b. The bias on M37a is also increased by Q69 being cut off, placing AN11 and R97 in parallel with R96. The 'Freeze' window is therefore widened, to improve the comparator's noise rejection. (*Refer to Fig. 9.6.*)

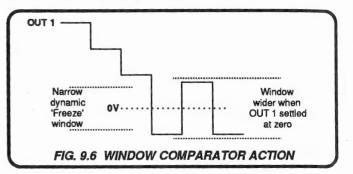
9.3.2.5 Action when OUT 1 Voltage Changes

When a user demands a new (greater) output from the instrument, REF+ increases as the Reference filter settles, and the OUT 1 voltage becomes more negative. The bias on M37b is eroded and finally exceeded, so M37-7 is placed at high impedance, pulled up to Common-2C by AN13. Q67 conducts setting CONT 1 to logic-Ø, which increments the count to step up the gain in the 1V Buffer.

Simultaneously, M36-12 is set to 0V (in guard logic-1). M36-10 rises from -15V to 0V, switching R99 to shunt R101 instead of shunting R100. Q69 conducts, switching R97 to shunt R98 instead of shunting R96. The bias levels shift back to 15mV, narrowing the hysteresis window.

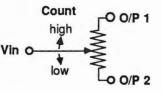
If the user had demanded a lower output, OUT 1 would have become more positive, exceeding M37a bias. CONT 2 would have fallen to logic-Ø, decrementing the counter and reducing the 1V Buffer gain. The effect on the comparator bias would be the same as for the incrementing case.

As the counter changes its numerical value, M38's internal resistance ladder is switched to back-off the OUT 1 voltage. When REF+ finally settles, the OUT 1 voltage once again enters (and widens) the comparator's dead band, The count freezes, and the 1V Buffer gain remains constant. Thus the OUT 1 voltage remains close to zero as the comparator and tracking ADC have a sensitive response to the variations of REF+; but once settled, the wider hysteresis window prevents the comparator from responding to noise.



9.3.2.6 10-bit Digital-to-Analog Converters

M42 and M43 binary inputs are identically connected, so they both behave in the same way:



For low counts the resistance between Vin and O/P 1 is large, and small between Vin and O/P 2. The condition is incrementally reversed as the count increases to high values.

M43

As we have seen; an increase in user output demand increases the DC Reference voltage REF+, so a higher ADC count results. This reduces the resistance between M43 pins 15 (Vin) and 1 (O/P 1), and increases the resistance between Vin and O/P 2; increasing the gain of the 1V Buffer and thus increasing the instrument output. This is the stepped coarse gain adjustment referred to in *sub-section 9.2*.

M42

M42 has a different function. The fine adjustment of output value is incorporated in the 'Gain Error Loop', in which the output sinewave and quasi-sinewave are compared. This comparison generates the 'AC AMPL ERROR', to be used in controlling the VCA gain.

The error loop thus also passes through the 1V Buffer, and the effect of an increase in ADC count would be to increase the error loop gain, possibly overloading the VCA input FETs. This is prevented by reducing the gain of the error amplifier M41a, using M42 to track the steps of the coarse gain adjustment.

With an increase of the ADC count, M41a feedback is increased, as the resistance between M42 pins 15 and 1 is reduced. This reduces the error loop gain to compensate for the increase due to M43. Thus the fine gain remains virtually constant over the full span of coarse gain adjustment.

9.4 AC LOW VOLTAGE LOOP

The circuits described in this section perform the following functions:

- Connect the VCA (1V buffer) output to the instrument's terminals to provide the AC 1V Range: 0.09V to 2V.
- Amplify the VCA output voltages and connect to the terminals for the AC 10V Range: 0.9V to 20V.
- Passively attenuate the basic AC 1V range voltages to provide the millivolt range outputs:
 Om V to 200m V on the AC 100m V Pange

$\mathbf{y}\mathbf{m}\mathbf{v}$ to $200\mathbf{m}\mathbf{v}$	on the	AC 100m v Kange
0.9mV to 20mV	on the	AC 10mV Range
90µV to 2mV	on the	AC 1mV Range

• Sense the voltages at the output terminals (or at the load in Remote Sense) and scale the signal to the 1V RMS Full-Range level for comparison with the quasi-sinewave.

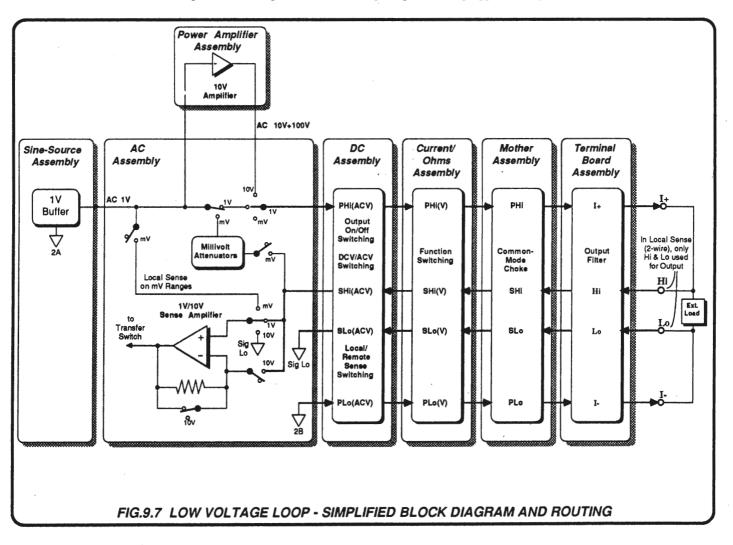
- Provide switching of AC voltage output, Range, Guard and Sense, under the control of signals from the Analog Control Interface.
- Detect excess currents in the output circuit, providing a status signal to the CPU via the Analog Control Interface.
- Detect excess voltages on the PHi (I+) output line, providing a status signal to the CPU via the Analog Control Interface.

The circuits in this section are located as follows:

Millivolt attenuator and sensing: Power amplification: Output control: Output Terminals:

AC Assembly. Power Amplifier Assembly. DC Assembly. Mother Assembly. Terminal Board.





9.4.1 GENERAL

The following description follows the 1V range path from the VCA buffer to the Sine/Quasi-Sine Comparator (at the input of the transfer switch M16). The 10V and millivolts outputs and sense conditioning are included, the outputs also being sourced from the 1V Buffer.

9.4.2 1V LOOP - POWER DELIVERY

9.4.2.1 Sine-Source Assembly

(Circuit diagram 430446 Page 11.6-3)

The 1V Buffer (page 11.6-3) is described in sub-section 9.3, as part of the output amplitude control circuitry. Its output sinewave, signal 'AC 1V' ranging between 0.09V and 2V RMS; is fed out of the Sine-Source assembly on J6-41, via the Mother assembly, and input to the AC assembly on J7-41 (page 11.7-1).

9.4.2.2 AC Assembly

(Circuit diagram 430663 Page 11.7-1)

With the 1V Range selected, relays RL7 (1V) and RL19 (1kV) are energized, but relays RL4, 5, 6, 17, 18 and 20 are not. Therefore the AC 1V signal is passed directly out of the AC assembly via RL7, iuse F1, RL19 and fuse F2 to become the Power-Hi signal PHI(ACV)' at J7-27.

The power common 'PLO(ACV)' is sourced from the in-guard lommon-2 supply at the star-point Common-2B, passing out via he energized contacts of AC Voltage selector relay RL10, to J7-31.

HI(ACV) and PLO(ACV) travel via the Mother assembly to the IC assembly at J5-25 and J5-29 respectively (*Page 11.5-2*).

On the circuit diagrams, the relay contacts are shown in the unactivated condition. 111

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For High Voltage output and High Voltage sense attenuation refer to Sections 9.5 and 9.6.

9.4.2.3 DC Assembly

(Circuit diagram 430536 Page 11.5-2)

Output Switching

The PHI and PLO (ACV) connections are passed to the instrument output terminals via several relay contacts which provide switching for Remote or Local Sense, Remote or Local Guard, and Output On/Off.

The terminal lines are switched for function changes on the Current/Ohms assembly.

ACV/DCV Switching

For AC voltage outputs, relays RL10 and RL11 are un-energized. The PHI(ACV) line for the 1V range bypasses the 1kV Range current sensing resistors R107 and R108, via contacts 7/10 of the unenergized relay RL13. It then passes directly via TP8, 1A fuse F6, and RL15 contacts (if output is set ON); to the PHI(V) line at J5-19.

When in Remote Sense, the power return line PLO(ACV) is linked from J5-29, via 1A fuses F4 and F3, RL14 and RL15 contacts to become PLO(V) at J5-23.

(For DC voltage outputs, the four ACV lines at J5-25/26/29/30 are disconnected by the Range relays and the ACV relay RL10 in the AC assembly).

4.2.4 Connections to the Terminals (Section 7)

the PHI(V) and PLO(V) lines are routed to the I+ and I- terminals the front panel exactly as for DC 1V Range outputs.

scriptions of the processing and routing can be found in the lowing sub-sections of *Section* 7:

Output On/Off:	7.3.6.2
Remote Sense:	7.3.6.3
Remote Guard:	7.3.6.4
Overvoltage Detection:	7.3.7.2
Output to Terminals:	7.3.8

9.4.3 AC 1V LOOP - OUTPUT SENSING

The SHI(V) and SLO(V) lines are routed from the Hi and Lo terminals on the front panel exactly as for DC 1V Range outputs.

9.4.3.1 DC Assembly

(Circuit diagram 430536 Page 11.5-2)

In normal 4-wire operation (Remote Sense selected) with OUTPUT 'ON' on the AC 1V Range, relays RL14 and 15 are energized; RL10 and 11 are un-energized.

SHI(V) enters from the Mother assembly at J5-20, passing directly through RL15 contacts, TP9 and R98, to J5-26 as SHI(ACV).

SLO(V) travels via RL15 contacts and TP10 to J5-30 as SLO(ACV).

With Remote Sense not selected, relay RL14 is unenergized: RL14-9/8 short SHI(V) to the power Hi output PHI(V). RL14-2/3 short SLO(V) to the power Lo output PLO(V).

SHI(ACV) and SLO(ACV) are routed from J5-26 and J5-30 via the Mother assembly to the AC assembly.

The processing and routing back to the DC assembly is described in *Section 7, sub-sections 7.3.9.1 to 7.3.9.3*.

9.4.3.2 AC Assembly (Circuit diagram 430663 Page 11.7-1)

SLO(ACV) passes via the energized contact of the AC Voltage selector relay RL10, to be referred to the Sine/Quasi-Sine comparator transfer switch common 'SIG LO'.

With the 1V Range selected, relay RL19 ($\overline{1kV}$) contacts are closed, so SHI(ACV) appears at RL19-11 as 'SENSE Hi'. (Refer to the circuit diagram on page 11.7-2.)

With the 1V Range selected, relay RL8 (1V) is energized, thus SENSE Hi is applied to the non-inverting input of the Sense Amplifier via R126. RL14 is un-energized as shown, so the inverting input via R115 is referred to SIG LO.

RL3 ($\overline{100V+1kV}$) is energized, connecting the Sense Amplifier output to the Sine/Quasi-Sine comparator transfer switch M16-11 (*page 11.7-3*). The amplifier is described in *sub-section 9.4.4*.

9.4.4 AC 1V SENSE AMPLIFIER (Circuit Diagram 430663 page 11.7-2)

The same amplifier is used on the 10V, 1V, 100mV, 10mV and 1mV AC Ranges. Its main purpose is to buffer the sense voltage, providing a high impedance input, low DC offset and flat frequency response.

On the AC 1V and millivolt ranges it is connected as a voltagefollower, sensing always being carried out at the 1V level. The 1V Range sense signal originates at the load in remote sense, or in the DC assembly in local sense.

9.4.4.1 General Arrangement

A discrete amplifier is used to provide the required slew rate up to 1MHz, all time constants being set well above 1MHz, with the first pole above 5MHz. It is configured into its follower circuit by relay switching.

Relays RL8, RL12 and RL3 are all energized on the 1V range. Relays RL11, RL13, RL14, RL15 and RL16 remain un-energized as shown in the diagram.

Dual JFET Q41 is a unity gain buffer in totem pole configuration. It drives the input protection diodes D37-D40, D44-D47; the screen on Q40 inverting input; and the bootstrap buffer Q46. The total input capacitance is thus reduced to 1-1.5pF.

The differential input amplifier, dual FET Q40, has low input capacitance and low input current. Q36 provides constant-current drive to Q40 and the bootstrapped followers Q38/Q39. R107 permits initial DC input-offset cancellation. The stage gain is low.

For the millivolt ranges the 'AC 1V' drive signal to the millivolt attenuators is sensed directly (see sub-section 9.4.5).

On the AC 10V range an inverting configuration is employed. The circuit divides by 10, scaling the sense signal down to 1V range levels, for input to the Sine/Quasi-Sine comparator.

Separate arrangements are made for attenuation and scaling on the 100V and 1kV AC ranges. These are described in *Section 9.6*.

Emitter-followers Q34 and Q35 buffer the high-impedance low-gain FET stage, driving a differential signal into the high gain voltage amplifier Q29/Q30. This arrangement has the advantage of placing all the gain in one stage. The single-ended drive to Q31 output stage is taken from Q30 collector.

Q24 and Q25 form a current mirror to equallize the collector currents of Q29 and Q30, preventing signal injection into the sense amplifier power rails.

L6 and L7 isolate the amplifier power rails from the 15V supply at HF. C50 is the main frequency-response compensation capacitor, providing smooth roll-off, with unity gain at around 5MHz.

On the 1V Range, the output from Q31 is returned at low impedance, as 100% negative feedback to the amplifier input, via the closed contacts of RL12-8/14.

9.4.5 MILLIVOLT LOOP

(Circuit Diagram 430663 pages 11.7-1 and 11.7-2)

The basic 1V loop is extended by inserting a switched, passive, attenuator network. The switching circuit connects the selected millivolt output via RL4-13/9 and RL19-11/8 directly to the SHI(ACV) line, not 'PHI'. Thus only the two front panel Sense Hi and Lo terminals are used to connect to the load.

The software forces Remote Sense OFF in the millivolt ranges. Except for a series resistor (R154) on the 1mV range, the AC 1V signal is connected directly to the input of the Sense Amplifier via

9.4.5.1 Millivolt Attenuators (Fig. 9.8)

The AC 1V signal is diverted from its 1V range route by contacts 13/11 of un-energized relay RL7, and applied to the attenuator network.

The fixed chain (formed by R120 in series with the parallel combination of R112B and R110) is permanently connected between RL7-11 and the Common-2 star-point. Three levels of attenuation are achieved by switching R112A and R118. Relay RL5 is energized for the 10mV range only, RL6 for the 100mV range.

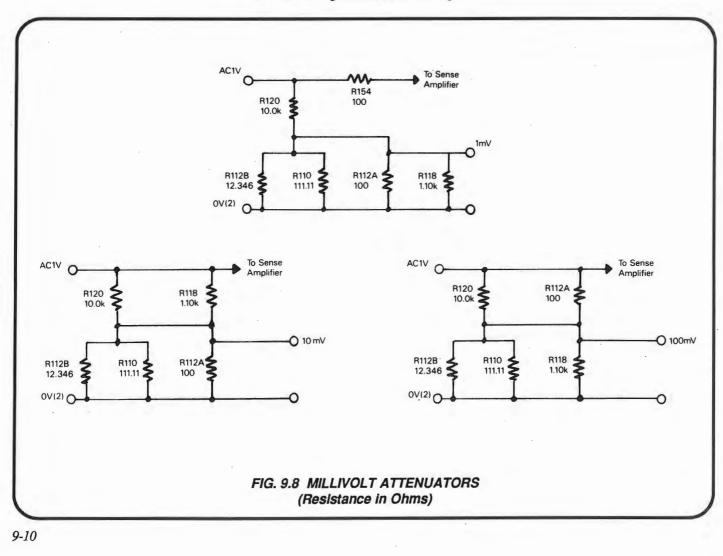
RL11-4/5 at RL8-13. The amplifier circuit remains permanently in its non-inverting configuration for all three millivolt ranges, so local sensing is carried out at 1V range levels.

Thus the output value at the terminals depends on both the calibrated value of the AC 1V signal and the division ratio of the attenuator. In addition to the 1V range calibration, each millivolt range is also 'Autocalibrated' separately (*refer to Section 1*).

On the 1mV range, the series resistor R154 is connected between RL7-11 and the Sense Amplifier input via RL11-5, but it is shorted on the 10mV and 100mV ranges by the closed contacts of RL5 and RL6 respectively.

Relay RL4 is energized on all millivolt ranges. The attenuator output is passed out via RL4-8/9 and RL19-11/8 to the SHI(ACV) line. C89 defines the specified bandwidth, filtering noise at HF.

The three arrangements are shown in Fig. 9.8.



9.4.6 10V LOOP

(Circuit Diagrams: 430446 page 11.6-3, 430618 page 11.9-1/2 and 430663 page 11.7-1)

As noted in *sub-section 9.4.1*, the 1V Buffer is part of the power delivery system for all ranges. On the 10V range its output (AC 1V) passes via J6-41 from the Sine-Source assembly and into the Power Amplifier assembly (PA) at J9-36 (*page 11.9-2*).

The AC1V signal is amplified by a factor of 10 in the inverting 10V Power Amplifier, whose output is placed on the 'AC 10V+100V' line. This 10V range signal returns to the AC assembly at relay contacts RL17-13/4. It passes through RL19-2/5 to the PHI(ACV) line at J7-27.

9.4.7 10V POWER AMPLIFIER (Circuit Diagram 430618 page 11.9-2)

The AC 1V signal enters the PA assembly at J9-36, passing to the input of the 10V Amplifier via relays RL4-9/13 and RL3-9/13. It is referred to Common-2B by developing a voltage across R124.

9.4.7.1 DC Path

The DC path is blocked by C56; M17 is the DC input amplifier, connected as an integrator with diode clamping. M19 operates as an inverter in open loop, so applies high DC gain to the output from M17 on M19-2.

The output from M19 drives both halves of the symmetrical, inverting, discrete power amplifier through current-limiters Q21 and Q24, and is buffered by emitter-followers Q22 and Q23. Commonemitters Q27 and Q29 form a voltage amplifier, driving the complementary output stage Q32 and Q33. Input and feedback resistors R119 and R120 set the gain of the discrete stages to approximately 4.5.

The forward amplification contains three inversions, DC negative feedback being applied to M17 inverting input by R122, defining an overall gain of 10 in conjunction with input resistor R123.

The DC path senses and corrects the DC offsets throughout the whole AC amplifier, referring the output to Common-2A at M17-3.

9.4.7.2 AC Path

The AC path is blocked by the integrator M17, but is applied to the non-inverting input of M19 through the coupling capacitor C56. M19 operates in open loop, applying its output to the discrete power amplifier (see 9.4.7.1 above).

The amplifier AC gain is also set to 10 by R122 and R123, the circuit time constants being selected to allow overall instrument output operation over the full frequency range of 10Hz to 1MHz.

9.4.7.3 Power Supplies

M17 and M19 are supplied from $\pm 15V$ common-2A rails, but the discrete amplifier receives power from the $\pm 38V$ supply.

The 10V range outputs then follow the same route (to and from the output terminals) as the 1V signals. Whether in Remote Sense or not, the sensed voltages return via the SHI(ACV) line to the same Sense Amplifier used for 1V range signals.

With 10V range selected, the sense amplifier has an inverting gain of 0.1, returning the signal to the 1V Range levels required by the Sine/Quasi-Sine comparator.

The amplifier has already been described for the DC 10V Range; in this text, the effects on the 10V AC Range of its separate DC and AC paths are considered below.

9.4.7.4 Overload Detection

The 10V FLAG line, connected to TP12, is pulled up to 0V (inguard logic-1) in the Reference Divider assembly (*page 11.4-4*) by AN2-9/1 (1M Ω). The Error OL message results from this line being driven to logic- \emptyset .

RL8 is energized for the AC 10V Range, so overload detector Q31 reaches Vbe threshold on output current peaks, when the RMS value in R139/R172 and R141 exceeds approximately 80mA. Similarly, Q34 detects peak currents in R147 and R149/R173. In either case, Q34 conducts, pulling TP12 down to -15.7V. The 10V FLAG line is driven to logic-Ø, so the status message is returned to the CPU via the SSDA serial interface, and the Error OL message is displayed.

This does not preclude further increase in output current, but the accuracy specification is not guaranteed.

9.4.7.5 Overload Limiting

If the RMS output current increases to approximately 100mA, the peaks of current cause the V_{be} threshold of Q28 or Q30 to be exceeded, shunting the base current of the corresponding voltage amplifier. This hard-limits the output drive to the final stage.

9.4.7.6 Output Protection

The output current passes through the combination of R144 and L8. At low frequencies the inductor provides a low output impedance, whereas at high frequencies the resistor stabilizes the amplifier when driving capacitive loads.

9.4.8 **10V SENSE AMPLIFIER** (Circuit Diagram 430663 page 11.7-2)

9.4.8.1 General

A common sense amplifier is used for the 10V, 1V, 100mV, 10mV and 1mV Ranges. Its main purpose is to buffer the sense voltage, providing a high impedance input, low DC offset and flat frequency response.

The operation of the Sense Amplifier for the AC 1V and millivolt ranges, is described in para 9.4.4.1. For these ranges it is connected as a voltage-follower.

The AC millivolt ranges' outputs are simply the AC 1V range after passive attenuation; these levels are not sensed directly. The AC 1V signal is sensed before attenuation.

On the 10V range an inverting configuration is employed. The circuit divides by 10, scaling the sense signal down to 1V range levels, for input to the Sine/Quasi-Sine comparator.

Separate arrangements are made for attenuation and scaling on the 100V and 1kV ranges. These are described in sub-section 9.6.

9.4.8.2 **10V Range Configuration**

On the 10V Range, relays RL14 and RL3 are both energized. Relays RL8, RL11, RL12, RL13, RL15 and RL16 remain un-energized as shown in the diagram.

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The 'SENSE HI' signal is routed to the inverting input of the amplifier through the closed contacts of RL14 and resistor R115. With relays RL8 and RL11 not energized, the non-inverting input is referred to SIG LO.

The output from Q31 is returned via R121 as negative feedback to the amplifier input, the contacts of RL12-8/14 being open.

Thus the circuit is configured as an inverting amplifier, resistors R115 and R121 scaling the sense signal down by a factor of 10. Extensive screening is employed at the amplifier's virtual ground, bootstrapped by buffers Q46 and Q41 to follow the virtual-common potential. This reduces the input capacitance, which is further compensated by feedback capacitor C60.

9.5 AC HIGH VOLTAGE LOOPS

The Model 4705 includes two high voltage AC ranges: The nominal 100V full range extends from 9V to 200V full scale. The nominal 1000V AC range covers the span from 90V to 1100V.

9.5.1 **AC HIGH VOLTAGE DELIVERY**

Both ranges employ the same precision sinewave oscillator and VCA arrangement used for the 1V AC Range, but the techniques necessary to generate high voltages differ from those in the low voltage loops:

- On the 100V range, the AC 1V signal is switched directly into the 100V Amplifier, where it is scaled up by a factor of 100, the amplifier output being delivered via the 'AC 10V+100V' line to the PHI(ACV) line on the AC assembly.
- For the 1000V range the DC Reference is scaled in software, so that the AC 1V signal Full Scale value represents 1100V output. The signal is routed through extra stages of amplification before being applied to the 100V Amplifier, whose output now drives one of two 1:6 step-up transformers (LF or HF). The power-amplifier gain on the 1000V range is controlled by feedback from the transformer secondary, into the input of the 1000V Error Amplifier. The 'AC 1kV' line transfers the transformer output to the AC assembly, where it is switched onto the PHI(ACV) line.

Circuit Diagrams 430663 page 11.7-1 and 430618 page 11.9-1 together illustrate the high voltage AC circuit arrangement and indicate signal flow. The details of the 100V and 1000V ranges are described in sub-sections 9.6 and 9.7.

9.5.2 AC HIGH VOLTAGE SENSING

Guarded high-voltage precision attenuators reduce the AC sense voltage from the Hi and Lo terminals to 1V Range levels. The attenuated voltage is compared with the quasi-sinewave voltage, their mean-square difference being used as an error signal to correct the range output level by controlling the gain of the VCA.

9.6.1 INTRODUCTION

(Circuit Diagram 430618 page 11.9-1)

The AC 1V signal, generated by the 1V Buffer in the Sine-Source assembly, enters the Power Amplifier as for the 10V range; but the 10V Amplifier is bypassed for the high voltage ranges.

On the 100V range, the signal is switched directly into the 100V Amplifier, where it is scaled up by a factor of 100, the amplifier output being delivered via the 'AC 10V+100V' line to the PHI(ACV) line on the AC assembly. Thereafter the output is transferred to the instrument terminals as for the 10V range.

9.6.2 AC 100V RANGE POWER ROUTING (Circuit Diagrams: 430618 pages 11.9-2 and 11.9-3; 430663 page 11.7-1)

'AC 1V' enters the Power Amplifier assembly at J9-36 (page 11.9-2). Relay RL3 is un-energized, shorting the 10V Amplifier input; and RL4 is energized, routing the AC 1V signal to the 100V Amplifier as '100V I/P' (page 11.9-3).

Relay contacts RL2-8/4 apply the signal to the Gain Stage, which provides drive to the power amplifiers in the positive and negative heat sinks, via J3-12 and J3-11. The single-ended output from the heatsinks at J3-9 passes via R89, L7 and relay RL2-13/9, to RL3-6 (*page 11.9-2*), and onto the 'AC 10V+100V' line via RL4-4/8.

On the AC assembly (page 11.7-1), the signal is routed to the PHI(ACV) line as for the 10V range.

9.6.3 100V AMPLIFIER

The AC 1V signal enters the PA assembly at J9-36, passing to the input of the 100V Power Amplifier via closed relays RL4-9/13 and RL2-8/4. It is referred to Common-2B by developing a voltage across R72.

The 100V Amplifier is described in Section 7.8, which deals with the 100V DC outputs.

The description is sub-divided as follows:

7.8.3	100V Amplifier Introduction
7.8.3.1	Input to Gain and Driver Stages
7.8.3.2	DC Offset Correction
7.8.3.3	Signal Processing
7.8.3.4	Driver Regulator
7.8.3.5	Driver Output
7.8.4	100V Power Amplifier
7.8.4.1	Positive Heatsink Assembly
7.8.4.2	Negative Heatsink Assembly
7.8.4.3	Over-Temperature Detection
7.8.4.4	100V Output Connection
7.8.4.5	Heatsink Removal

9.6.4 POWER SUPPLIES AND PROTECTION

The power supplies and protection for the 100V Amplifier are also described in *Section 7.8*.

The description is sub-divided as follows:

7.8.5	Power Supplies and Protection Introduction	7.8.6	PA Power Supply Monitors
7.8.5.1	38V Supply	7.8.6.1	Comparator Supply Protection
	(The 38V supply circuit is also described	7.8.6.2	15V Monitor
•	in Section 6.7, para 6.7.3.4.)	7.8.6.3	38V Monitor
7.8.5.2	400V Transformation and Rectification	7.8.6.4	400V Monitor
7.8.5.3	400V Current Control		
7.8.5.4	100V Current Sense and 1kV Overvolts Detector		
	(This detector circuitry is used only for AC High		
	Voltage ranges, and is therefore described in		
	sub-sections 9.6.4.1 and 9.7.6.1 below).		

9.6.4.1 100V Current Sense (Circuit Diagram 430618 Page 11.9-6)

The 400V(2)B lines enter the Power Amplifier assembly from the PS/I Heatsink at J1-8/6 and are filtered by L1 and L2 before being applied across two neon lamps LP1 and LP3. These lamps are visible from the top and rear of the instrument when the PA board is exposed, indicating that a dangerous voltage is present.

The 400V(2)B lines continue on to power the driver stage of the 100V amplifier, where the voltage is regulated as described in *para* 7.8.3.4.

The 400V(2)C lines supply the power amplifier in the Positive and Negative Heatsinks. On the 100V range, the current in each of these lines is used as an analog of the load placed on the amplifier. (On the 1000V range, any overload is sensed by a series detector in the DC assembly.)

The '100VAC' line is set to logic-1 (0V) only when the 100V range is selected. Driver Q7 pinches off the FET switch Q6, removing the short from R37, thus allowing the overload detector to operate. In normal use, links LKB and LKC are not connected. Their test purpose is to allow the current mirrors Q1 and Q3 to be powered without the level-shifters Q2 and Q4.

Most of the positive output current for the heatsinks passes through the series combination of R34 and D27, the negative currents through R9 and D4. As the both positive and negative circuits are symmetrical, only the positive circuit is described. Current mirror Q3 diverts approx. 1.8% of the positive supply current into the level-shifter Q4, R36 and into the common reistor R37. Similarly Q1 draws current out of R37. Under no terminal load conditions these two currents are balanced, even if the output

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Any AC output load current from the power amplifier is reflected by ripple currents in both positive and negative supplies. The net instantaneous current flowing in R37 alternates in synchronism with the output cycles, its amplitude increasing as the load current increases. So the amplitude of the alternating voltage across R37 is an analog of the output load current, and can be compared against a scaled reference voltage.

voltage is high.

A window comparator is formed from the two halves of M2 and the voltage across R37 is applied to both halves. The outputs at M2-12 and M2-7 are uncommitted. Each half is biassed by 2.45V in the correct polarity, provided by the reference zeners D9 and D17 in the 400V Monitor circuit. Unless any voltage peak across R37 exceeds this level, both M2 outputs will be pulled to 0V by R20. The '100V FLAG' line (TP2) therefore remains at logic-1.

Any peak greater than 2.45V overcomes the bias on one half, causing its output to fall to -15V, resulting in the 100V FLAG line being pulled to logic- \emptyset . This signal then sets the limit detector latch M5a (page 11.9-5), as described in para 7.12.7.1.

9.7 AC 1000V RANGE

9.7.1 INTRODUCTION (Circuit Diagram 430618 page 11.9-1)

The AC 1V signal, generated by the 1V Buffer in the Sine-Source assembly, enters the Power Amplifier as for the 10V range; but the 10V Amplifier is bypassed for the high voltage ranges.

On the 1000V range, the signal is switched via the $1kV \times 2$ Amplifier and 1kV Error Amplifier, before being applied to the 100V Amplifier. The 100V Amplifier output is stepped up to 1000V Range levels by one of two (LF or HF) transformers, whose secondary voltage is delivered via the 'AC 1kV' line to the PHI(ACV) line on the AC assembly. Thereafter the output is transferred to the instrument terminals as for the 10V range.

9.7.2 1000V RANGE POWER ROUTING (Circuit Diagrams: 430618 pages 11.9-2 and 11.9-3; 430663 page 11.7-1; 430537 page 11.14-1)

'AC 1V' enters the Power Amplifier assembly at J9-36 (*page 11.9-2*). Relay RL3 is un-energized, shorting the 10V Amplifier input; and RL1 is energized, routing the AC 1V signal to the 1000V Amplifier chain.

Energized relay contacts RL1-8/4 apply the signal to the Gain x2 Stage, whose output is summed with error feedback, providing drive to the 1kV Error Amplifier.

The 1kV Error Amplifier output is passed as '1kV ERROR O/P' via relay RL1-9/13 to the 100V Amplifier (*page 11.9-3*). It is input through the contacts of un-energized relay RL2-6/4.

The output from the heatsink at J3-9 is transferred directly, as the 'OUTPUT' signal, to the '1kV ENABLE' relay contacts RL6-8 and RL6-9 (*page 11.9-2*). Relay RL7 determines whether the LF or HF transformer assembly is to be used, the OUTPUT signal being applied to the appropriate primary winding.

The secondaries of both transformers are connected into the High Voltage assembly (*page 11.14-1*). Relay RL2 or RL3 selects the appropriate output to be passed on to the AC assembly, via J1-28 and J1-22, as the AC 1kV signal.

The AC 1kV signal is also applied as the negative 'Error' feedback to the 1000V amplifier system. It passes through R138 and R155 on the PA assembly (*pages 11.9-1 and 11.9-2*), to be summed at the inverting input of M18a-2. A single net inversion is present around this loop.

On the AC assembly (*page 11.7-1*), the AC 1kV signal is routed by the contacts of energized relay RL20, and through fuse F2 to the PHI(ACV) line at J7-27.

9.7.3 1kV POWER AMPLIFIER (Circuit Diagram 430618 page 11.9-1)

Amplification to a maximum of 1100V is in four stages:

- 1. Gain x2 Stage: the AC 1V signal is HF-boosted and amplified. For the 1000V range the DC Reference is scaled in software, so that the AC 1V signal Full Scale value represents 1100V output.
- 1kV Error Amplifier: the Gain x2 Stage output is summed with error feedback from the secondary of the step-up transformer.
- 3. 100V Amplifier: possessing a gain of 100, the output from its heatsinks drives one of two (LF or HF) step-up transformers.
- 4. Step-up Transformer: a ratio of 1:6.6 (LF) or 1:6.17 (HF) allows sufficient gain in the system to provide a maximum RMS output of 1100V.

The frequency response of the amplifier is matched to the step-up transformer in use. The 'LF' signal into the amplifier is at logic-1 (0V) only when the 1kV range, and either the 100Hz or the 1kHz frequency range, is selected.

9.7.3.1 Gain x2 Stage (Circuit Diagram 430618 page 11.9-2)

The AC 1V signal is routed via relay RL1-8/4 to be developed across resistor R160. It is filtered by R162/C30 and applied to the non-inverting input of M15.

The feedback divider generates the x2 gain in M15; R159 and C67 providing HF lift to compensate the step-up transformer responses. FET Q35 adds C68 on the 100Hz and 1kHz frequency ranges, activated by the LF signal at logic-1, to boost the lift.

Output from the x2 stage is applied to the 1kV Error Amplifier via its input resistors R156/R95.

9.7.3.2 1kV Error Amplifier

The input resistance to M18a is split between R156 and R95 to allow the saturation detector to reduce the gain in the event of transformer saturation.

At the inverting input of M18a the signal input is summed with the AC 1kV negative feedback signal, output from the selected transformer secondary. The resulting error signal is amplified by the two stages of M18.

On the 100kHz frequency range, the maximum voltage available from the instrument is 750V. A tapping on the HF step-up transformer secondary reduces the maximum output to this level. The signal '1kV GAIN' is therefore set to logic- \emptyset only on the 100kHz range, cutting off FET Q19 and restoring adequate loop gain.

The second stage, M18b, adjusts the bandpass of the amplifier to match the selected step-up transformer:

100Hz and 1kHz ranges:

Q26 connects C58 and R126 across the input resistor R97; relay RL5 shorts R48, connecting C34 and R93 directly across the feedback resistor R92, also shorting C38 in the output line.

10kHz and 100kHz ranges:

Q26 connects C57 and R125 across the input resistor R97; relay RL5 shorts R47, connecting C33 and R94 directly across the feedback resistor R92, and leaves C38 dominant in the output line.

These measures give the necessary loop compensation for each transformer.

When the 1000V range is selected the amplifier output is fed to the 100V Amplifier via RL1-9/13 as the '1kV ERROR O/P' signal.

9.7.4 100V AMPLIFIER

This operates as for the 100V range, but its output signal 'OUTPUT' is fed directly to relay RL6 contacts for application to the step-up transformer.

The 100V Amplifier is described in *Section 7.8*, which deals with the 100V DC outputs.

The description is sub-divided as follows:

7.8.3	100V Amplifier Introduction
7.8.3.1	Input to Gain and Driver Stages
7.8.3.2	DC Offset Correction
7.8.3.3	Signal Processing
7.8.3.4	Driver Regulator
7.8.3.5	Driver Output
7.8.4	100V Power Amplifier
7.8.4.1	Positive Heatsink Assembly
7.8.4.2	Negative Heatsink Assembly
7.8.4.3	Over-Temperature Detection
7.8.4.4	100V Output Connection
7.8.4.5	Heatsink Removal

9.7.5 STEP-UP TRANSFORMER CIRCUITRY

9.7.5.1 '1kV ENABLE' Relay RL6

Relay RL6 allows the OUTPUT signal from the 100V Amplifier to energize a step-up transformer, providing the following conditions are met:

The $\overline{1kV}$ signal is at logic- \emptyset :

This is a processor-controlled signal, set to logic-Ø when the instrument AC output is switched on, in the 1000V range.

The watchdog has not 'Barked'.

On the PA assembly, the '1kV ENABLE' switch S1 is set to 'ENABLE'.

S1 is situated below the left-hand ejector lever (viewed from the front of the instrument), facing the rear of the instrument. It allows the high voltage to be switched off for servicing purposes. A red LED glows when all other conditions are met.

When RL6 is closed, the OUTPUT signal from the 100V Amplifier is switched through to the contacts of RL7.

9.7.5.2 LF/HF Transformer Selection

Relay RL7 is activated by the 'LF' signal, applying the 100V amplifier output to the HF step-up transformer for the 10kHz and 100kHz frequency ranges, and to the LF transformer for the 100Hz and 1kHz ranges.

The two transformers are separately located, their secondaries being connected into the High Voltage assembly. The HF transformer is selected when RL7 is un-energized, its primary being returned to Common-2C. RL7 is energized to select the LF transformer, whose primary current is sensed by the Saturation Detector.

9.7.5.3 Saturation Detector

To obtain the required performance, the LF transformer core is constructed from a material with high remanence. It is possible for the 1kV range to be deselected when the core is magnetized, and subsequently reselected in the same sense, with resultant saturation.

The Saturation Detector circuit is activated by sensing any excess primary current in R114, associated with the loss of reactance. It progressively removes the signal input to M18b during half cycles of the appropriate sense until the core recovers, then automatically returns to its quiescent mode.

The dual amplifier M20 is biassed by R115-R118 to approximately 1V on each input. Under normal operating conditions, the unsaturated core reactance holds R114 current down, so the voltage developed across R114 is insufficient to overcome the bias. The output from both amplifiers is of negative polarity, both diodes D58 and D59 are reverse-biassed, and FET Q18 is cut off by its gate being pulled down to -15V.

When the core saturates, the current in R114 rises rapidly and its voltage exceeds the bias on one of the detector amplifiers. One diode conducts, forcing Q18 into conduction; so the signal feed to M18a is shorted, the current in the transformer core is reduced to zero, and Q18 is cut off again.

On the next half-cycle the current is reversed, so saturation is reduced. If the core saturates on successive half-cycles, they again activate the detector with further reduction. The process continues until the core remains unsaturated over the full dynamic range of the primary current, when the detector becomes inactive.

9.7.6 POWER SUPPLIES AND PROTECTION

The power supplies and protection for the 100V Amplifier are described in Section 7.8.

The description is sub-divided as follows:

- 7.8.5 Power Supplies and Protection Introduction
- 7.8.5.1 38V Supply (The 38V supply circuit is more fully described in Section 6.7, para 6.7.3.4.)
- 7.8.5.2 400V Transformation and Rectification
- 7.8.5.3 400V Current Control
- 7.8.5.4 100V Current Sense and 1kV Overvolts Detector (This detector circuitry is used only for AC High Voltage ranges, and is therefore described in sub-sections 9.6.4.1, and 9.7.6.1 below).
- 7.8.6 PA Power Supply Monitors
- 7.8.6.1 Comparator Supply Protection
- 7.8.6.2 15V Monitor
- 7.8.6.3 38V Monitor
- 7.8.6.4 400V Monitor

9.7.6.1 AC 1kV Overvoltage Detector (Circuit diagram 430618 Page 11.9-6)

On the 1000V Range the primary voltage of the step-up transformer in use is fed as 'AC OVERVOLTAGE DRIVE' from RL6-4/13 (page 11.9-2), via R176 and a screened lead, to the M2 comparator input (page 11.9.6). (The operation of the comparator is described for the 100V Current Sense application in Section 9.6, para 9.6.4.) On the 1000V Range the 100V overcurrent sense resistor R37 is shorted by Q6, whose gate is driven by $\overline{100V \text{ AC}}$ at logic-1.

The HF (1:6.17) step-up transformer primary voltage is divided by R176 and R180 (ie by 1/116), but for the LF (1:6.6) transformer R181 shunts R180 (increasing the division ratio to 1/124.5), activated by the \overline{LF} signal and Q43. The result is that overvoltage is detected on the HF transformer primary at approx. 305V, but on the LF transformer primary at approx. 285V. Taking the step-up ratios into account, the 1kV Overvolts Detector trips at LF or HF for the same secondary voltage: approx. 1880V peak, 1330V RMS. This in turn activates the 100V FLAG signal as on the 100V Range.

9.7.6.2 AC 1kV Overcurrent Detector (Circuit Diagram 430536 Page 11.5-2)

For the AC 1000V range, so as to protect the step-up transformers, overloads are detected directly in the output lines to the terminals. For this range only, resistance is inserted in the PHI(ACV) line in the DC assembly. The voltage across the resistance is rectified and compared against a reference. If the voltage is excessive, the comparator generates a LIM DET signal. At higher frequencies, where the internal and external connections to the load will draw extra capacitive current, part of the resistance is short circuited.

The 'AC 1kV RANGE' signal enters at J5-102 (page 11.5-3). This is at logic-1 to energize relay RL13, only if the 1000V range is selected. RL13 removes the short from R107 and R108.

The 'HIGH I LIMIT' signal enters at J5-98 (also on page 11.5-3). When the 1000V range is selected, this is at logic-1 only for the 10kHz, 100kHz and 1MHz frequency ranges. It energizes relay RL12, shorting R108, so that higher currents are required to trip the LIM DET signal. As frequency increases, so do the currents taken by the capacitance of the internal tracking and wiring; R107 is compensated by C45 and C49 to bypass this extra capacitive loading.

A diode-bridge rectifies the voltage developed across the selected resistor(s). The voltage is limited to 10V by D31, and resistor R84 sets the trip current level for the opto-isolator M19.

The isolator operates from the 5 volts between -10V and -15V. In normal operation M19 output at M19-6 is open-collector so Q4 does not conduct. When the output current is sufficient to trip M19, Q4 emitter is pulled low and so Q4 conducts, its collector current being drawn through R79.

M18 is a switch which under no-overload conditions is biassed by R79 to +15V; and with its output at -15V, its non-inverting input is set to approx. -2V. When Q4 conducts, its collector is pulled down close to the -15V rail voltage. This is applied to the inverting input of M18, whose output reverses to +15V providing a positive trigger edge to M12-4.

For AC outputs the $\overline{\text{DC FNCT}}$ signal is inactive at logic-1, M12-3 at logic-1 removes the reset which is present for all DC voltage ranges. Monostable M12 is set to produce a logic- \emptyset at its Q output (M12-6) unless its A input at M12-4 is edge-triggered positively. In normal conditions no trigger is given, so M12-6 remains at logic- \emptyset , D10 is unbiassed and the LIM DET line remains at the logic- \emptyset level of -15V.

When M18 output reverses to +15V, M12-6 produces a logic-1 (0V) pulse of 1ms duration, which forward-biasses D10, so the LIM DET line transmits a logic-1 pulse of 1ms duration. Successive positive or negative peaks of overcurrent retrigger the monostable, maintaining its Q output (and thus the LIM DET signal) at logic-1.

9.8 AC HIGH VOLTAGE SENSING

(Circuit Diagram 430663 Pages 11.7-1 and 11.7-2)

The SHI(ACV) signal, returned from the terminals via the Current and Output Control assemblies, enters the AC assembly as for the 10V range; but the 1V/10V Sense Amplifier is bypassed for the high voltage ranges.

On these ranges, the signal is switched into one of two guarded attenuators, both housed in the Attenuator/Cage assembly plugged directly into the AC assembly. Each attenuator is a separate resistor chain which acts as the input resistor to the inverting amplifier M32. The output of the amplifier is passed to the Comparator transfer switch.

9.8.1 100V SENSE AMPLIFIER

The SHI(ACV) signal passes through the contacts of energized relays RL19 and RL15, and is applied via the four pins of J1 into the 100V attenuator chain. The attenuator consists of four $25k\Omega$ 0.1% resistors in series. To eliminate leakage, each junction between the resistors is guarded, the guards being taken to equivalent voltage points on a chain of four capacitors, C64 to C67. The capacitive chain is also driven from the sense signal. The attenuator acts as the input resistor for the 100V/1000V Sense Amplifier M32.

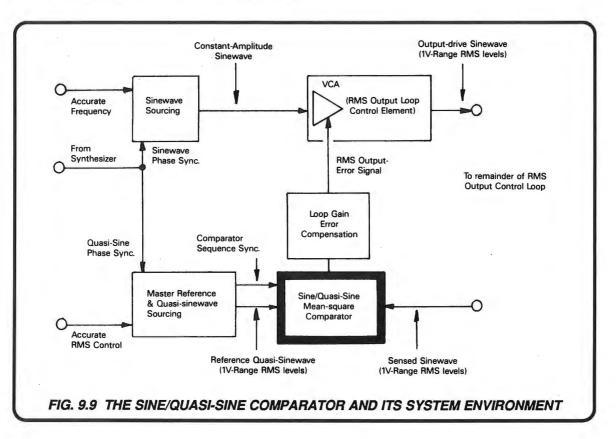
Relay RL13 is un-energized on this range, so R124 acts alone as the feedback resistor, producing an amplifier gain of 1/100. The sense signals are thus reduced to 1V range levels. The amplifier output is routed through the contacts of un-energized relay RL3 as the comparator 'SIG' input, to transfer switch M16-11 (*page 11.7-3*).

9.8.2 1000V SENSE AMPLIFIER

The SHI(ACV) signal is blocked by the contacts of un-energized relay RL15, but RL16 is energized, applying SHI(ACV) as the '1kV SENSE' signal via link LK1 into the 1000V attenuator chain. The chain has ten 50k Ω 1% resistors in series, which combine to form the input resistance for M32. The guards are taken to equivalent voltage points on a chain of eight capacitors, C70 to C77, again driven from the sense signal.

Relay RL13 is energized on the 1000V range, so R123 and R124 act in parallel as the feedback resistance, giving a gain of 1/550. The sense signals are thus reduced to 1V range levels (the 1000V range FS voltage is 1100V; the equivalent 1V range FS voltage is 2V). The amplifier output passes to the transfer switch as on the 100V range.

9.9 SINE/QUASI-SINE RMS COMPARATOR



9.9.1 PURPOSE AND ENVIRONMENT (Fig. 9.9)

The VCA acts as the control element of the Fine Amplitude Control Loop, having variable gain which is adjusted to change the output value.

The main purpose of the comparator, in conjunction with the coarse amplitude control, is to cause the output RMS value to track the value set on the front panel OUTPUT display. It generates a DC error voltage which adjusts the VCA gain.

Because it is part of the fine amplitude control loop, the comparator also corrects output RMS changes due to loading and other disturbances, within the instrument specification.

The Comparator receives two analog inputs:

- a. The reference quasi-sinewave whose RMS value is set by the value on the OUTPUT Display, and is also modified by stored calibration data (sub-section 6.6), and
- b. The sensed and conditioned output sinewave, which is compared against the reference quasi-sinewave (sub-sections 9.4 and 9.5).

The Comparator output is the DC error voltage resulting from the difference between the mean-square values of the two inputs. As the VCA gain (and hence the output RMS level) is adjusted, the RMS value of the comparator's sense input approaches that of the reference, and the error voltage is driven towards zero. The output value stabilizes when the RMS values of the two inputs are equal.

The buffered DC error signal output from the comparator is adjusted in approx. 1000ppm FS steps by the action of the Coarse Amplitude DAC, to give a virtually constant loop gain. The effects are described in *sub-section 9.3*.

9.9.2 IMPLEMENTATION

Both inputs are scaled to 1V Range levels and compared in an Integration/Sample-and-Hold system. They are sequentially steered through a common squaring circuit into separate 'REF' (Reference²) and 'SIG' (Reference² minus Sense²) averaging integrators.

A capacitor and voltage follower samples and holds the settled REF integrator voltage. It generates a DC 'REF²' signal which is subtracted from the AC 'SIG²' signal. The result is applied to the SIG integrator, then another sample-and-hold circuit generates the 'AC ERROR' signal from the integrator's output.

'AC ERROR' is thus a DC analog of the difference between the 'mean-square' values of the two inputs. It is buffered and applied to the VCA via the Error Amplifier.

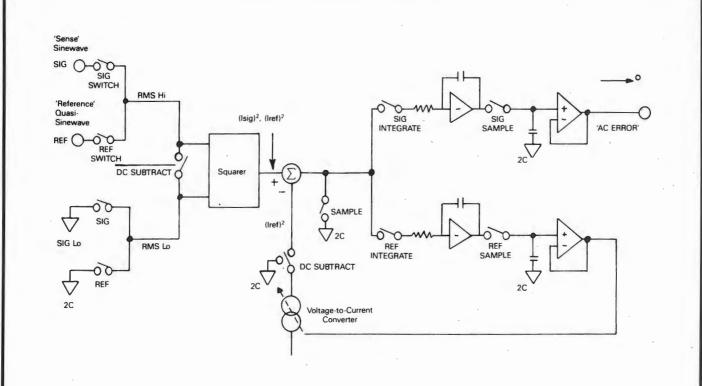
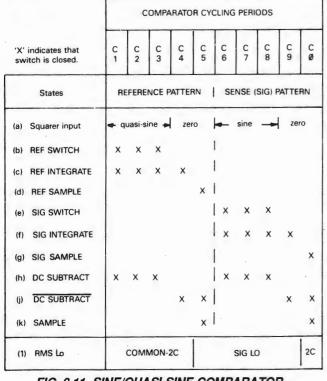
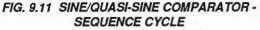


FIG. 9.10 SINE/QUASI-SINE COMPARATOR - BLOCK DIAGRAM





9.9.3 METHOD OF COMPARISON (Figs. 9.10 and 9.11)

The comparator is based on a ten-state recycling sequence of squaring, integration, sampling and subtraction. Operation and accuracy rely heavily on synchronization between sine and quasi-sine.

At relevant points in the following description, reference is made to a specific output frequency of 500Hz (1kHz Range), as an example to clarify the following points:

- a. As the output sinewave frequency is varied, the quasi-sinewave tracks an exact sub-multiple of its frequency; except on the 100Hz Range, where both are at the same frequency. In our example at 500Hz, the quasi-sinewave has half the output frequency. The various relationships between output and quasi-sinewave frequencies for different frequency ranges are detailed in Section 8, Table 8.3.
- b. The duration of each comparison cycle is always equal to ten quasi-sinewave periods (here 40ms), and each of the 'C' periods persists for one quasi-sinewave period (for 500Hz output - 4ms). This effect can be observed using an oscilloscope, say at TP46.
- c. Using this specific case also gives a point of reference for examination of the circuit waveforms using an oscilloscope.

9.9.3.1 The Comparator Sequence

(Figs. 9.10 and 9.11)

The table in Fig. 9.11 shows the conduction patterns of the switches in the block diagram of Fig. 9.10, within a complete sequence cycle. The cycle is broadly divided into two similar patterns ('REF' and 'SIG'), each occupying five quasi-sinewave periods. The cycle repeats continuously.

In the following analysis, the effects of the closed switches are described; all other switches are open.

Periods C1, C2 and C3

- a. REF SWITCH is closed to input the quasi-sinewave to the squarer.
- **b.** REF INTEGRATE steers the squarer output current into the Reference Integrator.
- c. DC SUBTRACT allows Iref² to be drawn from the summing junction.
- **d.** RMS Lo has been connected to common 2C since the start of CØ in the previous period, in preparation for REF squaring.

The quasi-sinewave is squared, and the result is output as a current (at twice the input frequency) into the summing junction. The DC current $Iref^2$ is subtracted at the junction, and the residue goes to charge the Reference Integrator capacitor.

(Note that every time that OUTPUT OFF is selected, REF and SIG integrator capacitors are discharged, driving both 'AC ERROR' and 'Iref²' to zero. During the first REF integration when OUTPUT ON is next selected, $Iref^2$ remains at zero so the integrator capacitors start charging from zero.)

Period C4

- a. REF SWITCH is opened, removing the input to the squarer.
- b. DC SUBTRACT is opened, subtraction ceases.
- c. DC SUBTRACT closes to input a hard zero to the squarer.
- d. REF INTEGRATE remains closed, allowing the squarer and integrator to settle.
- RMS Lo remains connected to Common-2C until the integrator has settled.

The REF integrator remains in its integrating (on) condition during period C4, to ensure that any energy stored in the squarer during C1 to C3 is acquired.

DC subtraction during period C4 would generate an error, as full subtraction was already applied during period C1. DC SUBTRACT is therefore turned off by transferring the source of Iref² from the summing junction to Common-2.

Period C5

- a. REF INTEGRATE opens, stopping the integrator action.
- b. SAMPLE closure forces the squarer output to a hard zero, to nullify any leakage effects in the integrator switch.
- c. REF SAMPLE closes, and current from the integrator op-amp charges the sampling capacitor to the integrator capacitor voltage.
- d. RMS Lo is switched from the Ref Common-2C to the Sense SIG Lo in preparation for SIG squaring.

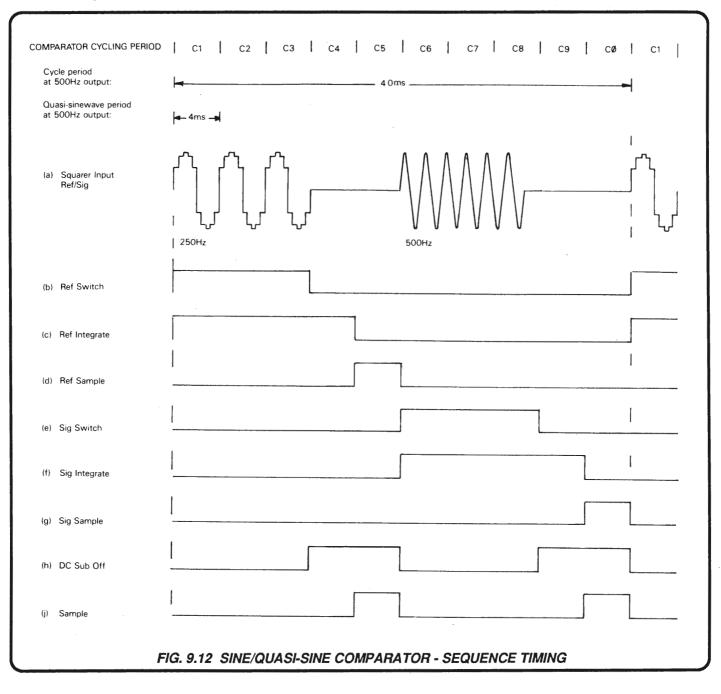
As the sampling capacitor changes its charge, its voltage-follower drives the voltage-to-current converter to change the DC subtraction current. The new $Iref^2$ is sourced from Common-2 during this period, but during the next SIG and REF integration periods, it will be subtracted from the squarer output current at the summing junction.

Periods C6 to CØ

As can be seen from *Fig. 9.11*, the closure pattern is repeated for SIG squaring, integration and sampling. The SIG circuit action is identical to REF, except that:

- a. the squarer input is now the sensed sinewave;
- the subtraction current has been set to a new value during period C5. This does not change again until period C5 of the next cycle;
- c. During period CØ, the 'AC ERROR' output from the SIG sample-and-hold voltage follower is changed, updating the VCA gain via the Error Buffer and Error Amplifier.
- d. RMS Lo was switched from Common-2C to SIG Lo during period C5 in preparation for SIG squaring. It remains connected to SIG Lo during the squaring periods C6, C7 and C8, and also during period C9 for the Sig Integrator settling. At Period CØ it is reconnected to Common-2C in preparation for REF squaring.

9.9.3.2 Comparator Action



The sequence described in 9.9.3.1 is necessarily simplified. When a new output demand changes the amplitude of the quasi-sinewave, a few sequence cycles are required to stabilize the conditions of the Ref integrator, Sig integrator, subtraction current and AC ERROR output. The circuit must also respond to demands for reduced output in addition to those for increases.

The comparator forms part of the output amplitude control loop, ultimately affecting the output voltage and hence the sensed voltage input to the squarer as 'SIG'. As the sequence recycles, the meansquare value of the SIG input sinewave will approach that of the REF quasi-sinewave, and as it does so the AC ERROR output must approach a steady-state value. The squarer output current has an AC component in its waveform, but Iref^2 being subtracted at the summing junction is a DC current. In the settled condition, Iref^2 is driven on successive cycles to balance the quasi-sinewave REF² AC current (being applied to its integrator) about zero. The final level of Iref^2 is just sufficient to be self-sustaining.

Meanwhile, the sensed SIG² current approaches the REF² value, and the same Iref² is a DC analog of the quasi-sinewave mean-square voltage. In the output loop, the VCA is driven until the instrument output (and sensed SIG input) is at the correct level just to generate a self-sustaining 'AC ERROR'. In the comparator, Iref² is subtracted from both SIG² and REF² currents. This maintains the AC AMPL ERROR as an analog of the difference between the quasi-sinewave and the output sinewave mean-square voltages (when the latter is reduced by sense conditioning to 1V Range levels). Thus when the sensed SIG input voltage approaches the quasi-sinewave REF voltage (mean-square values), the AC ERROR approaches stability and the system settles.

A further complication: a bias is applied to the squaring circuit to avoid distortion by maintaining permanent conduction. The bias is controlled by the value of the positive reference voltage, and a bias current is superimposed on the subtraction current. These factors will be discussed later during the circuit analysis.

9.9.4 COMPARATOR CONTROL LOGIC

(Circuit Diagram 430663 page 11.7-3)

The Comparator operating cycle originates at M15, which is a 10-bit sequencing counter, clocked at the quasi-sinewave frequency by the carry-out from M11-12.

The SYNC \emptyset input to M15 RESET is a decoded address, whose function at logic-1 is to disable counters M11 and M15, inhibiting operation of the comparator and generation of the quasi-sinewave. In this instrument, SYNC \emptyset is held permanently at logic- \emptyset , enabling both quasi-sinewave and comparator for AC Voltage and Current functions.

The clock continuously recycles M15 in ascending count through Q_{\emptyset} to Q_9 , ten clocks (ie ten quasi-sinewave periods) constituting one cycle of the comparator sequence. Only one 'Q' output is at logic-1 (+8V) at a time, the remainder being at logic- \emptyset (-8V).

With increase of frequency range, the difference between the frequencies of sensed sinewave and reference quasi-sinewave increases in decade steps. As the comparison is performed at mean-square levels, this frequency difference does not matter, so long as the sinewave is at an exact multiple of the quasi-sinewave frequency. However, to optimize the operation of the Sense/Reference

comparator, the zero crossings of the quasi-sinewave are synchronized to occur coincident with a sinewave zero crossing, and all comparator state changes are also synchronized to sinewave zero-crossings.

Synchronization is achieved by clocking M17 so that all the analog switching data changes simultaneously. Thus data is latched from M17 'D' inputs to its permanently-enabled outputs, one complete quasi-sinewave period after it was clocked through M15. This ensures that the transit times of M15, M18 and M20 do not affect synchronism with the quasi-sinewave zero-crossing.

The data is thus strobed through M15 and M17, being delayed by one clock period. This does not affect the operation of the comparator, although it must be accounted for when observing waveforms on an oscilloscope.

The sequence, as described earlier in *sub-section 9.9.3*, begins with REF SWITCH connecting the quasi-sinewave to the squarer input during period C1. The logical origin of the comparator switch state during C1 corresponds to M15-2 (Q1 output) at logic-1; but because of the data delay its actual timing is coincident with the Q2 output of M15-4 at logic-1.

9.9.5

COMPARATOR TIMING LOGIC (Fig. 9.13)

The comparator timing waveforms for the sequence are illustrated in *Fig. 9.13*. To highlight the data delay, the main waveforms are grouped into two blocks: 'REF' and 'SIG', each headed by the states of the comparator cycle. *Line (b)* shows which of M15 (Q) outputs is at logic-1 during each of the states. It can be seen that the effects of M15 output states are delayed by 1 clock period, in the translation to comparator states.

9.9.5.1 Squarer Commons Switching ['REF' and 'SIG' waveforms (d) and (k)]

Waveform (c) shows the variation of M15-12 (Cout). Waveforms (d) and (k) are the direct results of Cout inputs to M17 after the translation by one clock shift (note the inversion at M20-10).

During states CØ to C4, waveform (d) at logic-1 connects the squarer common (RMS Lo) to Common-2 at M16-4 for quasi-sinewave squaring; whereas during states C5 to C9, waveform (k) connects RMS Lo to SIG Lo at M16-8 for sensed sinewave squaring. In both cases, the appropriate common is connected one period ahead of the squarer input, and disconnected at the end of the integrator settling time.

9.9.5.2 Squarer Input Switching ['REF SW' and 'SIG SW' waveforms (e) and (l)]

M15 outputs Q1 to Q3 are 'OR' gated at M18-6 and applied as D2

input to M17. The result is to generate the REF SW waveform (e) at M17-7.

REF SW connects the quasi-sinewave as input to the squarer by M16-13 only during states C1 to C3.

Similarly, SIG SW waveform (1), logically derived from M15 outputs Q6 to Q8, is at logic-1 only during states C6 to C8, connecting the sensed sinewave as input to the squarer by M16-12.

9.9.5.3 Integration and Sample Switching ['INT' and 'SAMPLE' waveforms (f) and (h)]

At any instant, the comparator is either sampling or integrating. The INT waveform is thus the inverse of the SAMPLE waveform.

SAMPLE

M15 outputs QØ and Q5 are 'OR' gated at M18-9 and applied as D3 input to M17. The result is to generate the SAMPLE waveform (h) at M17-10.

Therefore, for CØ and C5 only, SAMPLE provides two enabling inputs to AND gates M13 at M13-2 and M13-5. It also places a hard zero on the squarer output by M7-5 (*page 11.7-4*) when this is disconnected from both integrator inputs. With both input and output at zero volts, any offsets are removed in preparation for the subsequent squaring and integration sequence.

INT

The 'SAMPLE' output of M18-9 is inverted at M20-4, applying logic-1 to the D1 input of M17 for the whole of the cycle except for CØ and C5. The INT output at M17-5 is *waveform* (f), which enables M13-1 and M13-13.

REF INT

INT is 'AND-gated' with REF waveform (d) at M13-11 to generate the 'REF INT' waveform (g), which is at logic-1 only during periods C1 to C4. During this time M7-12 (page 11.7-4) at logic-1 connects the squarer output to the REF Integrator input.

SIG INT

INT is 'AND-gated' with SIG waveform (k) at M13-10 to generate the 'SIG INT' waveform (m), which is at logic-1 only during periods C6 to C9. During this time M7-6 (page 11.7-4) at logic-1 connects the squarer output to the SIG Integrator input.

REF SAM

'SAMPLE' is 'AND-gated' with SIG waveform (k) at M13-4 to generate the 'REFSAM' waveform (j), which is at logic-1 only during state C5. During this time driver M6-1 at logic-1 causes FET Q2 to conduct (*page 11.7-4*), connecting the REF Integrator output to the REF Sample-and-Hold input.

SIG SAM

'SAMPLE' is 'AND-gated' with REF waveform (d) at M13-3 to generate the 'SIG SAM' waveform (n), which is at logic-1 only during state CØ. During this time driver M6-7 at logic-1 causes FET Q3 to conduct (page 11.7-4), connecting the SIG Integrator output to the SIG Sample-and-Hold input.

9.9.5.4 DC Subtraction

['DC SUBTRACT OFF waveform (p)]

Subtraction is required only when either input is being applied to the squarer. As REF SW and SIG SW already exist, it remains only to provide an OR function to join them. The analog circuits need an inverted waveform, so a NAND gate is used. For loading purposes two elements of M20 are connected in parallel: REF SW and SIG SW are combined as *waveform* (p) at M20-3 and M20-11.

Squarer Input Short

When at logic-1 during C4-C5 and C9-CØ, M7-13 places a hard short between RMS Hi to RMS Lo; otherwise the short is released.

Subtraction Current Control

During C1 to C3 and C6 to C8, DC SUBTRACT OFF at logic-Ø cuts off D8 (*page 11.7-4*), allowing Q6 to draw subtraction current through D6, D5 and R54. When at logic-1, D8 conducts and sets D5 and D6 in reverse bias, diverting the subtraction current.

(b)	M11-12 M1 M15 output at	I5/M17 Clocks logic-1	
(c)	<u>M15-12 (Cout</u>)		۲ <u>ـــــ</u>
	Comparator <u>RE</u>	E Cycle	C9 CØ C1 C2 C3 C4 C5 C6 C7 C8 C9 C2
(d)	M17-15 (05)	REF	Squarer Common = COMMON 2C
(e)	<u>M17-7 (02)</u>	REF SW	Quasi-sine input to Squarer
(f)	<u>M17-5 (01)</u>	INT	
(g)	M13-11	REF INT	Quasi-sine (squared) being integrated
(h)	<u>M17-10 (03)</u>	SAMPLE	Squarer Squarer Squarer O/P Zero O/P Zero O/P Zero
(j)	M13-4	REF SAM	REF sample-and-hold input isolated REF Int. REF sample-and-hold input isolated being sampled
(k)	Comparator <u>S</u> M17-12 (04)		C9 CØ C1 C2 C3 C4 C5 C6 C7 C8 C9 C0
(k) (l)	Comparator <u>S</u> M17-12 (04) M17-2 (00)	IG Cycle SIG SIG SW	C9 CØ C1 C2 C3 C4 C5 C6 C7 C8 C9 C0 Squarer Common = SIG Lo Sinewave input to squarer
(1)	M17-12 (04)	SIG	Squarer Common = SIG Lo
(I) (f)	M17-12 (04)	<u>sig</u> Sig sw	Squarer Common = SIG Lo
(I) (f) (m)	M17-12 (04) M17-2 (06) M17-5 (01)	<u>sig</u> Sig Sw Int	Squarer Common = SIG Lo INT INT INT Sinewave input to squarer Sinewave (squared) being integrated Squarer O/P Zero
(l) (f) (m) (h)	<u>M17-12 (04)</u> <u>M17-2 (06)</u> <u>M17-5 (01)</u> M13-10	<u>sig sw</u> <u>INT</u> Sig int	Squarer Common = SIG Lo INT INT Sinewave input to squarer Sinewave (squared) being integrated Squarer

9.9.6 SQUARE-LAW DETECTOR CIRCUIT (Circuit Diagram 430663 Page 11.7-4)

The basic action of the squaring circuitry is the same as is used for \sin^2 and \cos^2 in the Sinewave Oscillator amplitude loop, but there are some differences in detail (*Refer to sub-section 8.2*).

The Square Detector is biassed in such a way that it is permanently turned on, to improve bandwidth and permit control of gain scaling. Its differential output current at AN3-3 and AN3-2 is proportional to the square of its input voltage divided by the bias voltage. The bias is derived from the DC version of the demanded signal level REF+ve, the DC output from the Reference Divider.

Thus the transfer proportionality of the signal magnitude is given by:

Vout is proportional to Vin² / Vbias

but as Vbias is derived from REF+ve,

Vin / Vbias is a constant: k,

and the instantaneous squarer gain is:

$$\frac{d(Vout)}{d(Vin)} = \frac{d(\frac{kVin^2}{Vin})}{d(Vin)} = 2k$$

Thus the basic gain equation has no amplitude or frequency components, so is constant over a wide bandwidth and dynamic range. The squarer therefore has a fast response at all signal levels.

The bias is applied as currents to Q17 and Q18 emitter circuits. The transistors in the array of M22 are all used as current generators.

9.9.6.1 Bias Control

The input to Reference Amplifier M24 is the positive DC REF +ve voltage, which varies between approx. 0.14V and 2.8V, depending on the output value selection.

M24 output voltage rises until M22-9 pulls enough current through R50 to reduce M24-3 to zero. The other transistors in M22 act as current mirrors, so their collector currents are defined by the REF +ve voltage and the resistance of R50.

Thus bias current is applied to Q17 and Q18 in direct proportion to he REF +ve voltage, which is an accurate analog of the demanded output value.

).9.6.2 Current Driver

The 'SIG^{2'} and 'REF^{2'} current outputs from the square detector levelop a differential voltage input between TP48 and TP49, to the urrent driver Q9/Q10/M19. This amplifier generates a single-ended urrent drive to the integrators.

 $(9(B) \text{ collector drives the output directly, but in order to establish a table DC voltage reference level, Q9(A) collector current is mirrored y Q10(B):$

M19 bootstrap steers Q9(A) collector current through Q10(A), maintaining Common-2C potential at Q10(A) collector.

Q10(B) mirrors the Q9(A)/Q10(A) collector current so that when the differential input voltage between TP48 and TP49 is zero, Q9(B) collector current is all taken by Q10(B), and the potential at TP9 is the Common-2C zero, at high impedance.

Differential input variations between TP48 and TP49, due to 'SIG^{2'} and 'REF^{2'} outputs from the Square Detector are translated to differential currents into and out of the junction at TP9. The current difference passes through R35 to R148 during SIG INT states, and to R149 during REF INT states.

At other times, when both of the integrator input switches M7-8/9 and M7-11/10 are open, the 'SAMPLE' waveform closes M7-4/3 to pass any difference current to Common-2C.

(During the SAMPLE periods, DC SUBTRACT OFF is zeroing the Square Detector input RMS Hi anyway, by shorting to RMS Lo via M7-2/1 - page 11.7-4.)

Resistors R35, R148 and R149 are of very low value compared with Q9(B) and Q10(B) output impedance, so the driver compliance is high.

9.9.6.3 Output Amplitude Loop - LF Gain Reduction

On the 100Hz Frequency range the gain around the output amplitude loop needs to be less than on other ranges. It is convenient to adjust the error immediately following its generation in the square detector, by shunting the input to the current driver.

Adjustment is in two stages, using dual open-collector comparator M21:

a. For 100Hz Range selection

The '100Hz' signal input to M21-3 is derived in the Frequency Synthesizer, and is at logic-1 when the 100Hz Range is selected by the operator. M21-1 is pulled up by R41 and Q7 conducts, connecting R43 and R44 between TP48 and TP49, thus shunting R49 and the base-emitter junctions of Q9. For a given 'SIG²' or 'REF²' signal, the input feed to the current driver is reduced.

b. For frequency selections below 32Hz

The '>31Hz' signal input to M21 is also generated in the Synthesizer.

- i. For any frequency above 31Hz, the >31Hz signal is set to logic-1, M21 output is at logic-Ø (-15V) and Q8 does not conduct.
- II. For frequencies of 31Hz and below, the >31Hz signal is at logic-Ø, M21 output is pulled up by R42. Q8 conducts, connecting R45 and R46 between TP48 and TP49, in addition to R43 and R44. For a given 'SIG²' or 'REF²' signal, the input feed to the current driver is further reduced.

9.9.7.1 'REF' Integration

The integrator circuit is very basic. Feedback for M12 is by C25, but the input resistance is formed by R149, R35 and the output impedance of the Current Driver, which is heavily predominant. The current from the driver is virtually unaffected by R35 and R149.

M7-11/10 conducts for periods C1 to C4 (REF INT). During C1 to C3 the REF SW waveform inputs the quasi-sinewave to the squarer, and during C4 the squarer settles to its zero input.

The REF² output from the driver is an AC current, which for a constant quasi-sinewave amplitude is integrally charge-balanced about

zero due to the DC subtraction, at twice the quasi-sinewave frequency. C25 therefore receives equal positive and negative charge during each cycle of quasi-sinewave, so the mean voltage at M12-1 does not change.

A discharge path for C25 is provided by Q5/R30. The 'INT HOLD' signal at J7-46 is logic-1 when the instrument is in 'OUTPUT OFF' condition, discharging both REF and SIG integrators. For so long as the output remains 'ON', the INT HOLD signal stays at logic-Ø, and the integrators are never discharged other than by the action of their inputs.

9.9.7.2 'REF' Sample-and-Hold

Q2 conducts during each 'REF SAM' period, when the charge on C25 has settled for the cycle. M12 drives C12 to the voltage on C25, and the voltage follower M4 passes the same voltage as 'REF ERROR' on to the REF V to I Converter.

9.9.7.3 'REF' V to I Converter

The circuit of M19 and Q6 converts the DC voltage output of M4 into the subtraction current. A second function is to draw an extra DC current which compensates for the bias control currents.

The DC 'REF ERROR' voltage from M4-6 is divided by R37/R31 and applied to the non-inverting input of M19. A second input results from the DC bias current drawn by M22-14, defined by the 'REF+ve' voltage and the two resistors AN2-10/7 and R141.

M19 drives FET Q6, which draws current via Q12-3 emitter, R54, D5 and D6. The current is sunk into Common-2C via R47, R38 and AN2-12/5, and into the -15V supply via the M22-14/12 bias circuit.

Capacitor C34 filters out any HF transients remaining from the switching edges of REF SAMPLE, and D7 protects against positive excursions of Q6 gate.

In the simplified diagram of Fig. 9.10, the subtraction current is shown as being sourced by the summing junction. In reality, it is taken from Q12-3 emitter for three main reasons:

- The Current Driver input bias is removed, allowing a zero-offset reference.
- **b.** The control bias for the squarer is compensated at the earliest opportunity, reducing the required dynamic range of the driver.
- c. Q12 emitter voltage remains virtually constant for all squarer inputs.

Q2, C12 and M4 are low-leakage devices and M4 input circuit is screened, at low impedance, to the sampled voltage. Thus the 'Droop' is specified as less than $20\mu V$ during the 'Hold' part of the cycle when Q2 is not conducting.

Relocating the subtraction point does not affect the essential action of the square detector and driver, because of the current-mirror action of the driver.

Subtraction is valid only during times when a quasi-sinewave or sensed sinewave is being input to the Square Detector. Thus for periods C1 to C3 and C6 to C8, diode D8 is held in reverse bias by the signal 'DC SUBTRACT OFF' at logic-Ø. During periods C4, C5, C9 and CØ, the signal is at logic-1, so D8 conducts and reverse-biases D5 and D6. The subtraction current passed by Q6 is then diverted through D8 from M20-11/3, the 'DC SUBTRACT OFF' parallel NOR gates' output being at logic-1 (*page 11.7-3*).

When an operator selects a different output value, the result is a change in amplitude of the quasi-sinewave. This unbalances the integrator input, so C25 charges to a different mean voltage at the output of M12. The DC subtraction current change takes place over a few comparator cycles until balance is restored, when C25 and C12 will have charged to a new voltage.

9.9.8 'AC ERROR' SIGNAL GENERATION

9.9.8.1 Integration and Sampling Circuit

The SIGNAL Integration and Sample-and-Hold circuitry is identical to the REF arrangement described in *Section 9.9.7*. Moreover, the SIGNAL Integrator M12 is the other half of a matched pair with the REF Integrator.

The difference lies in the timing. Switch M7-6 allows current to pass into the SIG integrator only during periods C6 to C9, so it is the SIGNAL (sensed sinewave)² current minus the (DC REF)² subtraction current which is integrated.

The integrator voltage is sampled and output as the 'AC ERROR' DC voltage (*sub-sections 9.2.4 and 9.9.2*), into the output amplitude control loop.

9.9.8.2 Output Amplitude Loop Action

Consider the case of 'OUTPUT OFF'

- a. The quasi-sinewave has an amplitude determined by the 'OUTPUT' display value:
- b. The quasi-sinewave is squared and appears as a current in R35 during periods C1-C4, but because Q5 is conducting, the REF integrator capacitor C25 is discharged. Thus the DC subtraction current is effectively zero (it is actually sufficient to cancel the DC current in R35 due to the squarer bias).
- c. The AC ERROR signal voltage is zero, as Q4 conduction prevents any charge on the SIG integrator capacitor C26. Also, the output amplitude is zero, hence the sensed output applied to the squarer is zero.

Therefore during periods C6-C9 the current in R35 is zero.

Now consider the case when OUTPUT is switched ON, with the OUTPUT display set to the minimum value of 9% of range:

As the quasi-sinewave is already present, it is squared into a negativegoing waveform in R35.

Quasi-Sinewave Input

During the first comparator cycle, this appears as a voltage at TP9 thus:

(Quasi-Sinewave)²

Zero Reference

The standing bias on the Ref. V to I Converter has immediately set the $(quasi-sinewave)^2$ to an approximate zero mean.

The (quasi-sinewave)² current is integrated across C25, resulting in a positive 'REF ERROR' voltage after period C5, and hence a positive subtraction current in R35. The effect of the current can be seen in the TP9 voltage waveform: an increase of (quasi-sinewave)² amplitude is accompanied by a positive shift as its mean value seeks coincidence with zero.

After a few comparator cycles the current in R35 becomes chargebalanced about zero, the DC subtraction current stabilizing to a steady-state value.

Meanwhile, during the 'SIG' sections of the comparator cycle, the positive subtraction current is integrated across C26. A negative 'AC ERROR' voltage is generated, which increases the instrument output voltage via the VCA. This increase is detected by the sense feedback circuits. After squaring, the result is an AC current in R35, whose mean level begins to offset the effect of the subtraction current on the SIG integrator.

After a few comparator cycles, the AC SIG² mean current and the DC subtraction current are equal and opposite, so the current fed through R35 into the integrator is charge-balanced about zero. The integrator capacitor C26 is thus being charged and discharged by the same amount during each half-cycle of output (SIG² current being at twice the output frequency), so the AC ERROR voltage stabilizes.

Fig. 9.14 illustrates three stages in the process of increasing output from zero; observing the current in R35 (ie. the voltage at TP9), the 'AC ERROR' signal, and the output sinewave. The waveforms are not to scale.

Stage 1.

This is the first cycle that the quasi-sinewave starts to charge C25. During period C6 a non-zero subtraction current is applied to the SIG integrator, resulting in a non-zero value of 'AC ERROR', starting at CØ as the integrator voltage is sampled. This causes the instrument sinewave output to rise from zero.

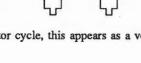
Stage 2.

On the next cycle the subtraction current imposes a positive shift on the R35 waveform during C1-C3 and C6-C8. The squared quasisinewave does not change in amplitude, but it is more equally balanced about zero, so the next increase in subtraction current will not be so great.

During C6-C8 the sinewave is being applied to the squarer, so TP9 exhibits its squared waveform shifted positively by the subtraction current. A smaller increase in 'AC ERROR' and output sinewave results, as the AC input to the SIG integrator is more equally balanced about zero.

Stage 3.

In this state the loop has stabilized. The squared quasi-sinewave and sensed sinewave are both charge-balanced about zero, the subtraction current and 'AC ERROR' have reached constant values, and the instrument output is stable.



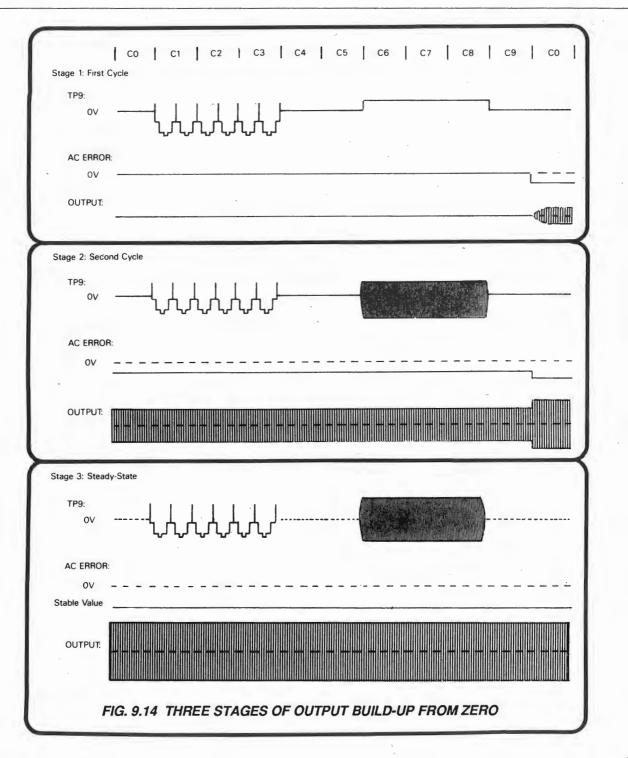
9.9.8.3 'AC ERROR' V-to-I Converter (Circuit Diagram 430663 page 11.7-6)

To avoid pick-up during transit, the AC ERROR voltage is converted into a current, for transmission to the Error Amplifier on the Sine-Source Assembly. One half of M3 is used as a unity-gain inverting buffer, and the other as a voltage-to-current converter. The relay RL1 is not fitted, so M3-7 is linked directly to the test switch S1 'NORM' terminal.

At M3-7 the DC 'AC ERROR' voltage is inverted and used to drive the current converter via AN1-3/12. The current in AN1-4/13 is

mirrored by the current in AN1-11/6 (AC AMPL ERROR), which is sourced in the Sine-Source Assembly by M41a, the Error Amplifier (Circuit Diagram 430446 page 11.6-3).

As the AC ERROR signal DC voltage is varied by the comparator, the current in M41a input resistance also varies, and is converted into a varying voltage at M41a-1. This voltage is used to control the main voltage-controlled amplifier M48 via Q71. For further information about the VCA, refer to Section 9.3.



9-29

9.10 LOGIC CONTROL OF AC OUTPUTS

The general aspects of analog control functions are discussed earlier in *sub-section 7.10*, subdivided as follows:

7.10.1	Logic Levels
7.10.2	Heat Reduction
7.10.2.1	Update Considerations

The AC signals are routed through the DC assembly on their way to the terminals and back; for the 10V, 100V and 1000V ranges they are amplified in the Power Amplifier assembly. The signals are subject to digital controls incorporated in those assemblies.

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Descriptions of the controls in the DC and PA assemblies are indexed in *sub-sections 9.10.1 and 9.10.2*, below.

9.10.1 DC ASSEMBLY - LOGIC AND RELAY DRIVES (Circuit Diagram 430536 Page 11.5-3)

The AC voltage output and sense signals pass through the DC assembly, and are affected by the analog control signals present there.

The effects of the control logic on the DC assembly are detailed in *Section 7*, subdivided as indexed, except for the 'HIGH I LIMIT' and 'AC 1kV RANGE' Logic.

As these two signals are activated only on the AC 1kV Range, their effects are described in *sub-section 9.7.6* (but reference is also made to relays 12 and 13 in *para 9.4.2.3*).

7.11.1 Introduction 7.11.1.1 Latched Bistable Relays 7.11.1.2 'Tristate' Relay Drivers 7.11.2 Clamp Assembly 7.11.2.1 UPD(IG) Distribution 7.11.2.2 Buffer Clamping 7.11.3 DC Assembly Switching Logic 7.11.3.1 DC Range Switching Logic Function and Output Switching Logic 7.11.3.2

9.10.2 PA ASSEMBLY - LOGIC AND RELAY DRIVES (Circuit Diagram 430618 Page 11.9-5)

The extensive switching needed to control the many modes of operation of the Power Amplifier assembly, is described earlier in *Section 7.12*. The subjects are subdivided as listed below:

		7.12.7	'LIM ST' Logic
7.12.1	DC Range Switching	7.12.7.1	'LIM DET'
7.12.2	AC Range Switching	7.12.7.2	'LIM ST' Generation
7.12.3	Function and Ranging Logic	7.12.7.3	CPU Response
7.12.4	'PA CLAMP ON' Signal	•	
7.12.5	'400V ENABLE' Logic	7.12.8	'LF', 'LF' and '1kV GAIN'
7.12.6	'BIAS OFF' Logic	7.12.9	Thermistor Comparator

9.10.3 AC ASSEMBLY LOGIC AND RELAY DRIVES (Circuit Diagrams 430663 Page 11.7-5)

The analog control signals are transferred into guard on the Reference Divider assembly, and latched as 'Q' outputs in the Serial/Parallel Data Converter. Offset positive logic is used:

$$\log c - \emptyset = -15V$$
, $\log c - 1 = 0V$.

The signals enter the AC assembly via J7 from the Mother assembly.

M28 and M29 are inverting, open-collector Darlington drivers. The relay-drive logic places a logic-1 (0V) on the input of the selected drivers and logic- \emptyset (-15V) on those not required. A selected driver operates its relay by pulling its output to -14V.

9.10.3.1 Range Switching (Page 11.7-5)

Range control data is input as a 3-bit code on ACR_{gh} , ACR_1 and ACR_2 lines. The bit-pattern is decoded to '1 of 8' by M25, to energize the correct relays for the selected range. In this instrument only eight of the M25 'Q' outputs are connected. The resulting variants are listed in *Table 9.1* against range selections.

9.10.3.2 AC FNCT and IFNCT Logic (Page 11.7-5)

In addition to its primary function of controlling AC Voltage range switching, the AC assembly logic also needs to respond to AC Current range selections; because the AC voltage reference for the Current/Ohms assembly is generated by the Voltage circuitry. For this purpose the two signals AC FNCT and I FNCT are used.

AC FNCT is at logic-Ø only when AC Voltage output is selected, holding M25-11 'D' input at logic-Ø, and energizing relays RL2 and RL10. This connects the star-point at Common-2B to the PLO(ACV) line (J7-31) and SIG LO to the SLO(ACV) line (J7-32) (page 11.7-1). The bit-patterns controlling the voltage range switching are shown on Table 9.1.

I FNCT is at logic-Ø only when Current output is selected, holding M25-11 'D' input at logic-Ø, and energizing relays RL2 and RL9. This connects the ACI REF lines (J7-69 to J7-72) to the ACV lines (page 11.7-1). The 10V range output is used as reference for the 100mA, 10mA and 1mA Current ranges, but the 1V range output is used for the 100µA and 1A ranges. The bit-patterns controlling the current range switching are also shown on Table 9.1.

The signals AC FNCT and I FNCT are never at logic-Ø at the same time in normal operation. The only time they are at logic-1 together is when all outputs from the Control Data latches in the Reference Divider are 'Tristated'. 'DCI' ensures that RL2 and RL9 cannot be energized by selection of DC Current ranges. Whenever a switching command has been received, the CPU performs a control-data transfer and the $\overline{UPD(IG)}$ line from J7-53 is pulsed to logic-Ø for 50ms. Q19 is turned on, applying +15V to the relays connected to its collector. The selected relays are thus energized by 30V, but after the $\overline{UPD(IG)}$ pulse has ended Q19 turns off, and they are held on by the -12.6V between -1.4V at the cathode of D20 and -14V at the selected driver output. This method reduces the heat, generated locally by energized relay solenoids, in the relay contacts.

FETs Q42 and Q43 damp the coils of RL12 and RL13; diodes D59 and D60 isolate parts of the printed circuit to these relays, which are sensitive to power-common breakthrough when they are deselected. D55 and D56 are overswing diodes.

9.10.3.3 'AC Zero'

For zero output, the lines from the voltage generators to the I+ and Iterminals are disconnected by deselection of the ranges, and a hard short is placed across the output lines by RL18.

The ACR₂₋₀ code is '1,1,1'. This sets M25-4 to logic-1 (energizing relay RL18) and all other M25 range outputs to logic- \emptyset (the resultant bit-pattern is shown in Table 9.1). Thus all ranges are deselected, but relays RL2 (ACV and ACI), RL3 (AC Low Voltage Output), RL10 (ACV) and RL19 ($\overline{1kV}$) remain energized. Relay RL18 connects the PLO(ACV) star-point of Common-2B to the PHI(ACV) line.

9.10.3.4 'BARK DELAYED'

The BARK' signal does not affect the AC assembly relays. However, if the Watchdog is activated, the CPU imposes OUTPUT OFF conditions and forces the Precision DC Reference to ramp down to zero, so the PHI REF voltage also falls to zero.

All outputs from the Control Data latches in the Reference Divider (*page 11.4.4*) are 'Tristated' by the 'BARK DELAYED' signal. This allows the pull-up resistors (AN4 and AN5) to become effective.

The $\overline{AC FNCT}$ and $\overline{I FNCT}$ are pulled to logic-1, and the $ACR_{2.0}$ code is '1,1,1'. This imposes 'AC Zero' conditions on the analog circuit, but RL2, RL9 and RL10 are also de-energized. So the DC precision reference is disconnected from the input to the quasi-sinewave generator; the ACI(REF) is disconnected from the input to the AC Current circuitry, and the Sense and Power Lo lines are disconnected from the sense amplifiers.

9-31

Function	Range	Range Range Code			M25 at L	Output ogic-1	Relays Energized [* = Energized]																		
			ACR1		ΥΩ'	Pin	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19	20
AC Volts	1000∨	0	0	0	00	3									•			•			•				
	100∨	0	0	1	Q1	14	•								•					•		•		•	
AC FNCT	10V	0	1	0	Q2	2	•	•							•				•			٠		•	
at Logic-Ø,	1۷	0	1	1	03	15		•				•			•	,	•							•	
IFNCT	100mV	1	0	0	Q4	1	•	•	•		+				•	•	•							•	
at Logic-1)	10mV	1	0	1	Q5	6 ·	. •	•		•					•	•	•							•	
	1mV	1	1	0	Q6	7	•	•							•	•	•							•	
	Any	1,	1	1	۵7	4		•															•	•	
AC Current	100µA 1A }	0	1	1	03	15	•	•				•	•	•			•							•	
(AC FNCT at Logic-1,																								_	
IFNCT at Logic-0)	1mA 10mA 100mA	0	1	0	Q2	2		٠						•					•					•	

Note 1 With the 4200 operating normally: either AC FNCT or TFNCT, but not both, will be at logic-Ø; unless SAFEtY message is displayed.

TABLE 9.1 AC ASSEMBLY SWITCHING LOGIC

9-32

SECTION 10 CURRENT OUTPUTS AND RESISTANCE

10.1 DC AND AC CURRENT

The circuits described in this sub-section perform the following functions:

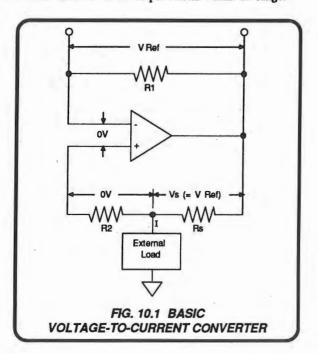
- Divide the DC reference voltage by 10 to (-2V to +2V).
- Generate a DC output current whose value varies directly as the reduced value of the DC reference Voltage.
- Convert the ACI Reference Voltage into an AC reference current, having a high-impedance source.
- Generate an output current whose value varies directly as the value of the AC reference current.
- Provide switching of the DC or AC Current Range and Output, under the control of the Analog Control Interface.
- Sense excess output (compliance) voltage, providing a status signal to the CPU via the Analog Control Interface.

The voltage-to-current converter is located on the Current/Ohms assembly, providing five DC and five AC ranges of current output. The nominal full range values are 1A, 100mA, 10mA, 1mA and 100 μ A, each extending to 100% overrange, for both DC and AC Current selections. The output is drawn from the instrument I+ and I-terminals; the Hi and Lo terminals not being used.

10.1.1 VOLTAGE-TO-CURRENT CONVERTER

Fig. 10.1 shows the basic arrangement. A DC or AC reference voltage is developed across R1 between the output and the inverting input of the high-gain amplifier. Its output connects to its other input by a 'shunt' network, part of which carries the output current.

The combined feedback forces the differential input to zero. The current in the positive feedback path is adjusted until the full value of the reference is developed across the path. For example in *Fig. 10.1* no current flows in R2, so all of VRef is developed across Rs. The values of VRef and 'shunt' Rs thus determine the value of current flowing in the external circuit. Rs is switched to select the range, and VRef is varied to set the output current within the range.



10.1.2 AC CURRENT GENERATOR (Circuit Diagrams 430614 Page 11.8-1 and 430540 Page 7.13-3)

Because a return path is needed for the output current, a 'compliance' signal voltage appears between the I+ and I- terminals. The magnitude of this voltage is specified in the User's Handbook, and the specification is met by floating the input to the output amplifier.

On the DC ranges the floating DC reference is input directly into the output amplifier, which therefore acts as a voltage to current converter in the style of *Fig. 10.1*. Resistors R44 and R45 provide 10:1 attenuation, to set the 'VRef' to 1/10 of the reference value.

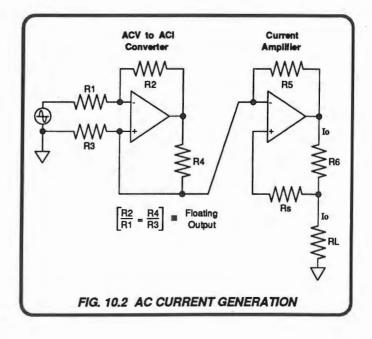
For AC ranges the ACI Reference is buffered from the output amplifier in a two-stage circuit. A fixed voltage-to-current conversion stage is followed by a range-switchable current amplifier (the latter is the voltage-to-current converter for DC ranges). The combination is simplified at Fig. 10.2.

In the figure, the AC Reference voltage is applied via two resistors R1 and R3 to both inputs of the first stage. It is arranged for the resistor values to conform to:



so the output impedance of the stage is virtually infinite, and its output 'floats'.

The second stage is a current amplifier, receiving the output current of the fixed stage to generate a voltage across R5. This voltage is repeated across R6, whose value is range-switched. Any resistor Rs does not affect the output, carrying no current. The current amplifier supplies are bootstrapped to improve common mode rejection.



10.1

10.1.3 DC AND AC REFERENCE - SOURCING AND SCALING

The DC output currents are bipolar, controlled within each range by the value of reference voltage (REF) applied directly from the Reference Divider. On all DC ranges, REF is divided by 10 in the input attenuator. On the 1mA, 10mA and 100mA ranges, the span is $\pm 20V$, so a full scale span of $\pm 2V$ can be applied across the selected range shunt.

To optimize the choice of components and minimize the number of relays required for range switching, the DC reference for the other two ranges is additionally divided by 10 in software. On the 1A Range a full scale span of ± 200 mV can be applied across its 0.1 Ω shunt, and for the 100 μ A Range the ± 200 mV can be applied across the combined shunt resistance of 1000 Ω assigned to the 1mA Range.

The AC output currents are controlled within each range by the value and frequency of the ACI(REF) voltage. This reference voltage is generated by the circuitry used for AC voltage ranges: the 10V Range for the 1mA, 10mA and 100mA ranges; but the 1V Range for the 100 μ A and 1A ranges. Thus the same shunt values and switching relays can be used for both AC and DC current outputs. The highest frequency available is 5kHz.

10.1.4 DC CURRENT REFERENCE '(REF)' (Circuit Diagrams 430652 Page 11.4-3 and 430614 Page 11.8-1)

The (REF) signal is the main DC reference for the whole instrument. It is sourced in the Reference Divider on J4-9/10/11/12 (page 11.4-3) as a 4-wire output, which enters the Current/Ohms assembly from the Mother assembly on J8-1/2/3/4 (page 11.8-1). Relay RL7 is activated for DC Current Ranges, so the PHI(REF) and PLO(REF) levels are sensed at TP3 and TP4 respectively.

(REF) is divided by R43/R44, so 1/10 of (REF) is developed across R43, and applied between the inverting input of the V-I converter and the output of the Darlingtons on the PS/I heatsink at J19-7 (one of the relay contacts RL1-2/3 or RL1-10/11 is always made).

10.1.5 AC CURRENT REFERENCE 'PHI (ACI REF)'

(Circuit Diagrams 430663 Page 11.7-1 and 430614 Page 11.8-1)

On the 100µA and 1A ranges, the AC 1V Range circuit provides the 2V RMS Full Scale reference; on the 1mA, 10mA and 100mA ranges the AC 10V Range circuit provides 20V RMS at Full Scale.

On the AC assembly (*Page 11.7-1*), for T function, RL9 is energized and RL10 is not. The reference voltage for the current generator is derived from the PHI (ACV) and PLO (ACV) signals; and sensed at the input to the Current/Ohms assembly. The sensed ACI REF is returned to the appropriate connections on the 1V/10V Sense Amplifier. The 4-wire connections are made via J7, pins 69 to 71, to the same pins of J8 on the Current/Ohms assembly.

The AC preamplifier M8 divides the reference voltage by 10, so that the value of the RMS voltage applied to R43 is the same as the DC voltage applied for corresponding range and output settings.

10.1.6 RANGE SELECTION

Fig. 10.3 shows two Range configurations of the current amplifier. In each case V Ref is 10% of the reference voltage. RL1 is a bistable latching relay, in which the polarity of the solenoid current determines which state is selected. Solenoid current is not required for hold-on, being necessary only to change state.

The voltage across the I+ and I- terminals is allowed to rise to 3V DC or RMS with full compliance. Each range incorporates a series resistive element connecting the range selection relay contact to the I+ terminal. These resistors enhance the stability of the circuit, with reactive loads.

10.1.6.1 1A Range (Refer to Fig. 10.3a)

Relay RL1 is activated to close contacts 8/9, 11/10 and open contacts 2/3. Relays RL2, 3, 4, and 5 are not energized. The only output current path available is through the 0.1Ω shunt R80. Thus in the positive feedback path all of V Ref is developed across R80, and no current flows in R79, R8, R9 or R10. As V Ref is scaled to 100mV DC or RMS Full Range, the full range output current in R80 is: $100mV/0.1\Omega = 1A$.

10.1.6.2 100mA, 10mA, and 1mA Ranges (Refer to Fig. 10.3b)

Relay RL1 is activated so that contact RL1-3/2 is closed, contacts RL1-10/11 and 8/9 are open. One relay from RL2, 3 and 4 is energized by range, RL5 is also energized on the 10mA and 100mA ranges for extra HF filtering. All currents now avoid the 0.1Ω shunt, passing instead through the 10Ω shunt R79.

R79 is mounted with R80 on a separate heatsink assembly, plugged into the main Current/Ohms assembly (refer to the Layout Drawing, *page 11.8-1* for alternative versions).

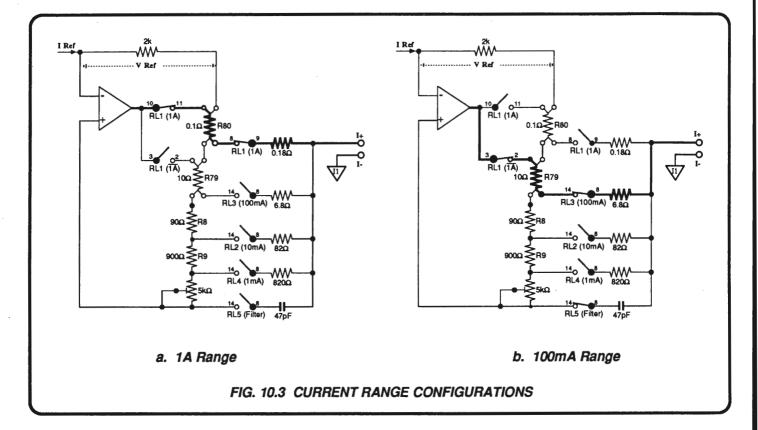
On the 100mA range, VRef is scaled to 1V DC or RMS Full Range, so the full range current flowing through R79 to the I+ terminal via RL3-14/8 is: $1V/10\Omega = 100mA$.

For the 10mA range, R8 (90.00 Ω) is included in the current path, so the full range output current is reduced to 10mA. 900.0 Ω (R9) is added on the 1mA range.

10.1.6.3 100µA Range (Refer to Fig. 10.3b)

The hardware is switched as for the 1mA range, but either the DC REF voltage is scaled in software to 1V full range, or the ACI REF voltage is obtained, as for the 1A range, from the AC 1V range circuitry. Thus VRef is scaled to 100mV DC or RMS Full Range, and the full range output current is 100μ A.

10.2



10.1.7 DC VOLTAGE-TO-CURRENT CONVERSION

The value of the REF input sets the output current value, scaled for range as described earlier. REF is coupled: Hi (TP3) to the output, and Lo (TP4) to the inverting input through R44.

The conversion amplifier is in two sections: a voltage preamplifier on the Current/Ohms assembly (*page 11.8-1*), and a power amplifier on the PS/I Heatsink assembly (*page 11.13-3*). The latter is also drawn, for convenience, on *page 11.8-1*.

The whole amplifier is also used as the Current Amplifier for AC output currents. In that case it is preceded by the AC preamplifier M8 (*sub-section 10.1.9*).

10.1.7.1 Voltage Preamplifier

M3, M4 and Q6 form a high-gain, chopper-stabilized voltage amplifier. M3, itself a chopper-stabilized amplifier of high gain and approximately 10Hz bandwidth, trims the input offset of Q6, which provides the bandwidth necessary to pass the signal frequencies and reject common-mode noise.

M4 contributes additional gain and drives the high-current output stage via link TLE. Its load, consisting of R26, R23 and R28 shunted by Q7 in the Heatsink assembly, is supplied with a constant current by Q9, D6 and Q11. Additional frequency compensation is provided by C43 and R81.

The supplies to Q6 and M3 are bootstrapped by M7 for commonmode rejection, also linearizing the preamplifier's dynamic response. Extensive screening and filtering is employed to eliminate the effects of the chopping spikes at the inputs and output of M3.

10.1.7.2 High Current Output Stage (Circuit Diagrams 430614 Page 11.8-1 and 430540 Page 11.13-3)

The main current amplifier and temperature-sensing driver load (Q7) are located on the PS/I Heatsink assembly. The quiescent current 'SET I_0 ' adjustment is situated on the Current/Ohms assembly.

10.1.7.3 Temperature Compensation

Transistor Q7, thermally attached to the heatsink and in parallel with R26, R23 and R28 on the Current/Ohms assembly, acts as the load for the preamp. buffer. As the heatsink temperature increases, Q7 conduction increases, reducing the drive to the current amplifier. This compensates for increased intrinsic quiescent current in the two Darlington output devices.

10.1.7.4 Quiescent Current Adjustment

FET Q9 acts as constant 1.4mA ballast for the 3.3V zener diode D6, which sets the voltage across R27 to approx. 2.6V. This establishes the collector current in Q11, generating a constant current in the buffer load.

The voltage across the load is supplied to the PS/I heatsink as drive for the high-current amplifier. The tapping at J8-110 sets the base conduction level of Q7 on the heatsink, which in turn sets the level of its collector conduction, adjustable by R23. This therefore adjusts the quiescent current in the output devices Q1 and Q2.

10-3

10.1.7.5 Power Amplifier

Darlington emitter-followers Q1 and Q2 form the power output amplifier, current-limited by Q5 and Q6. The bias is set to provide some 100mA of quiescent current, which reduces the output resistance of the stage, improving the dynamic response of the output current. This also suppresses any tendency for the drive from

10.1.8 AC VOLTAGE-TO-CURRENT CONVERSION

10.1.8.1 AC Voltage-to-Current Converter M8 (Circuit Diagram 430614 Page11.8-1)

The reference voltage PHI(ACI REF) is applied to the inverting input of M8 via resistor R45, with R46 as feedback resistor. Similarly R47 and R48 are connected on the non-inverting side. The $18M\Omega$ resistors R82 and R83 shunt R47 to allow compliance adjustment by R31. R86 refers the input to Common-I1, the main 'signal' common.

10.1.9 OUTPUT PROTECTION

Diodes D18 and D19 are 5V, 5 Watt zeners, placing an absolute limit on the excursions of output voltage. The output compliance specification is valid only up to 3V DC or RMS at the output terminals. Nevertheless, occasions may arise when a user overloads the circuit by attempting to drive current into open circuit (e.g. by disconnecting from a load with OUTPUT ON). In this case D18 and D19 protect any voltage-sensitive load by limiting the output voltage to 5V. But before the voltage reaches this limit, the overvoltage protection circuit generates the LIM ST signal.

10.1.9.1 Guard Buffers

M1 guards out the leakage of D18 and D19 in normal operation, and protects against other leakage, by maintaining the output screens and shields around the output circuitry at the output potential. In addition to its bootstrap function, M7 also acts as a buffer for guards around the amplifier input, thus preventing any common-mode disturbances from affecting the performance of the main amplifier. the preamp buffer to fluctuate for output currents around zero; as the drive voltage must slew through approximately 1.3V after switching one device off before the other is switched on. The current shunts complete the feedback and output circuits, the output current being fed to the I+ terminal via protection circuitry and output switching.

10.1.8.2 Current Amplifier

The output AC current from the converter, flowing through R48 to restore M8 input virtual-common, passes via R85 into the Current Amplifier feedback resistor R43. It generates a reference AC voltage between the output of the whole Current Amplifier and its inverting input. This is reflected on its non-inverting side by the current flowing through the range-switched output 'shunts'.

The whole amplifier is also used as the Voltage-to-Current Converter for DC output currents (*sub-section 10.1.8*). The Preamplifier and Output sections have the same operation as in the DC case.

10.1.9.2 Overvoltage Detection

The output guard buffer M1 drives the overvoltage detection circuit. M15 divides the output voltage by two and acts as an inverting full-wave rectifier, accommodating AC and both polarities of DC. The full-wave rectified voltage at M15-14 thus increases negatively as the output voltage increases, charging C32 to its mean value at M15-10. M15-9 is biassed to -2.2V, so M15-8 reverse biasses D10 unless the terminal voltage exceeds 4.8V RMS, when M15-8 swings to the negative rail and pulls the \overline{LIM} ST line to -15V (logic-Ø).

The diode D10 is part of a diode-OR gate, linking $\overline{\text{LIM ST}}$ to the $\overline{\text{LIM ST}}$ line, which enters the Reference Divider at J4-76. The CPU receives the $\overline{\text{LIM ST}}$ status signal via the SSDA serial interface, and if at logic-Ø presents the 'Error OL' message on the MODE display. If in the 100mA or 1A range, the Output is turned off and the DC precision reference is ramped to zero, to limit the power developed as heat within the instrument. Other sources and the effects of the $\overline{\text{LIM ST}}$ signal are described in *sub-section 7.12.7*.

10.2 RESISTANCE

10.2.1 INTRODUCTION

Eight standard resistors are mounted on the Current/Ohms Assembly, each being part of a combination whose total resistance is factoryadjusted to a value close to nominal. They are 4-wire connected to the instrument terminals by range-selection relays. Nominal values are 10Ω , 100Ω , $1k\Omega$, $10k\Omega$, $10k\Omega$, $10M\Omega$ and $100M\Omega$.

10.2.2 RESISTOR CIRCUITS

10.2.2.1 4-Wire Connection Symmetry. (Circuit Diagram No. 430614 Page 11.8-3).

For any given resistor combination, the connections on the Hi side are made through contacts of the same relays used for the Lo side, except for the ' Ω OUTPUT' relays RL24 and RL25. This ensures that both sides of each resistor connect to the front panel terminals through the same number of similar thermal connections.

To achieve the low leakage required for the Megohm ranges, particularly for the 100M Ω range, a further relay RL17 is used to isolate the parallel leakage paths of the lower range circuits.

The use of latching relays eliminates the heating effect from their solenoids. But it is important that all non-thermal relay contacts are made back-to-back to cancel thermal effects. Thus only the connections to non-latching relays RL24 and RL25 actually need to be back-to-back, although most others are.

This symmetrical, 4-wire arrangement transfers the stability and accuracy of each resistor to the front (or rear) panel terminals.

10.2.2.2 4-Wire Junctions and Pre-set Trimming.

R63, R64, R65 and R72 are 4-wire resistors, so for 10Ω - $10\Omega\Omega$ selections the 4-wire junction is at the standard resistor itself. These resistors are parallel-trimmed. R62, R74, R73 and R71 are two-wire resistors. For these higher resistance values, $100K\Omega$, $1M\Omega$, $10M\Omega$ and $100M\Omega$, series trimming is used and the 4-wire junctions enclose the series chain.

Trimming resistors are selected and adjusted in the factory, in a carefully-controlled environment, against traceable standards.

10.2.3 METHODS OF CALIBRATION

10.2.3.1 Routine Autocalibration

The nominal value of each standard resistor is labelled below its RANGE key. When the key is pressed, the OUTPUT display does not show nominal; but instead gives the value measured at its most recent calibration. This is the main criterion for many users, rather than having the resistor internally trimmed to nominal. So routine recalibration consists of accurately measuring the resistor value and setting the display to read that measured value, without removing the instrument covers (*sub-section 1.2.10*). The factor which corrects the nominal value to the measured value is stored in non-volatile RAM on the Digital assembly.

During recalibration, if a user enters a value on the OUTPUT display which is outside the span of the calibration memory, the instrument displays "Error 6" (Section 1.2). As any resistor drift is normally just a fraction of the span, "Error 6" appears only when an erroneous value is entered, (eg. if a resistor's value has been changed by the stress of an overload).

10.2.3.2 Internal Adjustment

A severe overload can alter a resistor's value, possibly taking it out of its calibration memory span. To restore the value to one which can be entered from the front panel, each resistor combination includes an internal trimmer (*para 10.2.2.2*). A procedure for adjustment of the trimmers is given in *sub-section 1.5*, but this should be limited to values less than about 50ppm outside tolerance. If a resistor is found to be more than \pm 50ppm outside its tolerance, it is likely to be unserviceably damaged, so it is advisable to have such a resistor tested or replaced by an agent of Datron Instruments.

10.2.4 USE OF 'Remote Sense' KEY

10.2.4.1 4-wire/2-wire Display Values.

In Ω function, selection of Remote Sense mode (Key LED lit) displays the measured value for the 4-wire connection, but with the Remote Sense LED unlit, the 2-wire value is displayed.

10.2.4.2 Two-wire Connections.

To avoid the intrusion of extra thermal voltages, no additional switching is employed for selection of 2-wire connections. Users are recommended to connect only to the Hi/Lo terminals, so the 2-wire mode should be recalibrated at these terminals.

10.2.5 OHMS ZERO

With Ω function selected, pressing the zero key on the front panel closes the contacts of relay RL16. This provides a true 4-wire short, the existing resistor remaining connected.

If the Remote Sense LED is lit, the displayed value is zero and cannot be calibrated; but if unlit, the resistance of the short plus internal wiring can be measured and entered on the display, using four-wire measurement at the Hi and Lo terminals. Subsequently, each time the 'Zero' key is pressed in ' Ω ' function with the Remote Sense key LED unlit, this entered value will be displayed.

10.3 FUNCTION SWITCHING.

10.3.1 OUTPUT CONNECTIONS - FUNCTION ROUTING (Circuit Diagram 430614 Pages 11.8-1 and 11.8-3)

The PHI, PLO, SHI and SLO connections are routed via the Current/Ohms assembly, and it is there that they are switched between functions. The outputs of the three functions V, I and Ω are switched by separate relays onto the terminal lines (*Fig 10.4*):

Voltage Outputs

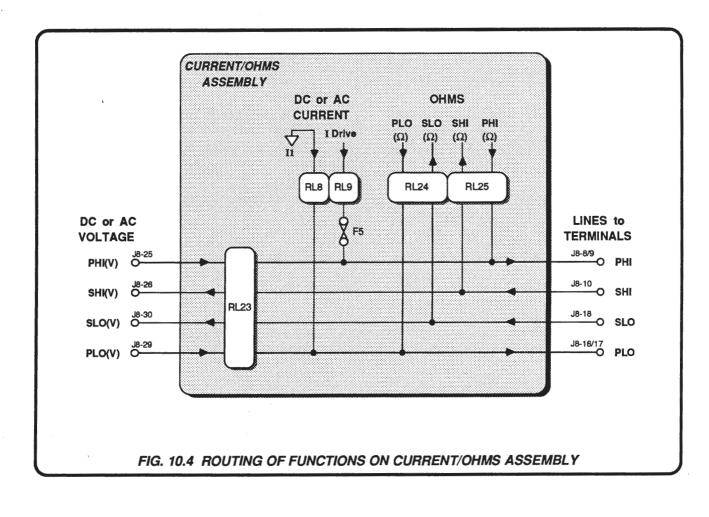
Relays RL8, RL9, RL24 and RL25 are de-energized as shown on *pages 11.8-1 and 11.8-3*. The DC or AC Voltage Power and Sense connections to the DC assembly are routed out to the I+, I-, Hi and Lo terminals via latching relay RL23 closed contacts.

Current Outputs

Relay RL23 contacts are latched open; relays RL24 and RL25 are unenergized; relays RL8 and RL9 are energized to connect the output from the selected shunt to the PHI and PLO lines only.

Resistance

Relay RL23 contacts are latched open; relays RL8 and RL9 are unenergized; relays RL24 and RL25 are energized to connect the selected standard resistor to the four PHI, PLO, SHI and SLO lines, regardless of the state of Remote/Local switching. To avoid the intrusion of extra thermal voltages, no additional switching is employed for selection of 2-wire connections.



10.4 CURRENT/OHMS ASSEMBLY ANALOG CONTROL

10.4.1 INTRODUCTION

(Circuit Diagram 430614 Page 11.8-2)

10.4.1.1 Control Signals

The analog control signals are transferred into guard on the Reference Divider assembly, and latched as 'Q' outputs in the Serial/Parallel Data Converter. Offset positive logic is used: logic- $\emptyset = -15V$, logic-1 = 0V.

The signals enter the Current/Ohms assembly via J8 from the Mother assembly.

10.4.1.2 Types of Relays

Guarded Reed Relays

Relays RL2, 3, 4 and 5 are guarded reed relays activated and held on by 15V.

24V Relays

Relays RL 8, 9, 24 and 25 are 24V relays, activated during the 50ms UPD(IG) pulse by approx. 30V, but held on by 15V.

Polarized Relays

Relays RL1, 7, 10, 11, 12, 13, 14, 16, 17, 18, 19, 20, 23 and 26 are 6V latching relays, activated by approx. 7.5V; between M10-13 at -7.5V and either 0V or -15V from the drive output of the clamp assembly. These relays, strung out between the output of their bias amplifier (M10) and the Clamp assembly, are activated only during the 50ms $\overline{UPD(IG)}$ pulse. They are polarized bistable relays, which require no hold-on power.

10.4.2 LATCHING RELAYS AND CLAMPING

The Ohms and DC Current circuitry is mainly controlled by lowthermal relays, many contacts being fitted back-to-back to reduce temperature effects. For the fastest response, the output relays RL8, 9, 24 and 25 are not latched, but can trip out quickly if the power supply fails, removing any sensitive circuitry from the terminals.

All the other Ohms relays, the AC/DC Current changeover relays, 1A Range relay, and Voltage output relay are latched; allowing holdon without power, to minimize the internal temperature at their contacts. As they are polarized they need a bipolar actuating drive, which is provided by Tristate' relay drivers and a bias amplifier.

10.4.2.1 Latched Bistable Relays (Circuit Diagram 430614 page 11.8-2).

As can be seen from the circuit diagram on *page 11.8-2*, the relays are strung out between the output of their bias amplifier (-7.5V at M10-13) and the drive outputs from the Clamp assembly.

The bias amplifier M10 is a frequency-compensated voltage follower, buffering the tapping of attenuator AN5/R97. So one side of each relay is held permanently at -7.5V. The relay drivers on the Clamp assembly can provide outputs at 0V or -15V when enabled by the $\overline{UPD(IG)}$ pulse, but return to tristate when disabled. A relay is therefore driven to one or the other of its bistable states during update, then magnetically latched in the chosen state when the driver output returns to open-circuit.

All the latched relays except RL17 operate in the same polarity sense: when its driver output updates at logic-1 (0V), the relay latches to select its nominal function; for a logic- \emptyset (-15V) update, the function is deselected. For RL17 these conditions are reversed. In the analog circuit diagrams, the relay contacts are shown in their deselected state, equivalent to the un-energized state of a conventional non-latching relay. In the analog descriptions relays may be referred to as being 'energized' or 'un-energized'.

10.4.2.2 'Tristate' Relay Drivers (Circuit Diagram 430669 Page 10-9).

The relay drivers (M1 and M3 on the Clamp assembly) are octal 'Tristate' buffers. Each chip is served by two inverted enable inputs on pins 1 and 19 (four buffers - half the chip - per enabling input).

Whenever a switching command has been received, the CPU performs a control data transfer and the \overline{UPD} (IG) line from J8-60 is pulsed to -15V for 50ms.

Generally, the switching logic places a logic-1 (0V) on the input of selected drivers, and logic- \emptyset (-15V) on those whose function is not selected. Because all the buffers are non-inverting, during the update pulse a driver selects its function by setting its output voltage to 0V, deselecting by pulling its output voltage to -15V. The driver serving RL17 (M3-15/5) performs in reverse, J13-15 being pulled to logic- \emptyset to allow selection of the lower resistance ranges.

10.4.3 CLAMP ASSEMBLY

(Circuit Diagrams 430614 Page 11.8-2 and 430669 Page 10-9).

On the Current/Ohms Relay Drive Logic circuit diagram the Clamp assembly is shown in block form (*page 11.8-2*). Also, the pcb pin numbers correspond to the pin numbers of the buffer chips: J14 and J15 being the connections to M1 and M3 respectively. For signals crossing the block from bottom to top, the output of each non-

10.4.3.1 UPD(IG) Distribution

As the $\overline{\text{UPD}(\text{IG})}$ signal is distributed as the 'enable' to 16 buffers, it is itself buffered by M16 at M16-3 before being fanned out. So the four $\overline{\text{UPD}(\text{IG})}$ connections at the left of the block are inputs to four sets of four buffers.

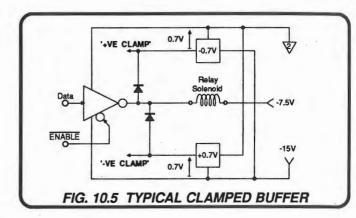
10.4.3.2 Buffer Clamping (Circuit Diagram 430669 Page 10-9).

The 40244 octal buffer can be sourced from several manufacturers. Some variants are protected against SCR avalanche if the output voltage were to exceed the rail voltage, but some are not. Each buffer drives its output into the solenoid of a relay, and is switched on and off by the update enable. The self inductance of the solenoid can generate back EMFs well in excess of the rail voltage, so to guard against the possibility of catastrophic failure, it was decided to provide external protection in the form of a clamp circuit.

On the Clamp assembly Q1, Q2, Q3 and Q4 form two power supplies, each delivering a regulated voltage of a diode-drop less than the rail voltage, called '+VE CLAMP' and '-VE CLAMP'.

A diode connected from the buffer output to each of the clamp lines allows the output voltage to rise to the rail voltage but not to exceed it (see Fig. 10.5).

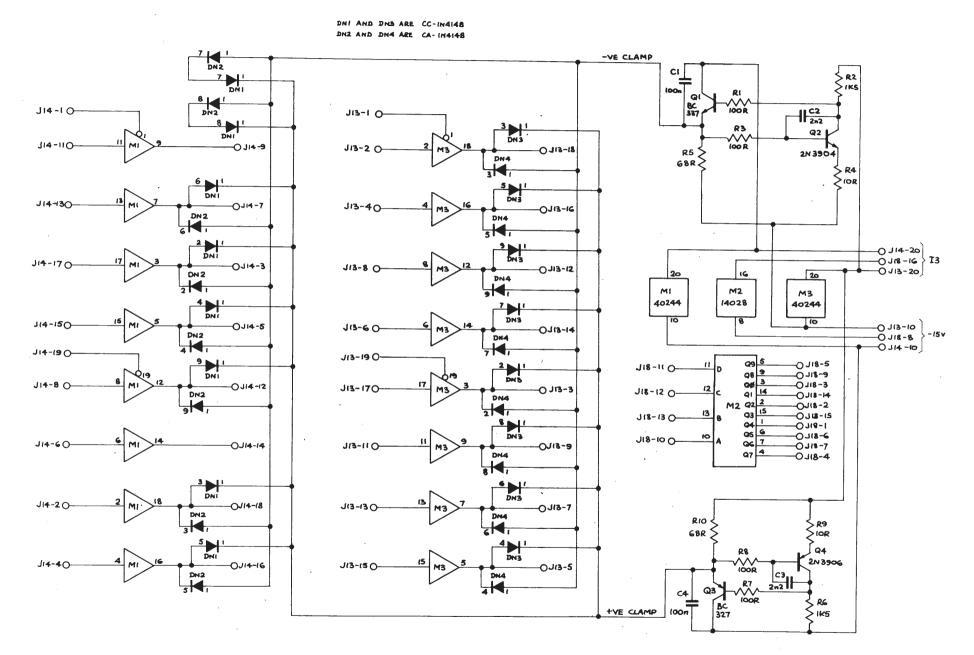
inverting buffer is drawn opposite its input, so the function remains unchanged as it crosses the block. As a further aid to identification, the pins of any one buffer are numbered so that the input and output numbers add up to 20.



10.4.3.3 BCD - Decimal Decoder M2

The function of M2 is to decode the octal Ohms Ranging signal $R\Omega_{2,\emptyset}$ with the Ω ZERO signal, providing switching information for individual relays. To provide flexibility for other applications, the inputs and decoded outputs for M2 are taken out to pins of J18, the outputs being linked back to selected pins of J13 and J14. These connections are shown on *page 11.8-2*.

Refer to sub-section 10.4.6 and Table 10.3 for a discussion of the M2 decode and resultant relay operation.



CURRENT / OHMS CLAMP CIRCUIT Drawing 430669

10-9

10.4.4 V, I AND Ω FUNCTION SWITCHING

10.4.4.1 Function Relays

The Function relays are located at top right of the circuit diagram on page 11.8-2.

RL8 and RL9, when energized, select the Current function.

RL24 and RL25 select the Ohms function.

RL23 connects the Voltage outputs to the instrument terminals.

For the analog connections refer to sub-section 10.3.

10.4.4.2 Voltage Output

Selection of the DC or AC Voltage function at the front panel also deselects Current and Ohms functions in software. The \overline{I} FNCT and $\overline{\Omega}$ FNCT signals are set to logic-1, and decoded by M17-8, M16-10 and M16-11 to set the V OUTPUT signal to logic-1. This activates relay RL23, connecting the voltage output lines to the front panel terminals.

The IR_{2-Ø} code is '1,1,1', setting only M6 'Q7' (pin 4) output to logic-1. Thus the Current range relays RLs 2, 3 and 4 are all unenergized. Relays RL8 and RL9 are un-energized, disconnecting the current output and shorting it to the current common-I1. RL1 is latched in the $\overline{1A}$ position, selecting R79 in preference to R80; and RL5 connects the 10mA/100mA filter.

Since $\overline{I \text{ FNCT}}$ is at logic-1, the DCI and ACI signals are at logic- \emptyset ; relays RL7 and RL26 are un-energized, disconnecting the DC and AC references from the current circuitry.

(Refer to Circuit Diagram 430663 Pages 11.7-1 and 11.7-5) In the AC assembly, the logic-1 $\overline{I \text{ FNCT}}$ signal (J7-86) de-energizes RL9. This disconnects the ACI REF lines (J7-69 to J7-72) from the ACV lines. Thus the voltage to current converter (M8 on the Current/Ohms assembly) receives no input voltage, and so no current is generated. AC FNCT connects the ACV lines only for voltage ranges.

10.4.4.3 Current and Ohms Function Switching

Their Function selection logic is included later in the descriptions at sub-sections 10.4.5 and 10.4.6.

Function			S	ignals			Relays Activated						
	OFF	BARK	IFNCT		DCI	AC FNCT	Curre RL8 RL9	RL24 RL25	s Assembly RL23 RL7 RL26 (Latching Relays - * = Pin 1 at Logic-1)	AC Assembly RL9 RL10 RL2 RL2			
DCI ACI	ø	Ø Ø	Ø Ø	1 1	1 Ø	1 1	*		*	*			
DCV ACV	Ø Ø	Ø Ø	1 1	1 1	Ø Ø	1 Ø			*	*			
Ω	ø	Ø	1	Ø	Ø	1		*					

TABLE 10.1 CURRENT/OHMS ASSEMBLY - FUNCTION LOGIC

10.4.5 CURRENT SWITCHING LOGIC (Circuit Diagram 430614 Page 11.8-2)

10.4.5.1 'I OUTPUT' Relays RL8 and RL9

Whenever a switching command has been received, the CPU performs a control-data transfer and the $\overline{UPD(IG)}$ line from J8-60 is pulsed to logic-Ø for 50ms. Q1 and Q7 remain cut off until the pulse arrives. The pulse turns Q1 and Q7 on, applying +15V to the relays connected to Q1 collector.

Any selected relays are thus energized by 30V, but after the $\overline{UPD(IG)}$ pulse has ended they are held on by the 13.3V between -0.7V at the

cathode of D2 and -14V at the selected driver (M20) output. This method reduces the local heat, generated by energized relay solenoids, in the relay contacts.

The IFNCT and OFF signals are decoded so that RL8 and RL9 are energized only when the Current function has been selected and Output is ON.

(i.e. RL8/9 are energized if M16-4 [OFF•I FNCT] = logic-1).

10-10

10.4.5.2 'DCI' and 'ACI' Relays RL26 and RL7

The I FNCT, BARK and DC I signals are decoded so that RL7 and RL26 can be energized only when the Current function has been selected and the Watchdog has not 'BARK'ed.

Under these conditions; if DC Current is chosen, then the DC I signal is at logic-1, so M9-10 is also at logic-1 and RL7 closes its contacts to apply the DC Reference 'REF to its voltage-to-current converter. If AC Current is chosen; DC I is at logic-Ø, so M9-9 goes to logic1 and RL26 closes its contact. This connects the output from its voltage-to-current converter M8 to the input of its current amplifier.

10.4.5.3 Current Range Relays RL1, 2, 3, 4 and 5

M12 is a Darlington open-collector inverting driver array. The relay drive logic places a logic-1 (0V) on the input of the selected drivers and logic- \emptyset (-15V) on those not required. A selected driver operates its relay by pulling its output to -14V.

The octal Current Ranging signal $IR_{2,\emptyset}$ is decoded by M6 to provide four individual outputs for Range relays:

Range	M6	Relay	Reference Source
	Output		DC AC
1A	Q2	RL1	-2V to +2V 1V Range
100mA	Q3	RL3	-20V to +20V 10V Range
10mA	Q4	RL2	-20V to +20V 10V Range
1mA	Q5	RL4	-20V to +20V 10V Range
100µA	Q5	RL4	-2V to +2V 1V Range

The Q3 and Q4 decoded outputs for the 100mA and 10mA ranges are ORed at M17-6 to operate RL5, which introduces HF filter capacitor C49 on both these ranges.

RL1 is a bistable latching relay with a single operating solenoid. A logic-1 at pin 1 switches the 1A range on, and a logic- \emptyset switches it off. Normally pin 1 is floating on open collector, so the relay remains latched in one bistable state with its solenoid un-energized. During the 50ms UPD(IG) pulse, non-inverting buffer M1 on the Clamp assembly is enabled, allowing the M6 Q2 state to change RL1 over (if programmed), before the UPD(IG) pulse ends.

10.4.5.4 Current Zero-Output

DC Current Zero

The DC Current output can be continuously incremented between its negative and positive Full-Scale outputs. Thus zero output can be selected by operator-adjustment of the 'REF' value using the 'OUTPUT' keys, or pressing the 'Zero' key, which ramps REF to zero. The zero value is corrected during Routine Autocalibration.

AC Current Zero

For AC zero output, as each range operates only between 9% and 200% of nominal, zero cannot be selected by adjustment of the OUTPUT keys. The AC zero is normally obtained by using the 'Zero' key which, through software, disconnects the lines from the current generator to the I+ and I- terminals.

The 'OFF' signal is set to logic-1, and the $IR_{2-\emptyset}$ code is ' \emptyset , \emptyset , \emptyset '. This sets all M6 outputs to logic- \emptyset , so the Current Range relays RLs 2,3 and 4, and the filter relay RL5, are all un-energized, and RL1 latches in the \overline{IA} position (R79 is selected in preference to R80).

Relays RL8 and RL9 are de-energized by the OFF signal, to opencircuit the I+ and I- terminals, and short the current amplifier output to common-I1. While setting OFF to logic-1, the CPU also forces the Precision DC Reference to ramp down to zero, so the AC reference voltage also falls to zero, and the current generator has no input. Thus the high current amplifier is not trying to produce an output current, and will not be damaged.

Function	Range	Ran	Range Code			M6 Output Pins					Relays Activated							
		IR ₂₋₆ IR ₂	ıR ₁	IRø		Q3 15				RL1 1+ 12- (Lato	RL1 1- 12+ ching)	RL2	RL3	RL4	RL5	RL		
V or Ω	N/A	1	1	1					1		•							
DCI	100µA	1	ø	1				1			*			*		*		
or	1mA	1	Ø	1				1			*			*		*		
ACI	10mA	1	Ø	Ø			1				*	*			*	*		
	100mA	Ø	1	1		1					*		*		*	*		
	1A	Ø	1	Ø	1	-				*						*		
ACI ZERO	Any	ø	Ø	ø							*							

TABLE 10.2 CURRENT RANGING LOGIC

10.4.6 **RESISTANCE SWITCHING LOGIC** (Circuit Diagram No. 430614 Page 11.8-2).

10.4.6.1 **Output Switching.**

Whenever a switching command has been received, the CPU performs a control-data transfer and the UPD(IG) line from J8-60 is pulsed to logic-Ø for 50ms. Q1 and Q7 remain cut off until the pulse arrives. The pulse turns Q1 and Q7 on, applying +15V to the relays connected to Q1 collector.

Any selected relays are thus energized by 30V, but after the UPD(IG) pulse has ended they are held on by the 13.3V between -0.7V at the cathode of D2 and -14V at the selected driver (M20) output. This method reduces the local heat, generated by energized relay solenoids, in the relay contacts.

The OFNCT, BARK and OFF signals are decoded so that RL24 and RL25 are energized only when the Ohms function has been selected, Output is ON and the Watchdog has not barked.

(i.e. If M16-9 [OFF•Ω FNCT•BARK] = logic-1, RL24 and RL25 are energized).

10.4.6.2 Range Switching

Range control data is input as a 3-bit code on ΩR_{\emptyset} , ΩR_1 and ΩR_2 lines. The bit-pattern is decoded by M2 in the Clamp assembly to activate the correct relay(s) for the selected range. The resulting variants are listed in Table 10.3 against range selections.

Relay RL17 is activated to connect the lower Ohms (<1M Ω) ranges to the output line only when the Megohm ranges are not activated. This reduces the parallel leakage (para 10.2.2.1). NOR gate M19-6 combines the signals which will activate RL17; bearing in mind that the polarized RL17 connections between its driver and the -7.5V rail are the reverse of all the other latching relays. Thus it closes its contacts when M19-6 is at logic-Ø (-15V), not logic-1 (0V).

10

The signal states which cause RL17 to close its contacts are:

	Ω FNCT	- logic-1	(Ohms function not selected);
or	Ω R2	- logic-Ø	$(10\Omega, 100\Omega, 1k\Omega, or 10k\Omega selected);$
or	Ω ZERO	- logic-1	(Ohms Zero selected);
or	J18-1	- logic-1	(Clamp assembly M2 Q4 @ logic-1
			- 100kΩ range selected).

10.4.6.3 Ohms Zero.

The Ω FUNCT and Ω ZERO signals are NORed by M19-10 and inverted by M17-12 so that RL16 is activated either when the Ohms function has been selected and the Zero Key has been pressed, or at times when the Ohms function is not selected.

Range	2)	ge C 2R ₂₋ 2 ΩR ₁		M2 'Q' Output (Clamp Assembly)	Relays Ac (All latching		
10Ω	ø	ø	ø	QØ	RL13)	
100Ω	Ø	Ø	1	Q1	RL10)	
1kΩ	Ø	1	Ø	Q2	RL14)	
10kΩ	Ø	1	1	Q3	RL12)	Each relay selects when
100kΩ	1	Ø	Ø	Q4	RL11	ý	pin 1 = Logic - 1 (0V)
1MΩ	1	Ø	1	Q5	RL20	ý	
10MΩ	1	1	Ø	Q6	RL19	ý	
100MΩ	1	1	1	Q7	RL18	ý	
Ω Zero	(All I	Range	e relays	deselected)	RL16		Relay selects when pin 1 = Logic-1 (0V)
Ranges <	:1 Μ Ω (e	exclud	ding Ω Z	Zero)	RL17		Relay selects when $pin 12 = Logic-1 (0V)$

TABLE 10.3 OHMS RANGING LOGIC

10.4.7 DEFAULT AND STATUS LOGIC

10.4.7.1 'OFF'

The OFF signal is combined with the \overline{IFNCT} and $\overline{\Omega FNCT}$ signals to ensure that when the instrument OUTPUT OFF key is pressed, the selected function's circuitry is disconnected from the terminals. For Current outputs, RL8 and RL9 disconnect the terminals from the current output; and for Resistance, RL24 and RL25 disconnect the standard resistor.

10.4.7.2 'BARK'

The BARK signal is combined with the $\overline{\Omega \text{ FNCT}}$ and DC I signals to ensure that when the Watchdog barks, the selected function is disabled. For DC Current outputs, RL7 disconnects the REF signal from the High-current V-to-I converter; for AC Current outputs, RL26 disconnects the drive from the AC reference V-to-I converter to the High current amplifier; and for Resistance, RL24 and RL25 disconnect the standard resistor.

The effects of 'BARK DELAYED' follow after 47ms.

10.4.7.3 'BARK DELAYED'

If the Watchdog is activated, the BARK signal is generated, and 47ms later all outputs from the Control Data latches in the Reference Divider are 'Tristated' by the 'BARK DELAYED' signal. On the Current/Ohms assembly, this allows the pull-up resistors (AN1) and pull-down resistors (AN3) to become effective. At the same time the BARK DELAYED signal sets a -15V pulse on the UPD (IG) line for 1.5 seconds (M41 on page 11.4-5), to ensure that the latching relays on the DC and Current/Ohms assemblies will respond to the default state.

The full effect of the default is that relays RL5, RL16, RL17 and RL23 are activated, the remainder are not:

The Current and Ohms circuits are disconnected from the terminals, but relay RL23 connects the Power and Sense lines from the DC assembly to the terminals. However, on the DC assembly the same default has disconnected the voltage output from the lines.

The Current ranges are deselected, but relay RL5 holds the HF filter in circuit.

All Ohms standard resistors are deselected as well as disconnected from the terminals; the 4-wire Ohms-Zero short is activated, but is also isolated from the instrument terminals by RL24 and RL25.

As the Watchdog detects certain malfunctions in processor or Analog Control transfer operation, the default is a safe holding state, and subsequent changes will depend on the reaction of the CPU to the event. The Watchdog is described in *sub-section 6.4.6*.

10.4.7.4 'I/Ω ST'

The I/Ω ST line at J8-98 is pulled down to -15V (logic-Ø) for as long as the Current/Ohms assembly is fitted in the instrument. This state is passed back via the Reference Divider (J4-68) and the SSDA serial link to the CPU (Circuit Diagram 430652 page 11.4-4). Thus the CPU recognizes that the Current/Ohms assembly is fitted, and can operate the appropriate programs.

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Volume 2

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AUTOCAL MULTIFUNCTION CALIBRATOR

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CALIBRATION AND SERVICING HANDBOOK

for

THE DATRON 4705

AUTOCAL MULTIFUNCTION CALIBRATOR

Volume 2

Part 3 Reference

850065

Issue 1 (December 1986)

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Due to our policy of continuously updating our products, this handbook may contain minor differences in specification, components and circuit design to the instrument actually supplied. Amendment sheets precisely matched to your instrument serial number are available on request.

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DANGER HIGH VOLTAGE



THIS INSTRUMENT IS CAPABLE OF DELIVERING A LETHAL ELECTRIC SHOCK !



FRONT or REAR terminals carry the Full Output Voltage.



Guard terminal is sensitive to over-voltage

It can damage your instrument !

Unless you are sure that it is safe to do so, DO NOT TOUCH the I+ I- Hi or Lo leads and terminals

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PART 3

REFERENCE

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Component Lists

SECTION 11 SERVICING DIAGRAMS

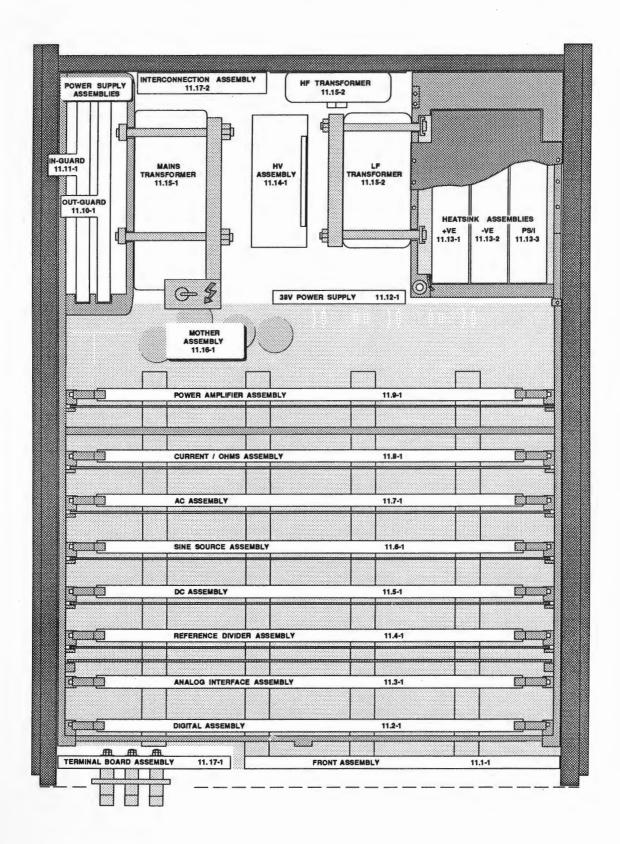


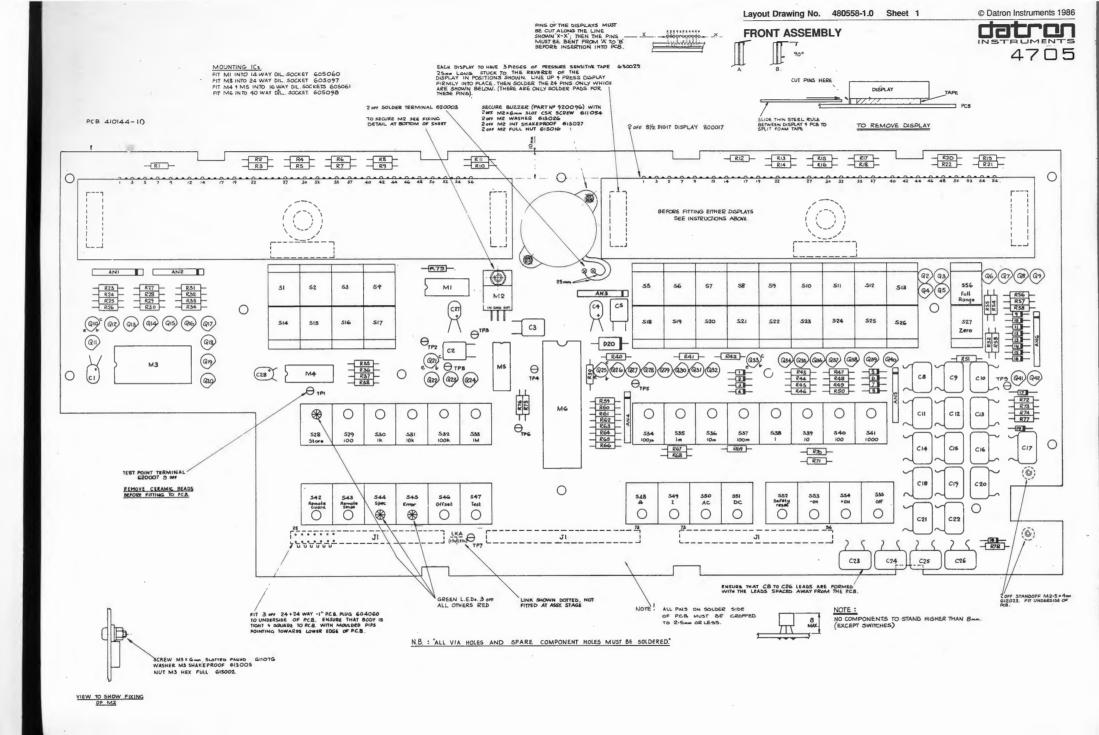
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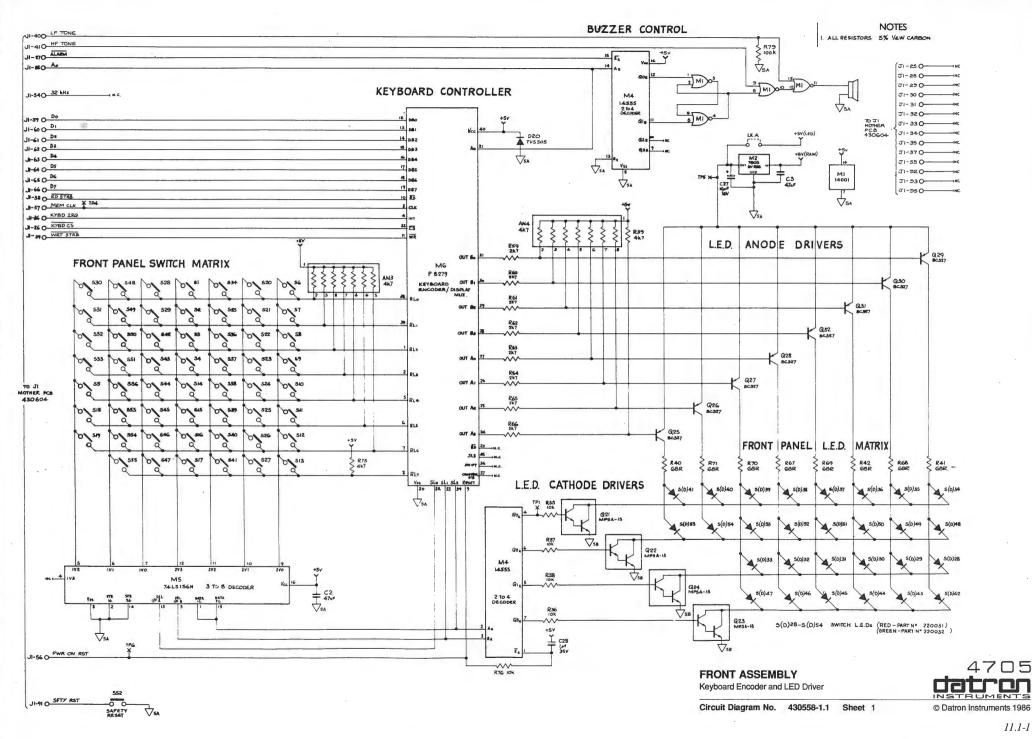
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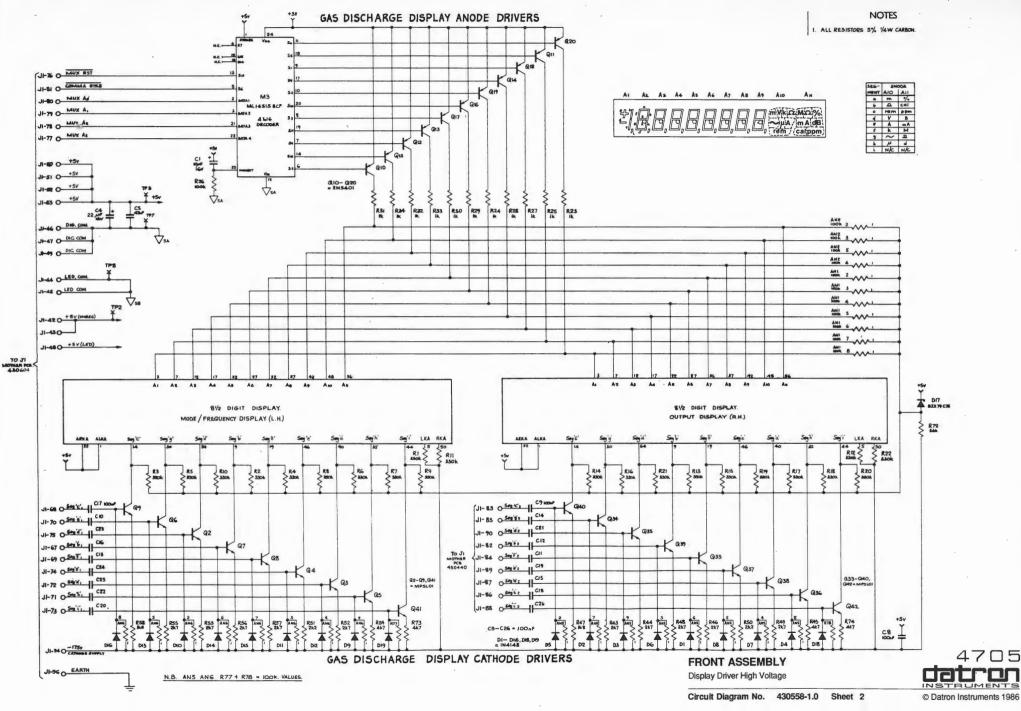
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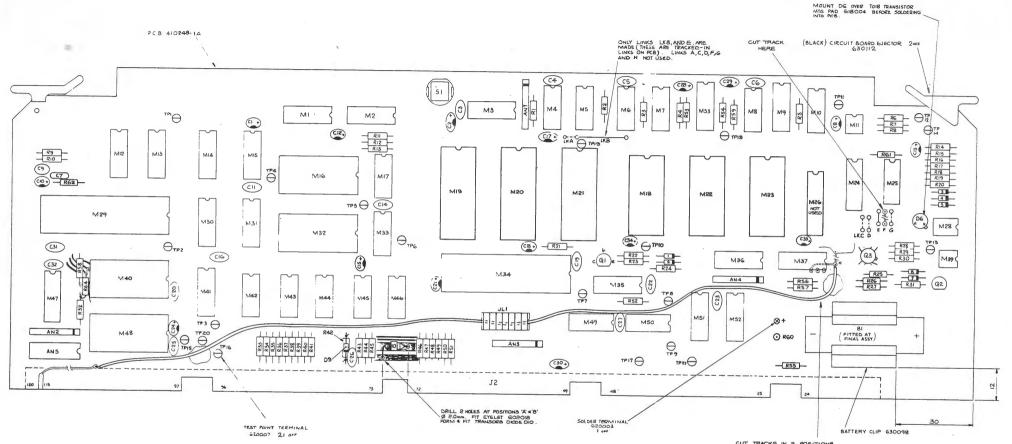


11.1-2

Layout Drawing No. 480559-1.2 Sheet 1

DIGITAL ASSEMBLY





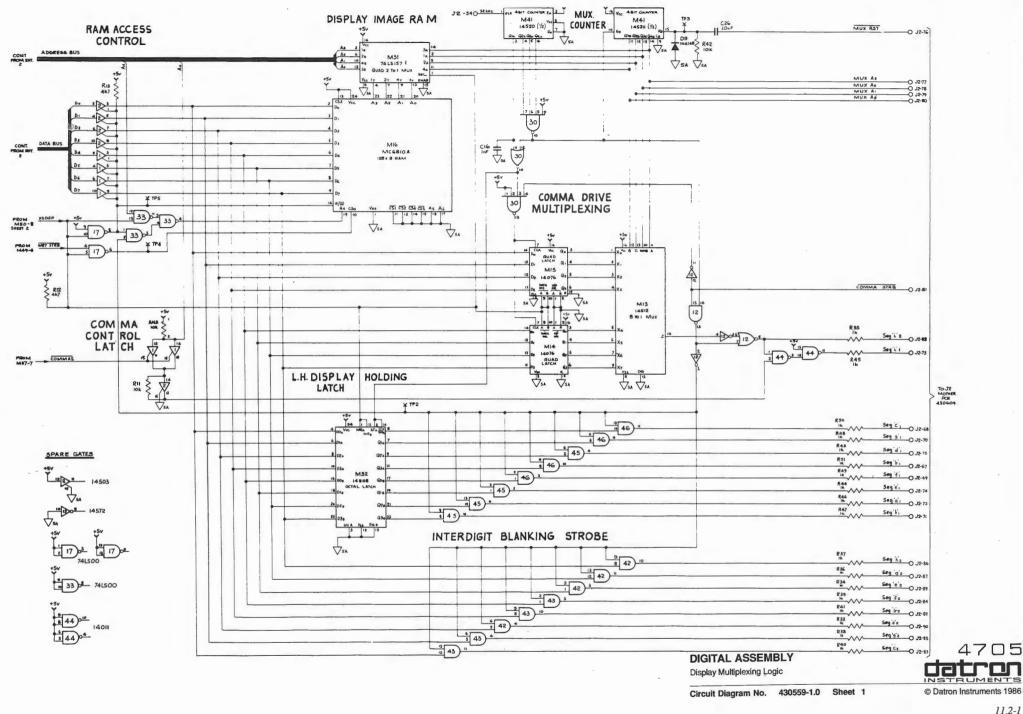
MOUNTING I.C.

FIT MII + M39 INTO 6-WAY DIL SOCKET GOSOGG 2000

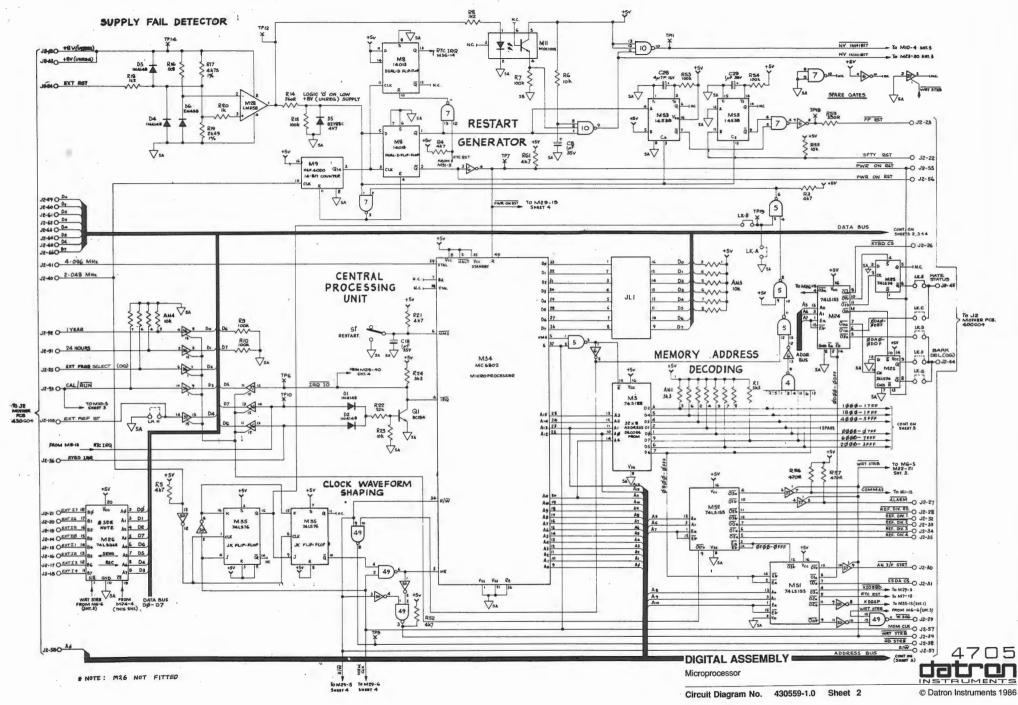
FTI MIT MAS INTO BY AND LL SOLLEL GODUED 2511 FTI MAS INTO BY AND TUL SOLLEL GODUED 2511 FTI MI-MS MID MID MID MAS MAS MAS MAS MID MAN MAS MAS A ULI INTO IGWAT DIL SOLLET GODOGI FTI MI-MS MID MID MAS AND MID MIDS-MAS MAN MAI MAS MAS A ULI INTO IGWAT DIL SOLLET GODOGI 20 OFF

FIT MI9-M2I INTO 28-WAY DIL SOCKET GOSO 65 30H FIT MIG VIB, MAZ, M23, M20 + M48 INTO 24-WAY DIL SOCKET GOSO 64 7 H FIT M29 + M34 INTO 40-WAY DIL SOCKET GOSO 50 20H

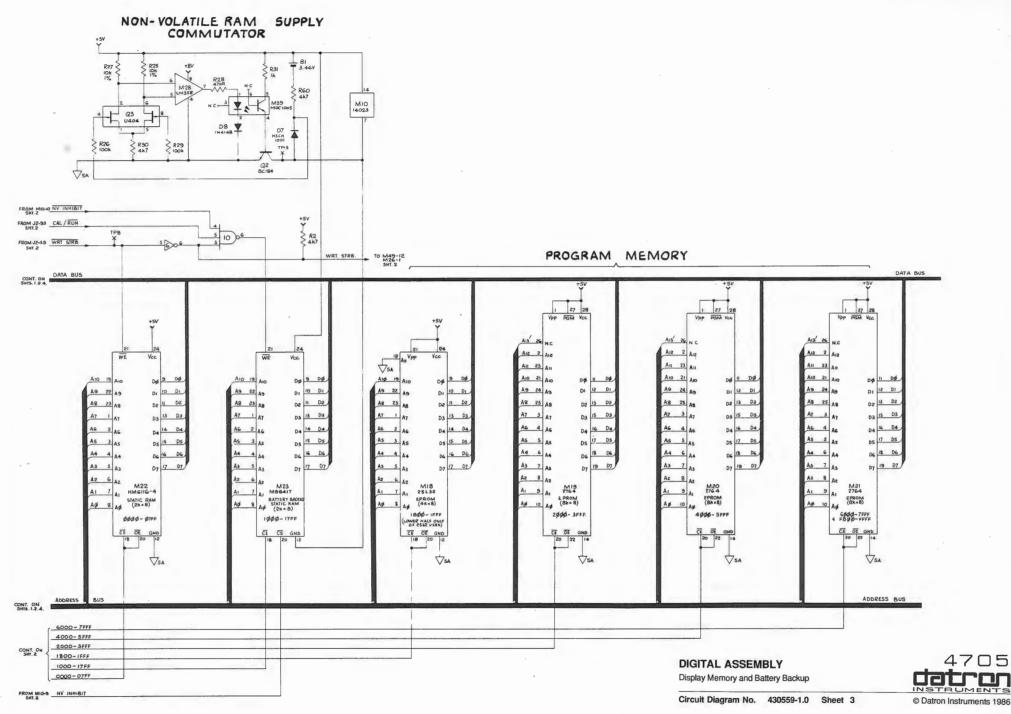
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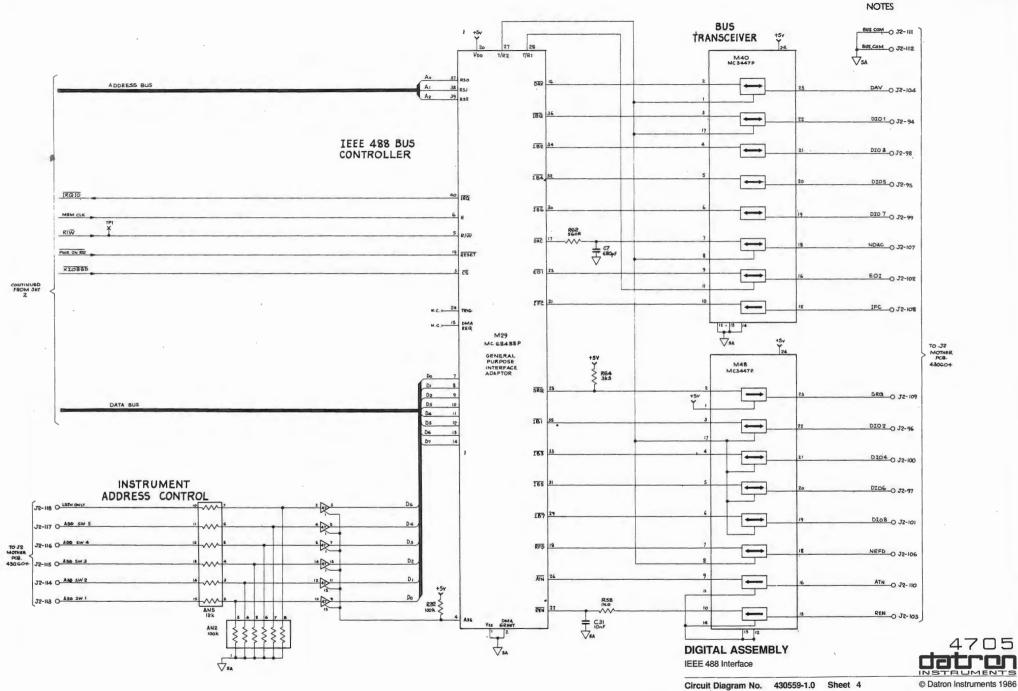
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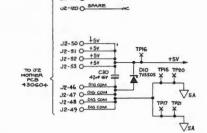
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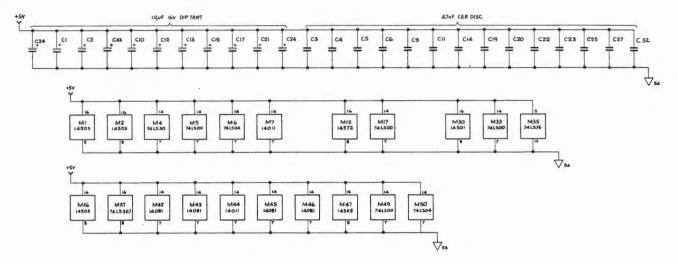
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J2-13 O SPARE



DIGITAL ASSEMBLY

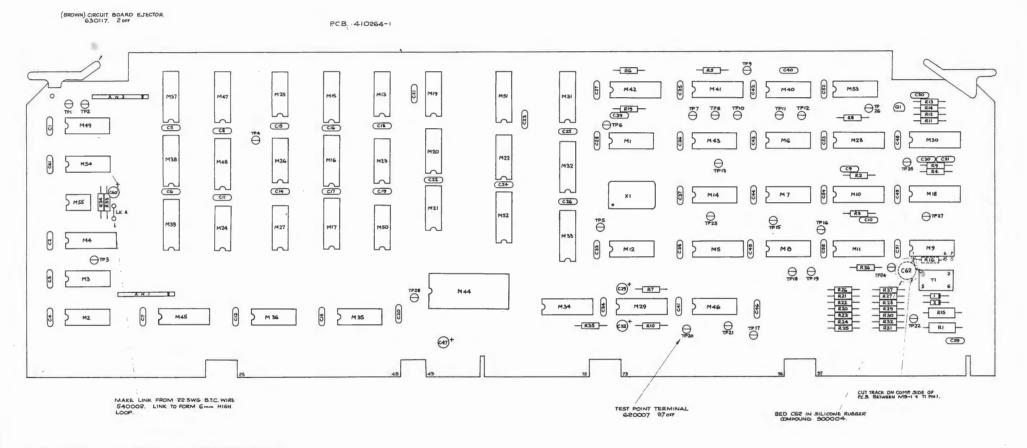


Circuit Diagram No. 430559-1.0 Sheet 5

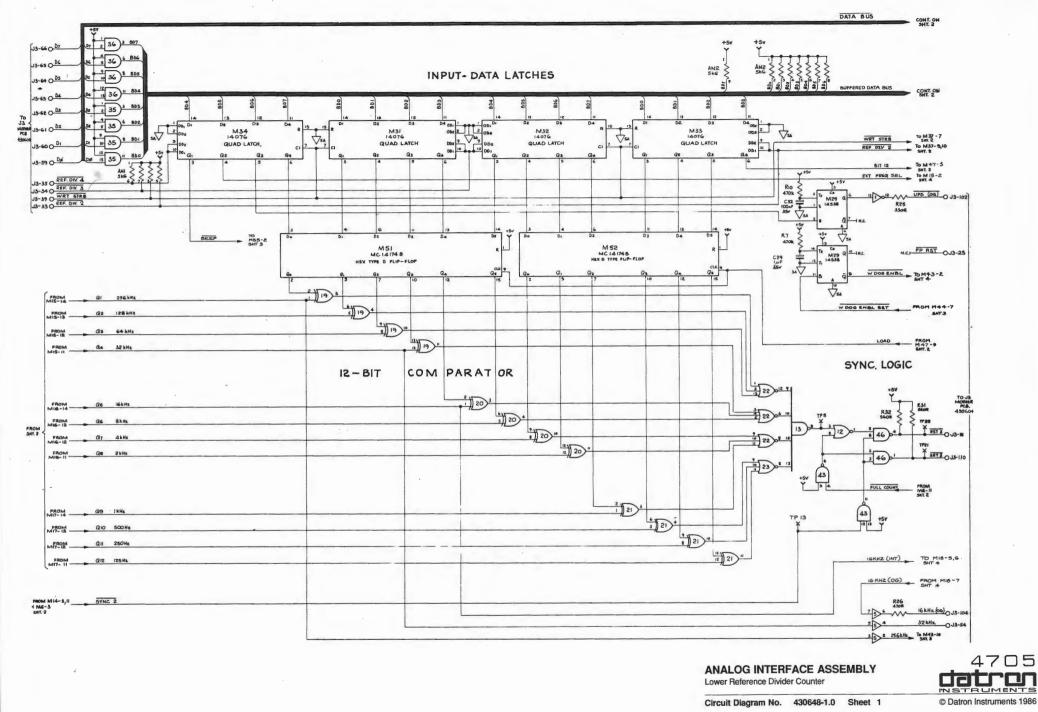
11.2-5

Layout Drawing No. 480648-1.3 Sheet 1 ANALOG INTERFACE ASSEMBLY © Datron Instruments 1986

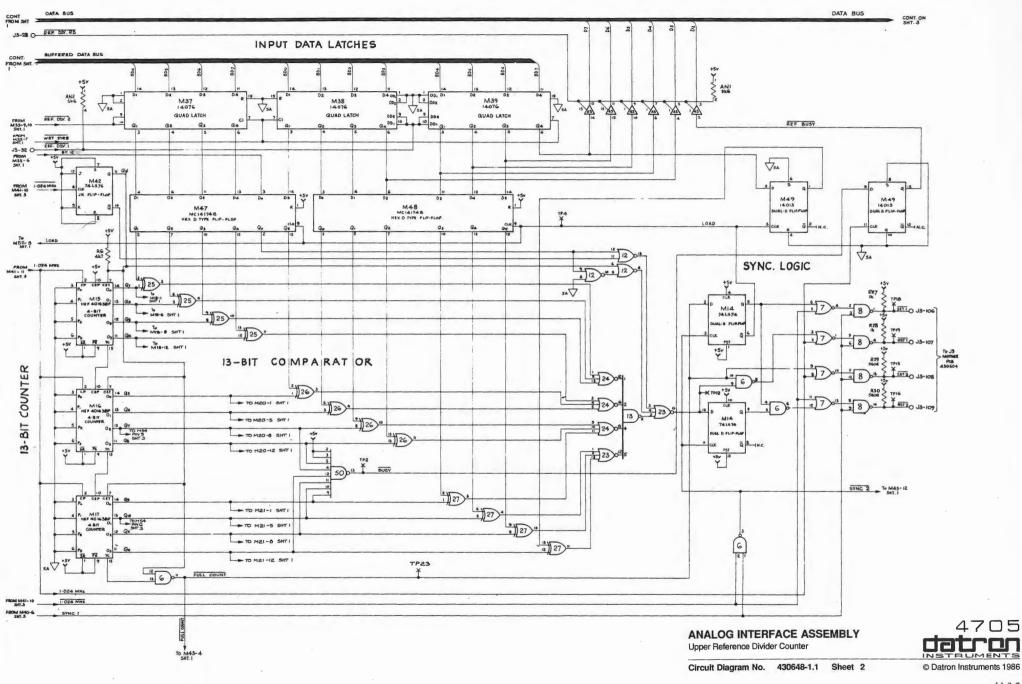
4705



MOUNTING I.C's.			
Nº OF	S PART Nº USED TO MOUNT	Nº WAYS	
1	605059 55	8	
28	605060 1-3, 6-9, 12-14, 19-27, 35, 36, 40, 43, 46, 49, 50, 53, 54	14	
25	605061 4-5, 15, 16, 17, 29, 31-34, 37-39, 41, 42, 45, 47, 48, 51, 52, 10, 11, 1	16	
1	605064 44	24	
	605064 44	24	

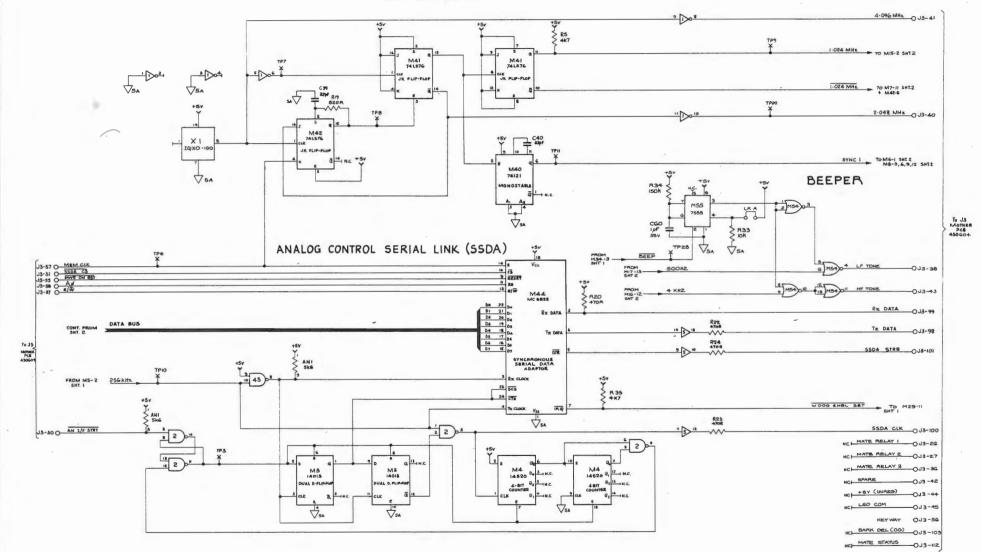


11.3-1



^{11.3-2}



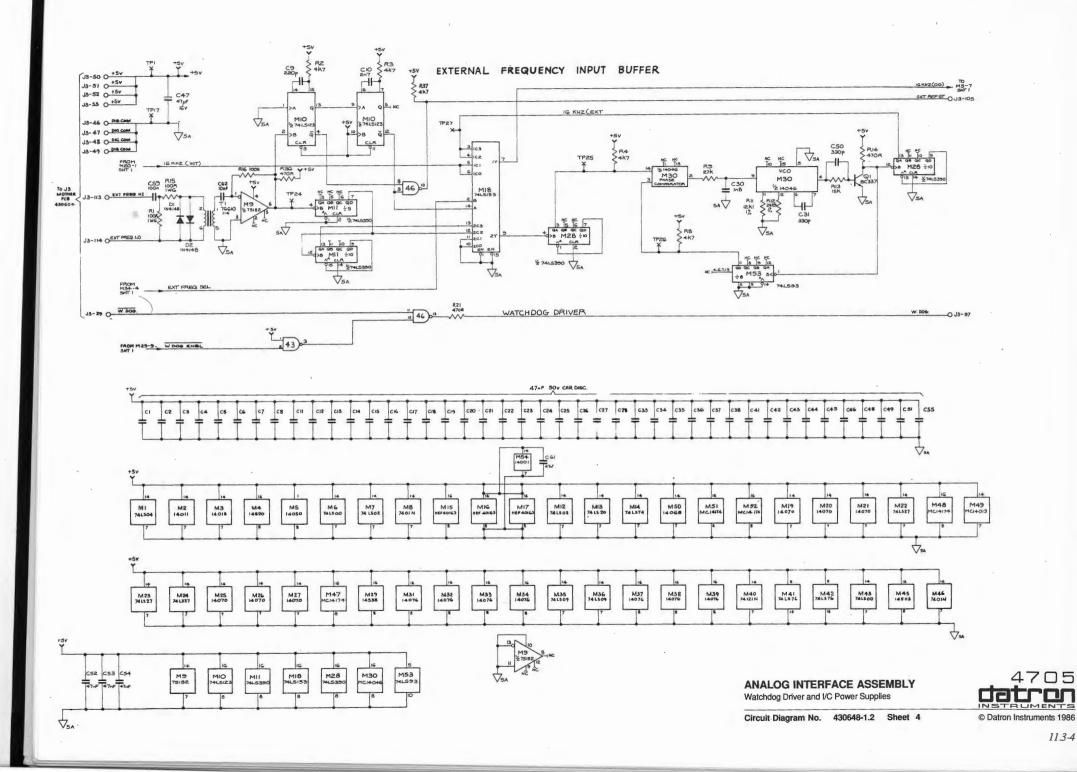


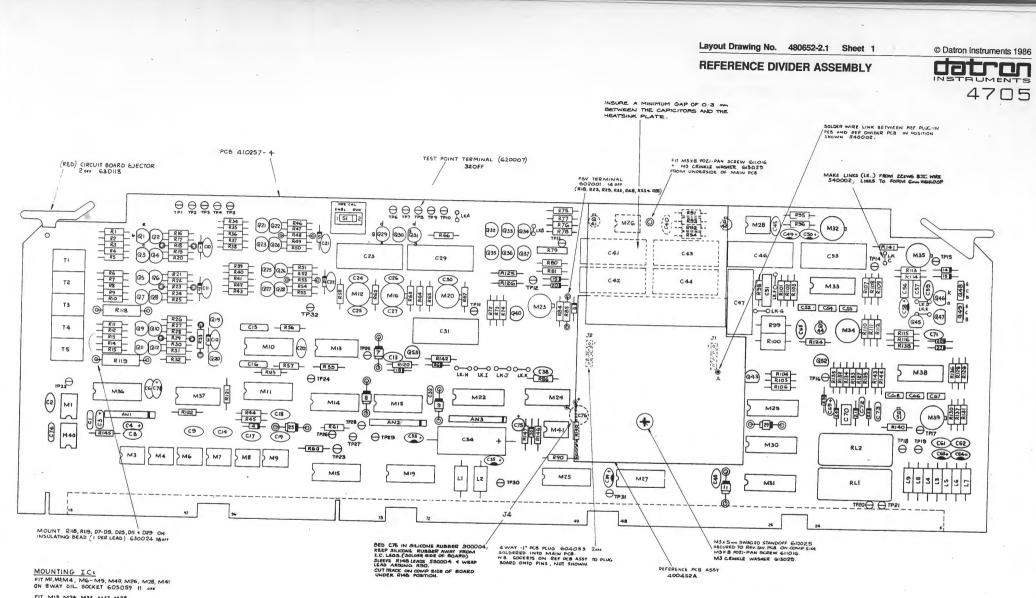
ANALOG INTERFACE ASSEMBLY Master Clocks and Analog Serial Link 4705

© Datron Instruments 1986

Circuit Diagram No. 430648-1.1 Sheet 3

11.3-3

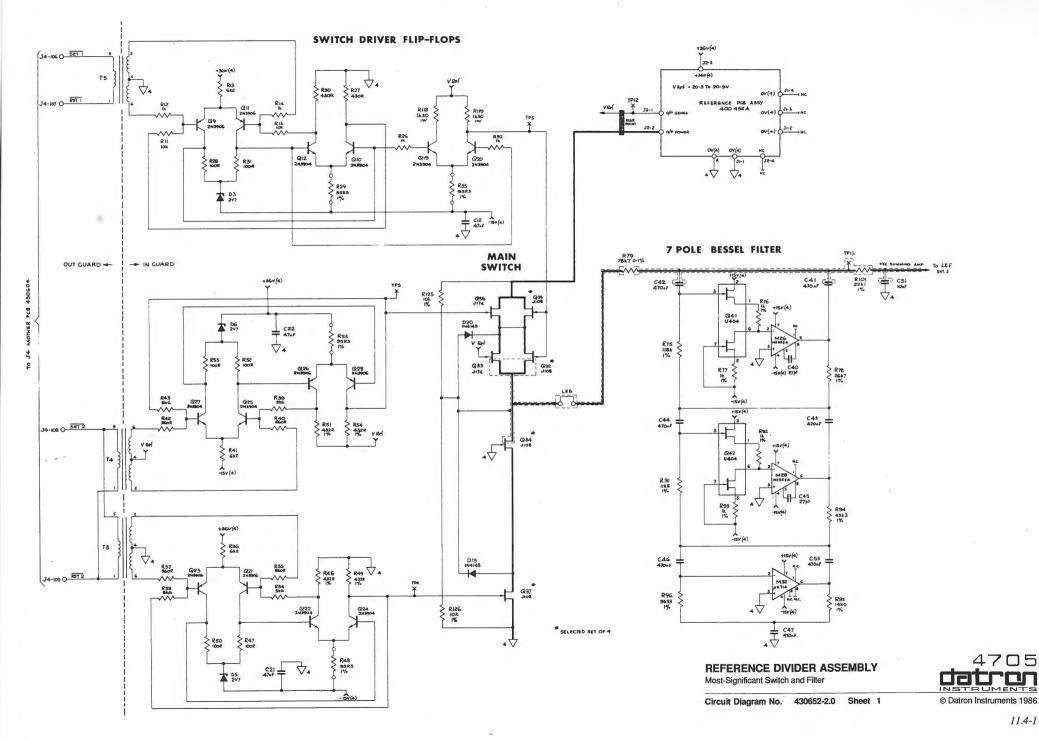


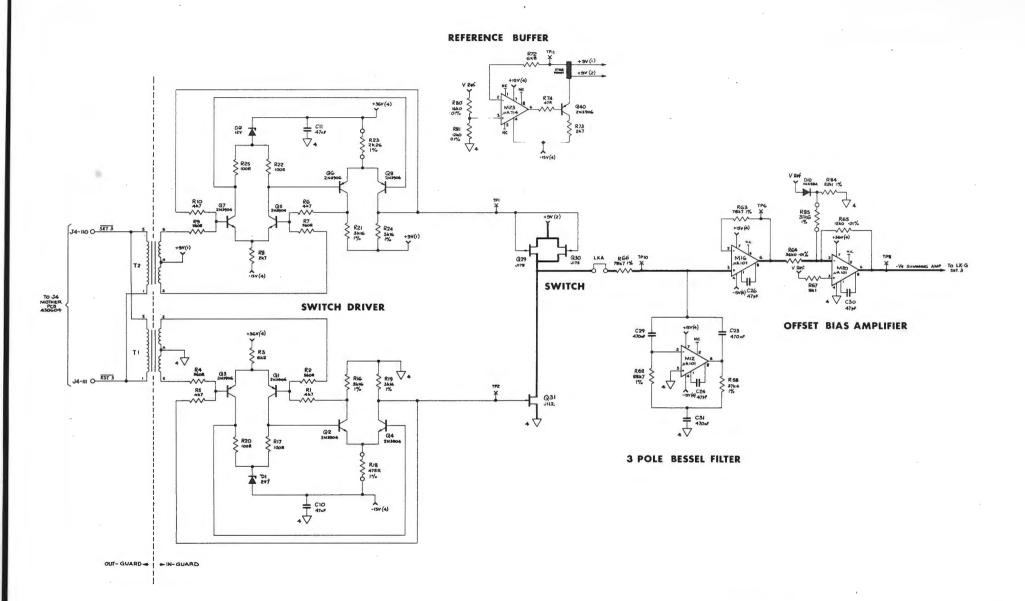


N.B. CLASS BEAD 630243 FITTED TO EACH LEG OF THE FOLLOWING COMPONENTS - CI, C2, C6, C8-Ci2, Ci4, CI7-C22, C25, C27, C32, C48, C59, C61, C62, C74

FIT MI3, M24. M33, M37, M38 ON 14 WAY DIL SOCKET 605060 5 050

FIT MIO, MII, MI4, MI5, , MI8, MI9, M22, M25, M27 M29, M30, M31, M36 ON 16 WAY DIL SOCKET 605061 13 off



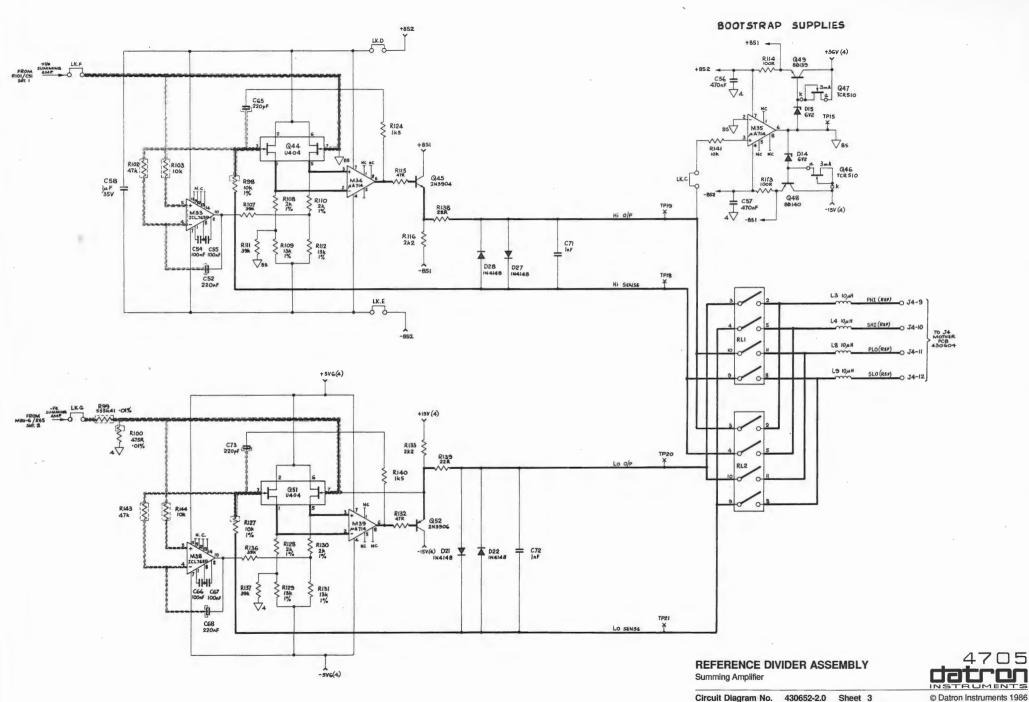


REFERENCE DIVIDER ASSEMBLY Least-Significant Switch and Filter

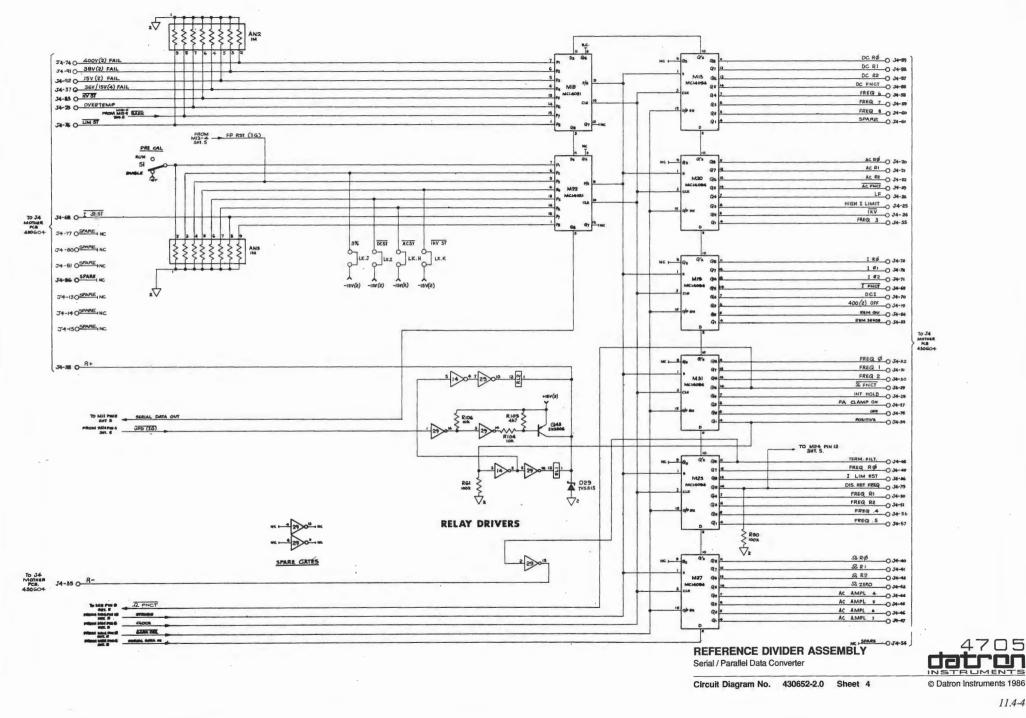


Circuit Diagram No. 430652-2.0 Sheet 2

11.4-2

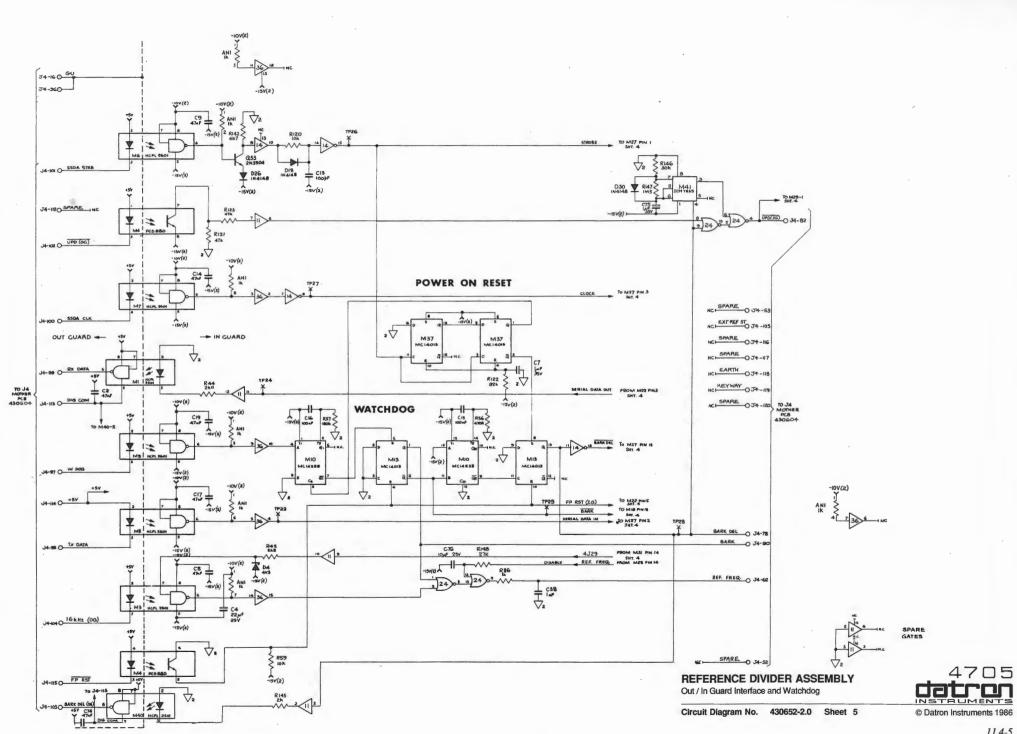


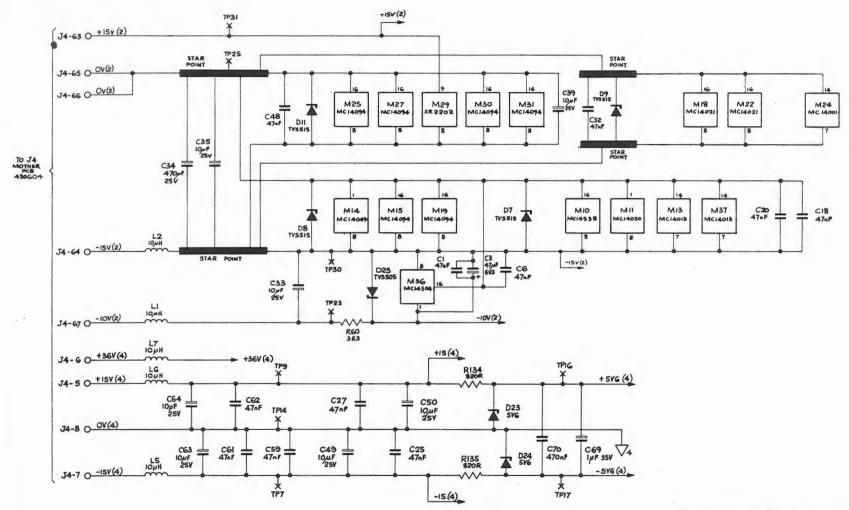
Circuit Diagram No. 430652-2.0 Sheet 3



4705 пг

11.4-4





REFERENCE DIVIDER ASSEMBLY Power Supplies



Circuit Diagram No. 430652-2.0 Sheet 6

Layout Drawing No. 480452-7.0 Sheet 1

REFERENCE ASSEMBLY

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ZENER DIODE KIT 219015 FITTING INSTRUCTIONS.

CARE MUST BE TAKEN THAT FACH DIODE IS PITTED TO ITS CORRECT POSITION ON THE BLOCK. DO NOT REMOVE DIODE SERIAL Nº LABELS. FIT DIODES TO THE CORRECT POSITION AS INDICATED ON THE RECORD SHEET IF ANY COMPONENT IS LOST OR DAMAGED REFER TO Q.A.

I.FIT CONTENTS OF BAG A TO DE, D4, D7, D9 & R3.

2.FIT CONTENTS OF BAG B TO DI, D3, D6, D8 & R4.

3.FILL IN REFERENCE RECORD SHEET :-

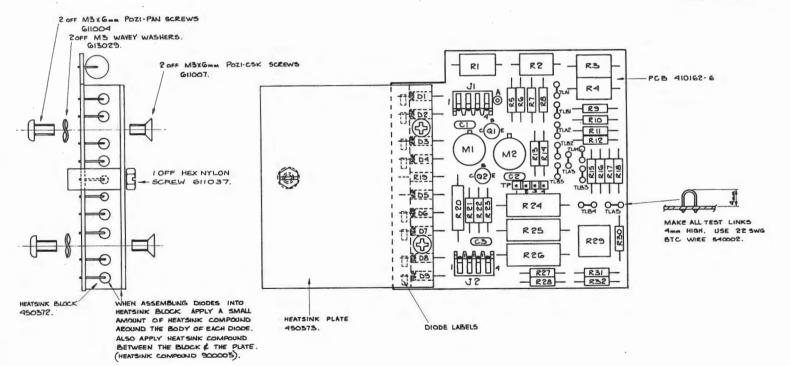
(1). ASSEMBLY SERIAL NO.

(II). ASSEMBLY ISSUE NO.

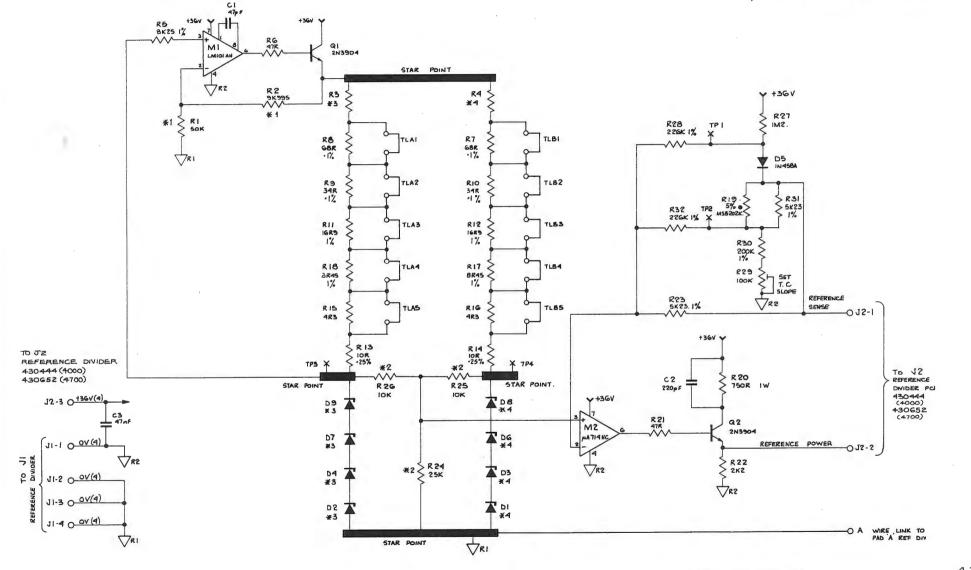
(III). ASSEMBLY DATE.

4. CUT TEST LINKS INDICATED ON THE RECORD SHEET.

5. THE RECORD SHEET MUST ACCOMPANY THE FINISHED ASSEMBLY.



1/ RS & R4 ARE SELECTED WITH THEIR DIDDE SETS. PART OF KIT 210015. VALUES ARE :- 475, GH, 747 & 883 D SEE DRAWING Nº 219015. 2,* INDICATES A MATCHED SET OF COMPONENTS.



REFERENCE ASSEMBLY



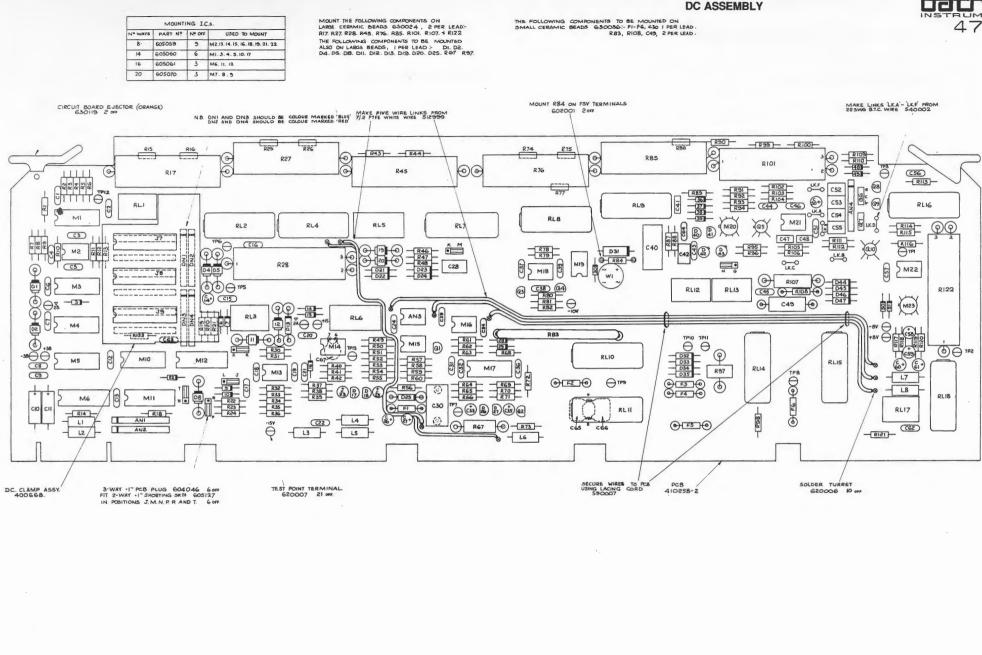
Circuit Diagram No. 430452-7.0 Sheet 1

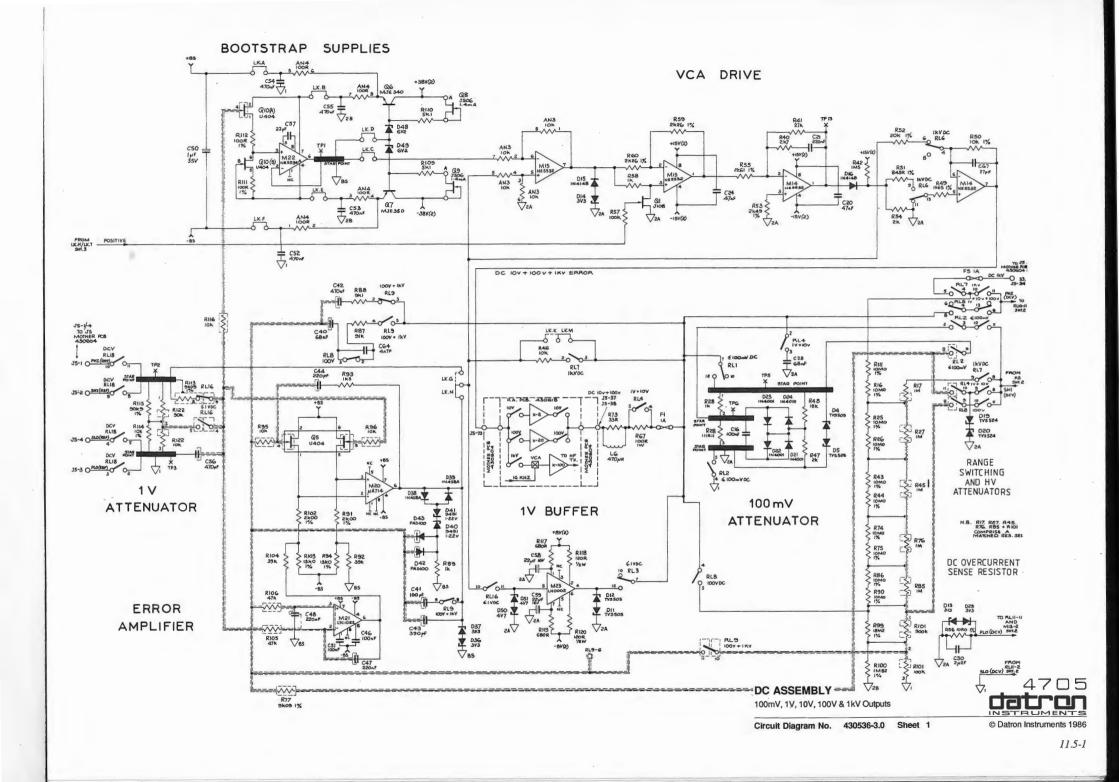
11.4-7

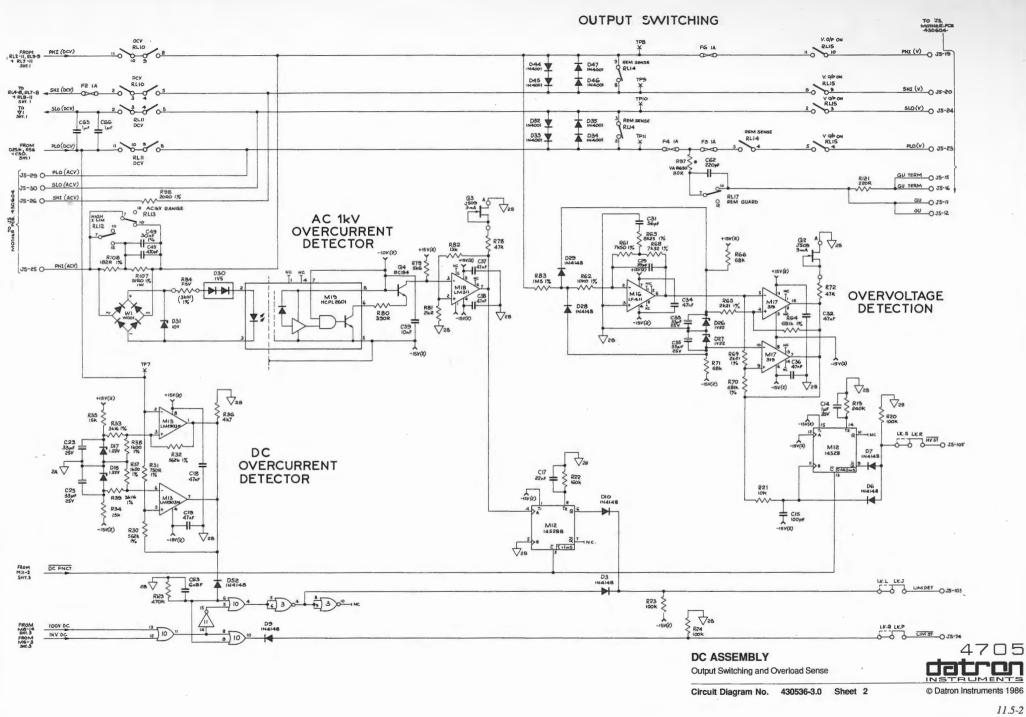
Layout Drawing No. 480536-3.0 Sheet 1

© Datron Instruments 1986

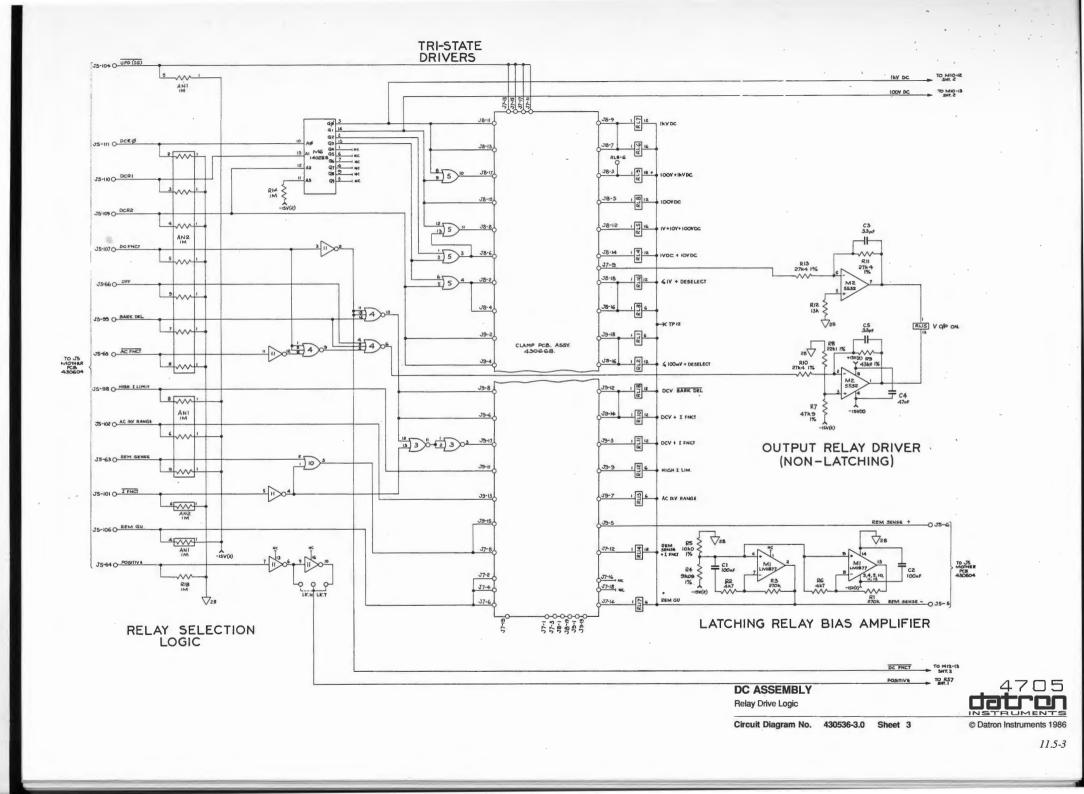




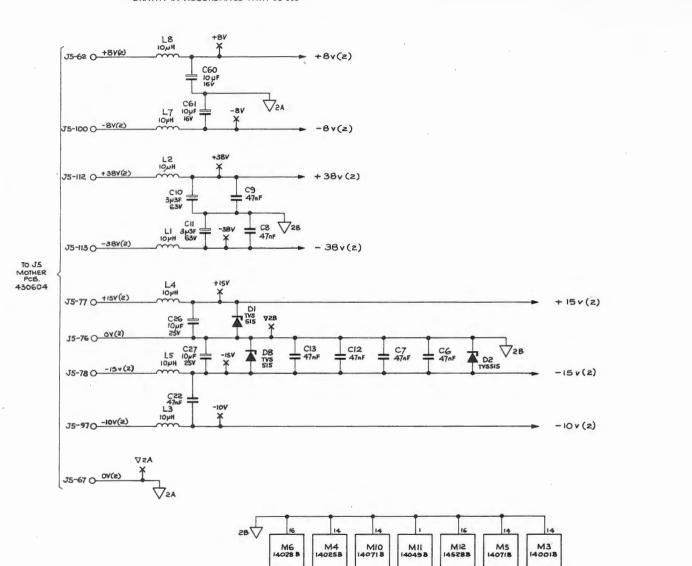




11.5-2



THIRD ANGLE PROJECTION DRAWN IN ACCORDANCE WITH BS 308



M 2 NC ~~ ~~~ NC ANI -15V(2) DN2 ∀гв Ta NC NC NC 2 4 19 DNI * -15V(2) RL14 REM SENSE DIO INC NC H 2003 NC -INC RLIG SIV DC SPARES

> SPARE O J5-75 NCH ov(2) _____ J5-114 NCI-

DC ASSEMBLY Power Supplies

-15V(2)



Circuit Diagram No. 430536-3.0 Sheet 4

© Datron Instruments 1986

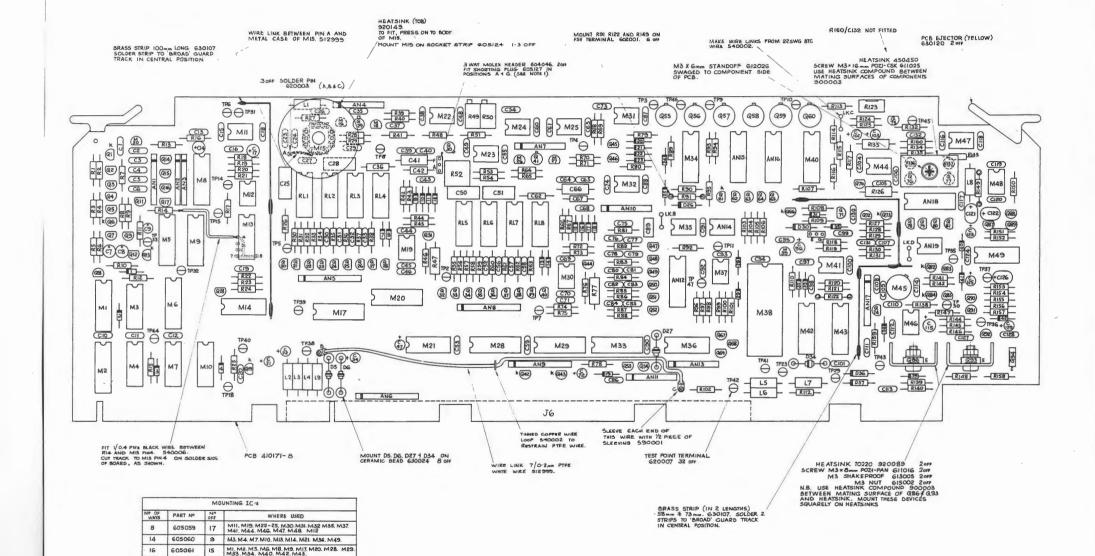
11.5-4

Layout Drawing No. 480446-9.0 Sheet 1

SINE SOURCE ASSEMBLY

NOTE I. FIT LINK'E' AND LINK 'F' IN PLACE OF LINK 'A' AND LINK 'G' FOR TEST.

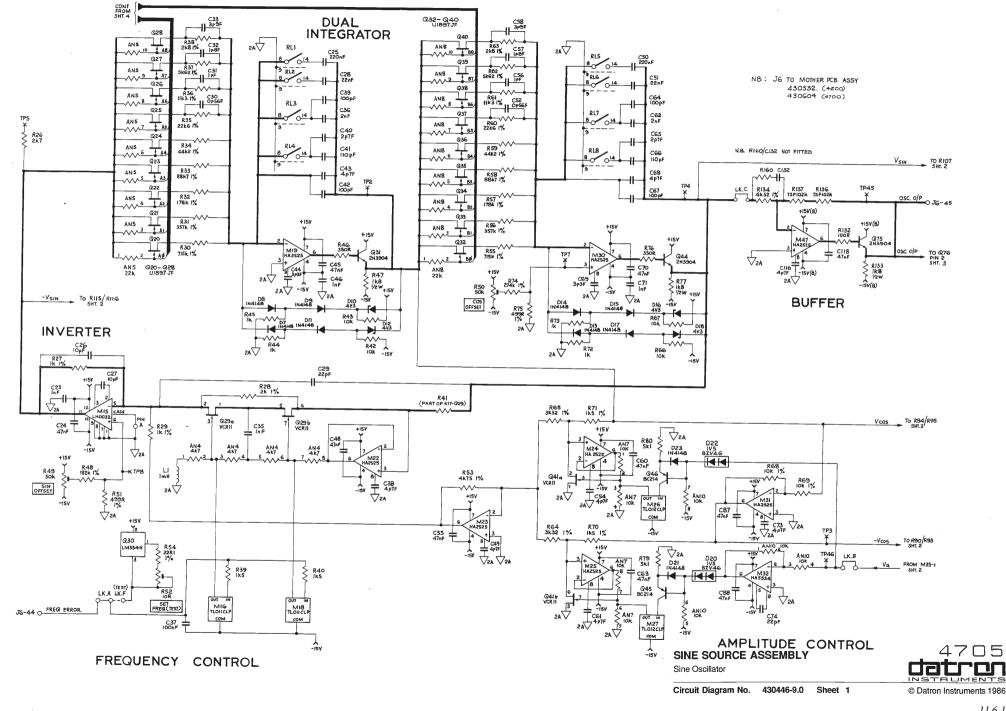




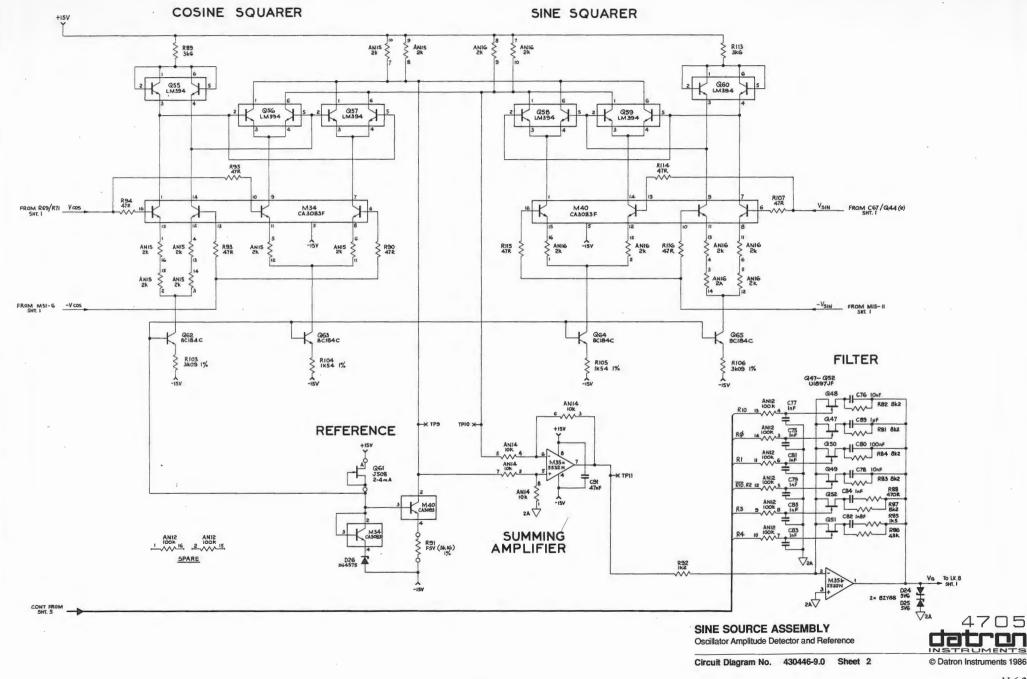
28

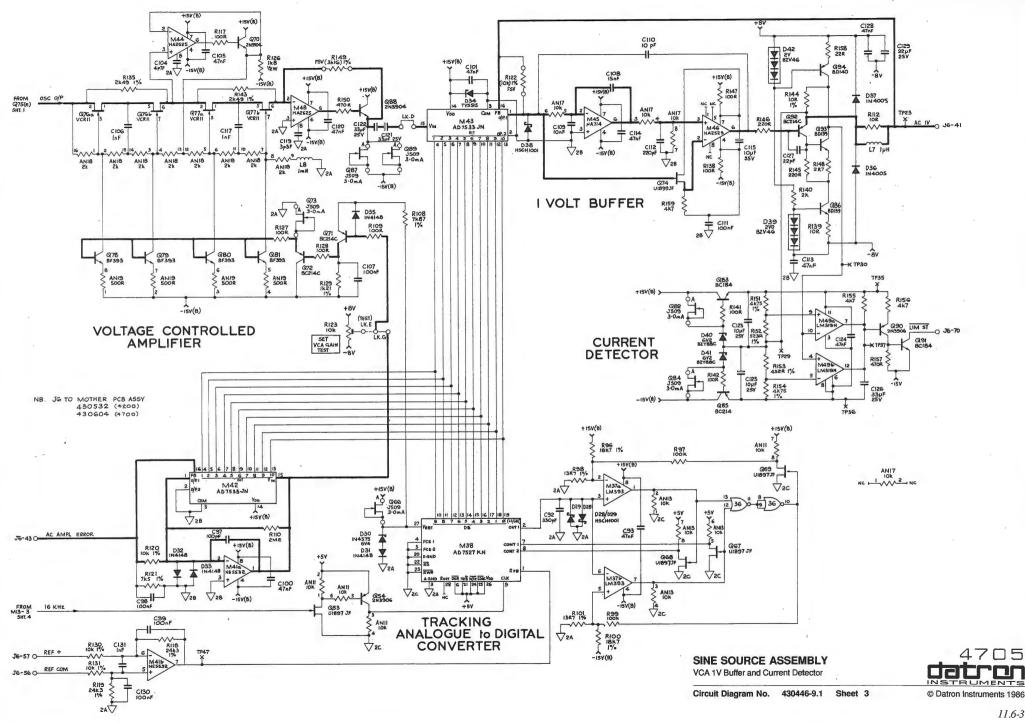
605065

J M38

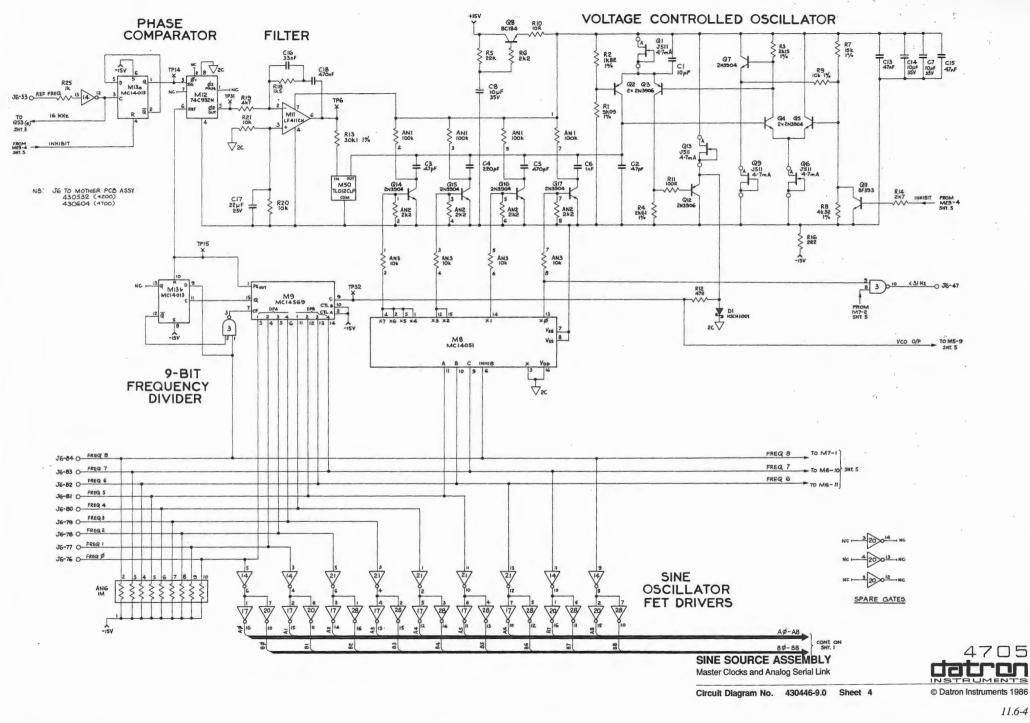


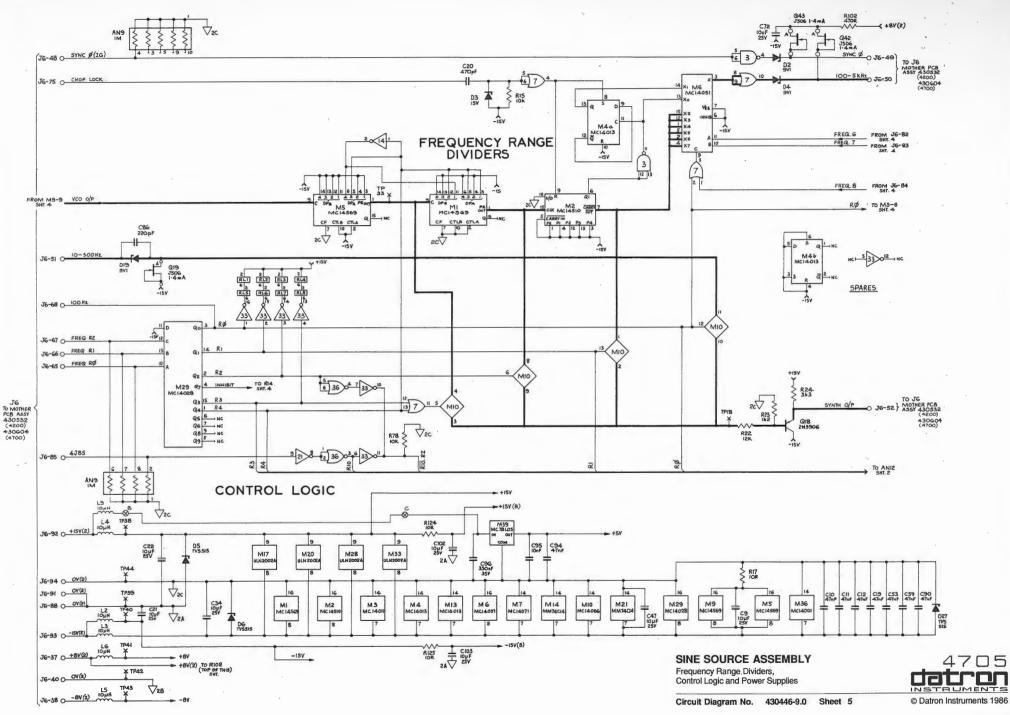
11.6-1

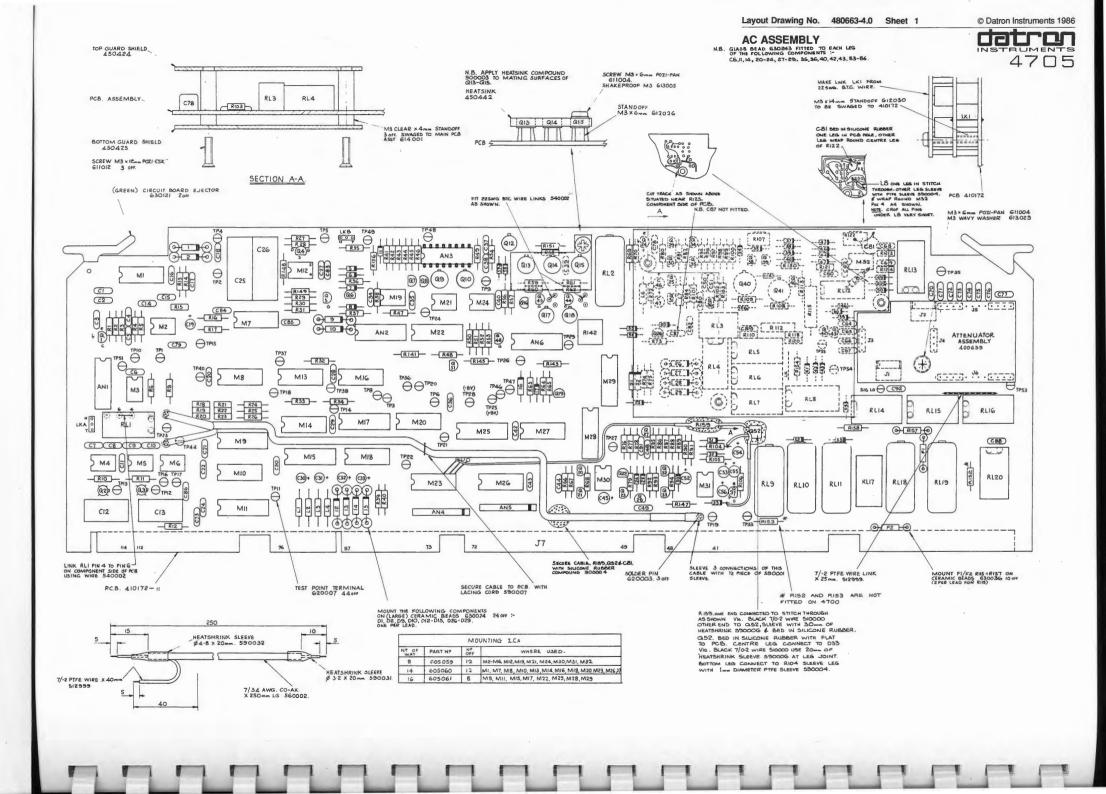


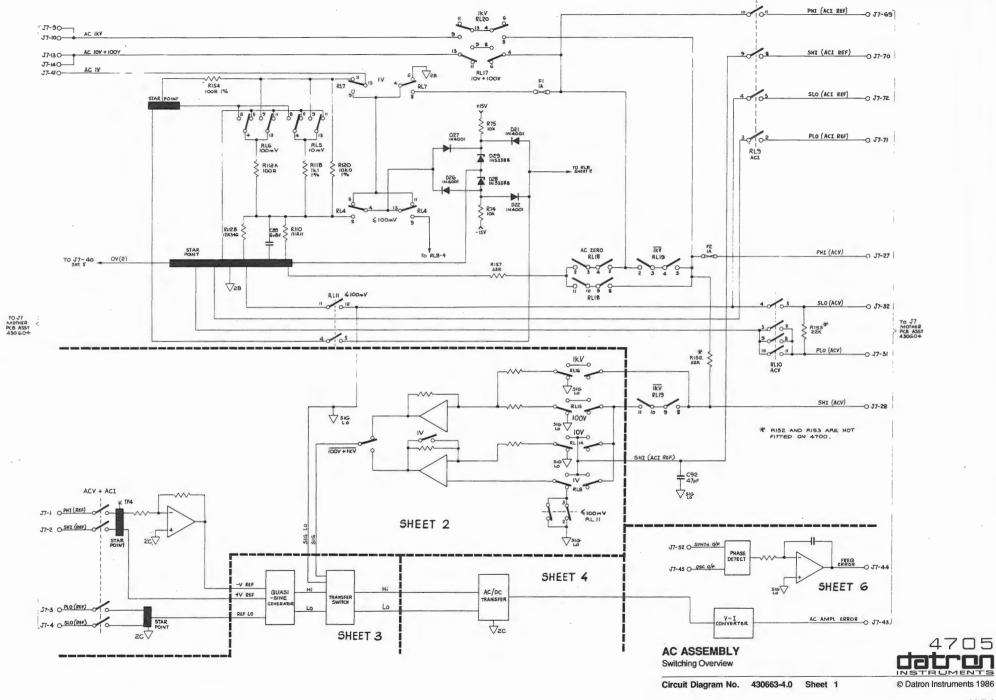


^{11.6-3}

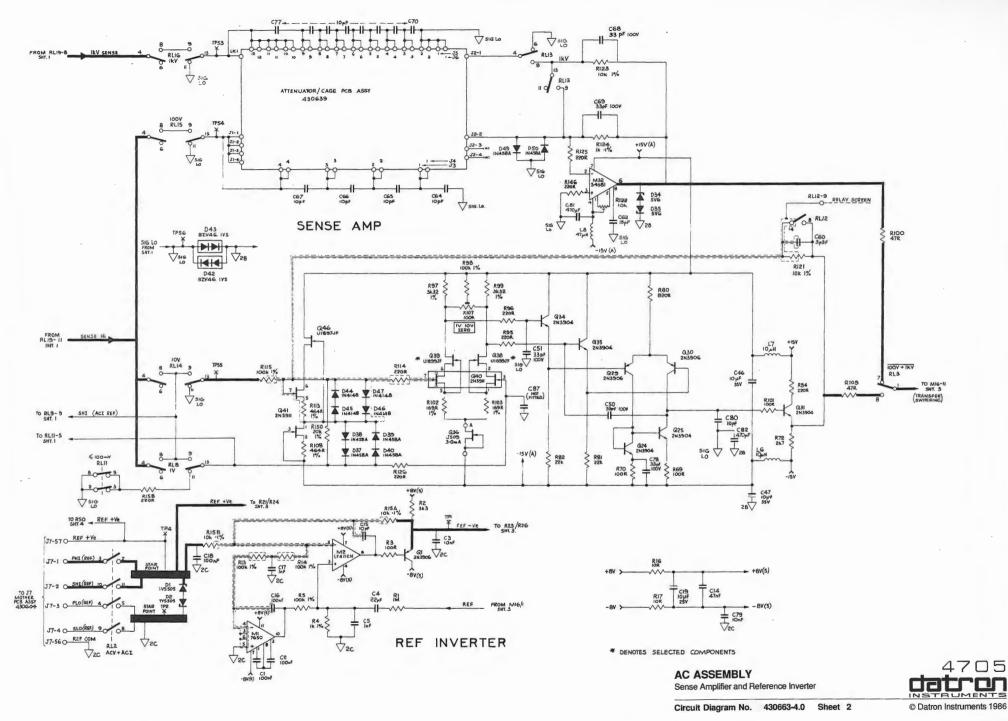


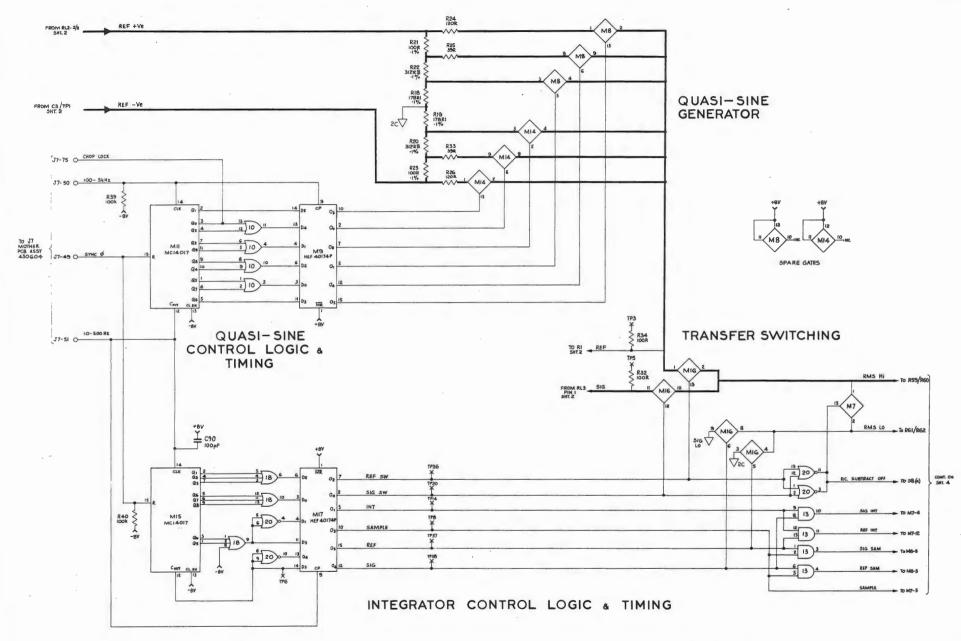






11.7-1



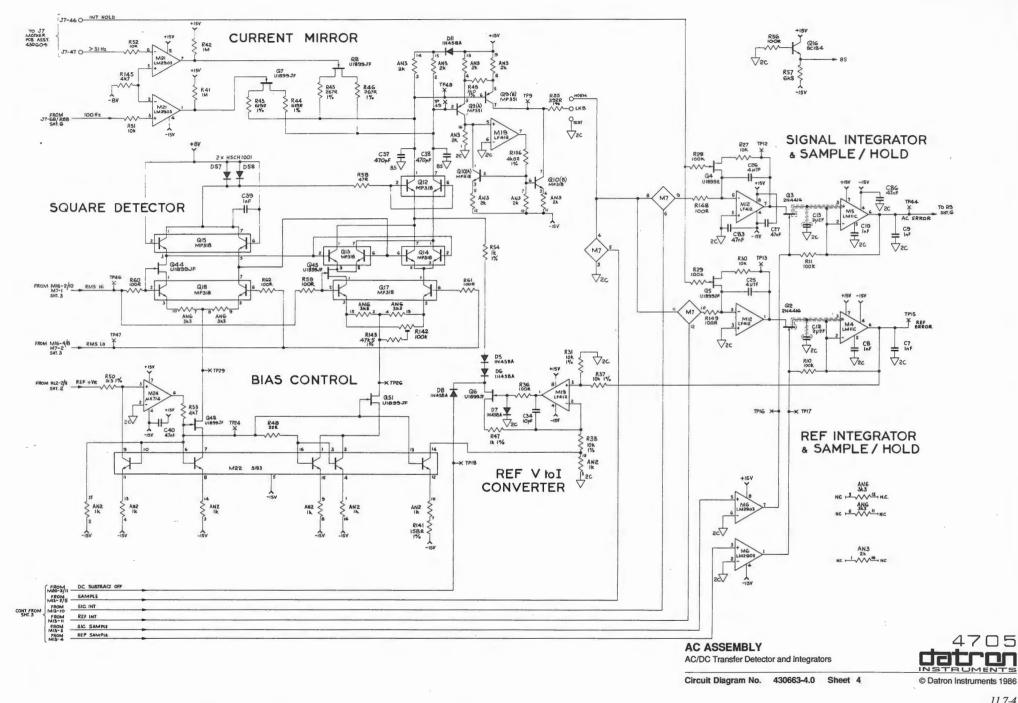


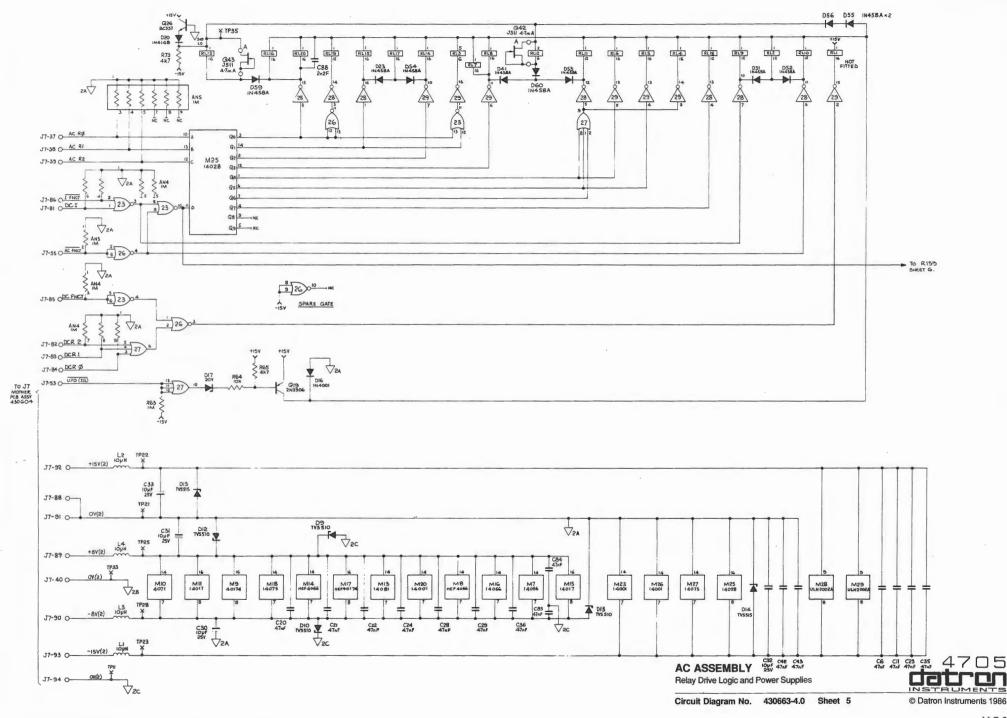
AC ASSEMBLY Quasi-Sine Generator and Timing Logic



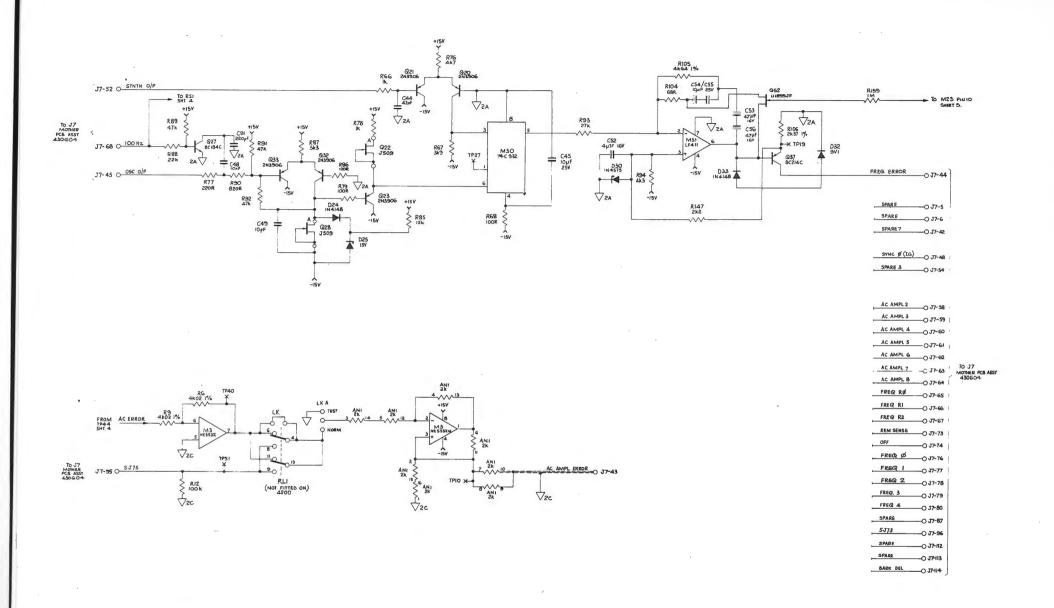
Circuit Diagram No. 430663-4.0 Sheet 3

11.7-3





11.7-5



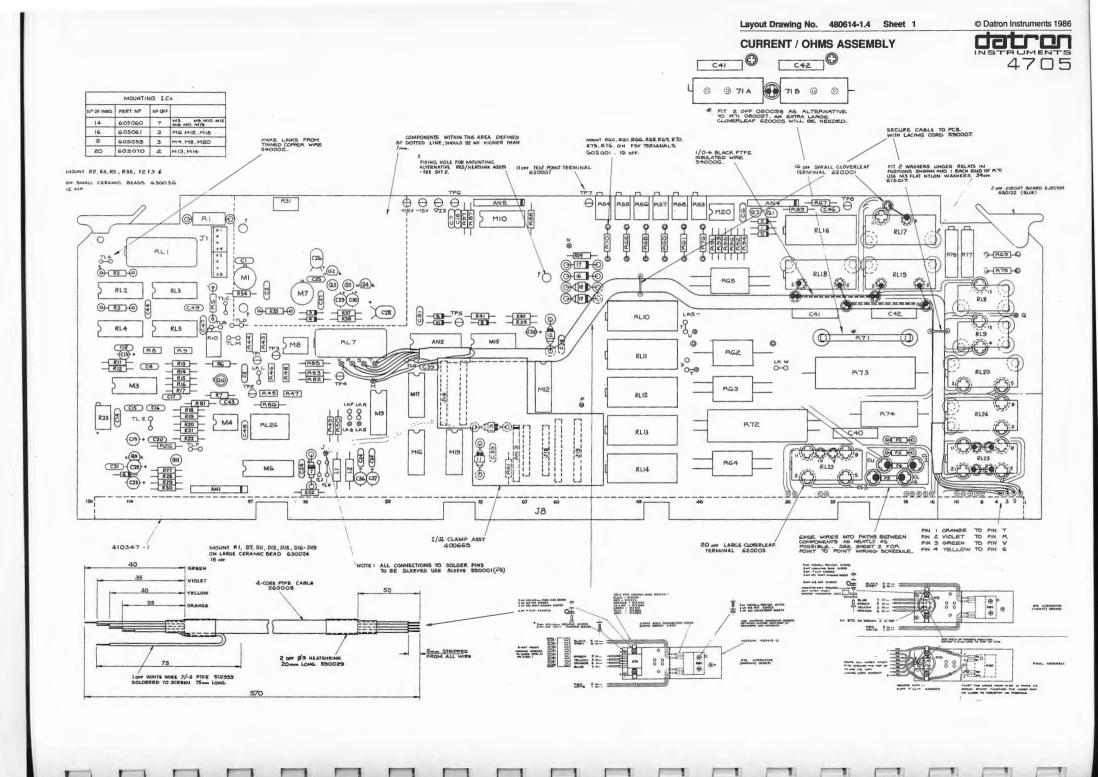
C41, R7, R8 - NOT FITTED.

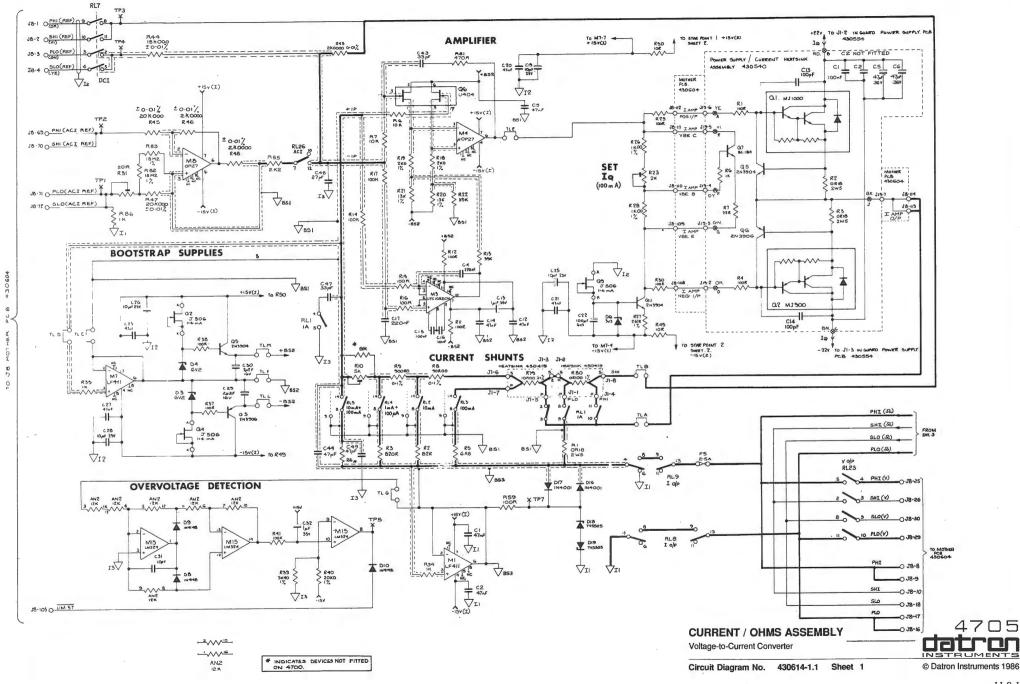
AC ASSEMBLY Phase Detector and Integrator; Power Supplies



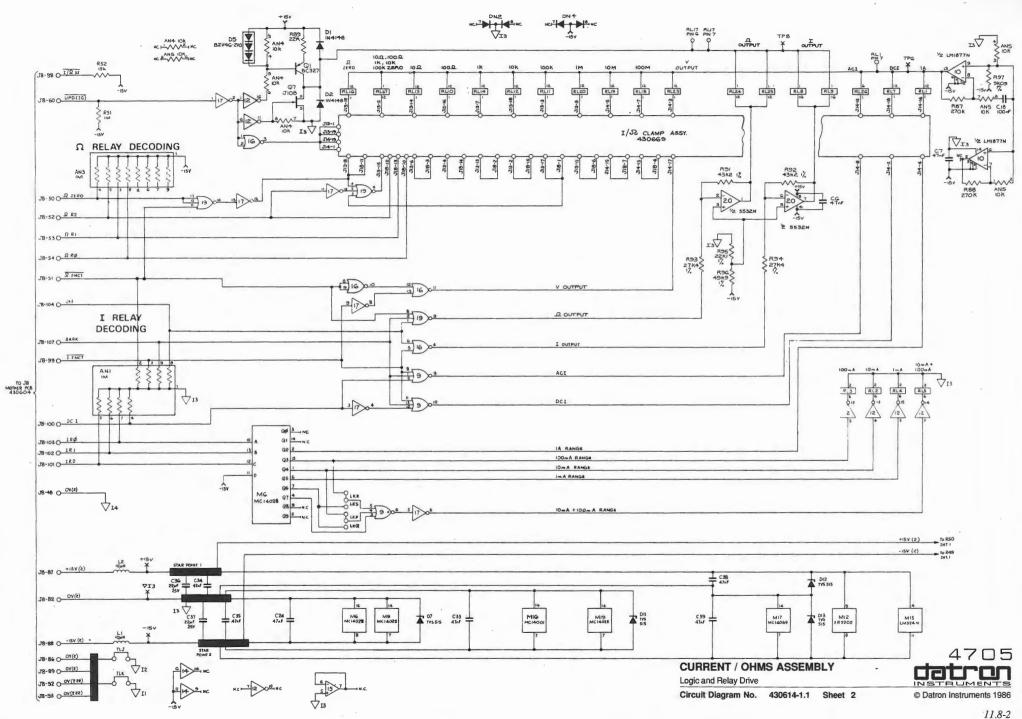
Circuit Diagram No. 430663-4.0 Sheet 6

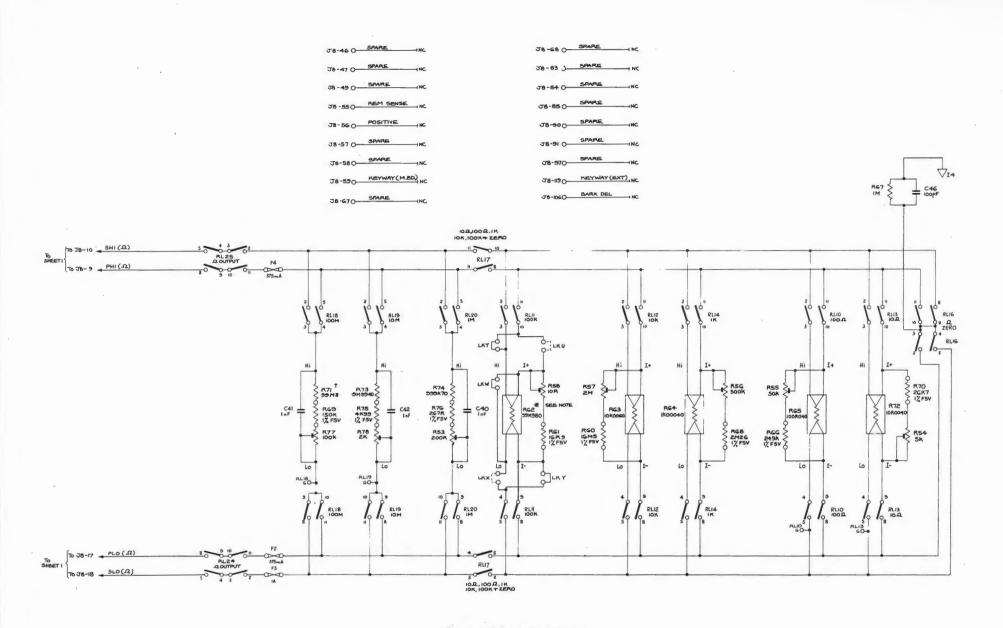
instruments 1960





^{11.8-1}



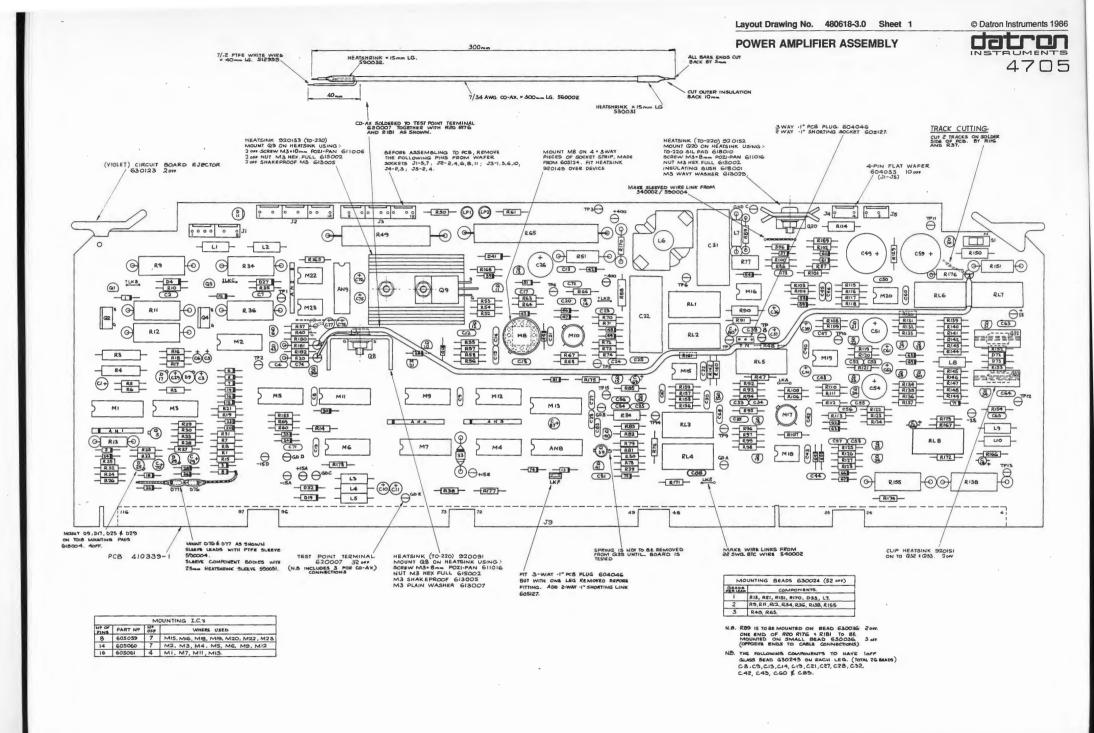


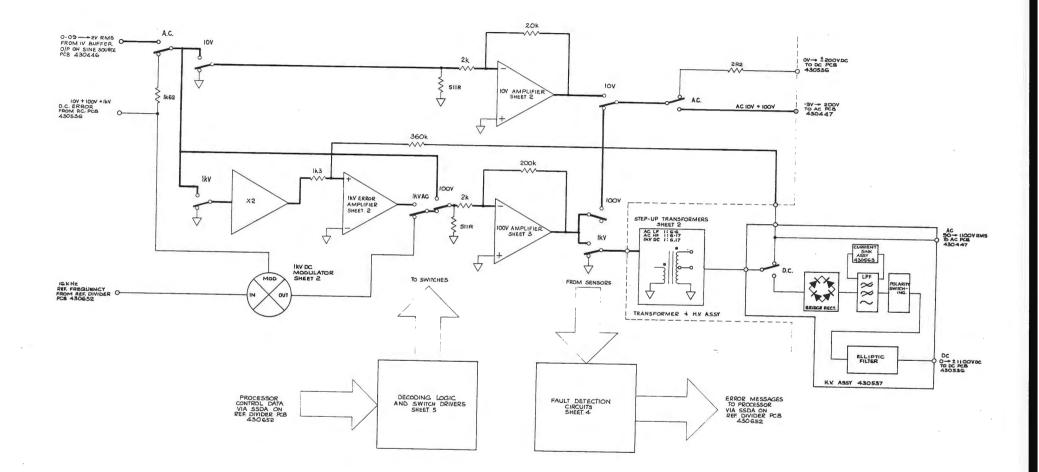
* NOTE RG2 IS A 2-WIRE RESISTOR ON THE 4700. ALTERNATIVE RESISTOR SET COMPRISES TWO 49 M9 IN BERIES.

> CURRENT / OHMS ASSEMBLY Standard Resistors and Switching

4705 INSTRUMENTS © Datron Instruments 1986

Circuit Diagram No. 430614-1.1 Sheet 3





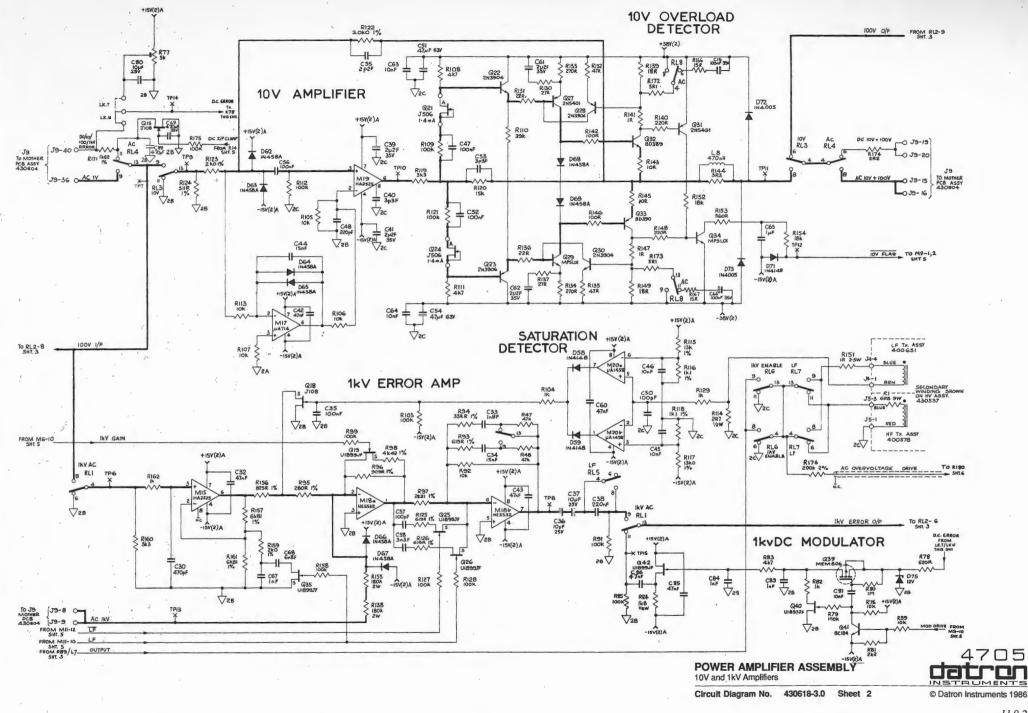
.

POWER AMPLIFIER ASSEMBLY Block Diagram

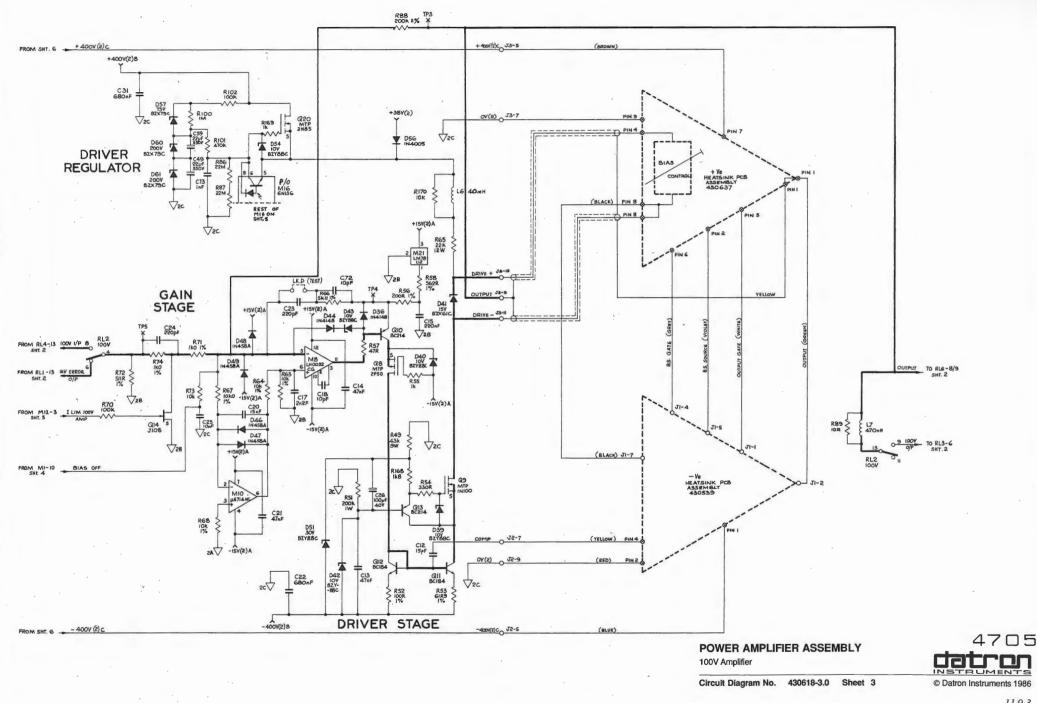


Circuit Diagram No. 430618-3.0 Sheet 1

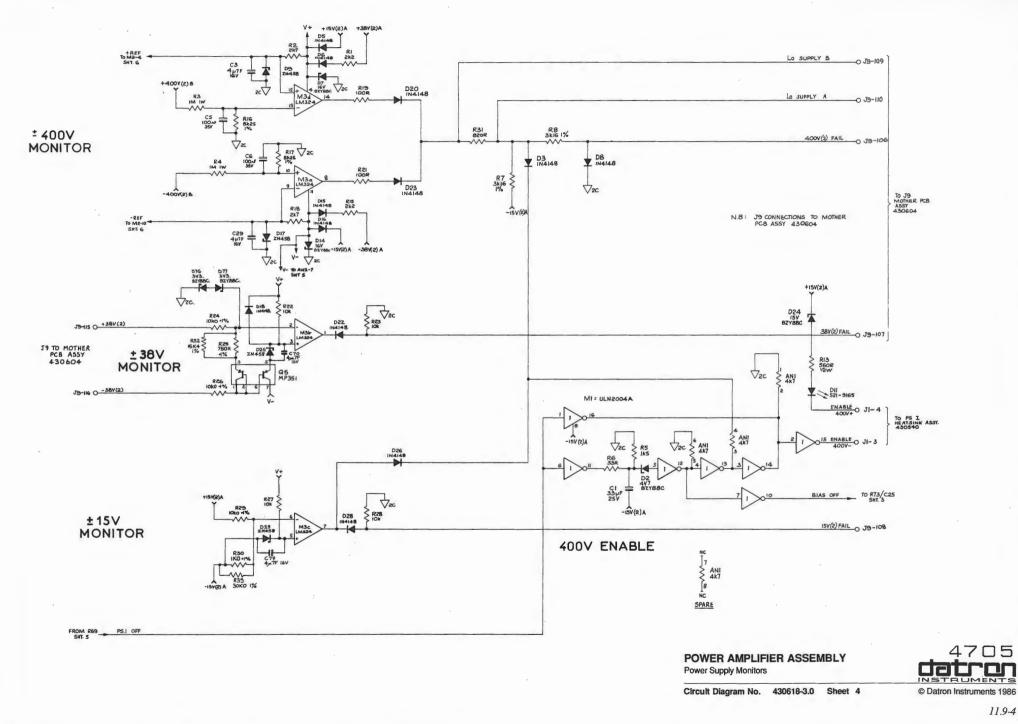
11.9-1

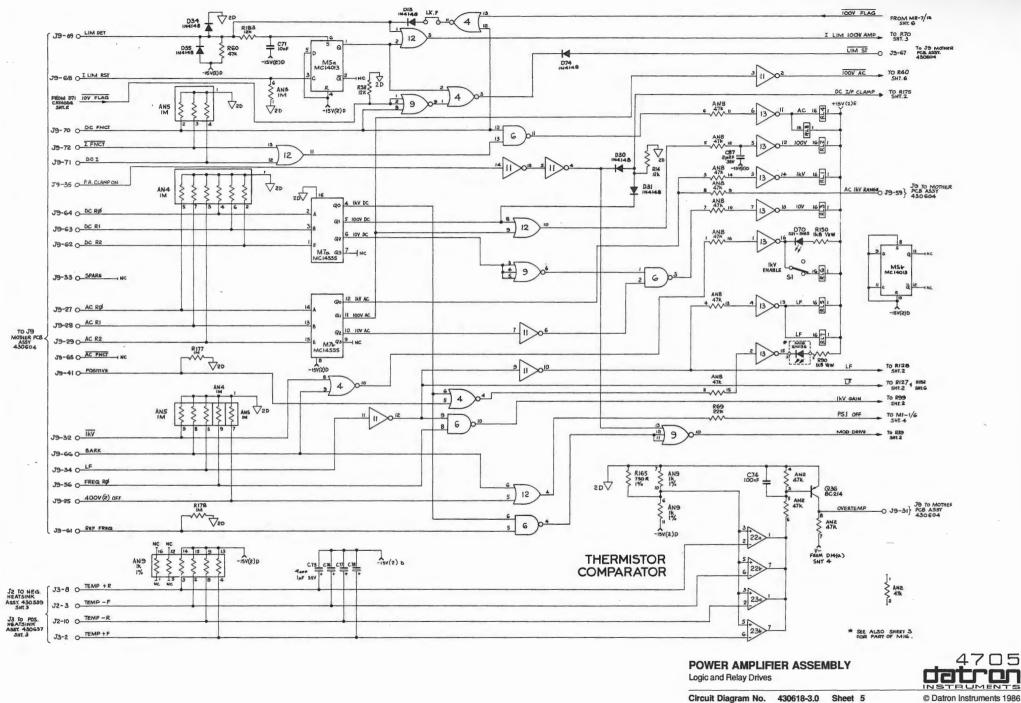


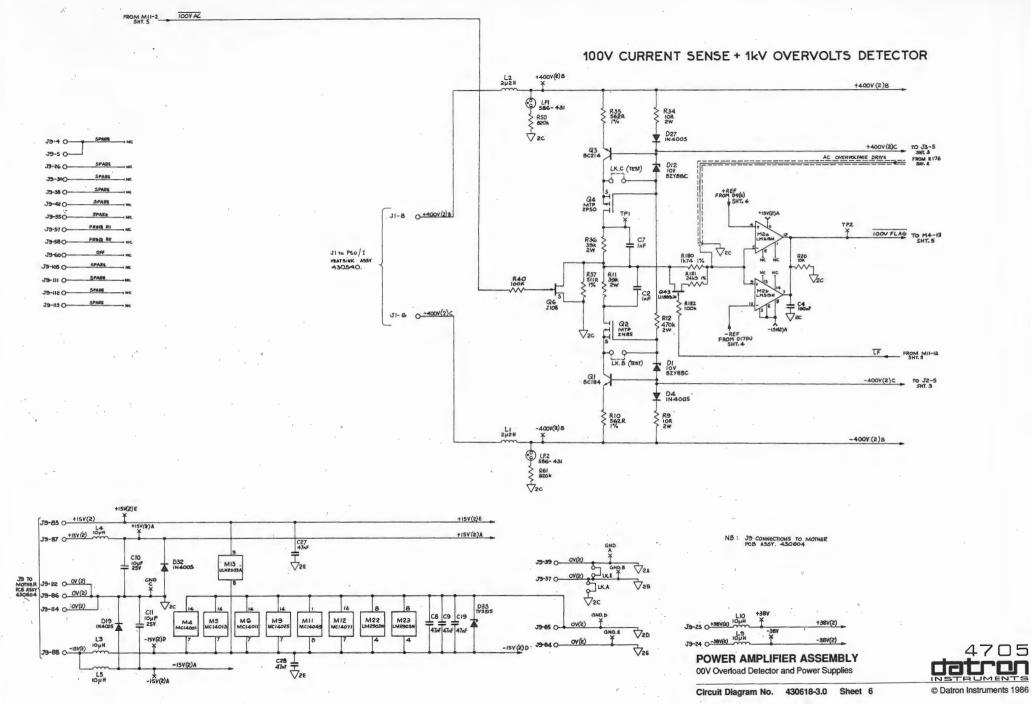
11.9-2_



11.9-3





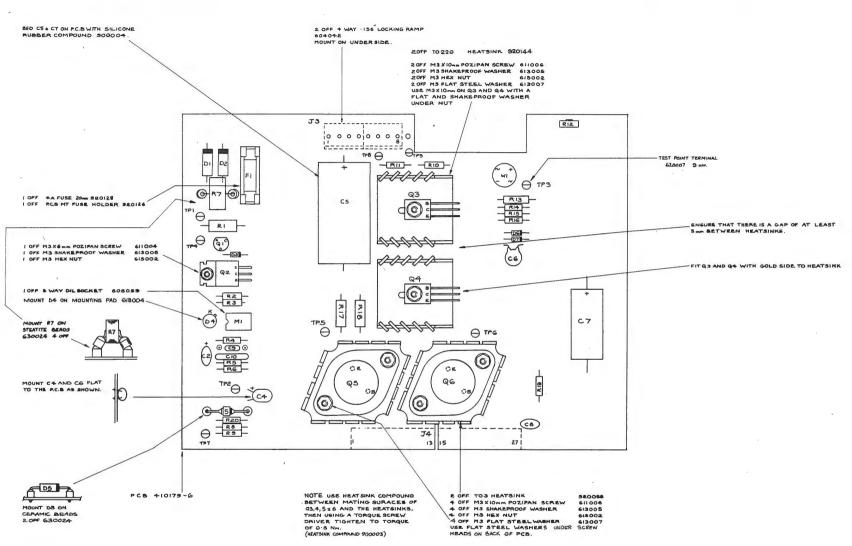


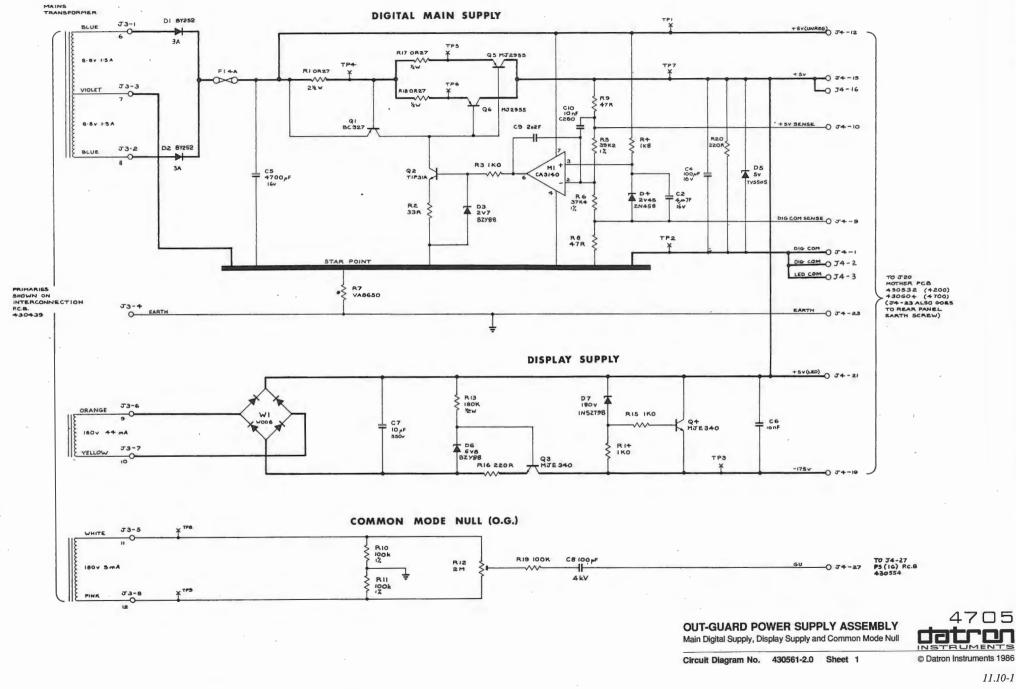
11.9-6

Layout Drawing No. 480561-2.1 Sheet 1

OUT-GUARD POWER SUPPLY ASSEMBLY

4705



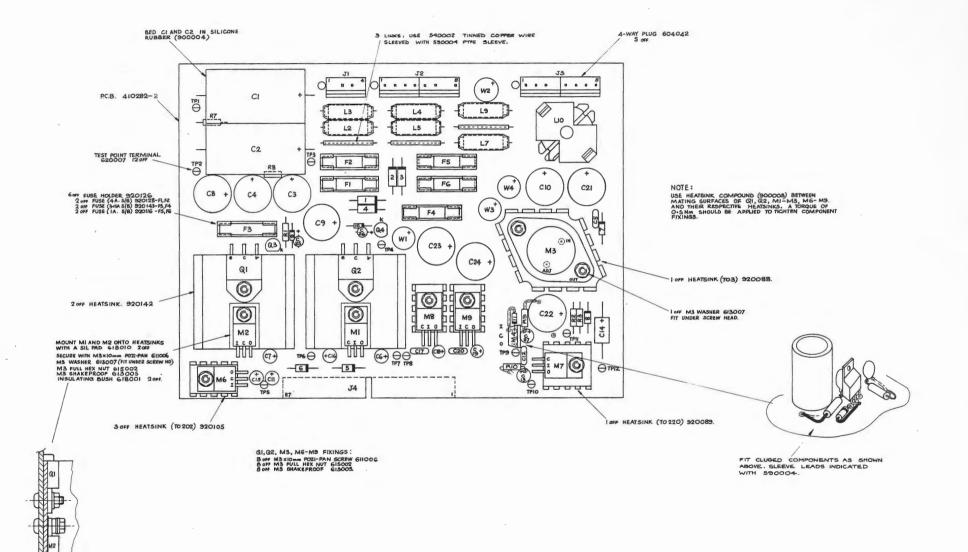


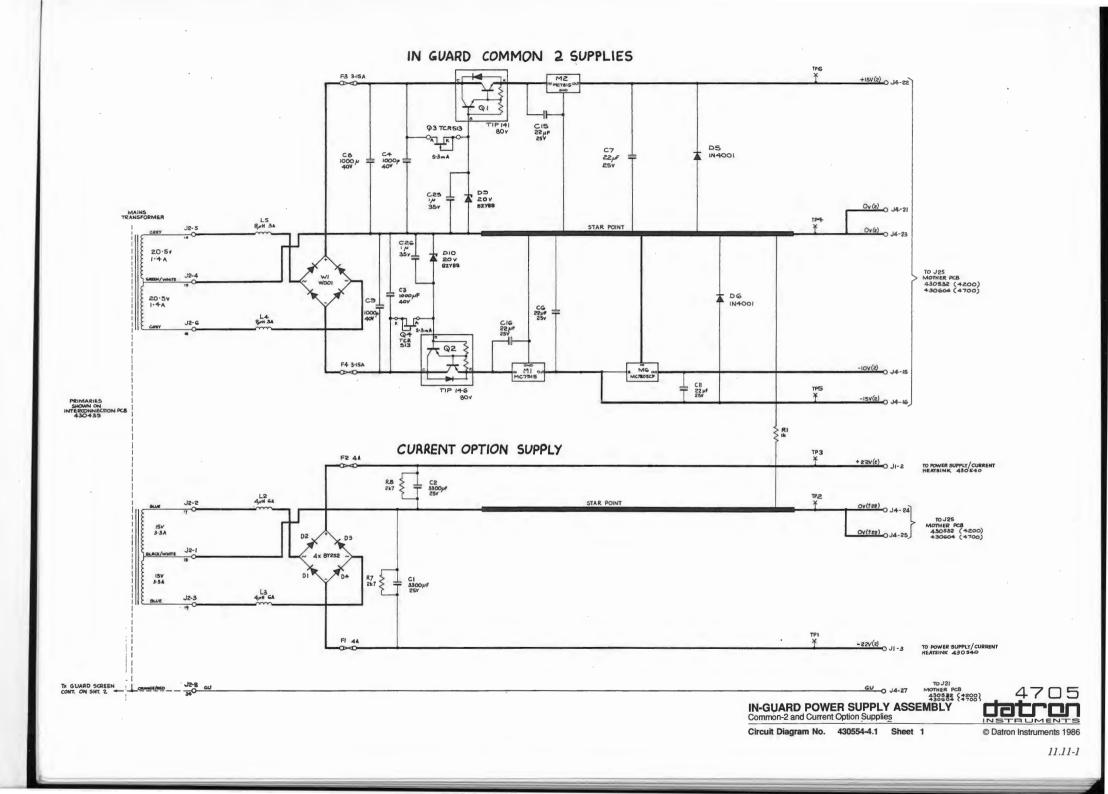
11.10-1

Layout Drawing No. 480554-4.1 Sheet 1

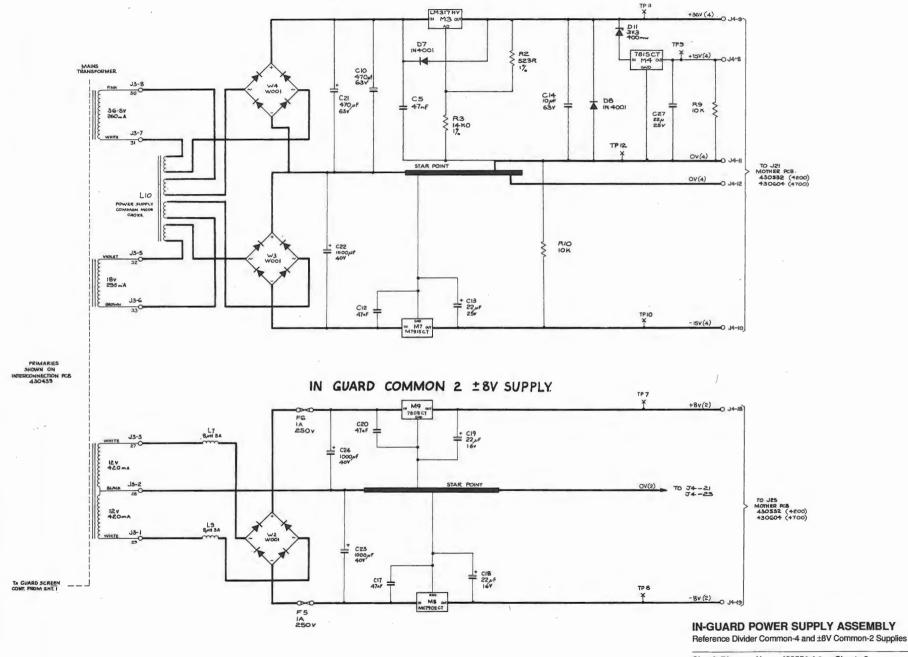
IN-GUARD POWER SUPPLY ASSEMBLY







REFERENCE DIVIDER COMMON 4 SUPPLIES



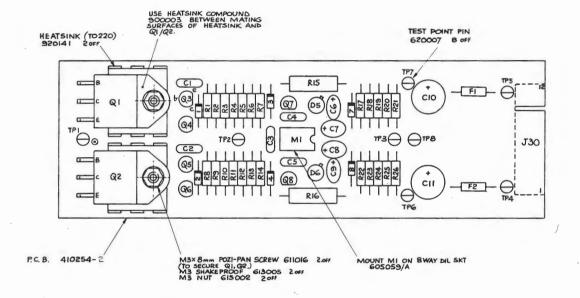


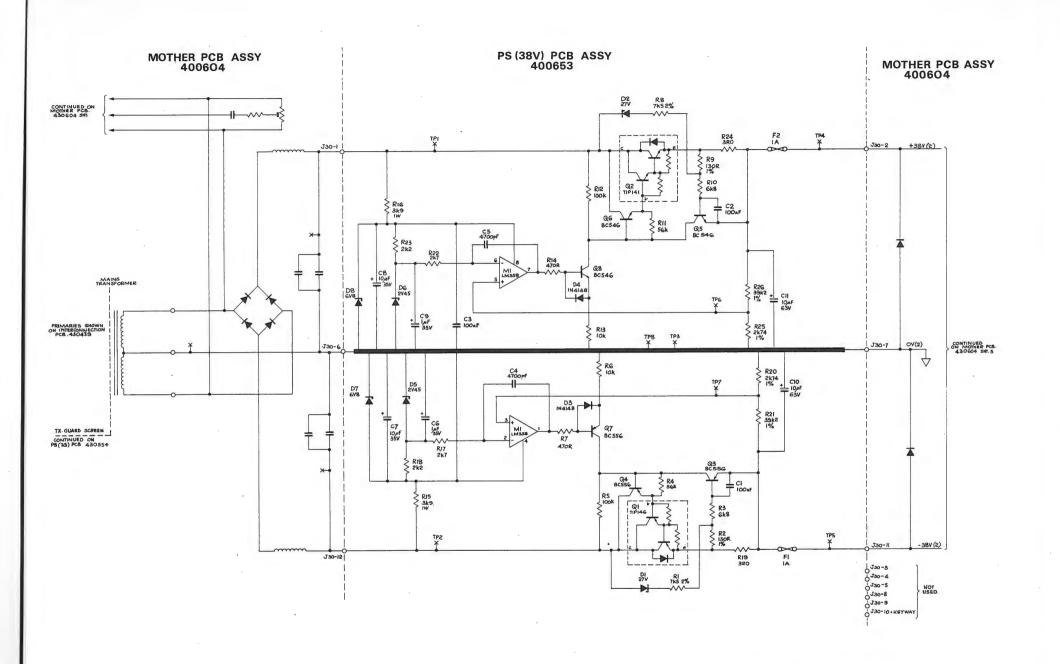
Circuit Diagram No. 430554-4.0 Sheet 2

Layout Drawing No. 480653-1.0 Sheet 1

±38V POWER SUPPLY ASSEMBLY



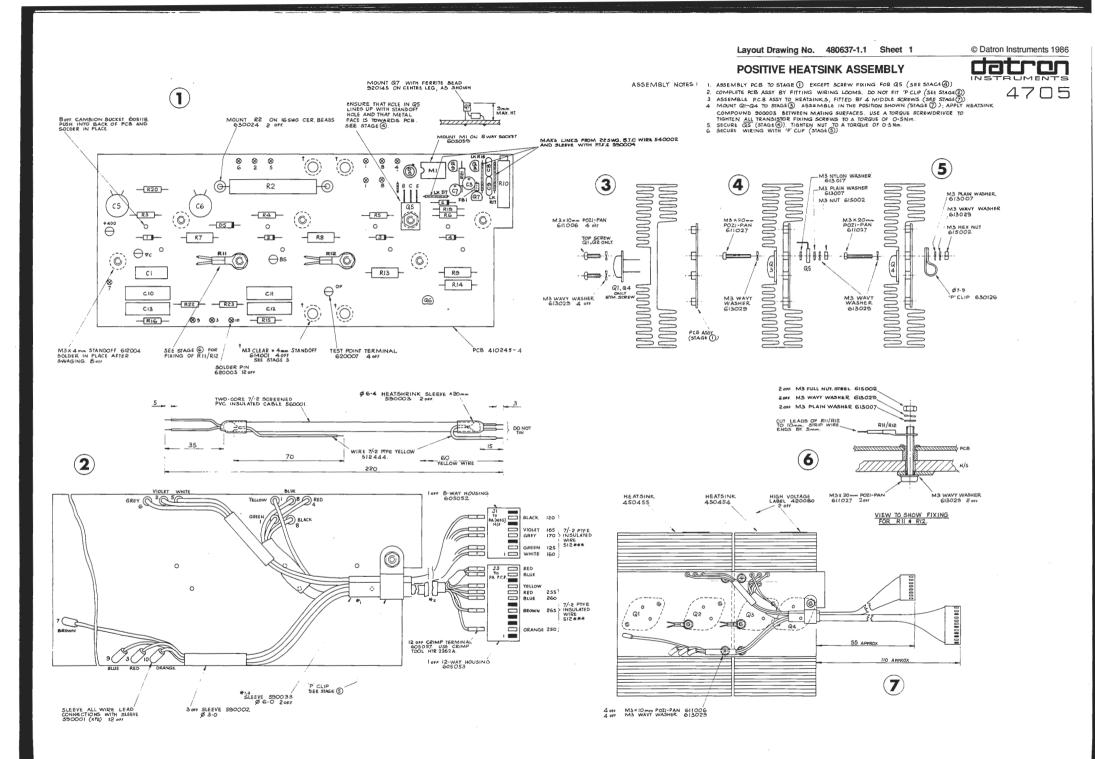




±38V POWER SUPPLY ASSEMBLY ±38V Power Supply with Mother Assembly Components



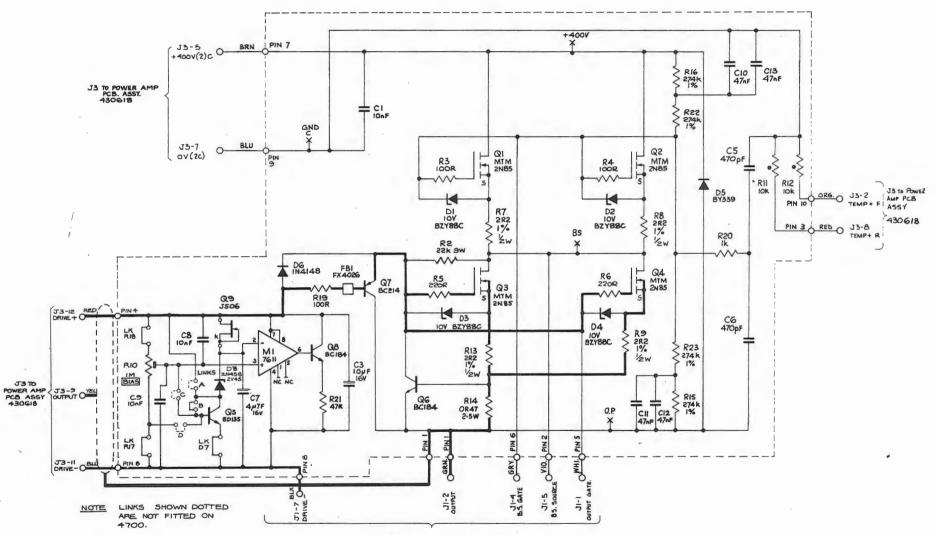
Circuit Diagram No. 430653-1.0 Sheet 1



THIRD ANGLE PROJECTION

NOTES

DRAWN IN ACCORDANCE WITH BS 308



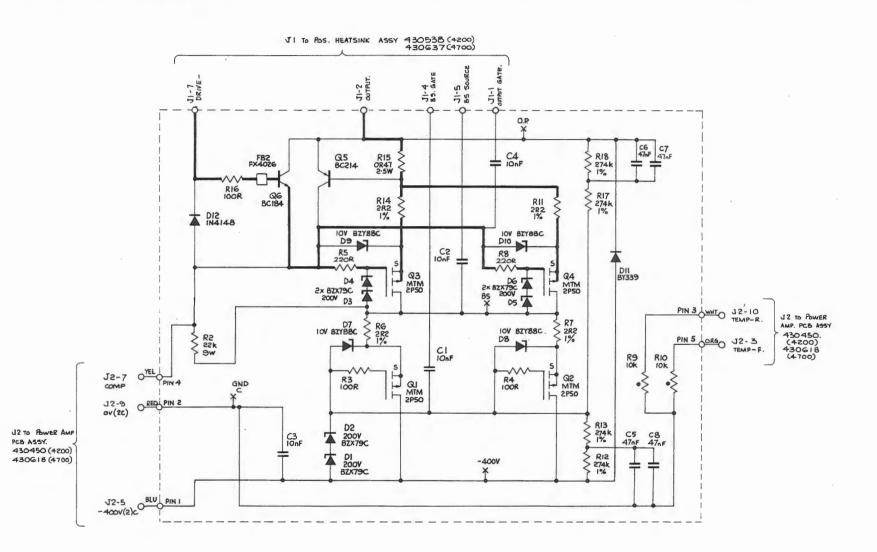
JI TO NEG. HEATSINK ASSY 430539

> **POSITIVE HEATSINK ASSEMBLY** Output Power Amplifier (Positive Half)



Circuit Diagram No. 430637-1.1 Sheet 1

THIRD ANGLE PROJECTION



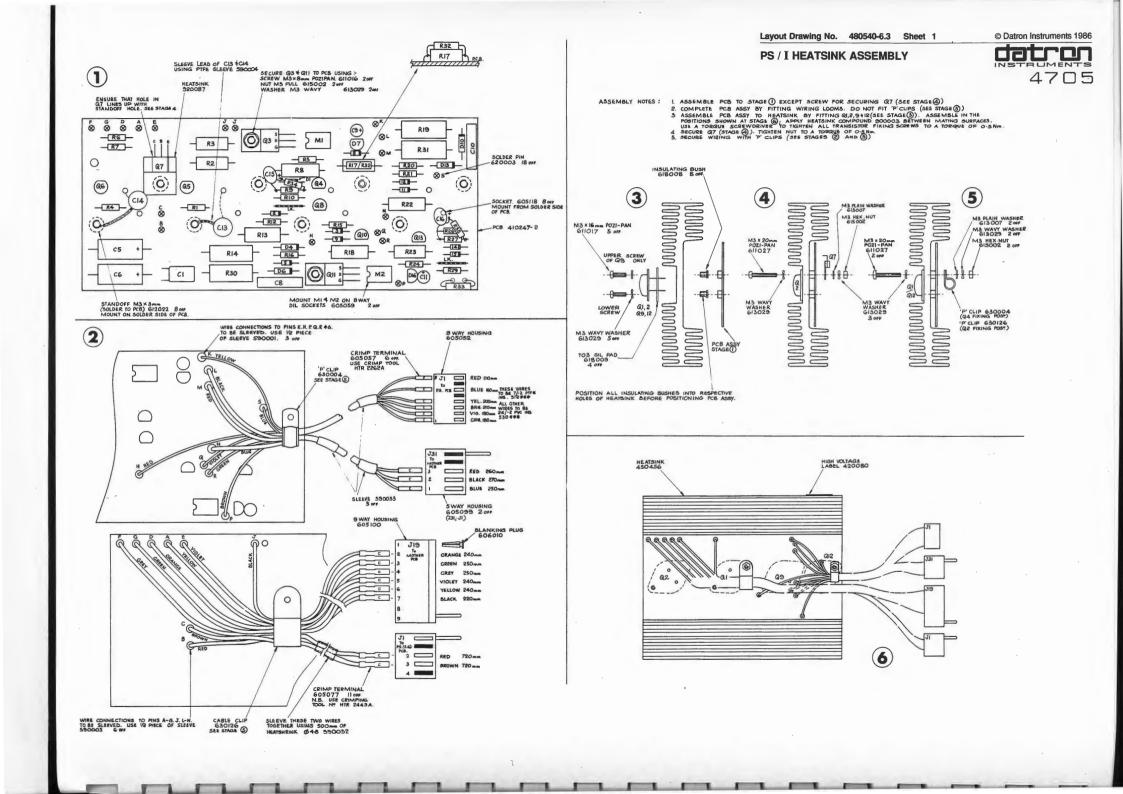
NEGATIVE HEATSINK ASSEMBLY Output Power Amplifier (Negative Half)

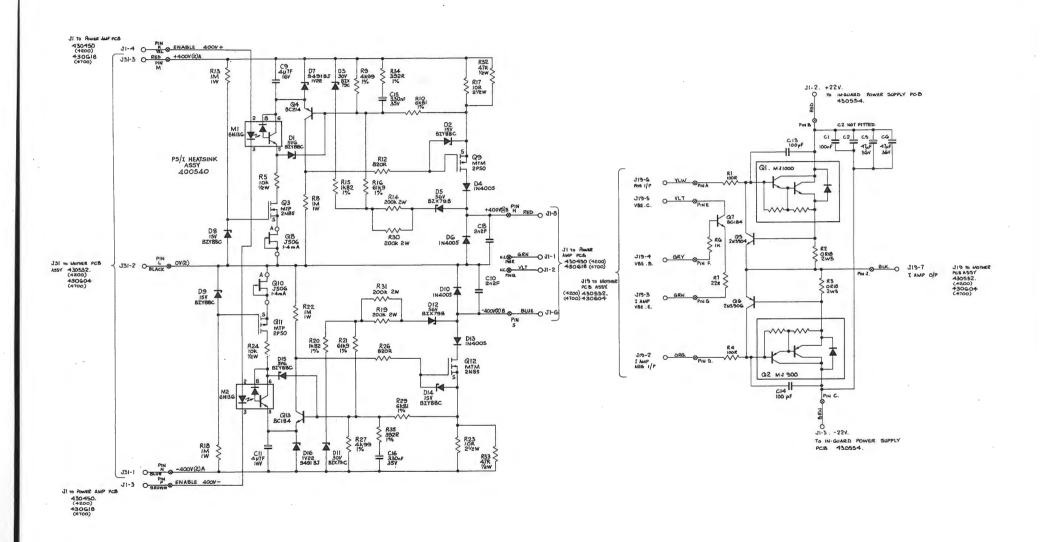


Circuit Diagram No. 430539-7.3 Sheet 1

NOTES

11.13-2





PS / I HEATSINK ASSEMBLY ±400V(2)B Regulator and Current Option Output Stage



Circuit Diagram No. 430540-6.0 Sheet 1

11.13-3

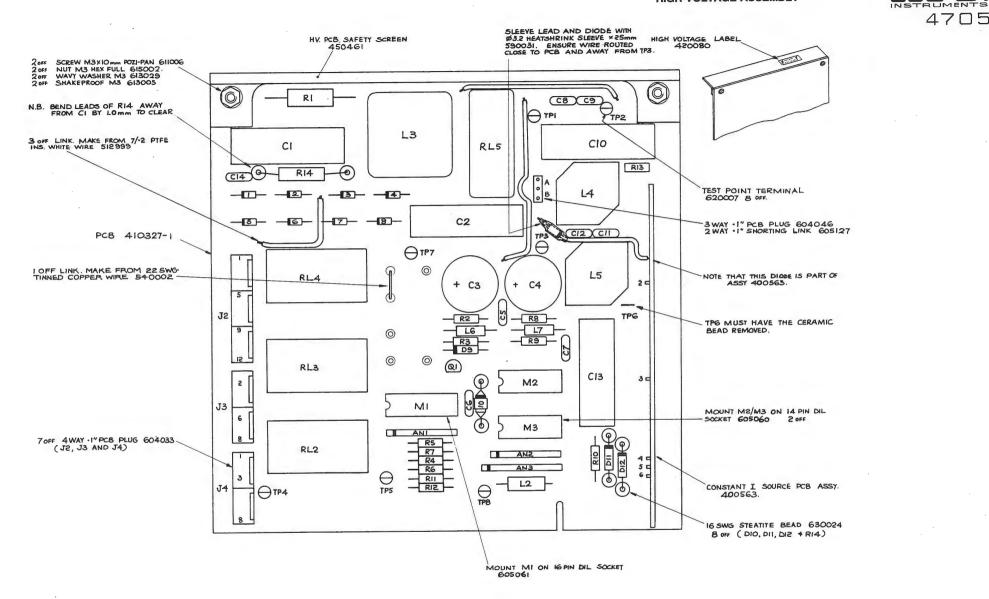
Layout Drawing No. 480537-1.3 Sheet 1

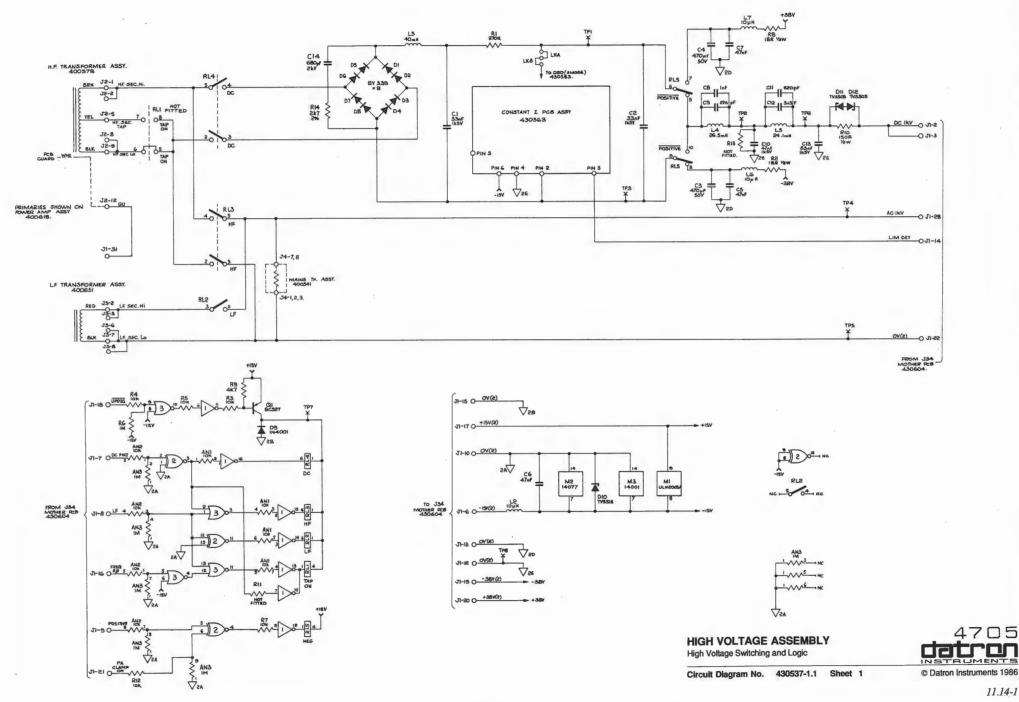
HIGH VOLTAGE ASSEMBLY

CET

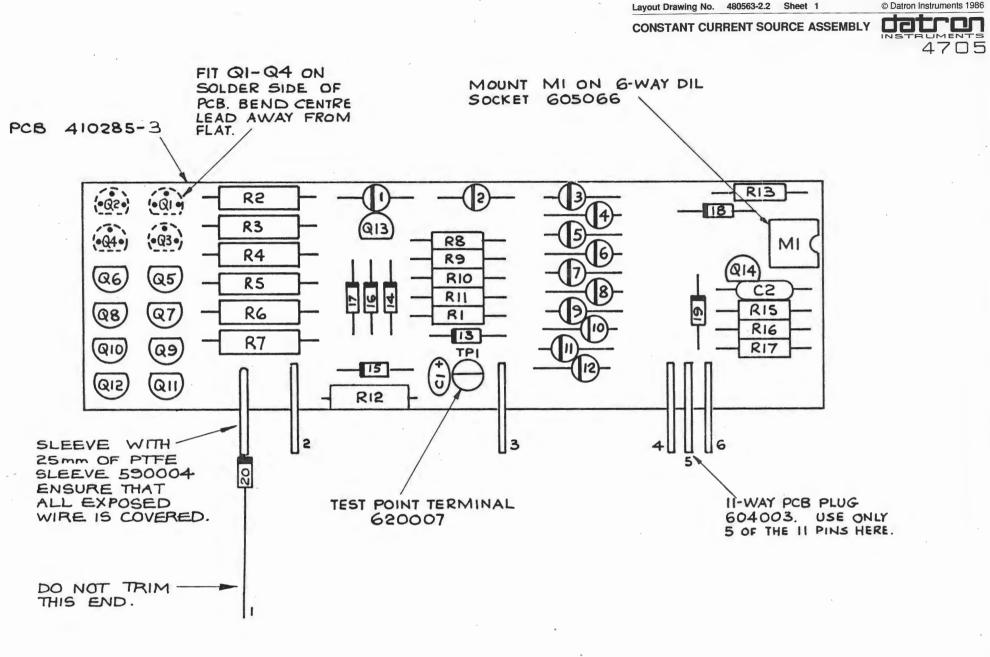
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4705

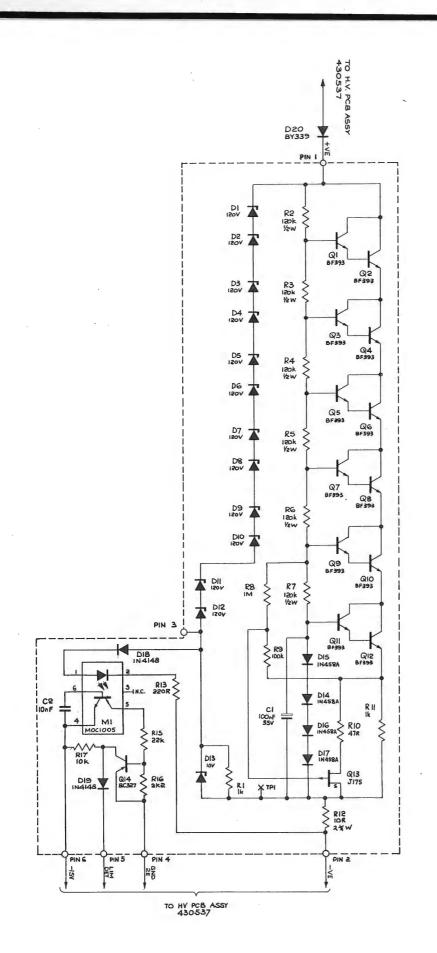




11.14-1



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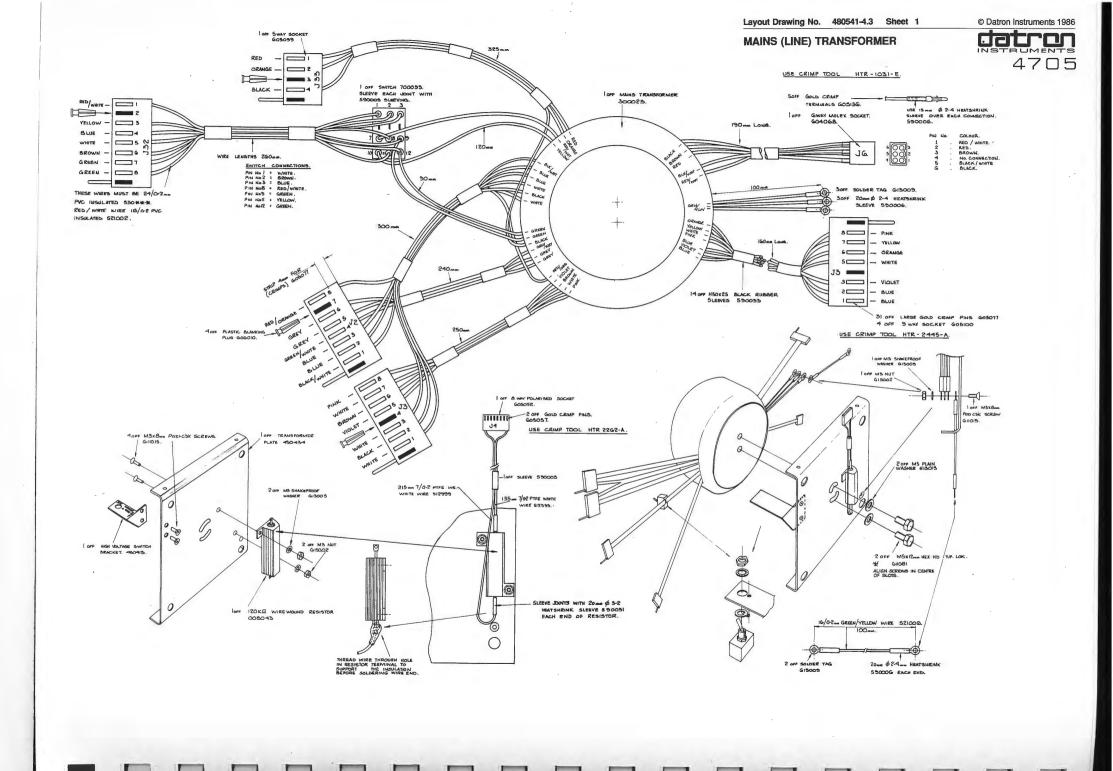


Circuit Diagram No. 430563-2.0 Sheet 1

CONSTANT CURRENT SOURCE ASSEMBLY High Voltage Rectifier Bleed Chain

© Datron Instruments 1986

11.14-2



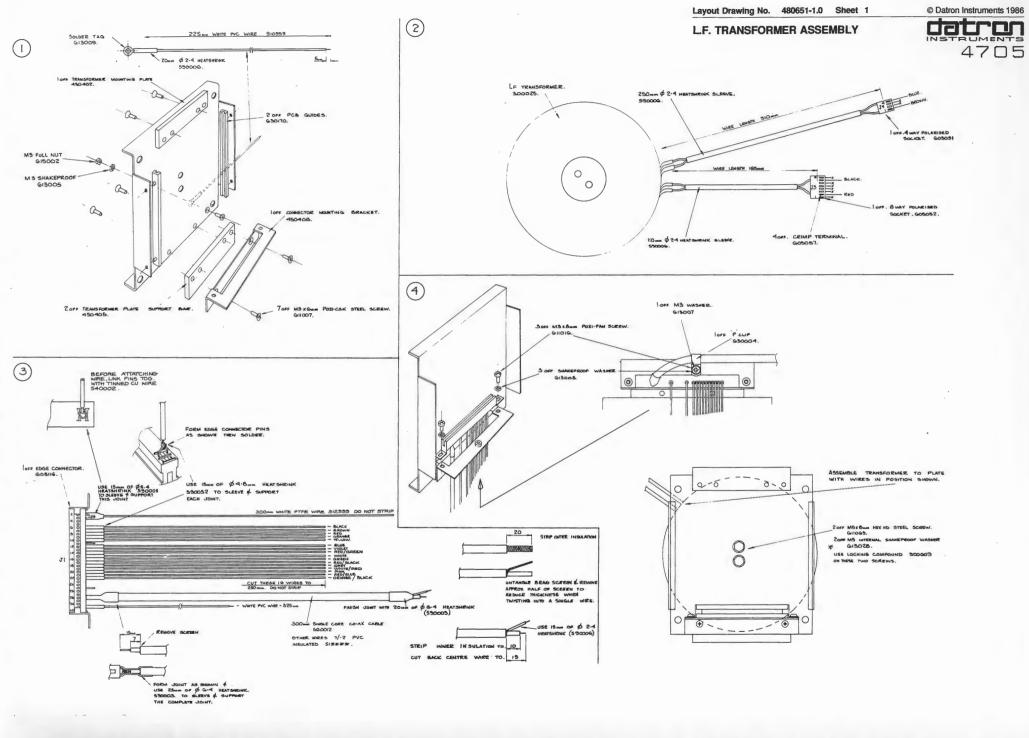
For mains (line) transformer circuits refer to the following pages:

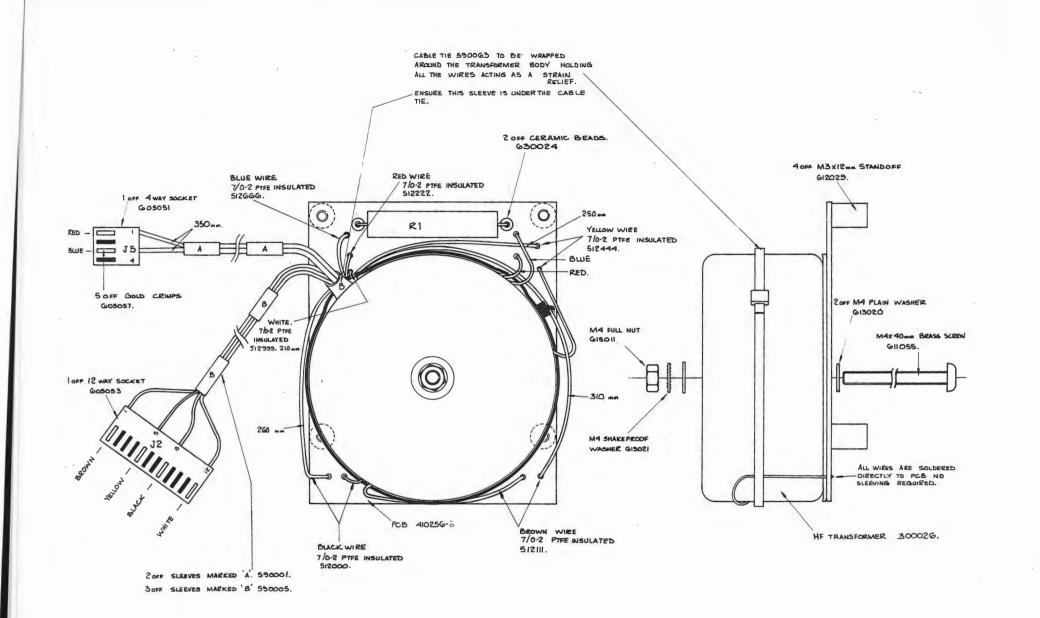
11.10-1	Main Digital Supply, Display Supply and Common Mode Null
11.11-1	Common-2 Supplies and Current Option Supply
11.11-2	Reference Divider Common-4 and 8V Common-2 Supplies
11.16-5	400V Power Supply, 38V Power Supply and Common Mode Null
11.17-2	Interconnections, Power Input Module and Mains Transformer Primary

TRANSFORMER CIRCUIT DIAGRAMS



11.15-1





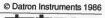
H.F. TRANSFORMER ASSEMBLY



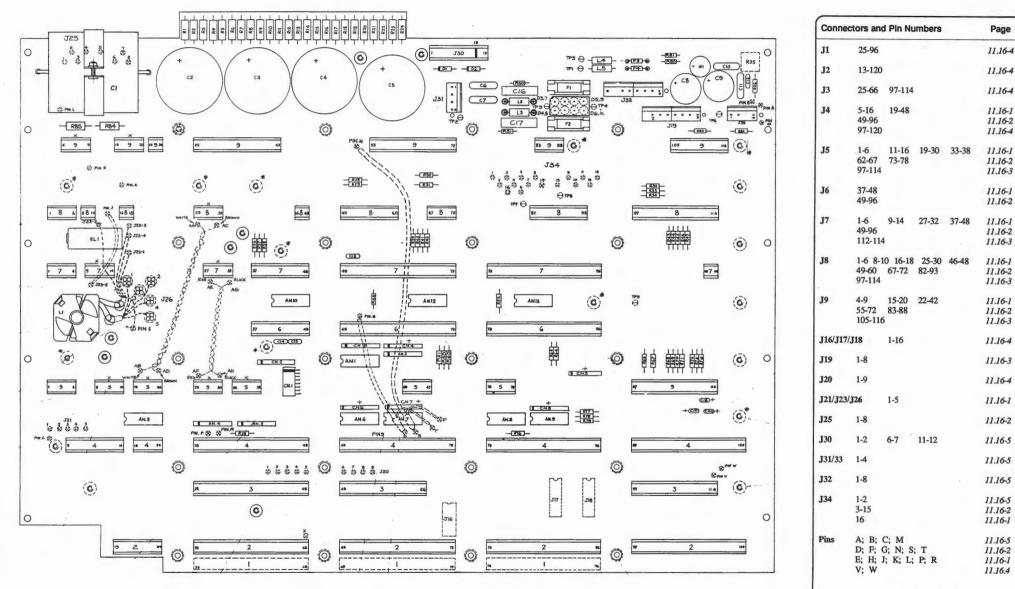
Layout Drawing No. 480578-4.1 Sheet 1

Layout Drawing No. 480604-1.3 Sheet 1

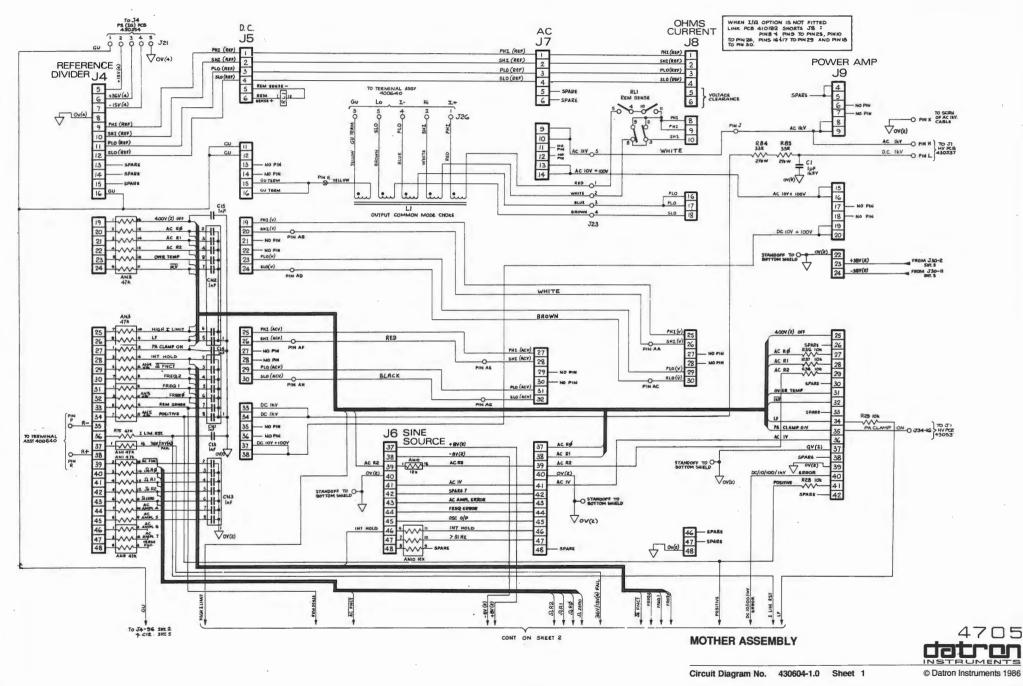
MOTHER ASSEMBLY

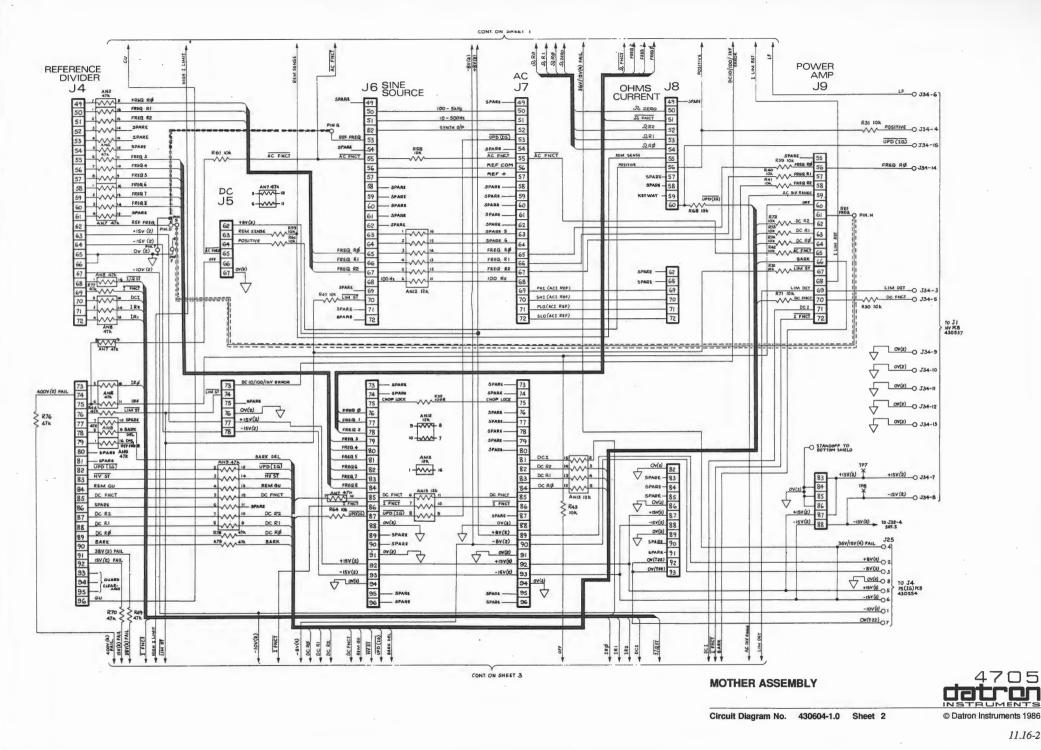


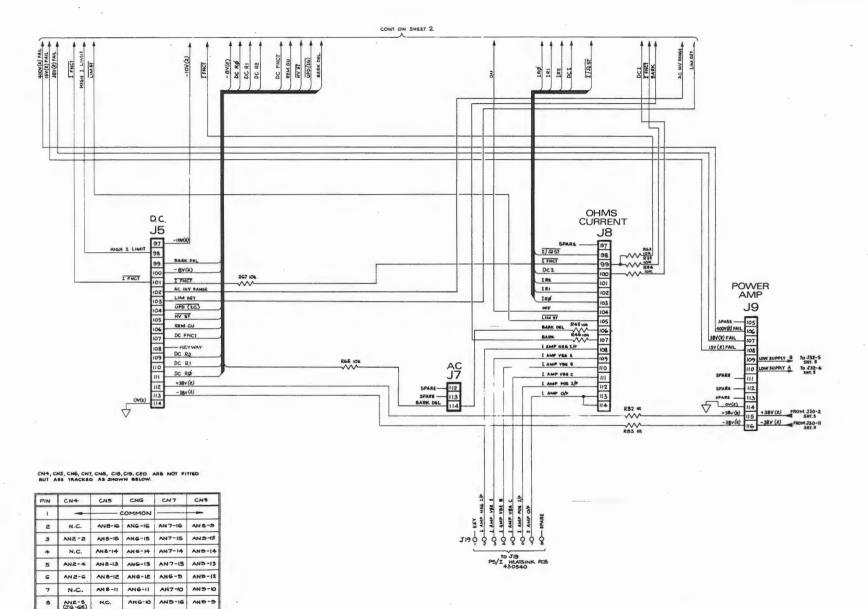




MOTHER ASSEMBLY EDGE CONNECTOR PIN INDEX





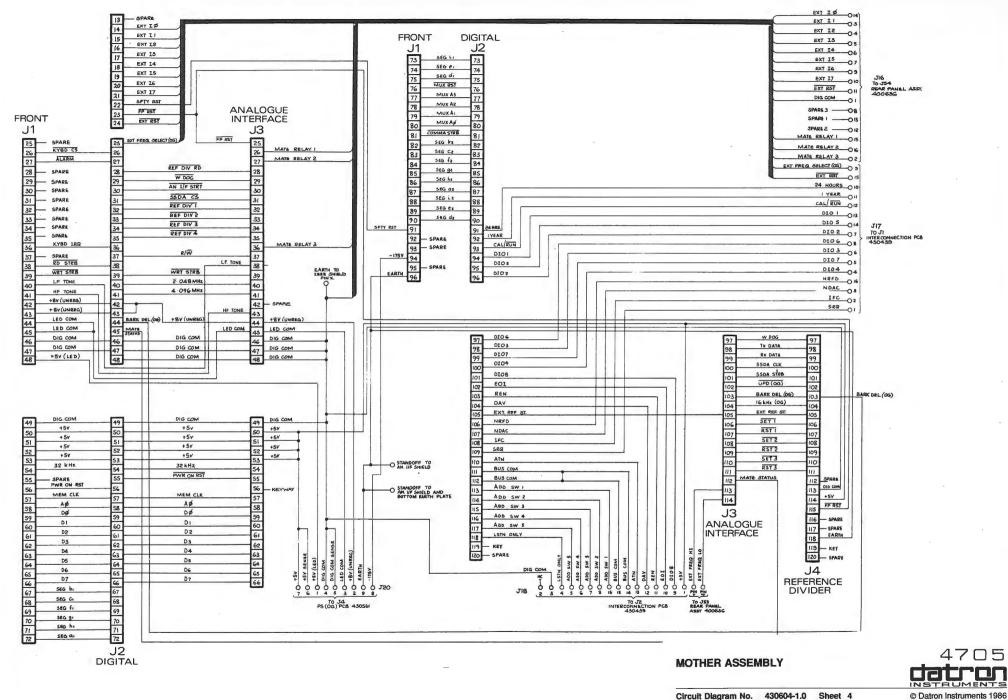


C18 - R77 C19 - R78 C20 - R79

MOTHER ASSEMBLY

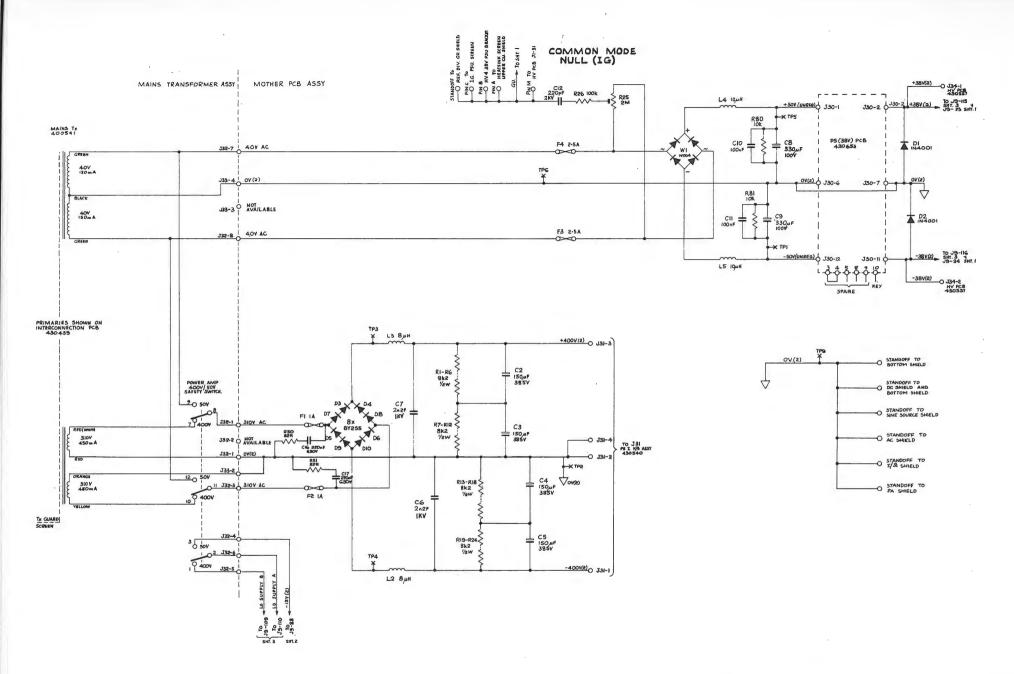


Circuit Diagram No. 430604-1.0 Sheet 3



Circuit Diagram No. 430604-1.0 Sheet 4

11.16-4

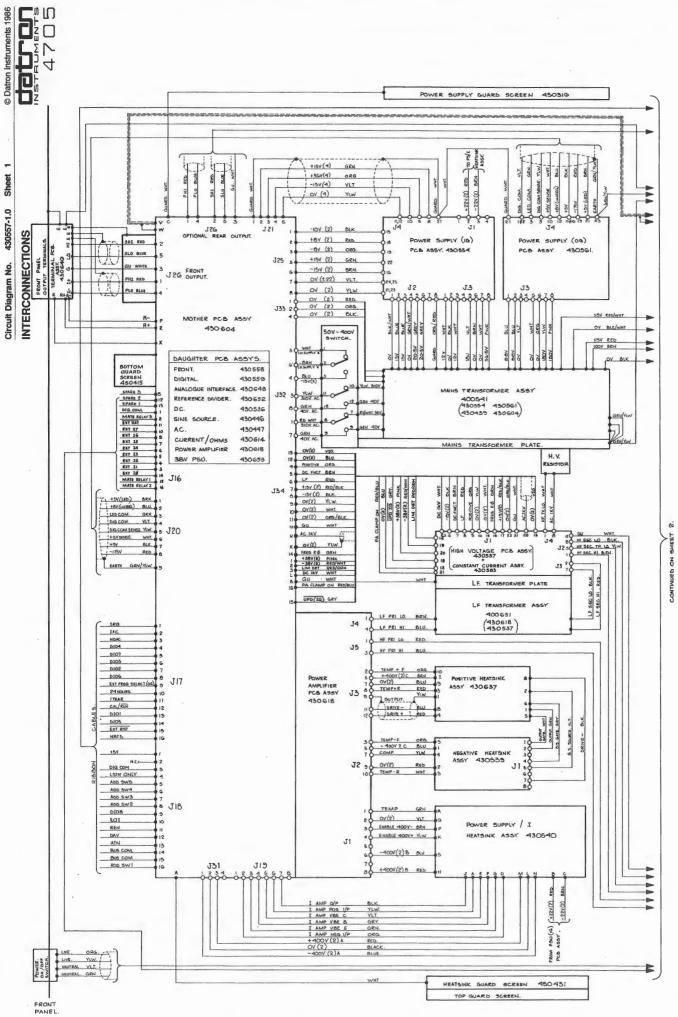


MOTHER ASSEMBLY



Circuit Diagram No. 430604-1.0 Sheet 5

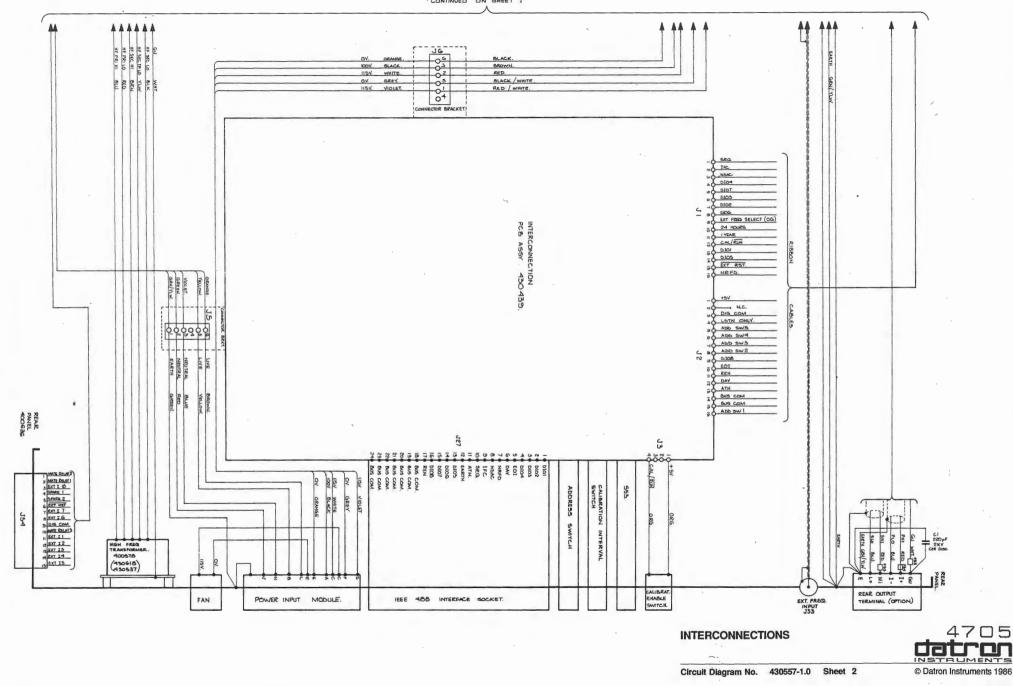
11.16-5



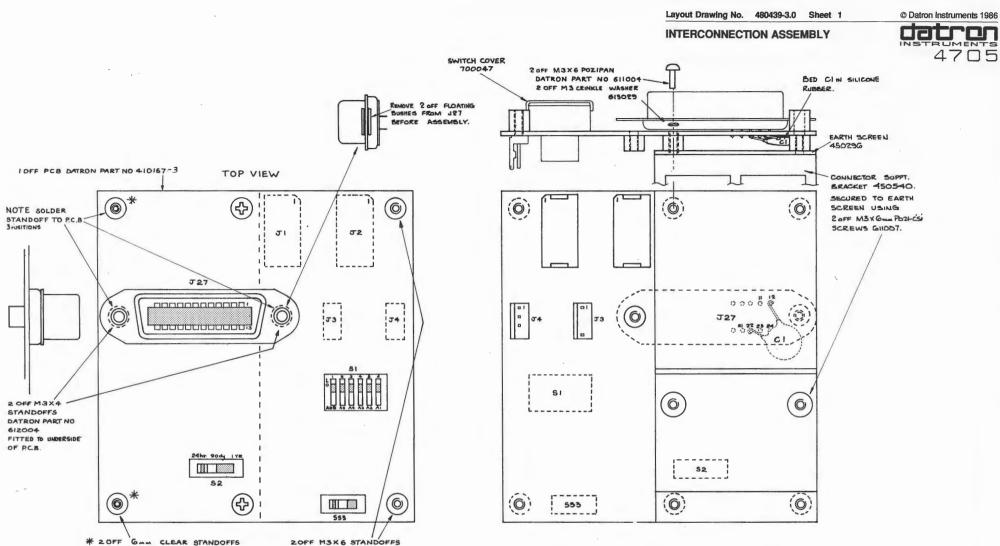
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a____

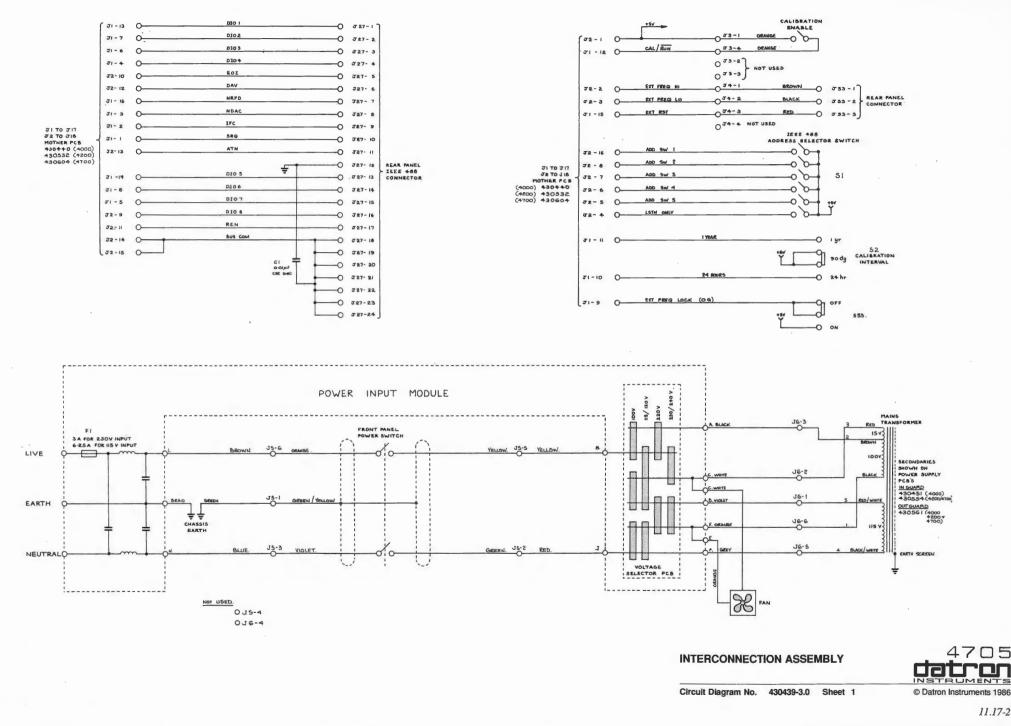


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20FF M3X6 STANDOFFS DATRON PART NO 612008

DATRON PART NO 614003

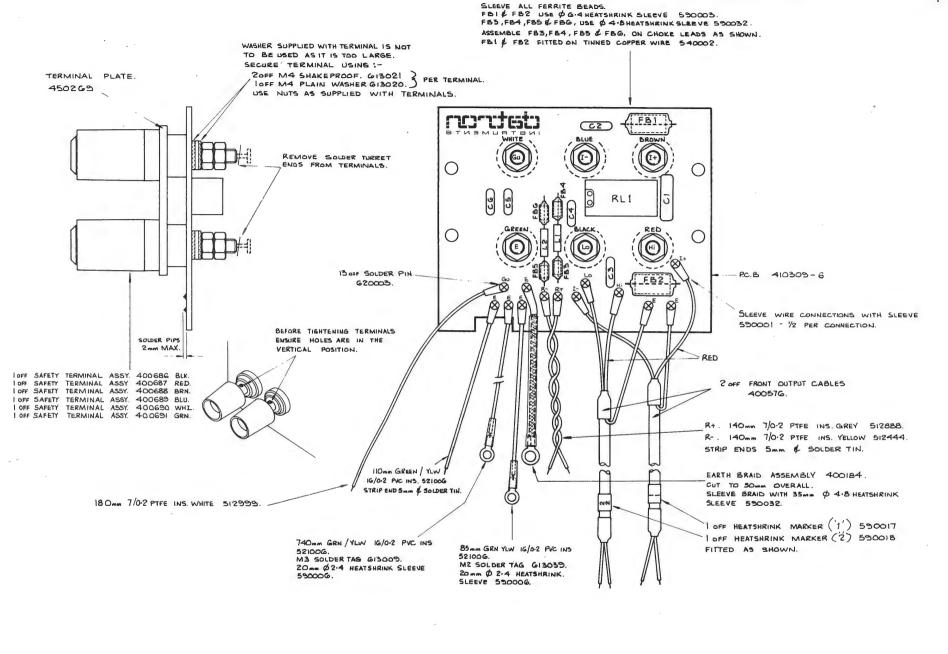


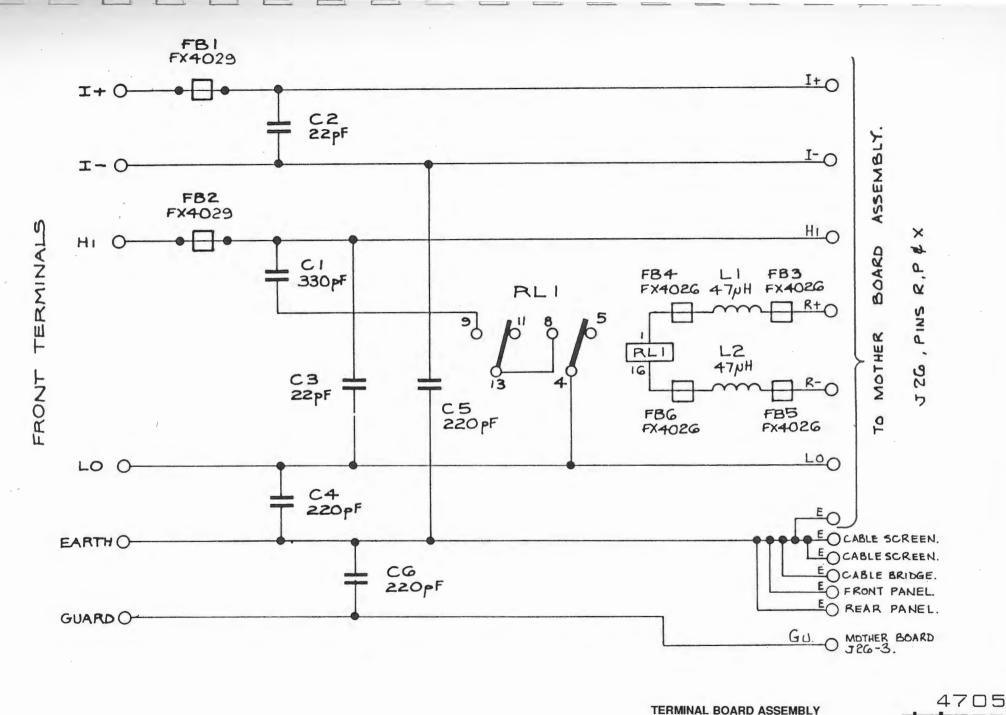
^{11.17-2}

пг

TERMINAL BOARD ASSEMBLY



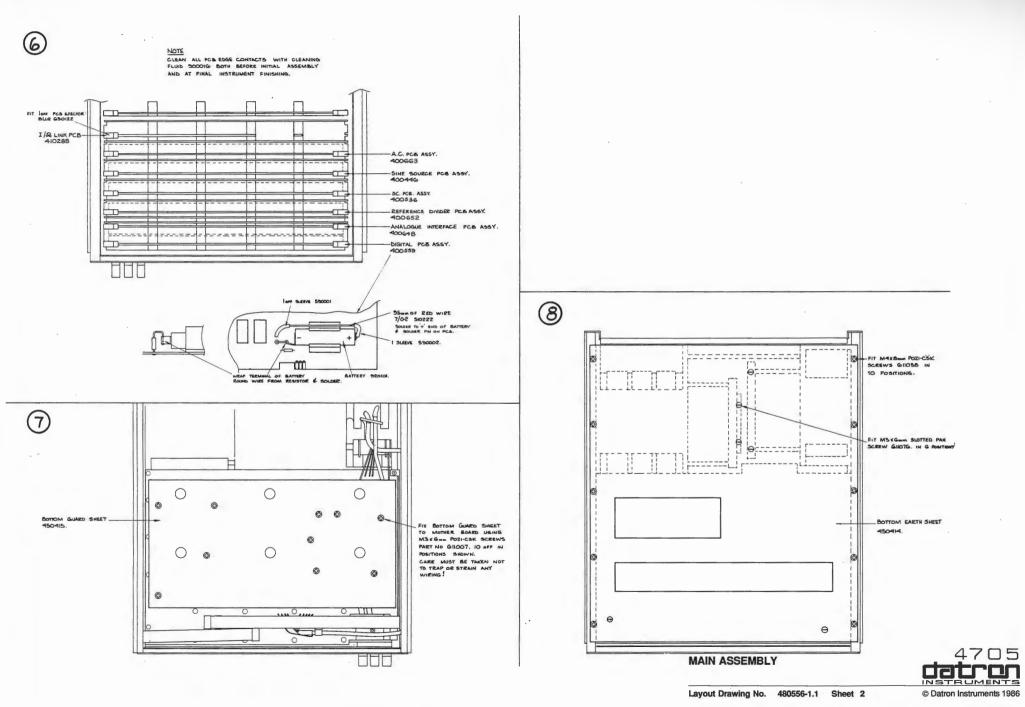




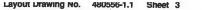
ENMINAL BOARD ASSEMBLT



Circuit Diagram No. 430640-1.0 Sheet 1



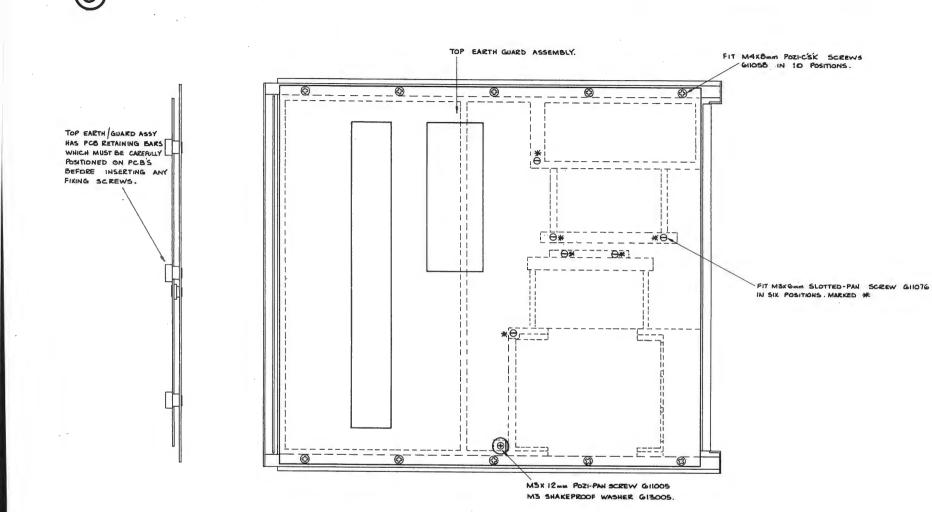
11.18-1

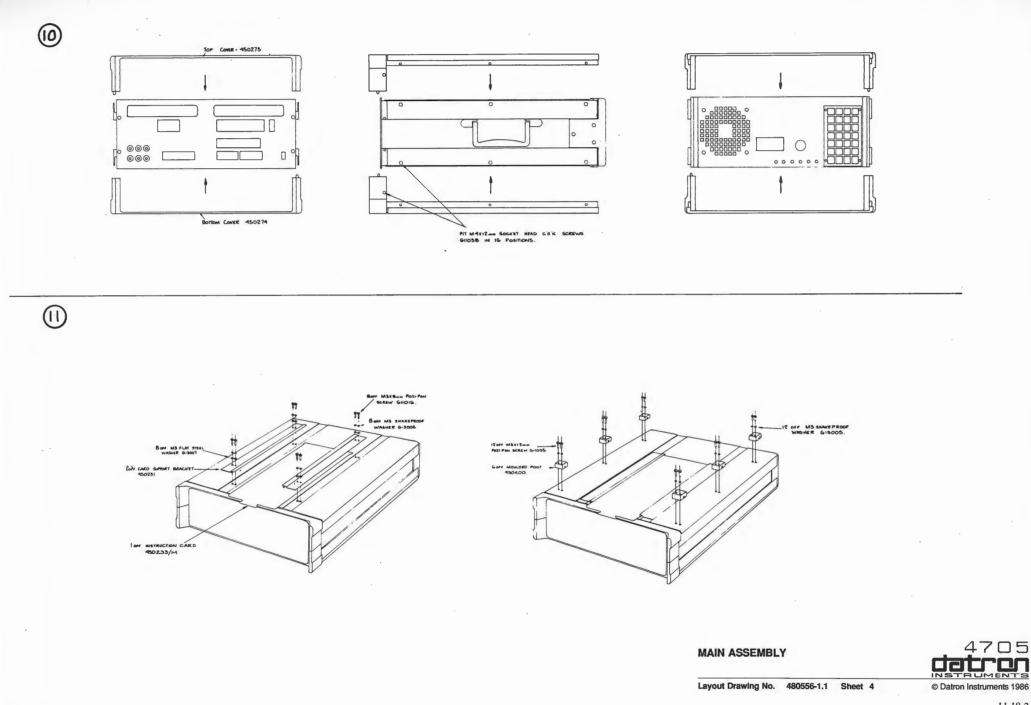


MAIN ASSEMBLY

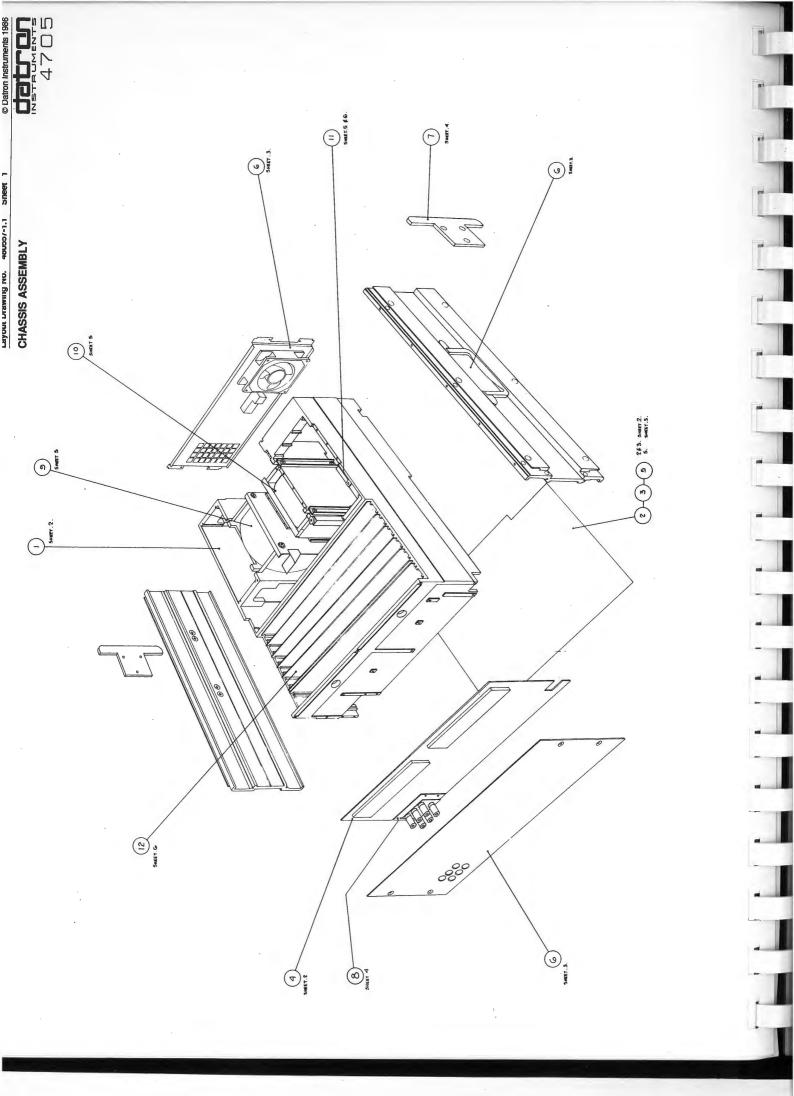


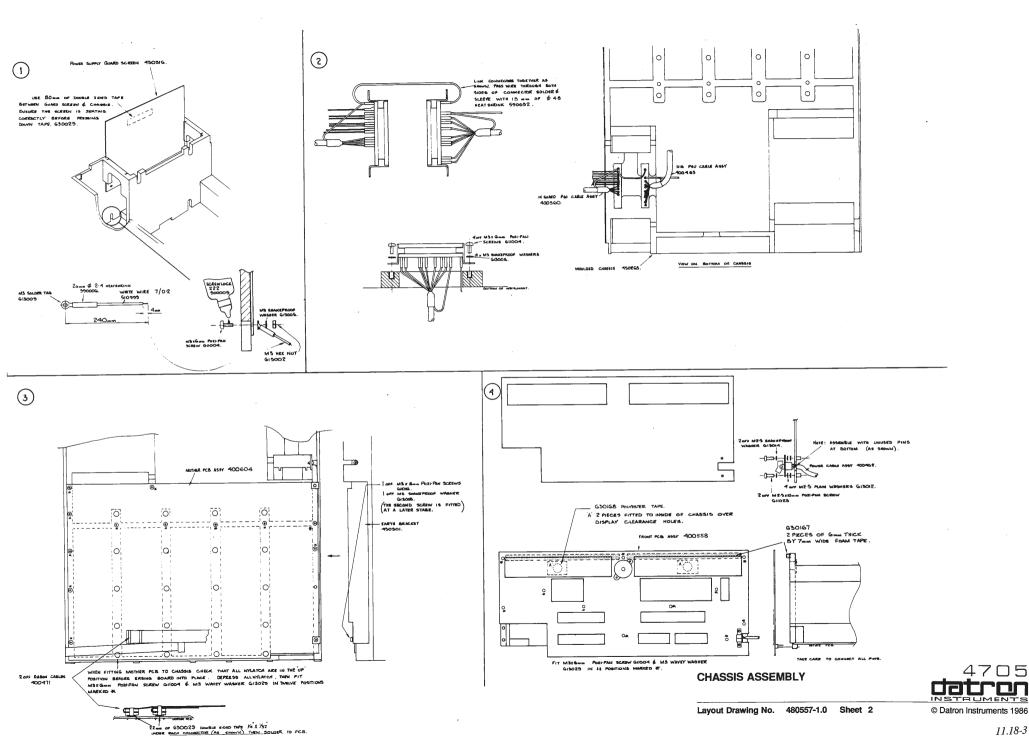


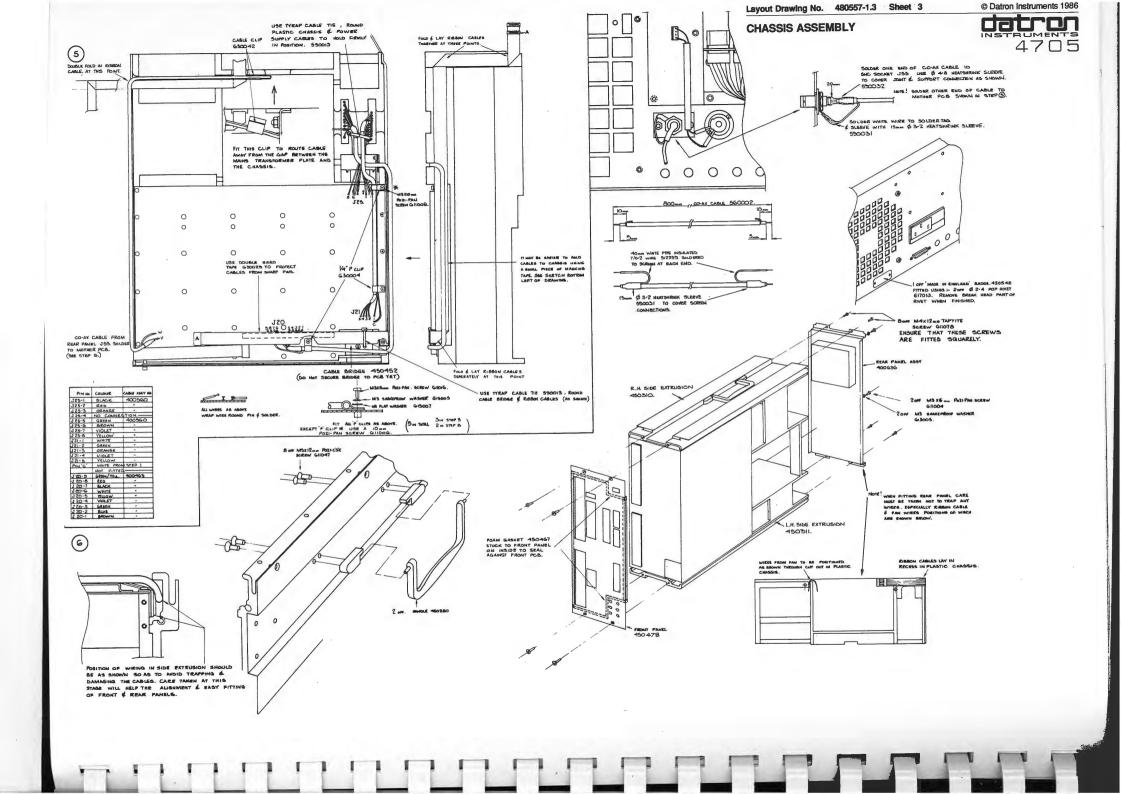


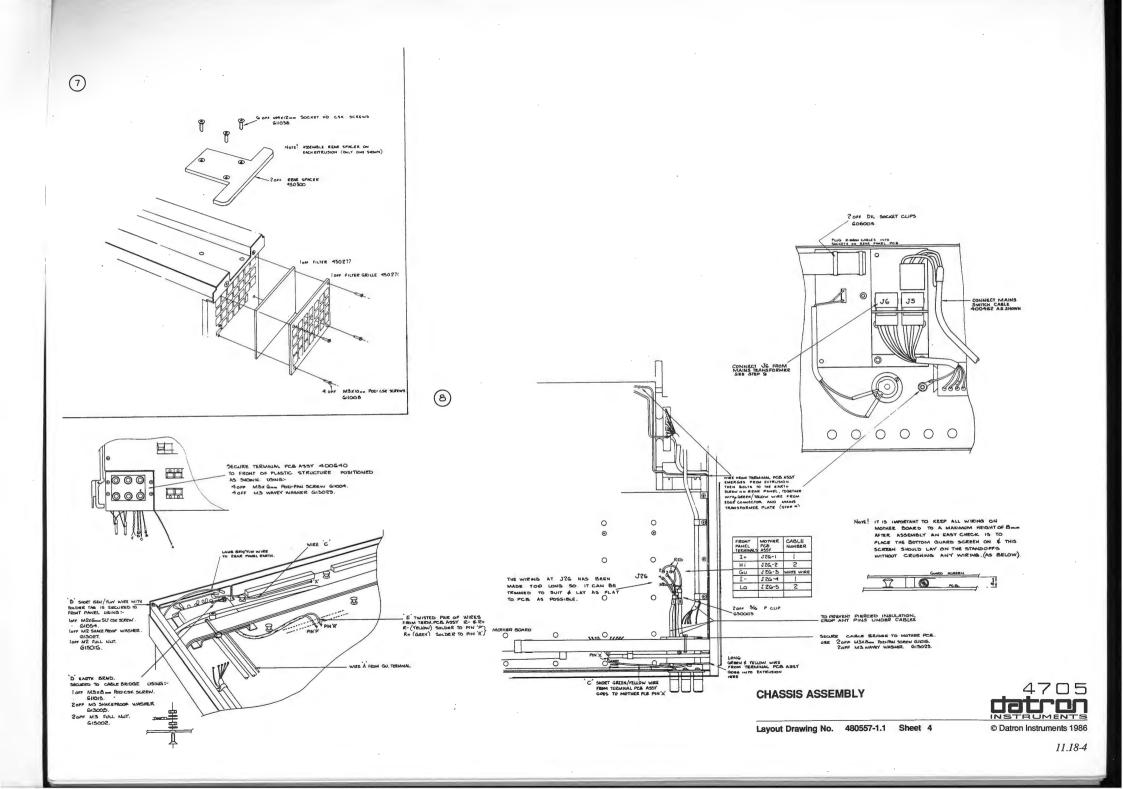


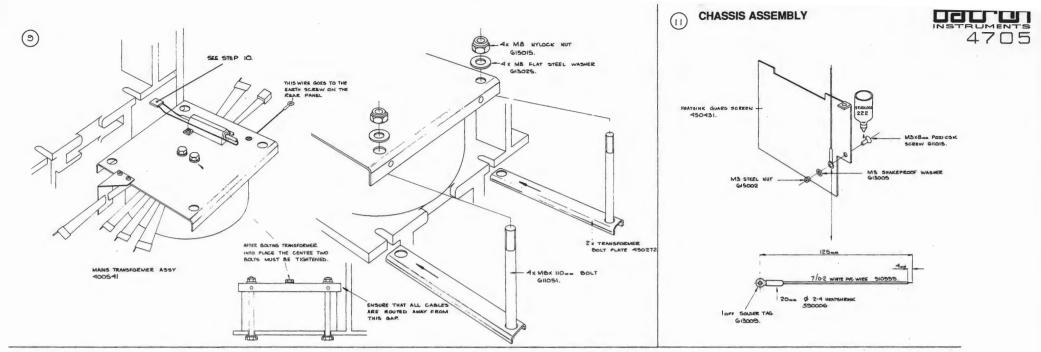
11.18-2

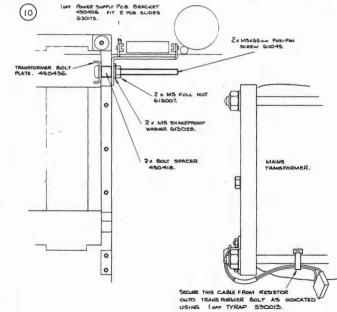


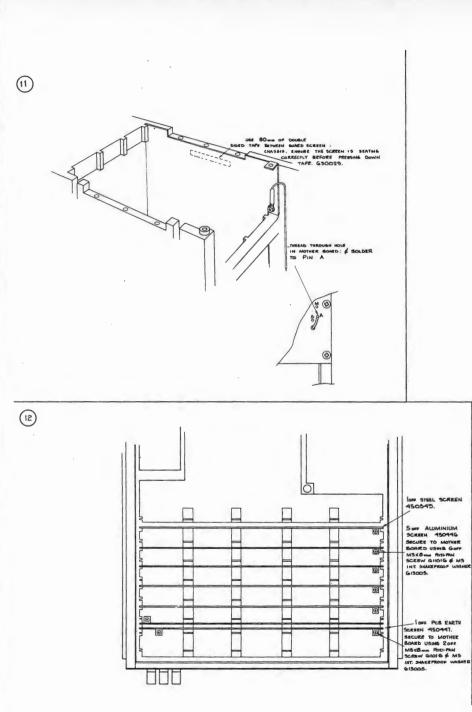










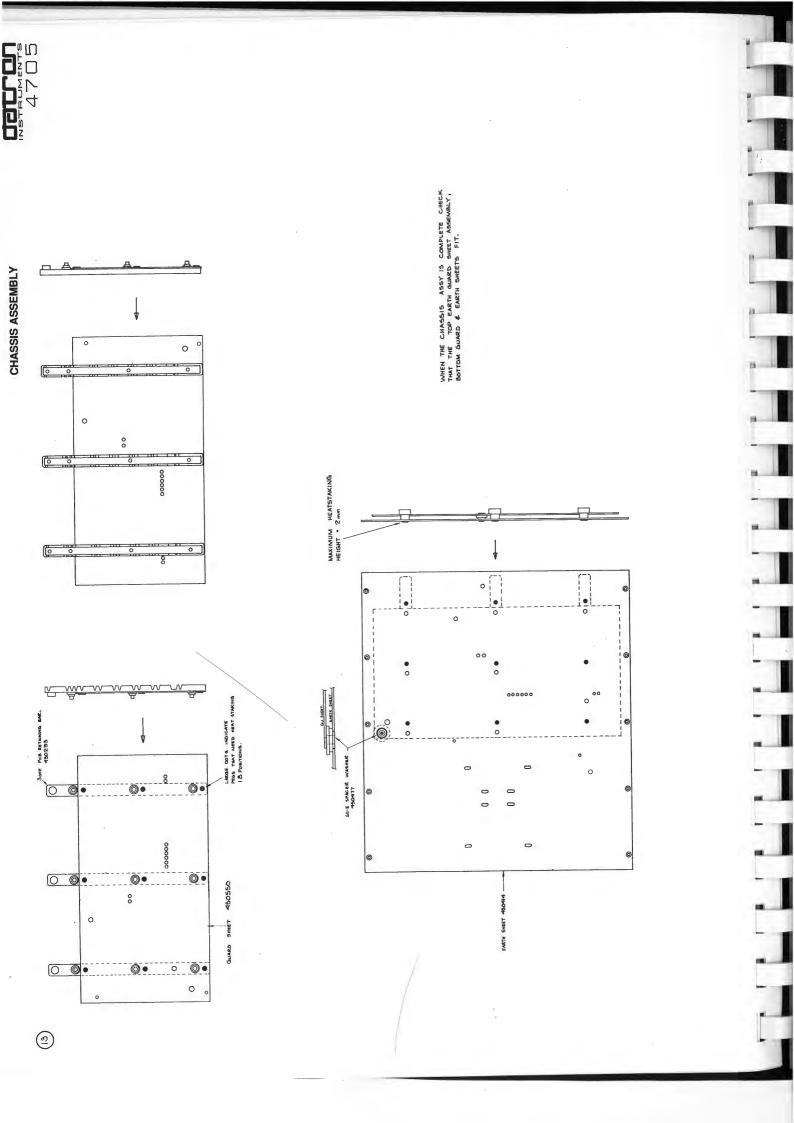


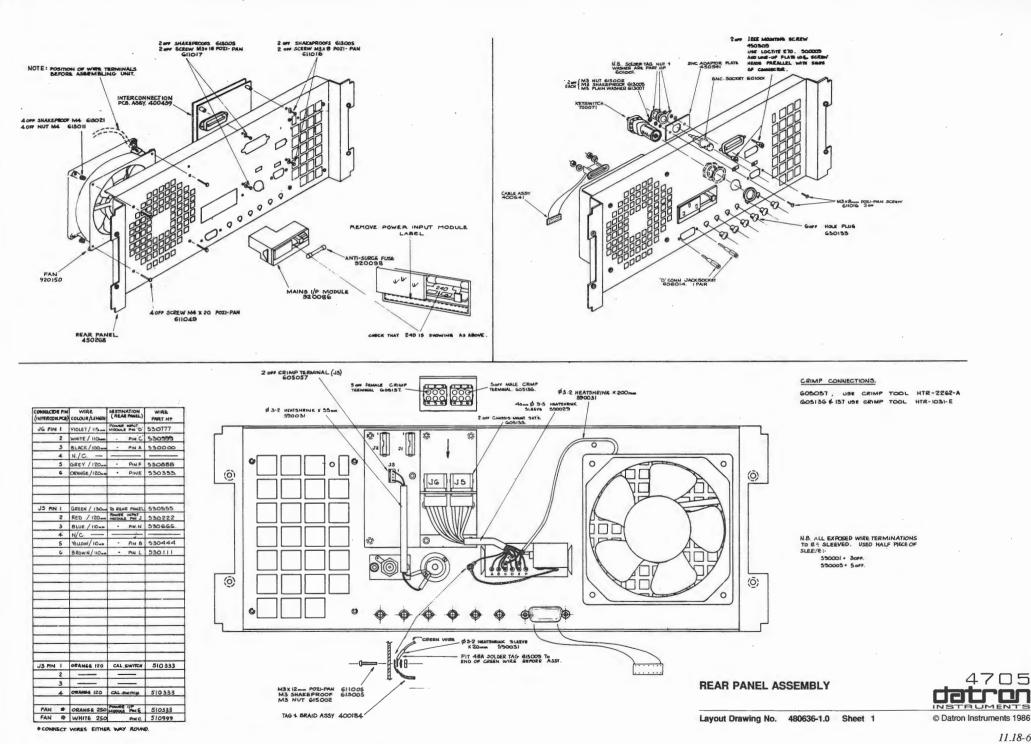
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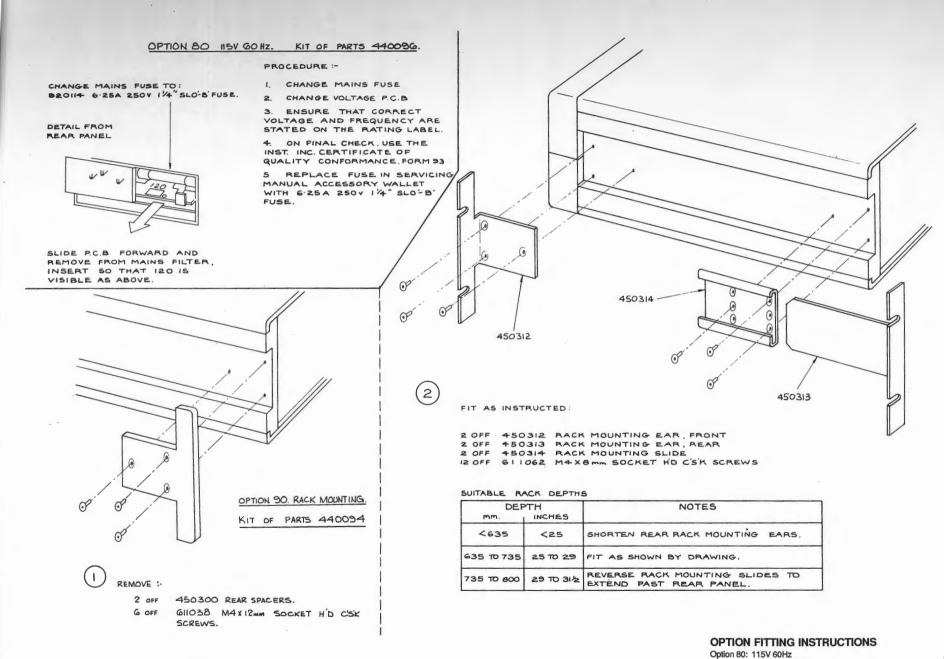
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Layout Drawing No. 480557-1.1 Sheet 6



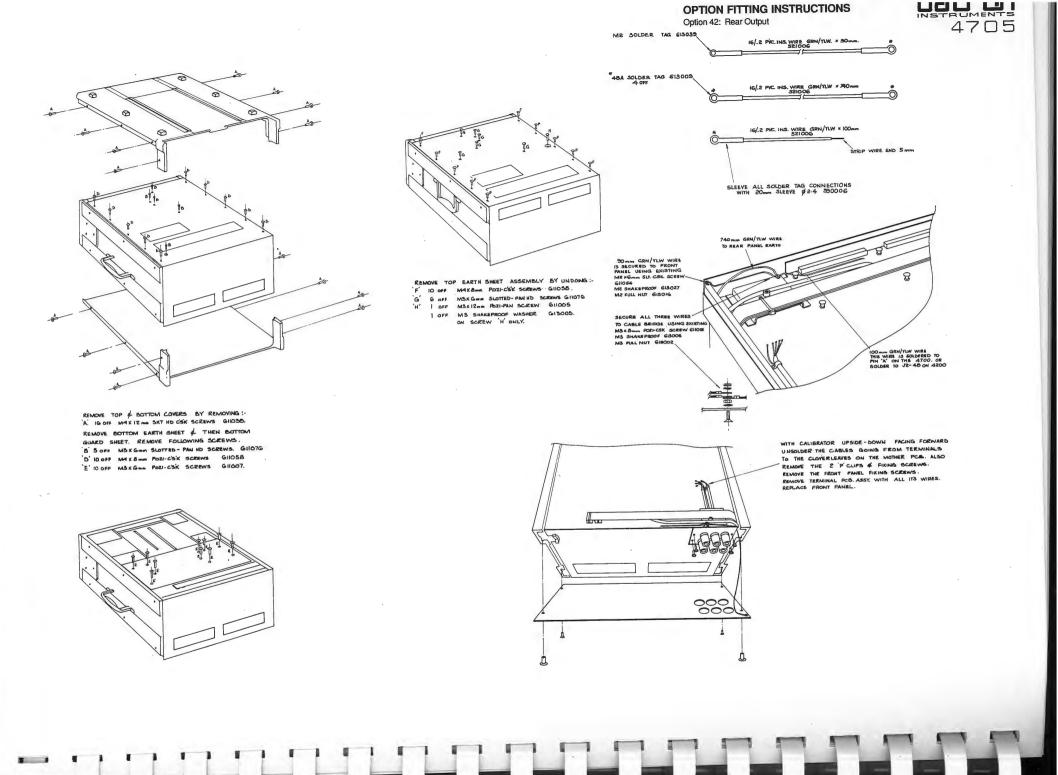


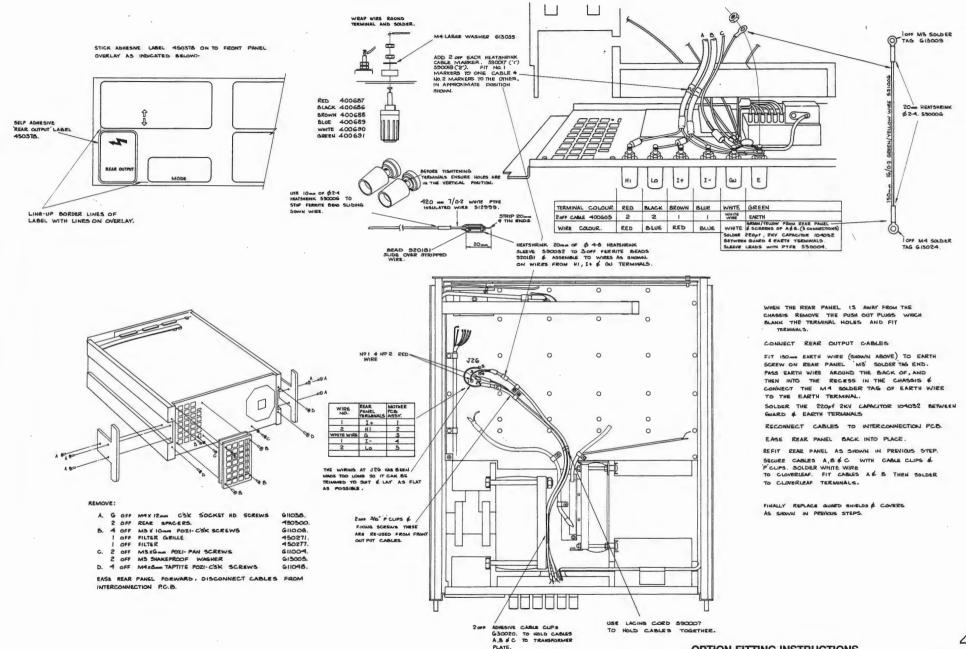


Layout Drawing No. 480603-3.2 Sheet 2

Option 90: Rack Mounting

11.19-1

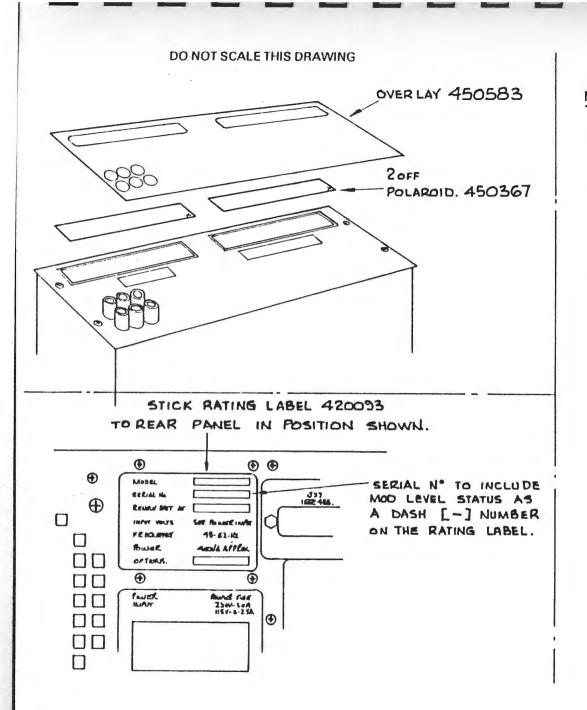




OPTION FITTING INSTRUCTIONS Option 42: Rear Output



Layout Drawing No. 480603-3.4 Sheet 4



ALL BURRS TO BE REMOVED

NOTES.

- PROGRAMMED E PROMS M18 No 290151 M19 " 290152 M20 " 290153 M21 " 290154 TO BE FITTED TO DIGITAL PCB ASSY. SEE DRAWING 480559.
- 2/ FIT INTO CAL & SERV. HANDBOOK:loff 920098 3A 14" ANTISURGE FUSE loff 630109 2.5mm A/F HEX KEY. 20FF CALSWITCH KEYS (FROM REAR PANEL ASSEMBLY).
- 3/ FITTING INSTRUCTIONS FOR CURRENT/OHMS & HIGH VOLTAGE ARE SHOWN ON DRAWING No. 480603.

INSTRUMENT ASSEMBLY

Layout Drawing No. 480716-1.0 Sheet 1

SECTION 12 4705 COMPONENT LISTS

Front Assembly	400558
Digital Assembly	400559
Analog Interface Assembly	400648
Reference Divider Assembly	400652
Reference Assembly	400452
DC Assembly	400536
Sine Source Assembly	400446
AC Assembly	400663
Current / Ohms Assembly	400614
Power Amplifier Assembly	400618
Out-guard Power Supply Assembly	400561
In-guard Power Supply Assembly	400554
±38V Power Supply Assembly	400653
Power Amplifier Positive Heatsink Assembly	400637
Power Amplifier Negative Heatsink Assembly	400539
Power Supply / Current Heatsink Assembly	400540
High Voltage Assembly	400537
Constant Current Source Assembly	400563
Mains (Line) Transformer Assembly	400541
L.F. Transformer Assembly	400651
H.F. Transformer Assembly	400578
Mother Assembly	400604
Interconnection Assembly	400439
Terminal Board Assembly	400640
Main Assembly	400556
Chassis Assembly	400557
Option Fitting Instructions	400603
Rear Panel Assembly	400636
4705 Instrument Assembly	400716

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COMPONENT	480558	1	0.1									 						_																								
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SCHEMATIC	430558	2	0.1																																							
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FUNCTIONAL TEST PROC.	460558/FT	1-3	0.1	_			_		L			_		_	_									_			_		-		_	_	_	_		1	_			_	_	
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DESIGNATOR	DATRON PART No.	DESCRIP	TION			PRINCIPAL MANUFACTURER		MANUFACT	URERS	No. USED Por Assy.
RI	000334	- 330k	5%	1/4 W	CARBON	MULLARD		CR25		22
<u>k</u> z	000334	"	-		*					-
R3	000334		41		4	**				
R4	000334	н		4		e ,				-
RS	000334	•	*	•	4	•		•• ·		-
Re	000334	"		•	*			• ~		-
R7	000334				4					-
88	000334		н	•	4	w		*		- 1
R9	000334			4				•	•	-
Rю	000334	. "	4	L.	•	4				-
211	000354	,		*	4			•		-
R12	000334			•	4	N .		•		
RI3	000334		4	•	4	N				
RI4	000334	•	4		*			•		-
Ris	000334		н		•			•		-
R16	000334	•		٠		"		•		-
R17	000334	4			N	4	,	-		-
28	000334	N			ب .			-		-
Rŋ	000334		4	N	•	v 7				-
R20	000334			۰,	•	•				-
221	000334		-		ħ					-
222	000334	4		•	•	*		•		-
R23	000102	lk			4	4			······································	11
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ESIGNATOR	DATRON PART No.	DESCRIPTI	ON		PRINCIPAL MANUFACTURER		MANUFACT PART No.	URER'S	No. USED Per Assy.
24	000102	1K 5%	1/3W	CARBON	MULLARD		CR25		-
225	000102	lk "	н		. H	· .	"		— ·
226	000104	100k*	н		н		N		4
27	000102	lk "	н		н				-
228	000102	lk "		u	, iii		"		-
29	000102	lk "		•	-		"		-
30	000102	lk "	н	N	•				
31	000102	1k "	н	м.					-
32	000102	k "	"	4	H .		-		
R33	000102	1k "	.,	ù					-
254	000102	lk "		4	**				-
R35	000103	lok "	"	м	•,		.,		5
236	000103	10k "	4				-		-
237	000103	104 "	4		"				
R.58	000103	10k "	и	n	"		11		-
239	000472	4k7 •	, i	н			N		6
R40	000680	68R "	4	4	-		~		8
R4i	000680	68R *		н.'			-	-	
242	000680	68R "	٩	H	"				-
1243	000272	2k7 •	••	*			-		18
R44	000272	2k7 •		ч	· · ·		-		-
R45	000472	4k7 •	w	· H					-
R46	000272	2k7 "		•	n				-
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FESIGNATOR	DATRON PART No.	DESCR	PTION			PRINCIPAL MANUFACTURER	۰.	MANUFACT	URER'S ·	No. USED Per Assy.
R47	000182	IK8	5%	1/3W	CARBON	MULLARD		CR25		2
R48	000272	2k7		"	14	.,				-
R49	000272	2k7	н	11		·			-	. –
Rso	000222	2k2		4	"		1.1			2
RSI	000222	2k2	н		"	-1				-
Rs2	000272	2k7	-11	ä	ч	14	,	γ.		
Rs3	000272	2k7		.,	•	ч				-
Rs4	000472	4k7	4		i a	u 1		-		~ '
Rss	000272	2k7	ч.		"	14				—
Rs6	000272	2k7		н		H .		•		. .
RS7	000272	2k7	4	••	"	-		-		-
RS8	000182	lk s	н		••	4				-
R59	000272	2K7	••		4	-		-		-
R60	000272	2k7	**			-				
RGI	000272	2k7		"	۰,	ч		•		-
R62	000 272	2K7	۰,		N					-
R63	000272	2k7	*		"			~		· · _
R64-	000272	2K7			W	-		-	5	-
R65	000272	2k7	ч	"	н	*		-		· -
R66	000272	2k7	14			•		4		—
R67 .	000680	68R	N	4	•			-		
R68	000680	68 R	4	"	•	-		-		
R69	000680	68R	.4	4	44	.,		-		
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
R70	000680	68R 5% 'SW CARBON	MULLARD	CR25	
R71	000 680	68R " " "			-
R72	000563	56k " " "		ł/	1
R73, R74, R75	000472	4k7 " " "	4		
R76	000103	lok " " "			
R77, R78, R79	000104	100k " " "	11	**	
ANI. AN2	090017	100k × 7 2% NETWORK	BECKMAN	108-1- R100k	2
AN3. AN4	090041	447 × 7 2% NETWORK	BECKMAN	L08-1- R4k7	2
ANS. ANG	090121	IOOK × 8 2% NETWORK	BECKMAN	Log-I- Riook	2
C1	150002	F 20% IGV DIP TANT	UNION CARBIDE	KIOEIG	2
C2	104026	47nF -20 % 50V CER DISC	SIEMENS	B37449	3
C3	104026	47 .F -20 % 50V CER DISC	SIEMENS	B37449	-
C4	150001	22 UF 20% IGV DIP TANT	UNION CARBIDE	K22E16	1
Cs	104026	47nF -20 % 50V CER DISC	SIEMENS	B37449	-
C6		NOT USED			-
C7		NOT USED			-
C8	110013	100 nF 20% 250V POLYESTER	MULLARD	C2BOAEPIOOK	19
Cy	110013	11 11 11 11	U		-
Cio	110013	E4 17 E5 14	êr .	W	-
Cn	110013		н	12	-
CIZ	110013	u a ^{E4} a	11	tt	_
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DESIGNATOR	DATRON PART No.	DESCRI	PTION			PRINCIPAL MANUFACTURER		MANUFACTU PART No.	JRER'S	No. USED Per Assy.
C13	110013	100nF	20%	2504	POLY STER	MULLARD		C280AE	Piook	-
C14	110013		- 11	"	ч	11		u	· · · · · · · · · · · · · · · · · · ·	-
CIS	110013		н	- 11	н	н		"		_
C16	110013	н		"	u .	44		u		-
C17	110013	N		н	**	11		"		-
C18	110013		r.	w		pi .		14		
C19	110013	- 11			"	e e		н		-
C20	110013	••	••		*	11		"		_
C21	110013	•		"	•	**		н		-
C22	110013	••	м	"	N					-
C23	110013	.,		м	"	11		н		-
C24	110013	н		н	"			н		-
C25	110013		**	•1	н	н		"		-
C26	110013	••	*1	••	~	н		н		_
C27	150002	IONF	20%	16V	DIP. TANT	UNION CARBIDE		KIDEIG		
C28	150016	F	20%	35v	DIP. TANT	UNION CARBIDE		KIRO35		1
DI	200001	75mA	75v (GP. Si	DIODE	FAIRCHILD		IN4148		18
52	200001	и		11 M	н.			н		-
D3	200001		4			"	·	н		-
D4	200001		н	N 54	- 11	н	, , ,	4		-
Ds .	200001	-,	M			•				-
D6	200001				••	11	,			-
D7 ·	200001		••	N N		u		1		-
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ESIGNATOR	DATRON PART No	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
08	200001	75mA 75V GP. SI. DIODE	FAIRCHILD	IN4148	
09	200001	4 14 14 14 14	**		-
010	200001		4		-
Dli	200001	17 . m 11. m 14	ч		-
DIZ	200001	12 14 HI HI HI	-	•	-
013	200001	11 H M M H	•		-
014	200001		•		-
015	200001	11 W 11 H W	•	4	-
016	200001	p 12 40 44 42	•	м	
017	213005	75V 1/2W ZENER	MOTOROLA	BZX79C75	1
CIB	200001	75 A 75V GP SI DIODE	FAIRCHILD	IN4148	-
D19	200001	75 mA 75v GP Si DIODE	FAIRCHILD	IN4148	-
>20	213006	5VI 5W ZENER	UNITRODE	TV5 505	1
		· ·			
छ।		NOT USED			-
Q2	240009	SI NPN TRANSISTOR	NATIONAL	MPSLOI / TO18	18
Q3	240009	и и и	•		-
Q ₄	24 0 009	11 /1 H		"	-
Q5	240009	n 1/ 1/	•	11	
Q6	24 0009	u , "	N	••	_
Q7	24 0 0 0 9	11 Ir 4			-
P8	240009	11 14 11			
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DESIGNATOR	DATRON	DESC	RIPTIO	ı	PRINCIPAL		MANUFACT	URER'S	No. USED
0.0	PART No.		1101	TRANSFER	MANUFACTURER		PART No.	17010	Per Assy.
Q9	240009			TRANSISTOR	NATIONAL		MPSLO	the second se	
QIO	250009			TRANSISTOR	NATIONAL		2N540	1/ TO18	
QII	250009				•				-
Q12	250009		"				"		
фıз	250009	- "	4	H					-
Q14	250009		"	**	••				
Qis	250009	"		4					
φ I6	250009		н	• •					-
Q ₁₇	250009	.,	н						
QR -	250009		•	"	-				-
9 19	250009	••	н -	*1	ų ·		·		-
920	250009	"		-	14		"		-
Q21	240025	Si	NPN	TRANSISTOR	12		MPSAI	3	4
Q22	240025	н	"	"					-
Q23	240025			**	u				-
Q24	240025	,u	4	14	17		I		-
Q25	250011	Si	PNP	TRANSISTOR	ч		BC 327/1	1018	8
Q26	250011		"	4	ч				-
P27	250011		ņ	ų					-
228	250011		4	н	4	1	-		-
(J29	250011	"		4			•		-
730	250011		4	ч	•		•	,	· _
Q31	250011	"	*	**			11		-
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
Q 32	250011	SI PNP. TRANSISTOR	NATIONAL	BC327/TOI8	-
<i>£</i> 13	240009	SI NPN TRANSISTOR	•	MPSLOI/TO18	
234	240009		•		
R 35	240009	++ w 3+		м	
Q36	240009	44 M 11	"		-
Q37	240009	. 11 17	н /	•	-
238	240009				-
Q39	240009			4,	
240	240009	al n 14		1.	-
Q4 1	240009		ч		
Q42	240009	11 11 11 II		"	-
			· · · · · · · · · · · · · · · · · · ·		
MI	280023	QUAD 2-1/P NOR GATE	MOTOROLA	MC14001 BCP	1
M2	260005	SY IA REGULATOR	MOTOROLA	MC7805CP	1
M3	280043	4 BIT LATCH/4 TO 16 LINE DECODE	r MOTOROLA	MC14515 BCP	l
M4	280090	DUAL BINARY INFA DECODER	MOTOROLA	MC 14555BCP	1
M5	270071	DUAL I OF 4 DECODER LS	NATIONAL	DM74LS156N	l
M6	280103	PROGRAMMABLE KEYBOARD/DI	M INTEL	8279-5	!
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACT	URER'S	No. USED Per Assy.
51-527	700079	KEYBOARD * SWITCH . BLACK	NSE	KIZ/HAI	F KEY. BLACK	28
529-543	700061	KEYBOARD SWITCH. RED LED.	SCHADOW	SRL-RE	D LED	25
528, 544, 545	700062	KEYBOARD SWITCH GREEN LE	SCHADOW	SRL- OR	EEN LED.	3
546-555	700061	KEYBOARD SWITCH . RED LED	SCHADOW	SRL-REI	LED	-
556	700079	KEY BOARD = 12 SWITCH . BLACK	NSF	KIZ/HALF	KEY. BLACK	-
	410144-10	РСВ				1
JI	604060	24+24 WAY . 1" PCB. PLUG GOLI	AMP	2-8254	40-4	3
<u> </u>	605098	40 PIN DIL LOW PROFILE SKT			40-01-06-00	1
· · · ·	605060	14 WAY DIL. "				1
	605061	IG WAY DIL " "				2
	605097		CAMBION	703-432	4-01-06-00	
	612023	STANDOFF M2-5x + LG. BRASS KK	CAMBION		81-22-07	2
	800017-3	81/2 DIGIT DISPLAY WITH LEGEN	DALE	SEE DRG		2
· · ·	920096	BUZZER PIEZOELECTRIC	τοκο	PB 2720		1
	620003	SOLDER PCB TERMINAL LUC	HARWIN	HILOSA		2
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ESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACT	URER'S	No. USED Per Assy.
1	611054	M2+6mm SLOT CSK STEEL	ZN PL		•	2
	611076	M3xGmm SLOT PAN HEAD.	ZN PL.		· · · ·	1
	613005	M3 INT. SHAKEPROOF				1
	613026	M2 WASHER STEEL ZN PL				2
	613027	M2 INT SHAKEPROOF			· · · · · · · · · · · · · · · · · · ·	2
	615027	M2 INT SHAKEPROOF				
	615002	M3 FULL NUT STEEL ZN PL				1
	615016	M2 FULL NUT STEEL ZN PL				2
	620007	TEST POINT TERMINAL	MICROVAR	C30		و
	630029	TAPE DOUBLE SIDED 14" × 32	3M	4032		1.50mm
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		ECO	2162 28.2.86 RH	2249	2258	2322	2346	2446	2386	2465																																	
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DESIGNATOR	DATRON PART No.	DESCRIPTION		PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
RI	000332	3k3 5%	1/4W CARBON	MULLARD	CR25	3
R2	000472	4k7 ''	n' n	и	U	
R3	000472	4k7 "	n n			
R4	000472	4k7 "	21 U		. U	-
R5	000472	4k7 "	11 H	п	11	·
RG	000103	10k "	н н		17	5
R7	000104	100k "	<i>11 4</i>	ч	it .	9
R8	000122	lk2 "	н и	"	hr .	2
R9	000104	100k "	n 11	н	11	-
RIO	000104	100k "		"		· _
RII	000103	lok "		"	11	
RIZ .	000472	4k7 "	14 IF			-
R13	000472	4k7 "	w "	Ĩu	u	-
R14-	000561	560R "	et 17	n	н	2
R15	000104	100k "	11 ti	"	<i>n</i> .	-
RIG	000182	lk8 "	13 H	u	"	
R17	014751	4k75 1%	VOW SOPPM MF	HOLCO	H8C	1
R/8	000122	1k2 5%	1/4W CARBON	MULLARD	CR25	-
R19	012491	2k49 1%	1/8W 5066m MF	HOLCO	HBC	1
R20	000102	1k 5%	1/4 W CARBON	MULLARD	CR2S	21
R21	000472	4k7 "	11 A		17	
R22	000223	22k "			11	1
R23	000103	lok "	er 4	"	11 .	
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DESIGNATOR	DATRON PART No.	DESCRIP	TION			PRINCIPAL MANUFACTURER		MANUFACT PART No.	URER'S	No. USED Per Assy.
R24	000332	3k3	5%	1/4W	CARBON	MULLARD		CR25	· .	
R25	011002	loko	1%	1/8W SC	ppm MF	HOLCO		H8C		2
R26	000104	IOOK	5%	1/4W	CARBON	MULLARD		CR2S		
R27	011002	IOKO	1%)þþm MF	HOLCO		HBC		-
R28	0 0 0 4 7 1	470R	5%	1/4W	CARBON	MULLARD		CR25		3
R29	000104	look			. 11	"		ч		-
R30	000472	4k7				"		н		-
R31	000102	lk		"	4	"		v		-
R32	000104	look		"		ч				-
R33	000102	lk				н		"	_	-
R34	000102	IK	11			11		"		-
R35	000102	lk		••	"	"		n		-
R36	000102	lk			4					-
R37	000102	lk	4	"	"	ч		"		-
R38	000102	Ik	"	••	4	ан (т. 1997) 19		4		
R39	000102	ík	"	* 11	н			4		-
R40	000102	lk			"	a				-
R41	000102	Ik	••					"		-
R42	000103	lok	~		"	**	•	4		
R43	000102	lk		••	11	**		"		-
R44	000102	lk								-
R45	000102	IK	ų	**	"	"		"		-
R46	000102	lk		н	и			"		-
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DESIGNATOR	DATRON PART No.	DESCRIPTION	1		PRINCIPAL MANUFACTURER		MANUFAC		No. USED Per Assy.
R47	000102	lk 5%	1/4W	CARBON	MULLARD		CR25		-
R48	000102	lk "		"	*1		"		
R49	000102	lk "	"				"		
R50	000102	lk "	4		ч		<u> </u>		· -
R51	000102	ik "	"	4	"		n		-
R52	000472	4k7 "			4		17		
R53	000104	look "	"	"	"				-
R54	000104	100k "	"	"	"		"	-	-
RSS	000103	10k "	"	н	"		11		-
R56	000471	470 R "	••	11	"		"		
R57	000471	470 R "	"	11	"		11		
R58	000102	lk "	4	н	"		"		
R59	000391	390R "	"	"	"		4		l .
R60	000472	4k7 "		*	"		"		-
R61	000472	4k7 "	"	"	**		"		_
R62	000 561	560R "	"	4	n		- 11		—
R63		NOT USE	D						-
R64	000332	3k3 "	4	11	ù.		4		-
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
ANI	090050	3k3 ×7 2% NETWORK	BECKMAN	764-1- R3k3	1
AN2	090017	100k ×7 2% NETWORK	BECKMAN	764-1- Riook	1
AN2 AN3	090046	IOK X7 2% NETWORK	BECKMAN	764-1-RIOK	2
AN4	090046	IOK X7 2% NETWORK	BECKMAN	764-1-RIOK	-
AN5	090085	12k x8 2% NETWORK	AB	761-3-12k	1
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CI	150002	10/1 F 20% IGV DIP TANT	UNION CARBIDE	KIOEIG	11
C2	150002	IONE 20% IN DIP TANT	UNION CARBIDE	KIDEIG	-
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACT PART No.	URER'S	No. USED Per Assy.
СЗ	104026	47nF -20% 50V CER DISC	SIEMENS	B37449		14
C4	104 026	470F -20% 50V CER DISC	SIEMENS	B37449		
C5	104026	47nF -20 % 50V CER DISC	SIEMENS	B37449		-
C6	104 026	47.F +50 % SOV CER DISC	SIEMENS	B37449		
C7	102681	680 PF 10% 500V CER DISC	ITT	CDIO		1
C8	150016	JUF 20% 35V DIP TANT.	UNION CARBIDE	K:18035		3
C9	104026	47 nF -20% 50V CER DISC	SIEMENS	B37449		-
00	150002	IONF 20% IGV DIP. TANT.	UNION CARBIDE	KIDEIG		-
CII	104026	470F 128% SOV CER DISC	SIEMENS	B374.44	9	-
C12	150002	ION F 20% IGV DIP TANT.	UNION CARBIDE	KIOEIG		-
CIB	150002	IOUF 20% IGV DIP. TANT.	UNION CARBIDE	KIDEIG		
C14	104026	47.F -20% 50V CER DISC	SIEMENS	B37449)	
C15	150002	IONE 20% IEV DIP. TANT.	UNION CARBIDE	KIDEI	à	-
CI6	102102	INF 10% 500V CER DISC	ITT	CDIO		1
CI7	150002	IQUE 20% IGV DIP. TANT	UNION CARBIDE	KIOE 16		-
C18	150016	JUF 20% 35V DIP. TANT	UNION CARBIDE	KIRO35		-
C19	104026	47nF -20% 50V CER DISC	SIEMENS	B37449		-
C20	104026	47 .F .20% 50V CER DISC	SIEMENS	837449		
C21	150002	IONF 20% IOV DIP. TANT.	UNION CARBIDE	KIDE 16		-
C22	104026	47. F +50% 50V CER DISC	SIEMENS	B37449	*.	-
C23	104026	47 F 120% SOV CER DISC	SIEMENS	B37449)	-
c24.	150002	IONE 20% IGV DIP TANT	UNION CABBIDE	KIDE 16		-
C25	104026	47nF -20% 50V CER DISC	SIEMENS	B37449		-
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ESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
226	101103	10 nF 25% 250V CER DISC	ITT	CDIO	2
27	104026	47 .F -20 % 50V CER DISC	SIEMENS	B374 49	-
28	150006	4.07F 20% IGY DIP TANT	UNION CARBIDE	K4R7EIG	1
C29	150016	INF 20% 35V DIP TANT	UNION CARBIDE	KIRO35	
30	150024	474F 20% IOV DIP TANT	UNION CARBIDE	K47EIG	
C31 (States)	101103	IONF 25% 250V CER DISC	ТТ	CDIO	
-32	104026	47 . F -20% 50V CER DISC	SIEMENS	B37449	-
C33	150002	IONF 20% IGV DIP TANT	UNION CARBIDE	KIDEIG	-
.34	150002	100 F 20% 16V DIP. TANT	UNION CARBIDE	KIDEIG	
2.55		/			
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)	200001	75mA 75V GP Si DIODE	FAIRCHILD	IN4148	6
2	200001	75 mA 75V GP SI DIODE	FAIRCHILD	IN414B	-
>3	200001	75 mA 75V GP Si DIODE	FAIRCHILD	IN 4-148	
24	200001	75mA 75Y GP Si DIODE	FAIRCHILD	IN4148	
)5	210047	4V7 400mW ZENER	MULLARD	BZY88C4V7	
26	214012	2V45 3060 ZENER	FERRANTI	ZN458	1
07 of the two start of	220010	SI HOT CARRIER DIODE	H.P.	HSCH1001 / IN6263	1
08	200001	75mA 75V GP Si DIODE	FAIRCHILD	IN4148	-
09 🐜 🖓 🖓 🗛	200001	75mA 75V GP Si DIODE	FAIRCHILD	IN4148	-
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
DIO	213006	5V SW ZENER	UNITRODE	TVS 505	
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QI	240001	SI NPN TRANSISTOR	NATIONAL	BC184/TO18	2
Q2	240001	SI NPN TRANSISTOR	NATIONAL	BC 184/ TO18	
Q3	230031	N-CHAN DUAL JEET	TELEDYNE	SU2656M	
				· · · · · · · · · · · · · · · · · · ·	
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACT	URER'S	No. USED Per Assy.
MI	280024	TRI-STATE HEX. NON-INV. BUFFE	R. MOTOROLA	MC14.50	D3 BCP	4
M2	280024	TRI-STATE HEX. NON-INV. BUFFER	MOTOROLA	MC1450	13 BCP	-
M3	290122-1	745188 PROM PROGRAMMED	DATRON (SEE DRG)	SN74518	BN (BLUE)	1
M4	270056	BI/P NAND LS	NATIONAL	DM74L	SON	I.
M5	270048	QUAD 2 1/P NAND LS	NATIONAL	DM74L	SOON	4
MG	270050	HEX.INVERTER	NATIONAL -	74LS04	4.	2
M7	280008	QUAD 2 1/P 'NAND' GATE	MOTOROLA	MC1401	I BCP	2
M8	280011	DUAL D FLIP-FLOP	MOTOROLA	MC14C	13 BCP	1
M9	280102	14 BIT BINARY COUNTER	MULLARD	HEF 40	20 BP	I I
MIO	280091	UN-BUFFERED TRIPLE 3 1/PNAND	MOTOROLA	MC140	Z3UBCP	1 1
MI	220015	5kV OPTO ISOLATOR	MOTOROLA	Mocio	05	2
M12	280077	HEX. INVERTER	MOTOROLA	MC145	72 BCP	1
Міз	280033	8 CHAN DATA SELECTOR	MOTOROLA	MC1451	2 Bcf	1
M14	280015	QUAD LATCH	MOTOROLA	MC140	76 BCP	2
MI5	280015	QUAD LATCH	MOTOROLA	MC140	76 вср	-
M16	280062	8-BIT STATIC RAM	MOTOROLA	MC681	ØĄ	1
MI7	270048	QUAD 21/P NAND GATE	NATIONAL_	74 LSO	0	-
M18	· .	FITTED AT INSTRUMENT	ASSY.			
M19		FITTED AT INSTRUMEN	T ASSY.			
M20		FITTED AT INSTRUMENT	ASSY.			
M21		FITTED AT INSTRUMENT	ASSY.			
M22	280107	2k × 8 STATIC RAM	НІТАСНІ	HMGIIGF	² -4	1
M23	280117	2kx 8 STATIC RAM LP	FUJITSU	MB 8417	7-25	1
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No USED Per Assy.
M24	2700 58	DUAL 2 TO 4 LINE DEMUX LS	NATIONAL	DM74 LS 155N	3
M25	270075	DUAL D FLIP-FLOP LS	NATIONAL	DM74 LS74 N	* 1.4
M26		NOT FITTED		S	
M27		NOT USED			_
M28	260043	358 DUAL OP AMP	NATIONAL	LM358N	1 1 1
M29	280064	IEEE 488 INTERFACE CHIP	MOTOROLA	MC68488P	and the second
M30	, 280005	TRIPLE GATE	MOTOROLA	MC14501 BCP	the start starts
M31	270045	QUAD 2 TO I LINE MUX LS	NATIONAL	DM74 LS157N	
M32	280092	DUAL 4 BIT LATCH	MOTOROLA	MC14508 BCP	1
M33	270048	QUAD 2 1/P NAND LS	NATIONAL	DM74LSOON	
M34	280144	MICRO-PROCESSOR CHIP	MOTOROLA	MC 68025	1 7
M35	270057	DUAL J-K FLIP-FLOP LS	NATIONAL	DM74 LS76 N	1
M36	280024	TRI-STATE HEX.NON-INV.BUTTE	MOTOROLA	MC14503 BCP	
M37	270077	TRI-STATE HEX. BUFFER LS	NATIONAL 18	DM74L5367	1
M38 ·		NOT USED			-
M39	2200 15	5KV OPTO ISOLATOR	MOTOROLA	MOCIOOS	-
M40	280086	BI-DIRECTIONAL BUS TRANSCE	IVER MOTOROLA	MC3447	2
M41	280059	DUAL BINARY UP COUNTER	MOTOROLA	MC14520 BCP	1
M42	280085	QUAD 2 1/P 'AND' GATE	MOTOROLA	MC 14081 BCP	4
M43	280085	QUAD 2 1/P 'AND' GATE	MOTOROLA	MC 14081 BCP	-
M44	280008	QUAD 2 1/P 'NAND' GATE	MOTOROLA	MCI4OII BCP	
M45	280085	QUAD 2 1/P 'AND' GATE	MOTOROLA	MCI408IBCP	-
M46	280085	QUAD 21/P 'AND' GATE	MOTOROLA	MCI408IBCP	-
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DESIGNATOR	DATRON	DESCRIPTION	PRINCIPAL	MANUFACTURER'S	No. USED
	PART No.		MANUFACTURER	PART No.	Per Assy.
M47	28 0024	TRI-STATE HEX NON-INV BUFFER	MOTOROLA	MC14503 BCP	er po de 🗕 🗆 🔸
M48	280086	BI-DIRECTIONAL BUS TRANSCE	IVER MOTOROLA	MC3447	-
M49	270048	QUAD 21/P NAND LS	NATIONAL	DM74LSOON	1996 - Star Star (1997)
M50	270050	HEX. INVERTER	NATIONAL	74 LS04	-
M51	270058	DUAL 2TO4 LINE DEMUX. LS	NATIONAL	DM74LSISSN	-
M52	270058	DUAL 2 TO4 LINE DE MUX.LS	NATIONAL	DM74 LS155N	
M53	280068	DUAL PRECISION MONOSTABLE	MOTOROLA	MC14538 BCP	1
	605059	BWAY DIL SOCKET	·	1 1. 19 5. 2	1.50
	410248-1A	PCB	-	•	1
TP's	540002	22 SWG BTC WIRE	,		A/R
JLI	604 037	PROGRAMMING CLASS 160 PLUG	AUGAT	8136-4756-8	1
	605050	40 WAY DIL LOW PROFILE SKT.			2.
	605060	14 WAY DIL SOCKET			16
	605061	IG WAY DIL SOCKET			20
			·		
	605064	24 WAY DIL . SOCKET			7
	605066	6 WAY DIL SOCKET		γ. γ.	2
	620003	SOLDER PCB. TERMINAL LUG	HARWIN	H2IOSA Providential	
	630098	COMPONENT CLIP	RICHCO	KKU-8	l se s
	630112	CIRCUIT BOARD EJECTOR	RICHCO	CBE BLACK	2
51	700065	KEYSWITCH IPIW MOMENT.	LIPA + ISOSTAT	DG	2. S. S. 1 . S. M.
	* G20007	TEST POINT TERMINAL	MICROVAR	C30	•21
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ESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
	618004	MOUNTING PAD TOI8	JERMYN	TO18-008D	1
	590004	SLEEVE . PTFE	HELLERMAN ELECTRIC	FEIO	A/R
	605065	28 WAY DIL SOCKET			3
	630243	GLASS BEAD 2.4 0/0 x 0.8 1/0 x 1.8	MANSOL (PREFORMS) LTD	M5363B/3	28
	512999	7/-2 PTFE WIRE WHITE			A/R
	900004	SILICONE RUBBER	RS	555.586	A/R
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	602.018	EYELET Ø1.6	PACE INC.	1347-0042	2
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
RI	008031	100R 5% 1.6 W MF	MULLARD	PR37	2
R2	000472	447 5% 4W CARBON	MULLARD	CR25	8
R3	000472	447 5% 4W CARBON	MULLARD	CR25	
R4-	000472	4 1 5% 4W CARBON	MULLARD	CR25	
R5	000472	4k7 5% 1/4W CARBON	MULLARD	CR25	
R6	000 472	4k7 5% 1/4W CARBON	MULLARD	CR25	-
R7	000 474	470k 5% 1/4W CARBON	MULLARD	CR2S	2
R8	000472	4k7 5% 4W CARBON	MULLARD	CR25	-
R9	000273	27k 5% 4W CARBON	MULLARD	CR25	1
RIO	000474	470k 5% 1/4W CARBON	MULLARD	CR25	
RII	011212	IZKI 1% 18W 50ppm MF	HOLCO	нвс	1
R12	012492	24 k9 1% 18W 50ppm MF	HOLCO	HBC	1
R13	000153	15k 5% 4W CARBON	MULLARD	CR25	1
RH-	000471	470R 5% 4W CARBON	MULLARD	CR25	8
RIS	008031	1008 5% 1.6W MF	MULLARD	PR37	
RIG	, 000104	100k 5% 1/4W CARBON	MULLARP	CR25	1
RI7		NOT USED			
RIB		NOT USED			-
RI9	000821	8208 5% 1/4W CARBON	MULLARD	CR25	1
R20	000471	4708 5% 1/4W CARBON	MULLARD	CR25	
R21	000471	470R 5% 1/4W CARBON	MULLARD	CR25	·
R22	000471	4708 5% 1/4W CAR BON	MULLARD	CR25	
R23	000471	470R 5% 1/4W CARBON	MULLARD	CR25	-
NOTES.		<u>\-\-\-\-</u> \		9/1/86 datro 4700.	PCB. ASSY.

ESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
{24	000471	4708 5% 1/4W CARBON	MULLARD	CR25	
225	000331	330R 5% 1/4W CARBON	MULLARD	CR25	·
26	000471	470R 5% 1/4W CARBON	MULLARD	CR25	-
27	000102	IK 5% 1/4W CARBON	MULLARD	CR25	2
28	000102	IK 5% VAW CARBON	MULLARD	CR25	-
29	000 561	5608 5% 1/4W CARBON	MULLARD	CR25	4
230	000561	560R 5% 1/4W CARBON	MULLARD	CR25	-
31	000561	560R 5% 1/4W CARBON	MULLARD	CR25	-
32	000561	560R 5% 1/4W CARBON	MULLARD	CR25	_
233	000103	lok 5% 4W CARBON	MULLARD	CR25	1 1
234	000154	150k 5% 4W CARBON	MULLARD	CR25	1
135	000472	447 5% 1/4W CARBON	MULLARD	CR25	-
36	000471	470 5% 4W CARBON	MULLARD	CR25	
237	000472	4k7 5% 14W CARBON	MULLARD	CR25	
ANI	090079	5kG × 8 2% NETWORK	АВ	850-91-5k6	2
ANZ	090079	5kG × 8 2% NETWORK	Ав	850-91-5kG	-
NOTES. SEE SHEET 2 FOR I	ATEST ISSUE	Lo			
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CHKD.				DATE NUMBER 4.006	48 3 .

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DESIGNATOR	DATRON PART No.	DESCRIPTION			PRINCIPAL MANUFACTURER		MANUFACTURER'S PART No.	No. USED Per Assy.
CI '	104026	47nF + 28%	50V C	ERIDISC	SIEMENS		B37449	46
C2	104026	47nF "		u ¹ u	"			
C3	104026	47nF "	"				v	-
C4	104026	47nF "	"		"		"	-
C5	104 026	470F "	"		"			-
C6	104026	47nF "			4			-
C7	104026	47nF "	.,				"	-
c8	104026	47nF "	ų		11		н	-
C9	100221	220pF 2%	100 10	ER PLATE	MULLARD		2222 683 221	1
CIO	100272	the second division of			MULLARD		2222 630 19272	1
CII	104026	47nF + 50 %	50V C	ER DISC	SIEMENS		B37449	
CI2	104026	470F "						
CI3	104026	47oF "					"	-
C14	104026	47.5 "			"			
CIS	104026	47of "			"			-
C16	104026	47nF "						-
C17 ·	104026	47oF "						-
C18	104026	47nF "			U			_
C19	104026	47nF "			e	1	"	_
C20	104026	470F "					"	-
C21	104026	47.F "			"		11	
C22 .	104026	47nF "			"			-
C23	104026	47nF "					"	-
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E.C.O.						CHECKE	INTERFACE	PCB. ASSY.
DATE CHKD						DATE	DRAWING NUMBER 40064	18 4 SHEET 9

DESIGNATOR	DATRON PART No	DESCRIPTION	PRINCIPAL MANUFACTURE R	MANUFACTURER'S PART No	No USED Per Assy
C24	104026	47 .F -20% 50V CER. DISC	SIEMENS	B37449	
C25	104026	11 11 11 11 11	.,	ч.,	-
C26	104026	1) 11 11 11 12	14	4	-
C27	104 0 26		υ		-
C28	104 0 26	11 II II <u>11</u>	**	4	
C29	150016	1 N F 20% 354 DIP. TANT	UNION CARBIDE	KIROE35	2
C30	100182	INBE 10% 100V CER PLATE	MULLARD	2222 630 19182	1
CBI	100331	330pf 2% 100V CER PLATE	MULLARD	2222 681 331	2
C 32	150012	100 .F 20% 35V DIP. TANT	UNION CARBIDE	KRIOE35	1
C33	104026	47 nF -20% 50V CER. DISC	SIEMENS	B37449	-
C34	104 026		*1	"	-
C35	104026		**		·
C36	104026			4	-
C37	104026				
c38	104026		14	.,	
C39	102220	22%F 5% 500V CER. DISC	. ITT	CDIO	1
C40	102330	334F 5% 500V CER DISC	ТТ	CDIO	1
C41	104026	47nF -20% 50V CER.DISC	SIEMENS	B37449	-
C42	104026		u.	11	-
C43	104026				-
C44	104026				-
C45	104026		u		-
C46	104026	11 11 12 11 11	**		
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11.0			L 11] L 11]	INTERFACE	PCB. ASSY.
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
C47	150024	47,4F 20% IGV DIP. TANT		K47E16	· •
C48,51	104026	47nF -20% 50V CER.DISC		B37449	, _
C49,52-55,61	104 0 26	47nF +50 % 50V CER DISC	SIEMENS	837449	
C50	100331	330pF 2% 100V CER PLATE	MULLARD	2222 681 331	
C59	110042	100 F 20% G3V POLYESTER	WIMA	MK52	I
C60	150016	1/1 20% 35V DIP TANT	UNION CARBIDE	KIROE35	
C62	104041	10nF 25% 250V CER DISC	STC	CDIO	1
DI	200001	75 mA 75 v GP SI DIODE	FAIRCHILD	IN4148	2
DZ	200001	75mA 75v GP Si DIODE	FAIRCHILD	IN4148	-
			•		
QI	240014	SI NPN TRANSISTOR	NATIONAL	BC337	I .
			·		
MI	270050	HEX INVERTER LS	NATIONAL	DM74LSO4N	1
M2	280008	QUAD 21/P'NAND' GATE	MOTOROLA	MC14011BCP	· · · · · · · · · · · · · · · · · · ·
M3	280011	DUAL D FLIP-FLOP	MOTOROLA	MC14013BCP	2
M4	280059	DUAL BINARY UP COUNTER	MOTOROLA	MCI4520BCP	<u>_</u>
M5	280037	HEX BUFFER	MOTOROLA	MC14050BCP	I
M6	270048	QUAD 2 1/P 'NAND' LS	NATIONAL	DM74LSOON	2
M7	270072	QUAD 2 1/P 'NOR' L'S	NATIONAL	DM74 LSO2N	2
MB	270002	QUAD 2 1/P O/C NAND	NATIONAL	DM740IN	2
M9	270094	DUAL LINE RECEIVER	TEXAS	SN75182N	1
MIO	270076	DUAL MONOSTABLE LS	NATIONAL	DM74L5123N	. 1
MIL ·	270095	DUAL DECADE COUNTER	NATIONAL	DM74L5 390N	2
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
M12	270072	QUAD 2 1/P 'NOR' LS	NATIONAL	DM74LS02N	-
M13	270055	DUAL 4 1/P NAND LS	NATIONAL	DM74LS20N	1
MI4	270075	DUAL D FLIP-FLOP LS	NATIONAL	DM74LS74N	1
MIS	280095	4 BIT SYNC. BINARY COUNTER	MULLARD	" HEF40IG3BP	3
MIG	280095	4.BIT SYNC. BINARY COUNTER	MULLARD	HEF 40163BP	-
M17	280095	4 BIT SYNC. BINARY COUNTER	MULLARD	HEF401638P	. –
118	2700.96	DUAL 4TO I MULTIPLEXER	NATIONAL	DM74L5153N	1
MI9	280093	QUAD EXCLUSIVE-OR GATE	MOTOROLA	MCI4070BCP	6
M20	280093	QUAD EXCLUSIVE-OR GATE	MOTOROLA	MCI4070BCP	-
M2I	280093	QUAD EXCLUSIVE-ORGATE	MOTOROLA	MC14070 BCP	-
M22	270074	TRIPLE 3 I/P 'NOR' LS	NATIONAL	DM74LS27N	3
M23	270074	TRIPLE 3 1/P 'NOR' LS	NATIONAL	DM74LS27 N	-
M24	270074	TRIPLE 3 1/P 'NOR' LS	NATIONAL	DM74LS27N	-
M25	280093	QUAD EXCLUSIVE - OR GATE	MOTOROLA	MCI4070BCP	-
M26	280093	QUAD EXCLUSIVE - OR GATE	MOTOROLA	MC14070 BCP	-
M27	280093	QUAD EXCLUSIVE-ORGATE	MOTOROLA	MC14070 BCP	,
M28	270095	DUAL DECADE COUNTER	NATIONAL	DM74LS390N	-
M29	280068	DUAL PRECISION MONOSTABLE	MOTOROLA	MC14538 BCP	1
M30	280145	PHASE LOCKED LOOP	MOTOROLA	MCI4046BCP	1
M3I	280015	QUAD LATCH	MOTOROLA	MC14076 BCP	7
M32	280015	QUAD LATCH	MOTOROLA	MCI4076 BCP	-
M33	280015	QUAD LATCH	MOTOROLA	MC14.076 BCP	-
M34	280015	QUAD LATCH	MOTOROLA	MC14.076BCP	-
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DESIGNATOR	DATRON PART No	DESCRIPTION 2	PRINCIPAL MANUÉ ACTURE R	MANULACTURE 83 PART No	No. USED Per Assy
M35	270073	QUAD 21/P O/C AND' LS	NATIONAL	DM74LS09N	2
M36	270073	QUAD 21/P O/C 'AND' LS	NATIONAL	DM741509N	
M37	280015	QUAD LATCH	MOTOROLA	MC14-076 BCP	-
M38	280015	QUAD LATCH	MOTOROLA	MC 14076 BCP	-
M39	280015	QUAD LATCH	MOTOROLA	MC14076 BCP	_
M40	270036	MONOSTABLE	NATIONAL	DM7412IN	1
M4I	270057	DUAL JK FLIP-FLOP LS	NATIONAL	DM74LS76N	2
M42	270057	DUAL JK FLIP- FLOP LS	NATIONAL	DM74LS76N	
M43	270048	QUAD 2 1/P NAND LS	NATIONAL	DM74LSOON	-
M44	280094	SYNC! SERIAL DATA ADAPTOR	MOTOROLA	MC6852P	1
M45	280024	TRI-STATE HEX, NON-INV. BUFFE	R MOTOROLA	MC14503 BCP	1
M46	270002	QUAD 2 1/P O/C NAND	NATIONAL	DM7401N	
M47	280038	HEX D FLIP-FLOP	MOTOROLA	MC14174 BCP	4
M48	280038	HEX D FLIP-FLOP	MOTOROLA	MC14174 BCP	-
M49	2800 11	DUAL D FLIP-FLOP	MOTOROLA	MC 14013 BCP	_
M50	280105	8 I/P NAND	MOTOROLA	MC14068 BCP	1
M5I	280038	HEX D FLIP-FLOP	MOTOROLA	MC14174 BCP	-
M52	280038	HEX D FLIP- FLOP	MOTOROLA	MC14174 BCP	
M53	270086	4-BIT BINARY COUNTER	NATIONAL	DM74LS93N	1
M54	280023	QUAD 2 1/P NOR GATE	MOTOROLA	MCI400IUBCP	1
M55	290149	GEN. PURPOSE TIMER	INTERSIL	ICM75551PA	1
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
	410264-1	PCB			1
	605060	14 WAY DIL SOCKET	JERMYN	J23- 18014	28
	605061	IG WAY DIL SOCKET	JERMYN	J23-18016	25
	605064	24 WAY DIL SOCKET	JERMYN	J23-18024	1 1
	630117	CIRCUIT BD EJECTOR	RICHCO	CBE BROWN	2
×I	800029	CRYSTAL OSCILATOR	4.096 MHZ IQD	IQ×0-100	1
	620007	TEST POINT TERMINAL	MICROVAR	C 30	27
	540002	22 SWG TINNED CU WIRE	RS		A/R
<u></u> Τι	310003	PULSE TRANSFORMER	NEWPORT	76610/1	1
1	605059	8 WAY DIL SOCKET			1
	900004	SILICONE RUBBER COMPOUND	RS	555-588	A/R
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DESIGNAT	TOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
RI		000472	4k7 5% 1/4W CARBON	MULLARD	CR25	6
RZ		000561	560R 5% VAW CARBON	MULLARD	CR25	8
R3		000622	6k2 5% 1/4W CARBON	MULLARD	CR25	4
R4		000561	560R 5% 1/4W CARBON	MULLARD	CR25	
RS		000 472	4k7 5% 1/4W CARBON	MULLARD	CR25	-
R6		000 472	4k7 5% 1/4W CARBON	MULLARD	CR25	_
R7		000561	560R 5% 1/4W CARBON	MULLARD	CR25	·
R8		000 272	2k7 5% 1/4W CARBON	MULLARD	CR25	2
R9		000561	560R 5% 1/4W CARBON	MULLARD	CR25	-
RIO		000472	4k7 5% 1/4W CARBON	MULLARD	CR25	
RII		000103	IOK 5% 1/4W CARBON	MULLARD	CR25	9
RIZ		000102	IK 5% 1/4W CARBON	MULLARD	CR25	5
RI3		000622	6k2 5% 1/4W CARBON	MULLARD	CR25	
R14		000102	Ik 5% 1/4W CARBON	MULLARD	CR25	
RIS		000103	IOK 5% 1/4W CARBON	MULLARD	CR25	
R16		013161	3k16 1% 1/8W 50ppm MF	носсо	H8C	4
R17		000101	100R 5% 1/4W CARBON	MULLARD	CR25	12
R18	(F5V)	014750	475R 1% 1/8W 5060 MF	HOLCO	нвс	1
R19		013161	3k16 1% 1/8W 504 MF	носсо	H8C	
RZO		000101	IOOR 5% 1/4W CARBON	MULLARD	CR25	
RZI		013161	3k16 1% 1/8W 5060 MF	HOLCO	HBC	
R22		000101	100R 5% 1/4W CARBON	MULLARD	CR25	
R23	(FSV)	012261	2k26 1% 1/8W 5040 MF	HOLCO	H8C	I
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DESIGNATOR		DATRÔN PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	M'INUFACTURER'S PART No.	No. USED Per Assy.
R24		013161	3k16 1% 1/8W 5000 MF	Holco	H8C	-
R25		000101	100R 5% 1/4W CARBON	MULLARD	CR25	
R26		000102	IK 5% 1/4W CARBON	MULLARD	CR25	-
R27		000431	430R 5% 1/4W CARBON	MULLARD	CR25	2
R28		000101	IOOR 5% 1/4W CARBON	MULLARD	CR25	-
R29	(FSV)	019538	95R3 1% 1/8W 5060 MF	HOLCO	H8C	4
R30		000431	430R 5% 1/4W CARBON	MULLARD	CR25	-
R31		000101	100R 5% VAW CARBON	MULLARD	CR25	
R32		000102	IK 5% 1/4W CARBON	MULLARD	CR25	
R33	(F5V)	019538	95R3 1% 1/8W 5060 MF	HOLCO	H&C	-
R34		000562	5k6 5% 1/4W CARBON	MULLARD	CR25	4
R35		000561	560R 5% 1/4W CARBON	MULLARD	CR2S	-
R36		000622	6k2 5% 1/4W CARBON	MULLARD	CR25	-
R37		000561	560R 5% 1/4W CARBON	MULLARD	CR25	-
R38		000562	5kG 5% 1/4W CARBON	MULLARD	CR25	
R39		000562	5k6 5% 1/4W CARBON	MULLARD	CR25	-
R40		000561	560R 5% 1/4W CARBON	MULLARD	CR25	-
R41		000622	6k2 5% 1/4W CARBON	MULLARD	CR25	-
R42		000561	560R 5% 1/4W CARBON	MULLARD	CR25	
R43		000562	5k6 5% 1/4W CARBON	MULLARD	CR25	-
R44		000202	2ko 5% 1/4W CARBON	MULLARD	CR25	2
R45		000222	2k2 5% 1/4W CARBON	MULLARD	CR25	3
R46		014320	432R 1% YOW 50ppm MF	HOLCO	F8C	4
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DESIGNAT	OR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
R47		000101	1008 5% 1/4W CARBON	MULLARD	CR25	
R48	(F5V)	019538	95R3 1% 18W 50 ppm MF	HOLCO	H8C	
R49		014320	432R 1% 1/8W 50 pm MF	HOLCO	нвс	
R50		000101	100R 5% 1/4W CARBON	MULLARD	CR25	
R51		014320	432R 1% 1/8W 50 pm MF	HOLCO	Н8С	
R52		000101	100R 5% 1/4W CARBON	MULLARD	CR25	
R53	(FSV)	019538	95R3 1% 1/8W 50 pm MF	HOLCO	Н8С	
R54		014320	432R 1% 1/8W506 MF	HOLCO	H8C	
R55		000101	1008 5% 1/4W CARBON	MULLARD	CR25	
R56		000474	470k 5% 14W CARBON	MULLARD	CR25	I
R57		000184	180K 5% 1/4W CARBON	MULLARD	CR25	1
R58	····	01374.2	37k4 1% 1/8W 50 pm MF		H8C	II
R59		000103	10k 5% 1/4W CARBON	MULLARD	CR25	
R60		000338	3R3 5% 1/4W CARBON		CR25	1
R61		000104	100k 5% 1/4W CARBON		CR25	2
R62		018872	88k7 1% 1/8W 5060 MF		H8C	<u>I ·</u>
R63		017872	78k7 1% 1/8W 50/pm MF	HOLCO	HBC	2
R64		070144	36ko •01% 5þþm WW	MANN	MX 125 B	1
R65		070142	12ko 01% 5 pm WW	MÁNN	MX1258	2
R66		017872	78k7 1% 1/8W 5040m MF	HOLCO	1'80	
R67		000912	9k1 5% 1/4W CARBON	MULLARD	CR25	1
R68			NOT USED			
R69			NOT USED			
NOTES. SEE SHEET	7 2 FOR LATES	ST ISSUE				
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ESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
R70		NOT USED			-
R71		NOT USED			-
R72	000682	6k8 5% 1/4w CARBON	MULLARD	CR25	1
R73	000272	2k7 5% 1/4w CARBON	MULLARD	CR25	
R74	000470	478 5% 1/4W CARBON	MULLARD	CR25	3
R75	011183	118k 1% 1/8W 50ppm MF	HOLCO	нвс	1
R76	011001	1k00 1% 1/8W 50 ppm MF	HOLCO	HBC	4
R77	011001	100 1% 1/8W 50/0 MF	HOLCO	HBC	· ~
R78	012672	26k7 1% 1/8W 5040 MF	HOLCO	HBC	1
R79	080032	78k7 .1% IW 1040 MF	VISHAY	V53C5	1
280	070143	16k0 .01% 540m WW	MANN	MX 1258	1
R81	070142	12k0 .01% 566m WW	MANN	MX125B	-
282		NOT USED			-
783		NOT USED			-
R84	012212	22k1 1% 1/8W 5060 MF	HOLCO	HBC	2
R85 (F5V)	013162	31 K 6 1% 1/8 W 50 pm MF	HOLCO	HBC	1
R86	000102	IK 5% 1/4W CARBON	MULLARD	CR25	~
R87		NOT USED			-
888		NOT USED			-
R89		NOT USED			-
R90	000104	100k 5% 1/4W CARBON	MULLARD	CR25	-
R91	011182	11k8 1% 1/8W 506 MF	Holco	HBC	1
R92	011001	100 1% 1/8W 5040 MF	HOLCO	HBC	
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DESIGNATOR	DATRON PART №.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
R93	011001	1600 1% 1/8W 5040m MF	HOLCO	HBC	-
R94	014532	45k3 1% 1/8W SOPPM MF	HOLCO	нвс	
R95	011402	14k0 1% 1/8W 50ppm MF	HOLCO	HBC	1.
R96	019 531	9453 1% 18W 5060 MF	HOLCO	HBC	1
R97		NOT USED			-
R98	011002	IOK 1% Yow SOH ME	HOLCO	HBC	4
R99	070156	555k41 .01% 566m WW	MANN	AX1758	1
R100	070145	475R .01% 560 WW	MANN	AX1758	1
RIOI	012212	22K1 1% 1/8W 5000 MF	HOLCO	HBC	-
RIOZ	000473	47k 5% 1/4W CARBON	MULLARD	CR25	4
R103	000103	IOK 5% 1/4W CARBON	MULLARD	CR25	-
R104	000103	10k 5% 1/4W CARBON	MULLARD	CR25	-
RIOS	000472	4k7 5% 1/4W CARBON	MULLARD	CR25	-
R106	000103	lok 5% 1/4W CARBON	MULLARD	CR25	
R107	000393	39% 5% 1/4W CARBON	MULLARD	CR25	4
R108	012001	2400 1% 1/8W 504 MF	HOLCO	HBC	4
R109	011302	13ko 1% Yow Soft MF	HOLCO	HBC	4
RIIO	012001	2400 1% 1/8W 5010 MF	HOLCO	HBC	-
RIII	000393	39k 5% 1/4W CARBON	MULLARD	CR25	-
R112	011302	13k0 1% 1/8W 5060 MF	HOLCO	HBC	
R113	000101	1008 5% 1/4W CARBON	MULLARD	CR25	-
R114	000101	IOOR 5% 1/4W CARBON	MULLARD	CR25	-
RIIS	000470	478 5% 1/4W CARBON	MULLARD	CR25	-
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140016 104026 150020 150020 140051 * 110035 140016	100F 20% 25V DIP TANT 100F 20% 25V DIP TANT 100F 20% 400V POLYPROP 2200F 20% 63V POLYESTER	SIEMENS UNION CARBIDE UNION CARBIDE WIMA	РНЕ 402 НFK B374 4 9 KIDE 25 KIDE 25 MKPID	
150020 150020 140051 * 110035 140016	100F 20% 25V DIP TANT 100F 20% 25V DIP TANT 100F 20% 400V POLYPROP 2200F 20% 63V POLYESTER	UNION CARBIDE UNION CARBIDE WIMA	KIDE25 KIDE25	
150020 140051 * 110035 140016	10+ 20% 25V DIP TANT 10+ 20% 400V POLYPROP 220+ 20% 63V POLYESTER	UNION CARBIDE	KIOE 25	
140051 * 110035 140016	10nF 20% 400V POLYPROP 220nF 20% 63V POLYESTER	WIMA		
110035 140016	220 AF 20% 63V POLYESTER		MKPIO	1
140016		WINAA		
			MKS2	2
	470 of 10% 250V POLYPROP	RIFA	PHE 402 HFK	-
110042	100 AF 20% 63V POLYESTER	WIMA	MKS2	4
110042	100 nF 20% 63V POLYESTER	WIMA	MKS2	-
110039	470nF 20% 63V POLYESTER	WIMA	MKS2	3
110039	470 nF 20% G3V POLYESTER	WIMA	MKS2	
150016	4 F 20% 35V DIP TANT	UNION CARBIDE	KIROE35	-
104026	47hF -28% SOV CER DISC	SIEMENS	B37449	
	NOT USED			-
104026			B37449	-
104026	47 .F -20% 50V CER DISC	SIEMENS	B3744 9	
150020	100F 20% 25V DIP TANT	UNION CARBIDE	KIOE35	-
150020	100 F 20% 25V DIP TANT	UNION CARBIDE	KIDE35	
102221	220 F 10% SOON CER DISC	ITT	CDIO	2
110042			MK52	-
110042	100 NF 20% 63V POLYESTER	WIMA	MKS2	-
110035	220nF 20% 63V POLYESTER	WIMA	MKS2	-
150016	INF 20% 35V DIP TANT	UNION CARBIDE	KIROE 35	-
NE 140044 STEATI	TE MKP1841.	DHAWN CHECKE	"4700 REI "PCB. A	F. DIVIDER
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	110042 110042 110039 150016 104026 10039 10039 1004026 104026 104026 104026 104026 10039 10039 1004026 104026 104026 1004026 1004026 1004026 1004026 1004026 1004026 1004026 1004026 1004026 1004026 1004026 1004026 1004026 1004026 1004026 1004026 100020 100035 150016 100042 100045 1000045 100045 100045 100045 100045	IIOO42 IOOnF 20% 63V POLYESTER IIO042 IOOnF 20% 63V POLYESTER IIO039 470nF 20% 50V CER DISC NOT USED I04026 104026 47nF 150% 50V CER DISC I04026 47nF 150% 50V CER DISC I04026 47nF 150% 50V CER DISC I04026 47nF 20% 50V CER DISC I04026 47nF 150% 50V CER DISC I04026 47nF 20% 50V CER DISC I04026 47nF 20% 50V CER DISC I00020 I0µF 20% 25V DIP TANT I00221 220pF 10% 500 CER DISC II0042 I00nF 20% 63V POLYESTER II0035 220nF 20% 63V POLYESTER I50016 IµF 20% 35V DIP TANT VE 140044 STEATITE MIKP1841.	110042 100nF 20% 63V POLYESTER WIMA 110042 100nF 20% 63V POLYESTER WIMA 110039 470nF 20% 63V POLYESTER WIMA 150016 1wF 20% 35V DIP TANT UNION CARBIDE 104026 47nF 120% 50V CER DISC SIEMENS 104020 10wF 20% 25V DIP TANT UNION CARBIDE 150020 10wF 20% 25V DIP TANT UNION CARBIDE 102221 220pF 10% 500V CER DISC ITT 110042 100nF 20% 63V POLYESTER WIMA 110042 100nF 20% 63V POLYESTER WIMA 110035 220nF 20% 63V POLYESTER WIMA 150016 1wF 20% 35V DIP TANT UNION CARBIDE VE 140044 STEATITE MKP1841. Inteating	110042 100nF 20% 63V POLYESTER WIMA MKS2 110042 100nF 20% 63V POLYESTER WIMA MKS2 110039 470nF 20% 63V POLYESTER WIMA MKS2 104026 47nF *20% 50V CER DISC SIEMENS B37449 1004020 10µF 20% 25V DIP TANT UNION CARBIDE KI0E35 102021 10µF 20% 25V DIP TANT UNION CARBIDE KI0E35 100221 200nF 20% 63V POLYESTER WIMA MKS2 110042 100nF 20% 63V POLYESTER WIMA MKS2 110035 220nF 20% 63V POLYESTER <td< td=""></td<>

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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
C70	110039	470 nF 20% 63V POLYESTER	WIMA	MKS2	-
C71	110030	INF 20% 100V POLYESTER	WIMA	=K52	
C72	110030	InF 20% IOOV POLYESTER	WIMA	FKS2	-
C73	102221	220pf 10% 500V CER DISC	ITT	CDIO	
C74	104026	47nF -20% 50V CER DISC	SIEMENS	B37449	
C75	150016	1/1 20% 35V DIP TANT		KIROE35	
C76	150020	IONE 20% 25V DIP TANT		KIDE 25	-1
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
PI	210027	2V7 400mW ZENER	MULLARD	BZY88C2V7	4
D2	210120	12V 400mW ZENER	MULLARD	BZY88C12	1
D3	210027	2V7 400 mW ZENER	MULLARD	BZY88C2V7	
D4	210043	4V3 400mW ZENER	MULLARD	BZYB8C4V3	1
05	210027	2V7 400mw ZENER	MULLARD	BZY88C 2V7	-
DG	210027	2V7 400 mW ZENER	MULLARD	BZY88C2V7	~~
D7	. 213009	ISV SW ZENER	UNITRODE	TVS 515	5
08	1 213009	15V SW ZENER	UNITRODE	TVS 515	
D9	213009	ISV SW ZENER	UNITRODE	TVS SIS	-
DIO	200008	200mA 125V LL SI DIODE	FAIRCHILD	IN458A	1
DII	213009	ISV SW ZENER	UNITRODE	TVS515	-
D12		NOT USED	· · ·		-
DIB		NOT USED			
014-	210062	GV2 400mW ZENER	MULLARD	BZY88CGV2	2
DIS	210062	GV2 400 MW ZENER	MULLARD	BZY88CØV2	-
DIG		NOT USED	-		-
DI7		NOT USED			-
D18	200001	75mA 75V GP Si DIODE	FAIRCHILD	IN4148	9
019	200001	75 A 75V GPS' DIODE	FAIRCHILD	IN4148	-
D20	200001	75mA 75V GP Si DIODE	FAIRCHILD	IN4148	-
D2I	200001	75mA 75V GP SI DIODE	FAIRCHILD	IN4148	-
D22	200001	75mA 75V GP Si DIODE	FAIRCHILD	IN4148	-
D23	210056	5VG 400mW ZENER	MULLARD	BZY88C 5V6	2
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
D24	210056	5VG 400mW ZENER	MULLARD	BZY88C5V6	-
D25	213006	5V 5W ZENER	UNITRODE	TVS 505	I .
D26	200001	75mA 75V GP Si DIODE	FAIRCHILD	IN4148	-
D27	200001	75mA 75V GP Si DIODE	FAIRCHILD	IN4148	-
D28	200001	75mA 75Y GP Si DIODE	FAIRCHILD	IN4148	-
esa	213009	15V 5W ZENER	UNITRODE	TVS 515	-
D30	200001	75mA 75V GP Si DIODE	FAIRCHILD	IN4148	-
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	S No. USED Per Assy.
RIIG	000222	2k2 5% Vaw CARBON	MULLARD	CR25	
R117		NOT USED			
RIIB	006 132	IK30 2% IW MET-OX	ELECTROSIL	FPI	2.
2119	006132	1K30 2% IW MET-0X	ELECTROSIL	FPI	
R120	000103	IOK 5% 1/4W CARBON	MULLARD	CR25	-
R121	000473	47k 5% 4W CARBON	MULLARD	CR25	
R122	000823	82k 5% 1/4W CARBON	MULLARD	CR25	
R123	000473	47k 5% 1/4W CARBON	MULLARD	CR25	
R124	000152	IKS 5% YAW CARBON	MULLARD	CR25	2
Ř 125	011002	10K0 1% 1/8W 50pp m MF	HOLCO	HBC	-
2126	011002	IOKO 1% YOW SOPP ME	HOLCO	HAC	
R127	011002	10k0 1% 1/8W 50ppm MF	HOLCO	HBC	_
R128	012001	2k 1% 1/8W 50ppm MF	HOLCO	H8C	
R129	011302	13k 1% 1/8W 50ppm MF	HOLCO	H8C	
R130	012001	2k 1% 1/8W 50ppm. MF	HOLCO	H8C	
RIJI	011302	13k 1% 1/8W 50ppm MF	HOLCO	H8C	
R132	000470	47R 5% 1/3W CARBON	MULLARD	CR25	
R133	000222	2k2 5% 1/3W CARBON	MULLARD	CR25	
R134	000821	820R 5% 1/3W CARBON	MULLARD	CR25	2
R135	000821	820R 5% /3W CARBON	MULLARD	CR25	-
R136	000393	39k 5% 1/3W CARBON	MULLARD	CR25	-
R137	000393	39k 5% 1/3W CARBON	MULLARD	CR25	. —
R138	000220	22R. 5% 1/3W CARBON	MULLARD	CR25	2
NOTES. SEE SHEET 2 FOR 1	LATEST ISSUE	· 		DRAWN 11 TITLE	00 REF DIVIDER
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ESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
R139	000220	22R 5% /3W CARBON	MULLARD	CR25	
2140	000152	1k5 5% /3W CARBON	MULLARD	CR25	-
रा 4 । •	000103	IOK 5% 1/3W CARBON	MULLARD	L:R25	
2142	000472	4k7 5% 1/3W CARBON	MULLARD	CR25	
(143	000473	47k 5% /3W CARBON	MULLARD	CR25	
144	000103	IOK 5% YOW CARBON	MULLARD	CR25	-
2145	000 202	2k 5% YOW CARBON	MULLARD	CR25	
R146	000303	30k 5% '3W CARBON	MULLARD	CR25	
RI47	000155	IM5 5% Yow CARBON	MULLARD	CR25	I
2148	000273	27K 5% 13W CARBON	MULLARD	C.R25	1
ANI	090031	IK X7 2% NETWORK	BECKMAN	L08-1-R1k	I
AN2	090096	IM X8 2% NETWORK	BECKMAN	LO9-I-RIM	2
AN3	090096	IM x8 2% NETWORK	BECKMAN	LO9-1- RIM	
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ESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
1	104026	47 AF -20% 50V CER DISC	SIEMENS	B31449	23
2	104026	47 F -20% 50V CER DISC	SIEMENS	B37449	-
3	150003	47. F 20% 6V3 DIP TANT	UNION CARBIDE	K47EGV3	1
4	150021	22,05 20% 25V DIP TANT		K22E25	1
5		NOT USED			
6	104026	47nF 128% SOV CER DISC	SIEMENS	B37449	-
7	150016	F 20% 35V DIP TAN		KIRO E35	4
8	104026	47 .F -20% 50V CER DISC		837449	
.9	104026	47.F -20% 50V CER DISC		837449-	-
.10	104026	470F -20% 50V CER DISC	SIEMENS	B37449	
11	104026	47nF +20% SOV CER DISC		B37449	
12	104026	47 .F 120% 50V CER DISC	SIEMENS	B37449	-
.13	102101	100% 10% 500V CER DISC		CDIO	1
.14	104026	47nF = 20% SOVCER DISC		B37449	
.15	110013	100 nF 20% 250V POLYEST		C2BOAE PHOOK	2
.16	110013	100 nF 20% 250V POLVEST		C280AEPIOOK	-
.17	104026	47.F 120% SOV CER DISC		B37449	-
18	104026	47 nF -20% 50V CER DISC	SIEMENS	B37449	
.19	104026	47AF 150% SOV CER DISC		B37449	-
20	104026	4715 120% 50V CER DISC	SIEMENS	B374-49	
21	104026	47. F - 28% 50V CER DISC	SIEMENS	B37449	
222	104026	47 F +20% 50V CER DISC	SIEMENS	837449	
223	140016	470 NF 10% 250V POLYPROI	RIFA	PHE402 HFK	10
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
C24	102470	47pF 5% 500V CER DISC	ITT	CDIO	3
C25	104026	47 .F -20% 50V CER DISC	SIEMENS	B37449	-
C26	102 470	4755 5% 500V CER DISC	TTI	CDIO	
C27	104 026	47 F -20% 50V CER DISC	SIEMENS	B37449	-
C28		NOT USED			-
C29	140016	470 NF 10% 250V POLY PROF	RIFA	PHE402HFK	-
C30	102470	476F 5% SOOV CER DISC	ITT	CDIO	-
C31	140016	470 F 10% 250V POLYPROP	RIFA	PHE402 HFK	-
C32	104026	47nF 1월% 50V CER DISC		B37449	-
C33	150020	100F 20% 25V DIP. TAN	UNION CARBIDE	K10 E25	8
C34	180015	470 F 25V AL. ELECT.	MULLARD	017-16471	ł
C35	150020	10/0 F 20% 25V DIP. TANT	UNION CARBIDE	KIDE 25	
C36		NOT USED			-
C37		NOT USED			-
C 38	110030	InF 20% 100V POLYESTER	WIMA	FKS2	3
C39	150020	IDAF 20% 25V DIP TANT	UNION CARBIDE	K10625	-
<u>C40</u>	102270	27pf 5% 500V CER DISC	ITT '	CDIO	2
C41	140016	470 NF 10% 250V POLYPROP	RIFA	PHE 402 HFK	-
C42	140016	470 .F 10% 250V POLYPROP	RIFA	THE 402 HEK	-
C43	140016	470nF 10% 250V POLYPROP	RIFA	PHE 402 HFK	-
C44	140016	470 NF 10% 250V POLYPROP	RIFA	PHE 402 HFK	-
C45	102270	27 F 5% SOOV CER DISC	ITT	CDIO	-
C46	140016	470 F 10% 250V POLY PROP		PHE 402 HFK	_
NOTES.	ATEST ISSUE			AD MARK 11	EF. DIVIDER
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S	No. USED Per Assy.
QI	250004	SI PNP TRANSISTOR	NATIONAL	2N3906/TO18	13
QZ	240006	SI NPN "	NATIONAL	2N3904/TO18	14
Q3	250004	SI PNP "	NATIONAL	2N3906/ TO18	—
Q4	240006	SI NPN 11	NATIONAL	2N3904/T018	
Q5	240006	SI NPN "	NATIONAL	2N3904/TO18	
ୡୢ	250004	SI PNP 11	NATIONAL	2N3906/T018	
Q7	240006	SI NPN 1	NATIONAL	2N3904/TOI8	·
Q	250004	SIPNP "	NATIONAL	2N 3906 / TO18	-
Q9	250004	SI PNP "	NATIONAL	2N3906/T018	-
QID	240006	SINPN "	NATIONAL	2N 3904/TO18	-
QII	250004	SIPNP "	NATIONAL	2N3906/TO18	-
QI2	240006	SI NPN "	NATIONAL	2N3904/TO18	-
Q13		NOT USED			
Q14		NOT USED			· _
QIS		NOT USED			
QIG		NOT USED			
Q17		NOT USED			-
ଦାଃ		NOT USED			
Q19	24 0006	SI NPN "	NATIONAL	2N3904/T018	
Q20	240006	SI NPN "	NATIONAL	2N 3904/TO18	-
Q21	250004	SI PNP "	NATIONAL	2N3906/TO18	-
Q22	240006	SI NPN "	NATIONAL	2N3904/TO18	
Q23	250004	SI PNP "	NATIONAL	2N3906/T018	-

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C118	<u> </u>				<u>``</u>				DATE		15 04 21

DESIGNATOR	DATRON	DESCRIPTION	PRINCIPAL	MANUFACTURER'S	No. USED Per Assy.
Q24	240006			2N3904/T018	
<u>Q</u> 25	240006	SINPN TRANSISTOR	NATIONAL	2N3904/TOI8	_
Q26	250004	SINPN "	NATIONAL	2N3906/TOI8	
	240006	SI NPN "	NATIONAL	2N3904/TO18	-
Q27	+		NATIONAL	2N3906/TOI8	
Q28	250004			J175	2
Q29	230039	P-CHAN JEET	SILICONIX		^
Q30	230039	P-CHAN JEET	SILICONIX	J 175 J 112	
Q31	230038	N-CHAN JEET	SILICONIX		
<u>Q32</u> *	20/00/	N-CHAN J FET SEL SET	DATRON (SEE DRG)	JIOB (COLOUR)	I SET OF 4
Q33	230048	P- CHAN J FET	TELEDYNE	J174	2
Q34 *	239037-1	N-CHAN JET SEL SET	DATRON (SEE DRG)	J108 (COLOUR)	
Q3S 🗶 🗶	239037-1	N-CHAN JEET SEL SET	DATRON (SEE DRG)	JIOB (COLOUR)	-
Q36	230048	P. CHAN J FET	TELE DYNE	J174	-
Q37 *	239037-1	N-CHAN JET SEL SET	DATRON (SEE DRG)	JIOB (COLOUR)	
Q38	·	NOT USED			—
Q39		NOT USED			
Q40	250004	SI PNP	NATIONAL	2N3906/TO18	-
Q41	230031	N-CHAN DUAL JEET	TELEDYNE	SU2656M	4
Q42	230031	N-CHAN DUAL JET	TELEDYNE	SU2656M	
Q43	250004	SI PNP	NATIONAL	2N 3906/TO18	
Q44	230031	N-CHAN DUAL JET	TELEDYNE	SU2656M	-
Q45	240006	SINPN	NATIONAL	2N3904/TO18	
Q46	230042	N-CHAN CURRENT LIM. 3m	TELEDYNE	TCR SIO	2
	4 FETS MUST HAVE	THE SAME COLOUR CODIN		2.2.86 datron	DIVIDER
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IGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
47	230042	N-CHAN CURRENT LIM 3	MA TELEDYNE	TCR510	. — •
18	250021	SI PNP TRANSISTOR	MOTOROLA	BD140	
19	240031	SI NPN TRANSISTOR	MOTOROLA	BD139	A State of a
50		NOT USED			-
51	230031	N-CHAN DUAL JEET	TELEDYNE	SU2656M	
52	250004	SI PNP TRANSISTOR	NATIONAL	2N3906/TO18	— .
53	240006	SI NPN TRANSISTOR	NATIONAL	2N 3904/ TO 18	
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
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МІ	220027	HIGH CMR OPTO ISOL.	НР	HCPL-2601 (5082-4361)	7
M2		NOT USED			-
M3	220027	HIGH CMR OPTO ISOL	нР	HCPL- 2601 (5082-4361)	
M4	220017	2K5V DUAL OPTO ISOLATOR	FAIRCHILD	FCD 880	1
MS		NOTUSED			· _
MG	220027	HIGH CMR OPTO ISOL.	НР	HCPL-2601 (5082-4361)	-
M7	220027	HIGH CMR OPTO ISOL.	НР	HCPL- 2601 (5082-4361)	-
M8	220027	HIGH CMR OPTO ISOL.	НР	HCPL-2601 (5082-4361)	
M9	220027	HIGH CMR OPTO ISOL	нр	HCPL-2601 (5082-4361)	
MIO	280068	DUAL PRECISION MONOSTABLE	MOTOROLA	MC14538 BCP	1
МЛ	280037	HEX BUFFER	MOTOROLA	11C14050BCP	· I
M12	260025	IOI OP AMP	NATIONAL	L.MIOIAH	3
MI3	280011	DUAL-D FLIP. FLOP	MOTOROLA	MCI4013 BCP	2
M14-	280009	HEX INVERTER / BUFFER	MOTOROLA	MC14049 BCP	1
Mis	280089	8 BIT SHIFT REGISTER	MOTOROLA	MC14094 BCP	6
M16	260025	IOI OP AMP	NATIONAL	LMIOLAH	
M17		NOT USED			-
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
M18	280088	BBIT STATIC SHIFT REGISTER	MOTOROLA	MC14021BCP	2
MI9	280089	8 BIT STATIC SHIFT REGISTER	MOTOROLA	MC14094 BCP	-
M20	260025	101 OP AMP	NATIONAL	LMIOIAH	·
M21		NOT USED			
M22	280088	BBIT STATIC SHIFT REGISTER	MOTOROLA	MC14021 BCP	
M23	260027	714 OP AMP	FAIRCHILD	UA 714 HC	5
M24	280023	QUAD 21/P NOR GATE	MOTOROLA	MCI4001 BCP	1
M25	280089	8 BIT STATIC SHIFT REGISTER	MOTOROLA	MC 14 094 BCP	-
M26	260057	5534 OP AMP	SIGNETICS	NE 5534 N	2
M27	280089	BBIT STATIC SHIFT REGISTER	MOTOROLA	MC14094 BCP	
M28	260057	5534 OP AMP	SIGNETICS	NE 5534 N	
M29	290090	7X DARLINGTON DRIVER	SPRAGUE / EXAR	ULN2002A/XR2202CP	1
M30	280089	8 BIT STATIC SHIFT REGISTER	MOTOROLA	MC14094 BCP	-
M31	280089	BBIT STATIC SHIFT REGISTER		MCI4094 BCP	
M32	260027	714 OP AMP	FAIRCHILD	JIA 714 HC	
M33	260053	7650 OP AMP	INTERSIL	ICL7650CPD	2
M34	260027	714 OP AMP	FAIRCHILD	UA 714 HC	
M35	260027	714 OP AMP	FAIRCHILD	A 714 HC	
M36	280106	HEX LEVEL SHIFTER	MOTOROLA	MC14504 BCP	1
M37	280011	DUAL D FLIP FLOP	MOTOROLA	MC14-013 BCP	-
M38	260053	7650 OP AMP	INTERSIL	ICL7650 CPD	-
М39	260027	714 OP AMP	FAIRCHILD	A 714 HC	_
M40	220027	HIGH CMR OPTO ISOL.	HP	HCPL-2601 (5082-4361))
M4I	290149	CMOS 555 TIMER	INTERSIL	ICM7555 IPA	1
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DATE			AP	DIRAWING 40065	

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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
RLI	330030	RELAY 4P N/O	SDS	54 24 V	2
RL2	3300 30	RELAY 4P N/O	SDS	54 24 V	
RL3		NOT USED	· · · ·		
LI-L9	370001	100H O.85Q RF CHOKE	PLESSEY	58/10/0011/10	9
		· · · · · · · · · · · · · · · · · · ·			
TI-T5	310002-2	PULSE TX	NEWPORT	76616/4 HV	5
51	700070	SLIDE SWITCH , EXTRA HI. LEVE	RAPR	254.46A H6	1
	400452A-7	REF PCB ASSY			1
	410257-4	РСВ			1
	540002	225WG BTC WIRE			A/R
	590004	ØIO PTE SLEEVE			A/R
	602001	FSV TERMINAL	MOLEX	02-04-5114	14-
	605059	BWAY DIL. SOCKET			11
	605060	14 WAY DIL. SOCKET		· · ·	5
	605061	IG WAY DIL. SOCKET			13
······································	611016	SCREW M3X8mm STEEL POZI-P	AN ZINC PLATED GK	(N	2
	604053	4 WAY .I" PCB PLUG GD. PL	MOLEX	4030-04 AG (.825"PINS) 2
	612025-1	STANDOFF M3X5mm BRASS	DATRON	SEE DRAWING.	1
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	613029	M3 CRINKLE WASHER SS.			2
	630024	STANDARD STEATITE INS. BEAD	PARK ROYAL PORCELAIN CO	TYPE Nº2 (IGSWG)	16
	630118	CIRCUIT BOARD EJECTOR	RICHCO	CBE RED	2
	620007	TEST POINT TERMINAL	MICROVAR	C30	32
	630243		MANSOL (PREFORMS) LTD .	M5363B/3	46
	300004	SILICONE RUBBER COMPO		555 - 588	A/R.
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
RI	090014-2	50K .02% R ZppmR W.W.	MANN	AX175B	3
R2	090014-2	9K995 .02/R 2000 W.W	MANN	AX175B) I SET
R3		PART OF KIT DI-4 DG-9	MANN	AX175B	-
R4		PART OF KIT DI-4 DG-9	MANN	AX175B	•
R5	018251	8K25 1% 18W 50ppm MF	HOLCO	HBC	1
RG	000470	478 5% 1/4W CARBON	MULLARD	CR25	5
R7	070152	68R .1% 10ppm W.W	MANN	MX125	2
RB	070152	GBR .1% IDppm W.W	MANN	MX125	-
R9	070153	34R .1% 10ppm W.W.	MANN	MX125	2
RIO	070153	34R . 1% 10ppm W.W.	MANN	MXI25	-
RII	011698	16 R9 1% 18W 50ppm MF	HOLCO	HBC	2
RIZ	ପା <i>(</i> ତ୍ରେମ	16 R9 1% 1/8W 50ppm MF	HOLCO	HBC	-
RIB	050056	10R .25% /8w 50ppm MF	HOLCO	HBC	2
RIA	050056	10R .25% /8W 50ppm MF	HOLCO	HBC	-
R15	000438	4R3 5% 1/4W CARBON	MULLARD	CR25	2
RIG	000438	4R3 5% VAW CARBON	MULLARD	CR25	-
R17	018459	8R45 1% 1/8W 50ppm MF	HOLCO	HOC	2
RIB	018459	8845 1% 1/8W 50ppm MF	HOLCO	HBC	-
RID	090081	2K NTC THERMISTOR	RHOPDINT	MOB 202K	1
R20	006751	750R 2% IW MET.OX	ELECTROSIL	FPI	1
R21	000470	47R 5% YAW CARBON	MULLARD	CR25	-
R22	000222	2K2 5% YAW CARBON	MULLARD	CR25	1
	015231	5K23 1% /8W 50ppm MF	HOLCO	HBC	2

ECO REDARD 1367 1432 1445 1492 1685 1760 DATE 22.912 23.9142 1512 82 1512 83 7.6 831.8 84 15.11 84 DIRD MJD MJD MJD MJD MJD MJD MJD 400452 2 or 5 DATE 2.2.83. 7

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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
R24	090099-3	25 K)			1
R25	090099-3	IOK ATTEN SET	MANN	SEE DRG A4	I SET
R26	090099-3	IOK			J
R27	000125	IM2 5% 1/4 W CARBON	MULLARD	CR25	1
R28	012263	226K 1% 18W 50ppm MF		HBC	2
R29	063104	IOOK POT 3/8 50 CERMET	BECKMAN	72P	1
R30	012003	200K 1% 1/8W 50ppm MF	HOLCO	HBC	1
R31	015231	5K 23 1% 1/8W 50ppm MF	HOLCO	HBC	-
R32	012263	226K 1% 18W 50ppm MF	HOLCO	HBC	-
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFAC PART No.	FURER'S	No. USED Per Assy.
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CI	102470	470F 5% 500V CERDISC	177	CDIO		1
C2	102221	220pf 10% SOON CER DISC	177	CDIO		I
C3	104026	47 . F - 20% 500V CER DISC	SIEMENS	837449		
D1,2,3,4,6,7,8,9.	219015-4	GV2 X B ZENER + RESISTOR X 2	DATRON	INB29A	8 + AX1758 X 2.	1 KIT
D5	200008	200MA 125V LL SI DIODE	FAIRCHILD	IN458A		1
			··.			
aı	240006	SI NPN TRANSISTOR	NATIONAL	2N3904		2
Q2	240006	SI NPN TRANSISTOR	NATIONAL	2N3904		-
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MI	260025	IDI OP AMP	NATIONAL	LM IOI A	ч	
MZ	260027	714 OP AMP	FAIRCHILD	MATIAH		1
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12 605085 4 WAY PCB SOCKET MOLEX 22-17-2042 410162-6 PRINTED CIRCUIT BOARD	1 2 -
J2 605085 9 way PCB SOCKET MOLEX 22-17-2042 410162-6 PRINTED CIRCUIT BOARD	
12 605085 4 WAY PCB SOCKET MOLEX 22-17-2042 410162-6 PRINTED CIRCUIT BOARD	
12 605085 4 WAY PCB SOCKET MOLEX 22-17-2042 410162-6 PRINTED CIRCUIT BOARD	
450372-3 HEATSINK BLOCK 450373-3 HEATSINK PLATE 540002 22 swg tinned copper wire Gli004 M3xGmm Pozipan Steel Gli007 M3xGmm Pozicićk Steel	1
450373-3 HEATSINK PLATE 540002 22 SWG TINNED COPPER WIRE GIIO04 M3XGwm POZIPAN STEEL ZN PL GII007 M3XGwm POZI-CSK STEEL ZN PL	1
450373-3 HEATSINK PLATE 540002 22 SWG TINNED COPPER WIRE GIIO04 M3XGwm POZIPAN STEEL ZN PL GII007 M3XGmm POZI-CSK STEEL ZN PL	
540002 22 SWG TINNED COPPER WIRE 611004 M3xGww Pozipan Steel 011007 M3xGww Pozipan Steel	<u> </u>
GIIOOA M3XGww POZIPAN STEEL ZN PL GIIOO7 M3XGww POZICSK STEEL ZN PL	
GIIOO7 M3xGmm POZICSK STEEL ZN PL	<u>A/R</u>
	2
	2
GIO 37 M3X8mm HEX NYLON SCREW	1
GI3029 M3 CRINKLE WASHER SS	2
900003 HEATSINK COMPOUND R5 554-311	A/R

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DESIGNATOR	DATRON , PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
RI	000274	270k 5% Yow CARBON			2
R2	000 472	4k7 5% /3W CARBON			3
R3	000274	270k 5% 1/3W CARBON			-
R4	160610	9k09 1% 18W 50ppm MF	HOLCO	HBC	3
R5	011002	ICKO 1% 'BW 50ppm MF	HOLCO	HBC	3
RG	000472	4K7 5% '3W CARBON			-
R7	014 992	49k9 1% 18W 50ppm MF	HOLCO	H8C	1
R8	012212	22k1 1% 18W 50ppm MF	HOLCO	H8C	1
R9	014322	43K2 1% YOW 50ppm MF	HOLCO	H8C	1
RIO	012742	27k4 1% '8W 50ppm MF	HOLCO	HBC	3
RII	012742	27k4 1% Yaw 50ppm MF	HOLCO	H8C	-
RIZ	000133	13k 5% /3W CARBON			2
RIB	012742	27K4 1% 18W 50ppm MF	HOLCO	HBC	-
RI4	000105	IM 5% YOW CARBON			2
RIS	041005	10MO 1% 1/2W 100ppm CF	ALLEN BRADLEY	CC	10
RIG	041005	10MO 1% YZW 100ppm CF	ALLEN BRADLEY	CC	-
R17	090157-1	GM ATTEN. SET		SEE DRG	J ···
R18	000105	IM 5% VOW CARBON			-
RIS	000244	240K 5% VOW CARBON		,	1
RZO	000104	100k 5% "3W CARBON			4
R21	000103	IOK 5% 1/3W CARBON			5
R22	000164	IGOK 5% 1/3W CARBON			1
R23	000104	100k 5% /3W CARBON			-
NOTES. SEE SHEET 2 FOR L		, ,			
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DESIGNATOR	DATRÒN PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFAC PART No.		No. USED Per Assy.
R24	000104	100k 5% 'SW CARBON				-
R25	041005	IOMO 1% YOW LOOPPM CF	ALLEN BRADLEY	CC		_
R26	041005	IOMO 1% YOW IOOPPM CF	ALLEN BRADLEY	CC		·
R27	090157-1	GM ATTEN. SET		SEE DI	୧ଜ	
R28	090159-1	IK/IIIRII ATTEN SET		SEE DI	ଽୢ	1
R29		NOT USED				~
R30	045623	562k 1% 18W 50ppm MF	ALLEN BRADLEY	CC		2
R31	017500	750R1% /8W 50ppm_ MF	HOLCO	НВС		1
R32	045623	562k 1% YOW 50ppm MF	ALLEN BRADLEY	CC		-
R33	013161	3k16 1% 18W 50ppm MF	HOLCO	H8C		2
R34	000153	15K 5% Yaw CARBON				2
R35	000153	15k 5% 1/3W CARBON				
R36	000472	4K7 5% /3W CARBON				
R37	011001	IKOO 1% VOW SOPPM MF	HOLCO	HBC		2
R38	011001	1k00 1% 18W 50ppm MF	HOLCO	HBC		-
R39	013161	3ki6 1% YOW SOPPM MF	HOLCO	HBC		-
R40	000272	2k7 5% 'SW CARBON			×	1
R41	000273	27K 5% 3W CARBON				1
R42	000155	IM5 5% YOW CARBON				1
R43	041005	10M0 1% 12W 100ppm CF	ALLEN BRADLEY	cc		-
R44	041005	IOMO 1% V2W 100ppm CF	ALLEN BRADLEY	CC		-
R45	090157-1	GM ATTEN SET		SEE DR	20	
R46	000103	IOK 5% "BW CARBON				
NOTES.	TEST ISSUE			25.2.86	datron	ELECTRONICS LTD
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
R47	000202	2ko 5% /3W CARBON			2
R48	000183	18k 5% /3W CARBON			1
R49	011651	1k65 1% 18W 50ppm MF	HOLCO	H8C	1
R 50	011002	IOK 1% YOW SOPPM MF	HOLCO	H8C)
R51	018450	845R 1% 18W 50ppm MF	HOLCO	H8C	1
R52	012.002	ZOK 1% YOW SOPPM MF	HOLCO	H4C	1
R53	012491	2k49 1% 18W 50ppm MF	HOLCO	H8C	1
R54	000202	2ko 5% /3W CARBON			
R55	015611	2k61 1% 18W 50ppm MF	HOLCO	H&C	1
R56	011008	IORO 1% VOW SOPPM MF	HOLCO	H8C	1
R57	000104	100k 5% VOW CARBON			
R58	000102	IK 5% "3W CARBON			2
R59	012261	2k26 1% VBW 50ppm MF	HOLCO	H8C	2
R60	012261	2k26 1% 1/8W 50ppm MF	HOLCO	H8C	-
R61	017501	7k50 1% 18W 50ppm MF	HOLCO	H8C	1
R62	011002	IOKO 1% VBW 50ppm MF	HOLCO	H8C	`
R63	018251	8k25 1% 18W 50ppm MF	HOLCO	H8C	1
R64	046813	681k 1% 1/2W 100ppm CF	ALLEN BRADLEY	CC	2
R65	012211	2k21 1% 18W 50ppm MF	HOLCO	H8C	2
R66	000683	68k 5% V3W CARBON			2
R67	008067	IOOR 5% IW MF	VISHAY	5105K	1
R68	017321	7k32 1% 18W 50ppm MF	HOLCO	H8C	1
R69	012211	2K21 1% YOW SOPPM MF	HOLCO	HBC	-
NOTES.	ATEST ISSUE			DATE 25. 2. 86 DRAWN TITLE	
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
R70	046813	681k 1% 12W 100ppm CF	ALLEN BRADLEY	CC	
R71	000683	68K 5% YOW CARBON			
R72	000470	47R 5% "3W CARBON			2
R73	000330	33R 5% 'SW CARBON			11
R74	041005	10MO 1% Yew 100ppm CF	ALLEN BRADLEY	CC	-
R75	041005	10MO 1% VEW 100ppm CF			
R76	090157-1	GM ATTEN. SET		SEE DRG	
R77	012091	9k09 1% 18W 50ppm MF	HOLCO	HBC	-
R78	000470	47R 5% YOW CARBON			
R79	000562	5k6 5% YOW CARBON			1
R80	000391	390R 5% YOW CARBON			1
R81	000222	2k2 5% 1/3W CARBON			1
R82	000133	13k 5% 1/3W CARBON			
R83	050059	IM5 1% ZW 100ppm MF	HOLCO	HBO3RE	1
R84	013011	3KOI 1% BW 50ppm MF	HOLCO	HBC	1
R85	090157-1	IM MATCHED SET		SEE DRG	
R86	041005	10MO 1% YZW 100ppm CF	ALLEN BRADLEY	CC	
R87	000913	91K 5% YOW CARBON			1
R88	000912	SKI 5% "3W CARBON			!
R89	000102	IK 5% YOW CARBON			
R90	041005	10M 1% 12W 100ppm CF	ALLEN BRADLEY	CC	-
R9I	012001	2 koo 1% Vaw 50ppm MF	HOLCO	H8C	2
R92	000393	39k 5% YOW CARBON			2
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DESIGNATOR	DATHON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURE PART No.	ER'S No. USED Per Assy.
R93	000152	IKS 5% YOW CARBON			1
R94	011302	13ko 1% /8W SOPPM MF	HOLCO	HBC	2
R95	000103	IOK 5% YOW CARBON			
R96	000103	IDK 5% "3W CARBON			-
R97	100000	PTC THERMISTOR	MULLARD	VA8650	€. , I
R98	012008	20RO 1% VOW 50ppm MF	HOLCO	HBC	
R99	041825	18M2 1% 12W 100ppm MF	ALLEN BRADLEY	cc	1
RIDO	041824	1M82 1% 1/2W 100ppm MF	ALLEN BRADLEY	CC	1
RIOI	090157-1	GM ATTEN SET (1000)		SEE DRG	-
RIOZ	012001	2K00 1% 18W 50ppm MF	HOLCO	HBC	
RIO3	011302	13KO 1% YOW SOPPM MF	HOLCO	HBC	
R104	000393	39k 5% 1/3W CARBON			-
R105	000473	47K 5% YOW CARBON			2
R106	000473	47K 5% YOW CARBON		•	
R107	050062	51RO 1% IW 250ppm M.O.	WELWYN	MRG	
R108	021820	182R 1% 1/4W 50ppm MF	Holco	H4C	1.
RIOS	000512	5ki 5% "3W CARBON			2_
RIIO	000512	5ki 5% 1/3W CARBON			-
RIII	011000	IOOR 1% YOW SOPPM ME	HOLCO	HBC	2
R112	011000	IOOR 1% YOW 50ppm MF	HOLCO	н8с	. –
RII3	019091	9KO9 1% VOW 50ppm MF	HOLCO	HBC	-
R114	011002	loko 1% 18W 50ppm MF	HOLCO	HBC	-
R115	019092	90k9 1% 18W 50ppm MF	HOLCO	H8C	1
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFAC PART No.	TURER'S	No. USED Per Assy.
RIIG	000103	IOK 5% Y3W CARBON				-
R117	000681	680R 5% "3W CARBON				2
R118	001121	120R 5% 1/2W CARBON				2
RIIS	000681	680R 5% V3W CARBON				-
R120	001121	120R 5% 1/2W CARBON				-
R121	000221	220R 5% "3W CARBON				1
R122	090158-1	90K OK ATTEN SET				1
R123	000474	470k 5% '3W CARBON				
Ani Anz Anz	090096 090096 090096 090142	IM ×8 2% NETWORK IM ×8 2% NETWORK IM ×8 2% NETWORK IOK ×4 0.5% DIL NETWORK	BECKMAN BECKMAN BECKMAN	Log-1- Log-1- 694-3	RIM	2 1
\N4	090105	100R × 4 2% NETWORK	BECKMAN	L08-3-	- R100	
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFAC PART No.	TURER'S	No. USED Per Assy.
CI	110042	100nF 20% 63V POLYESTER	WIMA	MKSZ		5
C2	110042	100 nF 20% 63V POLYESTER	WIMA	MKSZ		
СЗ	100330	33 PF 2% LOOV CER PLATE	MULLARD	2222	683 34339	2
C4	104026	470F + 20% 50V CER DISC	SIEMENS	B3744	9	17
C5	100 330	33pf 2% 100V CER PLATE	MULLARD	2222	683 34339	
C6	104026	47 .F -20% 50V CER DISC	SIEMENS	B3744	3	-
C7	104026	47 nF + 20% 50V CER DISC	SIEMENS	B3744 9	>	-
C8	104026	47 nF + 50% 50V CER DISC	SIEMENS	8374.4	>	-
C9	104026	47 nF 1 20% SOV CER DISC	SIEMENS	B3744	3	-
CIO	180021	3, 3F G3V AL. ELEC.	MULLARD	015-183	38	2
CII	180021	JUSF 63V AL. ELEC.	MULLARD	015-183	38	-
C12	104026	470F -20% 50V CER DISC	SIEMENS	B3744	9	
СІЗ	104026	47 nF + 58% SOV CER DISC	SIEMENS	B3744	9	-
C14	150016	JUF 20% 35V DIP TANT	UNION CARBIDE	KIRE35	-	2
C15	100101	100pf 2% 100V CER PLATE	MULLARD	2222-	683-34101	2
C16	110042	100 nF 20% GBV POLYESTER	WIMA	MKSZ		-
C17	110050	22 F 10% 63V POLYESTER		MK52		1
C18	104026	47 nF +50% 50V CER DISC	SIEMENS	B3744	9	
CIS	104026	47 AF - 20% 50V CER DISC	SIEMENS	B3744	3	-
C20	104026	47 oF + 50% 50V CER DISC	SIEMENS	B3744	2	-
C21	110035	220 F 20% 63V POLYESTER	WIMA	MKSZ		3
C22	104026	47 F - 20% 50V CER DISC	SIEMENS	B37449	3	
C23	150023	33,0F 20% 25V DIP TANT		K33E2	5	4
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACT PART No.	URER'S	No. USED Per Assy.
C24	104026	47 NF -20% 50V CER DISC	SIEMENS	B37449		-
C25	150023	33, F 20% 25V DIP TANT	UNION CARBIDE	K33E25	5	-
C26	150020	IONE 20% 25V DIP TANT	UNION CARBIDE	K10E25		2
C27	150020	10,0F 20% 25V DIP TANT	UNION CARBIDE	KIOE25		
C28	110055	68 .F 10% 100V POLYESTER	WIMA	MKS4		1
C29	100390	39 PF 2% IOOV CER PLATE	MULLARD	2222 683	3 34339	1
C30	120014	2µ2F 20% 63V POLYCARB	ASHCROFT	A2B		1
C31	100560	56PF 2% IOOV CER PLATE		2222 6	83 34569	1
C32	104026	47nF 128% 50V CER DISC	SIEMENS	B37449		-
C33	150023	33 UF 20% 25V DIP TANT		K33E25		
C 3 4	104026	47nF + 20% 50V CER DISC	SIEMENS	B37449		
C35	150023	33,0F 20% 25V DIP TANT	UNION CARBIDE	K33E25		
C36	104026	47 NF 120% 50V CER DISC	SIEMENS	B37449		-
C37	104026	47 F 18% 50V CER DISC	SIEMENS	B3744 9		
C38	104026	47 nF 1 28% 50V CER DISC	SIEMENS	B37449		
C39	101 103	10nf 25% 250V CER DISC	ТТ	CDIO		<u> </u>
C40	110049	68nf 10% 630V POLYESTER	WIMA	MKS4		1
C41	100101	100pf 2% 100V CER PLATE	MULLARD	2222-6	83-34101	
C42	110051	470 F 10% 63V POLYESTER	WIMA	MKSZ		1
C43	100391	390pf 10% 100V CER PLATE	MULLARD	2222-6	30-19391	
C44	100221	220pf 2% 100V CER PLATE	MULLARD	2222-6	83-58221	I
C45	100471	470pf 10% 100V CER PLATE	MULLARD	222-63	50- 19471	<u> </u>
C46	110042	100nf 20% 63V POLYESTER	WIMA	MKS2		
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFA PART No.	TURER'S	No. USED Per Assy.
C47	110035	220nF 20% 63V POLYESTER	WIMA	MKSZ		-
C48	110035	220nF 20% 63V POLYESTER	WIMA	MKS2		-
C49	130086	30nf 1% 63V POLYSTY RENE	MULLARD	424 4	3 <i>0</i> 03	1
C50	150016	INF 20% 35V DIP TANT	UNION CARBIDE	KIRE 35		
C51	110042	100nf 20% 63V POLYESTER	WIMA	MKSZ		
C52	110039	470nF 20% 63V POLYESTER	WIMA	MKS2		4
C53	110039	470nF 20% 63V POLYESTER	WIMA	MKS2		-
254	110039	470nf 20% 63V POLYESTER	WIMA	MKSZ		
C55	110039	470nF 20% 63V POLYESTER	WIMA	MKS2		-
C56	120036	470pf 20% 160V POLYCARB	WIMA	FKC 3		1
C57	100220	22pf 2% 100V CER PLATE	MULLARD	2222-	683-34229	· 1
258	150001	22 JF 20% IGV DIP TANT	UNION CARBIDE	K22E K	5	2
C59	150001	2245 20% IGV DIP TANT	UNION CARBIDE	K22E10	,	-
C60	150002	10µF 20% 16V DIP TANT	UNION CARBIDE	KIDEIE		2
C61	150002	104F 20% IEV DIP TANT	UNION CARBIDE	KIDEIG		
C62	104032	220pf 10% 2KV CER DISC	דדו	HD09		1
C63	110026	GABE 20% IOOV POLYESTER	WIMA	FKS2		<u> </u>
C64	102472	4.7F 25% 500V CER DISC	ТТ	CDIO		
265	104045	14F 780% 50V CER PLATE	MULLARD	62300	105 Z	2
666	104045	HF 788% 50V CER PLATE	MULLARD	C 7 300	105 2	-
567	100270	27pF 2% 100V CER PLATE	MULLARD	2222-0	83-34279	<u>·</u> 1
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFAC PART No.	TURER'S	No. USED Per Assy.
DI	213009	15V 5W ZENER	UNITRODE	TVS515		3
D2	213009	15V SW ZENER	UNITRODE	TVS515	· · · · · · · · · · · · · · · · · · ·	
D3	200001	75mA 75V GP SI DIODE	FAIRCHILD	IN4148		10
D4	213006	5V 5W ZENER	UNITRODE	TVS505		4
D5	213006	5V 5W ZENER	UNITRODE	TVS 505		-
6	200001	75mA 75V GP SI DIODE	FAIRCHILD	IN4148		
07	200001	75mA 75V GP SI DIODE	FAIRCHILD	IN4 148	•	-
D8	213009	15V 5W ZENER	UNITRODE	TVS515		-
09	200001	75 mA 75V GP Si DIODE	FAIRCHILD	IN4148		
DIO	200001	75mA 75V GP SI DIODE	FAIRCHILD	IN4148		
DII	213006	SV SW ZENER	UNITRODE	TVS 505		
DI2	213006	SV SW ZENER	UNITRODE	TVS 505		-
DIB	213025	3V3 5W ZENER	SIEMENS	IN5333	в	2
D14	210033	3V3 400mW ZENER	MULLARD	BZY880	C3V3	3
DIS	200001	75mA 75V GP SI DIODE	FAIRCHILD	IN414	8	-
D16	200001	75mA 75V GP SI DIODE	FAIRCHILD	IN414	8	-
D17	214014	IV22 100ppm ZENER	TELEDYNE	949I B	ז	6
D18	214014	IV22 100 ppm ZENER	TELEDYNE	9491 B	J	
DIG	213008	24V 5W ZENER	UNITRODE	TVS524		2
D20	213008	24V 5W ZENER	UNITRODE	TVS524		-
D21	200002	1A SOV GP SI DIODE	FAIRCHILD	IN 400		12
022	200002	IA SOV GP SI DIODE	FAIRCHILD	IN4001		-
D23	200002	IA SOV GP SI DIODE	FAIRCHILD	IN400		-
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFAC PART No.	TURER'S	No. USED Per Assy.
D24	200002	1A 50V GP SI DIODE	FAIRCHILD	IN4001		
D25	213025	3V3 5W ZENER	SIEMENS	IN5333	в	
D26	214014	IV22 100ppm ZENER	TELEDYNE	94918	J	
D27	214014	IV22 100ppm ZENER	TELEDYNE	9491 B	J	
028	200001	75mA 75V GP SI DIODE	FAIRCHILD	IN4148		
029	200001	75mA 75V GP SI DIODE	FAIRCHILD	IN4148	\$	
030	213011	IVS 250mW ZENER	MULLARD	BZV46-	175	1
D31	213001	IOV SW ZENER	MOTOROLA	IN 5347	B	1
D32.	200002	IA SOV GP SI DIODE	FAIRCHILD	IN400	l	-
D33	200002	IA SOV GP SI DIODE	FAIRCHILD	IN400		
D34	200002	IA SOV GP SI DIO DE	FAIRCHILD	1N4001		
035	200002	IA SOV GP SI DIODE	FAIRCHILD	1N4001		
D36	210033	3V3 400mW ZENER	MULLARD	BZY88C	3V3	
D37	210033	3V3 400 mW ZENER	MULLARD	BZY88C	31/3	
D38	200008	200mA 125V LL SI DIODE	FAIRCHILD	IN458A		2
039	200008	200mA 125V LL SI DIODE	FAIRCHILD	IN4584		
D40	214014	IV22 100ppm ZENER	TELEDYNE	949IB	נ	·····
D41	214014	1V22 100ppm ZENEP	TELEDYNE	949IB	T	
042	220020	FET DIODE 100PA IR	TELEDYNE	PADIOO	·	2
043	220020	FET DIODE 100PA IR	TELEDYNE	PADIOO		
D44	200002	IA SOV GP SI DIODE	FAIRCHILD	IN4001		-
045	200002	IA SOV GP SI DIODE	FAIRCHILD	IN4001		-
046	200002	IA SOV GP SI DIODE	FAIRCHILD	IN4001		-
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ESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER		MANUFACT	URER'S	No. USED Per Assy.
)47	200002	IA SOV GP SI DIODE	FAIRCHILD		IN4001		
48	210062	GV2 400mW ZENER	MULLARD		BZY88C	612	2
49	210062	GV2 400mW ZENER	MULLARD		BZY88CG	6V2	
>50	210047	4V7 400mW ZENER	MULLARD		BZY88C4	4√7	2
>51	210047	4V7 400mW ZENER	MULLARD		BZY88C	4V7	-
)52	200001	75mA 75V GP SI DIODE	FAIRCHILD		IN4148		-
							1
			-				
					,		
21	230036B	N-CHAN JFET	SILICONIX		J108		1
22	230042	N-CHAN I LIM 3.0 mA	SILICONIX		J509		2
<u>3</u> 3	230042	N-CHAN I LIM 3.0 m A	SILICONIX		J509		-
Q4	240001	SI NPN TRANSISTOR	NATIONAL		BC184/T	018	I
Q5	230031	N-CHAN DUAL JEET	TELEDYNE		U404		2
Q6	240018	SI NPN TRANSISTOR	MOTOROLA		MJE 34	0	1 .
Q7	250025	SI PNP TRANSISTOR	MOTOROLA		MJE 350		1
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No. USED DESIGNATOR DATRON DESCRIPTION PRINCIPAL MANUFACTURER MANUFACTURER'S PART No PART No. Per Assy. J506 2 Q8 N-CHAN I LIM 1.4 mA 230001 SILICONIX J506 Q9 230001 SILICONIX N-CHAN I LIM 1.4 mA U404 -230031 QIO SILICONIX N-CHAN DUAL JEET I 260086 DUAL 2W AUDIO AMP NATIONAL LM1877N MI 5532 DUAL OP AMP 3 SIGNETICS <u>M2</u> 260042 NE5532N QUAD 2 1/P OR MOTOROLA MЗ 280023 MC14001 UBCP 1 TRIPLE 3 1/P NOR I M4 MCI4025BCP 280045 MOTOROLA 2 M5 QUAD 2 1/P OR MCI407IBCP 280079 MOTOROLA MG MC14028 BCP 280035 BCD/DECIMAL DECODER MOTOROLA I M7 _ NOT USED -NOT USED M8 NOT USED _ M9 MIO 280079 QUAD 2 1/P OR MOTOROLA MC14071 BCP t MII 280009 HEX INVERTER MOTOROLA MCI4049UBCP MIZ 280034 DUAL MONOSTABLE MOTOROLA MC 14528 BCP 1 MI3 2903 DUAL COMPARATOR NATIONAL LM2903N I 260075 M14 5532 DUAL OP AMP NE 5532N 260042 SIGNETICS -MI5 260042 5532 DUAL OP AMP SIGNETICS NE 5532N ----MIG 260073 411 OP AMP NATIONAL LF411CN 1 MI7 260049 319 DUAL COMPARATOR NATIONAL LM3I9N 1 NOTES. DATE 25.2.86 SEE SHEFT 2 FOR LATEST ISSUE ISS ECO DATE CHPD CHECKED 4700 DC.PCB. ASSY

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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
M18	260080	311 COMPARATOR	NATIONAL	LM3IIN	1
MIS	220027	HIGH CMR OPTO ISOLATOR	HP	HCPL-2601 (5082-	4361) 1
M2Ò	260027	714 OP AMP.	FAIRCHILD	A 714 HC مىر	
MSI	260082	IOSE OP. AMP.	LINEAR TECH.	LTC IOS2 CN8	1
M22	260081	5534A OP. AMP.	SIGNETICS	NE5534AN	1
M23	260059	OCO2 BUFFER AMP	NATIONAL	LH0002CH	1
			-	· · · · · · · · · · · · · · · · · · ·	
RLI	330040	RELAY IP 2W	SDS	DSIE-SL-GV	5
RL2_	330039	RELAY 4P NO	SDS	S4-L-6V	6
RL3	330040	RELAY IP 2W	SDS	DSIE -SL-GV	
RL4	330039	RELAY 4P NO	SDS	54-L-6V	
RL5	330041	RELAY 2P 2W	SDS	DS2E-SL-GV	2
RL6	3300 4 1	RELAY 2P ZW	SDS	DSZE -SL-GV	
RL7	330039	RELAY 4P NO	SDS	54-L- 6V	
RL8	330042-2	RELAY 3P NO; IP NC		SEE DRG	<u> </u>
RLO	330038	RELAY 2P NO	SDS	52-L-6V	3
RLIO	330039	RELAY 4P NO	SPS	54-L-6V	
RLII	330039	RELAY 4P NO	SDS	S4-L-6V	
RL12	330040	RELAY IP 2W	SDS	DSIE-SL-6V	-
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUF/ PART No	ACTURER'S o.	No. USED Per Assy.
RLI3	330040	RELAY IP 2W	SDS	DSIE-	SL-6V	-
RL14	330038	RELAY 2P NO	SDS	52-L-	6V	
RL15	330030	RELAY 4P NO	SDS	54-2	4V	
RLIG	330038	RELAY 2P NO	SDS	51-L-	õV	-
RLI7	330040	RELAY IP ZW	SDS	DSIE -S	5L-6V	-
2118	330039	RELAY 4P NO	SDS	\$4-L	-61/	-
					,	
_1	370001	OUH 0.85 & RF CHOKE	PLESSEY		10011/10	7
_2	370001	IOUH O.85 JU RF CHOKE	PLESSEY		10011/10	
∟3	370001	10,0 H O.85 JZ RF CHOKE	PLESSEY	58/10	10011 10	
_4	370001	IOH O.85 SO RE CHOKE	PLESSEY		10011/10	
L5	370001	IONH O.85 SRF CHOKE	PLESSEY	58/10	10011/10	
LG	370012	470 H 0.1 & RF CHOKE	SIGMA	SCIO		1
L7	370001	IOUH 0.85 & RF CHOKE	PLESSEY		0011 10	-
L8	370001	100H 085 S RF CHOKE	PLESSEY	58/10/	10011/10	-
WI	209003	IAS 100V BRIDGE RECT.	MICRO-ELECTRONIC	s woo	1	
<u> </u>	209003	TAS TOOY BRIDGE RECT.	MICRO-ELECTRONIC	3 100	•	
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
					5
FI	920120	FUSE IA 125V 7mm	LITTLEFUSE	275-001	
-2	920190	250mA PIGTAIL FUSE	BESWICK	TDC 483	
F3	920120	FUSE IA 125V 7mm	LITTLEFUSE	275-001	
-4	920120	FUSE IA 125V 7mm	LITTLEFUSE	275-001	
-5	920120	FUSE IA 125V 7mm	LITTLEFUSE	275-001	
F6	920120	FUSE IA 125V 7mm	LITTLEFUSE	275-001	-
	400668-1	CLAMP PCB ASSY	DATRON		
	410258 - 2	PCB			<u> </u>
	540002	22 SWG BTC WIRE			A/R
	604046	3WAY .I" PCB PLUG GD PL	MOLEX	22-10-2031	6
	605059	BWAY DIL SOCKET	JERMYN	J23-18008	9
	605060	14 WAY DIL SOCKET	JERMYN	J23-18014	6
	605061	IG WAY DIL SOCKET	JERMYN	J23-18016	3
	605127	2 WAY .I" SHORTING SKT	ASSMANN	AKSPL-G	6
	602001	FSV TERMINAL	MOLEX	02-04-5114	2
	620007	TEST POINT TERMINAL	MICROVAR	TYPE C30	21
	630024	STEATITE BEAD IS SWG-	PARK ROYAL PORCELAIN	Nº2 LARGE	68
	630036	STEATITE BEAD 18 SWG-	PARK ROYAL PORCELAIN	Nº I SMALL	26
	630119	PCB EJECTOR ORANGE	RICHCO	CBE	2
	605070	20 WAY DIL SOCKET	JERMYN	J23-18020	3
	620006	SOLDER TURRET	HARWIN	H9001-01	10
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
	512.999	7/2 PTFE INS. WIRE WHI	<u> </u>		A/R
	590007	LACING CORD		MW/062 BLACK	A/R
* .					
	618004	MOUNTING PAD TOIS	JERMYN	TO18-008D	2
	900004	SILICONE RUBBER COMP.	RS	555-588	A/R
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
RI	019091	9k09 1% 1/8W 50ppm MI	HOLCO	HBC	1
RZ	011821	1k82 1% /8W 50ppm MI		H&C	
R3	012151	2k15 1% 18W 50ppm M	Holco	H8C	1
R4	012611	2kG1 1% /8W 50ppm M		H8C	1
R5	000 223	22k 5% /3W CARBON	MULLARD	CR25	1
RG	000222	2k2 5% /3W CARBON	MULLARD	CR25	1
R7	011502	15k 1% 18W 50ppm Mf	HOLCO	H8C	1
R8	014321	4k32 1% 1/8W 50ppm Mf	HOLCO	HBC	2
R9	011002	lok 1% VOW SOPPM MI		H8C	7
RIO	000100	IOR 5% 1/3W CARBON	MULLARD	CR25	6
RII	000101	IOOR 5% /3W CARBON	MULLARD	CR25	10
RIZ	000470	47R 5% 1/3W CARBON	MULLARD	CR2S	9
RIS	013012	30k1 1% 1/8W 50ppm MF	Holco	H8C	1
RI4	000272	2k7 5% /3W CARBON	MULLARD	CR25	2
RI5	000103	IOK 5% V3W CARBON	MULLARD	CR25	8
RIG	000228	2R2 5% 1/3W CARBON	MULLARD	CR25	1
R17	000100	IOR 5% 1/3W CARBON	MULLARD	CR25	-
R18	000152	IK5 5% V3W CARBON	MULLARD	CR25	4
RIS	000472	4k7 5% 1/3W CARBON	MULLARD	CR2S	4
R20	000103	IOK 5% 1/3W CARBON	MULLARD	CR25	-
R21	000103	IOK 5% 1/3W CARBON	MULLARD	CR25	-
R22	000123	IZK 5% "3W CARBON	MULLARD	CR25	1
R23	000122	IK2 5% "JW CARBON	MULLARD	CR25	2
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ESIGNATOR	DATRON PART No.	DESCRIPTION		PRINCIPAL MANUFACTURER	MANUFAC PART No.	TURER'S	No. USED Per Assy.
24	000332	3k3 5% 1/3	W CARBON	MULLARD	CR25	1	1
25	000102	lk 5% %	W CARBON	MULLARD	CR25		5
26	000272	2k7 5% 1/	W CARBON	MULLARD	CR25		-
27	011001	1k 1% 181	N 50ppm MF	Holco	H8C		2
28	012001		N SOPPM MF	HOLCO	H8C		. 1
29	011001	lk 1% 1/8	W 50ppm MF	HOLCO	H8C		
30	047153	715k 1% 1/2V		ALLEN BRADLEY	cc		2
31	013573	357k 1% 181	N SOppm MF	HOLCO	H8C		2
32	011783	178k 1% 18	W 50ppm MF	HOLCO	HBC		2
33	018872	88k7 1% 18	W 50ppm MF	HOLCO	H8C		2
34	014422	44k2 1% 18	W 50ppm MF	HOLCO	H8C		2
35	012262	22k6 1% 1/8	W SOPPM MF	HOLCO	H8c		2
36	011132	11K3 1% 1/8		HOLCO	H8C		2
37	015621	5k62 1% 18	W 50ppm MF	HOLCO	HBC.		2
38	012801	2k8 1% 1/8	W SOPPM MF	HOLCO	HBC		2
39	000152	1k5 5% 1/3	W CARBON	MULLARD	CR25		-
40	000152	lk5 5% 1/3	W CARBON	MULLARD	CR25		-
41		FSV (PART	OF KIT WITH Q29				-
42	000103	10k 5% 1/3	W CARBON	MULLARD	CR25		-
43	000103	lok 5% 1/3	W CARBON	MULLARD	CR25		-
44	000102	ik 5% 1/3	W CARBON	MULLARD	CR25		-
45	000102	lk 5% 1/3	W CARBON	MULLARD	CR25		
46	000331	330R 5% 1/3	W CARBON	MULLARD	CR25		2
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DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
001182	1k8 5% 1/2W CARBON	MULLARD	CR37	2
011823	182k 1% 1/8W 50ppm MF	HOLCO	H8C	I
067503	50k POT 20 TURN CERMET	BECKMAN	68X	2
067503	50k POT 20 TURN CERMET	BECKMAN	68x	-
014990	499R 1% 18W 50ppm MF	HOLCO	HBC	2
063100	IOR POT 3/8 SQ CERMET	BECKMAN	72P	1
014751	4k75 1% 1/8W 50ppm MF	HOLCO	HBC	3
012218	22R1 1% 1/8W 50ppm MF	HOLCO	H8c	1
047153		ALLEN BRADLEY	cc	-
013573		HOLCO	HBC	-
011783	178k 1% 18W 50ppm MF	HOLCO	H8C	
018872	88k7 1% 18W 50ppm MF	HOLCO	H8C	-
014422		Holco	HBC	-
012262		Holco	H8C	-
011132		HOLCO	H8C	
015621	5k62 1% 1/8W 50ppm MF	Holco	HBC	-
012801	2k8 1% 18W 50ppm MF	HOLCO	HBC	- 1
013321	3k32 1% YOW 50 PPM MF	HOLCO	HBC	2
013321			HBC	-
000103		MULLARD	CR25	-
second		MULLARD	CR25	
and the second s		HOLCO		-
the second		HOLCO	HBC	
		[DA1	F 1	
	•		4.7.84 datror	ELECTRONICE LTD
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	PART No. OOII 82 OII 823 O6 7503 O6 7503 O6 7503 O14 990 O63100 O14751 O12218 O47153 O13573 O11783 O18872 O14422 O12262 O11132 O15621 O1321 O13321 O13321 O13321 O00103 O0102	PART No. Ik8 5% % W CARBON 001182 Ik8 5% % CARBON 011823 182k 1% % W SOppm MF 067503 50k POT 20 TURN CERMET 067503 50k POT 20 TURN CERMET 014990 499R 1% % W SOppm MF 063100 IOR POT % SQ CERMET 014751 4k75 1% % W SOppm MF 012218 22RI 1% % W SOppm MF 013573 357k 1% % W SOppm MF 013573 357k 1% % W SOppm MF 014422 44k2 1% % W SOppm MF 012802 22k6 1% % W SOppm MF 012262 22k6 1% % W SOppm MF 013221 5k62 1% % W SOppm MF 012262 22k6 1% % W SOppm MF 013321 3k32 1% % W SOppm MF 013321 3k32 1% % W SOppm MF 000103 10k 5% % W SOppm MF 0013321 3k32 1% % W SOppm MF 00102 10k 1% SOppm MF	PART No. MANUFACTURER 001182 1k85% ½W CARBON MULLARD 011823 182k 1% ¼8W 50ppm MF HOLCO 067503 50k POT 20 TURN CERMET BECKMAN 067503 50k POT 20 TURN CERMET BECKMAN 067503 50k POT 20 TURN CERMET BECKMAN 014990 499R 1% ¼8W 50ppm MF HOLCO 063100 10R POT ¾ SQ CERMET BECKMAN 014751 4k75 1% ¼8W 50ppm MF HOLCO 012218 22R1 1% ¼8W 50ppm MF HOLCO 013573 357k 1% ¼8W 50ppm MF HOLCO 013573 357k 1% ¼8W 50ppm MF HOLCO 013872 88k7 1% ¼8W 50ppm MF HOLCO 013872 88k7 1% ¼8W 50ppm MF HOLCO 013821 1k3 1% ¼8W 50ppm MF HOLCO 013262 22k6 1% ¼8W 50ppm MF HOLCO 01321 1k32 1% ¼8W 50ppm MF HOLCO 01321 1k32 1% ¼8W 50ppm MF HOLCO 013321 3k32 1% ¼8W 50ppm MF HOLCO 013321 3k32 1% ¼8W 50ppm MF HOLCO </td <td>PART No. MANUFACTURER PART No. OOI182 Ik8 5% //ew CARBON MULLARD CR37 OI1823 I82k 1% //bw SOppm MF HOLCO H8C O67503 50k POT 20 TURN CERMET BECKMAN 68x O67503 50k POT 20 TURN CERMET BECKMAN 68x O14990 499R 1% //bw SOppm MF HOLCO H8C O63100 IOR POT % SQ CERMET BECKMAN 68x O14751 4k7s 1% //bw SOppm MF HOLCO H8C O12218 22RI 1% //bw SOppm MF HOLCO H8C O13573 357k 1% //bw SOppm MF HOLCO H8C O11783 178k 1% //bw SOppm MF HOLCO H8C O11322 18k3 1% //bw SOppm MF HOLCO H8C</td>	PART No. MANUFACTURER PART No. OOI182 Ik8 5% //ew CARBON MULLARD CR37 OI1823 I82k 1% //bw SOppm MF HOLCO H8C O67503 50k POT 20 TURN CERMET BECKMAN 68x O67503 50k POT 20 TURN CERMET BECKMAN 68x O14990 499R 1% //bw SOppm MF HOLCO H8C O63100 IOR POT % SQ CERMET BECKMAN 68x O14751 4k7s 1% //bw SOppm MF HOLCO H8C O12218 22RI 1% //bw SOppm MF HOLCO H8C O13573 357k 1% //bw SOppm MF HOLCO H8C O11783 178k 1% //bw SOppm MF HOLCO H8C O11322 18k3 1% //bw SOppm MF HOLCO H8C

DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
R70	011501	1k5 1% 1/8W 50ppm MF	HOLCO	HBC	2
R71	011501	1k5 1% 18W 50ppm MF	HOLCO	H8C	-
R72	000102	IK 5% 1/3W CARBON	MULLARD	CR25	. –
र73	000102	IK 5% 'SW CARBON	MULLARD	CR25	
R74	012743	274k 1% 1/8W 50ppm MF	HOLCO	HBC	1
R75	014990	499R 1% 1/8W 50ppm MF	HOLCO	HBC	-
R76	000331	33OR 5% "SW CARSON	MULLARD	CR25	-
R77	001182	1k8 5% 1/2W CARBON	MULLARD	CR37	
R78	000103	IOK 5% YOW CARBON	MULLARD	CR25	
R79	000512	5ki 5% 1/3W CARBON	MULLARD	CR25	2
R80	000512	5ki 5% Yaw CARBON	MULLARD	CR25	-
R81	000822	OKZ 5% YOW CARBON	MULLARD	CR25	5
R82	000822	8k2 5% Y3W CARBON	MULLARD	CR25	_
R83	000822	8k2 5% Y3W CARBON	MULLARD	CR25	
२८४	000822	8kz 5% ¹ /3w Carbon	MULLARD	CR25	-
R85	000152	IKS 5% Y3W CARBON	MULLARD	CR25	
R86	000433	43k 5% 1/3W CARBON	MULLARD	CR25	1
R87	000822	8kz 5% 1/3W CARBON	MULLARD	CR25	-
R88	000471	470R 5% 1/3W CARBON	MULLARD	CR25	4
R89	000362	3kG 5% 1/3W CARBON	MULLARD	CR25	2
R90	000470	47R 5% YOW CARBON	MULLARD	CR25	-
R9I	013161	FSV (3k16 1% NOM)	HOLCO	H8c	2
R92	000122	IKZ 5% Yaw CARBON	MULLARD	CR25	-
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
R93	000470	47R 5% Y3W CARBON	MULLARD	CR25	
R94	000470	47R 5% YOW CARBON	MULLARD	CR25	-
R95	000470	47R 5% VOW CARBON	MULLARD	CR25	
R96	011872	18k7 1% 18W 50ppm MF	HOLCO	HBC	2
९९७	000104	100k 5% 1/3W CARBON	MULLARD	CR25	2
R98	011378	13R7 1% 1/8W 50ppm MF	HOLCO	H8C	2
R99	000104	100k 5% 1/3W CARBON	MULLARD	CR25	
R100	011872	18k7 1% Vow 50ppm MF	HOLCO	HBC	
RIOI	011378	13R7 1% 18W 50 ppm MF	HOLCO	HBC	
R102	000471	470R 5% 1/3W CARBON	MULLARD	CR25	
R103	013091	3k09 1% 1/8W 50ppm MF	Holco	HBC	2
R104	011541	1k54 1% 1/8W 50ppm MF	HOLCO	H8C	2
R105	011541	1k54 1% 1/8W 50ppm MF	HOLCO	HBC	
R106	013091	3k09 1% 1/8W 50ppm MF	HOLCO	н8с	
R107	000470	47R 5% V3W CARBON	MULLARD	CRZS	4
R108	017871	7k87 1% 18W 50ppm MF	HOLCO	H8C	I
R109	000101	100R 5% /3W CARBON	MULLARD	CR25	
RIIO	000225	2M210% YOW CARBON	MULLARD	CR25	· / /
RIII		NOT USED			
R112	000100	IOR 5% 1/3W CARBON	MULLARD	CR25	
R113	000362	3kg 5% 1/3W CARBON	MULLARD	CR25	
R 14	000470	47R 5% 1/3W CARBON	MULLARD	CR25	. –
RIIS	000470	47R 5% Yow CARBON	MULLARD	CR25	-
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
2116	000470	47R 5% JAW CARBON	MULLARD	CR25	
RII7	000101	IOOR 5% YOW CARBON	MULLARD	CR25	
8118	012432	24k3 1% /8W 50ppm MF	Holco	HBC	2
RIIS	012432	24k3 1% 18W 50ppm MF	HOLCO	H8C.	
2120	011002	IOK 1% YOW SOppm MF	HOLCO	H8C	
R121	017501	7k5 1% 18W 50ppm MF	HOLCO	H8C	<u> </u>
R122	011002	FSV (10k 1% NOM)	HOLCO	HBC	-
R123	066103	IOK POT 3/8 SQ. VERT CERMET	BECKMAN	72×W	<u> </u>
R124	000100	IOR 5% YOW CARBON	MULLARD	CR25	
R125	000100	IOR 5% 1/3W CARBON	MULLARD	CR25	-
2126	001182	1k8 5% 1/2W CARBON	MULLARD	CR37	2
RI27	000101	1008 5% /3W CARBON	MULLARD	CR25	-
2128	000101	IOOR 5% V3W CARBON	MULLARD	CR25	-
R129	011211	121 1% 18W 50ppm MF	HOLCO	H8C	1
R130	011002	10K 1% 18W 50ppm MF	HOLCO	HBC	-
2131	011002	10k 1% 18W 50ppm MF	HOLCO	няс	-
R132	000101	IOOR 5% Yaw CARBON	MULLARD	CR25	-
R133	001182	IKB 5% 1/2W CARBON	MULLARD	CR37	
R134	014321	4k32 1% 1/8W 50ppm MF	Holco	HBC	-
R135	012491	2449 1% 18W 50ppm MF	HOLCO	H8C	2
R136	090063	PTC THERMISTOR	TEXAS	TSP102k	2
R137	090063	PTC THERMISTOR	TEXAS	TSP102k	
R138	000101	IOOR 5% "SW CARBON	MULLARD	CR25	-
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
R139	000100	IOR 5% 'SW CARBON	MULLARD	CR25	-
R140	000202	2K 5% 1/3W CARBON	MULLARD	CR25	1
R141	000101	IOOR 5% /3W CARBON	MULLARD	CR25	· -
R142	000101	IOOR 5% YOW CARBON	MULLARD	CR25	-
R143	012491	2 49 1% 18W 50ppm MF	HOLCO	H8C	-
R144	011008	IOR 1% VOW SOPPM MF	HOLCO	H8C	1
R145	000221	220R 5% YOW CARBON	MULLARD	CR25	2
R146	000221	220R 5% V/3W CARBON	MULLARD	CR25	-
R147	000101	IOOR 5% VOW CARBON	MULLARD	CR25	-
R/48	000278	2R7 5% Vaw CARBON	MULLARD	CR25	1
R149	013161	FSV (3KIG 1% NOM)	HOLCO	HBC	
R150	000471	470 8 5% /3W CARBON	MULLARD	CR25	-
RISI	014751	4k75 1% 18W 50ppm MF	HOLCO	HBC	
R152	015230	523R 1% 1/8W 50ppm MF	HOLCO	H8C	1
R153	014320	432R 1% 18W 50ppm MF	Holco	H8C	1
R154	014751	4k75 1% 18W 50ppm MF	HOLCO	HBC	-
R(55	000472	4k7 5% /3W CARBON	MULLARD	CR25	
RISG	000472	4K7 5% 'SW CARBON	MULLARD	CR25	-
R157	000471	470R 5% 1/3W CARBON	MULLARD	CR25	
RIS8	000220	22R 5% YOW CARBON	MULLARD	CR2S	1
R159	000472	4k7 5% Vaw CARBON	MULLARD	CR25	-
2160		NOT FITTED			
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ESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL	MANUFACTURER'S PART No.	No. USED Per Assy.
				·····	
ANI	090017	100k ×7 2% NETWORK	BECKMAN	LO8-1-RIOOK	
ANZ	090139	2k2 ×4 2% SIL NETWO		L08-3-R2k2	· 1
AN3	090131	IOK ×4 2% SIL. NETWOR		LO8-3-RIOK	6
4N4	090132	4k7 ×4 2% SIL. NETWO		L08-3- R4k7	1
ANS	090140	22k x 9 2% SIL, NETWO		L10-1-R22k	2
ANG	090141	IM × 9 2% SIL. NETWO		LIO-I-RIM	2
AN7	090131	IOK X4 2% SIL NETWO		LOB-3-RIOK	
AN8	090140	22k x 9 2% SIL NETWO			
NOTES.	090140	CZR X 9 2/ SIL. NEIWO	RNOECKMAN	L10-1- R22k	
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
AN9	090141	IM × 9 2% SIL NETWORK	BECKMAN	LIO-I-RIM	-
ANIO	090131	IOK ×4 2% SIL. NETWORK	BECKMAN	LO8-3-Riok	-
ANII	090131	IOK ×4 2% SIL. NETWOR	BECKMAN	LOB-3-RIOK	-
ANIZ	090086	100k ×8 2% NETWORK	АВ	761-3-100K	1
ANI3	090131	IOK X4 2% SIL. NETWORK	BECKMAN	L08-3-RIOk	-
ANI4	090142	IOK × 4 0.5% DIL NETWORK	BECKMAN	694-3-RIOKD	
ANI5	090136	2k ×8 0.5% DIL NETWORK	BECKMAN	698-3-R2kD	3
ANIG	090136	2k ×8 0.5% DIL NETWORK	BECKMAN	698-3-R2KD	-
ANI7	090131	IOK X4 2% SIL NETWORK	BECKMAN	LOB-3-RIOK	
ANI8	090136	2K × 8 0.5% DIL. NETWORK	BECKMAN	698-3-R2kD	-
ANIS	090143	500R ×4 0.5% DIL. NETWORK	BECKMAN	694-3-R500D	1
				2012	
C <u>I</u>	102100	10pf 5% 500V CER DISC		CD10	4
C2	102470	47pf 5% 500V CER DISC	ITT	CDIO	2
C <u>3</u>	102470	47pF 5% 500V CER DISC		CDIO	3
<u>C4</u>	102221	220 PF 10% 500V CER DISC		CDIO	2
C5 NOTES.	102471	470pf 10% 500V CER DISC		CDIO	
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
C6	102102	INF 10% 500V CER DISC	ITT	CDIO	15
C7	150015	10 F 20% 35V DIP TANT	UNION CARBIDE	K10E35	4
C8	150015	IONF 20% 35V DIP TANT	UNION CARBIDE	KIOE35	
C9	150020	10/ F 20% 25V DIP TANT	UNION CARBIDE	KIOE 25	10
CIO	104026	47nF +50 % 50V CER DISC	SIEMENS	B37449	30
CII	104026	47 nF + 50% 50V CER DISC	SIEMENS	B37449	-
CI2	104026	47nf + 50% 50V CER DISC	SIEMENS	B37449	-
CI3	104026	47 of +50% 50V CER DISC	SIEMENS	B37449	<u> </u>
CI4	150015	IONE 20% 35Y DIP TANT	UNION CARBIDE	KIOE35	-
C15	104026	470F -20% 50V CER DISC	SIEMENS	B37449	-
C16	110040	33 AF 20% 63V POLYESTER	WIMA	MKS2	1
C17	150021	22 JUF 20% 25V DIP TANT	UNION CARBIDE	K22E25	2
C18	110039	470 F 20% G3V POLYESTER	WIMA	MKS2	<u> </u>
CIA	104026	47. F -20% 50Y CER DISC	SIEMENS	B37449	-
C20	102471	470pf 10% 500V CER DISC	ITT	CDIO	
C21	150020	100F 20% 25V DIP TANT	UNION CARBIDE	KIDE25	
C22	150020	100F 20% 25V DIP TANT	UNION CARBIDE	KIOE25	-
C23	102102	INF 10% 500V CER DISC	ITT	CDIO	-
C24	104026	47nf +50% 50V CER DISC	SIEMENS	B37449	
C25	120034	220 NF 1% 63V POLYCARB	ASHCROFT	A2B2201E	2
C26	102100	IOPF 5% 500V CER DISC	ITT	CDIO	
C27	102100	10pf 5% 500V CER DISC	ITT	CDIO	
C28	120035	22nF 1% 400V POLYCARB	ASHCROFT	A2B22004E	2
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DESIGNATOR	DATRON	DESCRIPTION	PRINCIPAL		MANUFACTURE	R'S	No. USED
	PART No.		MANUFACTURER		PART No.		Per Assy.
C29	102220	22pf 5% 500V CER DISC	ITT		CDIO		3
C30	104017	Op56F to.1pf 500V CER DISC	ITT		GD08AGOP5	6BS	2
C31	102108	IPF 1.5pf 500V CER DISC	ITT		CDO6		2
C32	102188	IPBF ± .5pf 500V CER DISC	ITT		CD06		2
C33	102 398	3P9F + . SPF 500V CER DISC	ITT		CD08		2.
C 34	150020	100F 20% 25V DIP TANT	UNION CARBIDE		KIOE25		-
C35	102102	INF 10% 500V CER DISC	ITT		CDIO		-
C36	130083	2nF 1% IGOV POLYSTYRENE	MULLARD		425		2
C37	110042	100nf 20% GBV POLYESTER	WIMA		MKSZ		7
38	102478	4PTF 1.5PF 500V CER DISC	ITT		CD08		9
C 39	102101	100PF 10% 500V CER DISC	ITT		CDIO	1.	3
C40	102278	2p7F 1.5pF 500V CER DISC	ITT		CD08		2
C41	130084	110pf 1% 630V POLYSTYRENE	MULLARD		427		2
C42	130042	100pf 1% 630V POLYSTYRENE	SUFLEX		HS		2
C 43	102478	4p7F + SpF SOOV CER DISC	ITT		CD08		— .
C44	102338		ITT		CD08		3
C45	104026	47.F + 50 % 50V CER DISC	SIEMENS		B37449		-
C46	102102	InF 10% 500V CER DISC	ITT		CDIO		-
C47	150020	IONF 20% 25V DIP TANT	UNION CARBIDE		KIOE25		-
C48	104026	470F -20% 50V CER DISC	SIEMENS		B37449		-
C49	102478	4PTF 1.5PF 500V CER DISC	тт		CD08		-
C50	120034	220nF 1% 63V POLYCARB	ASHCROFT		A2B22101 E		-
C51	120035		ASHCROFT		A2B22004	8	
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SIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
2	104017	Op56F + OIPF 500V CER DISC	ITT	GD08AG0P56BS	-
3	104026	47.F -28% 50V CER DISC	SIEMENS	B37449	-
4	102478	4P7F ± .5PF 500V CER DISC	ITT	CD08	-
5	104026	47nF + 50% 50V CER DISC	SIEMENS	B37449	
6	102108	IPF ±.5pf 500Y CER DISC	ITT	CDO6	-
57	102188	IPBF 1.5pf SOOV CER DISC	זזו	CDOG	-
8	102 398	3P9F 1.5PF 500V CER DISC	ITT	CDOB	-
9	104026	470F -20% 50V CER DISC	SIEMENS	837449	-
io	104026	47nF - 80% 50Y CER DISC	SIEMENS	B37449	-
4	102478	4P7F ± .5PF 500V CER DISC	ITT	CDOS	
52	130083	2nF 1% IGOV POLYSTYRENE	MULLARD	425	-
3	104026	470F -20% 50V CER DISC	SIEMENS	B37449	-
54	102101	100pf 10% 500V CER DISC	ITT	CDIO	-
55	102278	2PTF + · SPF 500Y CER DISC	זדו	CDOS	-
6	130084	110pf 1% G3OV POLYSTYRENE	MULLARD	427	-
57	130042	100pf 1% 630V POLYSTYRENE	SUFLEX	HS	-
8	102478	4PTF 1.5PF 500V CER DISC	ITT	CDOS	-
59 	102338	3P3F 1 .5PF SOOV CER DISC	ITT	CDOS	-
0	104026	47 nF -20% 50Y CER DISC	SIEMENS	B37449	-
71	102102	INF 10% 500V CER DISC	ITT	CDIO	-
12	150020	100 F 20% 25V DIP TANT	UNION CARBIDE	KI0E 25	-
73	102478	4PTF ±.5PF 500V CER DISC	ITT	CD08	-
14	102220	22pf 5% 500Y CER DISC	ITT	CDIO	-
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
C75	102102	INF 10% 500V CER DISC	177	CDIO	-
C76	110041	10nF 20% 100V POLYESTER	WIMA	FKS2	3
c77	102102	INF 10% 500V CER DISC	ITT	CDIO	-
C78	110041	IONF 20% IOOV POLYESTER	WIMA	FKSZ	-
C79	102102	INF 10% 500V CER DISC	ITT	CDIO	-
C80	110042	100nF 20% G3V POLYESTER	WIMA	MKS2	-
C81	102102	INF 10% 500V CER DISC	ITT	CDIO	-
C82	102182	INBE 20% SOOV CER DISC	ITT	CDIO	1
C83	102102	INF 10% 500V CER DISC	ITT	CDIO	-
C84	102102	INF 10% 500V CER DISC	177	CDIO	-
C 8 5	102102	INF 10% 500V CER DISC	ITT	CDIO	-
C86	102221	220pf 10% 500V CER DISC	ITT	CDIO	
C87	104026	47 . F - 20% 50Y CER DISC	SIEMENS	837449	
C88	104026	47nF -20% 50V CER DISC	SIEMENS	B37449	-
C89	110046	INF 20% 50V POLYESTER	WIMA	MKS2	1
00	104026	47 . F 1 20% SOV CER DISC	SIEMENS	B37449	-
C91	104026	470F -20% 50V CER DISC	SIEMENS	B37449	-
C92	102331	330pf 10% SOOV CER DISC	ITT	CDIO	
C93	104026	47 E 18% SOV CER DISC	ITT	B37449	-
C94	104026	47nF +50% 50V CER DISC	ITT	B37449	-
C95	101103	10 F 25% 250V CER DISC	ITT	CDIO	1
C96	150010	330nF 20% 35V DIP TANT	UNION CARBIDE	KR33E35	
C97	102101	100pf 10% 500V CER DISC	ITT	CDIO	-
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
C98	110042	100nF 20% 63V POLYESTER	WIMA	CDIO	-
c99	110042	100nf 20% GAY POLYESTER	WIMA	CDIO	
C100	104026	47nF -20% 50V CER DISC	SIEMENS	B37449	-
CI01	104026	470F -20% 50V CER DISC	SIEMENS	B37449	-
C102	150020	100F 20% 25V DIP TANT	UNION CARBIDE	KIOE25	-
C103	150020	IONE 20% 25V DIP TANT	UNION CARBIDE	KIOE25	-
C104	102478	4.PTF ±.5 PF SOOV CER DISC.	ITT	CD08	-
C105	104026	47nF +50% 50V CER DISC	SIEMENS	B37449	-
C106	102102	InF 10% 500V CER DISC	ITT	CDIO	-
C107	110042	100nF 20% 63V POLVESTER	WIMA	CDIO	-
C108	110015	15 F 20% 63V POLYESTER	WIMA	MKSZ	1.
C109	110041	10nF 20% 100V POLYESTER	WIMA	FKSZ	-
C110	102 100	10 PF 5% 500V CER DISC	ITT	CDIO	-
CIII	110042	100nF 20% GBV POLYESTER	WIMA	CDIO	-
C112	102221	220pf 10% 500V CER DISC	ITT	CDIO	
CII 3, CII4	104026	47nF +50% 50V CER DISC	ITT	B37449	-
C115	150015	100F 20% 35V DIP TANT	UNION CARBIDE	KI0E35	-
CIIG	102478	4p7F - 5% 500V CER DISC	ITT	CD08	. –
C117	102102	INF 10% 500V CER DISC	ITT	CDIO	-
C118	104026	160 /	SIEMENS	B37449	·
CIIS	102338	3p3F +. 5pf 500V CER DISC.	ITT	CD08	
C150	104026			B37449	-
CI21	150023	33,0F 20% 25V DIP TANT	UNION CARBIDE	K33E25	3
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DESIGNATOR	DATRON	DESCRIPTION	PRINCIPAL	MANUFACTURER'S	No. USED
	PART No.		MANUFACTURER	PART No.	Per Assy.
C122	150023	33, F 20% 25V DIP TANT	UNION CARBIDE	K33E25	-
C123	150020	100F 20% 25V DIP TANT	UNION CARBIDE	KIOE 25	<u> </u>
C124	104026	47nF -20% SOV CER DISC	SIEMENS	B37449	-
CIZ 5	150020	IONE 20% 25V DIP TANT	UNION CARBIDE	KIOE 25	-
C126	150023	330F 20% 25V DIP TANT	UNION CARBIDE	K33E25	
C127	102220	22pf 5% 500V CER DISC	ТТ	CDIO	-
C128	104026	4705 +50% 50V CER DISC	SIEMENS	B37449	-
C129	150021	22 JF 20% 25V DIP TANT	UNION CARBIDE	K22E25	-
C130	110042	100nF 20% 63V POLYESTER	WIMA	MK52	-
CI31	102102	InF 10% 500V CERDISC		CDIO	-,
C132		NOT FITTED			
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFA PART N	ACTURER'S	No. USED Per Assy.
	220010	SI HOT CARRIER DIODE	ΗΡ	HSCHIC	01/IN 6263	4
)2	210091	9VI 400mW ZENER	MULLARD	BZY88	COVI	3
03	210150	15V 400 mW ZENER	MULLARD	BZY88	C15	1
04	210091	SVI 400 mW ZENER	MULLARD	BZY 82	SC9VI	-
5	213009	ISV SW ZENER	UNITRODE	TVSSI	5	4
6	213009	ISV SW ZENER	UNITRODE	TVS 51	5	-
7	200001	75mA 75V GP SI DIODE	FAIRCHILD	IN414	8	14
8	200001	75mA 75V GP SI DIODE	FAIRCHILD	IN414	8	-
9	200001	75mA 75V GP SI DIODE	FAIRCHILD	IN414	8	-
DIO	210043	4V3 400mW ZENER	MULLARD	BZY 88	C4V3	4
DII	200001	75 mA 75V GP Si DIODE	FAIRCHILD	IN414	8	-
212	210043	4V3 400 mW ZENER	MULLARD	BZ/88	SC4V3	-
DI3	200001	75mA 75V GP SI DIODE	FAIRCHILD	IN414	8	
D14	200001	75 mA 75V GP Si DIODE	FAIRCHILD	IN414	8	_
D15	200001	75 mA 75V GP Si DIODE	FAIRCHILD	IN414	8	-
016	210043	4V3 400mW ZENER	MULLARD	BZY88	{c4V3	
DI7	200001	75m A 75V GP Si DIODE	FAIRCHILD	ΙΝΔΙΔ	8	-
D18	210043	4V3 400 mW ZENER	MULLARD	BZY88	C4V3	-
DIA	210091	SVI 400mW ZENER	MULLARD	BZY82	COVI	
020	213011	IVS 250mW ZENER	MULLARD	BZV46	5-175	2
D21	200001	75mA 75V GP Si DIODE	FAIRCHILD	IN414	8	-
D22	213011	IV5 250mW ZENER	MULLARD	BZV46	5-175	-
D23	200001	75mA 75V GP Si DIODE	FAIRCHILD	IN414	3	~
NOTES. SEE SHEET 2 FOR L	ATEST ISSUE			DATE 24. 7. 84 DRAWN [] .	TITLE	
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
D24	210056	5VG 400mW ZENER	MULLARD	BZY88C5V6	2
D25	210056	5VG 400 mW ZENER	MULLARD	BZY88C 5VG	-
D2G	213023	GV4 100ppm ZENER	MOTOROLA	IN 4575	2
D27	213009	15V 5W ZENER	UNITRODE	TVS515	-
D28	220010	SI HOT CARRIER DIODE	HP	HSCHIOOI/IN6263	-
D29	220010	SI HOT CARRIER DIODE	НР	HSCH 1001/1N6263	-
D 30	213023	6V4 100ppm ZENER	MOTOROLA	IN4575	-
D31	200001	75mA 75V GP Si DIODE	FAIRCHILD	IN4148	-
D32	200001	75 mA 75V GP Si DIODE	FAIRCHILD	IN4148	
D33	200001	75mA 75V GP Si DIODE	FAIRCHILD	IN4148	-
D34	213009	ISV SW ZENER	UNITRODE	TVS5IS	-
D35	200001	75m A 75V GP SI DIODE	FAIRCHILD	IN4148	-
D36	200006	1A GOOV GP SI DIODE	FAIRCHILD	IN4005	2
D37	200006	IA GOOV OP SI DIODE	FAIRCHILD	IN4005	-
D 38	220010	SI HOT CARRIER DIODE	HP	HSCHIOOI/IN6263	-
039	213012	2VO 250mW ZENER	MULLARD	BZV46-2V0	2
D 40	210062	6V2 400mW ZENER	MULLARD	BZY88C6V2	2
D41	210062	6V2 400mW ZENER	MULLARD	BZY88C6V2	-
D42	213012	2VO 250mW ZENER	MULLARD	BZV46-2V0	
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ESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFA PART No	CTURER'S	No. USED Per Assy.
QI	230065	N-CHAN I LIM 4.7mA	SILICONIX	J511		4
Q2	250004	SI PNP TRANSISTOR	NATIONAL	2N390	6/7018	6
Q3	250004	SI PNP TRANSISTOR	NATIONAL		6/1018	-
24	240006	SI NPN TRANSISTOR	NATIONAL	2N390	4/1018	12
Q5	240006	SI NPN TRANSISTOR	NATIONAL	2N390	4/1018	-
26	230065	N-CHAN I LIM 4.7mA	SILICONIX	JSI		-
77	240006	SI NPN TRANSISTOR	NATIONAL	2N390	94/1018	-
38	2400.13	SI NPN TRANSISTOR	NATIONAL	BC184	C/TOI8	5 ి
29	230065	N-CHAN I LIM 4.7mA	SILICONIX	J51		-
210		NOT USED				-
211	240032	SI NPN TRANSISTOR	MOTOROLA	BF 393	/ TOI8	5
SIS	250004	SI PNP TRANSISTOR	NATIONAL	2N390	x6/TO18	-
R13	230065	N-CHAN I LIM 4-7mA	SILICONIX	J511		
214	240006	SI NPN TRANSISTOR	NATIONAL	2N390	4/1018	-
215	24 0006	SI NPN TRANSISTOR	NATIONAL	2N390	4/ 1018	-
216	240006	SI NPN TRANSISTOR	NATIONAL	2N390	4/ 1018	-
217	240006	SI NPN TRANSISTOR	NATIONAL	2N390	4/1018	-
918	250004	SI PNP TRANSISTOR	NATIONAL	2N390	6/1018	
219	230001	N-CHAN I LIM 1.4 mA	SILICONIX	J506		3
Q20	230035	N-CHAN JEET	TELEDYNE	UI897	JF	28
R21	230035	N-CHAN JEET	TELEDYNE	UI897)F	-
Q22	230035	N-CHAN JFET	TELEDYNE	UI897 -	JF	-
223	230035	N-CHAN JFET	TELEDYNE	U1897	JF	-
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ESIGNATOR		DESCRIPTION	PRINCIPAL	MANUFACTURER'	S No. USED Per Assy.
Q24	230035	N-CHAN JFET	TELEDYNE	UI897 JF	
Q25	230035	N-CHAN JFET	TELEDYNE	UI897 JF	~
Q26	230035	N-CHAN JFET	TELEDYNE	U1897 JF	-
Q27	230035	N- CHAN JFET	TELEDYNE	U1897JF	
Q28	230035	N-CHAN JEET	TELEDYNE	U1897JF	
Q29	239060-1	N-CHAN DUAL JET + R41	DATRON	VCRII (COLOUR)) + H8
Q25 Q30	260060	334 CURRENT SOURCE	NATIONAL	LM334H	1
Q31	240006	SI NPN TRANSISTOR	NATIONAL	2N3904/TOP	8 -
Q32	230035	N-CHAN JEET	TELEDYNE	U1897 JF	-
	230035	N-CHAN JEET	TELEDYNE	U1897JF	
Q33		N-CHAN JFET	TELEDYNE	U1897JF	_
334	230035	N- CHAN JFET	TELEDYNE	U1897JF	
Q35	230035	N-CHAN JFET	TELEDYNE	U1897JF	
Q <u>36</u>	230035	N-CHAN JFET	TELEDYNE	UI897JF	
Q37	230035	N-CHAN JFET	TELEDYNE	U(897JF	
Q38	230035	N- CHAN JEET	TELEDYNE	U1897JF	
Q39	230035	N-CHAN JFET	TELEDYNE	UI897JF	
<u>२</u> 40	230035		IELED/NE		
Q41	230046-1	N-CHAN DUAL JET	<u> </u>	SEE DRG	
Q42	230001	N-CHAN I LIM 1.4 mA	SILICONIX	J506	
Q43	230001	N-CHAN I LIM 1.4 mA	SILICONIX	J506	
Q44	240006	SI NPN TRANSISTOR	NATIONAL	2N3904/TOI	
945	250001	SI PNP TRANSISTOR	NATIONAL	BC214/TO18	3
946	250001	SI PNP TRANSISTOR	NATIONAL	BC214/TO18	
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
Q47	230035	N-CHAN JEET	TELEDYNE	UI897JF	-
Q48	230035	N-CHAN JEET	TELEDYNE	UI897JF	-
ଦ୍ୟୁ	230035	N-CHAN JFET	TELEDYNE	U1897JF	
Q50	230035	N-CHAN JFET	TELEDYNE	U1897JF	, - ,
Q51	230035	N-CHAN JEET	TELEDYNE	U1897JF	-
Q52	230035	N-CHAN JFET	TELEDYNE	U1897JF	-
Q53	230035	N-CHAN JEET	TELEDYNE	U1897JF	-
Q54	250004	SI PNP TRANSISTOR	NATIONAL	2N3906/TOI8	
QS5	240017	SI NPN DUAL TRANSISTOR	NATIONAL	LM394	6
Q56	240017	SI NPN DUAL TRANSISTOR	NATIONAL	LM394	
Q57	240017	SI NPN DUAL TRANSISTOR	NATIONAL	LM394	
Q 58	240017	SI NPN DUAL TRANSISTOR	NATIONAL	LM394	· -
Q59	240017	SI NPN DUAL TRANSISTOR	NATIONAL	LM394	-
Q60	240017	SI NPN DUAL TRANSISTOR	NATIONAL	LM394	-
ଦ୍ୱଣ	230050	N-CHAN ILIM 2.4mA	SILICONIX	J508	L
Q62	240013	SI NPN TRANSISTOR	NATIONAL	BCI84C/TOI8	-
Q63	240013	SI NPN TRANSISTOR	NATIONAL	BC184C/TO18	
Q64	240013	SI NPN TRANSISTOR	NATIONAL	BC184C/T018	
Q65	240013	SI NPN TRANSISTOR	NATIONAL	BC184C/TO18	
966	230042	N-CHAN I LIM 3.0mA	SILICONIX	J509	6
ସ୍ୱିଟେ	230035	N-CHAN JEET	TELEDYNE	U1897JF	-
Q68	230035	N-CHAN JFET	TELEDYNE	U1897JF	-
ଦ୍ୱ୍ୱେ	230035	N-CHAN JEET	TELEDYNE	U1897JF	-
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTU PART No.	RER'S	No. USED Per Assy.
Q70	240006	SI NPN TRANSISTOR	NATIONAL	2N3904/	1018	
Q71	250008	SI PNP TRANSISTOR	NATIONAL	BC214C/1	018	3
Q72	250008	SI PNP TRANSISTOR	NATIONAL	BC214C/	TO 18	— .
Q73	230042	N-CHAN I LIM 3.0mA	SILICONIX	J509		-
Q74	230003	N-CHAN JEET	TELEDYNE	U1899JF		1
Q75	240006	SI NPN TRANSISTOR	NATIONAL	2N3904/	1018	-
Q76	239059-1	N-CHAN DUAL JEET KIT	DATRON	VCRII 2 S	AME COLOUR	KIT
Q17	239059-1	N-CHAN DUAL JEET KIT	DATRON	VCRII		-
Q78	240032	SI NPN TRANSISTOR	MOTOROLA	BF 393/ TO	018	
Q79	240032	SI NPN TRANSISTOR	MOTOROLA	BF 393/ T		-
Q80	240032	SI NPN TRANSISTOR	MOTOROLA	BF 393/ TO	018	-
ୟ ଅ	240032	SI NPN TRANSISTOR	MOTOROLA	BF 393/T	018	-
ଦ ଃ୧	230042	N-CHAN I LIM 3.0mA	SILICONIX	J509		
Q83	240001	SI NPN TRANSISTOR	NATIONAL	BC184/TO	218	2
Q84	230042	N-CHAN I LIM 3.0 mA	SILICONIX	J509		-
085	250001	SI PNP TRANSISTOR	NATIONAL	BCE14/TO	218	-
ସଃଚ	240031	SI NPN TRANSISTOR	MOTOROLA	BDI39		2
Q87	230042	N-CHAN I LIM 3.0 mA	SILICONIX	J509		-
Q88	240006	SI NPN TRANSISTOR	NATIONAL	2N3904/	TOIB	-
Q89	230042	N-CHAN I LIM 3.0 mA	SILICONIX	J509		-
990	250004	SI PNP TRANSISTOR	NATIONAL	2N3906/	1018	-
991	240001	SI NPN TRANSISTOR	NATIONAL	BC184/TC		-
Q92	250008	SI PNP TRANSISTOR	NATIONAL	BC214C/1		-
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
Q93	240031	SI NPN TRANSISTOR	MOTOROLA	BDI39	
294	250021	SI PNP TRANSISTOR	MOTOROLA	BDI40	1
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		· · · · · · · · · · · · · · · · · · ·			
MI	280101	DUAL BCD/BINARY COUNTER	MOTOROLA	MC 14569BCP	3
M2	280057	BCD UP/DOWN COUNTER	MOTOROLA	MC 14 510BCP	1
13	280008	QUAD 2 I/P NAND	MOTOROLA	MC 14011 BCP	1
M4	280011	DUAL D FLIP-FLOP	MOTOROLA	MC14013BCP	2
M5	280101	DUAL BCD/BINARY COUNTER	MOTOROLA	MC 14569 BCP	
16	280076	8 CHANNEL AN MUX	MOTOROLA	MC 14051 BCL	2
M7	280079	QUAD 2 1/P OR	MOTOROLA	MC14071 BCP	1
18	280076	8 CHANNEL AN MUX	MOTOROLA	MC 14051 BCL	-
49	280101	DUAL BCD/BINARY COUNTER	MOTOROLA	MC14569 BCP	-
10	280025	QUAD ANALOG SWITCH	MOTOROLA	MC 14066 BCP	
MI	260073	411 OP AMP	NATIONAL	LF4IICN	1
A12	280125	PHASE DETECTOR	NATIONAL	MM 74C 932N	i
MIS	280011	DUAL D FLIP-FLOP	MOTOROLA	MCI4-013 BCP	-
114	280080	HEX SCHMITT TRIGGER	NATIONAL	MM74CI4N	2
415	260074	LHOO32C FAST FET OP AMP	NATIONAL	LHOO32 CG	1
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTUR PART No.	ER'S	No. USED Per Assy.
MIG	260076	CURRENT MIRROR 1:1	TEXAS	TLOII CLP		2
MI7	2900 90	7× DARLINGTON DRIVER	SPRAGUE / EXAR	ULN2002A	XR2202CP	4
M18	260076	CURRENT MIRROR 1:1	TEXAS	TLOIICLP		-
MIS	260046	2525 OP AMP	HARRIS	HA32527-5	5	- 11
M20	290090	7 × DARLINGTON DRIVER	SPRAGUE / EXAR	ULN2002A/	XR22O2CP	-
M21	280080	HEX SCHMITT TRIGGER	NATIONAL	MM74CI4	N	
M22	260046	2525 OP AMP	HARRIS	HA 32527-	-5	-
M23	260046	2525 OP AMP	HARRIS	HA 32527-	5	-
M24	260046	2525 OP AMP	HARRIS	HA 32527-	5	-
M25	260046	2525 OP AMP	HARRIS	HA 32527-	5	
MZG	260077	CURRENT MIRROR 2:1	TEXAS	TLOIZCLP		3
M27	260077	CURRENT MIRROR 2:1	TEXAS	TLOI2 CLP		-
M28	290090	7× DARLINGTON DRIVER	SPRAGUE / EXAR	ULN 2002A	/ XR 2202CP	-
MS9	280035	BCD/DECIMAL DECODER	MOTOROLA	MC14028		1
M 30	260046	2525 OP AMP	HARRIS	HA32527-5		-
M3I	260046	2525 OP AMP	HARRIS	HA32527-5		-
M32	260057	5534 OP AMP	SIGNETICS	NE 5534N		
M 33	290090	7 X DARLINGTON DRIVER	SPRAGUE / EXAR	ULN2002A	/xr2202CP	-
M34	290000	NPN TRANSISTOR ARRAY	RCA	CA3083F		2
M35	260042	5532 DUAL OP AMP	SIGNETICS	NE 5532 N		2
M3G	280023	QUAD 2 1/P NOR	MOTOROLA	MC 14001 U	BCP	1
M37	260078	DUAL COMPARATOR	NATIONAL	LM393AN	1	1
M 38	280126	D/A CONVERTER	ANALOG DEVICES	AD 7527 KI	4	1
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
M39	260033	5V VIOA REGULATOR	MOTOROLA	MC78LO5ACP	1
M40	290000	NPN TRANSISTOR ARRAY	RCA	CA3083 F	
M41	260042	5532 DUAL OP AMP	SIGNETICS	NE 5532 N	-
M42	280127	10-BIT MULTIPLYING DAC	ANALOG DEVICES	AD 7533JN	2
M43	280127	IO-BIT MULTIPLYING DAC	ANALOG DEVICES	AD7533JN	-
M44	260046	2525 OP AMP	HARRIS	HA32527-5	-
M45	260027	714 OP AMP	FAIRCHILD	JUA714HC	1
M46	260046	2525 OP AMP	HARRIS	HA 32527-5	-
M47	260046	2525 OP AMP	HARRIS	HA32527-5	_
M48	260046	2525 OP AMP	HARRIS	HA32527-5	-
M49	260049	319 DUAL COMPARATOR	NATIONAL	LM3I9N	l
M50	260077	CURRENT MIRROR 2:1	TEXAS	TLOI2 CLP	-
			94. 		· · · ·
RLI	330012-2	RELAY REED IA GUARDED	HAMLIN	HE721A 5134	8
RL2	330012-2	RELAY REED IA GUARDED	HAMLIN	HE721A 5134	-
RL3	330012-2	RELAY REED IA GUARDED	HAMLIN	HE721A5134	-
RL4	330012-2	RELAY REED IA GUARDED	HAMLIN	HE721A5134	
RLS	330012-2	RELAY REED IA GUARDED	HAMLIN	HE721A5134	- .
RLG	330012-2	RELAY REED IA GUARDED	HAMLIN	HE721A 5134	-
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ESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTU PART No.	JRER'S	No. USED Per Assy.
RL7	330012-2	RELAY REED IA GUARDED	HAMLIN	HE 721 A 51	34	
rl8	330012-2	RELAY REED IA GUARDED	HAMLIN	HE72IA5	134	-
						2
L <u>I</u>	370003	ImH 40& RF CHOKE	SIGMA	SCIO 58/10/00		
2	370001	IOUH 0.85 & RF CHOKE	PLESSEY	58/10/00		6
_3	370001	اروال U-852 RF CHOKE	PLESSEY	58/10/00		
- <u>+</u>	370001	IODH 0.85& RF CHOKE	PLESSEY	58/10/00		
LG	370001	IONH 0.853 RF CHOKE	PLESSEY	58/10/001		-
.7	370026	JUH 880mA CHOKE	SIGMA	SCIO		1
_8	370003	IMH 4032 RF CHOKE	SIGMA	5010		-
<u>.</u> 9	370001	10H D.85 Ω RF CHOKE	PLESSEY	58/10/00	01/10	-
	410171-8	РСВ				1
	450450-1	HEATSINK				<u> </u>
	540002	22 SWG BTC WIRE				A/R
	512999	7/-2 PTFE WIRE				A/R
	602 001	FSV TERMINAL	MOLEX	02-04-	5114	6
	605059	8 WAY DIL SOCKET	JERMYN	J23- 180	008	17
	605060	14 WAY DIL SOCKET	JERMYN	J23- 180		9
	605061	IG WAY DIL SOCKET	JERMYN	J23- 180	016	15
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ESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
	605065	28 WAY DIL SOCKET	JERMYN	J23- 18028	1
	604046	3-WAY .I" PCB PLUG GD.R	. MOLEX	22-10-2031	2
	611016	M3×8mm POZIPAN STEEL	ZN PL		2
	611 0 25	Max 16mm POZICSK STEEL	ZNPL		
	612026-1	M3×6mm STANDOFF	DATRON	SEE DRG	1
	613005	M3 INT SHAKEPROOF			2
	615002	M3 FULL NUT STEEL ZN. PL.			2
	620003	SOLDER PIN	HARWIN	HZIOS AOI	•3
	620007	TEST POINT TERMINAL	MICROVAR	TYPE C30	32
	630024	STEATITE BEAD IG SWG	PARK ROYAL PORCELAIN	Nº Z	8
	630107	BRASS STRIP 15.5 X .38mm	RIGHTON	CZ108 1/2H	A/R
	630120	PCB EJECTOR (YELLOW)	RICHCO	CBE	2
	900003	HEATSINK COMPOUND	RS	554-311	A/R
	920089-1	HEATSINK TO-220		SEE DRG-	2
	920149	HEATSINK TO8	SOURIAU	TXBF 2-050-033B	1
	605124	IO WAY SOCKET STRIP	AUGAT	510 - AG 910	1/3
	605127	2 WAY . I" SHORTING SKT	ASSMANN	AKSPL-G	2
	590001	20mm RUBBER SLEEVE.	HELLER MANN.	H15 x 20.	1
	540006	1/0.4 PTFE BLACK WIRE		BSGZIO TYPE A	A/R
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ESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
21	000105	IM 5% /3W CARBON	MULLARD	CR25	5
2	000332	3k3 5% /3W CARBON	MULLARD	CR25	2
3	000101	100R 5% 1/3W CARBON	MULLARD	CR25	17
24	011001	1k 1% VOW 50ppm MF	Holco	HBC	4
रऽ	011003	100k 1% VBW 50ppm MF	HOLCO	H8C	4
۲6	014021	4k02 1% 1/8W 50ppm MF	HOLCO	HBC	3
27		NOT USED			-
28		NOT USED			
۲۹	014021	4k02 1% 1/8W 50ppm MF	HOLCO	H8C	
RIO	000104	100k 5% VIW CARBON	MULLARD	CR25	7
211	000104	100k 5% YAW CARBON	MULLARD	CR25	-
R12.	000104	100k 5% 1/3W CARBON	MULLARD	CR25	
R13	011003	100k 1% VOW 50ppm MF	HOLCO	НВС	-
214	011003	100k 1% VOW 50ppm MF	HOLCO	НВС	
RI5	090138-1	IOK MATCHED PAIR	VISHAY	SEE DRG-	1
RIG	000100	IOR 5% YOW CARBON	MULLARD	CR25	2
217	000100	IOR 5% /3W CARBON	MULLARD	CR25	-
218	080071	178R1 .1% 3ppm M.FOIL	VISHAY	S102C	2
(19	080071	178R1 .1% 3ppm M. FOIL	VISHAY	SI02C	
220	080072	312 R8 . 1% 3ppm M. FOIL	VISHAY	S102C	2
₹ 2 1	080073	IOOR . 1% 3ppm M. FOIL	VISHAY	S102C	2
222	080072	312 R8 . 1% 3ppm M. FOIL	VISHAY	SIO2C	-
23	080073	100R +1% 3ppm M. FOIL	VISHAY	S102C	
155 20 1659 1659 1859 1859 185 185 185 185 185 185 185 185	ON NON ANY	SHEET I FOR TEST ISSUE. 1735 1738 1768 1761 17		2.7.84 datror	CB ASSY

DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTUR PART No.		No. USED Per Assy.
R24	000121	120R 5% /3W CARBON	MULLARD	CR25		2
R25	000390	39R 5% 'SW CARBON	MULLARD	CR25		2
R26	000121	120R 5% '3W CARBON	MULLARD	CR25		
R27	000103	IOK 5% 'SW CARBON	MULLARD	CR25		7
R28	000104	100k 5% 'SW CARBON	MULLARD	CR2S		~
R29	000104	100k 5% 1/3W CARBON	MULLARD	CR25		
R30	000103	IOK 5% Yaw CARBON	MULLARD	CR25		
231	011002	lok 1% 18W SOppm MF	HOLCO	HBC		3
R32	000101	100R 5% YSW CARBON	MULLARD	CR25		
R33	000390	39R 5% YOW CARBON	MULLARD	CR25		
₹34	000101	100R 1% YOW 50ppm MF	HOLCO	H8C		~
R35	013920	392R 1% 18W 50ppm MF	Holco	HBC		1
236	000101	IOOR 5% 'SW CARBON	MULLARD	CR25		-
237	011002	10k 1% 18W 50ppm MF	HOLCO	H8C		-
238	011002	IOK 1% VOW SOPPM MF	HOLCO	H8C ⁷		
R39	000104	100k 5% 1/3W CARBON	MULLARD	CR25		~
?40	000104	100k 5% 1/3W CARBON	MULLARD	CR25		
۲4۱	000105	IM 5% YOW CARBON	MULLARD	CR25		-
२42	000105	IM 5% /3W CARBON	MULLARD	CR25		
R43	016190	619R 1% 18W 50ppm MF	HOLCO	H8C		2
R44	016190	GIOR 1% YOW SOPPM MF	HOLCO	HBC		_
\45	012 670	267R 1% 1/8W 50ppm MF	Holco	H8C		2
R46	012670	267R 1% VOW 50ppm MF	HOLCO	HBC		 .
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFAC PART No.	TURER'S	No. USED Per Assy.
R47	011001	IK 1% 18W 50 ppm MF	HOLCO	H8C		
R48	000220	22R 5% 1/3W CARBON	MULLARD	CR25		1
R49	011001	IKO 1% YOW SOFFM MF	HOLCO	HBC		-
R50	011301	1k3 1% 18W 50ppm MF	HOLCO	H8C		1
R51	000103	IOK 5% YOW CARBON	MULLARD	CR25		-
R52	000103	IOK 5% YOW CARBON	MULLARD	CR25		-
R53	000472	4k7 5% 1/3W CARBON	MULLARD	CR25		5
R54	011001	1k 1% 1/8W 50ppm MF	Holco	H8C		
R55		NOT USED				
R56	000101	IOOR 5% YOW CARBON	MULLARD	CR25		-
R\$7	000682	6k8 5% /3W CARBON	MULLARD	CR25		1
R58	000470	47R 5% /SW CARBON	MULLARD	CR25		3
R59	000101	IOOR 5% VAW CARBON	MULLARD	CR25		
R60	000101	IODR 5% YOW CARBON	MULLARD	CR25		
R61	000101	100R 5% "SW CARBON	MULLARD	CR25		-
R62	000101	100R 5% YOW CARBON	MULLARD	CR25		
R63	000105	IM 5% YOW CARBON	MULLARD	CR25		-
R64	000103	IOK 5% 1/3W CARBON	MULLARD	CR25		~
R65	000472	4k7 5% 1/3W CARBON	MULLARD	CR25		-
R66	000102	IK 5% Yaw CARBON	MULLARD	CR25		2
R67	000392	3k9 5% 'SW CARBON	MULLARD	CR25		1
R68	000101	IOOR 5% YOW CARBON	MULLARD	CR25		-
R69	000101	IOOR 5% VIW CARBON	MULLARD	CR25		-
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LSIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFAC PART No.	TURER'S	No. USED Per Assy.
270	000101	IOOR 5% 'SW CARBON	MULLARD	CR25		
R71		NOT_USED				
R72	000272	2k7 5% 1/3W CARBON	MULLARD	CR25		
273	000472	4k7 5% /3W CARBON	MULLARD	CR2S		
R74	000103	IOK 5% Y3W CARBON	MULLARD	CR25		
R75	000103	IOK 5% Y3W CARBON	MULLARD	CR25		
R76	000472	4k7 5% /3W CARBON	MULLARD	CR25		
277	000221	220R 5% V3W CARBON	MULLARD	CR25		5
R78	000102	IK 5% Y3W CARBON	MULLARD	CR25		-
R79	000101	IOOR 5% VOW CARBON	MULLARD	CR25		
R80	000821	820R 5% YOW CARBON	MULLARD	CR25	• •	2
R81	000223	22k 5% 1/3W CARBON	MULLARD	CR25		3
R82	000223	22k 5% 1/3W CARBON	MULLARD 2	CR25		<u> </u>
R 83		NOT USED				
R84	000221	22OR 5% "3W CARBON	MULLARD	CR25		
R85	000153	ISK 5% 1/3W CARBON	MULLARD	CR25		1
R86	000101	100R 5% 1/3W CARBON	MULLARD	CR25		
R87	000332	3k3 5% Y3W CARBON	MULLARD	CR25		-
R88	000223	22K 5% /3W CARBON	MULLARD	CR25		-
R89	000473	47K 5% 1/3W CARBON	MULLARD	CR25	<u> </u>	3
R90	000821	820R 5% 1/3W CARBON	MULLARD	CR25		
R91	000473	47k 5% /3W CARBON	MULLARD	CR25		
R92	000473	47k 5% 1/3W CARBON	MULLARD	CR25		
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DESIGNATOR DATRON DESCRIPTION PRINCIPAL MANUFACTURER MANUFACTURER'S No. USED PART No PART No Per Assy. 893 5% YOW CARBON MULLARD 000273 CR25 27K 1 5% 'SW CARBON R94 000432 MULLARD CR25 4k3 1 2208 5% /3W CARBON 000221 R95 MULLARD CR25 R96 220R 5% /3W CR25 CARBON MULLARD 000221 1% 18W 50ppm MF 2 R97 013321 3k32 HOLCO H8C 1% 18W 50ppm MF R98 011003 H8C HOLCO 100k R99 3k32 1% 18W 50ppm MF _ 013321 H8C HOLCO R100 000470 5% VOW CARBON ----MULLARD 47R CR25 100R 5% YOW CARBON CR25 RIOI 000101 MULLARD 011690 2 R102 169R 1% 1/8W 50ppm MF HBC HOLCO R103 169R 1% 1/8W 50ppm MF H8C 011690 HOLCO R104 000680 68R 5% 1/3W CARBON MULLARD I CR25 4k64 1% 1/8W 50ppm MF HBC R105 014641 I HOLCO R106 012371 2k37 1% 1/8W 50ppm MF HBC 1 Holco R107 066104 100k POT 3/8 SQ VERT CERMET BECKMAN 72 X W I R108 014640 HOLCO 2 H8C R109 000470 47R 5% 1/3W CARBON MULLARD CR25 RIIO 080074 IIIRII 1% 3ppm M.FOIL 1 VISHAY S102C RIII NOT USED ----R112 12R346/100R VISHAY 090129-3 SEE DRG 1 464R 1% 18W 50ppm MF R113 014640 ----Holco HBC R114 220R 5% 1/SW CARBON MULLARD 4 008054 CRIG R115 090148-1 100k (MATCHED PAIR WITH RIZI) DATRON SEE DRG I NOTES. DATE SEE SHEET 2 FOR LATEST ISSUE DRAWN TITLE CHECKED 4700 AC PCB ASSY 100 APPROVED NUMBER 400663 DATE 6 or 24 DATE CIIND

DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACT PART No.	TURER'S	No. USED Per Assy.
RIIG		NOT USED		,		
RII7		NOT USED				-
R118	080095	IKI 1% IPPM M.FOIL	VISHAY	SIOSC		<u> </u>
RIIS	1	NOT USED				-
R120	080075	IOK 1% IPPM M.FOIL	VISHAY	SIOSC		2
R121	090148-1	IOK (MATCHED PAIR WITH RIIS)	DATRON	SEE DRG		-
R122	066103	10K POT 3/8 SQ VERT CERMET	BECKMAN	72×W		<u>'</u>
R123	080075	IOK 1% Ippm M. FOIL	VISHAY	S102C		
R124	080043-2	Ik · 1% 3ppm M. FOIL	VISHAY	SEE DRG		<u> </u>
R125	008054	220R 5% 1/5W CARBON	MULLARD	CRIG		-
R126	008054	220R 5% VSW CARBON	MULLARD	CRIG		-
R127		NOT USED				-
R128		NOT USED		٢,		
RI29		NOT USED				-
R130		NOT USED				
R131		NOT USED			s,	
R132		NOT USED				-
R133		NOT USED				-
R134		NOT USED	· · ·			-
R135		NOT USED				-
R136	,	NOT USED	``````````````````````````````````````			~
R137		NOT USED			· · · · · · · · · · · · · · · · · · ·	-
R138		NOT USED				
NOTES. SEE SHEET 2 FOR L	ATEST ISSUE			DATE	datron	ELECTRONICS LTD
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFAC PART No.	IURER'S	No. USED Per Assy.
R139		NOT USED				
RI40		NOT USED				-
R141	011580	15BR 1% YOW SOPPM MF	HOLCO	HBC		1
R142	063104	100K POT 3/8 SQ. CERMET	BECKMAN	72P		1
R143	014752	47k5 1% 18W 50ppm MF	HOLCO	HBC		1
R144		NOT FITTED				<u> </u>
R145	000472	4k7 5% YOW CARBON	MULLARD	CR25		-
R146	008054	220R 5% VSW CARBON	MULLARD	CRIG		-
R147	000 2 2 2	2k2 5% YEW CARBON	MULLARD	CRZS		1
R148		100R 5% YOW CARBON	MULLARD	CR25		-
R149	000101	IDOR 5% 'SW CARBON	MULLARD	CR25		-
RISO	012002	20k 1% 1/8W 50ppm MF	HOLCO	H8C		1
RISI		NOT USED				-
R152		NOT FITTED				
R153		NOT FITTED				-
R154	011000	100R 1% 1/8W 50ppm M	F HOLCO	HBC		1
R155		NOT USED				-
R156	014021	4k02 1% VOW 50ppm MF	HOLCO	HBC		-
R157	008064	33R 5% /5W CARBON	MULLARD	CRIG		1
RI58	000221	220R 5% Yaw CARBON	MULLARD	CR25		
R159	000105	IM 5% /3W CARBON	MULLARD	CR25		-
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				DATE	NUMBER 40066	3 8 5116 7

DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTU PART No.		No. USED Per Assy.
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ANI	090136	2k × 8 ± 5% DIL NETWORK	BECKMAN	698-3- R	SKD	2
ANZ	090144	IK × 8 1% DIL NETWORK	BECKMAN	698-3-R		1
ANS	090136	2K × 8 ± .5% DIL NETWORK	BECKMAN	698-3-R		-
AN4	090096	IM × 8 2% NETWORK	BECKMAN	109-1- RI	M	2
ANS	090096	IM +8 2% NETWORK	BECKMAN	L09-1-R	IM	-
ANG	090137	3k3 ×8 ±.5% DIL NETWORK	BECKMAN	698-3- R	3k3D	1
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				vrth	4700 AC PC	
DATE		······	DATE		NUMBER 40066	3 9 UF 24

DESIGNATOR DATRON DESCRIPTION PRINCIPAL MANUFACTURER MANUFACTURER'S No. USED PART No. PART No Per Assy. 100nF 20% 63V POLYESTER CI 110042 WIMA MK52 4 WIMA C2 110042 100nF 20% 63V POLYESTER MKS2 ----3 С3 101103 IONF 25% 250V CER DISC ITT CDIO 22 pf 5% 500V CER DISC 102220 ITT I C4 CDIO 110030 INF 20% 100V POLYESTER WIMA FKS2 2 C5 4715 - 20% 50V CER DISC SIEMENS B37449 104026 20 CG CDIO C7 102102 INF 10% 500V CER DISC ITT 4 C8 102102 10% 500V CER DISC ITT CDIO ---InF INF 10% 500V CER DISC ITT ___ C9 102102 CDIO ----ITT сю 102102 INF 10% 500V CER DISC CDIO _ СІІ 104026 47nF 128% 50V CER DISC SIEMENS 837449 2112F 10% 63V POLYCARB 2 C12 120014 ASHCROFT A2B2221B CIB 120014 242F 10% 63V POLYCARB ASHCROFT A2 B222 | B --------47 DF 128% SOV CER DISC C14 104026 SIEMENS <u>B37449</u> 102100 16 CIS CDIO 10pf 5% 500V CER DISC ITT 100nF 20% 63Y POLYESTER 110042 WIMA MKS2 C16 -C17 INF 20% 100V POLYESTER WIMA FKS2 110030 ____ 100nF 20% 63V POLYESTER WIMA MKSZ C18 110042 10 UF 20% 25Y DIP TANT UNION CARBIDE K10E25 C19 8 150020 47nF -20% 50V CER DISC C20 104026 SIEMENS B37449 47. F -20% 50V CER DISC 104026 SIEMENS ___ C21 837449 47 nF -20% 50V CER DISC SIEMENS 104026 B37449 C22 -104026 47nF -20% 50V CER DISC SIEMENS 837449 _ C23 NOTES DATE SEL SHEET 2 FOR LATEST ISSUE CHECKED 4700 AC PCB ASSY 155 1 C O APPILOVE ATE NUMBER 400663 10 0724 DATE снко

DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
C24	104026	47 .F -20% 50V CER DISC	SIEMENS	B37449	· . · · · · ·
C25	120025	4NTF 10% 63Y POLYCARB	ASHCROFT	A2B4721B	. 2
C26	120025	4 JITE 10% 63Y POLYCARB	ASHCROFT	A2B472IB	
C27	104026	47nF +50% 50V CER DISC	SIEMENS	B37449	
C28	104026	47 nF + 20% 50V CER DISC	SIEMENS	837449	
C29	104026	47 AF + 50% 50V CER DISC	SIEMENS	B37449	<u> </u>
C30	150020	IONE 20% 25V DIP TANT	UNION CARBIDE	KIOE 25	· · _
C3I	150020	IOHF 20% 25V DIP TANT	UNION CARBIDE	K10825	
C32	150020	IONF 20% 25V DIP TANT	UNION CARBIDE	K10E25	
C33	150020	IQUE 20% 25V DIP TANT	UNION CARBIDE	KIDE25	-
C34	102100	10pf 5% 500V CER DISC	ITT	CDIO	· _
C35	104026	47nF + 50% SOV CER DISC	SIEMENS	B37449	
C36	104026	47nF 120% SOV CER DISC	SIEMENS	837449	
C37	102471	470pf 10% 500V CER DISC	ITT	CDIO	4
C38	102471	470PF 10% 500V CER DISC	ITT	CDIO	
C 39	100102	INF 10% 100V CER PLATE	MULLARD	2222 630 19102	2
C40	104026	47nf to % SOV CER DISC	SIEMENS	B37449	-
C41		NOT USED			
C42	104026	47nF -20% 50V CER DISC	SIEMENS	B37449	-
C43	104026	470F -20% 50V CER DISC	SIEMENS	B37449	-
C44	102470	47pf 5% 500V CER DISC	ITT	CDIO	2
C45	150020	IOUF 20% 25V DIP TANT	UNION CARB	KIDE25	
C46	150015	IONF 20% 35V DIP TANT	UNION CARBIDE	KIOE 35	2
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per 'Assy.
C47	150015	IONE 20% 35V DIP TANT	UNION CARBIDE	KI0E35	
C48	101103	IONF 25% 250V CER DISC	ITT	CDIO	-
C49	102100	10pf 5% 500V CER DISC	ITT	CDIO	_
C50	100330	33 pF 2 % 100V CER DISC	MULLARD	2222 683	5
C51	100330	33 pF 2 % LOOV CER DISC	MULLARD	2222 683	-
C52	150006	447F 20% IGV DIP TANT	UNION CARBIDE	K4RTE IG	1
C53	150024	47 F 20% IOV DIP TANT	UNION CARBIDE	K47E16	2
C54	150020	IOUF 20% 25V DIP TANT	UNION CARBIDE	KIDE25	
C 55	150020	100F 20% 25V DIP TANT	UNION CARBIDE	K10E25	
C56	150024	47 IF 20% IGV DIP TANT	UNION CARBIDE	K47E 16	-
C57		NOT USED			-
C58		NOT USED			-
C59		NOT USED			
C 60	102338	3P3F 1.5PF 500V CER DISC	ITT	CD08	1
C61		NOT USED			
C62	102150	15pf 5% 500V CER DISC	ITT	CDIO	1
C63		NOT USED			-
C 64	102100	10pf 5% 500V CER DISC	ІТТ	CDIO	
C65	102100	10pf 5% 500V CER DISC	лт	CDIO	
C66	102100	10pf 5% 500V CER DISC	ITT	CDIO	—
C67	102100	10pf 5% 500V CER DISC	ITT	CDIO	-
C68	100330	33PF 2% 100Y CER DISC	MULLARD	2222 683	
C69	100330	33 PF 2% 100V CER DISC		2222 683	_
NOTES.		· · · · · · · · · · · · · · · · · · ·	0A 07		
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
C70	102100	10 PF 5% 500V CER DISC	ITI	CDIO	
C71	102100	10pf 5% 500V CER DISC	ITT	CDIO	-
C72	102100	10pf 5% 500V CER DISC	ITT	CDIO	·
C 73	102100	IOPE 5% 500V CER DISC	ITT	CDIO	-
C74 ····	102100	IOPE 5% 500V CER DISC	ITT	CDIO	-
C 75	102100	IOPF 5% 500V CER DISC	ITT	CDIO	
C76	102100	IOPF 5% 500V CER DISC	ITT	CDIO	-
-77	102100	10pf 5% 500V CER DISC	ITT	CDIO	
C78	10 0330	33pF 2% 100V CER DISC	MULLARD	2222 683	
C79	101103	10nf 25% 250V CER DISC	ITT	CDIO	
C80	102100		ITT	CDIO	-
C8I	102471	470pF 10% 500V CER DISC	ITT	CDIO	-
C82	102471	470pf 10% 500V CER DISC	ITT	CDIO	
C83	104026	470F 18% 50V CER DISC	SIEMENS	837449	-
C84	104026	47nF 10% 50V CER DISC	SIEMENS	B37449	-
C85	104026	47nF + 50% 50V CER DISC	SIEMENS	B37449	
C86	104026	47 .F 128% 50V CER DISC	JIEMENS	837449	
287		NOT FITTED			
C88	102222	2.2F 20% 500V CER DISC	ITT	CDIO	1
089	140063	GnBF 5% G3V POLYPROPYLENE	WIMA	FKP2.)
630	102101	100pF 10% 500V CER DISC	ITT	CDIO	1
291	102221	220pF 10%500V CER DISC	ITT	CDIO	1
NOTES. SEE SHEET 2 FOR L	ATEST ISSUE				
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DATRON PART No. PRINCIPAL MANUFACTURER MANUFACTURER'S PART No. No, USED Per Assy. DESIGNATOR DESCRIPTION 47pf 5% 500V CER DISC 102470 <u>C92</u> ITT CDIO. -------NUTES. DATE datron allenances 110 11th Aug.86. SEE SHEET 2 FOR LATEST ISSUE DILAWA B.S.JACKSON. TITLE 4700 ISS FCO DATE CHRD AC. PCB ASSY APPROVED DITAWING NUMBER 400663 14 .24 DATE

DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUF PART N	ACTURER'S o.	No. USED Per Assy.
DI	213006	5V 5W ZENER	UNITRODE	TVS 5	05	2
02	213006	5V 5W ZENER	UNITRODE	TVS 50	05	-
3		NOT USED				-
)4		NOT USED				
)5	200008	200mA 125V LL SI DIODE	FAIRCHILD	IN458	BA	21
6	200008	200 m A 125V LL SI DIODE	FAIRCHILD	IN458	A	
07	200008	200m A 125V LL SI DIODE	FAIRCHILD	IN45	BA	
08	200008	200 MA 1254 LL SI DIODE	FAIRCHILD	IN458	BA	-
)9	213022	IOV SW ZENER	UNITRODE	TVS5	>	4
010	213022	IOV SW ZENER	UNITRODE	TVS5	0	
>11	200008	200m A 125Y LL SI DIODE	FAIRCHILD	IN458	IN458A	
) 2	213022	IOV SW ZENER	UNITRODE	TVS51	0	-
>13	213022	IOV SW ZENER	UNITRODE	TVS51	0	-
>14	213009	ISV SW ZENER	UNITRODE	TVS 51	5	2
15	213009	15V 5W ZENER	UNITRODE	TVS51	5	
016	200002	IA SOV GP SI DIODE	FAIRCHILD	IN400	IN4001	
017	210200	20V 400mW ZENER	MULLARD	BZY8	8020	/
018		NOT USED				
919		NOT USED				
20	200001	75mA 75V GP SI DIODE	FAIRCHILD	IN41-	48	7
21	200002	IA SOV GP SI DIODE	FAIRCHILD	IN40	01	-
22	200002	IA SOV GP SI DIODE	FAIRCHILD	IN40	01	-
23	200008	200mA 125V LL SI DIODE	FAIRCHILD	IN 45	8 A	-
NOTES.	A1EST ISSUE			DATE	TITLE	ELECTRONICS LTD
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER		MANUFACI PART No.	URER'S	No. USED Per Assy.
D24	200001	75mA 75V GP SI DIODE	FAIRCHILD		IN4148		
D25	210130	13V 400mW ZENER	MULLARD		BZY88C	13	1
D26	200002	IA 50V GP SI DIODE	FAIRCHILD	CHILD IN 4001			
D27	200002	IA SOV GP SI DIODE	FAIRCHILD		IN4001	_	-
D28	213002	SVI SW ZENER	MOTOROLA		IN5 338	В	2
D29	213002	5VI SW ZENER	MOTOROLA		IN5338	3	-
D30	213023	6V4 100ppm ZENER	MOTOROLA		IN4575		1.
D31	200008	200mA 125V LL SI DIODE	FAIRCHILD		IN458A		-
D32	210091	9VI 400 mW ZENER	MULLARD		BZY88C	9γι	1
D33	200001	75 mA 75V GP SI DIODE	FAIRCHILD	IN4148			-
D34	210056	5V6 400mW ZENER	MULLARD		BZY88C	5V6	2
D35	210056	5VG 400mW ZENER	MULLARD		BZY88C	5V6	-
D36		NOT_USED					-
D37	200008	200mA 125V LL SI DIODE	FAIRCHILD		IN458A		-
D38	200008	200mA 125Y LL SI DIODE	FAIRCHILD	FAIRCHILD IN458			-
039	200008	200mA 125V LL SI DIODE	FAIRCHILD		IN458A		~
D40	200008	200 mA 125V LL SI DIODE	FAIRCHILD		IN458A		-
D41	200008	200mA 125V LL SI DIODE	FAIRCHILD		IN458A		-
D42	213011	IV5 250mW ZENER	MULLARD	:	BZV46-	IV5	2
043	213011	IV5 250mW ZENER	MULLARD		BZV46-	IV5	-
D44	200001	75mA 75V GP Si DIODE	FAIRCHILD		IN4148		-
D45	200001	75mA 75V GP SI DIODE	FAIRCHILD		IN4148		~
D46	200001	75mA 75V GP SI DIODE	FAIRCHILD		IN4148		-
NOTES.	ATEST ISSUE	,		DATE		datron	ELECTRONICS LTD
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFAC PART No.	TURER'S	No. USED Per Assy.
D47	200001	75mA 75V GP SI DIODE	FAIRCHILD	IN4141	3	-
048		NOT USED				
049	200008	200mA 125V LL SI DIODE	FAIRCHILD	IN458A		
50	200008	200mA 125V LL SI DIODE	FAIRCHILD	IN458	A	<u> </u>
51		NOT USED				-
52	200008	200mA 1254 LL SI DIODE	FAIRCHILD	IN 458	A	
53	200008	200mA 125V LL SI DIODE	FAIRCHILD	IN458	4	-
D 54	200008	200mA 125V LL SI DIODE	FAIRCHILD	IN458	٩	-
D55	200008	200mA 125V LL SI DIODE	FAIRCHILD	IN458	٩	-
D 56	200008	200mA 125V LL SI DIODE	FAIRCHILD	IN458/	1	
557	220010	SI HOT CARRIER DIODE	НР	HSCHIC	H5CH1001/IN6263	
58	220010	SI HOT CARRIER DIODE	нр	HSCHI	001/116263	
D59	200008	200mA 125V LL SI DIODE	FAIRCHILD	IN458/		-
D60	200008	200mA 125Y LL SI DIODE	FAIRCHILD	IN458/	<u>\</u>	
Q1	250004	SI PNP TRANSISTOR	NATIONAL	2N3906	5/1018	9
Q2	230069	N-CHAN JEET	SILICONIX		2N44I6	
Q3	230069	N-CHAN JEET	SILICONIX	2N441	6	-
 <u></u>	230003	N-CHAN JEET	TELEDYNE	01899	JF	8
Q5	230003	N-CHAN JEET	TELEDYNE	01899		-
R 6	230003	N-CHAN JFET	TELEDYNE	U1899-	F	
२ ७	230003	N-CHAN JEET	TELEDYNE	U1899J	F	-
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DUSIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
Q8	230003	N-CHAN JFET	TELEDYNE	U1899JF	
R9	250027	SI DUAL PNP TRANSISTOR	MICRO POWER SYSTEMS	MP351	<u> </u>
910	240038	SI NPN DUAL TRANSISTOR	MICRO POWER SYSTEMS	MP318	7
31I		NOT USED			-
212	240038	SI NPN DUAL TRANSISTOR	MICRO POWER SYSTEMS	MP318	-
213	240038	SI NPN DUAL TRANSISTOR	MICRO POWER SYSTEMS	MP318	-
314	240038	SI NPN DUAL TRANSISTOR	MICRO POWER SYSTEMS	MP318	-
Q15	2400 38	SI NPN DUAL TRANSISTOR	MICRO POWER SYSTEMS	MP 318	
Q16	240013	SI NPN TRANSISTOR	NATIONAL	BC184C/TO18	2
Q17	240038	SI NPN DUAL TRANSISTOR	MICRO POWER SYSTEMS	MP318	
Q18	240038	SI NPN DUAL TRANSISTOR	MICRO POWER SYSTEMS	MP318	
ຊ ເອ ຼ	250004	SI PNP TRANSISTOR	NATIONAL	2N3906/TOI8	
Q20	_250004	SI PNP TRANSISTOR	NATIONAL	2N3906/TOI8	
Q21	250004	SI PNP TRANSISTOR	NATIONAL	2N3906/TOI8	
Q22	230042	N-CHAN I LIM 3.0mA	SILICONIX	J 509	3
Q23	250004	SI PNP TRANSISTOR	NATIONAL	2N3906/TOI8	
Q24	240006	SI NPN TRANSISTOR	NATIONAL	2N3904/TOI8	5
Q25	240006	SI NPN TRANSISTOR	NATIONAL	2N3904/TOI8	
ି ସେଥି ।	240025	DARLINGTON	MOTOROLA	MPSA 13	1
Q27	240013	SI NPN TRANSISTOR	NATIONAL	BC 184C/TO18	
Q28	230042	N-CHAN I LIM 3.0mA	SILICONIX	J509	
Q29	250004	SI PNP TRANSISTOR	NATIONAL	2N3906/TOI8	
Q30	250004	SI PNP TRANSISTOR	NATIONAL	2 N3906/T018	
NOTES. SEE SHEET 2 FOR L	ATEST ISSUE		DATE - DRAM	N TITLE	ELECTRONICS LTD
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	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACI PART No.	TURER'S	No. USED Per Assy,
240006	SI NPN TRANSISTOR	NATIONAL	2N3904	/7018	-
250004	SI PNP TRANSISTOR	NATIONAL	2N3906	/ TOI8	-
250004	SI PNP TRANSISTOR	NATIONAL	2N3906	/ 7018	-
240006	SI NPN TRANSISTOR	NATIONAL	2N3904	/ 1018	
240006	SI NPN TRANSISTOR	NATIONAL	2N3904	/ 1018	-
230042	N-CHAN I LIM 3.0 mA	SILICONIX	J509		-
250008	SI PNP TRANSISTOR	NATIONAL	BC214C	/ דסו 8	1
239072-1	N-CHAN JEET SEL	DATRON (2.5V & VP & 3.5	V) UI899J	F (GREEN)	2
239072-1	N-CHAN JEET SEL	DATRON (2.5V € Vp ≤ 3.5	V) UI899J	F (GREEN)	
230070	N-CHAN DUAL JET	SILICONIX	2N5911		2
230070	N-CHAN DUAL JEET	SILICONIX	2N5911		-
230065	N-CHAN I LIM 4.7 mA	SILICONIX	JSII		2
230065	N-CHAN I LIM 4.7 mA	SILICONIX	J511		
	N-CHAN JEET SEL	DATRON (3.5V & Vp & 4.50)	U1899-	IF (BLUE)	2
239075-1	N-CHAN JEET SEL	DATRON (3.51 4 Vp 64.50)	018997	F (BLUE)	
230035	N-CHAN JEET	TELEDYNE	U1897JF		1
	NOT USED				
230003	N-CHAN JEET	TELEDYNE	U1899JF		
	NOT USED				-
260053	7650 OP AMP	INTERSIL	ICL 7650	CPD	J
260073		NATIONAL	LF411CI	4	2
	5532 DUAL OP AMP	SIGNETICS	NE 5532	N	1
260066	II OP AMP	NATIONAL	LMILCN	1	2
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	250004 250004 240006 240006 230042 250008 239072-1 239072-1 239070 230065 230065 230065 230065 230075-1 239075-1 239075-1 230035 230003 260053 260073 260042	PART No. Si NPN TRANSISTOR 240006 Si NPN TRANSISTOR 250004 Si PNP TRANSISTOR 250004 Si PNP TRANSISTOR 240006 Si NPN TRANSISTOR 240006 Si NPN TRANSISTOR 240006 Si NPN TRANSISTOR 230042 N-CHAN I LIM 3.0mA 250008 Si PNP TRANSISTOR 230042 N-CHAN I LIM 3.0mA 250008 Si PNP TRANSISTOR 239072-1 N-CHAN JFET SEL 239072-1 N-CHAN JFET SEL 230070 N-CHAN DUAL JFET 230070 N-CHAN DUAL JFET 230065 N-CHAN I LIM 4.7 mA 230065 N-CHAN I LIM 4.7 mA 230075-1 N-CHAN JFET SEL 230035 N-CHAN JFET SEL 230035 N-CHAN JFET 230035 N-CHAN JFET 230003 N-CHAN JFET 260053 7650 OP AMP 260073 411 OP AMP 260066 11 OP AMP	PART No. MANUFACTURER 240006 Si NPN TRANSISTOR NATIONAL 250004 Si PNP TRANSISTOR NATIONAL 250004 Si PNP TRANSISTOR NATIONAL 240006 Si NPN TRANSISTOR NATIONAL 240006 Si NPN TRANSISTOR NATIONAL 240006 Si NPN TRANSISTOR NATIONAL 230042 N-CHAN I LIM 3.0 mA SILICONIX 250008 Si PNP TRANSISTOR NATIONAL 239072-1 N-CHAN JFET SEL DATRON (2.5V & VP & 3.5 239072-1 N-CHAN JFET SEL DATRON (2.5V & VP & 3.5 230070 N-CHAN JFET SEL DATRON (2.5V & VP & 3.5 230070 N-CHAN DUAL JFET SILICONIX 230065 N-CHAN DUAL JFET SILICONIX 230065 N-CHAN J LIM 4.7 mA SILICONIX 230065 N-CHAN JFET SEL DATRON (3.5V & VP & 4.50) 230035 N-CHAN JFET SEL DATRON (3.5V & VP & 4.50) 230035 N-CHAN JFET TELEDYNE NOT USED 260053 7650 OP AMP INTERSIL	PART No. MANUFACTURER PART No. 240006 Si NPN TRANSISTOR NATIONAL 2N3904 250004 Si PNP TRANSISTOR NATIONAL 2N3906 240006 Si NPN TRANSISTOR NATIONAL 2N3906 240006 Si NPN TRANSISTOR NATIONAL 2N3904 250008 Si PNP TRANSISTOR NATIONAL 2N3904 239072-1 N-CHAN JFET SEL DATRON (2:5V 4 VP <3:5V)	PART No. MANUFACTURER PART No. 240006 Si NPN TRANSISTOR NATIONAL 2N3904/T018 250004 Si PNP TRANSISTOR NATIONAL 2N3906/T018 250004 Si PNP TRANSISTOR NATIONAL 2N3906/T018 240006 Si NPN TRANSISTOR NATIONAL 2N3906/T018 240006 Si NPN TRANSISTOR NATIONAL 2N3904/T018 230042 N=CHAN I LIM 3:0mA SILICONIX J509 250008 Si PNP TRANSISTOR NATIONAL Bc214c/T018 239072-1 N=CHAN JFET SEL DATRON (2:5V 4 VP 4 3:5V) UI899JF (GREEN) 230070 N=CHAN JFET SEL DATRON (2:5V 4 VP 4 3:5V) UI899JF (GREEN) 230070 N=CHAN JAL JFET SILICONIX 2NS911 230065 N=CHAN JET SEL DATRON (3:5V 4 VP 4 3:5V) UI899JF (BLUE) 230075-1 N=CHAN JFET SILICONIX ZNS911 230035 N=CHAN JFET SEL DATRON (3:5V 4 VP 4 - 50) UI899JF (BLUE) 230035 N=CHAN JFET TELEDYNE UI899JF (BLUE) 230035<

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DISIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
M5	260066	II OP AMP	NATIONAL	LMIICN	
Мб	260075	2903 DUAL COMPARATOR	NATIONAL	LM 2903 N	2
M7	280025	QUAD ANALOS SWITCH	MOTOROLA	MC14066BCP	4
M8	280025	QUAD ANALOG SWITCH	MOTOROLA	MC14066 BCP	
49	280124	HEX D-TYPE FLIP-FLOP	MULLARD	HEF 40174P	2
10	280079	QUAD 2 1/P OR	MOTOROLA	MC14071 BCP	1
MIL	280032	DECADE COUNTER / DIV.	MOTOROLA	MC14017 BCP	2
112	260050	412 DUAL FET I/P OP AMP	NATIONAL	LF4I2CN	2
VII3	280085	QUAD 2 I/P AND	MOTOROLA	MC14081 BCP	
M14	280025	QUAD ANALOG SWITCH	MOTOROLA	MC14066BCP	-
M15	280032	DECADE COUNTER / DIV.	MOTOROLA	MC14017BCP	
MI6	280025	QUAD ANALOG SWITCH	MOTOROLA	MCI4066 BCP	
M17	28 01 24	HEX D-TYPE FLIP-FLOP	MULLARD	HEF 40174P	~
M18	280122	TRIPLE 3 1/P OR	MOTOROLA	MC14075 BCP	2
MI9	260050	412 DUAL FET I/P OP AMP	NATIONAL	LF 4IZCN	
120	280023	QUAD 2 I/P NOR	MOTOROLA	MCI400IUBCP	3
121	260075	2903 DUAL COMPARATOR	NATIONAL	LM2903N	
M22	290135	HV TRANSISTOR ARRAY	PLESSEY	SL3183	1
M23	280023	QUAD 2 1/P NOR	MOTOROLA	MC 14001 UBCP	-
M24	260027	714 OP AMP	FAIRCHILD	A 714 HC	
M25	280035	BCD/DECIMAL DECODER	MOTOROLA	MC 14028 BCP	1
M26	280023	QUAD 2 1/P NOR	MOTOROLA	MC 14001 UBCP	-
M27	280122	TRIPLE 3 I/P OR	MOTOROLA	MC 14075 BCP	

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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFAC PART No.	MANUFACTURER'S PART No.	
M28	290090	7 X DARLINGTON DRIVER	SPRAGUE / EXAR	ULN 200	ULN 2002 A / XR 2202 CP	
V129	290090	7× DARLINGTON DRIVER	SPRAGUE / EXAR	ULNZOO	2A / XR2202CP	
V130	280125	PHASE DETECTOR	NATIONAL	MM740	932 N	<u> </u>
131	260073	411 OP AMP	NATIONAL	LF411CN	1	-
132	260087	BIFET OP. AMP	MOTOROLA	MC34	OBIP	1
RLI		NOT USED	_			5
RL2	330030	RELAY 4P NO	SDS		54-240	
RL3	330032	RELAY IP 2W MINIATURE	TAKAMISAWA	MZ24	ISC	
?L4	330029	RELAY 2P2W	SDS	DS2E -	DC 24V	!
?L5	330029	RELAY 2P2W	SDS	DS2E -	DC24V	·
૨ μο	330029	RELAY . 2P 2W	SDS	DS2E -	DC24V	
RL7	330029	RELAY 2P 2W	SDS	DS2E -	DC 24V	
RL8	330029	RELAY 2P 2W	SDS	DS2E-		
RL9	330030	RELAY 4P N/O	SDS	54-24	/	-
RLIO	330030	RELAY 4P NO	SDS	54-24	/	-
RLII	3 30 0 31	RELAY 2P NO 2P NC	SDS	52-241	/	1
RLIZ	330012-2	RELAY REED IA GUARDED	HAMLIN	HE721A	5134	1
RLI3	330029	RELAY 2P2W	SDS	DS2E- D	C24V	-
RLI4	330029	RELAY 2P2W	SDS	DS2E- C	x24V	-
7115	330029	RELAY 2P2W	SDS	DSZE-C	00241	-
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JESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
RLIG	330029	RELAY 2P2W	SDS	DS2E-DC24V	
RL17	330029	RELAY 2P2W	SDS	DS2E-DC24V	
rl18	330030	RELAY 4P NO	SDS	54-24V	
RLIS	330030	RELAY 4P NO	SDS	54-24V	-
RL20	330029	RELAY 2P2W	SDS	DS2E - DC24V	
L.I	370001	100H O.85 & RF CHOKE	PLESSEY	58/10/0011/10	6
Γ2	370001	10µH 0.85 & RF CHOKE	PLESSEY	58/10/0011/10	
L3	370001	IONH 0.85 & RF CHOKE	PLESSEY	58/10/0011/10	
L4	370001	IONH 0.85 S RF CHOKE	PLESSEY	58/10/0011/10	-
L5		NOT USED			
L6	370001	10 H 0.85 & RF CHOKE	PLESSEY	58/10/0011/10	-
L7	370001	IOHH O.852 RF CHOKE	PLESSEY	58/10/0011/10	-
L8	370027	47µH I IN RF CHOKE	SIGMA	<u>5C30-10-2533</u>	-10
F1	920120	FUSE IA 125V 7mm		275 001	2
F2	920120	FUSE 1A 125V 7mm	LITTLEFUSE	275 001	
	410172-11	PCB - AC			1
	400639-1	ATTENUATOR/CAGE ASSY	DATRON		1
NOTES. SEE SHEET 2 FOR L	ATEST ISSUE			DRAWN TITLE	
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SIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
	450442-1	HEATSINK			
	540002	22 SWG B.T.C. WIRE			A/R
4	512999	7/.2 PTFE WIRE			A/R
	560002	7/34 AWG CO-AX			Alr
	590007	LACING CORD		MW/062 BLACK	A/R
	590031	HEATSHRINK SLEEVE 32mm	HELLERMANN ELECTRIC		AlR
	5900 32	HEATSHRINK SLEEVE 48mm	4 n		Alr
	604056	4 WAY +1" PCB PLUG GD PL	MOLEX	22-10-2041	10
	605059	8 WAY DIL SOCKET	JERMYN	J23-18008	12
	605060	14 WAY DIL SOCKET	JERMYN	J23-18014	12
	605061	IG WAY DIL SOCKET	JERMYN	J23-1801G	8
KA, LKB	605127	2 WAY .I" SHORTING SKT.	ASSMANN	AKSPL-G	2
	611012	M3×12mm POZI-CSK STEEL	ZN PL		3
	611004	M3 × 6mm POZIPAN STEEL	ZNPL		2
	612030-1	M3×14mm STANDOFF	DATRON	SEE DRG GI2***	!!
	612026-1	M3 × 6mm STANDOFF	DATRON	SEE DRG 612+++	/
	614001	M3 CLEAR × 4 mm STANDOF	FDATRON		3
	613005	M3 INT SHAKEPROOF	ZN PL		
	613029	M3 WAVY WASHER S.S.			1
	620007	TEST POINT TERMINAL	MICROVAR	TYPE C30	44
	630024	STEATITE BEAD IG SWG	PARK ROYAL PORCELAIN	Nº 2 (LARGE)	24
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
	630036	STEATITE BEAD 18 SWG	PARK ROYAL PORCELAIN	Nº I	10
a ge in aine a : par any any a a a a a a a a	630121	PCB EJECTOR GREEN	RICHCO	CBF	2
	450424 - 1	TOP GUARD SHIELD			1
	450425-1	BOTTOM GUARD SHIELD			1
	900003	HEATSINK COMPOUND	RS	544-311	A/R
	590001	SLEEVE \$3.0 MAX	HELLERMANN ELECTRIC	HI5 × 20mm BLK. HELSYN	2
	590004	SLEEVE \$ 1.0 PTFE	HELLERMANN ELECTRIC	FEIO	A/R
KA, LKB	604046	3 WAY .I" PCB PLUG GD.PL.	MOLEX	22-10-2031	2
	620003	SOLDER PIN	HARWIN	H 2105 AO 1	3
	900004	SILICONE RUBBER COMPOUND	RS	554-311	A/R
·	590006	HEATSHRINK SLEEVE \$ 2.4			A/R
	630243	GLASS BEAD 2.4 0/D x 0.8 1/D x	1.8. MANSOL (PREFORMS)	M5363B/3	40
	510000	7/-2 PVC INSULATED BLACK			A/R.
		· · · · · · · · · · · · · · · · · · ·			
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		ECO	2162	2199	2210	2525	2256	2323	2365	2596																																	
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FUNCT. TEST	470614/ft	1-2	- -																																								
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
RI	008037	ORIB 10% 2W5 WIREWOUND	WELWYN	W51	
R2	000820	828 5% 1/4W CARBON	MULLARD	CR25	1
R3	000821	820R 5% YAW CARBON	MULLARD	CR25	1
R4		NOT USED			
R5	000688	GR8 5% 1/4W CARBON	MULLARD	CR25	1
RG	000103	IOK 5% YAW CARBON	MULLARD	CR25	2
R7	000103	IOK 5% YAW CARBON	MULLARD	CR25	-
RB	080084	90R00 .1% 3ppm M.FOIL	VISHAY	Slozc	1
<u> </u>	080085	DOORO .1% 3ppm M.FOIL	VISHAY	· SIO2C	
RID	067502	5k POT 20TURN CERMET	BECKMAN	68X	2
RII	101000	100 R 5% VAW CARBON	MULLARD	CR25	9
R12	000101	100 8 5% VAW CARBON	MULLARD	CR25	-
RIB	000393	39K 5% VAW CARBON	MULLARD	CR25	2
RIA	000104	100k 5% YAW CARBON	MULLARD	CR25	3
R15	000101	IOOR 5% YAW CARBON	MULLARD	CR25	-
RIG	000101	100R 5% /4 W CARBON	MULLAR D	CR25	-
R17	000104	100k 5% 14 W CARBON	MULLARD	CR25	
RIB	012001	2KOO 1% 18 W 50ppm MF	HOLCO	HBC	2
RID	012001	2KOO 1% /8 W 50 pm MF	HOLCO	HBC	-
R20	011302	13KO 1% 18 W 50ppm MF	HOLCO	HBC	2
R21	011 302	13KO 1% /8 w 5000 MF	HOLCO	HBC	-
R22	000393	39K 5% 1/4W CARBON	MULLARD	CR25	-
R23	067202	2K POT 20TURN CERMET	BECKMAN	68X	1
ISS. ECO DATE CHKD				01.11 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0	
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DESIGNATOR	PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
R24		NOT USED			
R 25		NOT USED			
R 2 6	011001	IKOD 1% YOW 50ppm MF	HOLCO	HBC	2
R27	012670	267R 1% YOW 50ppm MF	HOLCO	нвс	1
R28	011001	1KOO 1% /8W 50ppm MF	HOLCO	HBC	-
R 2 D	000101	IOOR 5% VAW CARBON	MULLARD	CR25	
R30	000101	IDOR 5% YAW CARBON	MULLARD	CR25	
R31	066200	20R POT 38 SQ. VERT.CERME	BECKMAN	72 × W	
R32		NOT USED			
R33		NOT USED			
R34	000102	IK 5% VAW CARBON	MULLARD	CR25	3
R35	000102	IK 5% 1/4 W CARBON	MULLARD	CR25	
R36	NOT USED				-
R 37	000101	IDOR 5% VAW CARBON	MULLARD	CR25	
R 38	000101	100R 5% VAW CARBON	MULLARD	CR25	
R 39	013401	3K40 1% 1/8 W 50pp MF	HOLCO	HBC	
R 40	012002	20KO 1% 1/8 W 50pp # MF	HOLCO	НВС	
R 41	000104	IOOK 5% 1/4 W CARBON	MULLARD	CR75	-
R 42		NOT USED			
R 43	080083	2k0000.01% 3ppm M.FOIL	VISHAY	S102C	3
R 44	080096	18 K000 .01% 3ppm M.FOIL	VISHAY	5102C	. 1
R 45	080082	20k000 .01% 3ppm M. FOIL		5102C	2
R 46	080083	2 K0000 .01% 3 ppm M. FOIL		S102C	
NOTES. SEE SHEET FOR L	ATEST ISSUE			лте 7. 5. 85 Druwn IL	
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DESIGNATOR	1	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACT PART No.	URER'S	No. USED Per Assy.
R47		080082	20k000 .01% 3ppm M. FOIL	VISHAY	S102C		-
R48		080083	2k0000 .01% 3ppm M. FOIL	VISHAY	S102 C		-
R49		000100	IOR 5% 1/4 W CARBON	MULLARD	CR25		2
R50		000100	IOR 5% VAW CARBON	MULLARD	CR2 5		-
R51		000105	IM 5% YAW CARBON	MULLARD	CR25		2
R52		000153	ISK 5% 1/4W CARBON	MULLARD	CR25		1
R53		067201	200R POT 20TURN CERMET	BECKMAN	68X		
R54		067 502	5K POT ZOTURN CERMET	BECKMAN	68X		-
R55		067 503	50K POT 20TURN CERMET	BECKMAN	68X		1
R56		067 504	500K POT 20TURN CERMET	BECKMAN	X B Q		
R57		067 205	2M POT 20TURN CERMET	BECKMAN	GBX		1
R 58		067100	IOR POT 20TURN CERMET	BECKMAN	X80		1
R 59		000101	100R 5% 1/4W CARBON	MULLARD	CR25	1	-
R 60	(FSV)	041655	16M5 1% Y2W 150pp # WF.	MEPCO	505371	-	<u> </u>
R61	(FSV)	011698	16R9 1% /8W 50ppm MF	HOLCO	HBC		ļ
R62		070134 - 3	99K980 50ppm WIREWOOND	MANN	SEE DR	KG.	11
RG3		070133 - 3	IOKOOGO 50ppm WIREWOUND	MANN	SEE DI	2G.	1
R 64		070132-3	IKOOOAO 50pp WIREWOUNT	MANN	SEE DI	ZG.	<u> </u>
R65		070131 - 3	100R040 50ppm WIREWOUND	MANN	SEE D	RG.	
R 66	(FSV)	012493	249K 1% /BW 50pm MF	HOLCO	HBC		1
R67		000105	IM 5% 4W CARBON	MULLARD	CR25		
R68	(FSV)	042264	2M26 1% 12W 100ppm CF	ALLEN BRADLEY	CC.		1
R69	(F5V)	011503	150K 1% /8W 50ppm MF	HOLCO	НВС	•	1
NOTES. SEE SHEET 2	FOR LATES	T ISSUE			7. 5. 85	datron	ELECTRONICS LTD
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
RTO (FSV)	012672	26K7 1% 1/8w 50ppm MF		HBC .	1
R71 *	080097-1	99MB 01% 15ppm MF	CADDOCK	SEE DRG.	1
R72	070130 - 3	10 ROOAD 50pp m WIRE WOUND	MANN	SEE DRG.	1.
R73	070136 -3	3M9940 50ppm WIRE WOUND		SEE DRG.	1
R74	070196 -1	999K70 50ppm WIREWOUND	7	SEE DRG .	
R75 (F5V)	014991	4K99 1% 18W 50ppm MF	HOLCO	HBC.	
R7G (FSY)	012670	267R 1% /BW 50ppm MF	HOLCO	HBC.	
R 77	064104	100 K POT ISTURN CERMET	BECKMAN	89 P	I
R 78	064202	2K POT ISTURN CERMET	BECKMAN	89P	I
R 79	080081-1	10R00 0.1%	VISHAY	SEE DRG	1
R 80	080022-1	OR100 1%	ISABELLENHUTE	SEEDRG	1
ROI	000471	4708 5% 4W CARBON	MULLARD	CR25	1
R82	041825	18M2 1% 12W 100ppm CF	ALLEN BRADLEY	сс	2
R83	041825	18 M2 1% 1/2W 100ppm CF		CC	-
R84		NOT USED			
R85	555000	2k2 5% 1/4W CARBON	MULLARD	CR25	1
R86	000102	IK 5% 1/4W CARBON	MULLARD	CR25	-
AN I	260060	IM XB 2% NETWORK	АВ	850-91-1M	2
ANZ	090085	12K XB 2% NETWORK	АВ	761 - 3 - 12K	1
AN3	090096	IMXB 2% NETWORK	АВ	850 - 91 - IM	-
AN4	090131	IOK X4 2% NETWORK	АВ	108-3-RIOK	2
AN5	090131	IOK X4 2% NETWORK	AB	108-3-RIOK	-
NOTES. * R71 A		371 A AND B 49M9 1 080098		5. 85 datron	ELECTRONICS LTD
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
R87	000274	270k 5% 4W CARBON	MULLARD	CR25	2
R88	000274	270k 5% 4W CARBON	MULLARD	CR 25	
R89	000220	22 R 5% 4W CARBON	MULLARD	CR 25	1
ROO		NOT USED			
ROI	014322	43K2 1% 8W 50ppm MF	HOLCO	HBC	2
R92	014322	43K2 1% 8W 50ppm MF	HOLCO	HBC	-
R93	012742	27K4 1% 8W 50 ppm MF	HOLCO	HBC	2
R94	012742	27K4 1% 8W 50ppm MF	HOLCO	HBC	
R95	012212	22KI 1/ 18W 50 ppm MF	HOLCO	HBC	I
R96	014 992	49K9 1% 8W 50 ppm MF	HOLCO	HBC	l
R97	019091	9K09 1% 18W 50ppm MF	HOLCO	H8C	I
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SEE SHEFT 2 FOR L	ATEST ISSUE			<u> </u>)	4700
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DESIGNATOR	DATRON PART No.	DESCRIPTION ,	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
CI	104026	47nf + 20% 50V CER DISC	SIEMENS	B37449	17
62	104026	47 .F 1 28% 50V CER DISC	SIEMENS	B31449	-
63		NOT USED			-
C4	110035	220nF 20% GBY POLYESTER		MKS2	2
C5	104026	47nF + 20% 50V CER DISC	SIEMENS	B37449	-
60	104026	47nF 120% 50V CER DISC		B37449	
C7	104026	47nF -20% 50V CER DISC	SIEMENS	B374 1 9	-
CB	NOT USED				-
60	NOT USED				-
C10	NOT USED				-
CII	NOT USED				
CIZ	104026	47nF 1 28% 50V CER DISC	SIEMENS	B37449	
C13	150016	14F 20% 35V DIP TANT	UNION CARBIDE	KIROE35	2
614	104026	97nF 18% 50Y CER DISC	SIEMENS	B37449	-
C 15	110042	100nF 20% G3V POLYESTER	WIMA	MK52	3
C 16	110042	1000F 20% G3V POLYESTER	WIMA	MK52	-
C 17	110035	220 NF 20% 63V POLYESTER	WIMA	MK52	-
C18	110042	100 F 20% G3V POLYESTER	WIMA	MKSZ	-
C19	150020	IONE 20% 25V DIP TANT	UNION CARBIDE	KIDE 25	4
C 20	104026	47nF -20% 50V CER DISC	SIEMENS	B37449	-
C21	104026	47.F - 20% 50V CER DISC	SIEMENS	B37449	-
622	150004	100 AF 20% GV3 DIP TANT	UNION CARBIDE	KIODE 6V3	1
C 23	150020	104 F 20% 254 DIP TANT	UNION CARBIDE	KIDE 25	-
NOTES. SEE SHEET 2 FOR L	ATEST ISSUE			5.85 datron	
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
C24	104026	47 nF - 20% 50V CER DISC		B37449	
C 25	104026	47 nF - 20% 50Y CER DISC	SIEMENS	837449	-
C 26	150020	104 F 20% 25V DIP TANT	UNION CARBIDE	KIDE 25	-
C 27	104026	47nF 128% SOV CER DISC	SIEMENS	837449	-
C 28	15 00 20	104 F 20% 25V DIP TANT	UNION CARBIDE	KIDE 25	-
C 29	150005	242F 20% IGY DIP TANT	UNION CARBIDE	K2R2EIG	2
C 30	150005	242F 20% 16V DIP TANT	UNION CARBIDE	KZRZEIG	-
C 31	102100	IDPF 5% 500V CER DISC	ITT	CDIO	1 1
C 32	150010	INF 20% 35Y DIP TANT	UNION CARBIDE	KIROE 35	-
C 33	104026	47nF 120% 50V CER DISC	SIEMENS	B37449	-
C 34	104026	47nF \$2% SOY CER DISC	SIEMENS	B37449	-
と35	104026	47nF 18% SOV CER DISC	SIEMENS	B37449	-
C 36	150021	2245 20% 25V DIP TANT	UNION CARBIDE	K22E25	2
C 37	1500.21	2245 20% 25V DIP TANT	UNION CARBIDE	K22E25	-
C 38	104026	47nF 18% 50V CER DISC	SIEMENS	B37449	-
C 39	104026	47nF 128% 50V CER DISC	SIEMENS	B37449	-
C 40	140054	JnF 20% 400VAC POLYPROP	WIMA	FKPI	3
C 41	140054	I NF 20% 400VAC POLY PROP	WIMA	FKPI	-
C 42	140054	I nF 20% 400Y AC POLY PROP	WIMA	FKPI	-
<u>C 43</u>	102 330	33pf 5% 500V CER DISC	ITT	CDIO	2
C 11	102470	47pf 5% 500V CER DISC	177	CDIO	2
C45		NOT USED			
C46	102101	100pF 10% 500V CER DISC	ודד	CDIO	1
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assγ.
C47	102 3 30	33PF 5% 500V CER DISC	ITT	CDIO	-
C48	102270	27PF 5% 500Y CER DISC	ITT	CDIO	I
C49	102470	47pf 5% 500V CER DISC	<u>דדו</u>	CDIO	-
<u></u>	20000	75 1 754 4 2 4 1 1004		IN4/48	5
DI	200001	75mA 75V GP SI DIODE	FAIRCHILD		
D2	200001	75mA 7.5v GP SI DIODE	FAIRCHILD	IN4148	
D3	210062	6V2 400mW ZENER	MULLARD	BZYBBC	2
D4	210062	GV2 400mW ZENER	MULLARD	BZY88C	
D5	213012	2VO 250mW REG DIODE	MULLARD	BZV46 - 2VO	- 1
DG	210033	3V3 400 W ZENER	MULLARD	BZY88C3V3	
D7	213009	15Y 5W ZENER	UNITRODE	TV5 515.	4
D8	200001	75 A 75V GP SI DIODE	FAIRCHILD	11448	
ea	200001	75MA 75V GP SI DIODE	FAIRCHILD	IN4148	
010	200001	75 MA 75V GP SI DIODE	FAIRCHILD	INAIAB	-
DII	213009	15V 5W ZENER	UNITRODE	TV5515	-
D12-	21300 9	15V 5W ZENER	UNITRODE	TV 5515	-
013	213009	15V 5W ZENER	UNITRODE	TYSSIS	
DI4	NOT USED.				-
D15	NOT USED.				-
DIG	200002	IA SOV GP SI DIODE	FAIRCHILD	IN4001	2
017	200002	IA SOV GP SI DIODE	FAIRCHILD	IN4001	-
DIB	213000	5Y 5W ZENER	UNITRODE	TV5505	2
NOTES. SEE SHEET 2 FOR L	ATEST ISSUE				
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DATRON PART No. PRINCIPAL MANUFACTURER DESIGNATOR DESCRIPTION MANUFACTURER'S No. USED PART No. Per Assy. -213006 DIS 5V 5W ZENER UNITRODE TV5 505 ----BC327/TO18 1 QI 250011 SI PNP TRANSISTOR NATIONAL 230001 SILICONIX J**50**6 з Q2 N-CHAN I LIM 1.4 MA 2N3906 / TO92 ١ Q3 SI PNP TRANSISTOR 250004 NATIONAL J506 -Q4 230001 N. CHAN I LIM 1.4 mA SILICONIX 2N3904 / TO92 2 Q5 240006 SI NPN TRANSISTOR NATIONAL aG 230031 N - CHAN DUAL J FET U404 1 SILICONIX ۱ Q7 230036 N- CHAN J FET SILICONIX JIOS ୟଞ NOT USED -ବ୍ର 230001 N-CHAN I LIM 1.4 mA J506 -Q10 NOT USED -QII 240006 SI NPN TRANSISTOR NATIONAL 2N3304 / TO32 -NOTES. DATE datron electronica LTD 7. 5. 85 SEE SHEET 2 FOR LATEST ISSUE TITLE 4700 ISS E.C.D. CHECKED I / Ω PCB ASSEMBLY. OVEC NUMBER 400614 10 or 15 DATE DATE CHIKD

DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
MI	260069	411 OP AMP	NATIONAL	LF411 CH	2
M2	NOT USED	AMP			-
MB	260083	LTCI052CN OP AMP	LINEAR TECHNOLOGY	LTC 1052 CN	1
M3	260065	OP27 OP AMP	PMI	OP27FZ	2
M5		NOT USED			_
MG	280035	BCD/DECIMAL DECODER	MOTOROLA	MC14028 BCP	2
M7	260069	411 OP AMP	NATIONAL	LF4IICH	
MB	260065	OP27 OP AMP	PMI	OP27 FZ	-
พจ	280045	TRIFLE ,3 1/P NOR	MOTOROLA	MC14-025 BCP	2
MIO	260086	DUAL POWER AUDIO AMP	NATIONAL	LM1877N	1
MU		NOT USED			-
M12	290090	7 X DARLINGTON DRIVER	SPRAGUE / EXAR	ULN 2002A / XR2202CP	<u> </u>
міз		NOT USED			-
MI1		NOT USED			
M15	260039	324 QUAD OP AMP	NATIONAL	LM324 N	<u> </u>
MIG	280023	QUAD 2 1/P NOR	MOTOROLA	MC 14001 UBCP	1
MI7	280017	HEX INVERTER	MOTOROLA	MC14069 UBCP	11
MI8		NOT USED			
M19	280045	TRIPLE 3 1/P NOR	MOTOROLA	MC14-025 BCP	-
M20	260042	5532 DUAL OP AMP	SIGNETICS	NE 5532 N	11
NOTES.			DATE	7. 5. 85 datron	
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
RLI	330042-2	RELAY 3P NO IP NC		SEE DRG	1
RL2	330012-2	RELAY REED IA GUARDED	HAMLIN	HE 72145134	4
RL3	330012-2	RELAY REED IA GUARDED	HAMLIN	HE721A5134	-
RL4	33001 2 ~ 2	RELAY REED IA GUARDED	HAMLIN	HE 72145134	-
RL5	330012-2	RELAY REED IA GUARDED	HAMLIN	HE 72145134	
RLG		NOT USED			-
RL7	330039	RELAY 4 POLE N/O	SDS	54-L-GV	12
RLO	330029	RELAY 2P2W	SDS	DS2E-M-DC24V	2
RLD	330029	RELAY 2PZW	SDS	D52E-M- DC24V	-
RLIO	330039	RELAY 4P NO	SDS	54- L-6V	-
RLII	330039	RELAY 4P NO	SDS	54- L-6V	- ·
RL12	3300.39	RELAY 4P N/O	SDS	54- L-6V	-
RL 13	3300 39	RELAY 4P N/0	SDS	54 - L-6V	-
RLIA	3300 39	RELAY 4P NO	SDS	54- L-6V	-
RL15		NOT USED			-
RL IG	3300 39	RELAY 4P NO	SDS	54-L-6V	-
RL 17	3300 39	RELAY 4P NO	SDS	54- L-6V	-
RL 18	3300 39	RELAY 4P NO	SDS	54- L-6V	-
RL 19,20,23	3300 39	RELAY 4P NO	SDS	54- L-6V	-
RL24,25	3300.30	RELAY 4P NO	SDS	S4-24V	2
RL2G	330040	RELAY IP 2W	SPS	DSIE - SL-GV	I
NOTES.	TEST ISSUE			DATE Datron 7. 5.85 Datron DRAWN II. TITLE 470	
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E.C.O. DATE					
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
_ 1	370001	IO _M H 0.85 Ω RF CHOKE	PLESSEY	58/10/0011/10	2
_2	370001	IONH O'85 RE CHOKE	PLESSEY	58/10/0011/10	-
	400669~1	I/S CLAMP ASSY	DATRON		1
	410347-1	I/A PRINTED CIRCUIT	BOARD		1
	450419 - 2	CURRENT HEATSINK			1
	512000	70.2 PTFE WIRE BLACK			A/R
	512222	7/0.2 PTFE WIRE RED			A/R
	512333	7/0.2 PTFE WIRE ORANGE			∧_R
	512444	7/0.2 PTFE WIRE YELLOW			A/R
	512555	7/0.2 PTFE WIRE GREEN			A/R
	512666	7/0.2 PTFE WIRE BLUE			A/R
	512868	7/0.2 PTFE WIRE GREY			A/R
	540002	225WG TINNED COPPER WIRE			A/R
	512999	7/02 WHITE PTE INSULATED	WIRE		A/R
•	540006	1/0.4 BLK. PTFE INS! WIRE		TO BSG 210 TYPE A	A/R
	560008	4 CORE PTE SCREENED 19	0.15 CABLE	SEE DRG.	370
	590001	SLEEVE Ø3 MAX CABLE	HELLERMANN ELECTRIC	HI5 × 20mm BLK	12
	590029	HEATSHRINK SLEEVE 09	HELLERMANN ELECTRIC	SFM9-3BK	40
	590007	LACING CORD			AIR
NOTES. SEE SHEET 2 FOR L	590007	LACING CORD	2 DAT DA	7. s. 85 datro	
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
JI	604033	4 WAY . I" PCB PLUG GD. PL	MOLEX	22-29-2041	2
	602001	FSV TERMINAL	MOLEX	02-04-5114	16
	605 059	8 WAY DIL SOCKET			3
	605060	14 WAY DIL SOCKET			7
	605061	IG WAY DIL SOCKET .			3
	605052	8 WAY . I" HOUSING	MOLEX	22-01-2085	1
	611008	M3X 10 MM POZI-CSK STER	L ZN PL		2
	611004	M3X6 MM POZI-PAN STE	EL. ZN.PL.		3
	611015	M3 X 8mm POZI-C.S.K STE	EL. ZN.PL.		2
	605057	CRIMP TERMINAL GD. PL	. MOLEX	4809-GL	8
	605070	20 WAY DILSOCKET			2
	613029	M3 WAVY WASHER SS			5
	613017	M3 FLAT WASHER NYLON			34
	615002	M3 FULL NUT STEEL ZN.PL			4
`*	618001	INSULATING BUSH TO 220		563590	2
	620001	CLOVERLEAF PTE INSUL.	SEALECTRO	FTE I2 P 59	16
	620003	SOLDER PIN	HARWIN	H 2105 AOI	9
	620005	CLOVER LEAF PTE INSUL	SEALECTRO	FTE 15259	20
	620007	TEST POINT TERMINAL	MICROVAR	TYPE C30	11
`* *´	620005	CLOVERLEAF PTE INSU	SEALECTRO	FTE 15P59	1
	ATING BUSH R AY RESISTOR A VERLEAF REQU	LEQUIRED ONLY WHEN LITERNATIVE USED. (R79)	ND B ALTERNATIVE US		
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
	630003	P' CLIP \$ 4.8 mm	SES	CNB	2
	630024	STEATITE BEAD IG SWG	PARK ROYAL PORCELAIN	Nº2	18
	630036	STEATITE BEAD 18 SWG	PARK ROYAL PORCELAIN	Nº1	12
	630122	PCB EJECTOR BLUE	RICHCO	CBE	2
	630167	FOAM TAPE 6mmT *9mm W	TESA	TESAMOLL 761/4763	A/R
	300003	HEAT SINK COMPOUND	RS	554-311	A/R
FI		NOT USED			
F2	920124	FUSE 375MA 1251 7mm	LITTLE FUSE	275 • 375	2
F3	920120	FUSE IA 125V 7mm	LITTLE FUSE	275 001	11
F4	920124	FUSE 375mA 125V 7mm	LITTLE FUSE	275 . 375	-
F5	920125	FUSE 21/2 A 1254 7mm	LITTLE FUSE	275 02.5	1
	613005	M3 SHAKEPROOF WASHER	STEEL		2
NOTES. SEE SHEET 2 FOR L	ATEST ISSUE			5.85 datron	ELECTRONICE LTD
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTU PART No.	RER'S	No. USED Per Assy.
RI	000222	2K2 5% VSW CARBON	MULLARD	CRZS		3
R2	0002.72	2k7 5% "3W CARBON	MULLARD	CR25		2
R3	006105	IM 2% IW MET-OX	ELECTROSIL	FPI		2
R4	006105	IM 2% IW MET-OX	ELECTROSIL	FPI		1
R5	000152	1K5 5% /3W CARBON	MULLARD	CR25		I
R6	000330	33R 5% 1/3W CARBON	MULLARD	CR25		1
R7	013161	3k16 1% 1/8W 50ppm MF	HOLCO	HBC		2
R8	013161	3k16 1% 1/8W 50ppm MF	HOLCO	HBC		-
R9	007100	IOR 2% 2W MET-OX	ELECTROSIL	FP2		2
RIO	015620	562R 1% 1/8W 50ppm MF	HOLCO	H8C		3
RII	007393	391 2% 2W MET-OX	ELECTROSIL	FP2		2
RI2	007474	470k 2% 2W MET-0X	ELECTROSIL	FP2		ŀ
RI3	001561	560R 5% 1/2W CARBON	MULLARD	CR37		1.1
RI4	000123	12k 5% "3W CARBON	MULLARD	CR25		3
RI5	000222	ZKZ 5% VOW CARBON	MULLARD	CRES		-
R16	018251	8k25 1% 1/8W 50ppm MF	HOLCO '	H8C		2
R17	018251	8K25 1% V8W 50ppm MF	HOLCO	HBC		
RI8	275000	2k7 5% Vaw CARBON	MULLARD	CR25		-
RIS	000101	100R 5% "3W CARBON	MULLARD	CR25	r	4
R20	000103	IOK 5% 1/3W CARBON	MULLARD	CR25		14
R21	000101	100R 5% VOW CARBON	MULLARD	CR25		-
R22	000103	IOK 5% VAW CARBON	MULLARD	CR25		-
R23	000103	IOK 5% YOW CARBON	MULLARD	CR25		-
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACT PART No.	TURER'S	No. USED Per Assy.
R24	070066	10k0 0.1% 5ppm W/W	MANN	MXIZSB	•	3
R25	080041	750R 0.1% 50ppm MF	VISHAY	VSRCI		11
R 26	070066	loko 0.1% 5ppm WW	MANN	MXIZS	в	-
R27	000103	IOK 5% YOW CARBON	MULLARD	CR25		-
R28	000103	IOK 5% YOW CARBON	MULLARD	CR25		~
R29	070066	IOKO 0.1% 5ppm WW	MANN	MXI25	3	-
R30	070170	Iko 0.1% 5ppm WW	MANN	MXI25	3	1
231	000821	820R 5% 'SW CARBON	MULLARD	CR25		1
232	011542	15k4 1% '8W 50ppm MF	HOLCO	H8C		1
833	013002	30k0 1% '8W 50ppm MF	HOLCO	HBC		1
234	007100	IOR 2% 2W MET-OX	ELECTROSIL	FP2		-
235	015620	562R 1% '8W 50ppm MF	HOLCO	HBC		-
836	007393	39k 2% 2W MET-OX	ELECTROSIL	FP2		
२३७	015110	511R 1% YOW SOPPM MF	HOLCO	H8C		3
९३८	000123	12k 5% 1/3W CARBON	MULLARD	CR25		-
239	000103	IOK 5% "3W CARBON	MULLARD	CR25		-
R40	000104	100k 5% '3W CARBON	MULLARD	CR25		16
R41		NOT USED				-
242		NOT USED				
R43		NOT USED				-
R44		NOT USED				-
245		NOT USED				
246		NOT USED				
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURE PART No.	R'S No. USED Per Assy.
R47	000473	47k 5% 1/3W CARBON	MULLARD	CR25	3
R48	000473	47k 5% '3W CARBON	MULLARD	CR25	
R49	008051	43k 5% 9W W.W.	WELWYN	W23	
R 50	000824	820k 5% '3W CARBON	MULLARD	CR25	2
R51	006204	200K 2% IW MET-0X	ELECTROSIL	FPI	1
R52	011000	100R 1% 1/8W 50ppm MF	HOLCO	н8с	1
R53	016198	61R9 1% /BW 50ppm MF	HOLCO	HBC	· · · ·
R54	0 00 331	330R 5% JAW CARBON	MULLARD	CR25	1
R55	000102	IK 5% V3W CARBON	MULLARD	CR25	6
R56	012000	200R 1% VOW 50ppm MF	Holco	HBC	. 1
R57	000470	47R 5% 1/3W CARBON	MULLARD	CR25	3
R58	015620	562R 1% 18W 50ppm MF	HOLCO	H8C	-
R59		NOT USED			-
RGO	000473	47k 5% 1/3W CARBON	MULLARD	CR25	
RGI	000824	820k 5% 1/3W CARBON	MULLARD	CR25	_
R62		NOT USED			
R63	011002	10ko 1% 1/8W 50ppm MF	HOLCO	- H8C	4
R64	011002	IOKO 1% YOW SOPPM MF	HOLCO	H8C	
R65	008058	22k 5% 12W W.W.	WELWYN	W24	
R66	015111	5k11 1% 1/8W 50ppm MF	Holco	НВС	1
R67	011002		HOLCO	H8C	-
R68	011002	IOKO 1% 1/8W SOppm MF	HOLCO	H8C	
R69	000223	22k 5% /3W CARBON	MULLARD	CR25	1
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACT PART, No.	URER'S	No USED Per Assy.
R70	000104	100k 5% 1/3W CARBON	MULLARD	CR25		
R71	011001	1KO 1% /8W 50ppm MF	Holco	HBC		2
R72	015110	511R 1% YOW SOPPM MF	HOLCO	HBC		 .
R73	000103	10k 5% 1/3W CARBON	MULLARD	CR25		-
R74	011001	1k0 1% 1/8W 50ppm MF	Holco	H8C		-
R75		NOT USED				-
R76	000103	IOK 5% YSW CARBON	MULLARD	CR25		-
R77	066 502	5k POT 3/8 SQ VERT CERMET		72.XW		1
R78	000621	GZOR 5% "3W CARBON	MULLARD	CR25		ł
R79	000104	100k 5% "JW CARBON	MULLARD	CR25		-
R80	000105	IM 5% "SW CARBON	MULLARD	CR25		4
R81	000222	2K2 5% SW CARBON	MULLARD	CR25		
R82	501000	IK 5% 'SW CARBON		CR25		— ·
R83	000472	4K7 5% SW CARBON		CR25		3
R84	001182	IK8 5% 1/2 W CARBON		CR37		3
R85	000104	100k 5% "3W CARBON	MULLARD ,	CR25		
R86	000226	22M 5% 'SW CARBON	MULLARD	CR25		2
R87	000226	22M 5% 'SW CARBON	MULLARD	CR25		-
R88	005204	200K 2% 12W CARBON	ELECTROSIL	TR5		2
R89	000100	IOR 5% YOW CARBON	MULLARD	CR25		3
R90	001182	1k8 5% 1/2W CARBON	MULLARD	CR37		-
R91	000104	100k 5% 1/3W CARBON	MULLARD	CR25		-
R92	000103	lok 5% 1/3W CARBON	MULLARD	CR25		
NOTES.	ATEST ISSUE			e AWN	datron	FLECTRONICS LTD
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ESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFAC PART No.	TURER'S	No. USED Per Assy.
R93	016190	619R 1% 1/8W 50ppm MF	HOLCO	H8C		3
R94	013320	332R 1% VBW 50ppm MF	HOLCO	H8C		1
R95	012800	280R 1% 1/8W 50ppm MF	HOLCO	H8C		1
R96	019090	909R 1% 1/8W 50ppm MF	HOLCO	HBC		1
R97	012211	2k21 1% 1/8W 50ppm MF	Holco	HBC		ł
898	014421	4k42 1% 1/8W 50ppm MF	HOLCO	НВС		1
665	000104	IOOK 5% 1/3W CARBON	MULLARD	CR25		-
२100	000105	IM 5% VOW CARBON	MULLARD	CR25		
शाम	000474	470k 5% 1/3W CARBON	MULLARD	CR25		<u> </u>
R102	000104	100k 5% 1/3W CARBON	MULLARD	CR25		-
R103	000104	100k 5% 1/3W CARBON	MULLARD	CR25		
R104	000102	Ik 5% 1/3W CARBON	MULLARD	CR25		
R105	000103	IOK 5% YOW CARBON	MULLARD	CR25		
R106	000103	IOK 5% V3W CARBON	MULLARD	CR25		
R107	000103	IOK 5% YOW CARBON	MULLARD	CR25		
R108	000472	4k7 5% /3W CARBON	MULLARD	CR25		
R109	000104	100k 5% 1/3W CARBON	MULLARD	CR25		
RIIO	000393	39k 5% 1/3W CARBON	MULLARD	CR25		1
RIII	000472	4k7 5% "3W CARBON	MULLARD	CR25		
R112	000104	IOOK 5% 1/3W CARBON	MULLARD	CR25		-
R113	000103	IOK 5% V3W CARBON	MULLARD	CR25		
R114	001278	2R7 5% 1/2W CARBON	MULLARD	CR37		í
RIIS	011302	13k0 1% 18W 50ppm MF	Holco	HBC		2
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
RIIG	011101	1k1 1% 18W 50ppm MF	HOLCO	H8C	2
R117	011302	13k0 1% 1/8W 50ppm MF	HOLCO	HBC	
R118	011101	IKI 1% 18W 50ppm MF	HOLCO	НВС	-
R119	000332	3k3 5% /sw CARBON	MULLARD	CR25	2
R120	000153	15k 5% Yow CARBON	MULLARD	CR25	<u> </u>
R121	000104	100k 5% YOW CARBON	MULLARD	CR25	
R122	012002	20k0 1% /8W 50ppm MF	HOLCO	HBC	I
R123	012001	2KO 1% YOW SOPPM MF	HOLCO	нвс	2
R124	015110	511R 1% VOW 50ppm MF	HOLCO	нвс	-
R125	016190	619R 1% 1/8W 50ppm MF	HOLCO	HBC	
R126	016190	619R 1% 18W 50ppm MF	HOLCO	НВС	-
R127	000104	100k 5% /3W CARBON	MULLARD	CR25	-
R128	000104	100k 5% /3W CARBON	MULLARD	CR25	-
R129	000102	IK 5% 1/3W CARBON	MULLARD	CR25	
R130	000270	27R 5% /3W CARBON	MULLARD	CR25	2
R131	000220	22R 5% 1/3W CARBON	MULLARD	CR25	2
R132	000470	47R 5% /3W CARBON	MULLARD	CR25	
R133	000271	270R 5% /3W CARBON	MULLARD	CR25	2
R134	000271	270R 5% /3W CARBON	MULLARD	CR25	-
R135	000470	47R 5% 1/3W CARBON	MULLARD	CR25	· _
R136	000220	22R 5% /3W CARBON	MULLARD	CR25	-
RI37	000270	27R 5% /3W CARBON	MULLARD	CR25	-
RI38	007184	180K 2% 2W MET-OX	ELECTROSIL	FP2	2
NOTES.	ATEST ISSUE			DRAWN	CON ELECTRONICS LTD
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFA PART No	CTURER'S	No. USED Per Assy.
R139	000180	IBR 5% 1/3W CARBON	MULLARD	CR25		2
R140	000221	220R 5% 1/3W CARBON	MULLARD	CR25		2
R141	000108	IR 5% /3W CARBON	MULLARD	CR25		2
R142	000101	100R 5% 1/3W CARBON	MULLARD	CR25		-
R143	000100	IOR 5% YOW CARBON	MULLARD	CR25		
R144	000338	3R3 5% YOW CARBON	MULLARD	CR25		1
R14.5	000100	IDR 5% /3W CARBON	MULLARD	CR25		-
R146	000101	IOOR 5% YOW CARBON	MULLARD	CR25		-
R147	000108	IR 5% 1/3W CARBON	MULLARD	CR25		-
R148	000221	2208 5% 1/3W CARBON	MULLARD	CR25		-
R149	000180	IBR 5% YOW CARBON	MULLARD	CR25		~
R150	001182	IK8 5% 1/2W CARBON	MULLARD	CR37		-
R151	008005	IR 5% 21/2W W.W.	WELWYN	W21		1
R152	000183	18k 5% /3W CARBON	MULLARD	CR25		2
R153	000561	560R 5% /3W CARBON	MULLARD	CR25		1
R154	000183	18K 5% Yaw CARBON	MULLARD	CR25		-
R155	007184	180k 2% 2W MET-0X	ELECTROSIL	FP2		-
R156	018250	825R 1% 18W 50ppm MF	HOLCO	HBC		1
RI57	016811	6k81 1% 18W 50ppm MF	HOLCO	HBC		2
R158	000104	100K 5% SW CARBON		CR25		-
R159	012001	2KO 1% VOW 50ppm MF	HOLCO	HBC	· · · · · · · · · · · · · · · · · · ·	-
R160	000332	3K3 5% 'SW CARBON	MULLARD	CR25		-
RIGI	016811	6 k81 1% '8W 50 ppm MF	HOLCO	НВС		-
NOTES.	ATEST ISSUE	,		DATE	datron	ELECTRONICE LTD
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFAC PART No.	TURER'S	No. USED Per Assy.
R162	000102	IK 5% YOW CARBON	MULLARD	CR25		-
RIG3		NOT USED				-
R164		NOT USED				-
R165	017500	750R 1% 18W 50ppm MF	HOLCO	HBC		1
R166	000150	15R 5% 'SW CARBON	MULLARD	CR25		2
R167	000150	ISR 5% 'SW CARBON	MULLARD	CR25		
R168	000182	IKB 5% SW CARBON	MULLARD	CR25		1
R169	000102	IK 5% 1/3W CARBON	MULLARD	CR25		-
R170	000103	IOK 5% YOW CARBON	MULLARD	CR25		-
R171	011621	1k62 1% 1/8W 50ppm MF	HOLCO	H8C		1
R172	000518	5RI 5% "3W CARBON	MULLARD	CR25		2
R173	000518	5RI 5% 'SW CARBON	MULLARD	CR25		-
R174	855000	2RZ 5% YOW CARBON	MULLARD	CR25		1
R175	000104	100k 5% Vaw CARBON	MULLARD	CR25		-
RI76	005204	200K 2% 2W CARBON	ELECTROSIL	TRS		-
R177	000105	IM 5% YOW CARBON	MULLARD	CR25		-
R178	000105	IM 5% YOW CARBON	MULLARD	CR25		-
R179		NOT USED				-
R180	011741	1k74 1% 18W 50ppm MF	HOLCO	HBC		1
R181	012 492	2489 1% "8W SOPPM MF	HOLCO	H8C		1
R182	000104	100k 5% "SW CARBON	MULLARD	CR25		-
R183	000123	12k 5% "3W CARBON	MULLARD	CR75		-
R184		NOT USED				_
NOTES.	ATEST ISSUE			DATE	datron	ELECTRONICS LTD
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
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		· · · · · · · · · · · · · · · · · · ·			
ANI	090132	4k7 ×4 2% SIL NETWORK	BECKMAN	L08-3-R4k7	1
AN2	090095	47K ×4 2% SIL NETWORK	BECKMAN	L08-3-R47k	1
AN3		NOT USED			-
AN4	090096	IM ×8 2% NETWORK	BECKMAN	L09-1-RIM	2
AN5	090096	IM ×8 2% NETWORK	BECKMAN	L09-1- RIM	-
AN6		NOT USED			-
AN7		NOT USED			-
AN8	090090	47K ×8 2% NETWORK	АВ	761-3-47k	1
AN9	090144	IK X 8 1% DIL NETWORK	BECKMAN	698-3-RIKF	1
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFA PART No	ACTURER'S	No. USED Per Assy
CI	150023	33 UF 20% 25V DIP TANT	UNION CARBIDE	K33E	the strength of the state of th	1
C2	104018	INF 20% INV CER DISC	ITT	HDIOK	(IOI NOMS-SSI KODS	<u>z</u>
С3	150006	407F 20% 16V DIP TANT	UNION CARBIDE	K4R71	EIG	4
C4	110042	100 AF 20% 634 POLYESTER	WIMA	MKS2		6
C 5	150012	100 .F 20% 35V DIP TANT	UNION CARBIDE	KRIOE	135	4
C6	150012	100 AF 20% 354 DIP TANT	UNION CARBIDE	KRIOE	135	-
C7	104018		(TT	HDIOKIC	OINOMS-SSIKODSC	-
C 8	104026	47nF - 20% 50V CER DISC	SIEMENS	B374.4	19	13
C9	104026		SIEMENS	B374.4	1 9	-
C10	150020	100F 20% 25V DIP TANT	UNION CARBIDE	KIOE2	5	5
CII	150020	100F 20% 25V DIP TANT	UNION CARBIDE	KIOE2	.5	-
C12	104021	15pf 20% IKV NPO CD	ITT		ISPOMS-SSIKODSC	1
CIB	104026		SIEMENS	B3744	19	-
CI4	104026	47nF - 50% SOV CER DISC	SIEMENS	B37449		
C15	110035		WIMA	MK52		2
C16	150012	100nf 20% 35V DIP TANT	UNION CARBIDE	KRIDES	35	-
C17	102222	2n2F 10% 500V CER DISC	ITT	CDIO	• .	1
C18	102100	10pf 5% 500V CER DISC	ITT	CDIO		2
C19	104026		SIEMENS	B3744	19	-
C20	110015	15nF 20% 63V POLYESTER	WIMA	MKS2		3
C21	104026		SIEMENS	B374.4	49	-
C22	110044		WIMA	MKS4	,	2
C23	102221		ITT	CDIO	1	3
NOTES. SEE SHEFT 2 FOR L	LATEST ISSUE			DAT	datron	ELECTRONICS LTD
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANULA PART No	CTURER'S	No. USED Per Assy.
C24	102221	220 pf 10% 500V CER DISC	ITT	CDIO		-
C25	110041	10 nF 20% 100V POLYESTER	WIMA	FKS2		3
C26	180041	100 F 40V AL ELECT	STEATITE	EKM O	OFD 310G	1
C27	104026	470F -20% 50V CER DISC	SIEMENS	B3744	9	-
C28	104026	470F -20% 50V CER DISC	SIEMENS	B3744	9	-
C29	150006	4,07F 20% 16V DIP TANT	UNION CARBIDE	K4R7E	16	
C30	102471	470 PF 10% 500V CER DISC	ITT	CDIO		2
C3I	110044	680nF 20% 630V POLYESTER	WIMA	MKS4		
C32	104026	47.F -20% 50V CER DISC	SIEMENS	B37449	3	-
C33	100182	INBE 2% WOY CER DISC	MULLARD	2222	683	1
C34	110015	15 NF 20% 63V POLYESTER	WIMA	MKS2		-
C35	110042	100nF 20% G3V POLYESTER	WIMA	MKS2		-
C36	150020	IDUF 20% 25V DIP TANT	UNION CARBIDE	KIOE25		-
C37	150020	IONF 20% 25V DIP TANT	UNION CARBIDE	KIOE35		-
C38	110035	220 NF 20% 63V POLYESTER	WIMA	MKS2		-
C39	150022		UNION CARBIDE	K2R2E3	5	5
C40	102338	3p3F ± · 5pF 500V CER DISC	ITT	CD08		1
241	150022		UNION CARBIDE	K 2R2 E3	5	
C42	104026	47nF -5% 50V CER DISC	SIEMENS	B3744	9	-
C43	104026	470F - 20% 50V CER DISC	SIEMENS	B3744	9	-
C 44	110015	15nF 20% 63V POLYESTER	WIMA	MKS2		-
C 45	101103	10nF 25% 250V CER DISC	ITT	CDIO		4
C46	101103	IONF 25% 250V CER DISC	ITT	CDIO		-
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
C47	110042	100nF 20% 63V POLYESTER	WIMA	MKSZ	
C48	10222.1	220pf 10% 500V CERDISC	177	CDIO	
C49	180051	22 F 20% 350V AL. ELECT	ECC	SMVB	2
C50	100101	100pf 2% 100V CER DISC	MULLARD	2222 683	2
C51	180045	474F 63V AL. ELECT.	MULLARD	031-38479	2
C52	110042	100nF 20% 63V POLYESTER	WIMA	MK52	
253	100338	3p3F + 25pf 100V CER DISC	MULLARD	2222 683	I
254	180045	474F 63V AL. ELECT.	MULLARD	031-38479	
C55	105558	2p2F ± . 5pF 500V CER DISC	ITT	CD08	
C56	110042	100nF 20% G3V POLYESTER	WIMA	MKS2	
C57	100101	100pf 2% 100V CER DISC	MULLARD	2222-683	-
258	100332	3n3F 2% 100V CER DISC	MULLARD	2222-63019	1
059	180051	22, UF 20% 350V AL. ELECT	ECC	SMVB	_
000	104026	47nF -20% 50V CER DISC	SIEMENS	B37449	
C61	150022	202F 20% 35V DIP TANT	UNION CARBIDE	K2R2E35	
C62	150022	242F 20% 35V DIP TANT	UNION CARBIDE	K2R2E35	-
C 63	101103	10nF 25% 250V CER DISC	ITT	CDIO	
C64	101103	IONF 25% 250V CER DISC	ITT	CDIO	
C65	110046	INF 20% SOV POLYESTER	WIMA	MKSZ	1
266	150012	100nF 20% 35V DIP TANT	UNION CARBIDE	KRIOE35	
c67	100102	INF 2% 100V CER DISC	MULLARD	2222 63019	- 3
C68	110026	6nof 20% 100V POLYESTE	WIMA	FK52	1
569	150008	4700 F 20% 35V DIP TANT	UNION CARBIDE	KR47E35	1
NOTES. SEE SHEET 2 FOR L	LATEST ISSUE				
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANULACTURER'S PART No.	No. USED Per Assy.
C70	150006	4,17F 20% IGV DIPTANT	UNION CARBIDE	K4R7E16	-
C71	110041	10 nF 20% 100V POLYESTER	WIMA	FKS2	
C72	102100	10pf 5% 500V CER DISC	ITT	CDIO	-
C73	102102	INF 10% 500V CER DISC	<u>דדו</u>	CDIO	1
C74	110042	100nF 20% 63V POLYESTER	WIMA	MKS2	-
C75	150016	INF 20% 35V DIP TANT	UNION CARBIDE	KIROE 35	4
C76	150016	INF 20% 35V DIP TANT	UNION CARBIDE	KIROE35	-
277	150016	INF 20% 35V DIP TANT	UNION CARBIDE	KIROE35	-
78	150016	INF 20% 35V DIP TANT	UNION CARBIDE	KIROE35	_
c79	150006	4,07F 20% IGV DIP TANT	UNION CARBIDE	K4R7EIG	
C80	150020	IONE 20% 25V DIP TANT	UNION CARBIDE	KIOE25	-
681	110041	IONF 20% IOOV POLYESTER	WIMA	FKS2	
282		NOT USED			-
C83	100102	INF 2% IOOV CER DISC	MULLARD	2222 63019	
C84	100102	INF 2% LOOV CER DISC	MULLARD	2222 63019	
C85	104026	470F 120% 50V CER DISC	SIEMENS	B374-49	~
C86	110020	47nF 20% 63V POLYESTER	WIMA	MKS2	1
687	150022	2 NEF 20% 35V DIP TANT	UNION CARBIDE	K2R2E35	-
288	102471	470 pf 5% 500V CER DISC	<u>דדו</u>	CDIO	
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
DI	210100	IOV 400mw ZENER	MULLARD	BZY88CI0	7
D2	210047	4V7 400mW ZENER	MULLARD	BZY88C4V7	<u> </u>
03	200001	75mA 75V GP SI DIODE	FAIRCHILD	IN4148	23
D 4	200006	IA 600V GP SI DIODE	FAIRCHILD	1N4005	7
D 5	200001	75mA 75V GP SI DIODE	FAIRCHILD	IN4148	
06	200001	75mA 75V GP SI DIODE	FAIRCHILD	IN4148	-
D7	210160	IGV 400mW ZENER	MULLARD	BZY88CIG	2
08	200001	75mA 75V GP SI DIODE	FAIRCHILD	IN4148	
09	214012	2V45 30ppm ZENEP	FERRANTI	ZN458	4
DIO		NOT USED			
DII	220008	L.E.D RED	PYE-TMC	521-9165	2
DI2	210100	10V 400mW ZENER	MULLARD	BZY88C10	-
DI3	200001	75mA 75V GP SI DIODE	FAIRCHILD	IN4148	
DI4	210160	IGV 400mW ZENER	MULLARD	BZY88CK	
D15	200001	75mA 75V GP SI DIODE	FAIRCHILD	IN4148	
DIG	200001	75mA 75V GP Si DIODE	FAIRCHILD	IN4148	
D17	214012	2V45 30ppm ZENER	FERRANTI	ZN458	-
D18	200001	75mA 75V GP SI DIODE	FAIRCHILD	IN4148	-
D19	200006	IA GOOV GP SI DIODE	FAIRCHILD	IN4005	
D20	200001	75mA 75V QP SI DIODE	FAIRCHILD	IN4148	
D21		NOT USED.			
D22	200001	75mA 75V GP SI DIODE	FAIRCHILD	IN4148	
D23	200001	75mA 75V GP Si DIODE	FAIRCHILD	IN4148	
NOTES. SEE SHEFT 2 FOR L ISS ICO DATE	ATEST ISSUE			DRAWN TITLE	P.A. PCB. ASS

ESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER		MANUFACT PART No.	URER'S	No. USED Per Assy.
24	210150	15V 400 MW ZENER	MULLARD		BZY88C	15	11
)25	214012	2V45 30 ppm ZENER	FERRANTI		ZN458	· · · · · · · · · · · · · · · · · · ·	
)26	200001	75mA 75V GP Si DIODE	FAIRCHILD		IN4148		
27	200006	IA 600V GP SI DIODE	FAIRCHILD		IN4005		·
28	200001	75mA 75V GP Si DIODE	FAIRCHILD		IN4148		-
29	214-012	2V45 30ppm ZENER	FERRANTI		ZN458		-
>30	200001	75mA 75V GP SI DIODE	FAIRCHILD		IN4148		-
)31	200001	75mA 75V GP SI DIODE	FAIRCHILD		IN4148		-
32	200006	IA GOOV GP SI DIODE	FAIRCHILD		IN 4005		
)33	213009	ISV SW ZENER	UNITRODE		TVS 515		
)34	200001	75mA 75V GP SI DIODE	FAIRCHILD		IN4 148		-
35	200001	75mA 75V GP SI DIODE	FAIRCHILD		IN4148		
36	200001	75 mA 75V GP SI DIODE	FAIRCHILD		IN4148		
37		NOT USED	1				-
38		NOT USED					-
39	210100	IOV 400mW ZENER	MULLARD		BZY88C	10	-
>40	210100	IOV 400 MW ZENER	MULLARD		BZY88C	10	- 1
241	211150	ISV 1.3W ZENER	MULLARD	•	BZXGICI	5	1
)42	210100	10V 400mW ZENER	MULLARD		BZY88CI	0	-
)43	210100	IOV 400mW ZENER	MULLARD		BZY88CI	2	
X4	200001	75mA 75V GP SI DIODE	FAIRCHILD		IN4148		-
945		NOT USED					-
046	200008	200mA 125V LL SI DIODE	FAIRCHILD		IN458A		12
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
D47	200008	200mA 125Y LL SI DIODE	FAIRCHILD	IN458A	-
D 48	200008	200 mA 1254 LL SI DIODE	FAIRCHILD	IN 458A	<u> </u>
049	200008	200 mA 1254 LL SI DIODE	FAIRCHILD	IN458A	
050		NOT USED			—,
D51	210300	301 400 mW ZENER	MULLARD	BZY88C30	1
52		NOT USED			-
53		NOT USED			-
D54	210100	IOV 400mW ZENER	MULLARD	BZY88CIO	-
D55		NOT USED			-
D56	200006	IA GOOV GP SI DIODE	FAIRCHILD	IN 4005	-
D57	213005	75V VZW ZENER	MOTOROLA	BZX79C75	1
58	200001	75m A 75V GP SI DIODE	FAIRCHILD	IN4148	-
D5 9	200001	75mA 75V GP SI DIODE	FAIRCHILD	IN4148	~
060	213019	200V 5% 1/2W ZENER	MULLARD	BZX79C200	2
D61	213019	200V 5% 1/2W ZENER	MULLARD	BZX79C200	-
D62	200008	200 A 125Y LL SI DIODE	FAIRCHILD	IN458A	-
D63	200008	200 mA 125Y LL SI DIODE	FAIRCHILD	IN458A	-
D64	200008	200mA 125Y LL SI DIODE	FAIRCHILD	IN 4 58A	-
D65	200008	200mA 125Y LL SI DIODE	FAIRCHILD	IN458A	
D66	200008	200mA 125Y LL SI DIODE	FAIRCHILD	IN458A	· –
D67	200008	200mA 125V LL SI DIODE	FAIRCHILD	IN458A	-
D68	200008	200mA 125V LL SI DIODE	FAIRCHILD	IN 458A	-
D69	200008	200mA 125Y LL SI DIODE	FAIRCHILD	IN458A	-
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFAC PART No.	CTURER'S	No. USED Per Assy.
D70	220008	L.E.D. RED	PYE-TMC	521-9	165	
D71	200001	75mA 75V GPSI DIODE	FAIRCHILD	IN 414	8	-
D72	200006	IA GOOV GP SI DIODE	FAIRCHILD	IN400	5	
D73	200006	IA 600V GP SI DIODE	FAIRCHILD	IN400	5	-
D74	200001	75mA 75V GP SI DIODE	FAIRCHILD	IN 414	8	
D75	210120	12Y 400mW ZENER	MULLARD	BZY88	C12	1
D76	210033	3V3 400 mW ZENER	MULLARD	BZY88	C3V3	2
D77	210033	3V3 400mW ZENER	MULLARD.	BZYBBC	23√3	-
D78		NOT USED				-
21	240001	SI NPN TRANSISTOR	NATIONAL	8C184	/1018	4
§5	230063	N-CHAN TMOS JEET	MOTOROLA	MTP 21		2
23	250001	SI PNP TRANSISTOR	NATIONAL	BC214	A T COMPANY CONTRACTOR	4
λ 4	230064	P-CHAN TMOS JEET	MOTOROLA	MTP2		2
25	250027	SI PNP DUAL TRANSISTOR	MICRO POWER SYSTEMS	MP35	1	ī
26	230036	N-CHAN JEET	SILICONIX	J108		4
Q7		NOT USED				-
28	2 300 64	P-CHAN TMOS JEET	MOTOROLA	MTP2P	50	-
29	230073	N-CHAN TMOS JEET	MOTOROLA	MTPIN	1100	1
QIO	250001	SI PNP TRANSISTOR	NATIONAL	BC214/	1018	-
Qu	240001	SI NPN TRANSISTOR	NATIONAL	BC184/	1018	
Qiz	240001	SI NPN TRANSISTOR	NATIONAL	BC 184/	TOIS	
Q13	250001	SI PNP TRANSISTOR	NATIONAL	BC214/	T018	-
NOTES.	ATECT 155116			DRAWN	datron	ELECTRONICE LTD
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DESIGNATOR	DATRON PART No.	DÉSCRIPTION	PRINCIPAL MANUFACTURER	MANUFA PART No	CTURER'S	No. USED Per Assy.
Q14	230036	N-CHAN JEET	SILICONIX	J108		
Q15	230036	N-CHAN JEET	SILICONIX	J108		
216		NOT USED				-
Q17		NOT USED				
218	230036	N-CHAN JFET	SILICONIX	J108		-
219	230003	N-CHAN JFET	TELEDYNE	U1899	JF	66
220	230063	N-CHAN TMOS JEET	MOTOROLA	MTP21	185	-
221	230001	N-CHAN I LIM 1.4 mA	SILICONIX	J506		2
Q22	240006	SI NPN TRANSISTOR	NATIONAL	2N39	04 / 1018	2
223	250004	SI PNP TRANSISTOR	NATIONAL	2N 39	06 / 7018	2
324	230001	N-CHAN I LIM 1.4 mA	SILICONIX	J506		-
Q25	230003	N-CHAN JEET	TELEDYNE	UI 899	JF	-
Q26	230003	N-CHAN JFET	TELEDYNE	U1899	Burner of the local data and the second data a	
Q27	250009		NATIONAL		01/1018	22
Q28	250004	SI PNP TRANSISTOR	NATIONAL	2N390	6/1018	
Q29	240009	SI NPN TRANSISTOR	NATIONAL	MPSL	01/2N5550 TOI8	2
Q30	240006	SI NPN TRANSISTOR	NATIONAL	2N390	4/ 1018	-
Q3I	250009	SI PNP TRANSISTOR	NATIONAL	2N 540	1/ TOI8	-
Q32	240030	SI NPN TRANSISTOR	MOTOROLA	BD389		1
Q33	250019	SI PNP TRANSISTOR	MOTOROLA	BD 39 0)	1
Q34	240009	SI NPN TRANSISTOR	NATIONAL	MPSLO	01/2N5550 TOIB	· -
Q35	230003	N- CHAN JFET	TELEDYNE	01899	JF	-
Q36	250001	SI PNP TRANSISTOR	NATIONAL	BC214	/ 1018	-
NOTES.	ATEST ISSUE			DATE	datron	ELECTRONICS LTD
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ESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFAC PART No.	TURER'S	No. USED Per Assy.			
237		NOT USED				-			
38		NOT USED							
39	230019	PMOS ENH FET	G.I.	MEM8	MEM806				
40	230035	NCHAN J FET	TELEDYNE	U1897.	JF	1			
₹41	240001	SI NPN TRANSISTOR	NATIONAL	BC184	/ 1018	~			
42	/230003	N-CHAN JFET	TELEDYNE	01899	JF	-			
} 43	230003	N-CHAN JFET	TELEDYNE	01899		·			
<u> </u>	290077	7X DARLINGTON DRIVER	SPRAGUE/EXAR	ULN2C	04A/XR2204CF	1			
12	260049	319 DUAL COMPARATOR	NATIONAL	LM3/S	1				
13	260039	324 QUAD OP AMP	NATIONAL	LM324	LM324N				
14	280023	QUAD 2 11P NOR	MOTOROLA	MC14	MC14001UBCP				
45	280011	DUAL D FLIP-FLOP	MOTOROLA	MC140	DI3 BCP	<u> </u>			
16	280008	QUAD 2 1/P NAND	MOTOROLA	MC140	DIIBCP	<u> </u>			
47	280090	DUAL BINARY DECODER	MOTOROLA		555BCP	1			
18	260074	LHOO32C FAST FET OP. AMP	NATIONAL	LH OO3	1				
19	280045	TRIPLE 3 I/P NOR	MOTOROLA	MC 140	MC 14025 BCP				
110	260027	714 OP AMP	FAIRCHILD	NA 714	NA 714 HC				
411	280009	HEX INVERTER	MOTOROLA	MC140	MC14049UBCP				
112	280079	QUAD 2 I/P OR	MOTOROLA		71 BCP				
Л13	290089	7 × DARLINGTON DRIVER	SPRAGUE / EXAR	ULN20	03A/XR2203CP	1			
114		NOT USED				-			
115	260046	2525 OP AMP	HARRIS	HA325	525-5	2			
A16	220018	HI- SPEED OPTO ISOLATOR	нр	6N136		1			
IOTES.	ATEST ISSUE				datron	ELECTRONICS LTD			
					4700 PA PCB				
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFAC PART No.	TURER'S	No. U S ED Per Assy.				
MI7	260027	714 OP AMP	FAIRCHILD	JUA 7141	HC	-				
M18	260042	5532 DUAL OP AMP	SIGNETICS	NE 55	NE5532N					
MIƏ	260046	2525 OP AMP	HARRIS	HA 32	525-5					
M20	260028	1458 DUAL OP AMP	FAIRCHILD	UA 145	SCTC	1				
M21	260079	12V REGULATOR	NATIONAL	LM781	_12_	11				
122	260075	2903 DUAL COMPARATOR	NATIONAL	LM29	03N	2				
123	260075	2903 DUAL COMPARATOR	NATIONAL	LM 290	33N	-				
RLI	330029	RELAY 2P2W	SDS	DS2E-	DC24V	8				
212	330029	RELAY 2P2W	SDS	DS2E-	DC24V	-				
7L3	330029	RELAY 2P2W	SDS	DS2E-	DC24V					
RL4	330029	RELAY 2PZW	SDS	DS2E-	DC24V					
RL 5	330029	RELAY 2P2W	SDS	DS2E-	DSZE-DC24V					
RLG	330029	RELAY ZPZW	SDS	DS2E-	DSZE-DC24V					
RL7	330029	RELAY 2P2W	SDS	DS2E-	DC24V					
rl8	330029	RELAY 2P2W	SDS	DS2E-	DC24V	-				
LI	370025	2N2H 665mA CHOKE	SIGMA	5030		2				
L2	370025	2µ2H 665mA CHOKE	SIGMA	SC30		-				
.3	370001	IONH 0.85 & RF CHOKE	PLESSEY	58/10/	6011/10	3				
4	370001	IONH O.85 & RF CHOKE	PLESSEY	58/10/	0011/10					
L5	370001	IONH 0.85 & RF CHOKE	PLESSEY	58/10/	<u>∞11/10</u>	~				
16	370007-1	40mH CHOKE	SIGA	SEE D	RG					
_7	370012	470nH 0.1 & RF CHOKE	SIGMA	SCIO		2				
-8	370012	470 NH O.IR RE CHOKE	SIGMA	SCIO		-				
NOTES. SEE SHFET 2 FOR L	ATEST ISSUE			DATE	datro	FLECTADAICS LTD				
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DATE				DATE	- 4006	18 21 "				

ESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANULAC PART No	TURER'S	No. USED Per Assy.
L9	370001	100H O.85 S RF CHOKE	PLESSEY	58/10/0	011/10	-
LIO	370001	IOUH O.85 & RF CHOKE	PLESSEY	58/10/0	011/10	
-PI	920148	NEON 200/250V TI 4 BI-PIN	RS	586-4	31	2
.P2	920148	NEON 200/250V TI 4 BI-PIN	RS	586-4	31	-
	410339-1	PCB				1
	540002	22 SWG B.T.C. WIRE				A/R
·····						
TI-J5	604033	4-WAY .I"PCB PLUG GD.PL.	MOLEX	22-29		10
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	605060	14-WAY DIL SOCKET	JERMYN	J23-1		7
	605061	IG-WAY DIL SOCKET	JERMYN	J23-1	5016	4
	611006	M3x IOmm POZI-PAN STEEL	ZN. PL.			2
	611016	M3×8mm POZI-PAN STEEL	ZN.PL			2
	613005	M3 INT. SHAKEPROOF	ZN.PL.			3
	613007	M3 WASHER STEEL	ZN.PL.			
	615002	M3 FULL NUT STEEL	ZN.PL.	5635	20	4
	618001	INSULATING BUSH TO-220 M3 WAVY WASHER		5635.		
,	620007	TEST POINT TERMINAL	MICROVAR	TYPE C	30	32
NOTES.	620007	TEST POINT TERMINAL	MICKOVAK		.30	
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SEE SHEET 2 FOR L	ATEST ISSUE			CHECKED	1111	
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SIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
	630024	STEATITE BEAD 16 SWG	PARK ROYAL PORCELAIN	Nº 2	52
	630123	PCB EJECTOR - VIOLET	RICHCO	CBE	2
	700081	SWITCH IP 2 POS SLIDE	ALCO	SLS-121-PC	1
	1-160026	HEATSINK TOZZO	SEE DRG		1
	920151	HEATSINK TOZOZ SLIPCU	THERMALLOY	6046 PB	2
	920152	HEATSINK TO 220	AAVID	5425B-TT	1
	920153	HEATSINK TO 220	ASSMANN	V4330	1
	630036	STEATITE BEAD 18 SWG	PARK ROYAL PORCELAIN	Nº I	5
	630243	GLASS BEAD 2.40/D × 0.81/D x	-8 MANSOL (PREFORMS) LTD	M5363 B/3	26.
	590004	SLEEVING PTEE \$1.0			A/R
	618004	TOIS MOUNTING PAD	JERMYN	T018-008D	4
	618010	SIL PAD TO 220			1
	605124	IO WAY SOCKET STRIP	AUGAT	510-AG91D	1.33
	920149	HEATSINK TOB	SOURIAU	TXBF 2-050-033 B	1
	604046	3 WAY .I" PCB PLUG GD.PL	MOLEX	22-10-2031	2
	605127	2 WAY . I" SHORTING LINK	ASSMANN	AKS PL-G	2
	590031	HEATSHRINK \$3.2	RS		15 mm
	590032	HEATSHRINK Ø4.8			15 mm
and a set of a set of the base of the set of the base of the set o	512999	7/2 PTFE WHITE WIRE			40 mm
	560002	7/34 AWG CO-AX			300 mm
		7041110 00 17			- COOMM
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
RI	008024	OR27 10% 21/2 W WIREWOUND	WELWYN	W21	1
R2	000330	33R 5% 1/3W CARBON	MULLARD	CR25	1
R3	000102	IK 5% YOW CARBON	MULLARD	CR25	3
R4	000182	IKB 5% 'SW CARBON	MULLARD	CR25	1
R5	013922	39k2 1% 1/8W 50ppm MF	HOLCO	HBC	1
R6	013742	37k4 1% 1/8W 50ppm MF	HOLCO	HBC	<u> </u>
R7	090001	PTC THERMISTOR	MULLARD	VA8650	1
R8	000470	47R 5% 1/3W CARBON	MULLARD	CR25	2
R9	000470	47R 5% 1/3W CARBON	MULLARD	CR25	_
RIO	011003	100k 1% Yow 50ppm MF	HOLCO	H8C	2
RII	011003	100k 1% 1/8W 50ppm MF	HOLCO	H8C	-
R12	066205	2M POT 3/8 SQ VERT. CERMET	BECKMAN	72×W	1
R13	008069	180k 5% 1/2W CARBON	АВ	FB	1
R14	000102	IK 5% 1/3W CARBON	MULLARD	CR25	-
R15	000102	IK 5% 1/3W CARBON	MULLARD	CR25	-
R16	000221	220R 5% /3W CARBON	MULLARD	CR25	2
R17	008022	OR27 10% 1/2W MF	17T	RNOS	2
R18	008022	0R27 10% 1/2W MF	ITT	RN05	-
RIS	000104	100k 5% 1/3W CARBON	MULLARD	CR25	1
R20	000221	220R 5% /3W CARBON	MULLARD	CR25	-
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
CI		NOT USED			-
2	150006	4.17F 20% 16V DIP TANT	UNION CARBIDE	K4R7EIG	1
23		NOT USED		-	
-4	150017	1004F 20% 16V DIP TANT	UNION CARBIDE	K 100E16	1
25	180004	4700 JUF 16V AL. ELECT	WIMA	PRINTILYT I	. 1
.6	101103	IONF 25% 250V CER DISC	דדו	CDIO	1
27	180026	10µF 350V AL. ELECT	ITT	EN12.12 10/350	1
C8	104030	100pf 10% 4KV CER DISC	ITT	HDIG	1
C9	102222	2n2F 20% 500V CER DISC		CDIO	1
C10	110005	10nF 20% 250V POLYESTER	MULLARD	C280 A E PIOK	! !
DI	200022	3A 400Y GP SI DIODE	MOTOROLA	BY252	2
02	200022	3A 400V GP SI DIODE	MOTOROLA	BY252	
03	210027	2V7 400mW ZENER	MULLARD	BZY88C2V7	I
04	214012	2V45 30ppm ZENER	FERRANTI	ZN458	1
D5	213006	5V 5W ZENER	UNITRODE	TV\$505	1
6	210068	6V8 400mW ZENER	MULLARD	BZY88C6V8	1
07	213004	180V 1/2 W ZENER	MOTOROLA	IN 5279 B	- 1
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFAC PART No.	CTURER'S	No. USED Per Assy.
WI	209013	IAS 600V BRIDGE RECT	MICRO-ELECTRONICS	W006		
QI	250011	SI PNP TRANSISTOR	NATIONAL	BC327	/1018	1
Q2	240024	SI NPN TRANSISTOR	NATIONAL	TIP3IA		- 1
Q3	240018	SI NPN TRANSISTOR	MOTOROLA	MJE34	10	2
Q4	240018	SI NPN TRANSISTOR	MOTOROLA	MJE34	0	-
Q5	250016	SI PNP TRANSISTOR	MOTOROLA	MJ295	55	2
ର୍ବ	250016	SI PNP TRANSISTOR	MOTOROLA	MJ295	5	
мі	260061	3140 OP AMP	RCA	CA3140)E	1
	410179-6	PCB				1
	604042	4 WAY WAFER PIN .156"	MOLEX	09-72	-2041	2
	605059	8 WAY DIL SOCKET	JERMYN	J23-18	8008	- I
	611006	M3XIOMM POZIPAN STEEL	ZNPL			6
	611004	M3×6mm POZIPAN STEEL	ZN PL			<u> </u>
	613005	M3 INT. SHAKEPROOF	ZN PL			7
	613007	M3 WASHER STEEL	ZN PL			6
	615002	M3 FULL NUT STEEL	ZN PL			7
	618004	MOUNTING PAD TOIS	JERMYN	TO18-	0080	1
	620007	TEST POINT TERMINAL	MICROVAR	TYPE C	30	9
	630024	STEATITE BEAD 16 SWG	PARK ROYAL PORCELAIN	1 Nº 2 (L	ARGE)	6
	900003	HEATSINK COMPOUND	RS	554 - 3	511	A/R
	900004	SILICONE RUBBER COMPOUN	D RS	555- 5	88	A/R
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DESIGNATOR	DATRON	DESCRIPTION	PRINCIPAL	MANUFACTURER'S	No. USED
	PART No.		MANUFACTURER	PART No.	Per Assy.
	920088-1	HEATSINK TO-3	SEE DRG		2
	920126	FUSE HOLDER 20mm PCB	BELLING LEE	L1426	I
=1	920128	FUSE 4A 250V 20mm SLO-1	BELLING LEE	L2080A/4	1
	920144	HEATSINK TO-220	REDPOINT	TVISOO	2
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL	MANUFACTURER'S PART No.	No. USED Per Assy.
Ri	000102	IK 5% YOW CARBON	MULLARD	CR25	1
R2	015230	523R 1% 18W 50ppm MF	HOLCO	H8C	1
R3	021402	14k 1% 14W 50ppm MF	Holco	H4c	1
R4		NOT USED			-
R5		NOT USED			-
RG		NOT USED			
R7	000272	2k7 5% /3w CARBON	MULLARD	CR25	2
RB	000272	2k7 5% YOW CARBON	MULLARD	CR25	-
R9	000103	IOK 5% YOW CARBON	MULLARD	CR25	2
RIÓ	000103	10k 5% 1/3W CARBON	MULLARD	CR25	-
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CI	180042	3300 F 25V AL ELECT	STEATITE	EG. 00MG. 433E	2
C2	180042	3300 F 25V AL ELECT	STEATITE	EG. 00MG. 433E	-
C3	180047	1000 F 40Y AL ELECT	ECC	SMVB	7
C4	180047	F 40V AL ELECT	ECC	SMVB	-
C5	110020	47nF 20% 63V POLYESTER	WIMA	MKS2	1
C6	150021	22 MF 20% 25V DIP TANT	UNION CARBIDE	K22E25	7
C7	150021	22 NF 20% 25V DIP TANT	UNION CARBIDE	K22E25	-
C8	180047	1000MF 40V AL ELECT	ECC	SMVB	
C9	180047	1000 F 40V AL ELECT	ECC	SMVB	
CIO	180048	470 F 63V AL ELECT	ECC	SMVB	2
NOTES.		/	DATE		
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
CII	150021	22 MF 20% 25V DIP TANT	UNION CARBIDE	K22 E25	-
C12	104026	47nF 20% 50V CER DISC	SIEMENS	B37449	3
CI3	150021	22 UF 20% 25V DIP TANT	UNION CARBIDE	K22E25	-
C14	180024	IONE GOV AL ELECT	MULLARD	016-18109	1
CIS	150021		UNION CARBIDE	K22E25	-
CIG	150021	22 NF 20% 25V DIP. TANT	UNION CARBIDE	K22E25	
CI7	104026	47nF 20% SOV CER DISC	SIEMENS	B37449	
CI8	150001	22 UF 20% IGV DIP TANT	UNION CARBIDE	K22EIG	2
C19	150001	220F 20% IGV DIP TANT		K22EIG	
C20	104026	47nF 20% SOV CER DISC	SIEMENS	B37449	-
C2I	180048	4700F 63V AL ELECT	ECC	SMVB	-
C22	180047	10000F 40V AL ELECT	ECC	SMVB	-
C23	180047	1000 F 40V AL ELECT	ECC	SMVB	-
C24	180047	10000F 40Y AL ELECT	ECC	SMVB	-
C25	150016	INF 20% 35V DIP TANT	UNION CARBIDE	KIROE35	2
C26	150016	INF 20% 35V DIP TANT	UNION CARBIDE	KIROE35	-
C27	150021	22 JF 20% 25Y DIP TANT	UNION CARBIDE	K22E25	-
DI	200022	3A 400V GP SI DIODE	MOTOROLA	BY252	4
D2	200022	3A 400V GP SI DIODE	MOTOROLA	BY 252	-
D3	200022	3A 400V GP SI DIODE	MOTOROLA	BY252	-
NOTES.	ATECT ISSUE			DATE 29. 2. 84	
				CHECKED 4200	PS(IG) PCB ASS
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ESIGNATOR	DATRON PART No.	DESCRIPTION	FRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
D4	200022	3A 400V GP SI DIODE	MOTOROLA	BY252	
DS	200002	IA SOV GP SI DIODE	FAIRCHILD	IN4001	4
DG	200002	1A SOV GP SI DIODE	FAIRCHILD	IN4001	
D7	200002	IA 50V GP SI DIODE	FAIRCHILD	IN 4001	-
8	200002	IA SOV GP SI DIODE	FAIRCHILD	IN 4001	
09	210200	20V 400mW ZENER	MULLARD	BZY88C20	2
010	210200	20V 400mW ZENER	MULLARD	BZY88C20	—
DII	210033	3V3 400mW ZENER	MULLARD	BZY88C3V3	- 1
WI	209003	1A5 LOOV BRIDGE RECT	MICRO- ELECTRONICS	WOOI	4
W2	209003	LAS LOOV BRIDGE RECT	MICRO- ELECTRONICS	wool	-
W3	209003	IAS IOOV BRIDGE RECT	MICRO- ELECTRONICS	WOOI	
W4	209003	1A5 100V BRIDGE RECT	MICRO- ELECTRONICS	WOOI	_
QI	240037	SI NPN TRANSISTOR	MOTOROLA	TIP141	1
Q2	250026	SI PNP TRANSISTOR	MOTOROLA	TIPI46	I
Q3	230047	N-CHAN I LIM 5.3mA	TELEDYNE	TCR 513	2
Q4	230047	N-CHAN I LIM 5.3mA	TELEDYNE	TCR513	
•					
MI	260051	-15V IA REGULATOR	MOTOROLA	MC79.15CT	2
MZ	260006	15V IA REGULATOR	MOTOROLA	MC78ISCT	2
NOTES.	ATEST ISSUE				
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER		MANUFACTI PART No.	URER'S	No. USED Per Assy.
M3	260070	317 ADJ. REGULATOR	NATIONAL		LM317 H	VK	l
M4	260006	ISV IA REGULATOR	MOTOROLA		MC7815	ст	-
M5		NOT USED					
MG	260005	5V IA REGULATOR	MOTOROLA		MC 7805	CT	1
M7	260051	-15V IA REGULATOR	MOTOROLA		MC 79.15	ст	
MB	260072	-8V IA REGULATOR	NATIONAL		LM7809	СТ	<u> </u>
M9	260071	8V IA REGULATOR	NATIONAL		LM7808	СТ	1
<u> </u>							
LI		NOT USED					
L2	370013	4UH GA RF CHOKE	ERO		F1756-0	04-601	2
L3	370013	4NH GA RF CHOKE	ERO		F1756 - 0	04-601	-
L4	370014	BUH 3A RF CHOKE	ERO		F1756-0	08-301	4
L5	370014	BUH 3A RF CHOKE	ERO		F1756 - 0	08-301	-
LG		NOT USED					
L7	370014	BA RF CHOKE الر	ERO		F1756-0	08-301	-
L8		NOT USED					
L9	370014	BUH 3A RF CHOKE	ERO		F1756-00	8-301	
LIO	370019	PS COMMON MODE CHOKE	SIGA		SEE DRG		1
			Δ			/	
Fl	920128	FUSE 4A 250V 20mm SLO-B	BELLING LEE		L2080A		2
F2	920128	FUSE 4A 250V 20mm SLO-B	BELLING LEE		L2080A	4	-
NOTES. SEE SHEET 2 FOR L	ATEST ISSUE			0416 29.	2.84	norteb	ELECTRONICS LTD
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
F3	920143	FUSE 3.15A 250V 20mm SLO-E	BELLING LEE	L2080A/3.15	2
F4	920143	FUSE 3. 15A 250V 20mm SLO-	BELLING LEE	L2080 A / 3.15	-
F5	920116	FUSE IA 250V 20mm SLO-B	BELLING LEE	L2080A/1	2
F6	920116	FUSE IA 250V 20mm SLO-B	BELLING LEE	L2080A/1	-
	540002	22 SWG TINNED COPPER WIRE			A/R
	410282-2	PCB			1
	590004	SLEEVE- PTFE	HELLERMANN ELECTRIC	FEIO	A/R
	604042	4WAY . 156" PLUG GD. PL.	MOLEX	09-72-2041	5
	611006	M3×10mm POZIPAN STEEL	ZN PL		10
	613005	M3 INT SHAKEPROOF	ZN PL		10
	613007	M3 WASHER STEEL	ZNPL		3
	615002	M3 FULL NUT STEEL	ZN PL		10
:	618010	INSULATING PAD SIL TO-220	WARTH	3223-07FR-54	2
	618001	INSULATING BUSH TO-220	MULLARD	56359C	2
	620007	TEST POINT TERMINAL	MICROVAR	TYPE C30	12
	900003	HEATSINK COMPOUND	RS	554 - 311	A/R
	900004	SILICONE RUBBER COMPOUND	RS	555-588	A/R
	920088-1	HEATSINK TO-3	SEE DRG		1
	920089-1	HEATSINK TO-220	SEE DRG	,	
	920105-1	HEATSINK TO-202	SEE DRG		3
	920126	FUSE HOLDER 20mm PCB	BELLING LEE	L1426	6
	920142	HEATSINK 2 x TO-220	REDPOINT	TV35H19	2
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
RI	004752	7K5 2% 1/4W MET-OX	ELECTROSIL	TR4	2
R2	011300	130R 1% 1/8W 50ppm MF	HOLCO	H8C	2
RЗ	000682	6k8 5% /3W CARBON	MULLARD	CR25	2
R4	000563	56k 5% 1/3W CARBON	MULLARD	CR25	2
R5	000104	100k 5% 1/3W CARBON	MULLARD	CR25	2
RG	000103	IOK 5% 1/3W CARBON	MULLARD	CR25	2
R7	000471	470R 5% /3W CARBON	MULLARD	CR25	2
R8	004752	7k5 2% 1/4W MET-OX	ELECTROSIL	TR4	
R9	011300	130R 1% 1/8W 50ppm MF	HOLCO	H8C	-
RIO	000682	6k8 5% JAW CARBON	MULLARD	CR25	
RII	000563	56K 5% 1/3W CARBON	MULLARD	CR25	-
R12	000104	IOOK 5% /3W CARBON	MULLARD	CR25	-
R13	000103	IOK 5% 1/3W CARBON	MULLARD	CR25	
RI4	000471	470R 5% 1/3W CARBON	MULLARD	CR25	
R15	006392	3k9 % IW MET-OX	ELECTROSIL	FPI	2
R16	006392	3k9 % IW MET-OX	ELECTROSIL	FPI	-
R17	000272	2k7 5% 1/3W CARBON	MULLARD	CR25	2
R18	000222	2k2 5% 1/3W CARBON	MULLARD	CR25	2
R19	000308	3RO 5% VOW CARBON	MULLARD	CRZS	2
R20	012741	2k74 1% 1/8W 50ppm MF	HOLCO	НВС	2
R21	013922	39K2 1% 1/8W 50ppm MF	Holco	H8C	2
R22	000272	2k7 5% 1/3W CARBON	MULLARD	CR25	-
R23	000222	2k2 5% 1/3W CARBON	MULLARD	CR25	-
NOTES. SEE SHEET I FOR I	ATEST ISSUE		<u>-</u>	DRAWN	(38V) PCB AS
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S	No. USED Per Assy.
R24	000308	3RO 5% 1/3W CARBON	MULLARD	CR25	-
R25	012741	2k74 1% 1/8W 50ppm MF	Holco	Н8С	-
R26	013 922	39K2 1% 18W 50ppm MF	Ногсо	H8C .	-
CI	110042	100 NF 20% 63V POLYESTER		MKS2	3
C2	110042	100 nF 20% G3V POLYESTER		MK52	-
<u>C3</u>	110042	100nF 20% G3V POLYESTER	WIMA	MKS2	-
C4	120028	4.7F 20% 100V POLYCARB	WIMA	FKC2	2
C5	120028	4.7F 20% 100V POLYCARB	WIMA	FKC2	_
C6	150016	LUF 20% 35V DIP TANT	UNION CARBIDE	KIROE35	2
C7	150015	100 F 20% 35V DIP TANT	UNION CARBIDE	KIDE35	2
C8	150015	F 20% 35V DIP TANT	UNION CARBIDE	KIDE 35	-
29	150016	INF 20% 35V DIP TANT	UNION CARBIDE	KIROE35	
210	180040	QUE LOOV AL ELECT	ECC	SMVB	2
211	180040	100F 100V AL ELECT	ECC	SMVB	
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NOTES. SEE SHEET 2 FOR L	ATEST ISSUE	•		. 2.86 datron	ELECTRONICS LTD
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DESIGNATOR	DATRON	DESCRIPTION	PRINCIPAL	MANUFACT		No. USED
SEGRENATION	PART No.	DESCRIPTION	MANUFACTURER	PART No.	UNEN S	Per Assy.
DI	210270	27V 400mW ZENER	MULLARD	BZY88C	27	2
D2	210270	27V 400mW ZENER	MULLARD	BZY88C	27	-
DB	200001	75mA 75V GP SI DIODE	FAIRCHILD	IN4148		2
D4	200001	75mA 75V GP SI DIODE	FAIRCHILD	IN4148		-
D5	214012	2V45 30ppm ZENER	FERRANTI	ZN458		2
DG	214012	2V45 30 ppm ZENER	FERRANTI	ZN458		-
D7	210068	6V8 400mW ZENER	MULLARD	BZY88CG	578	2
08	210068	6V8 400 mW ZENER	MULLARD	BZY88C	678	
		3				
<u>A</u> 1	250026	SI PNP TRANSISTOR	MOTOROLA	TIDIAC	·	
Q1 Q2	240037	SI NPN TRANSISTOR	MOTOROLA	TIPI46 TIPI41		
Q2 Q3	250018	SI PNP TRANSISTOR	MOTOROLA	BC 556/1	2018	
Q4	250018	SI PNP TRANSISTOR	MOTOROLA	BC 556/		3
	240029	SI NPN TRANSISTOR	MOTOROLA	BC 556/		
<u>35</u>	240029	SI NPN TRANSISTOR	MOTOROLA	BC 546/1		3
Q6 Q7	250018		MOTOROLA			3
and the second se		SI PNP TRANSISTOR		BC 556/1		
Q8	240029	SI NPN TRANSISTOR	MOTOROLA	BC 546/1	018	
NOTES.				DATE		
SEE SHEET 2 FOR L	ATEST ISSUE			15.5.86	datron	ELECTRONICS LTD
155. E C D.					4700 PS(38V	
DATE				DATE	NUMBER 400653	3 4 or 5

DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACT	URER'S	No. USED Per Assy.
MI	260043	358 DUAL OP AMP	NATIONAL	LM358N	ł	1
					•	
FI	920120	FUSE IA 125V 7mm	LITTLEFUSE	275 001		2
2	920120	FUSE IA 1254 7mm	LITTLEFUSE	275 001		
	410254-2	^ν CB				1
	605059/A	8 WAY DIL SOCKET				1
	611016	M3×8mm POZIPAN STEEL	ZN.PL.			2
	613005	M3 INT. SHAKEPROOF	ZN. PL.			2
	615002	M3 FULL NUT STEEL	ZN.PL.			2
	620007	TEST POINT TERMINAL	MICROVAR	TYPE C30		8
	900003	HEATSINK COMPOUND	RS	554-311		A/R
	920141	HEATSINK TO-220	AAVID	50418		2
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
RI		NOT USED			-
R2	008057	22k 5% 9W WW RES	WELWYN	W23	1
R3	000101	100R 5% 1/3W CF RES	MULLARD	CR25	3
R4	000101	100R 5% 1/3W CF RES	MULLARD	CR25	-
R5	000221	220R 5% /3W CF RES	MULLARD	CR25	2
R6	000221	220R 5% 1/3W CF RES	MULLARD	CR25	-
R7	008055	2R2 1% 1/2W MET GLAZE	NEOHM	RGP0207	4
R8	008055	2R2 1% 12W MET GLAZE	NEOHM	RGP0207	-
R9	008055	2R2 1% 1/2W MET GLAZE	NEOHM	RGP02D7	-
RIO	064105	IM IS TURN V CM POT	BECKMAN	89P	i
RI	090155 - 1	IOK NTC THERMISTOR	DALE ELECTRONICS	SEE DRG	2
RI2	090155 - 1	IOK NTC THERMISTOR	DALE ELECTRONICS	SEE DRG	
RIB	008055	2R2 1% 1/2W MET GLAZE	NEOHM	RGPOZO7	-
R14	008021	0R47 5% 2.5W WW RES	WELWYN	W21	1
R15	012743	274k 1% 18W 50ppm MF	HOLCO	HBC	4
R 16	012743	274k 1% 18W 50ppm MF	HOLCO	H8C	-
R17		NOT USED			-
RIB		NOT USED			-
RIS	000101	1008 5% 1/3W CF RES	MULLARD	CR25	
R20	000102	IK 5% /3W CF. RES	MULLARD	CR25	1
R21	000470	47R 5% /3W CF RES	MULLARD	CR25	1
Rez	012743	274k 1% 18W 50ppm MF	HOLCO	H8C	
RE3	012743	274k 1% 18W 50ppm MF		HBC	
NOTES. SEE SHEET FOR L 155. E.C. DATE 29.5.84 2 CIIKD.		1741 1777 1818 1830 18 25.10.84 28.11.84 14 1, 85 29.1.85 19 40 40 40 40 40 40 40 40 40 40 40 40 40 4	00/	20.12.85 0atro III.e 1II.e Cxf0 4700 PA (Pi INVED DRAWING	D ELECTRONICE LTD 05) H/S ASSY

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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL	MANUFACTURER'S PART No.	No. USED Per Assy.
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CI	110043	10nF 20% 630V POLYESTER	WIMA	MKS4	1
C2		NOT USED			-
C3	150002	IOHF 20% IOV DT CAP	UNION CARBIDE	K10 E16	1
C4		NOT USED			-
C5	102471	470pf \$ 10% 500V CER DIS		CDIO	2
C6	102471	470 PF \$ 10% 500V CER DIS	c /TT	CDIO	
C7	150006	407F 20% 16V DIP TAN	UNION CARBIDE	K4R7EIG	<u> </u>
C8	101103	10 nF 25% 250V CER DIS		CDIO	2
C9	101103	10 .F 25% 250V CER DIS		CDIO	<u> </u>
C10	110053	47 NF 10% 630V POLYESTE	RWIMA	MKS4	4
CII	110053	47 F 10% 630V POLYESTE	RWIMA	MKS4	
C12	110053	47nF 10% 630V POLYESTE	RWIMA	MKS4	-
C13	110053	47NF 10% 630V POLYESTE	RWIMA	MKS4	
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
DI	210100	10V 400mW ZENER	MULLARD	BZY88CIO	4
D2	210100	IOV 400 mW ZENER	MULLARD	BZY88CIO	-
D3	210100	IOV 400 MW ZENER	MULLARD	BZY88CIO	-
D4	210100	IOV 400 mW ZENER	MULLARD	BZY88CIO	-
D5	200020	IA IKSV FR SI DIODE	MOTOROLA	BY339	1
06	200001	75 mA 75V GP SI DIODE	FAIRCHILD	IN4I48	I
D7		NOT USED			
DB	214012	2V45 30ppm ZENER	FERRANTI	ZN458	1
QI	239067-1	MTM 2N85 MATCHED	DATRON	SEE DRG.	2 PAIRS.
Q2		PAIR.			-
Q3	239067-1	MTM 2NB5 MATCHED	DATRON	SEE DRG.	
Q4		PAIR.			
Q5	240021	SI NPN TRANSISTOR	NATIONAL	BDI35	1
Q6	240001	SI NPN TRANSISTOR	NATIONAL	BC184/TO18	2
Q7	250001	SI PNP TRANSISTOR	NATIONAL	BC 214 / TO18	1
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CHKD.				DATE NUMBER 4006	37 4 " 7

ESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
18	240001	SI N.P.N. TRANSISTOR	NATIONAL	BC184/TO18	-
29	230001	N-CHAN I LIM 1.4mA	SILICONIX	J506	. 1
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٨	260048	7611 CMOS OP AMP	INTERSIL	ICL7611 DCPA	1
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SEE SHEET 2 FOR L	ATEST ISSUE			20.12. 85 UCU	LI ELECTRONICS LTD
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTU PART No.	RER'S	No. USED Per Assy.
	410245-4	PCB				1
	450454-1	HEATSINK 64mm				1
	450455-1	HEATSINK 91mm				1
	420080-1	HIGH VOLTAGE LABEL				2
	512000	7/-2 PIFE INSULATED (BLK)WIR	¥			A/R
	512111	7/+2 PTFE INSULATED (BRN)WIR				AIR
	512222	7/-2 PTFE INSULATED (RED)WIRE				AIR
	512444	7/-2 PTFE INSULATED (YEL) WIRE				AR
· · · · · · · · · · · · · · · · · · ·	512555	7/-2 PTFE INSULATED (GRN) WIRE				AIR
	512666	7/-2 PIFE INSULATED (BLUE)WIRE				AIR
	512777	7/-2 PTFE INSULATED (VIO.) WIRE				A/R
	512888	7/-2 PIFE INSULATED (GREY) WIR				AIR
	512999	7/-2 PIFE INSULATED (WHITE)WIRE				A/R
	512333	7/ 2 PTFE INSULATED (OR) WIRE				A/R
	560001	2 CORE 7/-2 BRAIDED SCN. CAB				•22M
	590001	SLEEVE MAX CABLE \$3.0	HELLERMANN ELECTRIC	H15 × 20m	m BLACK HELSYN	6
	590003	HEATSHRINK SLEEVE \$6.4		399-524	OR LVR64	40mm
	590002	SLEEVE MAX CABLE \$ 6.0	HELLERMANN ELECTRIC	H30 × 25m	BLACK HELSYN	3
JI	605052	8 WAY .I" HOUSING	MOLEX	22-01-20	085	I
	605057	CRIMP TERMINAL GD.PL.	Molex	4809-6	L	12
	605118-1	SOCKET \$ 1.02	CAMBION	SEE DRA	WING A4	8
	611006	M3 XIOMM POZIPAN STEEL				8
	611027	M3 × 20mm POZIPAN STEEL				4
NOTES.		, ,	DA11 2	0.12.85	datron	ELECTRONICS LTD
155.			Cited		4700.PA. (POS) H/S ASSY
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CIIKD.			DAT	E	10mmen 400637	6 . 7

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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
	612004-1	M3x4mm STANDOFF	HARWIN	CS2116/B	8
	613029	M3 WAVY WASHER 55			16
	615002	M3 FULL NUT STEEL ZN PL.	· · · · · · · · · · · · · · · · · · ·		4
	620003	SOLDER PIN	HARWIN	H2105A01	12
	620007	TEST POINT TERMINAL	MICROVAR	TYPE C30	4
	630024	STEATITE BEAD IS SWG	PARK ROYAL PORCELAIN	Nº 2	2
	630126	'P'CLIP Ø 7.9 mm	RICHCO	N5	
	613017	M3 WASHER NYLON			1
	900003	HEATSINK COMPOUND	RS	554-311	A/R
FBI	920145	FERROXCUBE BEAD	MULLARD	FX 4026	1
	590033	SLEEVE. MAX CABLE Ø 10	HELLERMANN ELECTRIC	H50 × 25mm BLK. HELSYN	2
	605059	8 WAY DIL SOCKET			
J3	605053	12-WAY +1" HOUSING	MOLEX	22-01-2125	
	613007	M3 WASHER STEEL ZN PL			4
	614001	M3 CLEAR × 4mm STANDOFF	HARWIN	CS2117B	4
	540002	22 SWG B.T.C. WIRE			A/R
	590004	SLEEVE Ø1.0 P.T.FE	HELLERMANN	FEIO	A/R
NOTES.			0410		
SEE SHEET 2 FOR L	ATEST ISSUE		UTA	20.12.85 datron	ELECTRONICS LTD
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
RI		NOT USED			-
R2	008057	22k 5% 9W WW RES	WELWYN	W23	-
R3	000101	100R 5% /3W CF RES	MULLARD	CR25	3
R4	000101	IOOR 5% YOW CF RES	MULLARD	CR25	-
R5	000221	220R 5% /3W CF RES	MULLARD	CR25	2
RG	008055	2R2 1% YOW MET-GLAZE	NEOHM	RGP0207	4
R7	008055	2R2 1% YOW MET-GLAZE	NEOHM	RGPO207	
R8	000221	220R 5% /3W CF RES	MULLARD	CR25	_
R9	090155-1	IOK NTC THERMISTOR	DALE ELECTRONICS	SEE DRG	2
RIO	090155-1	10k NTC THERMISTOR	DALE ELECTRONICS	SEE DRG	-
RII	008055	2R2 1% VZW MET-GLAZE	NEOHM	RGPO207	_
RIZ	012743	274k 1% 18W 50ppm MF		HBC	4
RI3	012743	274k 1% 18W 50ppm MF	HOLCO	HBC	-
RI4	008055	2R2 1% 1/2W MET- GLAZE		RGPOZO7	-
R15	008021		WELWYN	W21	1
RIG	000101	1008 5% /3W CF RES	MULLARD	CR25	÷
RI7	012743	274k 1% 18W 50ppm MF	HOLCO	H8C	
RI8	012743	274k 1% VBW 50ppm MF	HOLCO	HBC	
			-		
CI	110043	IONE 20% GOOV POLYESTER	WIMA	MKS4	4
C2 .	110043	100F 20% GBOV POLYESTER	WIMA	MKS4	
СЗ	110043	IONE 20% 630V POLYESTER	WIMA	MKS4	
C4	110043	10nF 20% GOV POLYESTER		MKS4	-
NOTES.	TEST ISSUE	.'		e. 2. 84 datron	ELECTRONICS LTD
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
C5	110053	47 NF 10% 630V POLVESTE	WIMA	MKS4	4
CG	1100 53	47 nF 10% 630V POLYESTER		MKS4	-
<u>C6</u> C7	110053	47nF 10% 630V POLYESTE	RWIMA	MKS4	-
C8	110053	47nF 10% 630V POLYESTER	WIMA	MKS4	-
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
DI	213019	2004 5% 1/2W ZENER	MULLARD	BZX79C200	6
D2	213019	2004 5% 1/2W ZENER	MULLARD	BZX79C200	-
D3	213019	2001 5% 1/2W ZENER	MULLARD	BZX79C200	-
D4	213019	2001 5% 1/2W ZENER	MULLARD	BZ×79 C 200	_
DS	213019	2001 5% 1/2W ZENER	MULLARD	BZX79 C200	-
D6	213019	2001 5% 1/2W ZENER	MULLARD	BZX79 C200	-
D7	210 100	IOV 400mW ZENER	MULLARD	BZY88CIO	4
D8	210100	IOV 400mW ZENER	MULLARD	BZY88CIO	
09	210100	IOV 400 mW ZENER	MULLARD	BZY88C10	
>10	210 100	IOV 400 MW ZENER	MULLARD	BZY88CIO	-
DII	200020	IA 145V FR SI DIODE	MOTOROLA	BY339	1
DI2	200001	75mA 75V GP Si DIODE	FAIRCHILD	IN4148	1
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<u> ସା</u>	239068-1 {	MTM 2P50 MATCHED	DATRON	SEE DRG.	2 PAIRS.
QZ		PAIR.			· _
ର୍ଞ	239068-1	MTM2P50 MATCHED	DATRON	SEE DRG.	-
Q4		PAIR.			-
Q5	250001	SI PNP TRANSISTOR	NATIONAL	BC214/TO18	
ସ୍ୱ	240001	SI NPN TRANSISTOR	NATIONAL	BC 184 / TO18	1
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SEE SHEET 2 FOR L	ATEST ISSUE	•		DATE 22.2.84	
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL	MANUFACTURER'S PART No.	No. USED Per Assy.
	410246-4	РСВ			1
	420080-1	LABEL 'DANCER HIGH VOLTAG	E'		2
· · ·	450454-1	HEATSINK 64mm			1
	450455-1	HEATSINK 91 mm			. 1
	605118-1	SOCKET Ø 1.02	CAMBION	SEE DRAWING. A4.	8
	590005	SLEEVE MAX, CABLE \$4.0		H20 × 20mm BLACK HELSYN	1
	590001	SLEEVE MAX. CABLE \$3.0		HIS X 20mm BLACK HELSY	
	590002	SLEEVE MAX. CABLE ØG.O		HIS X 25 mm BLACK HELSY	
FB2	920145	FERROX CUBE BEAD	MULLARD	FX4026	1
JI	604033	4 WAY .I" PCB PLUG GD. PL		22-29-2041	2
J2	605053	12 WAY .I" HOUSING	MOLEX	22-01-2125	1
	605057	CRIMP TERMINAL GD. PL.	MOLEX	4809-GL	5
		1			
	611006	M3 X 10mm POZI PAN STEEL	ZN PL		9
	611027	M3 × 20mm POZIPAN STEEL	ZN PL	,	3
	612004-1	M3×4mm STANDOFF	HARWIN	C52116/B	8
	613029	M3 WAVY WASHER SS			15
	613007	M3 WASHER STEEL	ZN PL		З
	615002	M3 FULL NUT STEEL	ZN PL		3
	620003	SOLDER PIN	HARWIN	H2105A01	5
	620007	TEST POINT TERMINAL	MICROVAR	TYPE C30	4
	630003	P'CLIP Ø4.8mm	SES	CN5	1
	900003	HEATSINK COMPOUND	RS	554-311	A/R
NOTES.			DATE 23 07440	8.2.84. datron	ELECTRONICS LTD
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E.C.O.			АРРВО		
DATE CHKD.			DATE	NUMBER 400539	5 OF 6

DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
	512222	7/-2 PTFE INSULATED (RED) WIRE			A/R
	512444	7/+2 PTFE INSULATED (YEL) WIRE			A/R
	512666	7/-2 PTE INSULATED (BLUE) WIRE			A/R
	512999	7/.2 PTFE INSULATED (WHITE) WIR			A/R
	512 333	7/-2 PTFE INSULATED (OR) WIR			A/R
	630024	STEATITE BEAD ISSWG	PARK ROYAL PORCELAIN	Nº 2	2
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	614001	M3 CLEAR ×4mm STANDOFF	HARWIN	CS2117B	4
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
RI	000101	100R 5% 1/3W CF RES	MULLARD	CR25	2
R2	008037	OR 18 10% 2.5W WW RES	WELWYN	W21	2
R3	008037	OR 18 10% 2.5W WW RES	WELWYN	W21	-
R4	000101	IOOR 5% YOW OF RES	MULLARD	CR25	-
R5	008045	IOK 1% YZW MET-GLAZE	NEOHM	RGP0207	2
RG	000102	IK 5% Yaw CF RES	MULLARD	CR25	1
R7	000220	228 5% 1/3W CF RES	MULLARD	CR25	1
R8	006105	IM 2% IW MET-OX	ELECTROSIL	FPI	4
R9	014 991	4k99 1% 18W 50ppm MF	HOLCO	HBC	2
RIO	016811	6k81 1% 1/8W 50ppm MF	HOLCO	HBC	2
RII		NOT USED			-
R12	000 821	8208 5% /3W CF RES	MULLARD	CR25	2
R13	006105	IM 2% IW MET-OX	ELECTROSIL	FPI	-
R14	007 204	200k 2% 2W MET-0X	ELECTROSIL	FP2	4
RIS	011821	1k 82 1% 1/8W 50ppm MF	HOLCO	HBC	2
RIG	016192	61k9 1% '8W 50ppm MF	Holco	H8C	2
R17	008062	IOR 1% 21/2W WW RES	WELWYN	W2I	2
RIB	006105	IM 2% IW MET-OX	ELECTROSIL	FPI	-
R19	007204	200k 2% 2W MET-0X	ELECTROSIL	FP2	-
R20	011821	1k82 1% 18W 50ppm MF	HOLCO	H8C	-
R21	016192	61k9 1% 1/8W 50ppm MF	HOLCO	H8C	-
R22	006105	IM 2% IW MET-OX	ELECTROSIL	FPI	-
R23	200800	IOR 1% 21/2W WW RES	WELWYN	W2!	
E C.O. DATE 29.5.84 20	ATEST, ISSUE 2 3 691 1731 . 1740 	4 1775. 1805 1869 1902 9/185 19 4530 485		DRAWN	CD ELECTROMICS LTD 5/I H/S ASS 5540 2 51467

DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL	MANUFACTURER'S PART No.	No. USED Per Assy.
R24	008045	IOK 1% 1/2W MET-GLAZE	NEOHM	RGP 02 07	
R25		NOT USED			
R26	000 821	820R 5% 1/3W CF RES	MULLARD	CR25	-
R27	014 991	4 899 1% 1/8W SOppm MF	Holco	HBC	-
R28		NOT USED			
R29	016811	6k81 1% 1/8W 50ppm MF	HOLCO	HBC	
R30	007204	200k 2% 2W MET-0X	ELECTROSIL	FP2	-
R31	007204	200k 2% 2W MET-0X	ELECTROSIL	FP2	
R32	005470	47R 2% 1/2W MET-OX	ELECTROSIL	TRS	2
R33	005470	47R 2% 1/2W MET-OX	ELECTROSIL	TRS	-
R34, R35	013920	392R 1% V8W 50ppm MF	HOLCO	HBC	2
CI	104025	100 nF +80 % 50V CER DISC	SIEMENS	B37449	1
C2		NOT USED			-
C3		NOT USED			-
C4		NOT USED			-
C5	180045	47 JF GOV AL. ELECT.	MULLARD	031-38479	2
C6	1800 45	47 uf 63V AL. ELECT.	MULLARD	031-38479	
C7		NOT USED			
C8	120033	2n2F 20% IKY POLYCARB	WIMA	FKC3	2
C9	150006	4 TF 20% IGV DIP TANT	UNION CARBIDE	K4R7E16	2
C10	120033	2n2F 20% IKV POLYCARB	WIMA	FKC3	-
CII	150006	4,47F 20% IEV DIP TANT	UNION CARBIDE	K4 R7E16	-
CI2		NOT USED			-
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	PART No.	No. USED Per Assy.
CI3	104043	100pf 10% 500V CER D	ISC STC	CDIOKWKIOOPMSSS500	2
C14	104043	100pf 10% 500V CERD	SC STC	CDIOKWKIOOPMS \$5 500050	
C15	150010	330nF 20% 35V DIPT	ANT UNION CARBIDE	KR33E35	2
C16	150010	330 NF 20% 35V DIP T		KR33E35	
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
DI	210056	5VG 400mW ZENER	MULLARD	8ZY88C 5V6	2
D2	210150	15V 400mW ZENER	MULLARD	BZY88CI5	4
D3	213020	30Y 5% 1/2W ZENER	MULLARD	BZ×79 C30	2
04	200006	IA GOOV OP SI DIODE	FAIRCHILD	IN4005	4
05	213021	56V 2% 400mw ZENER	MULLARD	BZX 79 B 56	2
D6	200006	IA GOOV GP SI DIODE	FAIRCHILD	IN4005	
D7	214014	IV22 100ppm ZENER	TELEDYNE	94918J	2
08	210150	15V 400mW ZENER	MULLARD	BZY88CI5	-
D9	210150	15V 400 mW ZENER	MULLARD	BZY88C15	
010	200006	IA GOOV GP SI DIODE	FAIRCHILD	IN4005	
DII	213020	30V 5% 1/2W ZENER	MULLARD	BZX79C30	
DIZ	213021	567 2% 400mW ZENER	MULLARD	87×79 856	-
DI3	200006	IA GOOY GP SI DIODE	FAIRCHILD	IN4005	-
D14	210150	154 400mW ZENER	MULLARD	BZY88C15	-
DIS	210056	5VG 400mW ZENER	MULLARD	BZY88C 5VG	-
D16	214014	IV22 100ppm ZENER	TELEDYNE	9491 BJ	-
QI	240036	SI NPN DARL TRANSISTOR	MOTOROLA	MJ1000	
Q2	250024	SI PNP DARL. TRANSISTOR	MOTOROLA	MJ 900	
Q3	230063	N-CHAN TMOS JFET	MOTOROLA	MTP2N85	
Q4	250001	SI PNP TRANSISTOR	NATIONAL	BC214/TO18	
Q5	240006	SI NPN TRANSISTOR	NATIONAL	2N3904/TOI8	·····
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
Q6	250004	SI PNP TRANSISTOR	NATIONAL	2N3906/T092	1
Q7	240001	SI NPN TRANSISTOR	NATIONAL	BC184/TO:92	2
ସ୍ୱ	230001	N-CHAN I LIM 1.4 mA	TELEDYNE	TCR 506	2
Q9	230062	P-CHAN TIMOS JEET	MOTOROLA	MTM 2 P 50	1
QID	230001	N-CHANILIM 1.4 mA	TELEDYNE	TCR 506	-
QII	230064	P-CHAN T.MOS JEET	MOTOROLA	MTP2P50	1
QIZ	230061	N-CHAN T.MOS JFET	MOTOROLA	MTM 2N85 TO3	1
QI3	240001	SI NPN TRANSISTOR	NATIONAL	BC184/T018	
MI	220018	HI-SPEED OPTO ISOLATOR	нр	6N13G	2
M2	220018	Hi- SPEED OPTO ISOLATOR	НР	GNI3G	-
	410247-2	РСВ			1
	420080-1	LABEL 'DANGER HIGH VOLTAGE	e'	-	1
	450456-1	HEATSINK			1
	512 111	7/-2 PIFE INSULATED (BRN) WIRI			AIR
	512 222	7/-2 PTFE INSULATED (RED) WIRI			AR
	512444	7/-2 PIFE INSULATED (YEL) WIRI	F RS		A/R
	512555	7/-2 PIFE INSULATED (GRN) WIR	e RS		AIR
	512666	7/+2 PTFE INSULATED (BLU) WIR	RS		AR
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ESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
	512777	7/-2 PTFE INSULATED (VIO) WIR	e RS		A/R
	530000	24 / +2 PVC INSULATED (BLK)	ARE RS		A/R
	530111	24/ .2 PVC INSULATED (BRN)			AIR
	530222	24 / +2 PVC INSULATED (RED) W	IRE RS		AIR
	530333	24/ +2 PVC INSULATED (OR.) W	IRE RS		AIR
	530444	24/ +2 PVC INSULATED (YEL) W			A/R
	530555	24/ +2 PVC INSULATED (GRN) W			AIR
	530666	24/ .2 PVC INSULATED (BLUE)			AIR
	530777	24/ +2 PVC INSULATED (VIO) W			AIR
	530888	24/ +2 PVC INSULATED (GREY)			AIR
				The 10000	
	605059	8 WAY DIL SOCKET	JERMYN	J23-18008	2
	605052	8 WAY .I" HOUSING	MOLEX	22-01-2085	6
	605057	CRIMP TERMINAL GD.PL		4809-GL	
	605077	CRIMP TERMINAL GD. PL		08-56-0106	11
	605099	5 WAY . 156" HOUSING	MOLEX	09-91-0501	2
	605100	9 WAY . 156" HOUSING	MOLEX	09-91-0901	1
	611016	M3X8mm POZIPAN STEEL	ZN PL		2
	611017	M3 × 16mm POZI PAN STEEL			5
	611027	M3 x 20mm POZIPAN STEEL	ZN PL		3
	612022-1	M3×3mm STANDOFF	DATRON	SEE DRG. 612###	8
	613007	M3 WASHER STEEL	ZN PL	· · · · · · · · · · · · · · · · · · ·	3
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL	MANUFACTURER'S	No. USED Per Assy.
·	613029	M3 WAVY WASHER	ZN PL		13
	615002	M3 FULL NUT STEEL	ZN PL		5
	606010	POLARISING KEY	MOLEX	15-04-0219	<u> </u>
	618008	INSULATING BUSH TO3	MULLARD / ASSMANN	56201C/Y5358	8
	618009	INSULATING PAD SIL TO3	WARTH	3223- 07FR-06	4
	620003	SOLDER PIN	HARWIN	H2105A0	18
	630004	19' CLIP \$6.4mm	SES	CNG	<u> </u>
	605118-1	50CKET \$ 1.02	CAMBION	SEE DRAWING. A4	8
	920087-1	HEATSINK TO-92	SEE DRG		1
	630126	'P' CLIP Ø 7.9 mm	RICHCO	N5	1
	590001	SLEEVE. MAX CABLE \$ 3.0	HELLERMAN ELECTRIC	HI5 X 20 BLACK HELSYN	3
	590005	SLEEVE, MAX CABLE Ø 4.0		H20×20 BLACK HELSYN	6
	590032	SLEEVE HEATSHRINK \$4.8			0.5M
	590033	SLEEVE, MAX CABLE \$ 10	HELLERMANN ELECTRIC	H50 x 25 BLACK HELSYN	3
	590004	SLEEVE, ØI.O PTFE	HELLERMANN ELECTRIC	FEIO	A/R
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
RI	008032	270R 5% 21/2W W/W	WELWYN	W2I	1
? ?	008029	18R 2% 1/2W MET GLAZE	NEOHM	RGPO207	2
₹3	000103	IOK 5% 1/3W CARBON	MULLARD	CR25	5
{4	000103	IOK 5% YOW CARBON	MULLARD	CR25	
25	000 103	IOK 5% '3W CARBON	MULLARD	CR25	-
26	000105	IM 5% V3W CARBON	MULLARD	CR25	<u> </u>
27	000103	IOK 5% 'SW CARBON	MULLARD	CR25	-
28	620800	IBR 2% VEW MET GLAZE	NEOHM	RGP0207	-
29	000472	4k7 5% VSW CARBON	MULLARD	CR25	1
210	001151	150R 5% 1/2W CARBON	MULLARD	CR37	<u> </u>
RII		NOT FITTED			-
212	000103	IOK 5% YOW CARBON	MULLARD	CR25	-
213		NOT FITTED			
R14	006272	2k7 2% IW MET- 0X	ELECTROSIL		
			· · · · · · · · · · · · · · · · · · ·		· · · · · · · · · · · · · · · · · · ·
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SEE SHEET 2 FOR L	ATEST ISSUE				HV PCB ASSY
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
ANI	090131	IOK × 4 2% SIL NETWOR	K BECKMAN	LOB-3-RIOK	2
AN2	090131	IOK ×4 2% SIL NETWOR	K BECKMAN	LO8-3-RIOK	-
AN3	090096	IM ×8 2% NETWOR	K BECKMAN	109-1-RIM	.1
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		· · · · · · · · · · · · · · · · · · ·	·		·····
CI	140047	33nF 10% 1K5V POLYPRO	PSTEATITE	MKP1841	3
C5	140047	33nF 10% 1k5V POLYPROL		MKP 1841	-
СЗ	180048	470 JF SOV AL. ELEC.	ECC	SMYB	2
C4	180048	470 JAF 50V AL. ELEC	ECC	SMVB	-
C5	104026	47nF +50 % 50V CER DISC	SIEMENS	B37449	З
C6	104026	47 .F 1 58% 50V CER DISC		837449	
C7	104026	47 F = 20% 50V CER DISC	SIEMENS	B37449	-
C8	102102	InF 10% 500V CER DISC		CDIO	1
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
C 9	102221	220pf 10% 500V CER DISC	ITT	CDIO	1
CIO	140048	470F 10% IKSV POLYPROP	STEATITE	MKP1841	1
CII	102821	820 PF 10% 500V CER DISC	ТТ	CDIO	I
C12	102332	3n3F 20% 500V CER DISC	ТТ	CDIO	1
C13	140047	33nF 10% IK5V POLYPROP	STEATITE	MKP1841	-
<u>CI4</u>	104044	680pf 10% 2kV CER DISC	JTT	НДОЭ	1
				·····	
DI	200020	IA IKSV FR SI DIODE	MOTOROLA	BY339	8
DS	2000 20	IA IKSV FR SI DIODE	MOTOROLA	BY339	-
D3	5000 50	IA IKSV FR SI DIODE	MOTOROLA	BY339	-
D4	200020	IA IKSV FR SI DIODE	MOTOROLA	вүззэ	-
Ds	500050	IA IKSV FR SI DIODE	MOTOROLA	ВУ339	-
D6	200020	IA 165V FR SI DIODE	MOTOROLA	Вү339	-
D7	500050	IA IKSV FR SI DIODE	MOTOROLA	By339	-
08	2000 20	IA IKSV FR SI DIODE	MOTOROLA	BY339	-
D9	200005	IA SOV GP SI DIODE	FAIRCHILD	IN4001	1
DIO	213009	15V 5W ZENER	UNITRODE	TVS 515	. 1
DII	213006	SV SW ZENER	UNITRODE	TVS 505	2
DIZ	213006	SV SW ZENER	UNITRODE	TVS505	-
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
QI	250011	SI PNP TRANSISTOR	NATIONAL	BC327 / TOI8	ľ
MI	290089	7 X DARLINGTON DRIVER	SPRAGUE/EXAR	ULN 2003A/XR 2203 CP	
M2	280039	QUAD EXCLUSIVE NOR	MOTOROLA	MC140778CP	1
M3	280023	QUAD 2 I/P NOR	MOTOROLA	MC 1400 I U BCP	1
RLI		NOT FITTED			
RL2	330033	RELAY 2P NO 5A 2KV	SDS	JC24 DC24V	3
RL3	330033	RELAY 2P NO 5A 24V	SDS	JC2a DC24V	
RL4	330033	RELAY 2P NO 5A 24V	SDS	JC 29 DC 24V	-
RLS	330044	RELAY 2P2W 5A	DATRON		
LI		NOT USED		· · · · · · · · · · · · · · · · · · ·	-
r5	370001	100H 0.85 JZ RF CHOKE	PLESSEY	58/10/0011/10	3
L3	370007-1	40mH CHOKE	SIGA	SEE DRG-	1
L4	370015-1	26m5H CHOKE	SIGA	SEE DRG-	1
L5	370016-1	24mlH CHOKE	SIGA	SEE DRG-	1
LG	370001	10H O.85 & RF CHOKE	PLESSEY	58/10/0011/10	-
L7	370001	IOAH O.85 J RF CHOKE	PLESSEY	58/10/0011/10	-
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
	400563	CONSTANT I PCB ASSY			1
	410327 1	H.V. PCB.			J
	420080-1	HIGH VOLTAGE LABEL			1
	450461-1	H.V. PCB SAFETY SCREEN	DATRON		1
	512999	7/0.2 PTFE INS. WHITE WIRE	RS		A/R
	590031	HEATSHRINK \$3.2 YEL.	HELLERMANN ELECTRIC	YELLOW OPACUE	Alr
J2, J3, J4	604033	4 WAY . I" PCB PLUG GD. PL	MOLEX	22-29-2041	7
LKA/B	604046	3 WAY .I" PCB PLUG GD.PL.	MOLEX	22-10-2031	1
	605127	2 WAY .I" 'SHORTING' SKT.	ASSMANN	AKSPL-G	· · ·
······	611006	M3×10mm SCREW POZIPAN ST.	ZN.D	GKN	2
	613029	M3 WAVY WASHER SS.			2
	615002	M3 FULL NUT STEEL ZN.PL.		-	2
	613005	M3 SHAKERROOF WASHER	ZN.PL		2
	620007	TEST POINT TERMINAL	MICROVAR	TYPE C30	8
	630024	IGSWG STEATITE BEAD	PARK ROYAL PORCELAIN	Nº 2	8
	605060	14 PIN DIL SOCKET	JERMYN	J23-18014	2
	605061	IG PIN DIL SOCKET	JERMYN	J23- 18016	1
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL	' MANUFACTURER'S PART №.	No. USED Per Assy.
RI	000102	IK 5% 1/4W CARBON	MULLARD	CR25	2
Re	005124	120K 2% YEW MET-OX	ELECTROSIL	TR5	6
R3	005124	120K 2% 2W MET-OX	ELECTROSIL	TR5	-
R4	005124	120k 2% 1/2W MET-0X	ELECTROSIL	TR5	-
R5	005124	120k 2% 1/2w MET-0X	ELECTROSIL	TR5	-
R6	005124	120K 2% 'ZW MET-OX	ELECTROSIL	TRS	-
R7	005124	120K 2% 1/2W MET-OX	ELECTROSIL	TRS	-
R8	000105	IM 5% 1/4W CARBON	MULLARD	CR25	1
R9	000104	100k 5% 1/4W CARBON	MULLARD	CR25	1
RIO	000470	47R 5% 1/4W CARBON	MULLARD	CR25	1
RII	000102	IK 5% 1/4W CARBON	MULLARD	CR25	-
RI2	008046	IOR, 5% 21/2W WIRE WOUND	WELWYN	Wal	1
RI3	000221	2208 5% '4W CARBON	MULLARD	CR25	1 .
RI4	000221	NOT USED			-
RIS	000 223	22k 5% '4W CARBON	MULLARD	CR25	1
RIG	000222	2k2 5% 1/4W CARBON	MULLARD	CR25	1
RIT	000103	IOK 5% 1/4W CARBON	MULLARD	CR2S	1
CI	150012	100nf 20% 35V DIP TANT	UNION CARBIDE	KRIDE 35	· I
C2	101103	10nF 25% 250V CER DISC		CDIO	
	101103	IUNI 2378 2307 CER DISC			
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACT	URER'S	No. USED Per Assy.
DI	213026	120V 3.25V ZENER	MULLARD	BZT 03C	20	12
DS	213026	120V 3.25V ZENER	MULLARD	BZT 03C	120	-
D3	213026	120V 3.25Y ZENER	MULLARD	BZT 03C	120	-
D4	2130 26	120V 3.25V ZENER	MULLARD	8ZT 030	120	· -
D5	2130 26	1204 3.25V ZENER	MULLARD	BZT 03C	120	-
D6	2130 26	120V 3.25V ZENER	MULLARD	8ZT 03C	120	-
D7	2130 26	1204 3.251 ZENER	MULLARD	BZT 03C	120	-
D8	2130 26	120V 3.25V ZENER	MULLARD	BZT 03C	20	-
D)	2130 26	120V 3.25V ZENER	MULLARD	BZT 03C	120	-
DIO	2130 26	120V 3.25V ZENER	MULLARD	BZT 03C	20	-
DII	213026	120V 3.25V ZENER	MULLARD	BZT 03C	20	-
PIZ	213026	1204 3.254 ZENER	MULLARD	BZT 03C	120	-
DI3	210100	IOV 400mW ZENER	MULLARD	BZY88C	10	1
D14	200008	200 mA 125V LL SI DIODE	FAIRCHILD	IN458A		4
D15	200008	200 mA 125V LL SI DIODE	FAIRCHILD	IN458A	۱ <u>ــــــــــــــــــــــــــــــــــــ</u>	-
DIG	200008	200 mA 125V LL SI DIODE	FAIRCHILD	IN458A		-
DI7	200008	200 mA 125V LL SI DIODE	FAIRCHILD	IN458A		-
DIS	200001	75mA 75V GP Si DIODE	FAIRCHILD	IN4148		2
DI9	200001	75 mA 75V GP Si DIODE	FAIRCHILD	IN4148		-
D20	200020	IA IKSV FR SI DIODE	MOTOROLA	BY339		1
			-			-
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
QI	240032	SI NPN TRANSISTOR	MOTOROLA	BF 393/ TO18	12
Q2	240032	SI NPN TRANSISTOR	MOTOROLA	BF 393/ TOIB	-
Q3	240032	SI NPN TRANSISTOR	MOTOROLA	BF 393/ TOI8	-
24	240032	SI NPN TRANSISTOR	MOTOROLA	BF 393/ TO18	-
Q5	240032	SI NPN TRANSISTOR	MOTOROLA	BF 393 /TO18	-
ସତ	240032	SI NPN TRANSISTOR	MOTOROLA	BF 393 /TO18	-
27	240032	SI NPN TRANSISTOR	MOTOROLA	BF 393/TO18	-
ହ	240032	SI NPN TRANSISTOR	MOTOROLA	BF 393/TOI8	-
29	240032	SI NPN TRANSISTOR	MOTOROLA	BF 393/TO18	· -
ହାତ	240032	SI NPN TRANSISTOR	MOTOROLA	BF 393/TO18	-
२ ॥	240032	SI NPN TRANSISTOR	MOTOROLA	BF 393/TO18	· -
ସାହ	240032	SI NPN TRANSISTOR	MOTOROLA	BF 393/TO18	-
QI3	230039 B	P-CHAN JEET	SILICONIX	J175	1
Q14	250011	SI PNP TRANSISTOR	NATIONAL	BC 327/TOI8	1
МІ	220015	5kV OPTO ISOLATOR	MOTOROLA	M0C1005	<u>I</u>
	590004	PTFE SLEEVE \$ 1.0		FE10	25 m m
	410285-3	PCB			1
	604003	II WAY PCB PLUG-	Амр	163740-9	5/11
	605066	6 WAY DIL SOCKET			I
	620007	TEST POINT TERMINAL	MICROVAR	TYPE C30	
NOTES. SEE SHEET 2 FOR LAT	EST ISSUE			DRAWN	
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
	008043	120K 5% 50W AL. W.W.	DALE	RH-50	1
	300023-2	4200 MAINS TRANSFORMER	2 SIGA	SEE DRG.	1
	450413-2	4200 HV SWITCH BRACKET	•		I
	450434-4	4200 MAINS TX PLATE.			1
	521006	IG/0.2 PVC INSULATED WIRE	. GREEN/YELLOW		A/R
	521002	16/0.2 PVC INSULATED WIR	E.WHITE RED.		A/R
	53011	24/0.2 PVC INSULATED WIR	BROWN.		A/R
	530444	24/0.2 PVC INSULATED WIR			A/R
	530555	24/0.2 PVC INSULATED WIR	F. GREEN.		A/R
	530666	24/0.2 PVC INSULATED WIR	E. BLUE .		A/R
	530999	24/0.2 PVC INSULATED WIE	E. WHITE.		A/R
	512999	7/0.2 PTE INSULATED WI	E. WHITE.		0.35
	590005	SLEEVING H 20 X20 BLACK			10
	590006	SLEEVE HEATSHRINK Ø 2-	4		Ale
	590033	SLEEVING HOOX 25 BLACK	4		14
	590031	SLEEVE HEATSHRINK \$3			A/R
	605052	BWAY OI HOUSING	MOLEX	22:01-2085.	1
	605057	CRIMP TERMINAL GD PL	MOLEX	4809 - GL	2
	605077	CRIMP TERMINAL GD PL	MOLEX	08-56-0106	31
	පොදු	SWAY DISG" HOUSING	MOLEX	09-91-0501	1
	605100	SWAY OUSING HOUSING	MOLEX	09-91-0901	4
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
	605136	0.093 MALE CRIMP TERM.GD.	MOLEX	02-09-6123	5
	01000	POLARISING KEY	MOLEX	15-04-0219	4
	604068	GWAY 0.093" PLUG	MOLEX	03-03-2062.	
	611015	M3x Bmm POZI-CSK STEEL	ZN PL		5
	611081-2	M5x12mm STEEL SCREW.	·	SEE DRAWING.	2
	613005	M3 INT SHAKEPROOF	· · · · · · · · · · · · · · · · · · ·		3
	613009	484 SOLDER TAG BRASS	TIN PL		5
	613013	M5 FLAT WASHER			2
	615002	M3 FULL NUT STEEL	ZN PL		3
	700093	SWITCH AP 2P C/O.	ARROW-HART	CTSIZ BP4	
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
	300025-2	L.F TRANSFORMER	SIGA		}
	450402-2	4200 LF. TX MTG. PLATE			1
	450405-1	4200 LF. TX PLATE SUPPT.	BAR.		2
	450408-1	4200 CONN. MTG. BRKT.			1
	540002	BTC WIRE			A/R
	510000	WIRE 7/ 2 BLACK PVC INS			A/R
	510111	WIRE 7/.2 BROWN PVC INS			A/R
	510220	WIRE 7/.2 RD/BK PVC INS	5.		A/R
	510330	WIRE 7/2 DE/BK PVC INS			A/R
	510333	WIRE 7/2 ORANGE PVC INS			A/R
	510444	WIRE 7/2 YELLOW PVC INS	5		A/R
	510555	WIRE 7/-2 GREEN PVC IN	5.		A/R
	510888	WIRE 7/-2 GREY PVC IN	5		A/R
	510399	WIRE 7/12 WHITE PVC IN	5.		A/R
	510666	WIRE 7/-2 BLUE PYC IN			A/R
-	510777	WIRE 7/2 VIOLET PYC IN	S		A/R
	560012	I CORE 1/0.64 CO-AX			A/R
	530003	SLEEVE HEATSHRINK ØG.4	RS OR HELLERMANN ELECTRIC	399-524 OR LVRGA	A/R
	530006	SLEEVE HEATSHRINK \$2.4	RS OR HELLERMANN ELECTRIC	399-495 OR LVR 24	A/R
	530032	SLEEVE HEATSHRINK Ø4.8			A/R
	510222	WIRE 7/2 RED PYC INS.			A/R
	605051	AWAY OI HOUSING	MOLEX	22-01-2045	1
	605052	BWAY OI HOUSING	MOLEX	22-01-2085	1
NOTES. SEE SHEET I FOR LAT	1651 ISSUE 2 3 4 94 1030 1031 94 9-5 0431-784		DATE 22. DRAWN CHECKEL APPROV DATE	L.F. TRANSFORM	IER ASSY

DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER		ANUFACTURER'S	No. USED Per Assy.
	605057	CRIMP TERMINAL GD PL	MOLEX		4089-GL	4
	605116-2	32+32WAY PCB EDGE SKT.			SEE DRG. A4.	1
	611007	M3xGmm POZICSK STEEL	ZN PL			7
	611016	M3x8mm POZI-PAN STEEL	ZN PL			3
	ତୋଠତର	M5x 8 MM HEX HEAD STEEL	ZNPL			2
	613005	M3 INTERNAL SHAKE PROOF				4
	613007	M3 WASHER STEEL	ZN PL			1
	613009	4BA SOLDER TAG BRASS	TIN PL			1
	613028	M5 INTERNAL SHAKE PROOF			· · · · · · · · · · · · · · · · · · ·	2
	615002	M3 FULL NUT STEEL	ZN PL			
	630004	PCLIP Ø G Amm	SES		CNG	1
	630170	PCB GUIDE	RICHCO		RCG2	2
	200003	LOCKING COMPOUND	LOCTITE		2.22	Alr
	510992	WIRE 7/2 WH/RED PVC INS				AIR
	51,6001	WIRE 7/2 PINK PVC INS				A/R
	510225	WIRE 7/2 RED/GRN PVC INS		-		A/R
	512999	WIRE 7/2 WHITE PTE INS				A/R
	510226	WIRE 7/2 RED/BLUE PVC INS				A/R

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	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
RI	008042	GRB 5% DW WIREWOUND	WELWYN	W 23	1
	300026-2	HE TRANSFORMER	SIGA	SEE DRG.	1
	410256 - 6	HE TX MOUNTING PCB.			
	512222	7/0.2 PTE INSUL. WIRE	RED.		0.35 м
	512666	7/0.2 PTE INSUL. WIRE	BLUE.		0.35 M
·	512000	7/0.2 PTFE INSUL. WIRE	BLACK.		O.50W
	512111	7/0.2 PTE INSUL. WIRE	BROWN .		0.3IM
	512444	7/0-2 PTFE INSUL. WIRE	YELLOW.		0·25M
	512 999	7/0.2 PTFE INSUL. WIRE	WHITE.		D.SIM
	590001	SLEEVING HI5x20 BLACK.			2
	530005	SLEEVING HEAXED BLACK.	· · · · · · · · · · · · · · · · · · ·		3
	530063	295mm CABLE TIE.	PANDUIT	PLT 31	
	605051	AWAY OI HOUSING	MOLEX	22-01-20-45	1
	605053	12 WAY OI HOUSING	MOLEX	22-01-2125	1
	605057	CRIMP TERMINAL GD. PL	MOLEX	4809-GL	6
	611055	M4x 40mm SLOT-PAN BRASS	NI PL		1
	612029-1	M3x12mm STANDOFF	HARWIN	SEE DRG GIZ ***	4

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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
	613020	MA WASHER STEEL.	ZN. PL		2
	613021	MA INT. SHAKEPROOF.			1
	615011	MA FULL NUT STEEL	ZNPL		1
	630024	STEATITE BEAD IGSWG	PARK ROYAL PORCELAIN	N° 2	2
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFAC PART No.	TURER'S	No. USED Per Assy.
RI	001822	8k2 5% 1/2W CARBON	MULLARD	CR37		24
R2	001822	8k2 5% 1/2W CARBON	MULLARD	CR37		-
R3	001822	8k2 5% 1/2W CARBON	MULLARD	CR37		-
R4	001 822	8k2 5% 1/2W CARBON	MULLARD	CR37		-
R5	001822	8k2 5% 1/2W CARBON	MULLARD	CR37		
R6 '	001 822	8k2 5% 1/2W CARBON	MULLARD	CR37		
R7	001 822	8k2 5% 1/2W CARBON	MULLARD	CR37		-
R8	001 822	8k2 5% 1/2W CARBON	MULLARD	CR37		-
R9	001 822	8k2 5% 1/2W CARBON	MULLARD	CR37		-
RIO	001 822	8k2 5% 1/2W CARBON	MULLARD	CR37		-
RII	001822	8k2 5% V2W CARBON	MULLARD	CR37		-
R12	001822	8k2 5% 1/2W CARBON	MULLARD	CR37		
RI3	001822	8k2 5% 1/2W CARBON	MULLARD	CR37		-
R14	001822	8k2 5% 1/2W CARBON	MULLARD	CR37		
R15	001822	8k2 5% 1/2W CARBON	MULLARD	CR37		-
R16	001822	8k2 5% 1/2W CARBON	MULLARD	CR37		-
R17	001822	8k2 5% 1/2W CARBON	MULLARD	CR37		-
R18	001822	8k2 5% 1/2W CARBON	MULLARD	CR37		
RIS	001822	8k2 5% 1/2W CARBON	MULLARD	CR37		
R20	001822	8k2 5% 1/2W CARBON	MULLARD	CR37		
R21	001822	8k2 5% 1/2W CARBON	MULLARD	CR37		
R22	001822	8k2 5% 1/2W CARBON	MULLARD	CR37		-
R23	001822	8k2 5% 1/2W CARBON	MULLARD	CR37		-
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R24	001822	8k2 5% 1/2W CARBON	MULLARD	CR37	-
R25	063205	2M POT 3/8 SQ CERMET	BECKMAN	72P	ġ.
226.	000104	100k 5% 1/3W CARBON	MULLARD	CR25	1
R27		NOT USED			
228	000103	IOK 5% 'SW CARBON	MULLARD	CR25	33
829	000103	IOK 5% /3W CARBON	MULLARD	CR25	-
230	000103	IOK 5% YOW CARBON	MULLARD	CR25	_
R31	000103	IOK 5% YOW CARBON	MULLARD	CR25	-
R32	000103	IOK 5% YOW CARBON	MULLARD	CR25	
R33	000103	IOK 5% /3W CARBON	MULLARD	CR25	-
R34	000103	IOK 5% YOW CARBON	MULLARD	CR25	
R35		NOT USED			_
R36	000103	IOK 5% 1/3W CARBON	MULLARD	CR25	
R37	000103	IOK 5% VAW CARBON	MULLARD	CR25	-
R38	000103	10k 5% Y3W CARBON	MULLARD	CR25	-
R39	000103	IOK 5% YOW CARBON	MULLARD	CR25	
R40	000103	IOK 5% 1/3W CARBON	MULLARD	CR25	
R41	000103	IOK 5% 1/3W CARBON	MULLARD	CR25	_
R42	000103	IOK 5% 1/3W CARBON	MULLARD	CR25	
R43	000103	IOK 5% YOW CARBON	MULLARD	CR25	
R44	000473	47k 5% /3W CARBON	MULLARD	CR25	8
R45	000103	IOK 5% /3W CARBON	MULLARD	CR25	
R46	000103	IOK 5% YOW CARBON	MULLARD	CR25	
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTU PART No.	URER'S	No. USED Per Assy.
R47	000103	10k 5% /3W CARBON	MULLARD	CR25		
R 4 8		NOT USED				-
<u>R49</u>		NOT USED				
R50	000820	82R 5% 'SW CARBON	MULLARD	CR25		2
R51	000820	82R 5% SW CARBON	MULLARD	CR25		-
R52	000101	100R 5% YOW CARBON	MULLARD	CR25		
R 53		NOT USED				
R54		NOT USED			,	-
R 55		NOT USED				-
R 56		NOT USED				_
R57		NOT USED				
R58	000103	10k 5% 'SW CARBON	MULLARD	CR25		-
259	000103	10k 5% Y3W CARBON	MULLARD	CR25		-
R60	000103	IOK 5% Y3W CARBON	MULLARD	CR25		-
R61	000103	IOK 5% 1/3W CARBON	MULLARD	CR25		-
R62		NOT USED				-
R63	000103	lok 5% Vaw CARBON	MULLARD	CR25		-
R64	000103	lok 5% 1/3W CARBON	MULLARD	CR25		-
R65	000103	IOK 5% /3W CARBON	MULLARD	CR25		
R66		NOT USED	`			-
R67	000103	lok 5% /3W CARBON	MULLARD	CR25		-
R68	000103	IOK 5% YOW CARBON	MULLARD	CR25		-
R69	000473	47k 5% 1/3W CARBON	MULLARD	CR25		
NOTES. SEE SHEET 2 FOR L	ATEST ISSUE			DATE DRAWN	datron	ELECTHONICS LTD
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFAC PART No.	TURER'S	No. USED Per Assy.
R70	000473	47k 5% Yaw CARBON	MULLARD	CR25		
R71	000103	IOK 5% YOW CARBON	MULLARD	CR25		
R72	000103	IOK 5% YOW CARBON	MULLARD	CR25		
R73	0 0 0 1 0 3	IOK 5% YOW CARBON	MULLARD	CR25		-
R74	000103	IOK 5% YOW CARBON	MULLARD	CR25		-
R75	000473	47k 5% 1/3W CARBON	MULLARD	CR25	<u></u>	-
R76	000473	47k 5% YOW CARBON	MULLARD	CR25		-
R77	000473	47k 5% V3W CARBON	MULLARD	CR25		-
R78	000473	47k 5% 1/3W CARBON	MULLARD	CR25		
R79	000473	47k 5% /3W CARBON	MULLARD	CR25		
R80	000103	IOK 5% "3W CARBON	MULLARD	CR25		
R81	000103	IOK 5% YOW CARBON	MULLARD	CR25		
R82	000108	IRO 5% 1/4W CARBON	MULLARD	CR25		2
R83	000108	IRO 5% 1/4W CARBON	MULLARD	CR25		-
R84	008035	33R 5% 21/2W W.W.	WELWYN	W2I		2
R85	008035	33R 5% 21/2W W.W.	WELWYN	W21		
ΑΝΙ	090090	47K ×8 2% NETWORK	AB	761-3-	47k	6
AN2	090095	47k ×4 2% NETWORK	BECKMAN	L08-3	- R47k	3
AN3	090090	47k ×8 2% NETWORK	AB .	761-3-	47k	
AN4	090095	47k x4 2% NETWORK	BECKMAN	LOB-3-	R47k	
AN5	090095	47k ×4 2% NETWORK	BECKMAN	L08-3-	R47k	-
ANG	090090	47K ×8 2% NETWORK	AB	761-3-	47k	-
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFAC PART No.	TURER'S	No. USED Per Assy.
AN7	090090	47k ×8 2% NETWORK	AB	761-3-4	47k ·	
AN 8	090090	47k x8 2% NETWORK	AB	761-3-4	47k	~
AN9	090090	47k ×8 2% NETWORK	АВ	761-3-4	47k	-
ANIO	090085	12K ×8 2% NETWORK	АВ	761-3-1	2k	3
ANII		NOT USED				
ANI2	090085	12k ×8 2% NETWORK	AB	761-3-	12k	
ANI3	090085	12k ×8 2% NETWORK	АВ	761-3-1	2k	-
	·····					
C1	140045	IF 20% IK5V POLYPROP	NORTRONICS (MFD)	N5C 202	27	1
<u>C2</u>	180050	150UF 385V AL. ELECT	MULLARD	052-5	8151	4
<u>C3</u>	180050	150 F 385Y AL. ELECT	MULLARD	052-5	8151	-
C <b>4</b>	180050	F 385V AL. ELECT	MULLARD	052-5	8,151	-
C5	180050	150 F 385V AL. ELECT	MULLARD	052-5	8151	
C6	104023	202F 20% IKV CER DISC	ITT	HDIG		2
C7	104023	2n2F 20% IKV CER DISC	117	HDIG		-
68	180049	330UF 100V AL. ELECT	ECC	SMVB		2
ເອ .	180049	330 F IOOV AL. ELECT	ECC	SMVB		
CIO	110013	100nF 20% 250V POLYESTER	MULLARD	C280AE	Plook	2
CII	110013	100nF 20% 250V POLYESTER	MULLARD	C280AE	Plook	-
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
CI2	104032	220 PF 10% 2KV CER DISC	ITT	Нроэ	1
CI3	102102	InF 10% 500V CER DISC	177	CDIO	3
CI4	102102	Inf 10% 500Y CER DISC	ITT	CDIO	-
C 15	102102	INF 10% 500V CER DISC	ITT	CDIO	
C16	110054	2201 10% 630V POLYESTER	WIMA	MKSA	2
C17	110054	2201 10% 630V, POLYESTER		MKS4	
C18		NOT FITTED			
C19		NOT FITTED			
C20		NOT FITTED			
CNI	104033	INF X7 20% 50V CAP NWK	SPRAGUE	470C7X7RIOZM5DG	3
CN2	104033	INF X7 20% 50V CAP NWK	SPRAGUE	470C7X7R102M5DG	-
CN3	104033	INF X7 20% SOV CAP NWK	SPRAGUE	470C7X7R 102M5DG	
CN4, CN5, CN6		NOT FITTED			· · · · · · · · · · · · · · · · · · ·
CNT, CNB		NOT FITTED	·		
DI	200002	IA SOV GP SI DIODE	FAIRCHILD	IN400I	2
D2	200002	IA SOV GP SI DIODE	FAIRCHILD	IN 4001	-
D3	200024	3A 143V GP SI DIODE	MOTOROLA	BY 255	8
D4	200024	3A IK3V GP SI DIODE	MOTOROLA	BY 255	'
D5	200024	3A IK3V GP SI DIODE	MOTOROLA	BY 255	-
DG	200024	3A IK3V GP SI DIODE	MOTOROLA	BY 2.55	· · · ·
D7-D10	200024	3A IK3V GP SI DIODE	MOTOROLA	Βγ255	
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTU PART No.	RER'S	No. USED Par Assy.
WI	209.014	AS 400V BRIDGE RECT	MICRO-ELECTRONICS	W004		I
RLI	330038	RELAY 2P N/0 2P N/C	SDS	52-L-6V	/	1
	370024-1	COMMON MODE CHOKE 5W	SIGA	SEE DRG		1
L2	370014	8µH 3A RF CHOKE	ERO	F1756-0	08-301	2.
L3	370014	BUH 3A RF CHOKE	ERO	F1756-00	08-301	-
L4	370001	IONH 0.85 S RF CHOKE	PLESSEY	58/10/001	/1,0	2
L5	370001	IOUH 0.85 & RF CHOKE	PLESSEY	58/10/0011	/10	-
	410361-1	DIODE LINK BOARD.				1
J4, J5, J7, J8, J9	605090-2	6+6 WAY PCB EDGE SKT	SEE DRG			. 8
	410348-2	PCB				1
	512999	7/-2 WHITE PTFE INS INV THE		TO BSG210	TYPEC	A/R
	560002	7/34 AWG CU. COV. STEEL CO-AX				A/R
	590031	HEATSHRINK SLEEVE \$ 3.2				A/R
J19, J31, J32, J33	604042	4 WAY .156" PLUG GD PL	MOLEX	09-72-2	041	6
J2, J3, J4, J6, J7	605087-2	24+24 WAY PCB EDGE SKT	SEE DRG			13
J3, J5, J8, J9	605088-2	18 + 18 WAY PCB EDGE SKT	SEE DRG	-		6
J2, J4, J6, J7, J8, J5	605089-2	12+12 WAY PCB EDGE SKT	SEE DRG			7
J5, J7, J8, J9	605091-2	6+6 WAY PCB EDGE SKT	SEE DRG			9
J7, J8, J9	605092-2	3+3 WAY PCB EDGE SKT	SEE DRG			_ 5
J30	605114-2	12 +12 WAY PCB EDGE SKT	SEE DRG			1
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612004-1 612027-1 617010	M3×4mm STANDOFF	0.100.0.1			Per Assy.
		DATRON	SEE DRO	<del>,</del>	13
617010	M3 × 8mm STANDOFF	DATRON	SEE DRG	÷	10
	NYLATCH PLUNGER 3/16"	HARTWELL CORP	HN3P-3	2-4-1	20
617011	NYLATCH GROMMET 3/16"	HARTWELL ORP	HN3G-3	2-1	20
620005	CLOVERLEAF PTFE INSUL.	SEALECTRO	FTE ISP 5	9	5
620006	SOLDER TURRET	HARWIN	H9001-	01	71
620007	TEST POINT TERMINAL	MICROVAR	TYPE C30	>	9
630036	STEATITE BEAD 18 SWG	PARK ROYAL PORCELAIN	Nº 1 . (	(SMALL)	-4
920116	FUSE IA 250V 20mm SLO-B	BELLING LEE	L2080A	/1	· 2
920116	FUSE IA 250V 20mm SLO-B	BELLING LEE	L2080A	/1	
920125	FUSE 2.5A 125V 7mm	LITTLE FUSE	275 02.	5	2
920125	FUSE 2.5A 125V 7mm	LITTLEFUSE	275 02	5	
920126	FUSE HOLDER 20mm PCB	BELLING LEE	L1426		2
605111	24 + 24 WAY . 1" PCB SKT	AMP	2-1415	92-4	3
612024-1	M3 X 12.7 M STANDOFF	DATRON	SEE DRO	\$	ļ
630024	STEATITE BEAD IG SWG	PARK ROYAL PORCELAI	N Nº 2 (	LARGE)	4
630131	CAPACITOR CLIP \$45 mm	Rs	543-00	68	1
512000	7/0.2 PTFE INSULATED BLACK	VIRE.			A/R
512111	7/0.2 PTFE INSULATED BROWN	WIRE.			A/R
512222	7/0.2 PTFE INSULATED RED	WIRE.			A/R
TEST ISSUE				datron	ELECTRONICS LTD
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	620005 620006 620007 630036 920116 920125 920125 920125 920126 605111 612024-1 630024 630131 512000 512111	620005       CLOVERLEAF PTFE INSUL.         620006       SOLDER TURRET         620007       TEST POINT TERMINAL         630036       STEATITE BEAD 18 SWG         920116       FUSE 1A 250V 20mm SLO-B         920125       FUSE 2.5A 125V 7mm         920125       FUSE 2.5A 125V 7mm         920126       FUSE 1A0LDER 20mm PCB         605111       24 + 24 WAY • 1" PCB SKT         612024-1       M3 X 12.7mm STANDOFF         630131       CAPACITOR CLIP Ø45 mm         512000       7/0.2 PTFE INSULATED BLACK         512111       7/0.2 PTFE INSULATED BROWN         512222       7/0.2 PTFE INSULATED RED	620005       CLOVERLEAF PTFE INSUL.       SEALECTRO         620006       SOLDER TURRET       HARWIN         620007       TEST POINT TERMINAL       MICROVAR         630036       STEATITE BEAD 18 SWG       PARK ROYAL PORCELAIN         920116       FUSE 1A 250V 20mm SLO-B       BELLING LEE         920116       FUSE 1A 250V 20mm SLO-B       BELLING LEE         920125       FUSE 2:SA 125V 7mm       LITTLE FUSE         920126       FUSE 1.32V 7mm       LITTLE FUSE         920126       FUSE 2:SA 125V 7mm       LITTLE FUSE         920126       FUSE HOLDER 20mm PCB       BELLING LEE         920126       FUSE HOLDER 20mm PCB       BELLING LEE         920126       FUSE HOLDER 30mm PCB       BELLING LEE         920126       FUSE HOLDER 20mm PCB       BELLING LEE         605111       24 + 24 WAY - 1" PCB SKT       AMP         612024-1       M3 X 12:7=m STANDOFF       DATRON         630131       CAPACITOR CLIP Ø45 mm       RS         512000       7/0-2 PTFE INSULATED BLACK WIRE.       S12222         512111       7/0-2 PTFE INSULATED RED       WIRE.         512222       7/0-2 PTFE INSULATED RED       WIRE. <td>620005       CLOVERLEAF PTFE INSUL.       SEALECTRO       FTE ISP 5         620006       SOLDER TURRET       HARWIN       H900I-         620007       TEST POINT TERMINAL       MICROVAR       TYPE C30         630036       STEATITE BEAD 18 SWG       PARK ROYAL PORCELAIN       Nº 1 · (         920116       FUSE IA 250V 20mm SLO-B       BELLING LEE       L2080A         920125       FUSE 2·5A 125V 7mm       LITTLE FUSE       275 02         920125       FUSE 2·5A 125V 7mm       LITTLE FUSE       275 02         920126       FUSE HOLDER 20mm PCB       BELLING LEE       L1426         605111       24 + 24 WAY · 1" PCB SKT       AMP       2-1415         612024-1       M3 X 12·7sm STANDOFF       DATRON       SEE DRG         512000       7/0·2 PTFE INSULATED BLACK WIRE.       543-00         512000       7/0·2 PTFE INSULATED BLACK WIRE.       MIRE.         512222       7/0·2 PTFE INSULATED BLACK WIRE.       MIRE.</td> <td>620005       CLOVERLEAF PTFE INSUL.       SEALECTRO       FTE ISP 59         620006       SOLDER TURRET       HARWIN       H9001-01         620007       TEST POINT TERMINAL       MICROVAR       TYPE C30         630036       STEATITE BEAD 18 SWG       PARK ROYAL PORCELAIN       Nº 1 · (sMA/L)         920116       FUSE 1A 250V 20mm SLO-B       BELLING LEE       L2080A/1         920125       FUSE 2-SA 125V 7mm       LITTLE FUSE       275 02.5         920126       FUSE 2-SA 125V 7mm       LITTLE FUSE       275 02.5         920126       FUSE 2-SA 125V 7mm       LITTLE FUSE       275 02.5         920126       FUSE 2-SA 125V 7mm       LITTLE FUSE       275 02.5         920126       FUSE HOLDER 20mm PCB       BELLING LEE       L1426         605111       24 + 24 WAY · 1" PCB 5KT       AMP       2- 141592- 4         612024-1       M3 X 12-7sm STANDOFF       DATRON       SEE DR3         630024       STEATITE BEAD 1G SWG       PARK ROYAL PORCELAIN       N° 2 (LARGE)         630131       CAPACITOR CLIP Ø45 mm       RS       543-068         512000       7/0-2 PTFE INSULATED BROWN       WIRE.       Integer         512111       7/0-2 PTFE INSULATED BROWN       WIRE.       Integer     &lt;</td>	620005       CLOVERLEAF PTFE INSUL.       SEALECTRO       FTE ISP 5         620006       SOLDER TURRET       HARWIN       H900I-         620007       TEST POINT TERMINAL       MICROVAR       TYPE C30         630036       STEATITE BEAD 18 SWG       PARK ROYAL PORCELAIN       Nº 1 · (         920116       FUSE IA 250V 20mm SLO-B       BELLING LEE       L2080A         920125       FUSE 2·5A 125V 7mm       LITTLE FUSE       275 02         920125       FUSE 2·5A 125V 7mm       LITTLE FUSE       275 02         920126       FUSE HOLDER 20mm PCB       BELLING LEE       L1426         605111       24 + 24 WAY · 1" PCB SKT       AMP       2-1415         612024-1       M3 X 12·7sm STANDOFF       DATRON       SEE DRG         512000       7/0·2 PTFE INSULATED BLACK WIRE.       543-00         512000       7/0·2 PTFE INSULATED BLACK WIRE.       MIRE.         512222       7/0·2 PTFE INSULATED BLACK WIRE.       MIRE.	620005       CLOVERLEAF PTFE INSUL.       SEALECTRO       FTE ISP 59         620006       SOLDER TURRET       HARWIN       H9001-01         620007       TEST POINT TERMINAL       MICROVAR       TYPE C30         630036       STEATITE BEAD 18 SWG       PARK ROYAL PORCELAIN       Nº 1 · (sMA/L)         920116       FUSE 1A 250V 20mm SLO-B       BELLING LEE       L2080A/1         920125       FUSE 2-SA 125V 7mm       LITTLE FUSE       275 02.5         920126       FUSE 2-SA 125V 7mm       LITTLE FUSE       275 02.5         920126       FUSE 2-SA 125V 7mm       LITTLE FUSE       275 02.5         920126       FUSE 2-SA 125V 7mm       LITTLE FUSE       275 02.5         920126       FUSE HOLDER 20mm PCB       BELLING LEE       L1426         605111       24 + 24 WAY · 1" PCB 5KT       AMP       2- 141592- 4         612024-1       M3 X 12-7sm STANDOFF       DATRON       SEE DR3         630024       STEATITE BEAD 1G SWG       PARK ROYAL PORCELAIN       N° 2 (LARGE)         630131       CAPACITOR CLIP Ø45 mm       RS       543-068         512000       7/0-2 PTFE INSULATED BROWN       WIRE.       Integer         512111       7/0-2 PTFE INSULATED BROWN       WIRE.       Integer     <

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ESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER		MANUFACTUF PART No.	RER'S	No. USED Per Assy.
	611006	M3 × 10mm POZI-PAN STEEL	ZN PL.			````	. 1
	611016	M3 × 8 mm POZI-PAN STEEL	ZN PL				1
1	613005	M3 INT. SHAKEPROOF					1
	613029	M3 WAVEY WASHER SS					1
	615002	M3 FULL NUT STEEL ZN PL					2.
	590001	SLEEVE , MAX.CABLE Ø3.	HELLERMANN EL	ECTRIC	H15 × 20m	m BLK HELSYN	2
	620003	SOLDER PIN	HARWIN		HEIOSAOI		5
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
	410167-3	PCB			1
	450540-1	CONNECTOR SUPPT. BRACK	ŦŢ		1
	450296-2	EARTH SCREEN			1
C1	101103	10 F 25% 250V CER DISC	177	CDIO.	1
J3-J4	604033	4 CCT POLARISING WAFER	MOLEX	22-29-2041 GOLD	2
J1, J2	605002	16 WAY DIL SOCKET	CA	CA- 105 - 1050	2
J27	605086	24 WAY PCB MNT RECEPTACL	E AMPHENOL	57-20240-8	1
	611004	M3X6 POZIPAN SCREW	GKN	ZINC PLATED	2
	612004	M3X4 STANDOFF VIG PLB	HARWIN	C5 2116.B	2
	612008	M3XG STANDOFF 16 PLB	CAMBION	350-5138-09-07	2
	613029	M3 CRINKLE WASHER			2
51	700046	SWITCH & POSN D.I.L S.P.S.T	AMP. OR CONTRAVES	435166-4 OR DS5-6	1
	700047	SWITCH COVER	AMP	435238-3	1 .
52	700080	SP3P SLIDE PC.8 MNT	ALCO	SLS - 131 - PC	L
553	700081	SPOT SLIDE P.C.B MNT	ALCO	SLS - 121 -PC	I
	614003	STANDOPF 3-3 CLEARX Gmm BRASS	HARWIN	C5 2117 - A	2
	900004	SILICONE RUBBER COMPONE	RS.	544-31	A/R
	611007	M3XGmm POZI-CSK SCREW	ZN. PL.		2
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COMP LAYOUT.	480640	1	<u> </u>	1.1	1.2						Γ														T																
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SCHEMATIC	430640	1	<u>.</u>						T															T																	_
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
CI	120037	330pF 20% 400V POLYCAR	WIMA	FKC3.	1
cz	104037	22pF 10% 2KV CER DISC	STC	HDIO	2
C3	104037	22pF 10% 2KV CER DISC	STC	HDIO	-
C4	104032	220PFIO/ 2KY CER DISC	STC	HDIO	3
C5	104032	220pF 10/ 2KY CER DISC	STC	HDIO	-
C6	104032	220pf 10% 2KV CER DISC	STC	HDIO	-
L1	370027	47NH RF CHOKE	SIGMA	5030-10-2533-10	2
L2	370027	47 H RF CHOKE	SIGMA	SC30-10-2533-10	-
RLI	330029	RELAY 2P2W	SDS	DS2E DC 24V	-
	400576-2	FRONT OUTPUT CABLE ASSY			2
FBI	920181	FERRIE BEAD	MULLARD	FX4029	2
FB2	520181	FERRITE BEAD	MULLARD	FX4029	-
FB3	920145	FERRITE BEAD	MULLARD	FX4 026	4
FB4	920145	FERRITE BEAD	MULLARD	FX402G	-
F85	920145	FERRITE BEAD	MULLARD	FX4026	-
FBG	920145	FERRITE BEAD	MULLARD	FX4026	-
	+10309 -6	P.C.B.	and a second	1	1
	450269-1	TERMINAL PLATE	DATRON	SEE DRAWING A4	1
	540002	22 SWG TINNED CU. WIRE	-		A/R
	590032	HEATSHRINK SLEEVING	4.8Ø		A/R
	620003	SOLDER PIN	HARWIN	H2105A01	13
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S	No. USED Per Assy.
		-			
	400686-1	SAFETY TERMINAL ASSY . BLACK	DATRON	SEE DRAWING A4	1
	400687-1	SAFETY TERMINAL ASSY RED	DATRON	SEE DRAWING A4	1
	400688-1	SAFETY TERMINAL ASSY. BRN	DATRON	SEE DRAWING A4	1
	400689-1	SAFETY TERMINAL ASSY. BLU.	DATRON	SEE DRAWING A4	1
	400690-1	SAFETY TERMINAL ASSY. WHI	DATRON	SEE DRAWING A4	1
	400691-1	SAFETY TERMINAL ASSY, GRN.	DATRON	SEE DRAWING A4	1
	613009	M3 SOLDER TAG.			1
	613021	M4 SHAKEPROOF WASHER.			12
	613020	M4 WASHER STEEL	ZN PL		୍ଦ
	613039	M2 SOLDER TAG.	ROSS COURTNEY	201002	1
		-			
	400184	EARTH BRAID ASSY	DATRON		1
	512999	7/0.2 PTFE INSUL, WHITE	WIRE		0.18M
	521006	16/0.2 PVC INS. GRN/YLW	WIRE		A/R
	590001	SLEEVE \$3.0	HELLERMANN.	H15 x 20	7
	530006	HEAT SHRINK SLEEVE	\$ 2·4		A/R
	512444	7/0.2 PTE INSUL. YELLOW	WIRE		0.14 M
	512888	7/0.2 PTFE INSUL. GREY.	WIRE.		0.14N
	590003.	HEATSHRINK SLEEVE \$	6.4		A/R
	590017	HEATSHRINK CABLE MARKE	<b>g</b> (`1´)		1
	590018	HEATSHRINK CABLE MARK			
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACT PART No.	URER'S	No. USED Per Assy.
	400446-9	4200 SINE SOURCE PCB	ASSY.			1
	400663-4	4700 A.C. PCB ASSY.				1
	400618-3	4700 POWER AMP PCBA	55Y.			1
	400557-1	1700 CHASSIS ASSY.				1
	400 5 59- 1	4700 DIGITAL PCB ASS	Y			1
	400652 - 2	4700 REFERENCE DIVIDE	R PCB ASSY.			· 1
	400653 - 1	4700 38V PSU. PCB A	ssy.			1
	400536-3	4700 D.C. PCB. ASSY.				1
	400554 - 4	4200 POWER SUPPLY PCB	ASSY (IN GUARD).			1
	400561 - 2	4200 POWER SUPPLY PCB	ASSY (OUT GUARD).			I
	400648-1	4700 ANALOGUE INTERFA	E PCB ASSY.			1
	400539-7	4200 PA (NEG) HS ASSY				1
	400637-1	4700 PA (POS) HS ASSY				
·	400 540-6	4200 PSU/I HS ASSY				<u> </u>
						1
	450231-4	CARD SUPPORT BRACKE	r			2
	450233/M-1	4700 INSTRUCTION CA	RD			<u> </u>
	450273-2	TOP COVER				1
	450274-2	BOTTOM COVER				1
						1
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ESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
	450400-1	MOULDED FOOT		-	6
	450430-2	4200 HEATSINK RETAINER			1
	410288-1	IALINK PCB	· · · · · · · · · · · · · · · · · · ·		1
	510222	7/0.2 PVC INSULATED R	ED WIRE		A/R
	Encon				
	590001		O. HELLERMANN ELECTI		· · · · ·
		SLEEVE MAX. CABLE Ø G		H30x25. BLK.	A/R
	<u>arccoc</u>	CLEANING FLUID	RS		
	920101	BATTERY LITHIUM AA	TADIRAN	TL 2100 SOLDER TAGS	
	611005	M3X Gmm SLOT PAN STEEL	ZN PL		12
	611003	M3x Gmm POZI-CSK STEEL	ZN PL		10
	611016	M3XBmm POZI PAN STEEL	ZN PL		8
	611038	MAXIZMM SKTCSK HTS.	CHEM. BLK.		16
	611058	MAXONN POZI-CSK STEEL	ZN PL		20
	611012	M3×12mm POZI-CSK STEEL	ZN PL		6
	611012	WISAIZMM FULLEUSK SIEEL			
	613005	M3 INT SHAKEPROOF	ZN PL		21
	613007	M3 WASHER STEEL	ZN PL		8
	630122	P.C.B BJECTOR BLUE	RICHCO	CBE	1
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
				1	
	400462-4	MAINS SWITCH CABLE ASSY	1		1
	400463-2	DIGITAL PSU CABLE ASSY	1		
	400471-1	RIBBON CABLE ASSY			2
	400636-1	4700 REAR PANEL ASSY			1
	400604-1	4700 MOTHER PCB ASSY			1
	400558-1	4700 FRONT PLB ASSY	-		1
	400640-1	TERMINAL PCB ASSY	DATRON		1
			:		
	450550-1	GUARD SHEET STEEL	:		1
	400541-4	4000 MAINS TX ASSY	6		1
	400560-1	4200 IN/GU, PSU. CABLE ASS	4.		1
	450467-1	FOAM GASKET.			1
	450265-4	MOULDED CHASSIS			1
	450478-1	4700 FRONT PANEL			11
	450542-1	MADE IN ENGLAND BADGE.			- 1
	450271-1	FILTER GRILLE			1
	450272-1	TX BOLT PLATE			2
	450277-1	FOAM FILTER	,		
-	450280-1	HANDLE			2
	450477-1	GUARD/EARTH SPACER WASHE	R.		1
	450293-1	PCB SUPPORT.			3
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTUI PART No.		No. USED Per Assy,
	450300-1	REAR SPACER				2
	450301-2	EARTH BRACKET				!
	450310-1	SIDE EXTRUSION R.H.				1
	450311-1	SIDE EXTRUSION L.H.				!
	450316-1	P.S. GUARD SCREEN				
	450452-3	CABLE BRIDGE	· · · · · · · · · · · · · · · · · · ·			1
	450406-1	404 PSU BRACKET				
	450414-2	EARTH SHEET				2
	450415-2	GUARD SHEET ALUM.	1			I
	450418 - 1	M5 BOLT SPACER	•			2
	450549-1	PCB GUARD SCREEN STEEL.				1
	450431-1	4200 HEATSINK GU. SCREE	Ν.			
	450436-1	TRANSFORMER BOLT PLA	TE			
	450446-1	PCB GUARD SCREEN AL	M			5
	450447 -	PCB EARTH SCREEN		•		· 1
	512999	7/0.2 PTE INSUL, WIRE.	WHITE			0.08M
	510999	7/0.2 PVC INSUL. WIRE.	WHITE.			A/R
						A/0
	590006	SLEEVE HEATSHRINK \$ 2.4				A/R3
	590013	STD CABLE TIE 3.6X140	al			
NOTES. SEE SHEET I FOR L	ATENT 100115		• •	DATE 6.8.85 URAWN /[.	datron	ELECTRONICS LTD
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
	560002	CO-AX CABLE 100 pf/M			0.8M
	540009	EARTH BRAID	HEAD BRAIDING LTD.		50mm
	590031	\$ 3.2 HEATSHRINK SLEEVE			A/R
	606005	DIL SOCKET CLIP IG W	CA	CAIG - 200- DL	2
	611004	M3X Gum POZI - PAN STEEL	ZN PL		34
-	611008	M3× 10 MM POZI-CSK STEEL	ZN PL		4
	611054	M3 × Gom SLOT - CSK STEEL	ZN PL		1
	611015	M3x Bun POZI-CSK STEEL	ZN PL		2
	611016	M3X 8mm POZI- PAN STEEL	ZN PL		15
	611023	M2.5x 10mm POZI - PAN STEEL	ZN PL		2
	611038	M4X12 WW SKTCSK HTS.	CHEM. BLK.		۵
	611047	M5x 12mm POZI- CSK STEEL	ZN PL		.8
	611078		STEEL ZN PL BLACK CONV.	LANDLIN DIP	8
	611051	MAX HOMM HEX STEEL	ZNPL		4
· .	611045	MBX 65 MM POZI-PAN STEEL	ZN PL		2
	590032	\$4.8 HEATSHRINK SLEEVE			A/R.
	000110	M3X10mm POZI-PAN STEEL	ZN PL.		1
	613005	M3 INT SHAKE PROOF		· · · · · · · · · · · · · · · · · · ·	24
	613007	M3 WASHER STEEL	ZNPL		5
	613009	ABA SOLDER TAG BRASS	TIN PL		2
	613012	M2.5 WASHER STEEL	ZN PL		4
	613013	M5 WASHER STEEL	ZN PL		4
	613014	M2.5 INT SHAKE PROOF	· · ·		2
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DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
613025	MA WASHER STEEL	ZN PL		4
613028	M5 INT SHAKE PROOF			2
613029	M3 CRINKLE WASHER	5.5.	•	29
613027	MZ INT SHAKEPROOF			1
C. 5 4 5 0				4
				2
615007	M5 FULL NUT STEEL	ZNPL		
615015	M8 NYLOCK NUT STEEL	ZN PL		4
615016	M2 FULL NUT STEEL	ZN PL		
617013	\$2.4 BP RIVET DOMED HD	GEORGE TUCKER EYELET	TAP/D/33/BH	2
630003	P' CLIP & A.Bum	SES	CN5	2
630004	P' CLIP & G.AMM	SES	CNG	3
630042	CABLE CLIP	RICHCO	CFCC-8	11
630029	TAPE DOUBLE SIDED 1/4 x 1/32	3M	4032	AR
				A/R
	POLYESTER TAPE 50mm WIDE			A/R
630175	PCB GUIDE	RICHCO	RCGI	2
200009	LOCKING COMPOUND	LOCTITE	222	A/R.
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		ci	4/00	ASSEMBLY
	PART No. GI3025 GI3028 GI3029 GI3027 GI5007 GI5007 GI5015 GI5015 GI5016 GI7013 G30004 G30042 G30029 G30167 G30168 G30175	PART No.         G13025       M8 WASHER STEEL         G13028       M5 INT SHAKE PROOF         G13029       M3 CRINKLE WASHER         G13027       M2 INT SHAKE PROOF         G13027       M2 INT SHAKEPROOF         G13027       M2 INT SHAKEPROOF         G15002       M3 FULL NUT STEEL         G15007       M5 FULL NUT STEEL         G15015       M8 NYLOCK NUT STEEL         G15016       M2 FULL NUT STEEL         G15013       Ø2.4 &P RIVET DOMED HD         G30003       P' CLIP Ø G4.8mm         G30004       P' CLIP Ø G4.8mm         G30029       TAPE DOUBLE SIDED 1/4X 1/32         G30167       FOAM TAPE GmmT X 9mm W         G30168       POLYESTER TAPE 50mm WIDE         G30175       PCB GUIDE         900009       LOCKING COMPOUND	PART No.         MANUFACTURER           G13025         M8         WASHER STEEL         ZN         PL           G13028         M5         INT         SHAKE PROOF         S.S.           G13029         M3         CRINKLE WASHER         S.S.           G13027         M2         INT         SHAKEPROOF           G13027         M2         INT         SHAKEPROOF           G15002         M3         FULL         NUT         STEEL           G15007         M5         FULL         NUT         STEEL         ZN           G15015         M8         NYLOCK         NUT         STEEL         ZN         PL           G15016         M2         FULL         NUT         STEEL         ZN         PL           G17013         Ø2:4         RP         River         Domeb         HD         Geordse         Tucker         eyblet           G30003         P'         CLIP Ø         Ø:4:8         SES         SES         G30004         P'         CLIP         Richco           G30029         TAPE         DUBLE SIDED 1/4 X 1/32         3M         SES         SM         SM           G301607         FOAM TAPE         Gaunt x 3	PART No.         MANUFACTURER         PART No.           G13025         M8 WA\$HER STEEL         ZN PL

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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
OPTION 30	400555 - 8	CURRENT PCB ASSY	DATRON.		A/R
OPTION 90.	440094-1	RACK MOUNTING KIT.	DATRON.		A/R
OPTION 42.	440117-3	REAR OUTPUT KIT.	DATRON.		A/R
OPTION 80.	440096 - 1	115V GOH KIT	DATRON.		A/R
OPTION 20./27	400614-1	CURRENT / OHMS PCB ASS	DATRON.		A/R
OPTION 10/17	440136-1	HIGH VOLTAGE KIT.	DATRON.		A/R
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
	400184-2	TAG + BRAID ASSY			1
	400439-3	INTERCONNECTION PCB. ASSY	DATRON		1
	400641-1	CAL. I/O PORT CABLE ASSY	DATRON		1
	450268-6	REAR PANEL			1
	450309-2	LEEE MOUNTING SCREW			2
	450541-1	BNC ADAPTOR PLATE			1
	510333	7/-2 PVC INS (ORANGE) WIRE			550 mm
	5109999	7/2 PVC INS (WHITE) WIRE			250mm
-				-7	
	530000	24/2 PVC INS (BLACK) WIRE		-	100 mm
	530111	24/2 PVC INS (BROWN) WIRE			110 mm
	530222	24/2 PVC INS (RED) WIRE			120
	530333	24/2 PVC INS (ORANGE) WIRE			120 mm
	530444	24/2 PVC INS (YELLOW) WIRE			110 mm
	530555	24/.2 PVC INS (GREEN) WIRE			130
	530666	24/2 PVC INS (BLUE) WIRE			110mm
	530777	24/2 PVC INS (VIOLET) WIRE			115mm
	530888	24/2 PVC INS (GREY) WIRE			120
	530 999	24/2 PVC INS (WHITE) WIRE			110

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SEE SHEET I FOR LATEST ISSUE	DHAWN IL:	TITLE ATOO
	CHECKED	REAR PANEL ASSY
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DAIL		DRAWING 400636 SILLET
СИКО	DATE	NUMBER 400030 2 of 4

DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
	590001		HELLERMANN ELECTRIC	HI5 × 20 BLK, HELSYN	3
	590029	HEATSHRINK SLEEVE. POLYOLEFIN	HELLERMANN	SFM9-3BK	40 mm
	590031	HEATSHRINK Ø3.2 YELLOW			275 mm
	500005	SLEEVE MAX CABLE \$4.0	HELLERMANN ELECTRIC	HON 20 BLK. HELSYN.	5
	601001	BNC 50& BULKHEAD SKT.	GREENPAR	GE350275	1
	605051	4-WAY POLARISED SOCKET	MOLEX	22-01-2045	1
	605 057	CRIMP TERMINAL	MOLEX	4809-GL	2
	605135	6-WAY CHASSIS MNT. 0.093"SKT	MOLEX	03-09-1061	2
P	605136	0.093" MALE CRIMP TERM.GD	. MOLEX	02-09-6123	5
	605137	0.093" FEMALE CRIMP TERM. GD	MOLEX	02-09-5123	5
	606013	D' CONN. JACKSCREW	T+ B ANSLEY	609-004	I PAIR
an i shinal kila filik Paalikashap kassingan	606014	D' CONN. JACKSOCKET	T+B ANSLEY	609-006	I PAIR
	611005	SCREW M3×12mm STEEL	POZI PAN ZINC PLATED GK	4	1
	611016	SCREW M3 × 8mm STEEL	POZIPAN ZINC PLATED GKN		4
	611017	SCREW M3×16mm STEEL	POZIPAN ZINC PLATED GKN		2
	611049	SCREW M4 × 20mm STEEL	POZIPAN ZINC PLATED GKN	· ·	4
	613005	WASHER M3 INT/SHAKEPROOF	STEEL ZINC PLATED GK	N	7
	613007	M3 FLAT STEEL WASHER	ZINC PLATED GK	N	2
	613009	SOLDER TAG 4BA			1
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DESIGNATOR	DATRON PART No.	DESCRIPTION	PRINCIPAL MANUFACTURER	MANUFACTURER'S PART No.	No. USED Per Assy.
	613021	M4 INT SHAKEPROOF			4
	615002	M3 FULL NUT STEEL ZN PL			3
	615011	M4 FULL NUT STEEL ZN PL			4
	630133	HOLE PLUG 14" BLACK	HEYCO	DP250	6
	700071	SWITCH IPOLE KEY	LORLIN		1
	6000C	LOCKING COMPOUND	LOCTITE	270	A/R
	920150	FAN 119mm 115V BALL-B	REDPOINT.	RCF 162/115	1
	920086	POWER INPUT MODULE	POTTER	7100-0002	1
	950098	FUSE 3A 250V 14 510-8	LITTLEFUSE	313 003	1
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SEE SHEET 2 FOR LATEST ISSUE	ORAWN [[	^{117LE} 4700
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DESIGNATOR	DATRON PART No.	DESCRIPTION .	PRINCIPAL MANUFACTURER	MANUFACTURER'S PĀRT No.	No. USED Per Assy.
MIB	290151-3	2532 EPROM PROGRAMMED	DATRON.	SEE DRG.	1
M19	290152-3	2764 EPROM PROGRAMMED	DATRON.	SEE DRG.	1
M20	290153-3	2764 EPROM PROGRAMMED	DATRON.	SEE DRG.	1
MZI	290154-3	2764 EPROM PROGRAMMED	DATRON.	SEE DRG.	1
	400556-1	4700 MAIN ASSEMBLY.			1
	400614-1	CURRENT / OHMS ASSE	MBLY.		1
	420093-3	RATING LABEL.			1
	440136-1	HIGH VOLTAGE KIT.			<u>,  </u>
	450307-Z	PACKING BOX			1
	450367-1	POLAROID			2
	450583-1	4705 OVERLAY.		v	1
	630109	2.5mm A/F HEXAGON KEY	UNBRAKO	2.5mm A/F	1
	630163	POLYTHENE BAG GUSSETTED.	ABBOTTS.	18"x 28" x42". 500g	1
	850054 - 1	4705 USERS HANDBOOK			1
	850063-1	4705 SERV. HANDBOOK	VOL I		1
	850065-1	4705 SERV. HANDBOOK	VOL II		1
	850908-	4700 IEEE CARD			1
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NOTES. SEE SHEET 2 FOR LA	TEST ISSUE			NOV. AG. datron	ELECTRONICS LTD
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